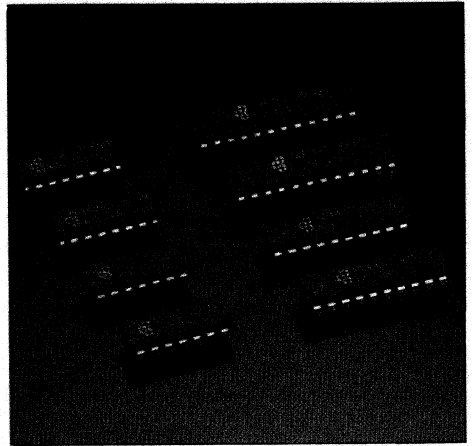


SAMSUNG

**High Performance
CMOS Logic
Data Book**



1987

INTRODUCTION

Samsung Semiconductor is a broad-line manufacturer of semiconductors that range from VLSI circuits such as memories (DRAM, SRAM, EPROM and EEPROM), microprocessors, gate arrays and programmable logic to transistors, linear circuits and telecommunications products.

The KS54/74AHCT and the KS54/74HCTLS high-performance CMOS logic families are Samsung's entry into the general purpose digital logic area.

The KS54/74AHCT advanced high-speed CMOS family is designed to provide performance equivalent to or better than that of the bipolar 54/74ALS (Advanced Low-power Schottky) family with the additional CMOS advantages of low power dissipation and high noise immunity. The AHCT parts can therefore be used as direct plug-in replacements for their ALS counterparts (and in most applications for FAST and Schottky) and improve the system performance.

The 54/74HCTLS high-speed CMOS family offers similar benefits as a replacement for industry-standard 54/74LS (Low-power Schottky), 54/74HCT and 54/74HC. While meeting all of the HCT electrical specifications, it also provides improved speed and drive capability, so that LS parts can be replaced with no performance degradation.

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High Performance CMOS Logic Data Book

KS54/74AHCT
Advanced High-Speed CMOS

KS54/74HCTL
High-Speed CMOS

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| KS54/74HCTLS664 | Octal Bus Transceivers with Parity | 656 |
| KS54/74HCTLS665 | Octal Bus Transceivers with Parity | 656 |
| KS54/74HCTLS670 | 4-By-4 Register Files with 3-State Outputs | 660 |
| KS54/74HCTLS679 | 12-Bit Address Comparators | 664 |
| KS54/74HCTLS680 | 12-Bit Address Comparators | 664 |
| KS54/74HCTLS682 | 8-Bit Magnitude Comparators | 669 |
| KS54/74HCTLS684 | 8-Bit Magnitude Comparators | 669 |
| KS54/74HCTLS686 | 8-Bit Magnitude Comparators | 669 |
| KS54/74HCTLS688 | 8-Bit Identity Comparators | 674 |
| KS54/74HCTLS689 | 8-Bit Identity Comparators with Open-Drain Outputs | 674 |
| KS54/74HCTLS793 | Octal Latches with Readback | 677 |
| KS54/74HCTLS794 | Octal Registers with Readback | 677 |
| KS54/74HCTLS821 | 10-Bit Bus Interface Registers with 3-State Outputs | 681 |
| KS54/74HCTLS822 | 10-Bit Bus Interface Registers with 3-State Outputs | 681 |
| KS54/74HCTLS823 | 9-Bit Bus Interface Registers with 3-State Outputs | 685 |
| KS54/74HCTLS824 | 9-Bit Bus Interface Registers with 3-State Outputs | 685 |
| KS54/74HCTLS825 | 8-Bit Bus Interface Registers with 3-State Outputs | 689 |
| KS54/74HCTLS826 | 8-Bit Bus Interface Registers with 3-State Outputs | 689 |
| KS54/74HCTLS841 | 10-Bit Bus Interface D-Type Latches with 3-State Outputs | 693 |
| KS54/74HCTLS842 | 10-Bit Bus Interface D-Type Latches with 3-State Outputs | 693 |
| KS54/74HCTLS843 | 9-Bit Bus Interface D-Type Latches with 3-State Outputs | 697 |
| KS54/74HCTLS844 | 9-Bit Bus Interface D-Type Latches with 3-State Outputs | 697 |
| KS54/74HCTLS4049 | Hex Inverting Logic Level Down Converters | 701 |
| KS54/74HCTLS4050 | Hex Logic Level Down Converters | 701 |



PRODUCT GUIDE

2. Functional Selection Guide

| Function Category | Part Number KS54/74AHCT KS54/74HCTLS | Description | Package |
|--------------------------|---|--|---------|
| Gates and Inverters | 00 | Quad 2-Input NAND Gates | 14 DIP |
| | 01 | Quad 2-Input NAND Gates with Open-Drain Outputs | 14 DIP |
| | 02 | Quad 2-Input NOR Gates | 14 DIP |
| | 03 | Quad 2-Input NAND Gates with Open-Drain Outputs | 14 DIP |
| | 04 | Hex Inverters | 14 DIP |
| | 05 | Hex Inverters with Open-Drain Outputs | 14 DIP |
| | 08 | Quad 2-Input AND Gates | 14 DIP |
| | 09 | Quad 2-Input AND Gates with Open-Drain Outputs | 14 DIP |
| | 10 | Triple 3-Input NAND Gates | 14 DIP |
| | 11 | Triple 3-Input AND Gates | 14 DIP |
| | 12 | Triple 3-Input NAND Gates with Open-Drain Outputs | 14 DIP |
| | 14 | Hex Schmitt-Trigger Inverters | 14 DIP |
| | 20 | Dual 4-Input NAND Gates | 14 DIP |
| | 21 | Dual 4-Input AND Gates | 14 DIP |
| | 22 | Dual 4-Input NAND Gates with Open-Drain Outputs | 14 DIP |
| | 27 | Triple 3-Input NOR Gates | 14 DIP |
| | 32 | Quad 2-Input OR Gates | 14 DIP |
| | 51 | Dual AND-OR-Invert Gates | 14 DIP |
| | 58 | Dual AND-OR Gates | 14 DIP |
| | 86 | Quad 2-Input Exclusive-OR Gates | 14 DIP |
| 132 | Quad 2-Input NAND Gates with Schmitt-Trigger Inputs | 14 DIP | |
| 133 | 13-Input NAND Gates | 16 DIP | |
| 266 | Quad Exclusive-NOR Gates with Open-Drain Outputs | 14 DIP | |
| Buffers and Line Drivers | 125 | Quad Buffers with 3-State Outputs | 14 DIP |
| | 126 | Quad Buffers with 3-State Outputs | 14 DIP |
| | 210 | Octal Buffers and Line Drivers with 3-State Outputs | 20 DIP |
| | 240 | Octal Buffers and Line Drivers with 3-State Outputs | 20 DIP |
| | 241 | Octal Buffers and Line Drivers with 3-State Outputs | 20 DIP |
| | 244 | Octal Buffers and Line Drivers with 3-State Outputs | 20 DIP |
| | 365 | Hex Bus-Drivers with 3-State Outputs | 16 DIP |
| | 366 | Hex Bus-Drivers with 3-State Outputs | 16 DIP |
| | 367 | Hex Bus-Drivers with 3-State Outputs | 16 DIP |
| | 368 | Hex Bus-Drivers with 3-State Outputs | 16 DIP |
| | 465 | Octal Buffers and Line Drivers with 3-State Outputs | 20 DIP |
| | 466 | Octal Buffers and Line Drivers with 3-State Outputs | 20 DIP |
| | 467 | Octal Buffers and Line Drivers with 3-State Outputs | 20 DIP |
| | 468 | Octal Buffers and Line Drivers with 3-State Outputs | 20 DIP |
| 540 | Octal Buffers and Line Drivers with 3-State Outputs | 20 DIP | |
| 541 | Octal Buffers and Line Drivers with 3-State Outputs | 20 DIP | |
| Flip-Flops | 73 | Dual J-K Negative-Edge-Triggered Flip-Flops with Clear | 14 DIP |
| | 74 | Dual D-Type Positive-Edge-Triggered Flip-Flops with Preset and Clear | 14 DIP |
| | 76 | Dual J-K Negative-Edge-Triggered Flip-Flops with Preset and Clear | 16 DIP |
| | 78 | Dual J-K Negative-Edge-Triggered Flip-Flops with Preset, Common Clear and Common Clock | 14 DIP |
| | 107 | Dual J-K Negative-Edge-Triggered Flip-Flops with Clear | 14 DIP |
| | 109 | Dual J-K Positive-Edge-Triggered Flip-Flops with Preset and Clear | 16 DIP |
| | 112 | Dual J-K Negative-Edge-Triggered Flip-Flops with Preset and Clear | 16 DIP |
| | 173 | 4-Bit D-Type Registers with 3-State Outputs | 16 DIP |
| | 174 | Hex D-Type Flip-Flops with Clear | 16 DIP |
| | 175 | Quad D-Type Flip-Flops with Clear | 16 DIP |

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| Function Category | Part Number KS54/74AHCT KS54/74HCTLS | Description | Package |
|---|---|--|---------|
| Flip-Flops | 273 | Octal D-Type Flip-Flops with Clear | 20 DIP |
| | 374 | Octal D-Type Flip-Flops with 3-State Outputs | 20 DIP |
| | 377 | Octal D-Type Flip-Flops with Clock Enable | 20 DIP |
| | 399 | Quad 2-Port Registers | 16 DIP |
| | 534 | Octal D-Type Flip-Flops with 3-State Outputs | 20 DIP |
| | 564 | Octal D-Type Flip-Flops with 3-State Outputs | 20 DIP |
| | 574 | Octal D-Type Flip-Flops with 3-State Outputs | 20 DIP |
| | 670 | 4-By-4 Register Files with 3-State Outputs | 16 DIP |
| | 794 | Octal Register with Readback | 20 DIP |
| | 821 | 10-Bit Bus Interface Registers with 3-State Outputs | 24 DIP |
| | 822 | 10-Bit Bus Interface Registers with 3-State Outputs | 24 DIP |
| | 823 | 9-Bit Bus Interface Registers with 3-State Outputs | 24 DIP |
| | 824 | 9-Bit Bus Interface Registers with 3-State Outputs | 24 DIP |
| | 825 | 8-Bit Bus Interface Registers with 3-State Outputs | 24 DIP |
| | 826 | 8-Bit Bus Interface Registers with 3-State Outputs | 24 DIP |
| Latches | 259 | 8-Bit Addressable Latches | 16 DIP |
| | 373 | Octal D-Type Transparent Latches with 3-State Outputs | 20 DIP |
| | 533 | Octal D-Type Transparent Latches with 3-State Outputs | 20 DIP |
| | 563 | Octal D-Type Transparent Latches with 3-State Outputs | 20 DIP |
| | 573 | Octal D-Type Transparent Latches with 3-State Outputs | 20 DIP |
| | 793 | Octal D-Type Transparent Latches with Readback | 20 DIP |
| | 841 | 10-Bit Bus Interface D-Type Latches with 3-State Outputs | 24 DIP |
| | 842 | 10-Bit Bus Interface D-Type Latches with 3-State Outputs | 24 DIP |
| | 843 | 9-Bit Bus Interface D-Type Latches with 3-State Outputs | 24 DIP |
| 844 | 9-Bit Bus Interface D-Type Latches with 3-State Outputs | 24 DIP | |
| Multiplexers | 151 | 1 of 8 Data Selectors/Multiplexers | 16 DIP |
| | 153 | Dual 1 of 4 Data Selectors/Multiplexers | 16 DIP |
| | 157 | Quad 2-Line to 1-Line Data Selectors/Multiplexers | 16 DIP |
| | 158 | Quad 2-Line to 1-Line Data Selectors/Multiplexers | 16 DIP |
| | 251 | 1-of-4 Data Selectors/Multiplexers with 3-State Outputs | 16 DIP |
| | 253 | Dual 1-of-4 Data Selectors/Multiplexers with 3-State Outputs | 16 DIP |
| | 257 | Quad 2-Line to 1-Line Data Selectors/Multiplexers with 3-State Outputs | 16 DIP |
| | 258 | Quad 2-Line to 1-Line Data Selectors/Multiplexers with 3-State Outputs | 16 DIP |
| | 352 | Dual 1-of-4 Data Selectors/Multiplexers | 16 DIP |
| 353 | Dual 1-of-4 Data Selectors/Multiplexers with 3-State Output | 16 DIP | |
| Shift Registers | 164 | 8-Bit Serial-In/Parallel-Out Shift Registers | 14 DIP |
| | 165 | 8-Bit Parallel-IN/Serial-Out Shift Registers | 16 DIP |
| | 166 | 8-Bit Parallel-IN/Serial-Out Shift Registers | 16 DIP |
| | 194 | 4-Bit Bidirectional Universal Shift Registers | 16 DIP |
| | 195 | 4-Bit Bidirectional Universal Shift Registers | 16 DIP |
| | 299 | 8-Bit Universal Shift/Storage Registers with 3-State Outputs | 20 DIP |
| | 595 | 8-Bit Shift Registers with Output Latches | 16 DIP |
| | 596 | 8-Bit Shift Registers with Output Latches | 16 DIP |
| 597 | 8-Bit Shift Registers with Input Latches | 16 DIP | |
| Transceivers/ Registered Transceivers | 242 | Quad Bus Transceivers with 3-State Outputs | 14 DIP |
| | 243 | Quad Bus Transceivers with 3-State Outputs | 14 DIP |
| | 245 | Octal Bus Transceivers with 3-State Outputs | 20 DIP |
| | 640 | Octal Bus Transceivers with 3-State Outputs | 20 DIP |
| | 643 | Octal Bus Transceivers with 3-State Outputs | 20 DIP |
| | 645 | Octal Bus Transceivers with 3-State Outputs | 20 DIP |
| 646 | Octal 3-State Bus Transceivers with Registers | 24 DIP | |

PRODUCT GUIDE

| Function Category | Part Number KS54/74AHCT KS54/74HCTLS | Description | Package |
|------------------------|--|--|---------|
| | 648 | Octal 3-State Bus Transceivers with Registers | 24 DIP |
| | 651 | Octal 3-State Bus Transceivers with Registers | 24 DIP |
| | 652 | Octal 3-State Bus Transceivers with Registers | 24 DIP |
| | 658 | Octal Bus Transceivers with Parity | 24 DIP |
| | 659 | Octal Bus Transceivers with Parity | 24 DIP |
| | 664 | Octal Bus Transceivers with Parity | 24 DIP |
| | 665 | Octal Bus Transceivers with Parity | 24 DIP |
| Counters | 160 | Synchronous 4-Bit Decade Counters | 16 DIP |
| | 161 | Synchronous 4-Bit Binary Counters | 16 DIP |
| | 162 | Synchronous 4-Bit Decade Counters | 16 DIP |
| | 163 | Synchronous 4-Bit Binary Counters | 16 DIP |
| | 168 | Synchronous 4-Bit Up/Down Decade Counters | 16 DIP |
| | 169 | Synchronous 4-Bit Up/Down Binary Counters | 16 DIP |
| | 191 | Synchronous 4-Bit Up/Down Binary Counters | 16 DIP |
| | 193 | Synchronous 4-Bit Up/Down Binary Counters with Dual Clock | 16 DIP |
| | 390 | Dual 4-Bit Binary Counters | 16 DIP |
| | 393 | Dual 4-Bit Binary Counters | 14 DIP |
| | 590 | 8-Bit Binary Counters with 3-State Output Register | 16 DIP |
| | 591 | 8-Bit Binary Counters with 3-State Output Register | 16 DIP |
| | 592 | 8-Bit Binary Counters with Input Register | 16 DIP |
| | 593 | 8-Bit Binary Counters with Bidirectional Input Register/Counter Output | 20 DIP |
| Decoders/ Encoders | 42 | BCD-to-Decimal Decoder | 16 DIP |
| | 138 | 3-Line to 8-Line Decoders/Demultiplexers | 16 DIP |
| | 139 | Dual 1-of-4 Decoders/Demultiplexers | 16 DIP |
| | 148 | 8-Line to 3-Line Priority Encoders | 16 DIP |
| | 154 | 4-Line to 16-Line Decoders/Demultiplexers | 24 DIP |
| | 155 | Dual 2-to-4 Line Decoders/Demultiplexers | 16 DIP |
| | 238 | 3-Line to 8-Line Decoders/Demultiplexers | 16 DIP |
| | 239 | Dual 1-of-4 Decoders/Demultiplexers | 16 DIP |
| Multivibrators | 121 | Monostable Multivibrators with Schmitt-Trigger Inputs | 14 DIP |
| | 123 | Dual Retriggerable Monostable Multivibrators | 16 DIP |
| | 423 | Dual Retriggerable Monostable Multivibrators | 16 DIP |
| Arithmetic Circuits | 280 | 9-Bit Parity Generators/Checkers | 14 DIP |
| | 518 | 8-Bit Identity Comparators | 20 DIP |
| | 519 | 8-Bit Identity Comparators | 20 DIP |
| | 520 | 8-Bit Identity Comparators | 20 DIP |
| | 521 | 8-Bit Identity Comparators | 20 DIP |
| | 522 | 8-Bit Identity Comparators | 20 DIP |
| | 679 | 12-Bit Address Comparators | 20 DIP |
| | 680 | 12-Bit Address Comparators | 20 DIP |
| | 682 | 8-Bit Magnitude Comparators | 20 DIP |
| | 684 | 8-Bit Magnitude Comparators | 20 DIP |
| | 686 | 8-Bit Magnitude Comparators | 20 DIP |
| | 688 | 8-Bit Identity Comparators | 20 DIP |
| | 689 | 8-Bit Identity Comparators with Open-Drain Outputs | 20 DIP |

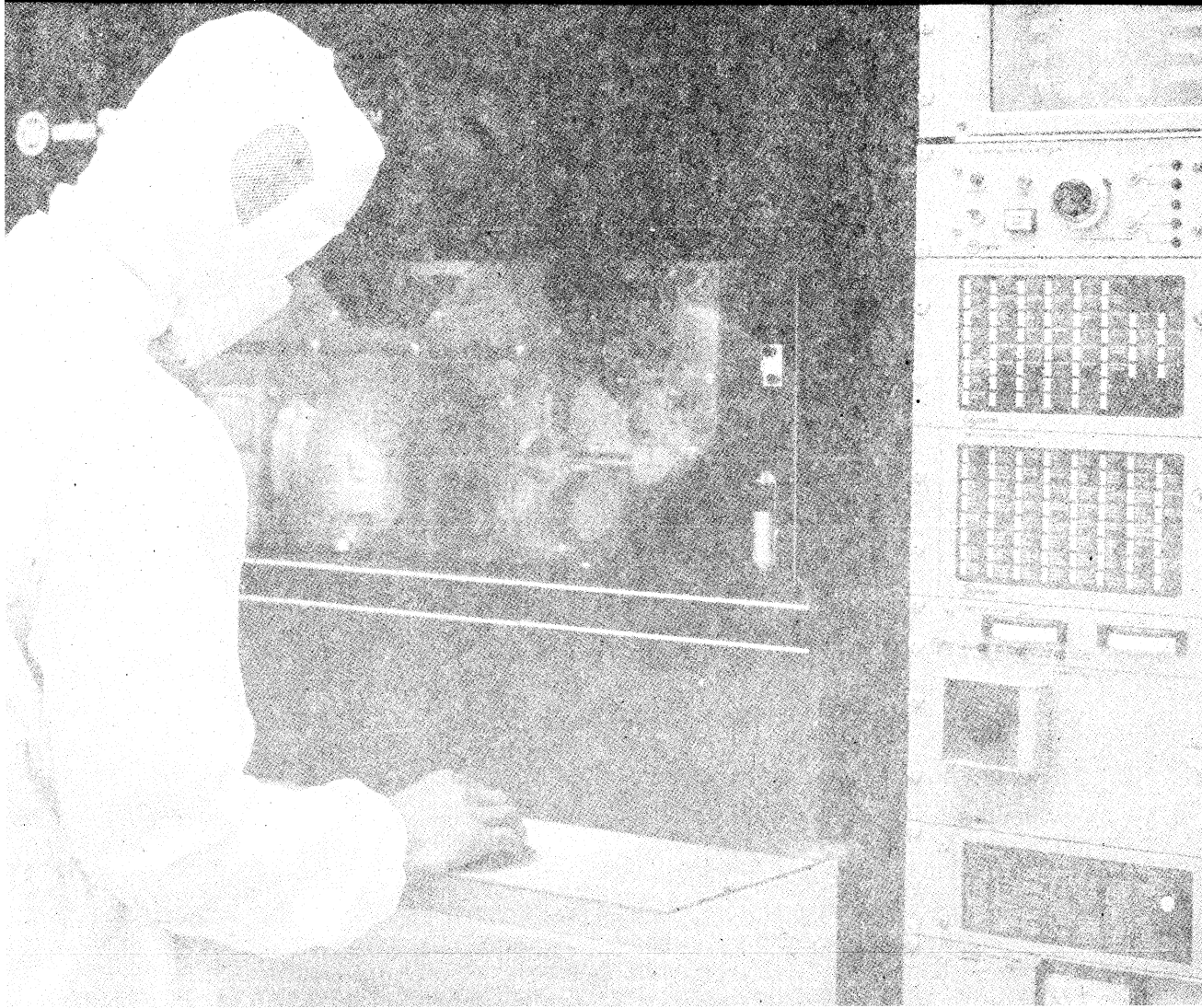
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NOTE

SPUTTER #2

PARAMETER MEASUREMENT INFORMATION

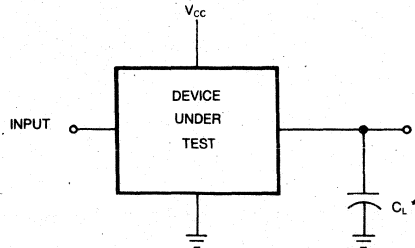
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PARAMETER MEASUREMENT INFORMATION

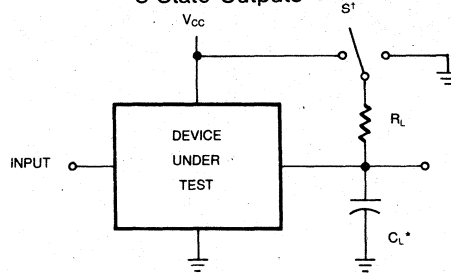
AC SWITCHING TEST CIRCUITS

Totem-Pole Outputs



* C_L includes load and test jig capacitance

3-State Outputs

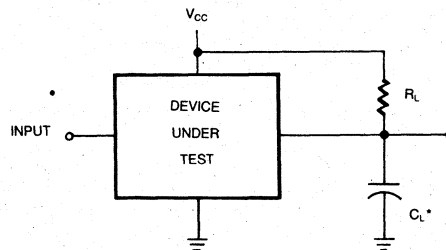


* C_L includes load and test jig capacitance

$S^* = V_{CC}$ for t_{PZL} and t_{PLZ} measurements

$S = GND$ for t_{PZH} and t_{PHZ} measurements.

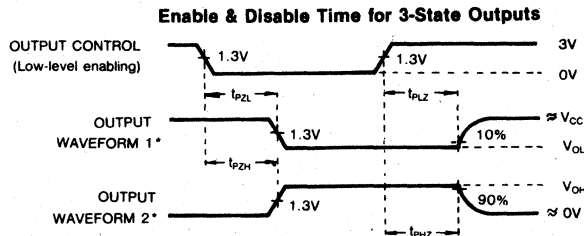
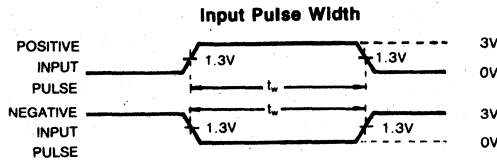
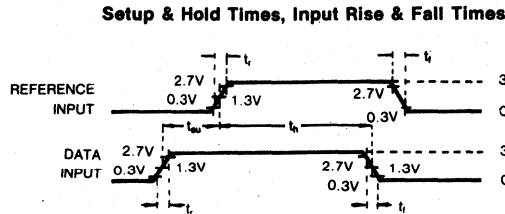
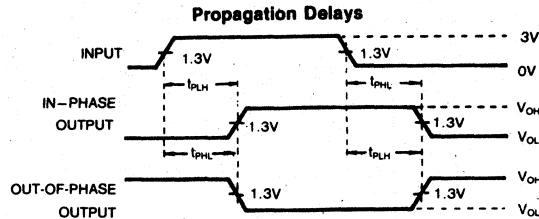
Open-Drain Outputs



* C_L includes load and test jig capacitance

PARAMETER MEASUREMENT INFORMATION

TIMING WAVEFORMS





- * Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. This waveform is applicable to both 3-state and open-drain outputs.
- * Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.



PARAMETER MEASUREMENT INFORMATION

DEFINITIONS OF TERMS & SYMBOLS

FUNCTION TABLE SYMBOLS

- H = Steady state high level
- L = Steady state low level
- ↑ = Transition from low to high level
- ↓ = Transition from high to low level
- X = Don't care (high, low states or transitions)
- Z = High-impedance state of a 3-state output
- a..h = The level of steady-state inputs at inputs A thru H, respectively
- Q_0 = Level of Q before the indicated steady-state input conditions were established
- \bar{Q}_0 = Complement of Q_0 or level of \bar{Q} before the indicated steady-state conditions were established
- Q_n = Level of Q before the most recent active transition indicated by ↑ or ↓
-  = One high-level pulse
-  = One low-level pulse

TOGGLE = each output changes to the complement of its previous level on each active transition indicated by ↑ or ↓
If, in the input columns, a row contains only the symbols H, L, and/or X, this means the indicated output is valid whenever the input configuration is achieved and regardless of the sequence in which it is achieved. The output persists so long as the input configuration is maintained.

If, in the input columns, a row contains H, L, and/or X together with ↑ and/or ↓, this means the output is valid whenever the input configuration is achieved but the transition(s) must occur following the achievement of the steady-state levels. If the output is shown as level (H, L, Q_0 , or \bar{Q}_0), it persists so long as the steady-state input levels and the levels that terminate indicated transitions are maintained. Unless otherwise indicated, input transitions in the opposite direction to those shown have no effect at the output. (If the output is shown as pulse,  or , the pulse follows the indicated input transition and persists for an interval dependent on the circuit)

DC Characteristics Terms

V_{IH} High-Level input voltage

An input voltage within the more positive (less negative) of the two ranges of values used to represent the binary variables. A minimum is specified that is the least-positive value of high-level input voltage for which operation of the logic element within specification limits is guaranteed.

V_{IL} Low-Level input voltage

An input voltage level within the less positive (more negative) of the two ranges of values used to represent the binary variables. A maximum is specified that is the most-negative value of low-level input voltage for which operation of the logic element within specification limits is guaranteed.

V_{OH} High-Level output voltage

The voltage at an output terminal with input conditions applied that, according to product specification, will establish a high level at the output.

V_{OL} Low-Level output voltage

The voltage at an output terminal with input conditions applied that, according to product specification, will establish a low level at the output.

V_{T+} Positive-Going threshold level

The voltage level at a transition-operated input that causes operation of the logic element according to specification as the input voltage rises from a level below the negative-going threshold voltage, V_{T-} .

PARAMETER MEASUREMENT INFORMATION

V_{T-} Negative-Going threshold level

The voltage at a transition-operated input that causes operation of the logic element according to specification as the input voltage falls from a level above the positive-going threshold voltage, V_{T+}.

I_O Output Current

The current into* an output with input conditions applied that, according to the product specification, will establish a high or a low level at the output.

I_{IN} Input Current

The current into* an input when a high or a low level voltage is applied to that input.

I_{OZ} Off-State (high-impedance-state) output current (of a three-state output)

The current flowing into* an output having three-state capability with input conditions established that, according to the product specification, will establish the high-impedance state at the output level voltage applied to the output.

This parameter is measured with other input conditions established that would cause the output to be at a low-voltage level (if it were enabled) when the externally applied voltage is high; or high-voltage level when the externally applied voltage is low.

I_{CC} Supply current

The current into* the V_{CC} supply terminal of an integrated circuit.

*Current out of a terminal is given as negative value.

AC CHARACTERISTICS TERMS

t_r Rise time

The time interval between two reference points (10% and 90% unless otherwise specified) on a waveform that is changing from the defined low level to the high level.

t_f Fall time

The time interval between two reference points (90% and 10% unless otherwise specified) on a waveform that is changing from the defined high level to the defined low level.

f_{max} Maximum clock frequency

The highest rate at which the clock input of a bistable circuit can be driven through its required sequence while maintaining stable transitions of a logic level at the output with input conditions established that should cause changes of output logic level in accordance with the specification.

t_{PLH} Propagation delay time, low-to-high-level output

The time between the specified reference points on the input and output voltage waveforms with the output changing from the defined low level to the defined high level.

t_{PHL} Propagation delay time, high-to-low-level output

The time between the specified reference points on the input and output voltage waveforms with the output changing from the defined high level to the defined low level.

t_{PZH} Enable time (of a three-state output) to high level

The time interval between the specified reference points on the input and output voltage waveforms with the three-state outputs changing from a high-impedance (off) state to the defined high level.

t_{PZL} Enable time (of a three-state output) to low level

The time interval between the specified reference points on the input and output voltage waveforms with the three-state outputs changing from a high-impedance (off) state to the defined low level.

PARAMETER MEASUREMENT INFORMATION

t_{PHZ} Disable time (of a three-state output) from high level

The time interval between the specified reference points on the input and output voltage waveforms with the three-state outputs changing from the defined high level to high-impedance (off) state.

t_{PLZ} Disable time (of a three-state output) from low level

The time interval between the specified reference points on the input and output voltage waveforms with the three-state outputs changing from the defined high level to high-impedance (off) state.

t_w Pulse width

The time interval between specified reference points on the leading and trailing edges of the pulse waveform.

t_{su} Setup time

The time interval between the application of a signal at a specified input terminal and a subsequent active transition at another specified input terminal.

NOTES: 1. The setup time is the actual time interval between two signal events and is determined by the system in which the digital circuit operates. A minimum value is specified that is the shortest interval for which correct operation of the digital circuit is guaranteed.

2. The setup time may have a negative value in which case the minimum limit defines the longest interval (between the active transition and the application of the other signal) for which correct operation of the digital circuit is guaranteed.

t_h Hold time

The time interval during which a signal is retained at a specified input terminal after an active transition occurs at another specified input terminal.

NOTES: 1. The hold time is the actual time interval between two signal events and is determined by the system in which the digital circuit operates. A minimum value is specified that is the shortest interval for which correct operation of the digital circuit is guaranteed.

2. The hold time may have a negative value in which case the minimum limit defines the longest interval (between the release of the signal and the active transition) for which correct operation of the digital circuit is guaranteed.

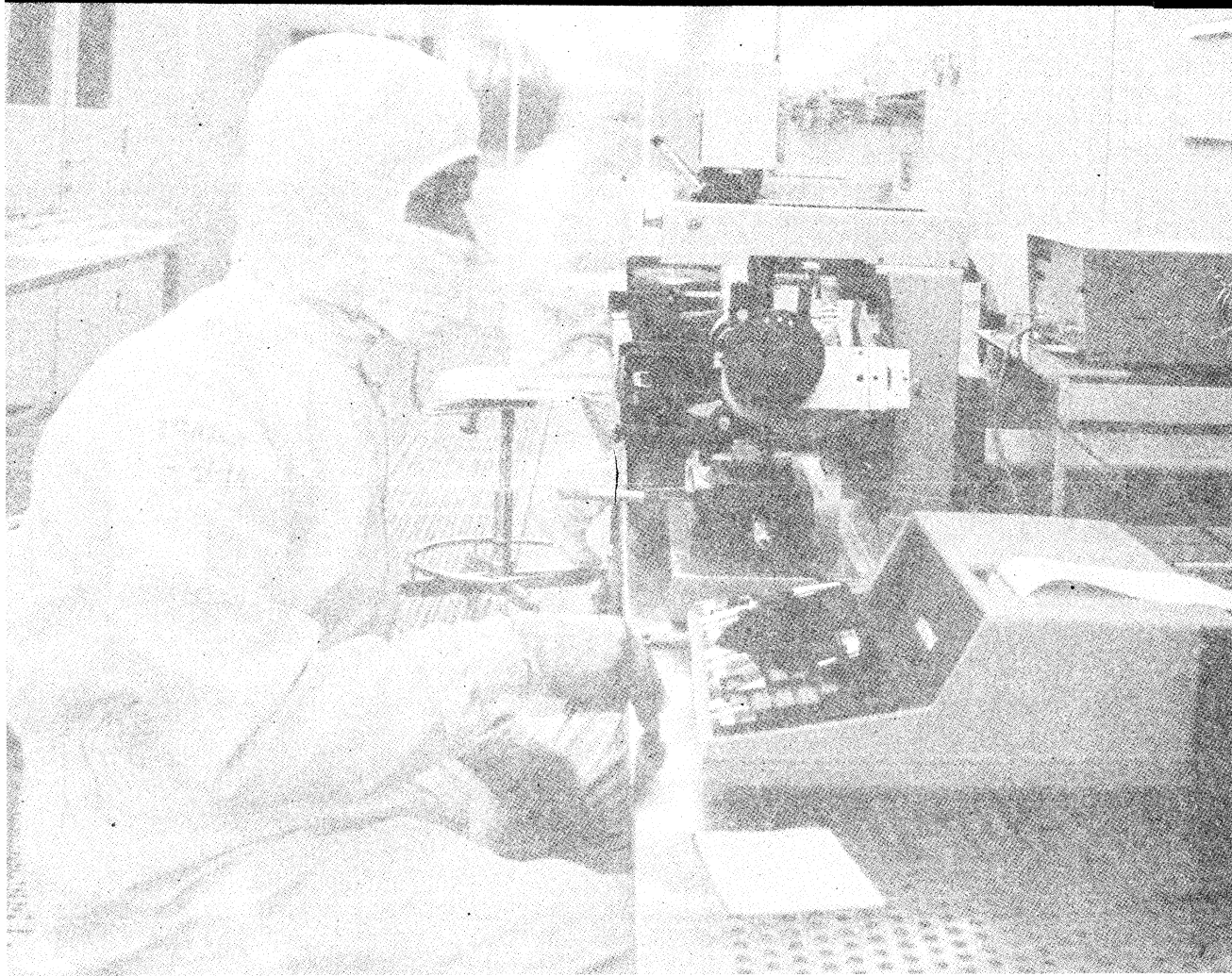
C_{PD} Power dissipation capacitance

Used to determine the no-load dynamic power dissipation per logic function (see individual circuit pages):

$$P_D = C_{PD} V_{CC}^2 + I_{CC} V_{CC}.$$

NOTE

TECHNICAL OVERVIEW 3



TECHNICAL OVERVIEW

INTRODUCTION

The 54/74AHCT Advanced High-Speed CMOS and the 54/74HCTLS High-Speed CMOS logic families were designed to offer the most desirable features of their CMOS and bipolar predecessors. They have the low power dissipation, superior noise immunity, wide voltage and temperature ranges and the very low input currents of the other high-speed CMOS logic families, in addition to the high speed and drive capability of LS and ALS bipolar logic.

The AHCT family is an exact equivalent of the bipolar ALS and can readily replace ALS in existing applications to reduce power dissipation. In many applications, AHCT parts can also be used as replacements for FAST™ and S (Schottky).

The HCTLS parts, on the other hand, meet and exceed all of industry-standard LS and HCT specifications, and can be used as replacements to these to lower the power dissipation and improve performance. Figure 1 shows how AHCT and HCTLS families rank with the other bipolar technologies in terms of speed and power dissipation.

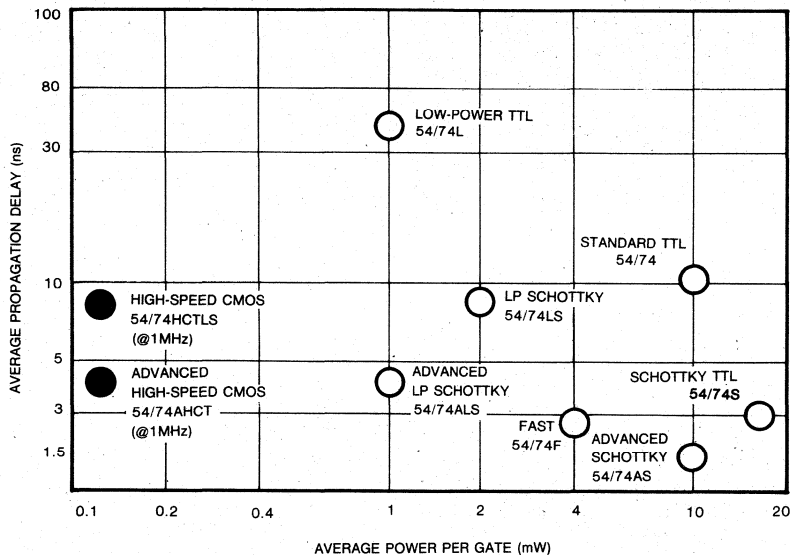


FIGURE 1. Power dissipation vs gate delay characteristics for a two-input NAND gate (74XX00) implemented in various bipolar and CMOS technologies

Both families feature TTL input voltage levels which enable them to interface with all TTL, NMOS or CMOS outputs without any external components. All AHCT and HCTLS parts are fully characterized and specified over the 4.5 to 5.5V voltage range, and the industrial (-40 to 85°C) and military (-55 to 125°C) temperature ranges. This is a significant improvement over the older bipolar logic families, where, for example LS would specify DC specs over 4.75V to 5.25V and AC specs only at 5V and room temperature. (ALS is specified over 4.5 to 5.5V and 0 to 70°C). A comparison of the key characteristics for an octal buffer illustrates these improvements clearly in Figure 2. The DC characteristics common to all AHCT and HCTLS parts are listed in Figure 3.

FAST is a trademark of Fairchild camera and Instrument.

TECHNICAL OVERVIEW

| | TTL | | | SAMSUNG CMOS | | | OTHER CMOS | |
|--|--|---|---|--|--|--|--|-------------------------------|
| | 74LS244 | 74ALS244 | 74F244 | 74HCTLS244 | 74AHCT244 | 74HC244 | 74HCT244 | |
| Operating Voltage Range (Commercial) | 4.75V to 5.25V | 4.5V to 5.5V | 4.75V to 5.25V | 4.5V to 5.5V | 4.5V to 5.5V | 2V to 6V | 4.5V to 5.5V | |
| Operating Temperature Range (Commercial) | 0°C to 70°C | 0°C to 70°C | 0°C to 70°C | -40°C to +85°C | -40°C to +85°C | -40°C to +85°C | -40°C to +85°C | -40°C to +85°C |
| Maximum Propagation Delay ($C_L = 50$ pF) | 18 ns ($V_{CC} = 5V$, $T_a = 25^\circ C$) | 10 ns (Over Operating Conditions) | 6.5 ns (Over Operating Conditions) | 18 ns ($V_{CC} = 5V$, $T_a = 25^\circ C$) | 10 ns (Over Operating Conditions) | 20 ns ($V_{CC} = 5V$, $T_a = 25^\circ C$) | 18 ns ($V_{CC} = 5V$, $T_a = 25^\circ C$) | |
| Maximum Quiescent Current | 54 mA | 27 mA | 90 mA | 0.08 mA | 0.08 mA | 0.08 mA | 0.08 mA | 0.08 mA |
| Typical Power Dissipation | Static | 120 mW | 70 mW | 0.004 mW | 0.004 mW | 0.004 mW | 0.004 mW | 0.004 mW |
| | At 100 kHz (All inputs toggling) | 120 mW | 70 mW | 260 mW | 0.6 mW | 0.6 mW | 1.0 mW | 1.8 mW |
| Output Drive Currents | I_{OH} | -3 mA ($V_{OH} = 2.4V$) -15 mA ($V_{OH} = 2.0V$) | -3 mA ($V_{OH} = 2.4V$) -15 mA ($V_{OH} = 2.0V$) | -15 mA ($V_{OH} = 2.0V$) | -12 mA ($V_{OH} = 3.84V$) | -6 mA ($V_{OH} = 3.84V$) | -12 mA ($V_{OH} = 3.84V$) | -6 mA ($V_{OH} = 3.84V$) |
| | I_{OL} | 12 mA ($V_{OL} = 0.4V$) 24 mA ($V_{OL} = 0.5V$) | 12 mA ($V_{OL} = 0.4V$) 24 mA ($V_{OL} = 0.5V$) | 64 mA ($V_{OL} = 0.55V$) | 12 mA ($V_{OL} = 0.4V$) 24 mA ($V_{OL} = 0.5V$) | 6 mA ($V_{OL} = 0.33V$) | 12 mA ($V_{OL} = 0.4V$) 24 mA ($V_{OL} = 0.5V$) | 6 mA ($V_{OL} = 0.33V$) |
| Input Threshold Voltages | V_{IL} | 0.8V | 0.8V | 0.8V | 0.8V | 0.9V ($V_{CC} = 4.5V$) | 0.8V | 0.8V |
| | V_{IH} | 2.0V | 2.0V | 2.0V | 2.0V | 3.15V ($V_{CC} = 4.5V$) | 2.0V | 2.0V |
| Input Currents | I_{IL} | -0.2 mA ($V_I = 0.4V$) | -0.1 mA ($V_I = 0.4V$) | -1.6 mA ($V_I = 0.5V$) | -1.0 μA | -1.0 μA | -1.0 μA | -1.0 μA |
| | I_{IH} | 20 μA ($V_I = 2.7V$) | 20 μA ($V_I = 2.7V$) | 20 μA ($V_I = 2.7V$) | 1.0 μA | 1.0 μA | 1.0 μA | 1.0 μA |

FIGURE 2. Key performance characteristics for 74XXX244 octal buffer

TECHNICAL OVERVIEW

The Samsung CMOS logic families include a comprehensive set of buffers, registers, latches and transceivers that are offered in 8, 9 and 10-bit versions. A wide variety of gates, flip-flops, multiplexers, shift registers, encoder/decoders, schmitt triggers and multivibrators complete the family of 147 part types. Each function is available in both AHCT and HCTLS version.

| Characteristic | Symbol | Conditions | $T_a = 25^\circ\text{C}$ | | Commercial | Military | Unit | |
|-----------------------------------|----------|--|--|-------------------|----------------|---|----------------|--|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V | |
| Minimum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN} = V_{IH}$ or V_{IL} | CMOS loads $I_{OH} = -20\mu\text{A}$ | V_{CC} | $V_{CC} - 0.1$ | $V_{CC} - 0.1$ | $V_{CC} - 0.1$ | V |
| | | | Standard Outputs $I_{OH} = -4\text{ mA}$ | 4.2 | 3.98 | 3.84 | 3.7 | |
| | | | Bus-Driver Outputs $I_{OH} = -6\text{ mA}$ | 4.2 | 3.98 | 3.84 | 3.7 | |
| Minimum Low-Level Output Voltage | V_{OL} | $V_{IN} = V_{IH}$ or V_{IL} | CMOS loads $I_{OL} = 20\mu\text{A}$ | 0.1 | 0.1 | 0.1 | 0.1 | V |
| | | | Standard Outputs $I_{OL} = 4\text{ mA}$ $I_{OL} = 8\text{ mA}$ | 0.2 0.3 | 0.26 0.39 | 0.33 0.5 | 0.4 | |
| | | | Bus-Driver Outputs $I_{OL} = 12\text{ mA}$ $I_{OL} = 24\text{ mA}$ | 0.2 0.3 | 0.26 0.39 | 0.33 0.5 | 0.4 | V |
| | | | | | | | | |
| Maximum Input Leakage Current | I_i | $V_{CC} = \text{Max}$, $V_{IN} = V_{CC}$ or GND | | ± 0.1 | ± 1.0 | 1.0 | μA | |
| Maximum 3-State Leakage Current | I_{oz} | $V_{CC} = \text{Max}$, Enable = V_{IH} or V_{IL} $V_{OUT} = V_{CC}$ or GND | | +0.5 | ± 5.0 | ± 10.0 | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{CC} = \text{Max}$ $V_{IN} = V_{CC}$ or GND All Outputs Open | SSI Circuits | | 2.0 | 20.0 | 40.0 | μA |
| | | | Dual and Quad Flip-Flops & Latches | | 4.0 | 40.0 | 80.0 | |
| | | | MSI Circuits & Circuits with High-Current Outputs | | 8.0 | 80.0 | 160.0 | |

FIGURE 3. DC characteristics of the 54/74AHCT and 54/74 HCTLS Families ($V_{CC} = 5.0\text{V} \pm 10\%$)

3

TECHNICAL OVERVIEW

PROCESS TECHNOLOGY

The high performance of the AHCT and HCTLS is a result of a unique self-aligned metal-gate CMOS process technology that features $1.2\mu\text{m}$ effective gate lengths and double metallization. The following table compares the general characteristics of this process with other existing CMOS and bipolar technologies used for logic circuits:

| | SAMSUNG CMOS | INDUSTRY CMOS (HC & HCT) | INDUSTRY ALS |
|------------------------------|----------------|--------------------------|----------------|
| Number of Masking Steps | 8 | 12-14 | 13 |
| Number of Metal Layers | 2 | 1 | 2 |
| Minimum Feature Size (drawn) | $2\mu\text{m}$ | $3-4\mu\text{m}$ | $4\mu\text{m}$ |
| Interconnections | All Metal | Poly & Metal | All Metal |
| Relative Die Size | 1X | 2.5-5X | 1.5-2X |
| Manufacturing Equipment | Standard | Standard | Standard |

Samsung's CMOS process was designed from the ground up to be a scaled two-layer metal CMOS process (see *Figure 4* for a cross section). The goal was to make the process as simple as possible, and be able to readily control gate length and gate dielectric thickness. The process uses 8 masking steps. Other semiconductor manufactures, in trying to go to two-layer metal short-channel processes have generally embellished pre-existing silicon-gate processes and have wound up with 12-14 masking steps. More masking steps, of course, make wafers more costly, but most importantly, reduce yield because of more chances for random defects.

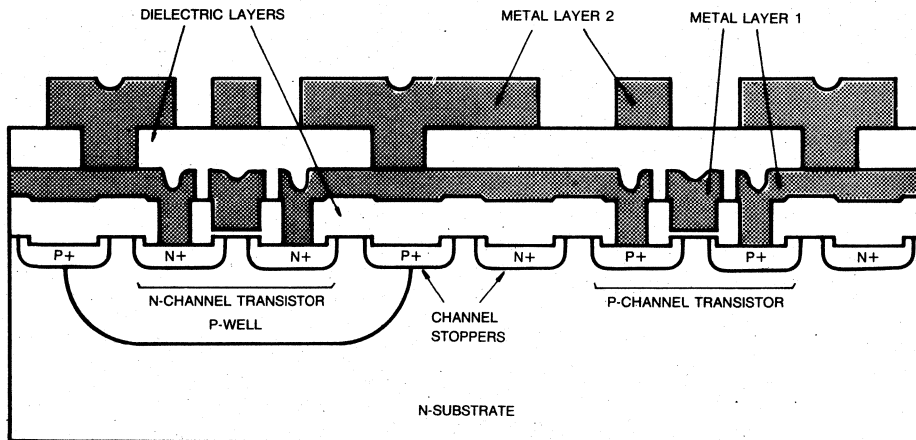


FIGURE 4. Samsung CMOS process cross section for an inverter stage

The Samsung process, with the short $2\mu\text{m}$ channel lengths ($1.2\mu\text{m}$ effective), yields gate delays as fast as those of the bipolar LS and ALS processes, and the same short channel lengths allow high-current output drivers to occupy a modest silicon area. Generally, the AHCT and HCTLS logic chips are much smaller than their CMOS and bipolar equivalents (see *Figure 5*). In achieving this small size, two-layer metal is as important as having short channels. For example, in the on-chip bussing of ground and V_{CC} to the output drivers, very wide metal lines have to be used that take considerable area. In this case, if these lines are in Metal 2, no extra area is wasted since the circuitry can be placed underneath.

TECHNICAL OVERVIEW

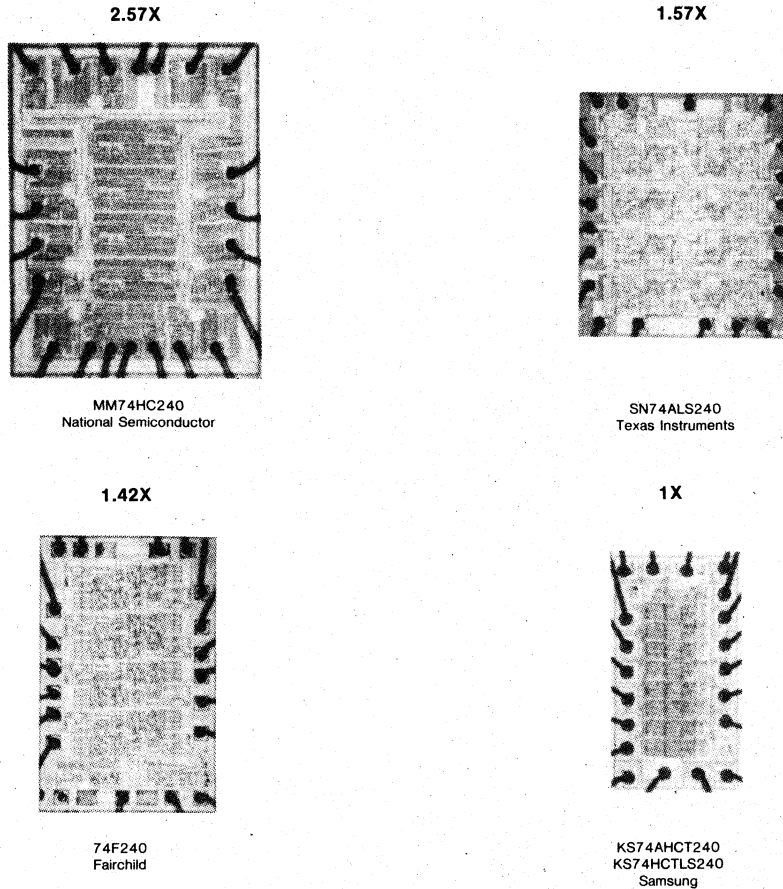


FIGURE 5. Die size comparison for a 74XX244 from various technologies.

INPUT CHARACTERISTICS

The input stage of an AHCT or HCTLS circuit is illustrated in *Figure 6*. It consists of a diode protection network and a CMOS inverter stage that has very high input impedance. The ultra-low input current specified in the data sheets ($1\mu\text{A}$ maximum) is due to the reverse leakage currents of the diodes and is not used for "driving" the CMOS transistors i.e. the inputs are voltage-driven. This makes AHCT and HCTLS inputs very easy to drive and results in a very high fan-in capability.

TTL-compatible input threshold voltages of $0.8\text{V } V_{IL}$ and $2.0\text{V } V_{IH}$ are accomplished by properly sizing the p- and n-channel transistors of the CMOS inverter stage. The actual logic transition takes place mid-way between these values, at 1.4V , and is very sharp compared to TTL logic due to the very high gain of the first inverter stage. This is illustrated in *Figure 7* for a two-input NAND gate. Note that the input threshold for CMOS is much more stable with temperature than that for LS.

While the AHCT and HCTLS parts are recommended as direct replacements for ALS and LS, one needs to pay attention to not leaving any inputs floating, i.e. unconnected. Since the inputs have very high impedance, they can easily pick up external noise which can result in random switching of the device and high power consumption. Therefore, all unused inputs must be terminated to either V_{CC} or ground.

TECHNICAL OVERVIEW

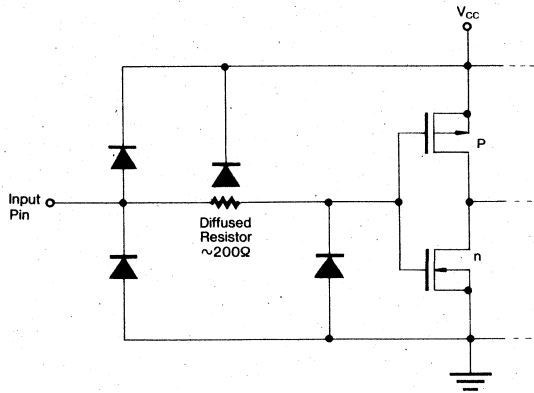


FIGURE 6. The input circuit of AHCT and HCTLS parts.

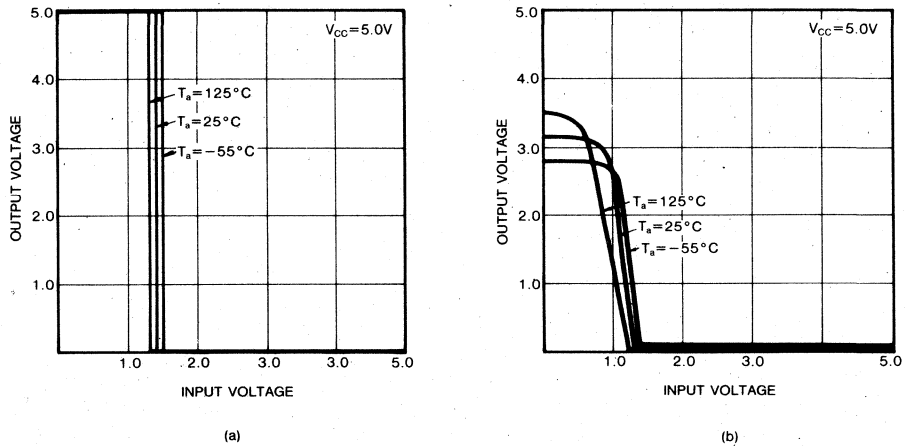


FIGURE 7. Input-Output transfer characteristics for (a) AHCT/HCTLS00, (b) LS00.

TECHNICAL OVERVIEW

OUTPUT CHARACTERISTICS

A typical output stage of an AHCT or HCTLS part consists of a complementary pair of transistors and a diode protection network (see Figure 8). Unlike the bipolar outputs, the voltage swing is rail-to-rail, which is responsible for the improved noise margin of AHCT/HCTLS systems. The drive capability of these outputs is similar to the bipolar parts, i.e. 24mA or 8mA I_{OL} (at 0.5V V_{OL}) for bus-driver and standard outputs, respectively. This means that AHCT and HCTLS parts can drive as many loads or as large bus capacitances as their ALS and LS counterparts. Figure 9 shows a comparison of the output drive capabilities of AHCT/HCTLS and LS/ALS outputs. Figure 10 illustrates the variations of I_{OL} and I_{OH} with supply voltage and temperature for a standard output ('00) and a bus driver ('244).

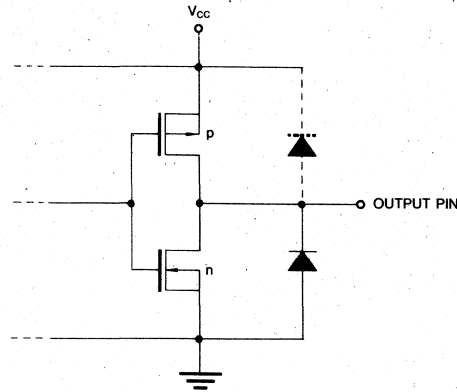


FIGURE 8. A typical output circuit of an AHCT or HCTLS part.
The upper diode is parasitic and embedded in the p-channel transistor.

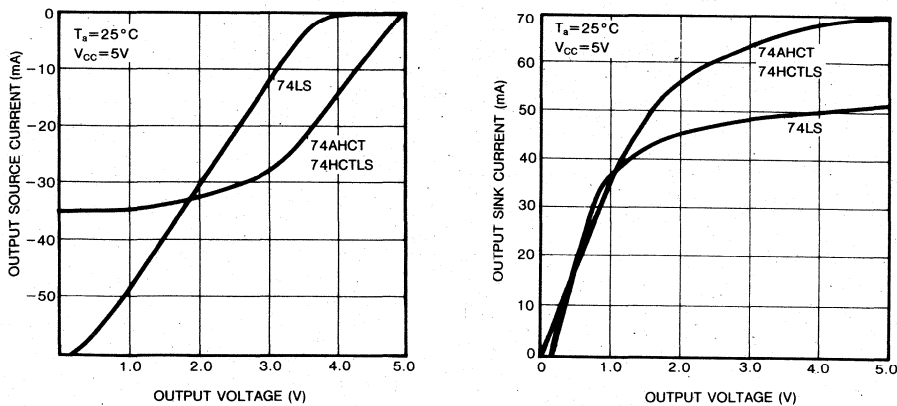
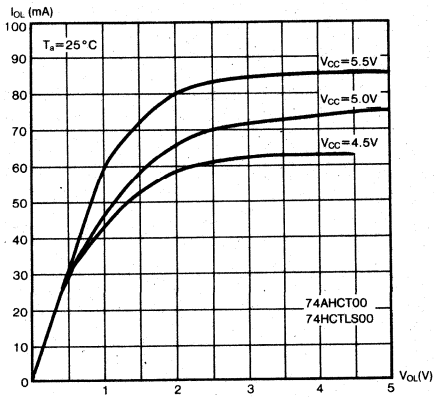
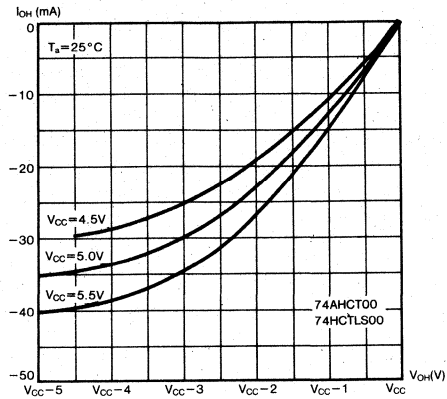


FIGURE 9. Comparison of standard AHCT/HCTLS and standard LS output (a) Source, and (b) sink currents.

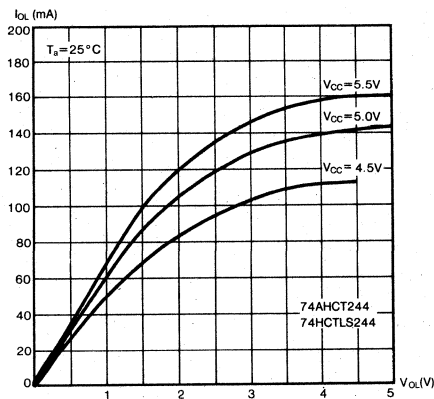
TECHNICAL OVERVIEW



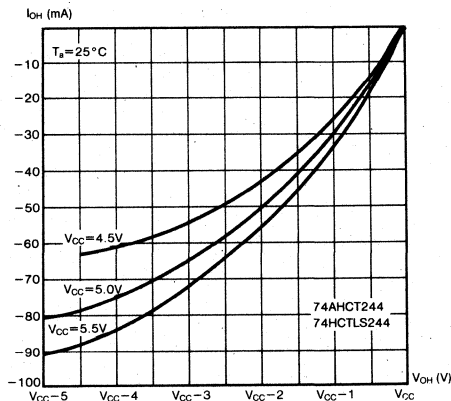
(a)



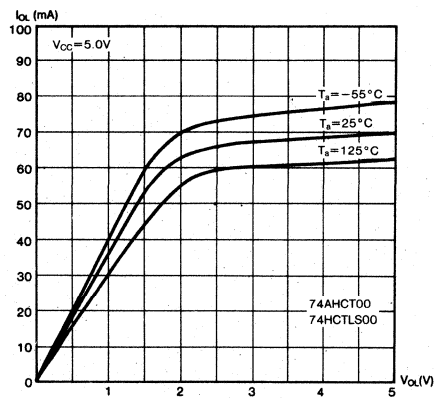
(b)



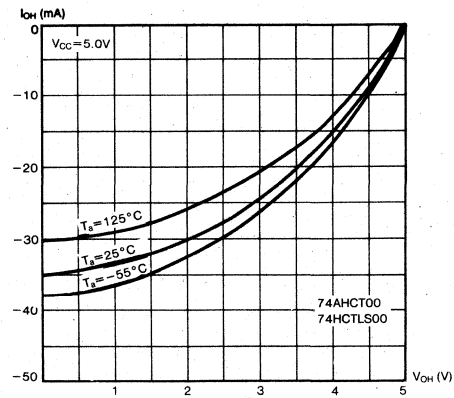
(c)



(d)



(e)



(f)

TECHNICAL OVERVIEW

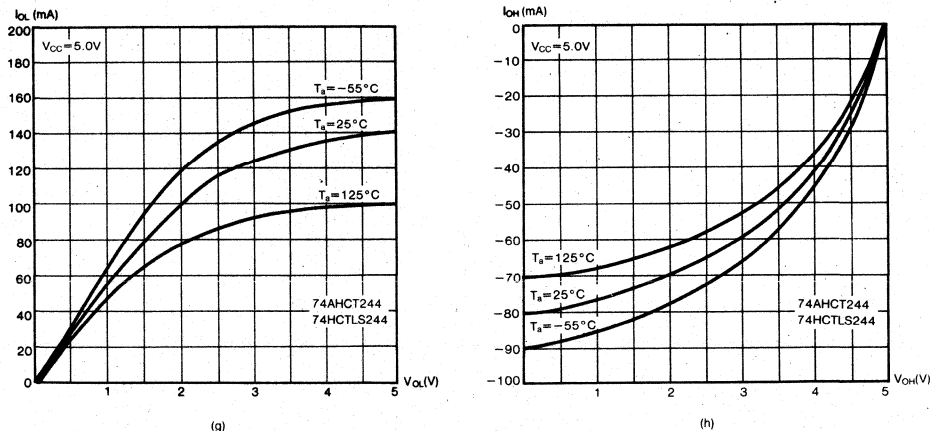


FIGURE 10. Output current variations with supply voltage and temperature for standard [(a), (b), (e) (f)] and bus driver [(c), (d), (g), (h)] outputs.

3

NOISE IMMUNITY & NOISE MARGINS

The term "noise" in the context of digital circuits and systems means unwanted transient variations of voltages and currents at logic nodes. Typically noise is transferred to logic nodes or interconnecting lines by unwanted capacitive or inductive coupling, as illustrated in Figure 11.

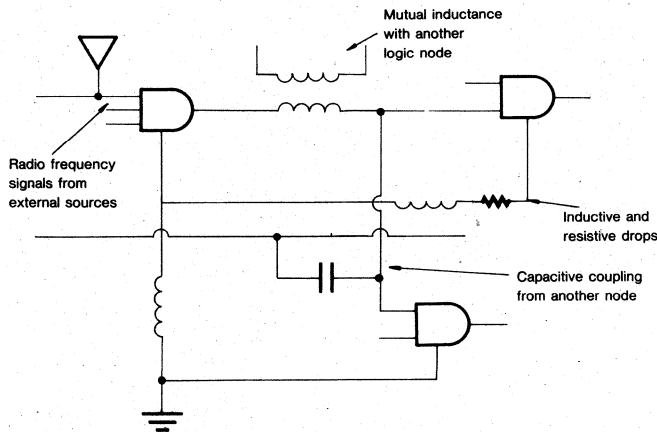


FIGURE 11. Sources of noise in digital systems.

Noise becomes a particularly critical issue in high-speed systems where fast voltage transitions accentuate these parasitic capacitances and inductances. Also, higher speeds allow the device to respond more quickly to noise transients. Therefore, special board layout and decoupling techniques have to be employed to confine noise to an "acceptable range". Obviously, the wider this range, the easier it is to design a clean system. This range is dictated by the input and output characteristics of the ICs in the system, as illustrated in Figure 12, and is measured in terms of "noise margins".

TECHNICAL OVERVIEW

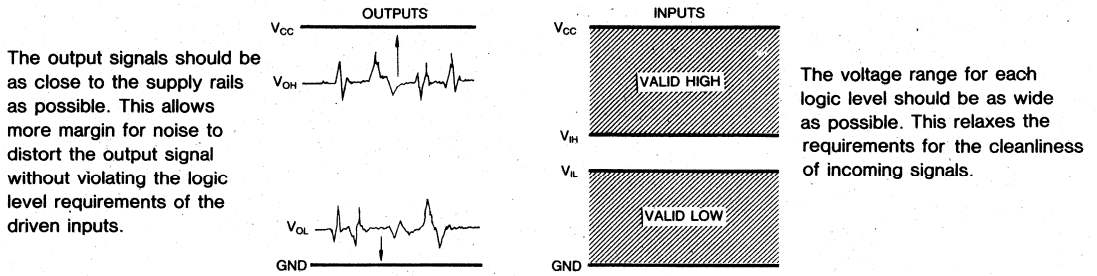


FIGURE 12. Requirements for good noise immunity.

Noise margins specify the maximum amplitude noise pulse that will not change the state of a driven stage, assuming the driving stage presents a worst-case logic level to the driven stage. Specifically, the high-level and the low-level noise margins (NM_H and NM_L) are defined as:

$$NM_H = V_{OH} - V_{IH}$$

$$NM_L = V_{IL} - V_{OL}$$

where the voltage values are the guaranteed worst-case extremes for each case. Figure 13 shows the noise margins for several different interfaces.

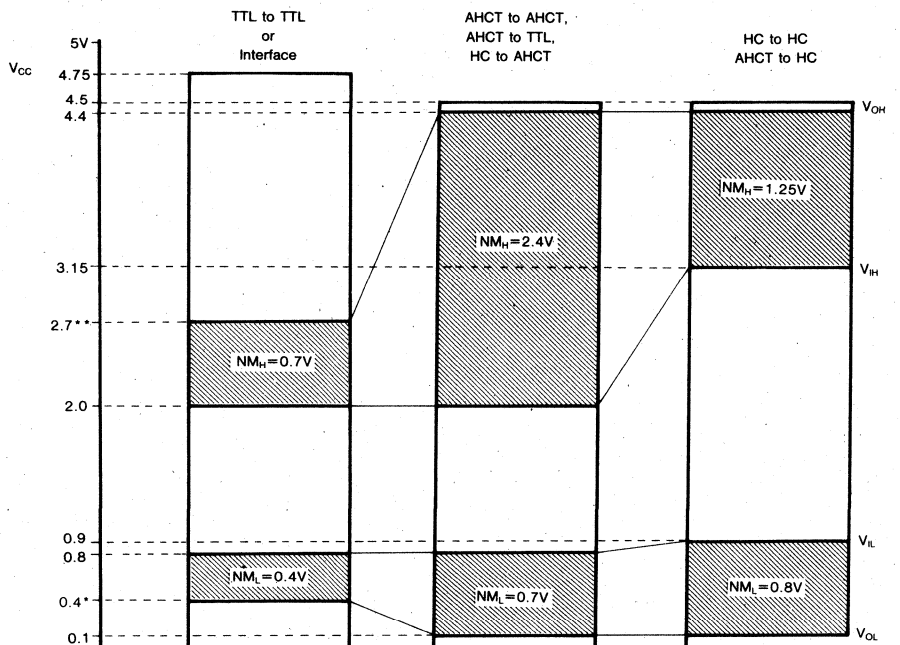


FIGURE 13. Noise margins for various interfaces. Noise margins for HCTLS are the same as those for AHCT.

- * When an AHCT output drives TTL loads the V_{OH} level will be dependent on how many loads are driven. For example if an AHCT244 drives 60LS loads, the V_{OH} will rise to 0.4V
- ** For some, TTL parts, V_{OH} is 2.4V, instead of 2.7V

TECHNICAL OVERVIEW

It is immediately obvious that the TTL-to-TTL interfaces have the poorest noise immunity and those driven by CMOS have the best. This is due to the rail-to-rail voltage swings of CMOS outputs.

Note the HC logic has almost symmetrical noise margins while AHCT (or HCTLS) has a very large noise margin for high level and a smaller low-level one. This is due to the fact that AHCT (or HCTLS) inputs are designed for direct interface with TTL and NMOS outputs as well as other CMOS. Notice, however, that the low-level noise margin (NM_L) for AHCT is only 0.1V less than that for HC, which means that it provides nearly as much immunity to ground noise. In addition, since AHCT drive capability is two to four times better than HC, it is less susceptible to noise currents coupled to its outputs. That is, lower stray voltages are induced for a given amount of current coupling than for HC.

ESD PROTECTION

Historically, MOS devices have always been considered to be more susceptible to damages due to electrostatic discharges (ESD), which can occur during handling and assembly procedures. However, the new protection circuitry, design, and special processing used for AHCT and HCTLS have improved the ESD immunity for these devices where it is now much better than that of bipolar logic.

Figure 6 and 8 show the input and output ESD protection circuitry employed. All AHCT and HCTLS pins are protected to ESD levels typically greater than $\pm 2kV$, the tests are conducted using the "human-body" model that is shown in Figure 14.

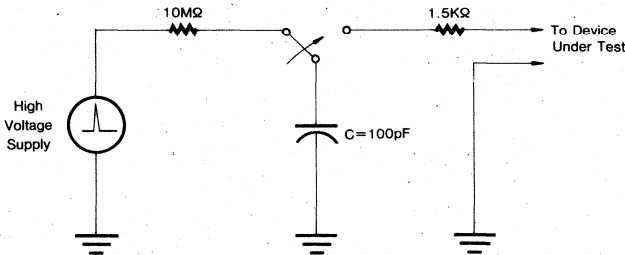


FIGURE 14. Test circuit used to measure ESD damage in AHCT and HCTLS circuits.

LATCHUP CHARACTERISTICS

SCR latchup is an undesirable parasitic phenomenon which is inherent in circuits fabricated using bulk CMOS technology. A parasitic four-layer (P-N-P-N) SCR structure that appears between V_{CC} and ground can be triggered when voltages greater than V_{CC} or less than ground are applied to inputs or outputs. When this happens, V_{CC} gets effectively shorted to ground, and the only way to get the device off the latchup mode is to shut off the power supply. If large currents are allowed to flow through the chip, it may be destroyed. Samsung CMOS logic parts have been designed and processed to virtually eliminate this possibility in real-life situations where voltages out of the supply range many appear at the input or output pins (overshoots, undershoots, power-up & power-down situations).

TECHNICAL OVERVIEW

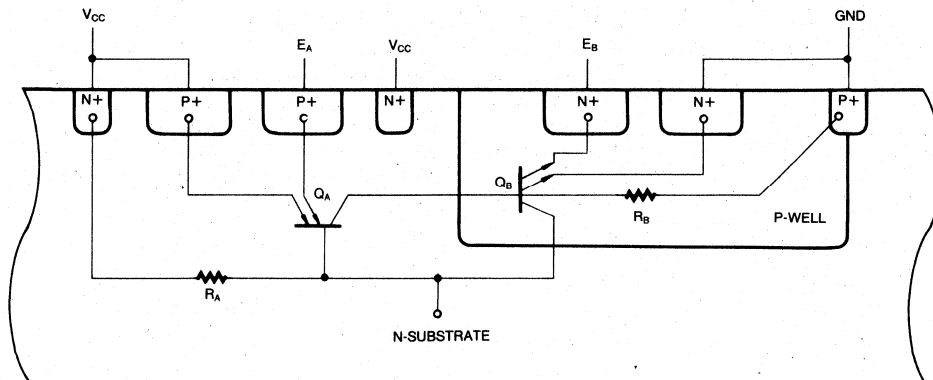


FIGURE 15. Simplified cross section of a CMOS inverter

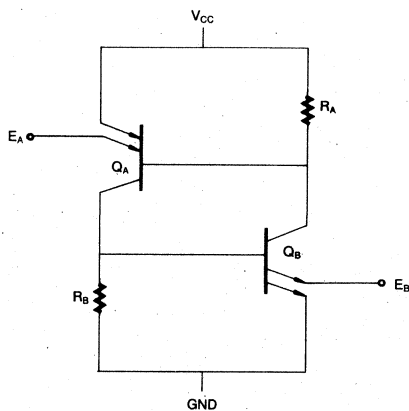


FIGURE 16. CMOS SCR structure

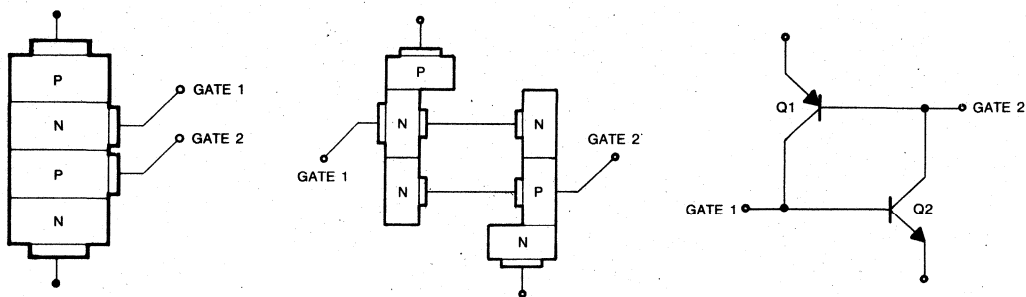


FIGURE 17. Simplified four layer SCR structure

TECHNICAL OVERVIEW

The parasitic SCR structure in a CMOS inverter cross section is illustrated in *Figure 15*, where vertical and lateral NPN and PNP transistors are formed back-to-back by the N and P diffusions. R_A and R_B are the P-well and the N-substrate power supply connections. *Figure 16* is a schematic representation of this parasitic structure that looks like a cross-coupled transistor model of an SCR (*Figure 17*). The exceptions are the R_A and R_B resistors and the fact that the real SCR is triggered at the gates, while the CMOS parasitic SCR is triggered at its emitters. This happens when either the E_A is raised above V_{CC} enough to turn on Q_A , or E_B is lowered below ground enough to turn on Q_B . When E_A is brought above V_{CC} , current is injected from the emitter of Q_A and is swept to its collector. This current, in turn, will increase the voltage at the Q_B gate and once it is above 0.7V, Q_B will turn on and feed current from its collector back into R_A and into Q_A . When 0.7V drop appears across R_A , Q_A will turn on even more.

If the two transistors have enough gain and enough current is provided by the supply to sustain the SCR, it will turn on and remain on even after E_A and E_B are returned to the rail voltages. Notice that low resistor values effectively reduce the gain of the transistors by stealing current away from their bases. Therefore, transistors should actually have much higher gains in order to have an overall SCR loop gain greater than one and enable SCR to trigger.

Samsung CMOS logic parts are designed and processed to have very low R_A , R_B values and low gains for the parasitic transistors. In addition, large diodes exist between each signal pin and the supply rails to shunt out voltages above V_{CC} and below ground. In fact, traditionally, one refers to the current that flows through these diodes as the element that triggers latchup, i.e. we talk of "latchup trigger currents", not voltages.

Measured on a static basis, i.e. by applying DC voltages above V_{CC} and below ground, Samsung parts can withstand currents typically well above 200mA—even under the worst-case conditions of 7V V_{CC} and +125°C operation. *Figure 18* illustrates the test set-up used for static latchup tests.

A common occurrence of voltages above V_{CC} and below ground in systems is overshoots and undershoots that are caused by signal line ringing and power supply transients. In this case, unlike the static operation, only short pulses cause forward-bias diode currents and hence possible latch-up. It turns out, fortunately, that the parasitic SCR has extremely slow response time to transients, i.e. very poor frequency characteristics. *Figure 19* shows the increased peak currents required to latch an AHCT or HCTLS device up when the pulse width is decreased. For pulse widths in the range of several tens of nanoseconds, it is virtually impossible to latch the device up.

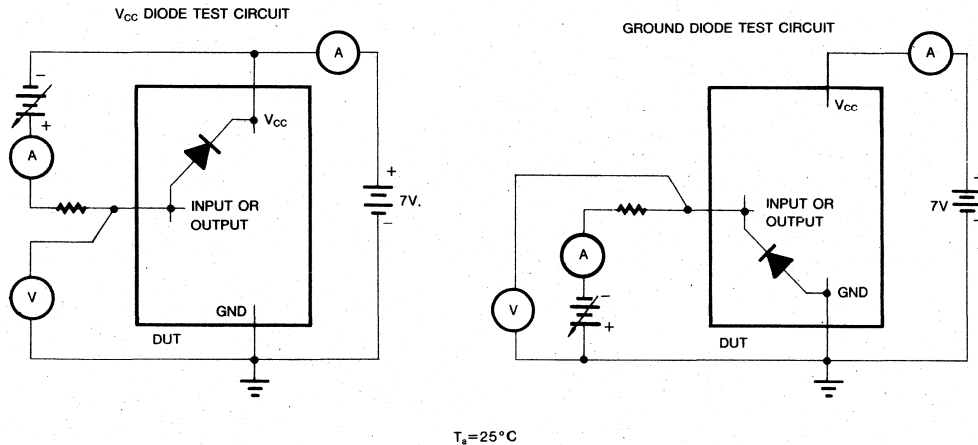


FIGURE 18. Test setup for measuring DC latch-up

TECHNICAL OVERVIEW

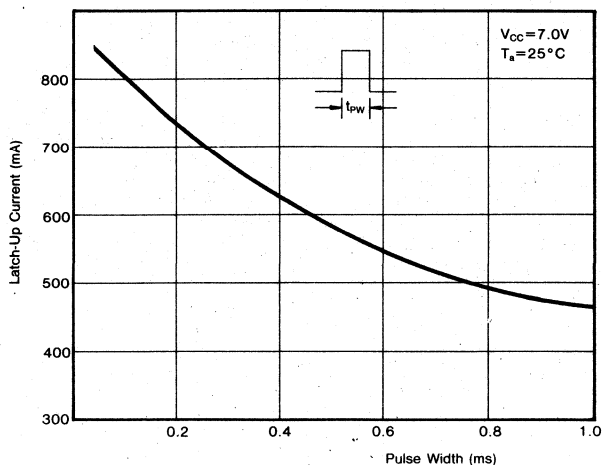


FIGURE 19. Pulsed latch-up characteristics

POWER DISSIPATION

Low power dissipation is by far the most important advantage of CMOS over any other technology. Particularly in the quiescent state, the AHCT and HCTLS circuits consume up to seven orders of magnitude less power than the equivalent TTL functions. This makes them ideal for battery-operated or ultra-low power systems where the system may be put to "sleep" by shutting off the system clock.

The dynamic power dissipation, however, depends on:

1. Cross-over currents of the internal CMOS transistors,
2. Internal load capacitances,
3. External load capacitances, and
4. Input voltage levels.

All of the above add up every time there is a logic transition and dynamic power dissipation is the sum of these contributions averaged at a given operating frequency. A practical formula is developed to calculate the dynamic power dissipation (P_D) resulting from the first three items: (input voltage transitions are rail-to-rail)

$$P_D = (C_L + C_{PD}) V_{CC}^2 f,$$

where C_L is the load capacitance; C_{PD} is the "internal power dissipation capacitance", V_{CC} is the supply voltage and f is the operating frequency. The C_{PD} value, as specified in each data sheet, sums up the contributions of the first two factors (crossover currents and internal load capacitances) as a capacitance value for purposes of this calculation. The equation indicates that the dynamic power dissipation is directly proportional to frequency.

The contribution of the fourth factor listed above, the input voltage levels, can also be significant when AHCT or HCTLS inputs are driven by TTL outputs. Figure 20 shows the typical crossover currents generated at the input inverter stage as the input voltage swings from 0 to V_{CC} . This is because both the n-channel and the p-channel transistors turn on partially and provide a low-resistance current path between V_{CC} and ground when the input voltage is near the threshold voltage of the complementary pair. At 2.7V, which is the worst case V_{OH} for TTL parts, the I_{CC} can be as high as 0.5mA per input. This has to be taken into account when calculating the worst-case power dissipation of an AHCT or HCTLS part operating in a TTL environment.

TECHNICAL OVERVIEW

Figure 21 shows the internal power dissipation for an AHCT244 (same for HCTLS244) and compares it with the dynamic power dissipation for LS, ALS and F244. It can be seen that the curves for the bipolar parts are essentially flat for frequencies up to 1 MHz where the quiescent currents mask out the dynamic effects. However, as the frequency goes up, the currents that charge the internal capacitances start adding to the quiescent currents and increase the overall power dissipation. The AHCT244 driven by worst-case TTL voltage levels (all inputs, 50% duty cycle) displays a similar trend but still dissipates an order of magnitude less power than the lowest-power TTL. When CMOS input voltage levels are used, however, the power dissipation is directly proportional to frequency as predicted by the above mentioned formula, and is less than those for the TTL parts, Although the power dissipation becomes comparable to ALS levels at around 10MHz, a crossover does not happen below 50MHz, which is already beyond the maximum clock frequencies of most systems. This behaviour is pretty much the same for all parts in the AHCT and HCTLS families.

In calculating the power dissipation of a system, however, note that only a small percentage of the devices operate at the maximum clock frequency while others operate at a fraction of that. Therefore the average operating frequency tends to be much lower where CMOS has a clear advantage.

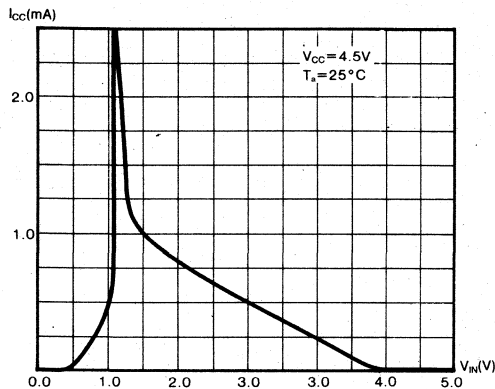


FIGURE 20. Typical crossover current of an AHCT or HCTLS input.

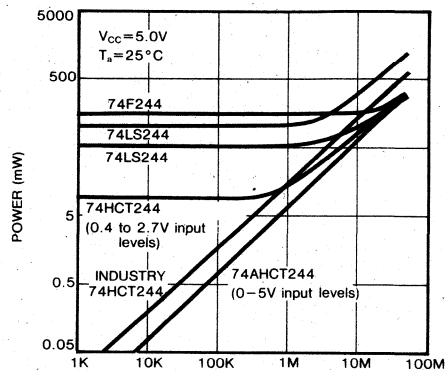


FIGURE 21. Typical dynamic power consumption (no-load) of the 74XX240 octal buffer with all inputs toggling.

3

TECHNICAL OVERVIEW

AC CHARACTERISTICS

All AHCT and HCTLS parts are designed to meet or exceed the ALS and LS propagation delay specifications, respectively. Coupled with the equivalent drive capability, this makes them ideal replacements for the ALS and LS in existing designs. In addition the AC specifications for AHCT and HCTLS parts are improved to reflect more realistic design situations. First of all, unlike LS, the AHCT & HCTLS propagation delays are specified with a 50pF load for all part types and guaranteed over the entire voltage and temperature ranges (5V±10%, -40°C to +85°C). Standard LS propagation delays are specified with a 15pF load and guaranteed only at room temperature and 5V V_{CC}. In addition, all bus drivers specify the propagation delays with a 150pF load capacitance to enable the designer to predict a worst-case maximum speed degradation due to capacitive loading.

The effect of the supply voltage variations on propagation delay is illustrated in *Figure 22* for a bus-driver (AHCT244). It can be seen that the parts are functional over a very wide range of voltages and that they slow down as V_{CC} goes down. However, propagation delays are specified and guaranteed only over the 4.5 to 5.5V range.

Figure 23 shows the effect of temperature on the propagation delays for the same part. As for all CMOS circuits, AHCT and HCTLS parts slow down as temperature goes up. Typically speeds derate linearly from 25°C at about 0.02 ns/°C. The propagation delay at any temperature (between -55°C and +125°C) can therefore be calculated using the following formula:

$$t_{PD}(T) = t_{PD}(25^\circ\text{C}) + k_T (T - 25^\circ\text{C})$$

where:

t_{PD}(T) = Propagation delay at the desired T temperature,

t_{PD}(25°C) = Propagation delay at 25°C,

k_T = Temperature derating factor = 0.02 ns/°C

The effect of capacitive loading of the outputs on the propagation delay is illustrated in *Figure 24*: the higher the load capacitance, the slower the propagation delay gets. To determine the maximum limit for propagation delay at any value of capacitive loading up to 500pF, the following equation is used:

$$t_{PD}(C_L) = t_{PD}(50\text{pF}) + k_C (C_L - 50\text{pF})$$

where:

t_{PD}(C_L) = Maximum propagation delay at the desired C_L,

t_{PD}(50pF) = Maximum propagation delay from device data sheet,

k_C = Maximum multiplicative factor (ns/pF):

- 0.04 for standard outputs, and
- 0.02 for bus-drivers.

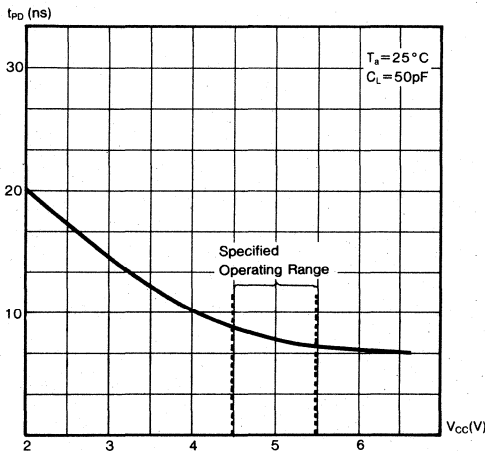


FIGURE 22. Propagation delay versus supply voltage for an AHCT244.

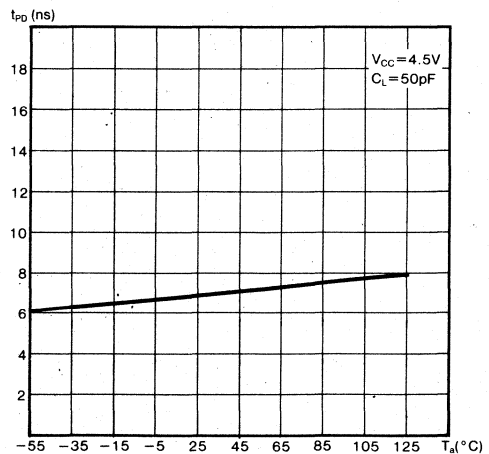


FIGURE 23. Propagation delay versus ambient temperature for an AHCT244.

TECHNICAL OVERVIEW

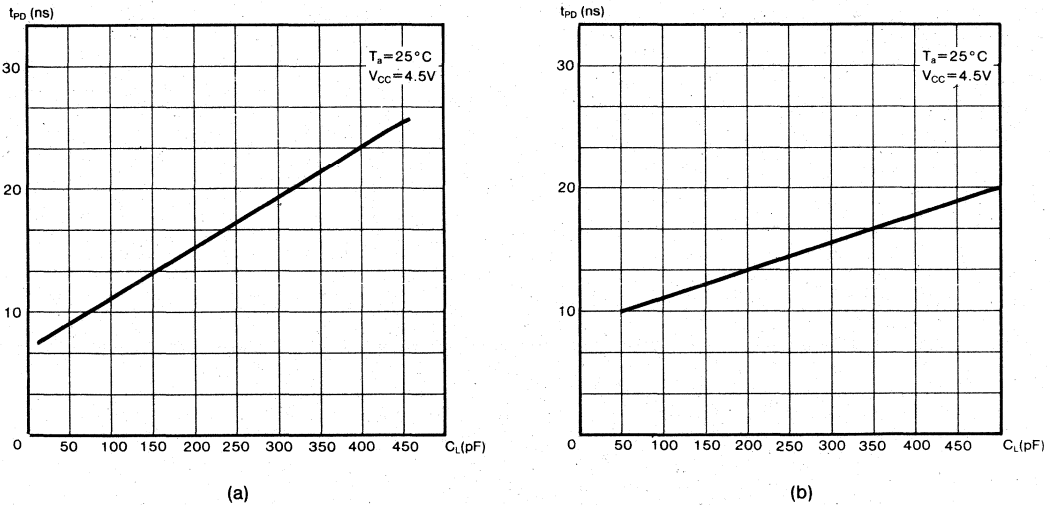


FIGURE 24. Propagation delay versus capacitive load for a (a) standard output (HCTLS00), (b) bus-driver output (HCTLS374)

3

INTERFACING 54/74AHCT AND 54/74HCTLS WITH OTHER LOGIC FAMILIES AND LOADS

Speed and power, while paramount in the initial choice of a logic family, are not the only basis of decision. Another very important factor is the interface flexibility: the inherent capacity of a family to interface with other types of logic and to drive various loads. The Samsung CMOS logic families have this very attractive feature that they can easily be interfaced to all other kinds of digital logic with minimal or no external components.

AHCT and HCTLS parts can be coupled directly with all other TTL, NMOS and CMOS parts if they operate from the same supply voltage. The list includes Standard TTL, Schottky(S), Low-Power Schottky(LS), Advanced Low-Power Schottky(ALS), Advanced Schottky (AS and FAST); all industry-standard CMOS logic families (HC, HCT, CD4000, 14000); all bipolar, NMOS and CMOS microprocessors, microcontrollers, peripherals and memory circuits (see figure 25). This is due to the TTL-compatible input voltage levels coupled with CMOS (rail-to-rail) output voltage swings.

Interface with ECL logic, however, requires external components as shown in Figure 26.

Methods of interfacing with standard CMOS logic families (4000 and 14000), when supply voltages are different, are illustrated in Figure 27 and 28.

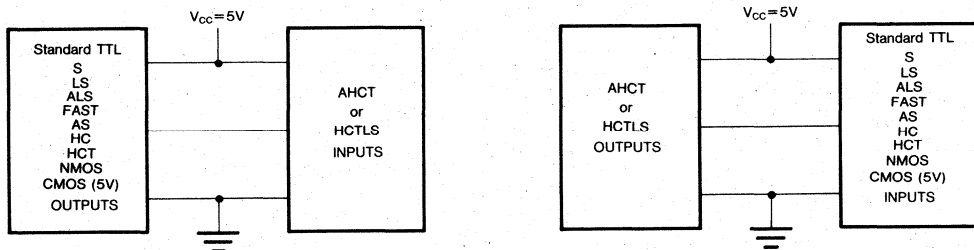


FIGURE 25. Interfacing with TTL, NMOS and other CMOS logic. No extra components are needed.

TECHNICAL OVERVIEW

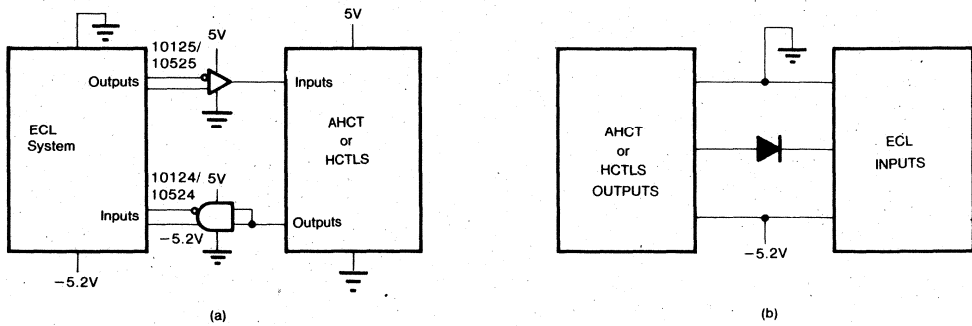


FIGURE 26. (a) General ECL interface

(b) Driving ECL from same power supply.

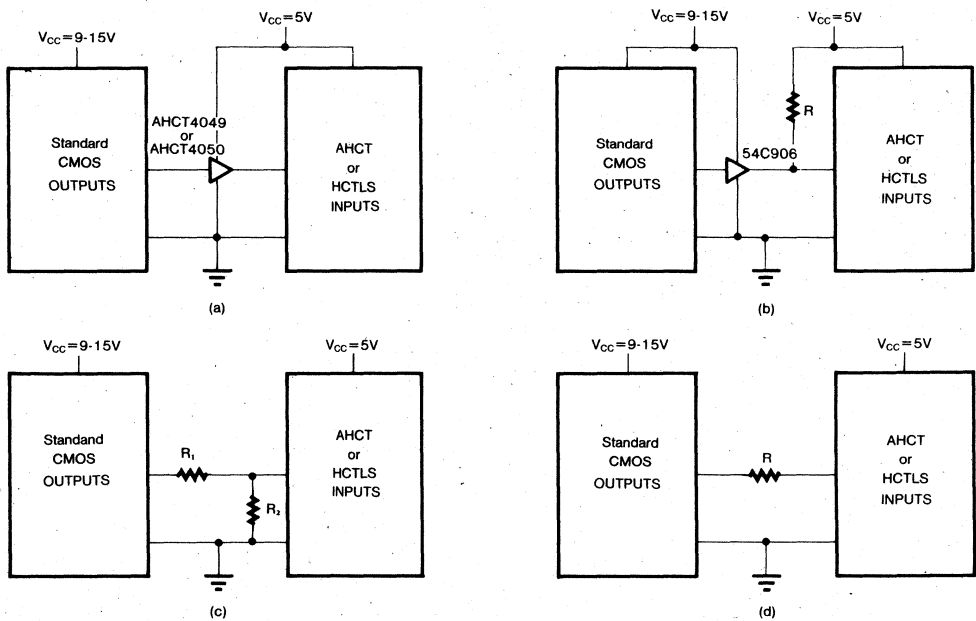


FIGURE 27. Methods of interfacing standard CMOS (4000 and 14000 series) outputs with AHCT and HCTLS inputs when supply voltages are different.

- (a) Using logic down converters,
- (b) Using Open-drain CMOS
- (b) Using resistor divider ($V_{OH} \cdot R_2 / (R_1 + R_2) \leq 5V$)
- (d) Using series resistor

TECHNICAL OVERVIEW

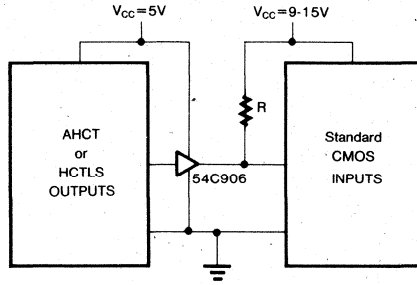


FIGURE 28. Interfacing AHCT and HCTLS outputs with standard CMOS (4000 and 14000) using an open-drain CMOS circuit.

High Voltage and Industrial Control Interfaces

Interfacing with high voltage industrial control circuitry where 4000 or 14000-type of CMOS logic is used has been described in Figure 27 and 28. In rugged industrial and automotive environments, more care may be required to prevent large transients from harming AHCT and HCTLS logic. Figure 29 shows a typical connection that utilizes external diode clamps for input and output protection. The values of R_1 and R_2 depend on the output voltage of the driving circuit and C depends on the noise level and speed. The values of R_3 and R_4 depend on supply voltage and transistor type.

Driving Relays

The high-drive of AHCT and HCTLS outputs enable direct interface with relays, but additional isolation is recommended. Clamp diodes can be used to prevent spikes generated by the relay from harming the circuit. For higher current drive, an external transistor may be employed (Figures 30 (a) and (b)). Alternatively, multiple gates may be connected in parallel to increase the current sinking and sourcing capability.

Driving LED's

Any AHCT or HCTLS output can be used to drive light-emitting diodes (LED's) directly. Figure 31 shows two methods of doing this. The resistor performs the function of current limiter. The luminous intensity of the LED depends on the amount of forward current.

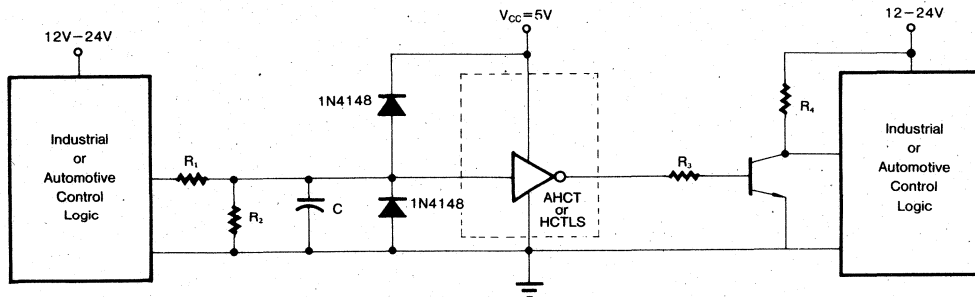


FIGURE 29. Interfacing between AHCT/HCTLS logic and high-voltage industrial and automotive circuitry in rugged environments.

TECHNICAL OVERVIEW

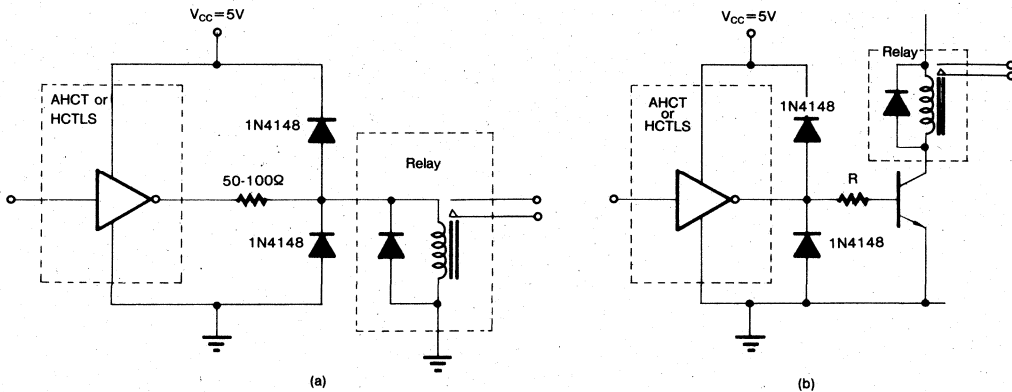


FIGURE 30. Methods of driving relays. (a) Direct and (b) Through a transistor for higher drive ($R = (V_{CC} - 0.7) / I_C / \beta$).

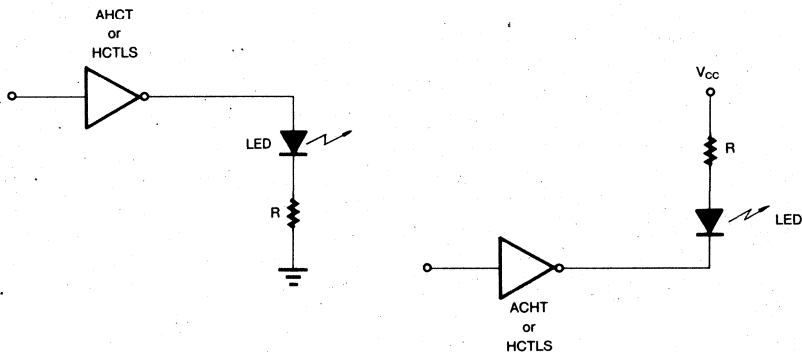


FIGURE 31. Methods of driving LED's

TECHNICAL OVERVIEW

Design Tips

Although the AHCT and HCTLS families are functionally equivalent to the ALS and LS families, some conditions have to be satisfied in order to be able to simply replace them in existing designs. The AHCT and HCTLS families essentially integrate TTL and CMOS characteristics into one family. Therefore, in general, the do's and don'ts of both families apply to the AHCT and HCTLS.

- Don't leave any AHCT or HCTLS input floating. This is frequency overlooked problem with bipolar devices although it is discouraged by every bipolar manufacturer. CMOS inputs have extremely high input impedance and if left unterminated, can pick up noise that causes excursions through the threshold. The result is random switching of the device and high power consumption which can be excessive, especially if the inputs stay very close to the device threshold. Prolonged exposure to these conditions can damage the device. The thing to do is to simply tie the unused inputs to V_{CC} or ground (or they can be tied to nearest operational pin although this may cause more power consumption).

- Don't power up inputs before both V_{CC} and ground are connected, and don't plug boards into or out of powered connectors unless input currents are limited to the absolute maximum ratings specified for the device, and are short-lived. Both conditions can forward bias the input and output ESD protection diodes, resulting in excessive diode currents (see *Figure 32*). If these conditions cannot be avoided, one of the following methods should be used to prevent damage to the AHCT/HCTLS circuits:

- Use connectors that apply power before signals.
- Add series resistors at each input to limit currents to the absolute maximum ratings (*Figure 33a*).
- Add logic to board interfaces that forces all outputs to either ground or high-impedance state when they are connected to unpowered devices (*Figure 33b*).
- Add logic to board inputs to prevent direct interface with unpowered HCTLS inputs (*Figure 33c*). Circuits designed for this purpose are 74AHCT4049 (Hex Inverting Logic Level Down Converter) and 74AHCT4050 (Hex Logic Level Down Converter). These parts have a modified input protection structure that enables them to be used as logic level translators which convert high-level logic to low-level logic while operating from the low logic supply. In this case, since the low logic supply is zero (unpowered), the outputs of the 4049 and 4050 will always be zero regardless of the inputs.

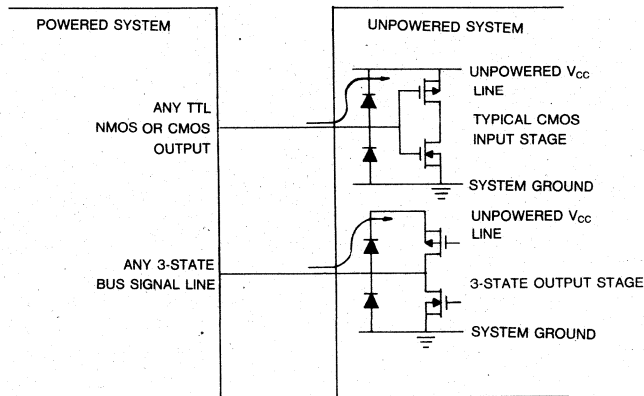


FIGURE 32. Direct interface to unpowered CMOS ICs presents a dangerous situation where high-level signals forward-bias input and output protection diodes and try to “power-up” the V_{CC} line. Excessive currents at such an interface can cause damage to the circuitry.

TECHNICAL OVERVIEW

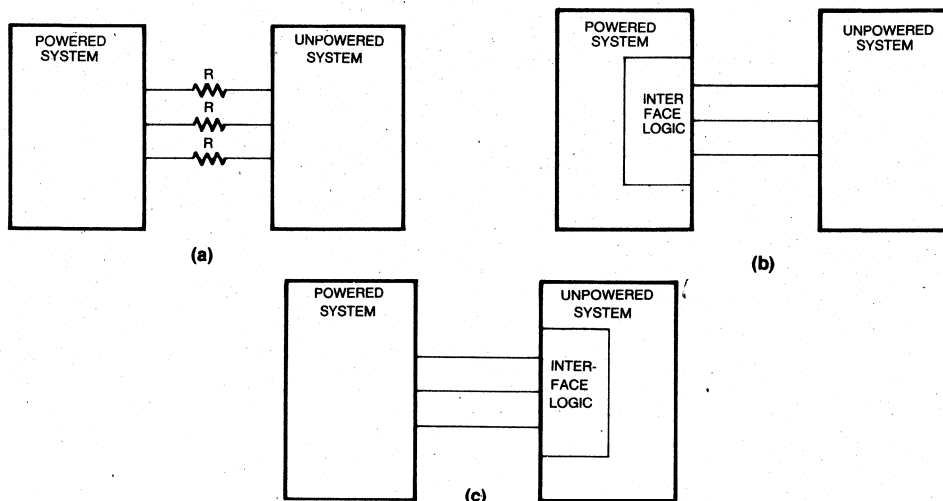


FIGURE 33. Methods of protection in power-down situations: (a) Use of series resistors to limit input currents to absolute maximum ratings, (b) interface logic circuitry that forces all outputs to either ground or high-impedance state, (c) interface circuitry at board inputs that acts as buffer between powered and unpowered devices; ideal components for this purpose are the 74AHCT4049 and 74AHCT 4050 Hex Logic Level Down Converters that lack the V_{CC} diode in their protection circuitry.

- In bus-oriented systems, don't allow the bus to stay in high-impedance state for extended periods of time if it is not terminated, because this will have the same effect as leaving inputs open. Two simple ways of terminating the bus are illustrated in *Figure 34*. Most microprocessor-based systems, however, do not keep the bus in 3-state for long periods, in which case, the bus capacitance can maintain valid logic levels. In these cases, pull-up or pull-down circuitry may not be necessary.

- The edge-rates of the AHCT and HCTLS part are similar to the very high-speed TTL parts. Therefore, system grounding and supply-decoupling techniques normally employed in high-speed TTL designs should be duplicated in AHCT/HCTLS designs to ensure proper operation. A good rule of thumb to reduce the affects of PC board trace inductance is to place 0.01 to 0.1 μF RF-grade capacitors every two-to-five ICs (octal flip-flops and buffers may require more decoupling). This, of course, has to be accompanied by careful pc board layout to minimize these inductances.

- The testing problems encountered in ALS, LS and FAST apply also to AHCT and HCTLS. Most of these problems result from the noise produced by the interactions of the device being tested and the test system. Typical test fixtures have lead inductances several times that of a PC board socket. This inductance, especially in the device ground path is the source of these problems.

The outputs, for example, can cause transient currents in the 50 to 200 mA range within a couple of nanoseconds while changing state. These appear as changes in the voltage drop across the device ground lead. The test system's input and output reference voltages are set with respect to tester ground and are not affected by these transients. Consequently the effective input voltages to the device will vary. If the ground pin goes up 1 volt, all the inputs effectively go down 1 volt. This must be considered in selecting input and output voltage levels. In functional tests, for example, solid input logic levels should be applied, instead of 0.8 and 2.0 volts.

Furthermore, if TTL test programs are to be used, one must be particularly careful not to apply voltages to inputs and outputs that are below ground or above V_{CC} in excess of the absolute maximum limits specified in the data sheets.

TECHNICAL OVERVIEW

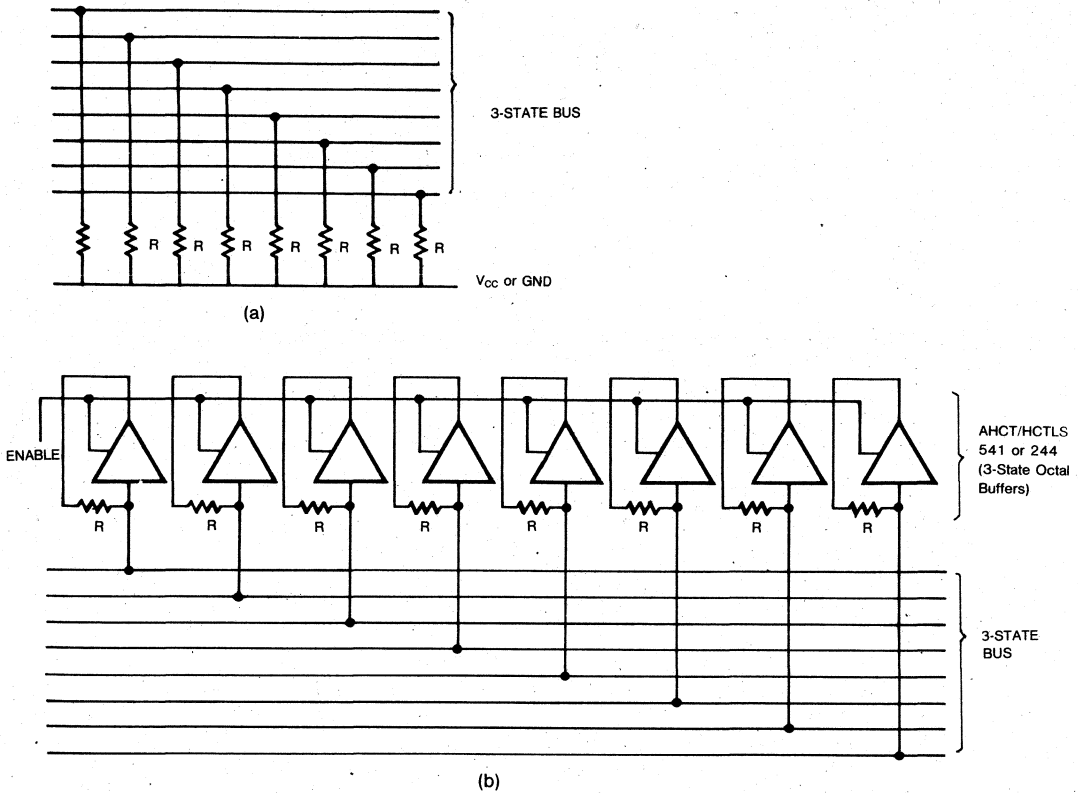


FIGURE 34. Methods of terminating 3-state buses; (a) Pullup or pulldown resistors (b) Use of 3-state buffers. The latter approach terminates the bus to the last active logic level and dissipates no static power.

NOTE

KS54/74AHCT DATA SHEETS 4



FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

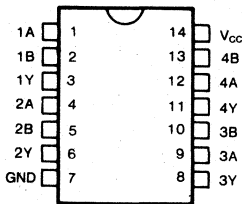
DESCRIPTION

These devices contain four independent 2-input NAND gates that perform the Boolean functions $Y = \overline{A \cdot B}$ or $Y = \overline{A} + \overline{B}$

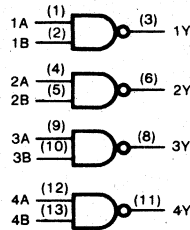
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| Inputs | | Output |
|--------|---|--------|
| A | B | Y |
| H | H | L |
| L | X | H |
| X | L | H |

Absolute Maximum Ratings*

| | |
|--|---|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

| | |
|----------------------|---|
| Plastic Package (N): | $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C |
| Ceramic Package (J): | $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C |

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74AHCT: -40°C to $+85^\circ\text{C}$ |
| | KS54AHCT: -55°C to $+125^\circ\text{C}$ |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|----------------------|---------------------|---------------|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-4\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns, AHCT00)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC}=5.0V$ | | KS74AHCT $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ $V_{CC}=5.0V \pm 10\%$ | | KS54AHCT $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ $V_{CC}=5.0V \pm 10\%$ | | Unit |
|--------------------------------|-----------|-------------------|---|-----|--|-----|---|-----|------|
| | | | Typ | Max | Min | Max | Min | Max | |
| Propagation Delay | t_{PLH} | $C_L=50\text{pF}$ | 7 | 11 | | | 14 | ns | |
| | t_{PHL} | | 7 | 11 | | | 14 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

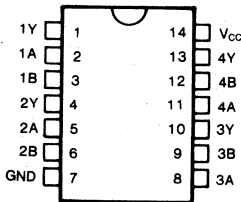
DESCRIPTION

These devices contain four independent 2-input NAND gates with open-drain outputs. Using a suitable pull-up resistor, these outputs may be connected to other open-drain outputs to implement wired-AND functions.

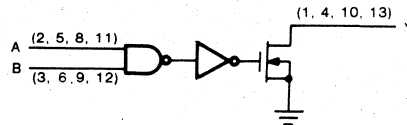
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



4

FUNCTION TABLE

(Each Gate)

| Inputs | | Output |
|--------|---|--------|
| A | B | Y |
| H | H | L |
| L | X | H |
| X | L | H |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C

Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | | KS54AHCT | | Unit |
|--------------------------------------|-----------------|--|--------------------------|---------------------|---|------------|--|--|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | | μA |
| Maximum Output Leakage Current | I_{OZ} | $V_{IN}=V_{IH}$ or V_{IL} $V_{OUT}=V_{CC}$ | | ± 0.5 | ± 5.0 | ± 10.0 | | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | | | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT01

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | | KS74AHCT | | KS54AHCT | | Unit |
|--------------------------------|-----------|--|--------------------------|-------------------|---|--|--|--|------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| Propagation Delay | t_{PLH} | $C_L=50\text{pF}$ $R_L=1\text{k}\Omega$ | 17 | | 25 | | 29 | | ns |
| | t_{PHL} | | 10 | | 16 | | 19 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74ALS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

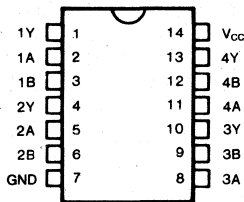
DESCRIPTION

These devices contain four independent 2-input NOR gates that perform the Boolean functions $Y = \overline{A+B}$ or $Y = \overline{A \cdot B}$.

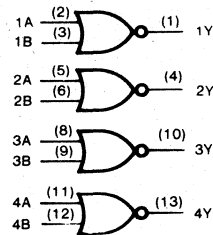
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| Inputs | | Output |
|--------|---|--------|
| A | B | Y |
| H | X | L |
| X | H | L |
| L | L | H |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature

Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C

Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|---|--|-----------------------|-------------------|
| | | | Typ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Guaranteed Limits |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT02

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | | | | | Unit | |
|--------------------------------|-----------|---------------------|--------------------------|-----|---|-----|--|------|--|
| | | | $V_{CC} = 5.0V$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay | t_{PLH} | $C_L = 50\text{pF}$ | 7 | | 12 | | 14 | ns | |
| | t_{PHL} | | 7 | | 12 | | 14 | | |
| Input Capacitance | C_{IN} | | 5 | | | | pF | | |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | pF | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74ALS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
I_{OL} = 8 mA @ V_{OL} = 0.5V
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C

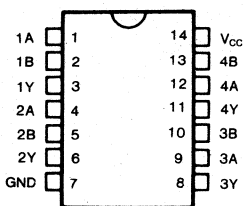
DESCRIPTION

These devices contain four independent 2-input NAND gates with open-drain outputs. Using a suitable pull-up resistor, these outputs may be connected to other open-drain outputs to implement wired-AND functions.

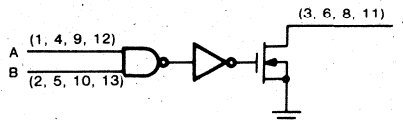
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| Inputs | | Output |
|--------|---|--------|
| A | B | Y |
| H | H | L |
| L | X | H |
| X | L | H |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_D † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|---|--------------------|--|--|---------------|
| | | | Typ | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | 2.0 | 2.0 | 2.0 | 2.0 | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | 0.8 | 0.8 | 0.8 | 0.8 | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | ± 0.1 | ± 1.0 | ± 1.0 | ± 1.0 | | μA |
| Maximum Output Leakage Current | I_{OZ} | $V_{IN}=V_{IH}$ or V_{IL} $V_{OUT}=V_{CC}$ | ± 0.5 | ± 5.0 | ± 5.0 | ± 10.0 | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ per input pin | 2.0 | 20.0 | 20.0 | 40.0 | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | 2.7 | 2.9 | 2.9 | 3.0 | | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT03

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------|-----------|-----------------------|--------------------------|---|-----|--|-----|------|
| | | | $V_{CC}=5.0V$ | $V_{CC}=5.0V \pm 10\%$ | | $V_{CC}=5.0V \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay | t_{PLH} | $C_L=50\text{pF}$ | 17 | | 25 | | 29 | ns |
| | t_{PHL} | $R_L=1\text{k}\Omega$ | 10 | | 16 | | 19 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74ALS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

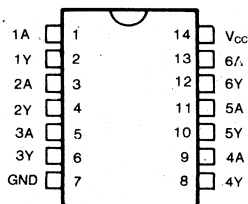
DESCRIPTION

These devices contain six independent inverters. They perform the Boolean function $Y = \bar{A}$.

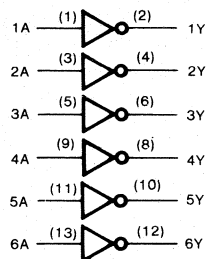
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



4

FUNCTION TABLE

(Each Inverter)

| Input | Output |
|-------|--------|
| A | Y |
| H | L |
| L | H |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_D^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature

Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C

Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ | | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ | | Unit |
|--------------------------------------|-----------------|--|--------------------|----------------------|--|---------------------|---|---------|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-4mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | $V_{CC}-0.1$ 3.7 | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | 0.1 0.4 | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | ± 1.0 | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 2.0 | 20.0 | 40.0 | 40.0 | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | 3.0 | mA | |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT04

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ $V_{CC} = 5.0V$ | | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ $V_{CC} = 5.0V \pm 10\%$ | | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ $V_{CC} = 5.0V \pm 10\%$ | | Unit |
|--------------------------------|----------|-------------|---------------------------------------|------------------------|--|--------|---|----------|------|
| | | | Typ | Min | Max | Min | Max | | |
| | | | Propagation Delay | t_{PLH} t_{PHL} | $C_L=50pF$ | 7 7 | | 11 11 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | | pF | |

* C_{PD} determines the no-load, dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

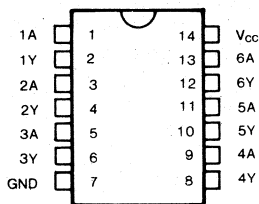
DESCRIPTION

These devices contain six independent inverters with open-drain outputs. Using a suitable pull-up resistor, these outputs may be connected to other open-drain outputs to implement wired-AND functions.

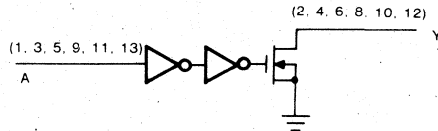
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



4

FUNCTION TABLE

(Each Inverter)

| Input A | Output Y |
|------------|-------------|
| H | L |
| L | H |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: $-40^\circ C$ to $+85^\circ C$
 KS54AHCT: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | KS74AHCT | | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------|--------------------------------------|---------------------------------------|------------|---------|
| | | | | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | 2.0 | 2.0 | 2.0 | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | 0.8 | 0.8 | 0.8 | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | ± 0.1 | ± 1.0 | ± 1.0 | | μA |
| Maximum Output Leakage Current | I_{OZ} | $V_{IN}=V_{IH}$ or V_{IL} $V_{OUT}=V_{CC}$ | ± 0.5 | ± 5.0 | ± 10.0 | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | 2.0 | 20.0 | 40.0 | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | 2.7 | 2.9 | 3.0 | | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT05

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ | KS74AHCT | | KS54AHCT | | Unit |
|--------------------------------|-----------|------------------------------|--------------------|--------------------------------------|---------------------------------------|----------|-----|------|
| | | | $V_{CC} = 5.0V$ | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay | t_{PLH} | $C_L=50pF$ $R_L=1k\Omega$ | 17 | | 25 | | 29 | ns |
| | t_{PHL} | | 8 | | 14 | | 33 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per inverter) | 15 | | | | | pF |

C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74ALS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5\text{V}$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

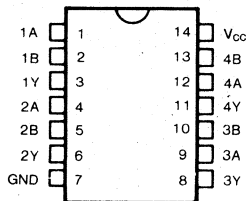
DESCRIPTION

These devices contain four independent 2-input AND gates. They perform the Boolean functions $Y=A \cdot B$ or $Y=\overline{A+B}$.

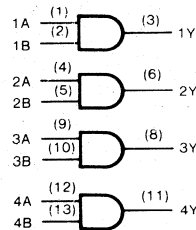
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| Inputs | | Output |
|--------|---|--------|
| A | B | Y |
| H | H | H |
| L | X | L |
| X | L | L |



Absolute Maximum Ratings*

| | |
|---|-----------------|
| Supply Voltage Range V_{CC} , | -0.5V to +7V |
| DC Input Diode Current, I_{IK} ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

| | |
|----------------------|------------------------------|
| Plastic Package (N): | -12mW/°C from 65°C to 85°C |
| Ceramic Package (J): | -12mW/°C from 100°C to 125°C |

Recommended Operating Conditions

| | |
|---|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} .. | 0V to V_{CC} |
| Operating Temperature Range | KS74AHCT: -40°C to +85°C KS54AHCT: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|---|-----|--|--|---------------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-4\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | | $V_{CC}-0.1$ 3.7 | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | | 0.1 0.4 | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | | ± 1.0 | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | | 40.0 | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | | 3.0 | | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT08

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------|-----------|-------------------|--------------------------|---|-----|--|-----|------|
| | | | $V_{CC}=5.0V$ | $V_{CC}=5.0V \pm 10\%$ | | $V_{CC}=5.0V \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay | t_{PLH} | $C_L=50\text{pF}$ | 8 | | 14 | | 17 | ns |
| | t_{PHL} | | 8 | | 14 | | 17 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

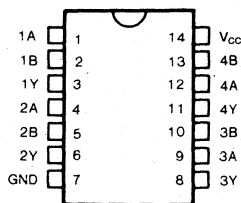
DESCRIPTION

These devices contain four independent 2-input AND gates with open-drain outputs. Using a suitable pull-up resistor, these outputs may be connected to other open-drain outputs to implement wired-AND functions.

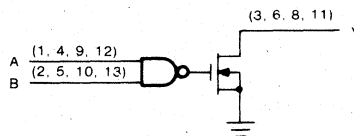
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| Inputs | | Output |
|--------|---|--------|
| A | B | Y |
| H | H | H |
| L | X | L |
| X | L | L |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_{d1} † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit |
|--------------------------------------|-----------------|--|--------------------------|---|--|---------------|
| | | | Typ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | 0.8 | 0.8 | 0.8 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Output Leakage Current | I_{OZ} | $V_{IN}=V_{IH}$ or V_{IL} $V_{OUT}=V_{CC}$ | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ per input pin | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT09

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0V$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | | Unit |
|--------------------------------|-----------|--|---|-----|---|-----|--|----|------|
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay | t_{PLH} | $C_L = 50\text{pF}$ $R_L = 1\text{k}\Omega$ | 18 | | 27 | | 31 | ns | |
| | t_{PHL} | | 9 | | 15 | | 18 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74ALS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

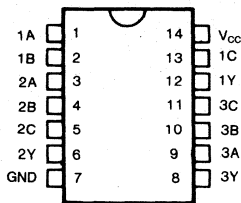
DESCRIPTION

These devices contain three independent 3-input NAND gates. They perform the Boolean functions $Y = \overline{A \cdot B \cdot C}$ or $Y = \overline{A + B + C}$.

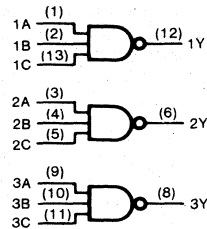
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| Inputs | | | Output |
|--------|---|---|--------|
| A | B | C | Y |
| H | H | H | L |
| L | X | X | H |
| X | L | X | H |
| X | X | L | H |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, $P_{D\uparrow}$ 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN}, V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C

Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|---|-------------------|--|-------------------|---------------|
| | | | Typ | Guaranteed Limits | Typ | Guaranteed Limits | Typ | Guaranteed Limits | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | | 2.0 | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | | 0.8 | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-4\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | | $V_{CC}-0.1$ 3.7 | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | | 0.1 0.4 | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | | ± 1.0 | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ per input pin | | 2.0 | 20.0 | | 40.0 | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | | 3.0 | | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns, AHCT10)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC}=5.0V$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC}=5.0V \pm 10\%$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC}=5.0V \pm 10\%$ | | Unit |
|--------------------------------|-----------|-------------------|---|-----|---|-----|--|----|------|
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay | t_{PLH} | $C_L=50\text{pF}$ | 9 | | 15 | | 18 | ns | |
| | t_{PHL} | | 9 | | 15 | | 18 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74ALS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

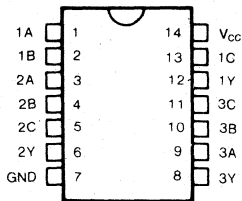
DESCRIPTION

These devices contain three independent 3-input AND gates. They perform the Boolean functions $Y = A \cdot B \cdot C$ or $Y = \overline{A+B+C}$.

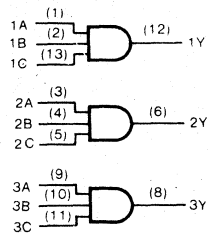
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



4

FUNCTION TABLE

(Each Gate)

| Inputs | | | Output |
|--------|---|---|--------|
| A | B | C | Y |
| H | H | H | H |
| L | X | X | L |
| X | L | X | L |
| X | X | L | L |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to $+85^\circ\text{C}$
 KS54AHCT: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|--|--|---|--|---------------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | | 2.0 | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | | 0.8 | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | | $V_{CC} - 0.1$ 3.7 | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | | 0.1 0.4 | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | | ± 1.0 | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | | 40.0 | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | | 3.0 | | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT11

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | Unit |
|--------------------------------|-----------|-------------------------|--------------------------|--|-----|---|-----|------|
| | | | $V_{CC} = 5.0V$ | $V_{CC} = 5.0V \pm 10\%$ | | $V_{CC} = 5.0V \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay | t_{PLH} | $C_L = 50\text{pF}$ | 9 | | 15 | | 18 | ns |
| | t_{PHL} | $R_L = 1\text{k}\Omega$ | 9 | | 15 | | 18 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.
 † For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

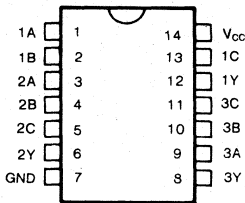
These devices contain three independent 3-input NAND gates with open-drain outputs. They perform the Boolean functions $Y = A \cdot B \cdot C$ or $Y = \bar{A} + \bar{B} + \bar{C}$.

Using a suitable pull-up resistor, these outputs may be connected to other open-drain outputs to implement wired-AND functions.

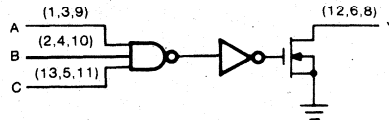
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



4

FUNCTION TABLE

(Each Gate)

| Inputs | | | Output |
|--------|---|---|--------|
| A | B | C | Y |
| H | H | H | L |
| L | X | X | H |
| X | L | X | H |
| X | X | L | H |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, $P_{d\uparrow}$ 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit |
|--------------------------------------|-----------------|--|--------------------------|--|---|---------|
| | | | Typ | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | 0.8 | 0.8 | 0.8 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Output Leakage Current | I_{OZ} | $V_{IN}=V_{IH}$ or V_{IL} $V_{OUT}=V_{CC}$ | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT12

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ $V_{CC} = 5.0V$ | | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ $V_{CC} = 5.0V \pm 10\%$ | | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ $V_{CC} = 5.0V \pm 10\%$ | | Unit |
|--------------------------------|-----------|--------------|---------------------------------------|-----|--|-----|---|----|------|
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay | t_{PLH} | $C_L = 50pF$ | 19 | | 27 | | 31 | ns | |
| | t_{PHL} | | 11 | | 18 | | 22 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74ALS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

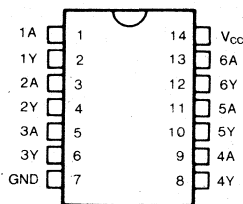
DESCRIPTION

These Schmitt-trigger devices contain six independent inverters. They perform the Boolean function $Y = \bar{A}$.

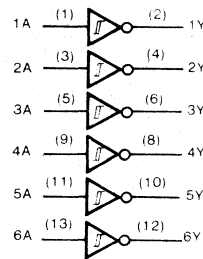
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Inverter)

| Input | Output |
|-------|--------|
| A | Y |
| H | L |
| L | H |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} ... -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN}, V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|--|-----------------|--|--------------------------|------------------------|------------------------|---|---------------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | |
| Minimum Positive-Going Threshold Voltage | V_{T+} | | 1.6 | 1.9 | 1.9 | 1.9 | V |
| Maximum Negative-Going Threshold Voltage | V_{T-} | | 0.8 | 0.5 | 0.5 | 0.5 | V |
| Hysteresis ($V_{T+} - V_{T-}$) | V_H | Min | 0.8 | 0.4 | 0.4 | 0.4 | V |
| | | Max | 0.8 | 1.4 | 1.4 | 1.4 | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT14

| Characteristic | Symbol | Conditions† | T _a = 25°C | KS74AHCT | | KS54AHCT | | Unit |
|--------------------------------|------------------|-----------------------|------------------------|---|-----|--|-----|------|
| | | | V _{CC} = 5.0V | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay | t _{PLH} | C _L = 50pF | 8 | | 14 | | 17 | ns |
| | t _{PHL} | | 8 | | 14 | | 17 | |
| Input Capacitance | C _{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | (per gate) | 15 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

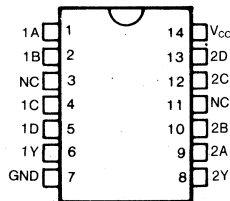
DESCRIPTION

These devices contain two independent 4-input NAND gates. They perform the Boolean functions $Y = \overline{A \cdot B \cdot C \cdot D}$ or $Y = \overline{\overline{A} + \overline{B} + \overline{C} + \overline{D}}$ in positive logic.

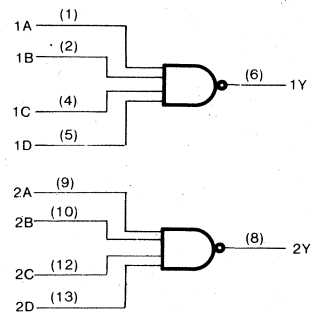
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each gate)

| INPUTS | | | | OUTPUT |
|--------|---|---|---|--------|
| A | B | C | D | Y |
| H | H | H | H | L |
| L | X | X | X | H |
| X | L | X | X | H |
| X | X | L | X | H |
| X | X | X | L | H |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|---|--|--|--|---------------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | | 2.0 | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | | 0.8 | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | | $V_{CC} - 0.1$ 3.7 | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | | 0.1 0.4 | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | | ± 1.0 | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | | 40.0 | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | | 3.0 | | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT20

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC}=5.0V$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC}=5.0V \pm 10\%$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC}=5.0V \pm 10\%$ | | Unit |
|--------------------------------------|-----------|---------------------|---|-----|---|-----|--|----|------|
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay, Any input to Y | t_{PLH} | $C_L = 50\text{pF}$ | 7 | | 11 | | 13 | ns | |
| | t_{PHL} | | 7 | | 11 | | 13 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

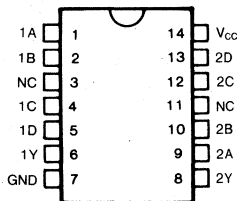
† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74ALS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



FUNCTION TABLE

(Each gate)

| INPUTS | | | | OUTPUT |
|--------|---|---|---|--------|
| A | B | C | D | Y |
| H | H | H | H | H |
| L | X | X | X | L |
| X | L | X | X | L |
| X | X | L | X | L |
| X | X | X | L | L |

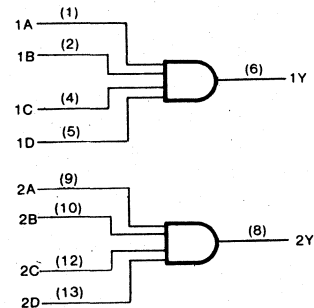
DESCRIPTION

These devices contain two independent 4-input AND gates. They perform the Boolean functions $Y = A \cdot B \cdot C \cdot D$ or $Y = \overline{A} + \overline{B} + \overline{C} + \overline{D}$ in positive logic.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAM



Absolute Maximum Ratings*

| | | |
|--|-------|-----------------|
| Supply Voltage Range V_{CC} | | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | | ± 20 mA |
| DC Output Diode Current, I_{OK} | | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | | ± 20 mA |
| Continuous Output Current Per Pin, I_O | | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | | ± 35 mA |
| Continuous Current Through | | |
| V_{CC} or GND pins | | ± 125 mA |
| Storage Temperature Range, T_{stg} | | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | | |
|--|-------|---|
| Supply Voltage, V_{CC} | | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | | 0V to V_{CC} |
| Operating Temperature | | |
| Range | | KS74AHCT: -40°C to +85°C KS54AHCT: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|---|--------------------------|------------------------|---|-----------------------|--|-----|---------------|
| | | | Typ | Guaranteed Limits | Min | Max | Min | Max | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | | | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT21

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------|---------------------|--------------------------|---|-----|--|-----|------|
| | | | $V_{CC}=5.0\text{V}$ | $V_{CC}=5.0\text{V} \pm 10\%$ | | $V_{CC}=5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, Any input to Y | t_{PLH} | $C_L = 50\text{pF}$ | 8 | | 14 | | 17 | ns |
| | t_{PHL} | | 8 | | 14 | | 17 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74ALS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C

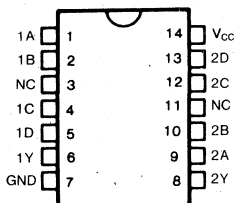
DESCRIPTION

These devices contain two independent 4-input NAND gates. These gates perform the Boolean functions $Y = \overline{A \cdot B \cdot C \cdot D}$ or $Y = \overline{A + B + C + D}$ in positive logic. The open-drain outputs require pull-up resistors to perform correctly. They may be connected to other open-drain outputs to implement active low wired-OR or active high wired-AND functions.

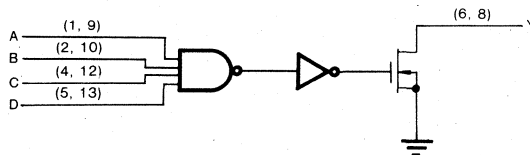
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| INPUTS | | | | OUTPUT |
|--------|---|---|---|--------|
| A | B | C | D | Y |
| H | H | H | H | L |
| L | X | X | X | H |
| X | L | X | X | H |
| X | X | L | X | H |
| X | X | X | L | H |



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} ... -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit |
|--------------------------------------|-----------------|--|--------------------|--|---|---------|
| | | | Typ | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | 0.8 | 0.8 | 0.8 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Output Leakage Current | I_{OZ} | $V_{IN}=V_{IH}$ or V_{IL} $V_{OUT}=V_{CC}$ | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT22

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ $V_{CC} = 5.0V$ | | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ $V_{CC} = 5.0V \pm 10\%$ | | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ $V_{CC} = 5.0V \pm 10\%$ | | Unit |
|--------------------------------|----------|-------------|---------------------------------------|------------------------|--|----------|---|----------|------|
| | | | Typ | Min | Max | Min | Max | | |
| | | | Propagation Delay, Any input to Y | t_{PLH} t_{PHL} | $C_L=50pF$ $R_L=1k\Omega$ | 19 11 | | 29 18 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.



Preliminary Specifications

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

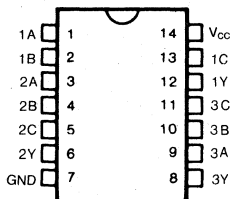
DESCRIPTION

These devices contain two independent 3-input NOR gates. They perform the Boolean functions $Y = A + B + C$ or $Y = \bar{A} \cdot \bar{B} \cdot \bar{C}$ in positive logic.

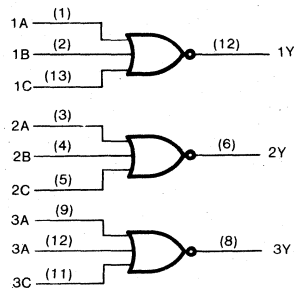
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| INPUTS | | | OUTPUT |
|--------|---|---|--------|
| A | B | C | Y |
| H | X | X | L |
| X | H | X | L |
| X | X | H | L |
| L | L | L | H |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{Sg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|---|-----------------------|--|-------------------|---------------|
| | | | Typ | Guaranteed Limits | Typ | Guaranteed Limits | Typ | Guaranteed Limits | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | | | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT27

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------|---------------------|--------------------------|---|-----|--|-----|------|
| | | | $V_{CC} = 5.0V$ | $V_{CC} = 5.0V \pm 10\%$ | | $V_{CC} = 5.0V \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, Any input to Y | t_{PLH} | $C_L = 50\text{pF}$ | 8 | | 14 | | 17 | ns |
| | t_{PHL} | | 8 | | 14 | | 17 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.



FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

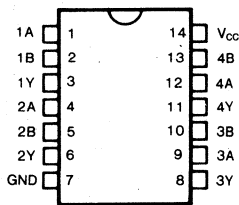
DESCRIPTION

These devices contain four independent 2-input OR gates. They perform the Boolean functions $Y = A + B$ or $Y = A \cdot B$.

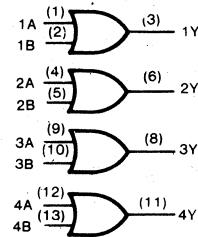
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damaged due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| Inputs | | Outputs |
|--------|---|---------|
| A | B | Y |
| H | X | H |
| X | H | H |
| L | L | L |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to $+85^\circ\text{C}$
 KS54AHCT: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|--|---|-----------------------|-------------------|
| | | | Typ | KS74AHCT $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | KS54AHCT $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | Guaranteed Limits |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT32

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0V$ | | KS74AHCT $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | | KS54AHCT $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | | Unit |
|--------------------------------|-----------|---------------------|---|-----|--|-----|---|----|------|
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay | t_{PLH} | $C_L = 50\text{pF}$ | 8 | | 14 | | 17 | ns | |
| | t_{PHL} | | 8 | | 14 | | 17 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

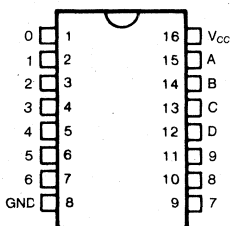


Preliminary Specifications

FEATURES

- Full decoding of Input Logic
- All outputs are High for Invalid BCD Conditions
- Also for application as 3-Line to 8-Line Decoders
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



FUNCTION TABLE

| No. | Inputs | | | | Outputs | | | | | | | | | | |
|---------|--------|---|---|---|---------|---|---|---|---|---|---|---|---|---|---|
| | D | C | B | A | 0 | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | |
| 0 | L | L | L | L | L | H | H | H | H | H | H | H | H | H | H |
| 1 | L | L | L | H | H | L | H | H | H | H | H | H | H | H | H |
| 2 | L | L | H | L | H | H | L | H | H | H | H | H | H | H | H |
| 3 | L | L | H | H | H | H | H | L | H | H | H | H | H | H | H |
| 4 | L | H | L | L | H | H | H | H | L | H | H | H | H | H | H |
| 5 | L | H | L | H | H | H | H | H | H | L | H | H | H | H | H |
| 6 | L | H | H | L | H | H | H | H | H | H | L | H | H | H | H |
| 7 | L | H | H | H | H | H | H | H | H | H | H | L | H | H | H |
| 8 | H | L | L | L | H | H | H | H | H | H | H | H | L | H | H |
| 9 | H | L | L | H | H | H | H | H | H | H | H | H | H | L | H |
| INVALID | H | L | H | L | H | H | H | H | H | H | H | H | H | H | H |
| | H | L | H | H | H | H | H | H | H | H | H | H | H | H | H |
| | H | H | L | L | H | H | H | H | H | H | H | H | H | H | H |
| | H | H | L | H | H | H | H | H | H | H | H | H | H | H | H |
| | H | H | H | L | H | H | H | H | H | H | H | H | H | H | H |

DESCRIPTION

The '42 decoder accepts for active-high BCD inputs and provides 10 mutually exclusive active-low outputs, as shown by logic symbol or diagram. The active-low outputs facilitate addressing other MSI units with active low input enables.

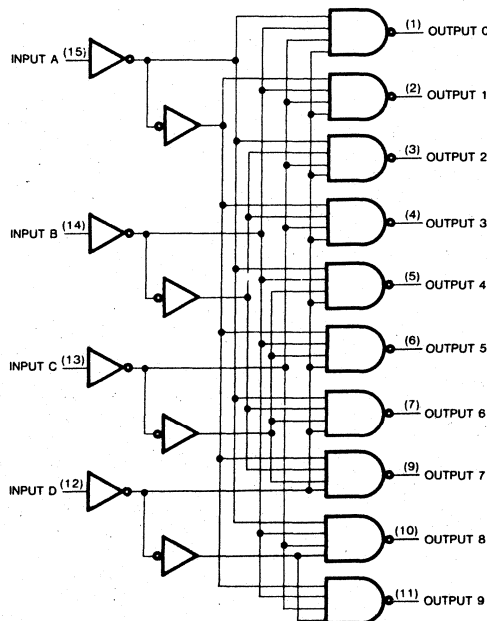
The logic design of the '42 ensures that all outputs are high when binary codes greater than nine are applied to the inputs.

The most significant input, D, produces a useful inhibit function when the '42 is used as a 1-of-8 decoder. The D input can also be used as the Data input in an 8-output demultiplexer application.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN}, V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|----------------------|----------------------|---------------------|---|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-4mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | ± 0.1 | ± 1.0 | ± 1.0 | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | 8.0 | 80.0 | 160.0 | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | 2.7 | 2.9 | 3.0 | mA | |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT42

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ | | KS74AHCT | | KS54AHCT | | Unit |
|-----------------------------------|-----------|-------------|--------------------|-----|--------------------------------------|-----|---------------------------------------|----|------|
| | | | $V_{CC}=5.0V$ | | $T_a = -40^\circ C$ to $+85^\circ C$ | | $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay, Any input to Y | t_{PLH} | $C_L=50pF$ | 11 | | 18 | | 22 | ns | |
| | t_{PHL} | | 11 | | 18 | | 22 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.



Preliminary Specifications

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

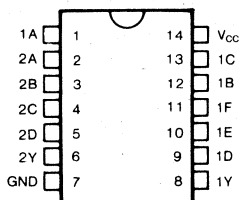
The '51 performs the following Boolean functions:
 $1Y = (1A \cdot 1B \cdot 1C) + (1D \cdot 1E \cdot 1F)$
 $2Y = (2A \cdot 2B) + (2C \cdot 2D)$

The '58 performs:
 $1Y = (1A \cdot 1B \cdot 1C) + (1D \cdot 1E \cdot 1F)$
 $2Y = (2A \cdot 2B) + (2C \cdot 2D)$

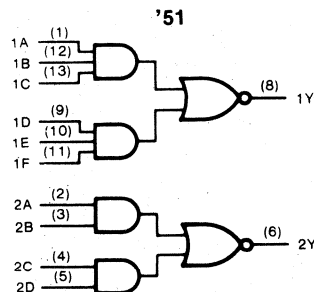
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAMS

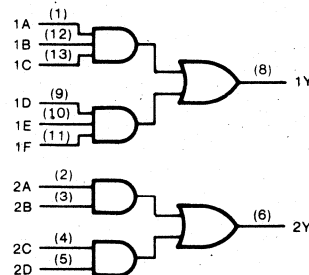


FUNCTION TABLES

| Inputs | | | | | | Output 1Y | |
|-----------------------|----|----|----|----|----|-----------|-----|
| 1A | 1B | 1C | 1D | 1E | 1F | '51 | '58 |
| H | H | H | X | X | X | L | H |
| X | X | X | H | H | H | L | H |
| Any other combination | | | | | | H | L |

| Inputs | | | | Output 2Y | |
|-----------------------|----|----|----|-----------|-----|
| 2A | 2B | 2C | 2D | '51 | '58 |
| H | H | X | X | L | H |
| X | X | H | H | L | H |
| Any other combination | | | | H | L |

'58



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
Continuous Output Current Per Pin, I_O
(-0.5V $< V_O < V_{CC} + 0.5V$) ± 35 mA
Continuous Current Through
 V_{CC} or GND pins ± 125 mA
Storage Temperature Range, T_{stg} , -65°C to +150°C
Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
Operating Temperature
Range KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C
Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ | | KS54HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ | | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|---|-----------------------|--|--|---------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 2.0 | 20.0 | 40.0 | | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | | | mA |

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AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT51, AHCT58

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ | | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ | | Unit |
|--------------------------------|-----------|--------------|--------------------|--|-----|---|-----|------|
| | | | $V_{CC}=5.0V$ | $V_{CC}=5.0V \pm 10\%$ | | $V_{CC}=5.0V \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay | t_{PLH} | $C_L = 50pF$ | 9 | | 15 | | 18 | ns |
| | t_{PHL} | | 9 | | 15 | | 18 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Objective Specifications

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

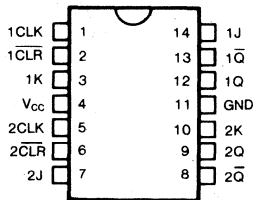
DESCRIPTION

These devices contain two independent J-K negative-edge-triggered flip-flops. A low level at $\overline{\text{CLR}}$ input resets the outputs regardless of the levels of the other inputs. When $\overline{\text{CLR}}$ is inactive (high), data at the J and K inputs meeting the setup time requirements are transferred to the outputs on the negative-going edge of the clock pulse. Clock triggering occurs at a voltage level and is not directly related to the rise time of the clock pulse. Following the hold time interval, data at the J and K inputs may be changed without affecting the levels at the outputs. These versatile flip-flops can perform as toggle flip-flops by tying J and K high.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | | | Outputs | |
|-------------------------|-----|---|---|---------|-----------------------|
| $\overline{\text{CLR}}$ | CLK | J | K | Q | $\overline{\text{Q}}$ |
| L | X | X | X | L | H |
| H | ↓ | L | L | Q_0 | \overline{Q}_0 |
| H | ↓ | H | L | H | L |
| H | ↓ | L | H | L | H |
| H | ↓ | H | H | TOGGLE | |
| H | H | X | X | Q_0 | \overline{Q}_0 |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d [†] 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN}, V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: $-40^\circ C$ to $+85^\circ C$
 KS54AHCT: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|------------------------|--------------------------------------|---------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ C$ to $+85^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 4.0 | 40.0 | 80.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

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AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT73

| Characteristic | Symbol | Conditions† | KS74AHCT | | | | | Unit | |
|---|----------------------|---------------------|--|-----|--|-----|---|------|--|
| | | | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 45 | 30 | | 25 | MHz | | |
| Propagation Delay, CLK to Q or \bar{Q} | t_{PLH} | | 10 | | 17 | | 20 | ns | |
| | t_{PHL} | | 10 | | 17 | | 20 | | |
| Propagation Delay, CLR to Q or \bar{Q} | t_{PLH} | | 10 | | 17 | | 20 | ns | |
| | t_{PHL} | | 10 | | 17 | | 20 | | |
| Setup Time before CLK↓ | J or K | | t_{su} | 8 | 13 | | 15 | ns | |
| | \bar{CLR} Inactive | 8 | | 13 | | 15 | | | |
| Hold Time, J or K after CLK↓ | t_h | | -3 | 0 | | 0 | ns | | |
| Pulse Width | CLK High or Low | t_w | 8 | 13 | | 15 | ns | | |
| | \bar{CLR} Low | | 8 | 13 | | 15 | | | |
| Input Capacitance | C_{IN} | | 5 | | | | pF | | |
| Power Dissipation Capacitance* | C_{PD} | (per flip-flop) | 40 | | | | pF | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

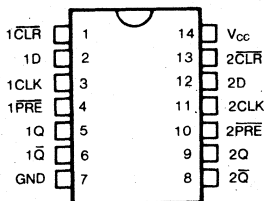
DESCRIPTION

These devices contain two independent positive-edge-triggered D-type flip-flops. Each flip-flop has its own data, clock, preset and clear inputs and complementary Q and \bar{Q} outputs. The preset and clear inputs are active-low and operate independently of the clock. Data at the D input is transferred to the Q outputs on the positive transition of the clock, provided setup requirements have been met.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | | | Outputs | |
|--------|-----|-----|---|-----------|-----------|
| PRE | CLR | CLK | D | Q | \bar{Q} |
| L | H | X | X | H | L |
| H | L | X | X | L | H |
| L | L | X | X | H* | H* |
| H | H | ↑ | H | H | L |
| H | H | ↑ | L | L | H |
| H | H | L | X | No Change | No Change |
| H | H | H | X | No Change | No Change |
| H | H | ↓ | X | No Change | No Change |

*Both outputs will remain high as long as PRE and CLR are low, but the output states are unpredictable if PRE and CLR go high simultaneously.

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature

Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C

Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------|----------------------|----------------------|---------------------|---------|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-4mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 4.0 | 40.0 | 80.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT74

| Characteristic | Symbol | Conditions† | T _a = 25°C | KS74AHCT | | KS54AHCT | | Unit | |
|--|---------------------|-----------------------|------------------------|---|-----|--|-----|------|----|
| | | | V _{CC} = 5.0V | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | | |
| | | | Typ | Min | Max | Min | Max | | |
| Maximum Clock Frequency | f _{max} | C _L = 50pF | 55 | 34 | | 30 | | MHz | |
| Propagation Delay, CLK to Q or \bar{Q} | t _{PLH} | | 10 | | 17 | | 20 | | ns |
| | t _{PHL} | | 10 | | 17 | | 20 | | |
| Propagation Delay, PRE or CLR to Q or \bar{Q} | t _{PLH} | | 9 | | 15 | | 18 | | ns |
| | t _{PHL} | | 9 | | 15 | | 18 | | |
| Setup Time before CLK↑ | Data | | t _{su} | 7 | 12 | | 15 | | ns |
| | PRE or CLR Inactive | 5 | | 8 | | 10 | | | |
| Hold Time, Data after CLK↑ | t _h | | -3 | 0 | | 0 | | ns | |
| Pulse Width | CLK High or Low | t _w | 9 | 15 | | 17 | | ns | |
| | PRE or CLR Low | | 9 | 15 | | 17 | | | |
| Input Capacitance | C _{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C _{PD} | | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

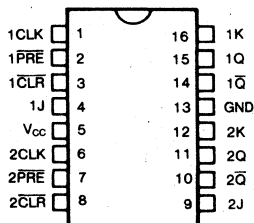
† For AC switching test circuits and timing waveforms see section 2.

Objective Specifications

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



DESCRIPTION

These parts consist of two negative-edge-triggered J-K flip-flops with independent J, K, preset, clear and clock inputs and complementary outputs. The J-K inputs at each flip-flop are enabled when the clock goes high. The input data are transferred to the outputs on the negative-going edge of the clock pulse, provided the setup requirements have been met.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLE

| Inputs | | | | | Outputs | |
|-------------------------|-------------------------|-----|---|---|----------------|-------------------------|
| $\overline{\text{PRE}}$ | $\overline{\text{CLR}}$ | CLK | J | K | Q | $\overline{\text{Q}}$ |
| L | H | X | X | X | H | L |
| H | L | X | X | X | L | H |
| L | L | X | X | X | H* | H* |
| H | H | ↓ | L | L | Q ₀ | $\overline{\text{Q}}_0$ |
| H | H | ↓ | H | L | H | L |
| H | H | ↓ | L | H | L | H |
| H | H | ↓ | H | H | TOGGLE | |
| H | H | H | X | X | Q ₀ | $\overline{\text{Q}}_0$ |

* Both outputs will remain high as long as preset and clear are low, but the output states are unpredictable if preset and clear go high simultaneously.

Absolute Maximum Ratings*

| | |
|---|-----------------|
| Supply Voltage Range V_{CC} , | -0.5V to +7V |
| DC Input Diode Current, I_{IK} ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74AHCT: -40°C to +85°C KS54AHCT: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|------------------------|---|---------------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 4.0 | 40.0 | 80.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

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AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT76

| Characteristic | Symbol | Conditions† | T _a = 25°C | KS74AHCT | | KS54AHCT | | Unit | |
|--|-------------------------------------|-----------------------|------------------------|---|-----|--|-----|------|----|
| | | | V _{CC} = 5.0V | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | | |
| | | | Typ | Min | Max | Min | Max | | |
| Maximum Clock Frequency | f _{max} | C _L = 50pF | 45 | 30 | | 25 | | MHz | |
| Propagation Delay, CLK to Q or \bar{Q} | t _{PLH} | | 10 | | 17 | | 20 | | ns |
| | t _{PHL} | | 10 | | 17 | | 20 | | ns |
| Propagation Delay, \bar{PRE} or \bar{CLR} to Q or \bar{Q} | t _{PLH} | | 10 | | 17 | | 20 | | ns |
| | t _{PHL} | | 10 | | 17 | | 20 | | ns |
| Setup Time before CLK↓ | J or K | | t _{su} | 10 | 17 | | 20 | | ns |
| | \bar{PRE} or \bar{CLR} Inactive | t _{su} | 10 | 17 | | 20 | | ns | |
| Hold Time, Data after CLK↓ | t _h | | -3 | 0 | | 0 | | ns | |
| Pulse Width | CLK High or Low | t _w | 8 | 13 | | 15 | | ns | |
| | \bar{PRE} or \bar{CLR} Low | | 8 | 13 | | 15 | | ns | |
| Input Capacitance | C _{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C _{PD} | (per flip-flop) | 40 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.



Objective Specifications

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74ALS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

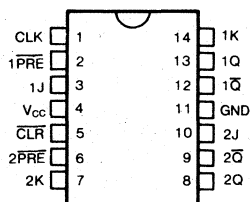
DESCRIPTION

These parts consist of two negative-edge-triggered J-K flip-flops with independent J, K and preset inputs and complementary outputs. The clear and clock inputs are common to both flip-flops. The J-K inputs are enabled when the clock goes high. The input data are transferred to the outputs on the negative-going edge of the clock pulse, provided the setup requirements have been met.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | | | | Outputs | |
|--------|-----|-----|---|---|---------|-------------|
| PRE | CLR | CLK | J | K | Q | \bar{Q} |
| L | H | X | X | X | H | L |
| H | L | X | X | X | L | H |
| L | L | X | X | X | H* | H* |
| H | H | ↓ | L | L | Q_0 | \bar{Q}_0 |
| H | H | ↓ | H | L | H | L |
| H | H | ↓ | L | H | L | H |
| H | H | ↓ | H | H | TOGGLE | TOGGLE |
| H | H | H | X | X | Q_0 | \bar{Q}_0 |

*Both outputs will remain high as long as preset and clear are low, but the output states are unpredictable if preset and clear go high simultaneously.

Absolute Maximum Ratings*

| | |
|--|---|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_d^\dagger | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

| | |
|----------------------|---|
| Plastic Package (N): | $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C |
| Ceramic Package (J): | $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C |

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74AHCT: -40°C to $+85^\circ\text{C}$ KS54AHCT: -55°C to $+125^\circ\text{C}$ |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|--|---|-----------------------|-------------------|
| | | | Typ | KS74AHCT $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | KS54AHCT $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | Guaranteed Limits |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 4.0 | 40.0 | 80.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT78

| Characteristic | Symbol | Conditions ¹ | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|--|---------------------|-------------------------|--------------------------|---|--|---------------------------------|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Clock Frequency | f_{max} | | 45 | 30 | | 25 | | MHz |
| Propagation Delay, CLK to Q or \bar{Q} | t_{PLH} | $C_L = 50\text{pF}$ | 10 | | 17 | | 20 | ns |
| | t_{PHL} | | 10 | | 17 | | 20 | |
| Propagation Delay, PRE or CLR to Q or \bar{Q} | t_{PLH} | | 10 | | 17 | | 20 | ns |
| | t_{PHL} | | 10 | | 17 | | 20 | |
| Setup Time before CLK \downarrow | J or K | t_{su} | 10 | 17 | | 20 | | ns |
| | PRE or CLR Inactive | | 10 | 17 | | 20 | | |
| Hold Time, J or K after CLK \downarrow | t_h | | -3 | 0 | | 0 | | ns |
| Pulse Width | CLK High or Low | t_w | 8 | 13 | | 15 | | ns |
| | PRE or CLR Low | | 8 | 13 | | 15 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per flip-flop) | 40 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

¹ For AC switching test circuits and timing waveforms see section 2.

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74ALS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C

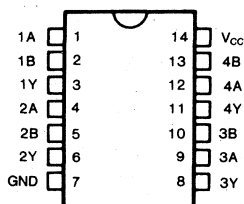
DESCRIPTION

These devices contain four independent 2-input Exclusive-OR gates. They perform the Boolean functions $Y=A\oplus B$ or $Y=\overline{A}B+AB$.

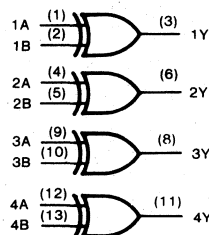
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| Inputs | | Output |
|--------|---|--------|
| A | B | Y |
| L | L | L |
| L | H | H |
| H | L | H |
| H | H | L |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|----------------------|---------------------|---------------|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-4\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

4

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT86

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|--|-----------|---------------------|--------------------------|--|-----|---|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, A or B to Y (Other Input Low) | t_{PLH} | $C_L = 50\text{pF}$ | 10 | | 16 | | 19 | ns |
| | t_{PHL} | | 10 | | 16 | | 19 | |
| Propagation Delay, A or B to Y (Other Input High) | t_{PLH} | | 12 | | 20 | | 24 | ns |
| | t_{PHL} | | 12 | | 20 | | 24 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per flip-flop) | 15 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

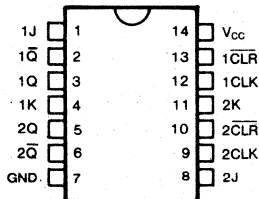
DESCRIPTION

These devices contain two independent J-K negative-edge-triggered flip-flops. A low level at the $\overline{\text{CLR}}$ input resets the outputs regardless of the levels of the other inputs. When $\overline{\text{CLR}}$ is inactive (high), data at the J and K inputs meeting the setup time requirements are transferred to the outputs on the negative-going edge of the clock pulse. Clock triggering occurs at a voltage level and is not directly related to the rise time of the clock pulse. Following the hold time interval, data at the J and K inputs may be changed without affecting the levels at the outputs. These versatile flip-flops can perform as toggle flip-flops by tying J and K high.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | | | Outputs | |
|-------------------------|-----|---|---|---------|-----------------------|
| $\overline{\text{CLR}}$ | CLK | J | K | Q | $\overline{\text{Q}}$ |
| L | X | X | X | L | H |
| H | ↓ | L | L | Q_0 | \overline{Q}_0 |
| H | ↓ | H | L | H | L |
| H | ↓ | L | H | L | H |
| H | ↓ | H | H | TOGGLE | |
| H | H | X | X | Q_0 | \overline{Q}_0 |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------|----------------------|----------------------|--------------------------------------|---------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ C$ to $+85^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-4mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 4.0 | 40.0 | 80.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT107

| Characteristic | Symbol | Conditions† | T _a = 25°C | KS74AHCT | | KS54AHCT | | Unit |
|---|----------------------|-----------------------|------------------------|---------------------------------|----------------------------------|------------------------------|-----|------|
| | | | V _{CC} = 5.0V | T _a = -40°C to +85°C | T _a = -55°C to +125°C | V _{CC} = 5.0V ± 10% | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Clock Frequency | f _{max} | C _L = 50pF | 45 | 30 | | 25 | | MHz |
| Propagation Delay, CLK to Q or \bar{Q} | t _{PLH} | | 10 | | 17 | | 20 | ns |
| | t _{PHL} | | 10 | | 17 | | 20 | ns |
| Propagation Delay, \bar{CLR} to Q or \bar{Q} | t _{PLH} | | 10 | | 17 | | 20 | ns |
| | t _{PHL} | 10 | | 17 | | 20 | ns | |
| Setup Time before CLK↓ | J or K | t _{su} | 10 | 17 | | 20 | | ns |
| | \bar{CLR} Inactive | | 10 | 17 | | 20 | | ns |
| Hold Time, J or K after CLK↓ | t _h | | -3 | 0 | | 0 | | ns |
| Pulse Width | CLK High or Low | t _w | 8 | 13 | | 15 | | ns |
| | \bar{CLR} Low | | 8 | 13 | | 15 | | ns |
| Input Capacitance | C _{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | (per flip-flop) | 40 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

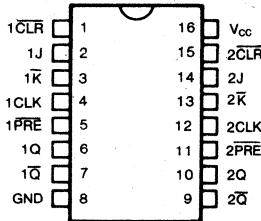
DESCRIPTION

These devices contain two positive-edge-triggered J-K flip-flops with independent preset and clear inputs and complementary Q and \bar{Q} outputs. The present and clear inputs are active-low and operate independently of the clock Data at the J and \bar{K} inputs are transferred to the outputs on the positive transition of the clock provided setup requirements have been met. These versatile flip-flops can perform as toggle flip-flops by grounding K and tying J high. They can also perform as D-type flops if J and \bar{K} are tied together.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | | | | Outputs | |
|-------------------------|-------------------------|-----|---|-----------|---------|-------------|
| $\overline{\text{PRE}}$ | $\overline{\text{CLR}}$ | CLK | J | \bar{K} | Q | \bar{Q} |
| L | H | X | X | X | H | L |
| H | L | X | X | X | L | H |
| L | L | X | X | X | H* | H* |
| H | H | ↑ | L | L | L | H |
| H | H | ↑ | H | L | TOGGLE | |
| H | H | ↑ | L | H | Q_0 | \bar{Q}_0 |
| H | H | ↑ | H | H | H | L |
| H | H | L | X | X | Q_0 | \bar{Q}_0 |

*Both outputs will remain high as long as $\overline{\text{PRE}}$ and $\overline{\text{CLR}}$ are low, but the output states are unpredictable if $\overline{\text{PRE}}$ and $\overline{\text{CLR}}$ go high simultaneously.

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: $-40^\circ C$ to $+85^\circ C$
 KS54AHCT: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | | Unit |
|--------------------------------------|-----------------|--|--------------------|--|---|-----------------------|---------|
| | | | Typ | Guaranteed Limits | | | |
| | | | | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 4.0 | 40.0 | 80.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

4

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT109

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|--|---|---------------------|--------------------------|---|--|----------|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 55 | 34 | | 30 | | MHz |
| Propagation Delay, CLK to Q or \bar{Q} | t_{PLH} | | 10 | | 17 | | 20 | ns |
| | t_{PHL} | | 10 | | 17 | | 20 | ns |
| Propagation Delay, PRE or CLR to Q or \bar{Q} | t_{PLH} | | 10 | | 17 | | 20 | ns |
| | t_{PHL} | 10 | | 17 | | 20 | ns | |
| Setup Time before CLK† | Data | t_{su} | 7 | 12 | | 15 | | ns |
| | $\overline{\text{PRE}}$ or $\overline{\text{CLR}}$ Inactive | | 5 | 8 | | 10 | | ns |
| Hold Time, Data after CLK† | t_h | | -3 | 0 | | 0 | | ns |
| Pulse Width | CLK High or Low | t_w | 9 | 15 | | 17 | | ns |
| | $\overline{\text{PRE}}$ or $\overline{\text{CLR}}$ Low | | 9 | 15 | | 17 | | ns |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
I_{OL} = 8 mA @ V_{OL} = 0.5V
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C

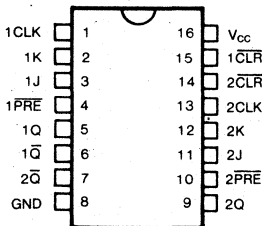
DESCRIPTION

These parts consist of two negative-edge-triggered J-K flip-flops with independent J, K, preset, clear and clock inputs and complementary outputs. The J-K inputs at each flip-flop are enabled when the clock goes high. The input data are transferred to the outputs on the negative-going edge of the clock pulse, provided the setup requirements have been met.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | | | | Outputs | |
|--------|-----|-----|---|---|----------------|-----------------|
| PRE | CLR | CLK | J | K | Q | Q̄ |
| L | H | X | X | X | H | L |
| H | L | X | X | X | L | H |
| L | L | X | X | X | H* | H* |
| H | H | ↓ | L | L | Q ₀ | Q̄ ₀ |
| H | H | ↓ | H | L | H | L |
| H | H | ↓ | L | H | L | H |
| H | H | ↓ | H | H | TOGGLE | |
| H | H | H | X | X | Q ₀ | Q̄ ₀ |

*Both outputs will remain high as long as PRE and CLR are low, but the output states are unpredictable if PRE and CLR go high simultaneously.



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} .. 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|--|---|-----------------------|---------|
| | | | Typ | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| Guaranteed Limits | | | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 4.0 | 40.0 | 80.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT112

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit | |
|--|--------------------------|---------------------|--------------------------|---|--|---------------------------------|-----|------|----|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | $V_{CC} = 5.0\text{V} \pm 10\%$ | | | |
| | | | Typ | Min | Max | Min | Max | | |
| Maximum Clock Frequency | f_{max} | | 50 | 30 | | 25 | | MHz | |
| Propagation Delay, CLK to Q or \bar{Q} | t_{PLH} | $C_L = 50\text{pF}$ | 10 | | 17 | | 20 | ns | |
| | t_{PHL} | | 10 | | 17 | | 20 | | |
| Propagation Delay, PRE or CLR to Q or \bar{Q} | t_{PLH} | | | 10 | | 17 | | 20 | ns |
| | t_{PHL} | | | 10 | | 17 | | 20 | |
| Setup Time before CLK↓ | J or K | t_{su} | 10 | 17 | | 20 | | ns | |
| | PRE or CLR Inactive | | 10 | 17 | | 20 | | | |
| Hold Time, Data after CLK↓ | t_h | | -3 | 0 | | 0 | | ns | |
| Pulse Width | CLK High or Low | t_w | 10 | 17 | | 20 | | ns | |
| | PRE or CLR Low | | 6 | 10 | | 15 | | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} (per flip-flop) | | 40 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

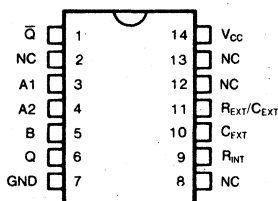
† For AC switching test circuits and timing waveforms see section 2.

Product Preview

FEATURES

- Schmitt-trigger for slow Input transitions
- Internal timing resistor
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | | Outputs | |
|--------|----|---|---------|----|
| A1 | A2 | B | Q | Q̄ |
| L | X | H | L | H |
| X | L | H | L | H |
| X | X | L | L | H |
| H | H | X | L | H |
| H | ↓ | H | ⏏ | ⏏ |
| ↓ | H | H | ⏏ | ⏏ |
| ↓ | ↓ | H | ⏏ | ⏏ |
| L | X | ↑ | ⏏ | ⏏ |
| X | L | ↑ | ⏏ | ⏏ |

DESCRIPTION

These multivibrators feature dual negative-transition-triggered inputs and a single positive-transition-triggered input which can be used as an inhibit input. Complementary output pulses are provided.

Pulse triggering occurs at particular voltage level and is not directly related to the transition time of the input pulse. Schmitt-trigger input circuitry for the B input allows jitter-free triggering from inputs with transition rates as slow as 1 volt/second, providing the circuit with excellent noise immunity.

Once fired, the outputs are independent of further transitions of the inputs and are a function only of the timing components. Input pulses may be of any duration relative to the output pulse. Output pulse length may be varied from 40 nanoseconds to 28 seconds by choosing appropriate timing components. With no external timing components (i.e., R_{INT} connected to V_{CC} , C_{EXT} and C_{EXT}/C_{EXT} open), an output pulse of typically 30 or 35 nanoseconds is achieved which may be used as a d-c triggered reset signal.

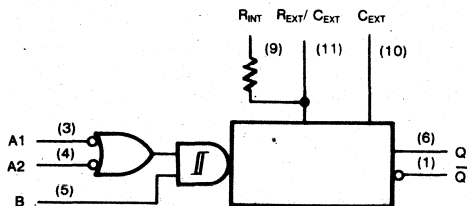
Pulse width stability is achieved through internal compensation and is virtually independent of V_{CC} and temperature. In most applications, pulse stability will only be limited by the accuracy of external timing components.

Jitter-free operation is maintained over the full temperature and V_{CC} ranges for more than six decades of timing capacitance (10 pF to 10 μ F) and more than one decade of timing resistance (2 k Ω to 40 k Ω). Throughout these ranges, pulse width is defined by the relationship $tw_{(out)} = C_{EXT} R_T \ln 2 = 0.7 C_{EXT} R_T$. In circuits where pulse cutoff is not critical, timing capacitance up to 1000 μ F and timing resistance as low as 1.4 k Ω may be used. Also, the range of jitter-free output pulse widths is extended if V_{CC} is held to 5 volts and free-air temperature is 25 $^{\circ}$ C. Duty cycles as high as 90% are achieved when using maximum recommended R_T . Higher duty cycles are available if a certain amount of pulse-width jitter is allowed.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAM



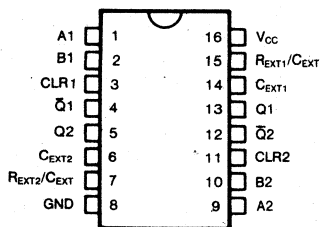
- Notes:**
1. An external capacitor may be connected between C_{EXT} (positive) and R_{EXT}/C_{EXT} .
 2. To use the internal timing resistor, connect R_{INT} to V_{CC} . For improved pulse width accuracy and repeatability connect an external resistor between R_{EXT}/C_{EXT} and V_{CC} with R_{INT} open-circuited.

Product Preview

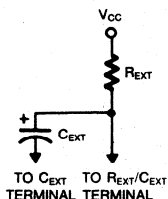
FEATURES

- Simple pulse width formula $T = RC$
- Wide pulse range: 40 ns to ∞ (typ)
- Part to part variation: $\pm 5\%$ (typ)
- Schmitt Trigger A & B Inputs enable infinite signal input rise and fall times
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



TIMING COMPONENT



DESCRIPTION

The '123 consists of two independent monostable multivibrators that feature both a negative, A, and a positive, B, transition triggered input, either of which can be used as an inhibit input. Also included is a clear input that when taken low resets the one shot. The '123 can be triggered on the positive transition of the clear while A is held low and B is held high.

The '123 is retriggerable. That is, it may be triggered repeatedly while their outputs are generating a pulse and the pulse will be extended.

Pulse width stability over a wide range of temperature and supply is achieved using linear CMOS techniques. The output pulse equation is simply: $PW = (R_{EXT}) (C_{EXT})$; where PW is in seconds, R is ohms, and C is in farads.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLE

| Inputs | | | Outputs | |
|--------|---|---|---------|-----------|
| CLR | A | B | Q | \bar{Q} |
| L | X | X | L | H |
| X | H | X | L | H |
| X | X | L | L | H |
| H | L | ↑ | | |
| H | ↓ | H | | |
| ↑ | L | H | | |

Preliminary Specifications

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

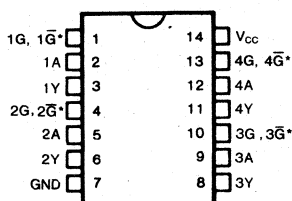
DESCRIPTION

These bus buffers feature four independent line drivers with 3-state outputs. The output enable functions for the '125 buffers are active-low, while those for '126 are active high.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



* \bar{G} for '125; G for '126

FUNCTION TABLES

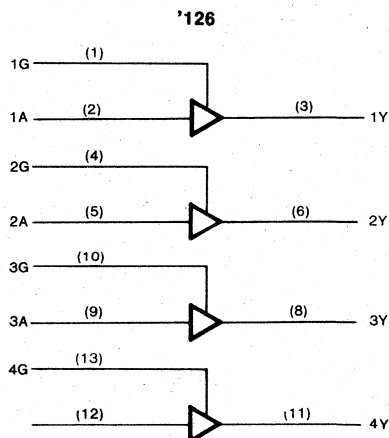
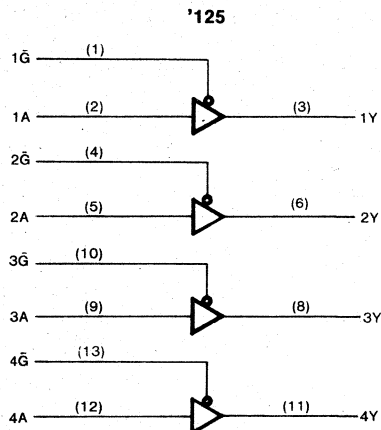
'125

| Inputs | | Output |
|--------|-----------|--------|
| A | \bar{G} | Y |
| H | L | H |
| L | L | L |
| X | H | Z |

'126

| Inputs | | Output |
|--------|---|--------|
| A | G | Y |
| H | H | H |
| L | H | L |
| X | L | Z |

LOGIC DIAGRAMS



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to $+85^\circ\text{C}$
 KS54AHCT: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|--|---|-----------------------|---------------|
| | | | Typ | KS74AHCT $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | KS54AHCT $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT125, AHCT126

| Characteristic | Symbol | Conditions† | T _a = 25°C | KS74AHCT | | KS54AHCT | | Unit | |
|---|------------------|----------------------------------|------------------------|---------------------------------|-----|----------------------------------|-----|------|----|
| | | | V _{CC} = 5.0V | T _a = -40°C to +85°C | | T _a = -55°C to +125°C | | | |
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay, A to Y | t _{PLH} | C _L = 50pF | 6 | | 10 | | 12 | ns | |
| | | C _L = 150pF | 9 | | 19 | | 23 | | |
| | t _{PHL} | C _L = 50pF | 6 | | 10 | | 12 | | |
| | | C _L = 150pF | 9 | | 19 | | 23 | | |
| Output Enable Time Enable to Y | t _{PZH} | R _L = 1kΩ | C _L = 50pF | 11 | | 18 | | 22 | ns |
| | | | C _L = 150pF | 17 | | 27 | | 33 | |
| | t _{PZL} | R _L = 1kΩ | C _L = 50pF | 11 | | 18 | | 22 | |
| | | | C _L = 150pF | 17 | | 27 | | 33 | |
| Output Disable Time, Enable to Y | t _{PHZ} | R _L = 1kΩ | 13 | | 18 | | 22 | ns | |
| | t _{PLZ} | C _L = 50pF | 13 | | 18 | | 22 | | |
| Input Capacitance | C _{IN} | | 5 | | | | | pF | |
| Output Capacitance | C _{OUT} | Output disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C _{PD} | G or \bar{G} = V _{CC} | 5 | | | | | pF | |
| | | G or \bar{G} = GND | 30 | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74ALS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

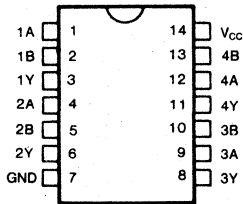
These Schmitt-trigger devices contain four independent NAND gates. They perform the Boolean function $Y = \overline{A \cdot B} = \overline{A} + \overline{B}$ in positive logic.

The input threshold levels are temperature compensated and can be triggered from the slowest of input ranges and still give jitter-free output signals.

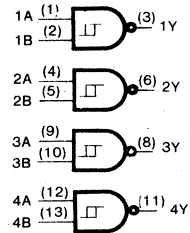
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| INPUTS | | OUTPUTS |
|--------|---|---------|
| A | B | Y |
| L | L | H |
| L | H | H |
| H | L | H |
| H | H | L |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN}, V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74AHCT | KS54AHCT | Unit |
|--|-----------------|--|--------------------|----------------------|--------------------------------------|---------------------------------------|---------|
| | | | Typ | | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | |
| | | | Guaranteed Limits | | | | |
| Minimum Positive-Going Threshold Voltage | V_{T+} | | 1.6 | 1.9 | 1.9 | 1.9 | V |
| Maximum Negative-Going Threshold Voltage | V_{T-} | | 0.8 | 0.5 | 0.5 | 0.5 | V |
| Hysteresis ($V_{T+} - V_{T-}$) | V_H | Min | 0.8 | 0.4 | 0.4 | 0.4 | V |
| | | Max | 0.8 | 1.4 | 1.4 | 1.4 | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-4mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT132

| Characteristic | Symbol | Conditions† | T _a = 25°C | KS74AHCT | | KS54AHCT | | Unit |
|--------------------------------------|------------------|-----------------------|------------------------|---------------------------------|-----|----------------------------------|----|------|
| | | | V _{CC} = 5.0V | T _a = -40°C to +85°C | | T _a = -55°C to +125°C | | |
| | | | Typ | V _{CC} = 5.0V ± 10% | | V _{CC} = 5.0V ± 10% | | |
| | | | Min | Max | Min | Max | | |
| Propagation Delay, Any input to Y | t _{PLH} | C _L = 50pF | 8 | | 14 | | 17 | ns |
| | t _{PHL} | | 8 | | 14 | | 17 | |
| Input Capacitance | C _{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | (per gate) | 15 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74ALS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C

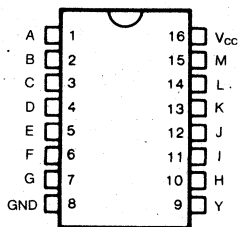
DESCRIPTION

The '133 contains a single 13-input NAND gate. It performs the boolean functions (in positive logic):
 $Y = \bar{A} \cdot \bar{B} \cdot \bar{C} \cdot \bar{D} \cdot \bar{E} \cdot \bar{F} \cdot \bar{G} \cdot \bar{H} \cdot \bar{I} \cdot \bar{J} \cdot \bar{K} \cdot \bar{L} \cdot \bar{M}$
 $Y = \bar{A} + \bar{B} + \bar{C} + \bar{D} + \bar{E} + \bar{F} + \bar{G} + \bar{H} + \bar{I} + \bar{J} + \bar{K} + \bar{L} + \bar{M}$

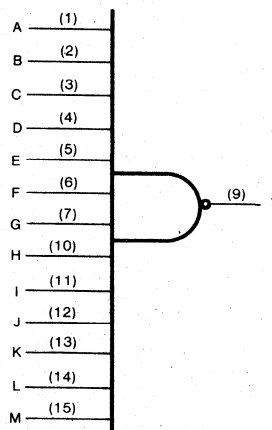
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

| INPUTS A THRU M | | OUTPUT Y |
|--------------------|---|----------|
| All inputs | H | L |
| One or more inputs | L | H |

Absolute Maximum Ratings*

| | |
|--|-----------------|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74AHCT: -40°C to +85°C KS54AHCT: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|---|--------------------------|--|---|-----------------------|---------------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT133

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|--------------------------------------|-----------|---------------------|--------------------------|--|-----|---|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, Any input to Y | t_{PLH} | $C_L = 50\text{pF}$ | 11 | | 18 | | 22 | ns |
| | t_{PHL} | | 11 | | 18 | | 22 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF |

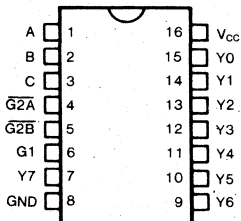
* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Designed specifically for high-speed memory decoders and data transmission systems
- Incorporates 3 enable inputs to simplify cascading and/or data reception
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



FUNCTION TABLE

| Enable Inputs | | Select Inputs | | | Outputs | | | | | | | |
|---------------|-----|---------------|---|---|---------|----|----|----|----|----|----|----|
| G1 | G2* | C | B | A | Y0 | Y1 | Y2 | Y3 | Y4 | Y5 | Y6 | Y7 |
| X | H | X | X | X | H | H | H | H | H | H | H | H |
| L | X | X | X | X | H | H | H | H | H | H | H | H |
| H | L | L | L | L | L | L | L | L | L | L | L | L |
| H | L | L | L | H | H | L | H | H | H | H | H | H |
| H | L | L | H | L | H | H | L | H | H | H | H | H |
| H | L | L | H | H | H | H | H | L | H | H | H | H |
| H | L | H | L | L | H | H | H | H | L | H | H | H |
| H | L | H | L | H | H | H | H | H | H | L | H | H |
| H | L | H | H | L | H | H | H | H | H | H | L | H |
| H | L | H | H | H | H | H | H | H | H | H | H | L |

*G2 = G2A + G2B

DESCRIPTION

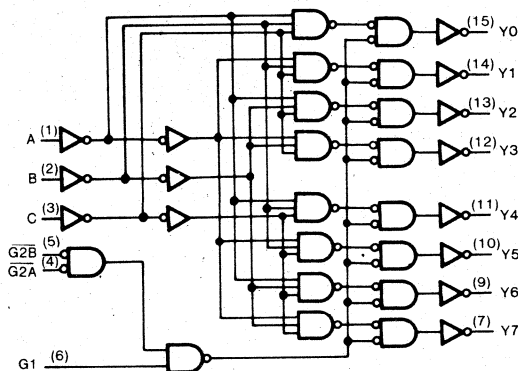
These devices are designed to be used in high-performance memory-decoding or data-routing applications requiring very short propagation delay times. In high-performance memory systems, these decoders can be used to minimize the effects of system decoding. When used with high-speed memories utilizing a fast-enable circuit, the delay times of these decoders and the enable time of the memory are usually less than the typical access time of the memory. This means that the effective system delay introduced by the decoder is negligible.

The conditions at the binary select inputs and the three enable inputs select one of eight input lines. Two active-low and one active-high enable inputs reduce the need for external gates or inverters when expanding. A 24-line decoder can be implemented without external inverters and a 32-line decoder requires only one inverter. An enable input can be used as a data input for demultiplexing applications.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|---|--|-----------------------|---------------|
| | | | Typ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT138

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|---|-----------|---------------------|--------------------------|---|-----|--|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, A, B, C or any Y | t_{PLH} | $C_L = 50\text{pF}$ | 12 | | 20 | | 24 | ns |
| | t_{PHL} | | 12 | | 20 | | 24 | |
| Propagation Delay, G1 to any Y | t_{PLH} | | 10 | | 17 | | 20 | ns |
| | t_{PHL} | | 10 | | 17 | | 20 | |
| Propagation Delay, G2A or G2B to any Y | t_{PLH} | | 10 | | 17 | | 20 | ns |
| | t_{PHL} | | 10 | | 17 | | 20 | |
| Input Capacitance | C_{IN} | | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | 50 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Designed specifically for high-speed memory decoders and data transmission systems
- Incorporates 2 enable inputs to simplify cascading and/or data reception
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

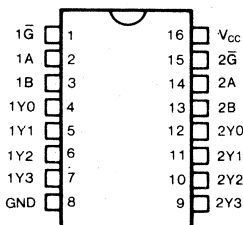
These devices are designed to be used in high-performance memory-decoding or data-routing applications requiring very short propagation delay times. In high-performance memory systems, these decoders can be used to minimize the effects of system decoding. When used with high-speed memories utilizing a fast-enable circuit, the delay times of these decoders and the enable time of the memory are usually less than the typical access time of the memory, this means that the effective system delay introduced by the decoder is negligible.

The '139 consists of two individual two-line to four-line decoders in a single package. The active-low enable input can be used as a data line in demultiplexing applications.

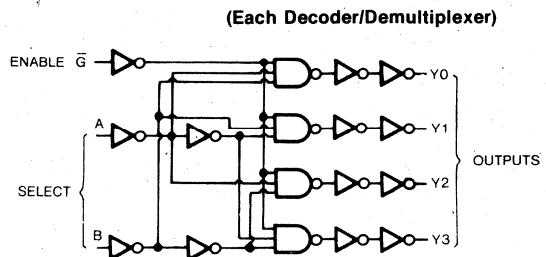
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

| Inputs | | Outputs | | | |
|---------------------|---------------|---------|----|----|----|
| Enable \bar{G} | Select B A | Y0 | Y1 | Y2 | Y3 |
| H | X X | H | H | H | H |
| L | L L | L | H | H | H |
| L | L H | H | L | H | H |
| L | H L | H | H | L | H |
| L | H H | H | H | H | L |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C

Input Rise & Fall Times; t_r , t_f Max 500 ns
 * Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|--|---|-----------------------|---------|
| | | | Typ | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| Guaranteed Limits | | | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT139

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|-----------------------------------|-----------|---------------------|--------------------------|---|--|---------------------------------|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, A or B to Y | t_{PLH} | $C_L = 50\text{pF}$ | 11 | | 17 | | 20 | ns |
| | t_{PHL} | | 11 | | 17 | | 20 | |
| Propagation Delay, G to any Y | t_{PLH} | | 11 | | 18 | | 21 | ns |
| | t_{PHL} | | 11 | | 18 | | 21 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | 50 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Objective Specifications

FEATURES

- Encodes eight data lines in priority
- Provides 3-bit binary priority code
- Input enable capability
- Easily cascadable
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

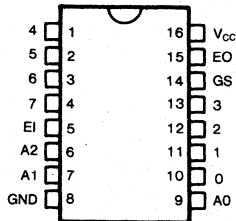
DESCRIPTION

The '148 provides three bits of binary coded output representing the position of the highest order active input, along with an output indicating the presence of any active input. It is easily expanded via input and output enables to provide priority encoding over many bits.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

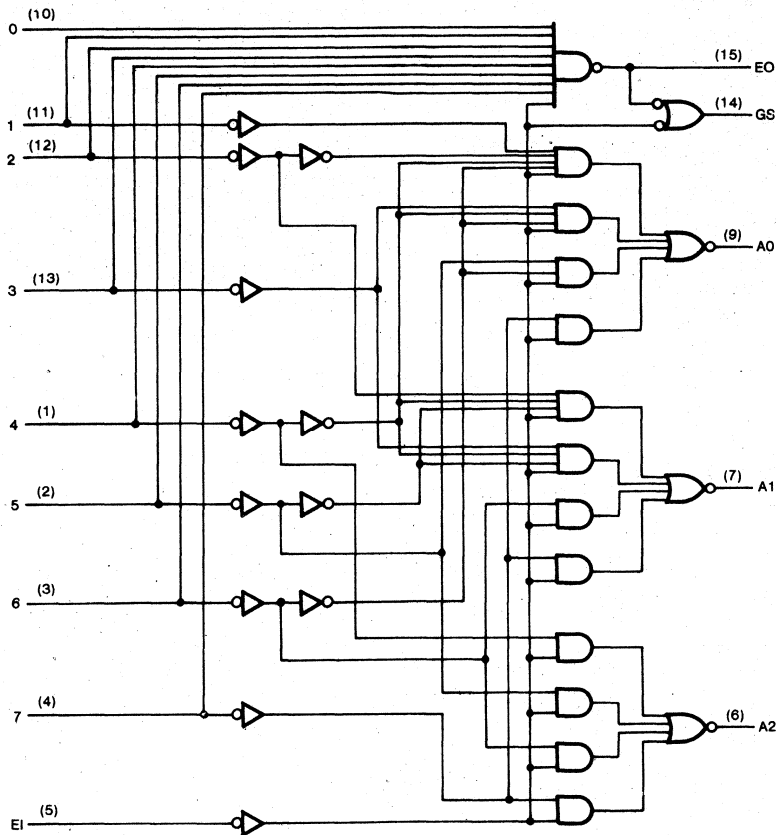
PIN CONFIGURATION



FUNCTION TABLE

| | | Inputs | | | | | | | | Outputs | | | | |
|---|----|--------|---|---|---|---|---|---|---|---------|----|----|----|----|
| | | 0 | 1 | 2 | 3 | 4 | 5 | 6 | 7 | A2 | A1 | A0 | GS | EO |
| H | EI | X | X | X | X | X | X | X | X | H | H | H | H | H |
| L | EI | H | H | H | H | H | H | H | H | H | H | H | H | L |
| L | EI | X | X | X | X | X | X | X | L | L | L | L | L | H |
| L | EI | X | X | X | X | X | L | H | H | L | L | H | L | H |
| L | EI | X | X | X | X | L | H | H | H | L | H | L | L | H |
| L | EI | X | X | X | L | H | H | H | H | H | L | H | L | H |
| L | EI | X | X | L | H | H | H | H | H | H | H | L | L | H |
| L | EI | L | H | H | H | H | H | H | H | H | H | H | L | H |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to $+85^\circ\text{C}$
 KS54AHCT: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ | | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ | | Unit |
|--------------------------------------|-----------------|--|--------------------|----------------------|--|---------------------|---|---------|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-4mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | | mA | |

4

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT148

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ $V_{CC}=5.0V$ | | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ $V_{CC}=5.0V \pm 10\%$ | | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ $V_{CC}=5.0V \pm 10\%$ | | Unit |
|---|-----------|-------------|-------------------------------------|-----|--|-----|---|----|------|
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay, 1-7 to A0, A1 or A2 | t_{PLH} | $C_L=50pF$ | 10 | | 17 | | 20 | ns | |
| | t_{PHL} | | 10 | | 17 | | 20 | | |
| Propagation Delay, 0-7 to EO | t_{PLH} | | 11 | | 18 | | 22 | ns | |
| | t_{PHL} | | 11 | | 18 | | 22 | | |
| Propagation Delay, 0-7 to GS | t_{PLH} | | 14 | | 24 | | 29 | ns | |
| | t_{PHL} | | 14 | | 24 | | 29 | | |
| Propagation Delay, EI to A0, A1 or A2 | t_{PLH} | | 10 | | 16 | | 19 | ns | |
| | t_{PHL} | | 10 | | 16 | | 19 | | |
| Propagation Delay, EI to GS | t_{PLH} | | 10 | | 17 | | 20 | ns | |
| | t_{PHL} | | 10 | | 17 | | 20 | | |
| Propagation Delay, EI to EO | t_{PLH} | | 11 | | 18 | | 22 | ns | |
| | t_{PHL} | | 11 | | 18 | | 22 | | |
| Input Capacitance | C_{IN} | | | 5 | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | 50 | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

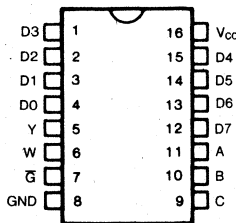
† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Can perform as:
 - Boolean Function Generators
 - Parallel-to-Serial Converters
 - Data Source Selectors
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High drive currents outputs
($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 - KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 - KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



DESCRIPTION

These monolithic data selectors/multiplexers provide full binary decoding to select one of eight data sources. The strobe input (\bar{G}) must be at a low logic level to enable the inputs. A high level at the strobe terminal forces the W output high and the Y output low.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLE

| INPUTS | | | | OUTPUTS | |
|--------|---|---|-----------|---------|-----------------|
| SELECT | | | STROBE | Y | W |
| C | B | A | \bar{G} | | |
| X | X | X | H | L | H |
| L | L | L | L | D0 | $\overline{D0}$ |
| L | L | H | L | D1 | $\overline{D1}$ |
| L | H | L | L | D2 | $\overline{D2}$ |
| L | H | H | L | D3 | $\overline{D3}$ |
| H | L | L | L | D4 | $\overline{D4}$ |
| H | L | H | L | D5 | $\overline{D5}$ |
| H | H | L | L | D6 | $\overline{D6}$ |
| H | H | H | L | D7 | $\overline{D7}$ |

H = high level, L = low level, X = irrelevant
D0, D1 ... D7 = the level of the D respective input

Absolute Maximum Ratings*

| | |
|---|---|
| Supply Voltage Range V_{CC} | -0.5V to $+7\text{V}$ |
| DC Input Diode Current, I_{IK} | $\pm 20 \text{ mA}$ |
| $(V_i < -0.5\text{V} \text{ or } V_i > V_{CC} + 0.5\text{V})$ | |
| DC Output Diode Current, I_{OK} | $\pm 20 \text{ mA}$ |
| $(V_o < -0.5\text{V} \text{ or } V_o > V_{CC} + 0.5\text{V})$ | |
| Continuous Output Current Per Pin, I_o | $\pm 70 \text{ mA}$ |
| $(-0.5\text{V} < V_o < V_{CC} + 0.5\text{V})$ | |
| Continuous Current Through V_{CC} or GND pins | $\pm 250 \text{ mA}$ |
| Storage Temperature Range, T_{stg} | -65°C to $+150^{\circ}\text{C}$ |
| Power Dissipation Per Package, P_d^{\dagger} | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

\dagger Power Dissipation temperature derating:

| | |
|----------------------|---|
| Plastic Package (N): | $-12\text{mW}/^{\circ}\text{C}$ from 65°C to 85°C |
| Ceramic Package (J): | $-12\text{mW}/^{\circ}\text{C}$ from 100°C to 125°C |

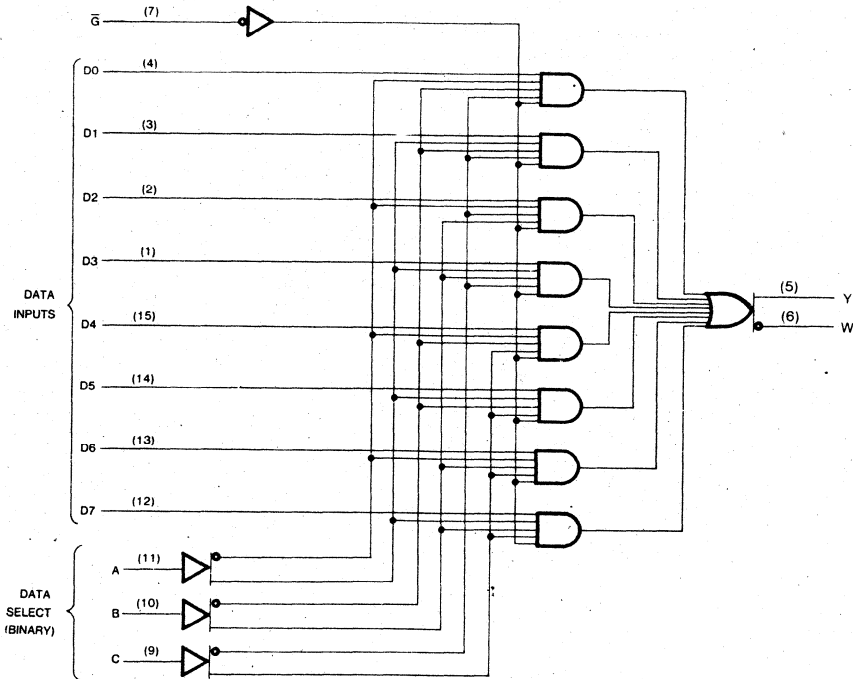
Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74AHCT: -40°C to $+85^{\circ}\text{C}$ KS54AHCT: -55°C to $+125^{\circ}\text{C}$ |

Input Rise & Fall Times, t_r, t_f ... Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

LOGIC DIAGRAM



4

DC ELECTRICAL CHARACTERISTICS (V_{CC}=5V±10% Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | T _a = 25°C | | KS74AHCT T _a = -40°C to +85°C | | KS54AHCT T _a = -55°C to +125°C | | Unit |
|--------------------------------------|------------------|---|------------------------|------------------------------|---|-----------------------------|--|--|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V _{IH} | | | 2.0 | 2.0 | 2.0 | | | V |
| Maximum Low-Level Input Voltage | V _{IL} | | | 0.8 | 0.8 | 0.8 | | | V |
| Minimum High-Level Output Voltage | V _{OH} | V _{IN} =V _{IH} or V _{IL} I _O =-20μA I _O =-6mA | V _{CC} 4.2 | V _{CC} -0.1 3.98 | V _{CC} -0.1 3.84 | V _{CC} -0.1 3.7 | | | V |
| Maximum Low-Level Output Voltage | V _{OL} | V _{IN} =V _{IH} or V _{IL} I _O =20μA I _O =12mA I _O =24mA | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | | V |
| Maximum Input Current | I _{IN} | V _{IN} =V _{CC} or GND | | ±0.1 | ±1.0 | ±1.0 | | | μA |
| Maximum Quiescent Supply Current | I _{CC} | V _{IN} =V _{CC} or GND I _{OUT} =0μA | | 8.0 | 80.0 | 160.0 | | | μA |
| Additional Worst Case Supply Current | ΔI _{CC} | per input pin V _I =2.4V other Inputs: at V _{CC} or GND I _{OUT} =0μA | | 2.7 | 2.9 | 3.0 | | | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT151

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|--------------------------------------|-----------|---|--------------------------|---|----------|--|----------|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, A, B or C to Y | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 13 16 | | 21 30 | | 25 36 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 13 16 | | 21 30 | | 25 36 | |
| Propagation Delay, A, B or C to W | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 15 18 | | 24 33 | | 27 38 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 15 18 | | 24 33 | | 27 38 | |
| Propagation Delay, Any D to Y | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 9 12 | | 15 24 | | 18 29 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 9 12 | | 15 24 | | 18 29 | |
| Propagation Delay, Any D to W | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 8 11 | | 15 24 | | 18 29 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 8 11 | | 15 24 | | 18 29 | |
| Propagation Delay, \bar{G} to Y | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 12 15 | | 19 28 | | 23 34 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 12 15 | | 19 28 | | 23 34 | |
| Propagation Delay, \bar{G} to W | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 13 16 | | 21 30 | | 25 36 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 13 16 | | 21 30 | | 25 36 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Allows Multiplexing from N Lines to 1 Line
- Performs Parallel-to-Serial Conversion
- Strobe (Enable) Line Provided for Cascading (N lines to n lines)
- '253 is the 3-State Version of this part
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High drive currents Outputs ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

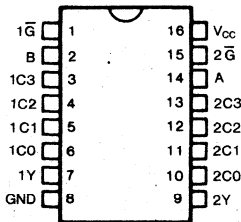
DESCRIPTION

Each of these data selectors/multiplexers contains inverters and drives to supply full binary decoding data selection to the AND-OR gates. Separate strobe inputs (G) are provided for each of the two four-line sections.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

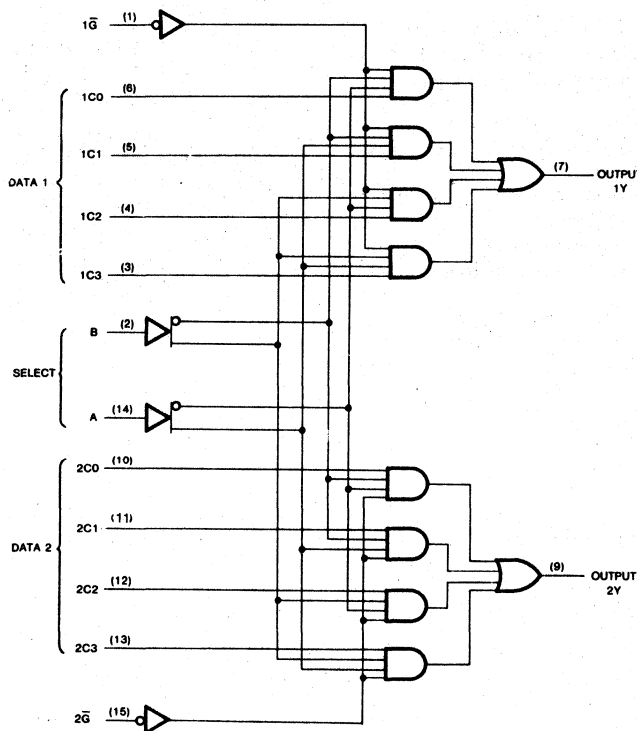


FUNCTION TABLE

| SELECT INPUTS | | DATA INPUTS | | | | STROBE | OUTPUT |
|---------------|---|-------------|----|----|----|-----------|--------|
| B | A | C0 | C1 | C2 | C3 | \bar{G} | Y |
| X | X | X | X | X | X | H | L |
| L | L | L | X | X | X | L | L |
| L | L | H | X | X | X | L | H |
| L | H | X | L | X | X | L | L |
| L | H | X | H | X | X | L | H |
| H | L | X | X | L | X | L | L |
| H | L | X | X | H | X | L | H |
| H | H | X | X | X | L | L | L |
| H | H | X | X | X | H | L | H |

Select inputs A and B are common to both sections.

LOGIC DIAGRAM



Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} -0.5V to +7V
- DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
- DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
- Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
- Continuous Current Through
 V_{CC} or GND pins ± 250 mA
- Storage Temperature Range, T_{stg} -65°C to +150°C
- Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

- † Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN}, V_{OUT} . . . 0V to V_{CC}
- Operating Temperature
Range
KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C
- Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|---|--------------------------|------------------------|---|-----|--|-----|---------------|
| | | | Typ | Guaranteed Limits | Min | Max | Min | Max | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | | $V_{CC} - 0.1$ 3.7 | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | | 0.1 0.4 | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | | ± 1.0 | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | | 160.0 | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | | 3.0 | | mA |

4

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT153

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC}=5.0\text{V}$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC}=5.0\text{V} \pm 10\%$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC}=5.0\text{V} \pm 10\%$ | | Unit |
|---|-----------|---|--|-----------|--|----------|---|----------|------|
| | | | Typ | Min | Max | Min | Max | | |
| | | | Propagation Delay, A or B to Y | t_{PLH} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 13 16 | | 21 30 | |
| | t_{PHL} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 13 16 | | 21 30 | | 25 36 | | |
| Propagation Delay, Data (Any C) to Y | t_{PLH} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 9 12 | | 15 24 | | 18 29 | ns | |
| | t_{PHL} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 9 12 | | 15 24 | | 18 29 | | |
| Propagation Delay, \bar{G} to Y | t_{PLH} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 11 14 | | 18 27 | | 22 33 | ns | |
| | t_{PHL} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 11 14 | | 18 27 | | 22 33 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | (per package) | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Objective Specifications

FEATURES

- Decodes 4 Binary-Coded Inputs into One of 16 Mutually Exclusive Outputs
- Performs the Demultiplexing Function by Distributing Data From One Input to Any One of 16 Outputs
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

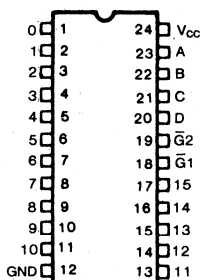
DESCRIPTION

These monolithic, 4-line to 16-line decoders decode four binary-coded inputs into one of sixteen mutually exclusive outputs when both the strobe inputs, $\bar{G}1$ and $\bar{G}2$, are low. The demultiplexing function is performed by using the 4 input lines to address the output line, passing data from one of the strobe inputs with the other strobe input low. When either strobe input is high, all outputs are high. These demultiplexers are ideally suited for implementing high-performance memory decoders.

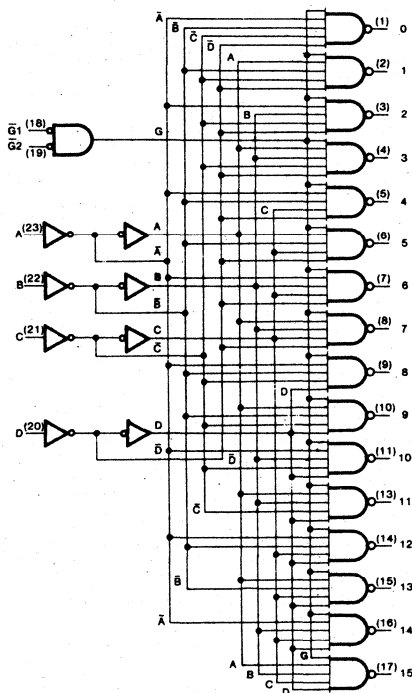
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

| Inputs | | | | Outputs | | | | | | | | | | | | | | | | | | |
|--------|----|---|---|---------|---|---|---|---|---|---|---|---|---|---|---|----|----|----|----|----|----|---|
| G1 | G2 | D | C | B | A | 0 | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 13 | 14 | 15 | |
| L | L | L | L | L | L | L | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H |
| L | L | L | L | L | H | H | L | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H |
| L | L | L | L | H | H | H | H | L | H | H | H | H | H | H | H | H | H | H | H | H | H | H |
| L | L | L | H | L | L | H | H | H | H | L | H | H | H | H | H | H | H | H | H | H | H | H |
| L | L | L | H | L | H | H | H | H | H | L | H | H | H | H | H | H | H | H | H | H | H | H |
| L | L | L | H | H | L | H | H | H | H | H | L | H | H | H | H | H | H | H | H | H | H | H |
| L | L | L | H | H | H | H | H | H | H | H | H | L | H | H | H | H | H | H | H | H | H | H |
| L | L | H | L | L | L | H | H | H | H | H | H | H | L | H | H | H | H | H | H | H | H | H |
| L | L | H | L | L | H | H | H | H | H | H | H | H | H | L | H | H | H | H | H | H | H | H |
| L | L | H | L | H | L | H | H | H | H | H | H | H | H | H | L | H | H | H | H | H | H | H |
| L | L | H | L | H | H | H | H | H | H | H | H | H | H | H | H | L | H | H | H | H | H | H |
| L | L | H | H | L | L | H | H | H | H | H | H | H | H | H | H | H | L | H | H | H | H | H |
| L | L | H | H | H | L | H | H | H | H | H | H | H | H | H | H | H | H | L | H | H | H | H |
| L | H | X | X | X | X | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H |
| H | L | X | X | X | X | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H |
| H | H | X | X | X | X | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H |

4

Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} -0.5V to +7V
- DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
- DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
- Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
- Continuous Current Through
 V_{CC} or GND pins ± 125 mA
- Storage Temperature Range, T_{stg} -65°C to +150°C
- Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

- † Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN} , V_{OUT} . . 0V to V_{CC}
- Operating Temperature
Range
KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C
- Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|---|--------------------------|----------------------|---|---------------------|--|--|---------------|
| | | | Typ | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-8\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4\text{V}$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | | | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT154

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--|-----------|-------------------|--------------------------|---|-----|--|-----|-------------|
| | | | $V_{CC}=5.0\text{V}$ | $V_{CC}=5.0\text{V} \pm 10\%$ | | $V_{CC}=5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, A, B, C, D to Any Output | t_{PLH} | $C_L=50\text{pF}$ | 12 | | 20 | | 24 | ns |
| | t_{PHL} | | 12 | | 20 | | 24 | |
| Propagation Delay, $\bar{G}1$ or $\bar{G}2$ to Any Output | t_{PLH} | | 12 | | 20 | | 24 | ns |
| | t_{PHL} | | 12 | | 20 | | 24 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | 50 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.



FEATURES

- Typical applications:
Dual 2-to-4 line decoder
Dual 1-to-4 line demultiplexer
3-to-8 line decoder
1-to-8 line demultiplexer
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

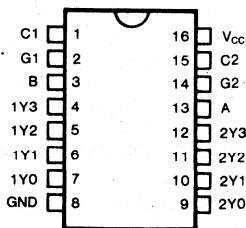
DESCRIPTION

The '155 consists of two 1-to-4 line demultiplexers with independent strobes and common binary address inputs. When both sections are enabled by the strobes, the common address inputs sequentially select and route associated input data to the appropriate output of each section. The individual strobes permit activating or inhibiting each of the 4-bit sections as desired. Data applied to input C1 is inverted at its outputs and data applied to C2 is true through its outputs. The inverter following the C1 data input permits use as a 3-to-8 line decoder, or 1-to-8 line demultiplexer, without gating.

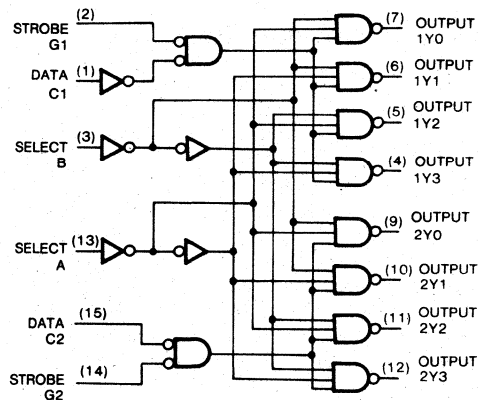
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLES

2-to-4 Line Decoder or 1-to-4 Line Demultiplexer

| Inputs | | | | Outputs | | | |
|--------|--------|------|----|---------|-----|-----|-----|
| Select | Strobe | Data | | | | | |
| B | A | G1 | C1 | 1Y0 | 1Y1 | 1Y2 | 1Y3 |
| X | X | H | X | H | H | H | H |
| L | L | L | H | L | H | H | H |
| L | H | L | H | H | L | H | H |
| H | L | L | H | H | H | L | H |
| H | H | L | H | H | H | H | L |
| X | X | X | L | H | H | H | H |

| Inputs | | | | Outputs | | | |
|--------|--------|------|----|---------|-----|-----|-----|
| Select | Strobe | Data | | | | | |
| B | A | G2 | C2 | 2Y0 | 2Y1 | 2Y2 | 2Y3 |
| X | X | H | X | H | H | H | H |
| L | L | L | L | L | H | H | H |
| L | H | L | L | H | L | H | H |
| H | L | L | L | H | H | L | H |
| H | H | L | L | H | H | H | L |
| X | X | X | H | H | H | H | H |

3-to-8 Line Decoder or 1-to-8 Line Demultiplexer

| Inputs | | | Outputs | | | | | | | |
|--------|----------------|----|---------|-----|-----|-----|-----|-----|-----|-----|
| Select | Strobe or Data | | (0) | (1) | (2) | (3) | (4) | (5) | (6) | (7) |
| ICB | A | IG | 2Y0 | 2Y1 | 2Y2 | 2Y3 | 1Y0 | 1Y1 | 1Y2 | 1Y3 |
| X | X | X | H | H | H | H | H | H | H | H |
| L | L | L | L | H | H | H | H | H | H | H |
| L | L | H | L | H | L | H | H | H | H | H |
| L | H | L | L | H | H | L | H | H | H | H |
| L | H | H | L | H | H | H | L | H | H | H |
| H | L | L | L | H | H | H | H | L | H | H |
| H | L | H | L | H | H | H | H | H | L | H |
| H | H | L | L | H | H | H | H | H | H | L |
| H | H | H | L | H | H | H | H | H | H | L |

IC = Inputs C1 and C2 connected together
IG = Inputs G1 and G2 connected together

Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} -0.5V to +7V
- DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
- DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
- Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
- Continuous Current Through
 V_{CC} or GND pins ± 125 mA
- Storage Temperature Range, T_{stg} -65°C to +150°C
- Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

- † Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN} , V_{OUT} . . . 0V to V_{CC}
- Operating Temperature
Range
KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C
- Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | | KS74AHCT | | KS54AHCT | | Unit |
|--------------------------------------|-----------------|--|--------------------|----------------------|----------------------|---------------------|---|---------------------|--|---------|------|
| | | | | | | | $T_a = -40^\circ C \text{ to } +85^\circ C$ | | $T_a = -55^\circ C \text{ to } +125^\circ C$ | | |
| | | | Guaranteed Limits | | | | | | | | |
| | | | Typ | | | | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-4mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | $V_{CC}-0.1$ 3.7 | $V_{CC}-0.1$ 3.7 | $V_{CC}-0.1$ 3.7 | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.33 0.5 | 0.1 0.4 | 0.1 0.4 | 0.1 0.4 | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | ± 1.0 | ± 1.0 | ± 1.0 | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 80.0 | 160.0 | 160.0 | 160.0 | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 2.9 | 3.0 | 3.0 | 3.0 | mA | |

4

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT155

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ | | KS74AHCT | | KS54AHCT | | Unit |
|---|-----------|-------------|--------------------|-----|---|-----|--|----|------|
| | | | $V_{CC}=5.0V$ | | $T_a = -40^\circ C \text{ to } +85^\circ C$ | | $T_a = -55^\circ C \text{ to } +125^\circ C$ | | |
| | | | Typ | Min | Max | Min | Max | | |
| Maximum Propagation Delay, A, B, C2, G1 or G2 to any Output (2 levels of logic) | t_{PLH} | $C_L=50pF$ | 12 | 12 | 20 | 20 | 24 | ns | |
| | t_{PHL} | | 12 | 12 | 20 | 20 | 24 | | |
| Maximum Propagation Delay, A or B to any Y (3 levels of logic) | t_{PLH} | | 14 | 14 | 23 | 23 | 28 | ns | |
| | t_{PHL} | | 14 | 14 | 23 | 23 | 28 | | |
| Maximum Propagation Delay, C1 to any Y | t_{PLH} | | 13 | 13 | 22 | 22 | 26 | ns | |
| | t_{PHL} | | 13 | 13 | 22 | 22 | 26 | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^\circ\text{C}$
KS54AHCT: -55°C to $+125^\circ\text{C}$

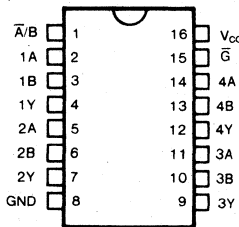
DESCRIPTION

These are data selectors multiplexers which select a 4-bit word from one of two sources via the control of a common select input (\bar{A}/B). A separate strobe input (\bar{G}) is provided. The '157 presents true data whereas the '158 presents inverted data at the outputs.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

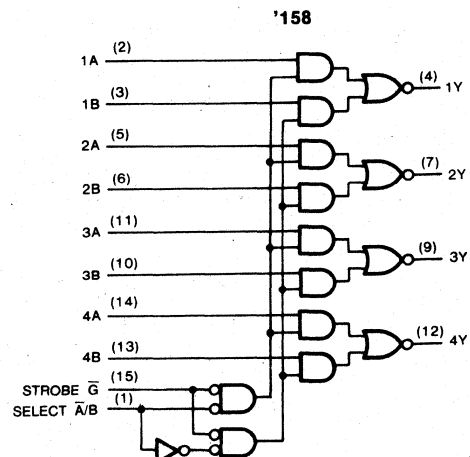
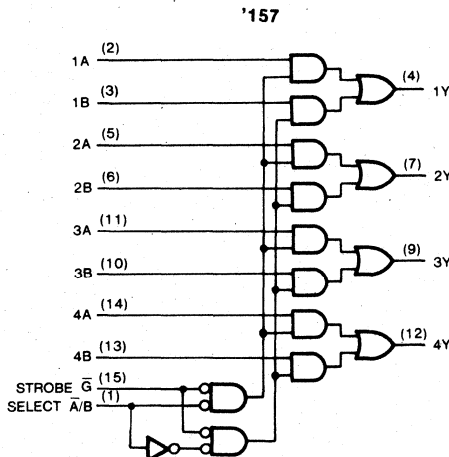
PIN CONFIGURATION



FUNCTION TABLE

| Strobe \bar{G} | Select \bar{A}/B | Inputs | | Output Y | |
|---------------------|-----------------------|--------|---|----------|------|
| | | Data | | '157 | '158 |
| | | A | B | | |
| H | X | X | X | L | H |
| L | L | L | X | L | H |
| L | L | H | X | H | L |
| L | H | X | L | L | H |
| L | H | X | H | H | L |

LOGIC DIAGRAMS



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range
 KS74AHCT: -40°C to $+85^\circ\text{C}$
 KS54AHCT: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|--|-----------------------|---|---|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V | | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V | | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA | | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA | | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA | | |

4

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT157, AHCT158

| Characteristic | Symbol | Conditions† | T _a = 25°C | KS74AHCT | | KS54AHCT | | Unit |
|-----------------------------------|------------------|-----------------------|------------------------|---------------------------------|----------------------------------|------------------------------|-----|------|
| | | | V _{CC} = 5.0V | T _a = -40°C to +85°C | T _a = -55°C to +125°C | V _{CC} = 5.0V ± 10% | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, A or B to Y | t _{PLH} | C _L = 50pF | 9 | | 14 | | 18 | ns |
| | t _{PHL} | | 9 | | 14 | | 18 | |
| Propagation Delay, A/B to Y | t _{PLH} | | 13 | | 22 | | 26 | ns |
| | t _{PHL} | | 13 | | 22 | | 26 | |
| Propagation Delay, Ḡ to Y | t _{PLH} | | 12 | | 19 | | 23 | ns |
| | t _{PHL} | | 12 | | 19 | | 23 | |
| Input Capacitance | C _{IN} | | 5 | | | | pF | |
| Power Dissipation Capacitance* | C _{PD} | (per gate) | | | | | | pF |

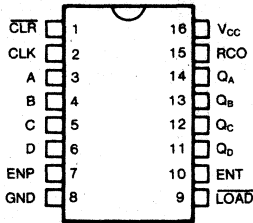
* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Internal Look Ahead for Fast Counting
- Carry Output for n-bit cascading
- Synchronous Counting
- Synchronously Programmable
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: $-40^{\circ}C$ to $+85^{\circ}C$
KS54AHCT: $-55^{\circ}C$ to $+125^{\circ}C$

PIN CONFIGURATION



FUNCTION TABLES

'160, '161

| CLK | CLR | ENP | ENT | LOAD | Function |
|-----|-----|-----|-----|------|---------------------|
| X | L | X | X | X | Clear |
| X | H | H | L | H | Count & RC disabled |
| X | H | L | H | H | Count disabled |
| X | H | L | L | H | Count & RC disabled |
| ↑ | H | X | X | L | Load |
| ↑ | H | H | H | H | Increment Counter |

'162, '163

| CLK | CLR | ENP | ENT | LOAD | Function |
|-----|-----|-----|-----|------|---------------------|
| ↑ | L | X | X | X | Clear |
| X | H | H | L | H | Count & RC disabled |
| X | H | L | H | H | Count disabled |
| X | H | L | L | H | Count & RC disabled |
| ↑ | H | X | X | L | Load |
| ↑ | H | H | H | H | Increment counter |

DESCRIPTION

These are synchronous, presettable 4-bit binary counters featuring internal carry-look-ahead for high-speed counting. The '160 and '162 are decade counters, and the '161 and '163 are 4-bit binary counters. The buffered clock input triggers all flip-flops simultaneously on the rising edge of the input waveform. This eliminates the output counting spikes normally associated with asynchronous counters.

These counters are fully programmable; that is, the outputs may be preset to either level. As presetting is synchronous, setting up a low level at the load input disables the counter and causes the outputs to agree with the setup data after the next clock pulse regardless of the levels of the enable inputs.

The clear function for the '160 and '161 is asynchronous and a low level at the clear input sets all four of the flip-flop outputs low regardless of the levels of the clock, load or enable inputs.

The clear function for the '162 and 163 is synchronous and a low level at the clear input sets all four of the flip-flop outputs low after the next clock pulse, regardless of the levels of the enable inputs. This synchronous clear allows the count length to be modified easily as decoding the maximum count desired can be accomplished with one external NAND gate. The gate output is connected to the clear input to synchronously clear the counter.

Two enable inputs and a ripple carry output allow easy cascading of the counters. Both count-enable inputs (ENP and ENT) must be high to count, and ENT is fed forward to enable the ripple carry output. The ripple carry output (RCO) thus enabled will produce a high-level pulse while the count is maximum (9 or 15 with Q_A high). This high-level overflow ripple carry pulse can be used to enable successive cascaded stages. Transitions at the ENP or ENT are allowed regardless of the level of the clock input.

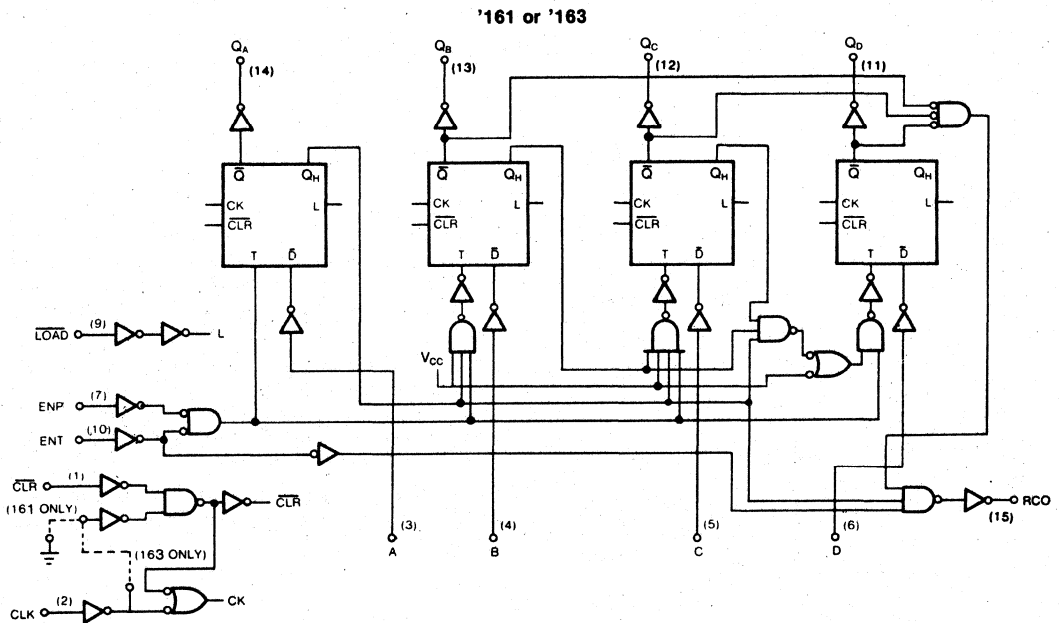
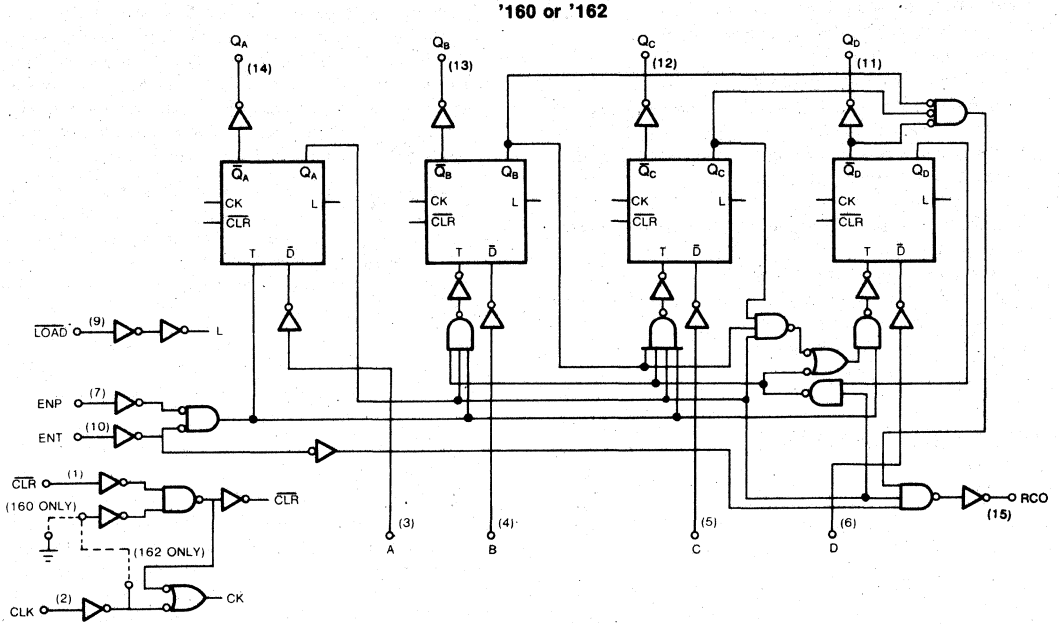
These counters feature a fully independent clock circuit. Changes at control inputs (ENP, ENT, or \overline{LOAD}) that will modify the operating model have no effect on the contents of the counter until clocking occurs. The function of the counter (whether enabled, disabled, loading, or counting) will be dictated solely by the conditions meeting the stable setup and hold times.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

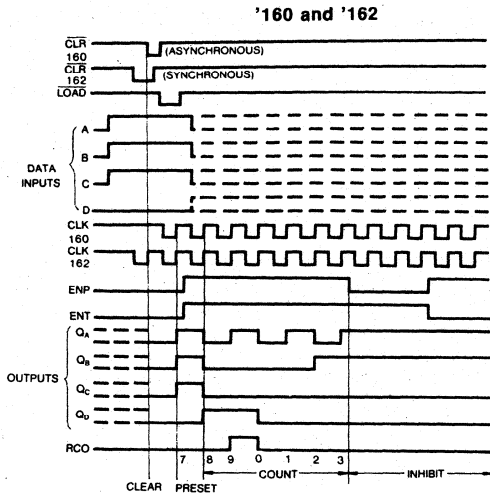
All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.



LOGIC DIAGRAMS

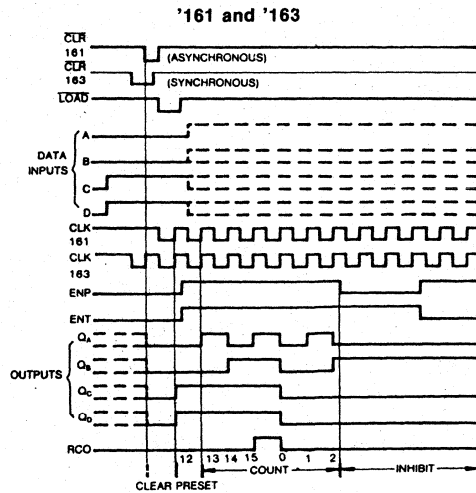


Typical Clear, Preset, Count and Inhibit Sequences



Sequence:

- (1) Clear outputs to zero
- (2) Preset to BCD seven
- (3) Count to eight, nine, zero, one, two, and three
- (4) Inhibit



Sequence:

- (1) Clear outputs to zero
- (2) Preset to binary twelve
- (3) Count to thirteen, fourteen, fifteen, zero, one and two
- (4) Inhibit

Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} , $-0.5V$ to $+7V$
- DC Input Diode Current, I_{IK}
 $(V_I < -0.5V$ or $V_I > V_{CC} + 0.5V)$ ± 20 mA
- DC Output Diode Current, I_{OK}
 $(V_O < -0.5V$ or $V_O > V_{CC} + 0.5V)$ ± 20 mA
- Continuous Output Current Per Pin, I_O
 $(-0.5V < V_O < V_{CC} + 0.5V)$ ± 35 mA
- Continuous Current Through
 V_{CC} or GND pins ± 125 mA
- Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
- Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

- Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
- Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN} , V_{OUT} . . . 0V to V_{CC}
- Operating Temperature
 Range KS74AHCT: $-40^\circ C$ to $+85^\circ C$
 KS54AHCT: $-55^\circ C$ to $+125^\circ C$
- Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | $T_a = -40^\circ C$ to $+85^\circ C$ | | $T_a = -55^\circ C$ to $+125^\circ C$ | | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|--------------------------------------|-----------------------|---------------------------------------|---------|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | | mA | |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT160, AHCT161

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ $V_{CC} = 5.0V$ | | $T_a = -40^\circ C$ to $+85^\circ C$ $V_{CC} = 5.0V \pm 10\%$ | | $T_a = -55^\circ C$ to $+125^\circ C$ $V_{CC} = 5.0V \pm 10\%$ | | Unit |
|---|-----------------|--------------|---------------------------------------|-----|--|-----|---|-----|------|
| | | | Typ | Min | Max | Min | Max | | |
| Maximum Clock Frequency | f_{max} | $C_L = 50pF$ | 50 | 40 | | 35 | | MHz | |
| Propagation Delay, CLK to RCO | t_{PLH} | | 15 | | 20 | | 24 | ns | |
| | t_{PHL} | | 15 | | 20 | | 24 | ns | |
| Propagation Delay, CLK to any Q | t_{PLH} | | 10 | | 16 | | 19 | ns | |
| | t_{PHL} | | 10 | | 16 | | 19 | ns | |
| Propagation Delay, ENT to RCO | t_{PLH} | | 8 | | 13 | | 16 | ns | |
| | t_{PHL} | | 8 | | 13 | | 16 | ns | |
| Propagation Delay, CLR to any Q | t_{PHL} | | 15 | | 24 | | 29 | ns | |
| Propagation Delay, CLR to RCO | t_{PHL} | 17 | | 23 | | 33 | ns | | |
| Pulse Width | CLK High or Low | t_w | 10 | 15 | | 20 | | ns | |
| | CLR Low | | 10 | 15 | | 20 | | ns | |
| Setup Time before CLK† | A, B, C, D | t_{su} | 10 | 15 | | 20 | | ns | |
| | LOAD | | 10 | 15 | | 20 | | ns | |
| | ENP, ENT | | 10 | 15 | | 20 | | ns | |
| | CLR inactive | | 6 | 10 | | 10 | | ns | |
| Hold time, All Synchronous Inputs after CLK† | t_h | | -3 | 0 | | 0 | ns | | |
| Input Capacitance | C_{IN} | | 5 | | | | pF | | |
| Power Dissipation Capacitance* | C_{PD} | | 80 | | | | pF | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT162, AHCT163

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|---|--------------|---------------------|--------------------------|--|-----|---|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Clock Frequency | f_{max} | | 50 | 40 | | 35 | | MHz |
| Propagation Delay, CLK to RCO | t_{PLH} | $C_L = 50\text{pF}$ | 15 | | 20 | | 24 | ns |
| | t_{PHL} | | 15 | | 20 | | 24 | |
| Propagation Delay, CLK to any Q | t_{PLH} | | 10 | | 16 | | 20 | ns |
| | t_{PHL} | | 10 | | 16 | | 20 | |
| Propagation Delay, ENT to RCO | t_{PLH} | | 9 | | 15 | | 18 | ns |
| | t_{PHL} | | 9 | | 15 | | 18 | |
| Pulse Width, CLK High or Low | t_w | | 8 | 12.5 | | 20 | ns | |
| Setup Time before CLK† | A, B, C, D | t_{su} | 10 | 15 | | 20 | ns | |
| | LOAD | | 10 | 15 | | 20 | | |
| | ENP, ENT | | 15 | 15 | | 20 | | |
| | CLR inactive | | 6 | 10 | | 10 | | |
| | CLR Low | | 6 | 15 | | 20 | | |
| Hold time, All Synchronous Inputs after CLK† | t_h | | -3 | 0 | | 0 | ns | |
| Input Capacitance | C_{IN} | | 5 | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | 80 | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- AND—Gated (enable/disable) serial inputs
- Fully buffered clock and serial inputs
- Direct clear
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

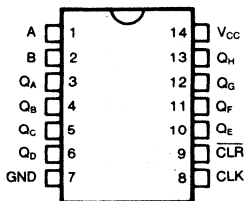
These are high-speed 8-bit registers with AND-gated serial inputs and an asynchronous clear. Data is entered serially through either one of the two inputs, A and B. A high on one input enables the other one, which will then determine the state of the first flip-flop. A low at either or both inputs inhibits data entry and resets the first flip-flop to a low level at the next positive clock transition.

Data at the serial inputs may be changed while the clock is high or low, provided the minimum setup time requirements are met. Clocking occurs on the low-to-high-level transition of their clock input.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

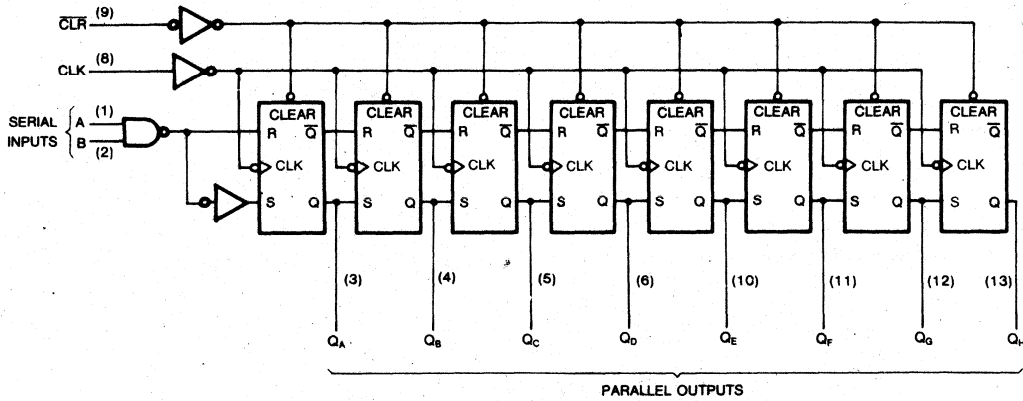


FUNCTION TABLE

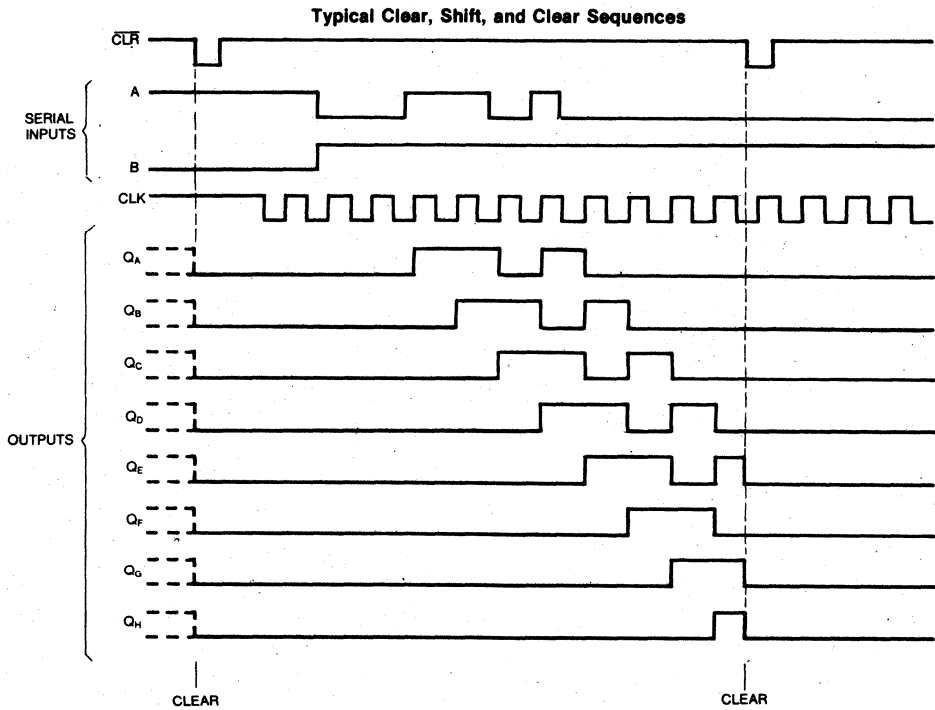
| Inputs | | | | Outputs | | |
|-------------------------|-----|---|---|----------|-----------------|----------|
| $\overline{\text{CLR}}$ | CLK | A | B | Q_A | $Q_B \dots Q_H$ | |
| L | X | X | X | L | L | L |
| H | L | X | X | Q_{A0} | Q_{B0} | Q_{H0} |
| H | ↑ | H | H | H | Q_{An} | Q_{Gn} |
| H | ↑ | L | X | L | Q_{An} | Q_{Gn} |
| H | ↑ | X | L | L | Q_{An} | Q_{Gn} |

H = high level (steady state), L = low level (steady state)
 X = irrelevant (any input, including transitions)
 ↑ = transition from low to high level.
 Q_{A0}, Q_{B0}, Q_{H0} = the level of Q_A, Q_B or Q_H , respectively, before the indicate steady-state input conditions were established.
 Q_{An}, Q_{Gn} = the level of Q_A or Q_G before the most-recent ↑ transition of the clock; indicates a one-bit shift.

LOGIC DIAGRAMS



4



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN}, V_{OUT} . . . 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: $-40^\circ C$ to $+85^\circ C$
 KS54AHCT: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|--|---|---------------------|---------|
| | | | Typ | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| Guaranteed Limits | | | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-4mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT164

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|------------------------------------|------------------------|---------------------|--------------------------|--|-----|---|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 60 | 36 | | 30 | | MHz |
| Propagation Delay, CLR to any Q | t_{PHL} | | 12 | | 20 | | 24 | ns |
| Propagation Delay, CLK to any Q | t_{PLH} | | 11 | | 18 | | 21 | ns |
| | t_{PHL} | | 11 | | 18 | | 21 | ns |
| Pulse Width | CLR Low | t_w | 8 | 12 | | 15 | | ns |
| | CLK High or Low | | 8 | 12 | | 15 | | ns |
| Setup Time before CLK† | Data | t_{su} | 8 | 12 | | 15 | | ns |
| | CLR Inactive | | 8 | 12 | | 15 | | ns |
| Hold Time Data after CLK† | t_h | | 1 | 4 | | 5 | 6 | ns |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} (per package) | | 120 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Complementary outputs
- Direct overriding load (data) inputs
- Gated clock inputs
- Parallel-to-Serial data conversion
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
I_{OL} = 8 mA @ V_{OL} = 0.5V
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C

DESCRIPTION

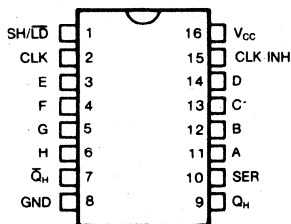
These are high-speed 8-bit parallel-load or serial-in shift registers with complementary serial outputs available from the last stage. Parallel-in access is asynchronous and is enabled by pulling the SH/LD input low. When SH/LD is high, data is entered serially at the SER input and shifted one place to the right with each positive clock transition.

Clocking is accomplished through a 2-input NOR gate which permits one of the clocks to be used as a clock inhibit function. Holding either clock input high inhibits clocking. Either clock input is enabled by holding the other clock input low while the SH/LD input is high.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

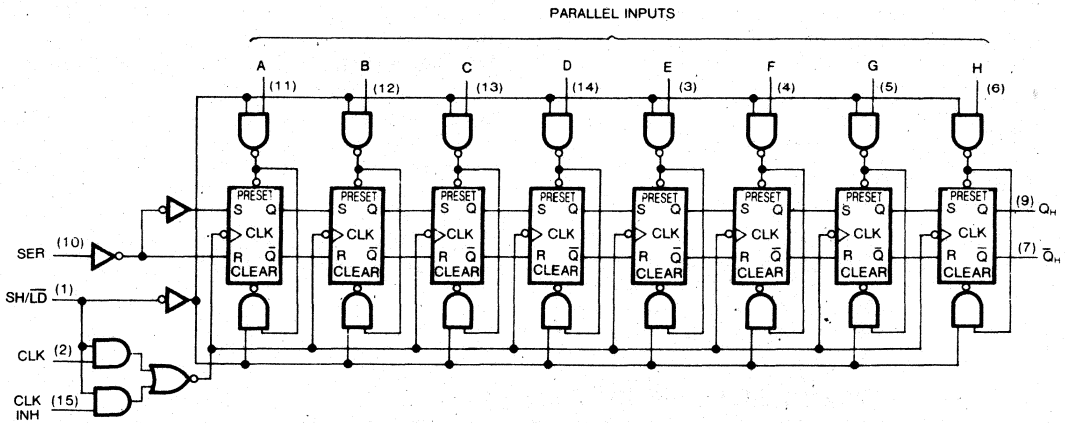


FUNCTION TABLE

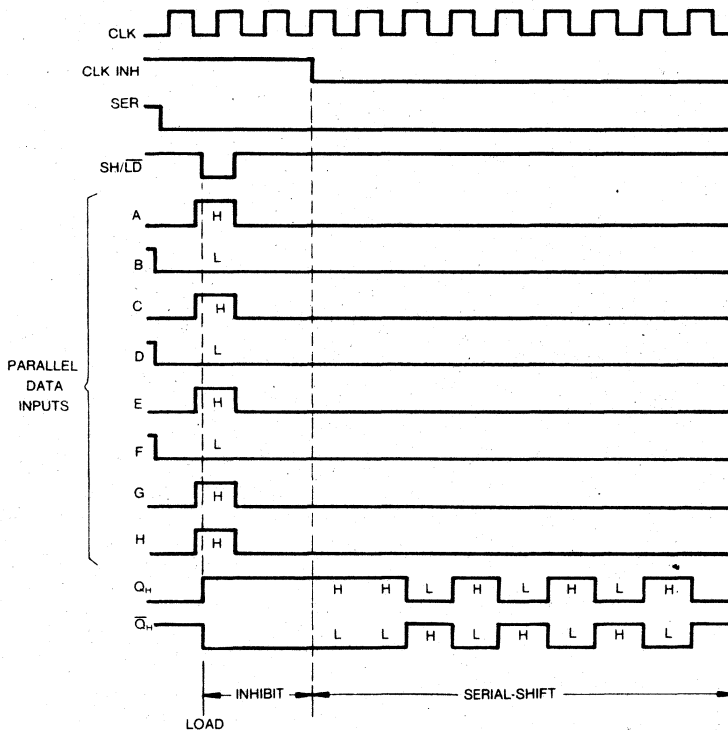
| Inputs | | | Function |
|--------|-----|---------|---------------|
| SH/LD | CLK | CLK INH | |
| L | X | X | PARALLEL LOAD |
| H | H | X | NO CHANGE |
| H | X | H | NO CHANGE |
| H | L | ↑ | SHIFT* |
| H | ↑ | L | SHIFT* |

*Content of each internal register shifts toward output Q_H. Data at serial input is shifted into first register.

LOGIC DIAGRAMS



Typical Shift, Load and Inhibit Sequences



4

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|--|---|---------------------|---------|
| | | | Typ | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| Guaranteed Limits | | | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-4mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns, AHCT165)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|---|-----------------------------|---------------------|--------------------------|---|--|---------------------------------|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Clock Frequency | f_{max} | | 50 | 30 | | 25 | | MHz |
| Propagation Delay, SH/LD to Q_H or \bar{Q}_H | t_{PLH} | $C_L = 50\text{pF}$ | 15 | | 25 | | 30 | ns |
| | t_{PHL} | | 15 | | 25 | | 30 | |
| Propagation Delay, CLK to Q_H or \bar{Q}_H | t_{PLH} | | 19 | | 31 | | 37 | ns |
| | t_{PHL} | | 19 | | 31 | | 37 | |
| Propagation Delay, H to Q_H or \bar{Q}_H | t_{PLH} | | 12 | | 20 | | 24 | ns |
| | t_{PHL} | | 12 | | 20 | | 24 | |
| Pulse Width | SH/LD Low | t_w | 8 | 12 | | 15 | | ns |
| | CLK High or Low | | 8 | 12 | | 15 | | |
| Setup Time | SH/LD High before CLK↑ | t_{SU} | 7 | 15 | | 20 | | ns |
| | SER before CLK↑ | | 8 | 12 | | 15 | | |
| | CLK INH Low before CLK↑ | | 7 | 15 | | 20 | | |
| | CLK INH High before CLK↓ | | 7 | 15 | | 20 | | |
| | Data before SH/LD↑ | | 5 | 8 | | 10 | | |
| Hold Time | SER Data after CLK↑ | t_H | -3 | 0 | | 0 | | ns |
| | PAR Data after SH/LD↑ | | -3 | 0 | | 0 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | 100 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Synchronous load
- Direct overriding clear
- Parallel to serial conversion
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

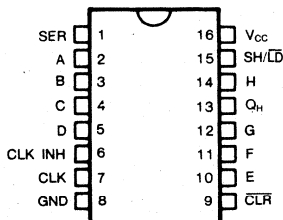
DESCRIPTION

These devices feature parallel-in or serial-in, serial-out registers, gated clock inputs and an overriding clear input. The parallel-in or serial-in modes are established by the shift/load input. When high, the input enables the serial data input and couples the eight flip-flops for serial shifting with each clock pulse. When low, the parallel data inputs are enabled and synchronous loading occurs on the next clock pulse. During parallel loading, serial data flow is inhibited. Clocking is accomplished on the low-to-high edge of the clock pulse through a two-input positive NOR gate permitting one input to be used as a clock-enable or clock-inhibit function. Holding either of the clock inputs high inhibits clocking; holding either low enables the other clock input. This allows the system clock to be free-running and the register can be stopped on command with the clock input. The clock-inhibit input should be changed to the high level only when the clock input is high. A buffered direct clear input overrides all other inputs, including the clock, and sets all flip-flops to zero.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

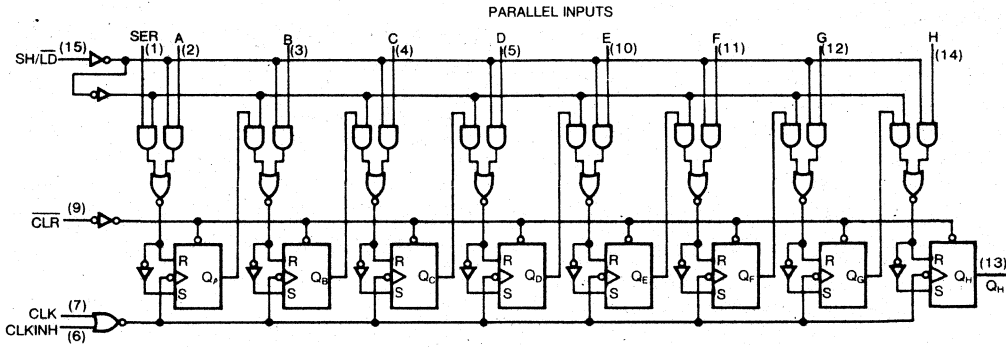
PIN CONFIGURATION



FUNCTION TABLE

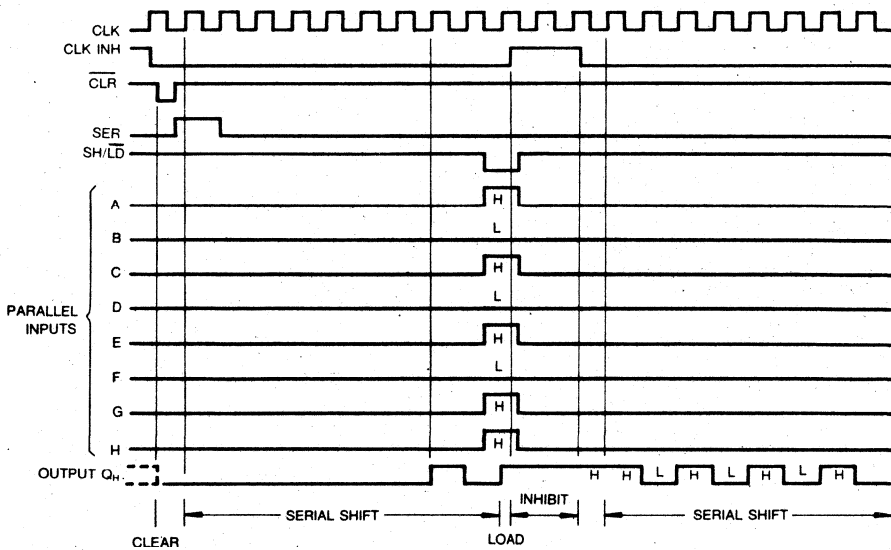
| Inputs | | | | | | Internal Outputs | | Output |
|--------|-------|---------|-----|-----|------------------|------------------|-----------------|-----------------|
| CLR | SH/LD | CLK INH | CLK | SER | Parallel A ... H | QA | QB | QH |
| L | X | X | X | X | X | L | L | L |
| H | X | L | L | X | X | QA0 | QB0 | QH0 |
| H | L | L | ↑ | X | a ... h | a | b | h |
| H | H | L | ↑ | H | X | H | QA _n | QH _n |
| H | H | L | ↑ | L | X | L | QA _n | QH _n |
| H | X | H | ↑ | X | X | GA0 | QB0 | QH0 |

LOGIC DIAGRAM



4

Typical Clear, Shift, Load, Inhibit, and Shift Sequences



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d † 500 mW

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to $+85^\circ\text{C}$
 KS54AHCT: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|--|---|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT166

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|--|--|---------------------|--|--|----------|---|----------|------|
| | | | Typ | Min | Max | Min | Max | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 60 | 36 | | 30 | | MHz |
| Propagation Delay, $\overline{\text{CLR}}$ to Q_H | t_{PHL} | | 10 | | 17 | | 20 | ns |
| Propagation Delay, CLK to Q_H | t_{PLH} t_{PHL} | | 13 13 | | 21 21 | | 25 25 | ns |
| Pulse Width | $\overline{\text{CLR}}$ Low | t_w | 8 | 12 | | 15 | | ns |
| | CLK High or Low | | 8 | 12 | | 15 | | |
| Setup Time | SH/ $\overline{\text{LD}}$ High before CLK↑ | t_{su} | 8 | 12 | | 15 | | ns |
| | SER before CLK↑ | | 8 | 12 | | 15 | | |
| | CLK INH before before CLK↑ | | 8 | 12 | | 15 | | |
| | Data before SH/ $\overline{\text{LD}}$ ↑ | | 8 | 12 | | 15 | | |
| | CLR Inactive before CLK | | 8 | 12 | | 15 | | |
| Hold Time | SH/ $\overline{\text{LD}}$ High after CLK↑ | t_h | 5 | 8 | | 10 | | ns |
| | SER after CLK↑ | | 5 | 8 | | 10 | | |
| | CLK INH after CLK↑ | | 5 | 8 | | 10 | | |
| | Data after SH/ $\overline{\text{LD}}$ ↑ | | 5 | 8 | | 10 | | |
| | CLR Active after CLK↑ | | 5 | 8 | | 10 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

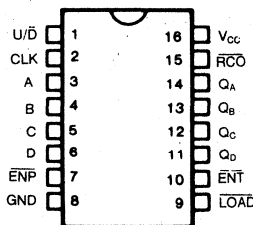
4

Preliminary Specifications

FEATURES

- Fully Synchronous Operation for Counting and Programming
- Internal Look Ahead for Fast Counting
- Carry Output for N-bit Cascading
- Fully Independent Clock Circuit
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



DESCRIPTION

These synchronous presettable counters feature an internal carry look-ahead for cascading in high-speed counting applications. The '168 is a decade counter and the '169 is a 4-bit binary counter. Synchronous operation is provided by having all flip-flops clocked simultaneously so that the outputs change coincident with each other when so instructed by the count enable inputs and internal gating. This mode of operation helps eliminate the output counting spikes that are normally associated with asynchronous (ripple clock) counters. A buffered clock input triggers the four flip-flops on the rising (positive-going) edge of the clock waveform.

These counters are fully programmable; that is, the outputs may each be preset to either level. The load input circuitry allows loading with the carry-enable output of cascaded counters. As loading is synchronous, setting up a low level at the load input disables the counter and causes the outputs to agree with the data inputs after the next clock pulse.

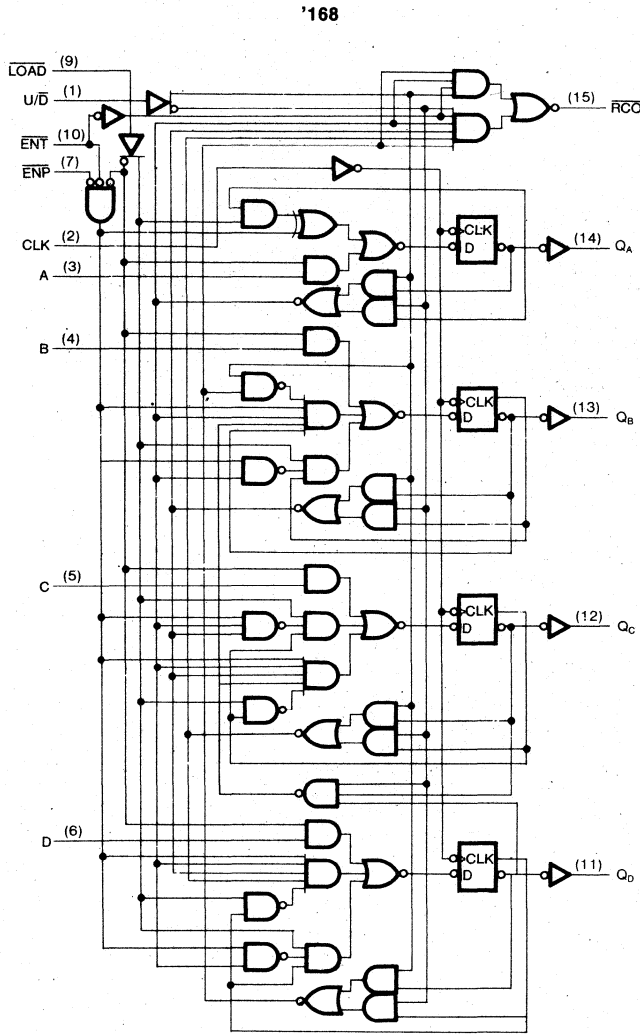
The carry look-ahead circuitry provides for cascading counters for n-bit synchronous application without additional gating. Instrumental in accomplishing this function are two count-enable inputs and a carry output. Both count enable inputs ($\overline{\text{ENP}}$ and $\overline{\text{ENT}}$) must be low to count. The direction of the count is determined by the level of the $\text{U}/\overline{\text{D}}$ input. When $\text{U}/\overline{\text{D}}$ is high, the counter counts up; when low, it counts down. Input $\overline{\text{ENT}}$ is fed forward to enable the carry output. The ripple carry output ($\overline{\text{RCO}}$) thus enabled will produce a low-level pulse while the count is zero (all inputs low) counting down or maximum (9 or 15) counting up. This low-level overflow carry pulse can be used to enable successive cascaded stages. Transition at $\overline{\text{ENP}}$ or $\overline{\text{ENT}}$ are allowed regardless of the level of the clock input.

These counters feature a fully independent clock circuit. Changes at control inputs ($\overline{\text{ENP}}$, $\overline{\text{ENT}}$, $\overline{\text{LOAD}}$, $\text{U}/\overline{\text{D}}$) that will modify the operating mode have no effect on the contents of the counter until clocking occurs. The function of the counter (whether enabled, disabled, loading, or counting) will be dictated solely by the conditions meeting the stable setup and hold times.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

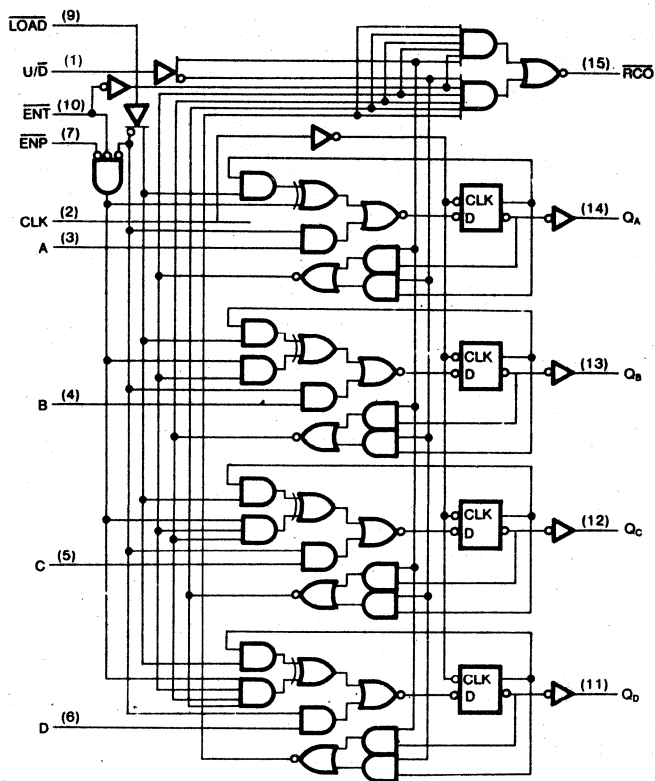
LOGIC DIAGRAMS

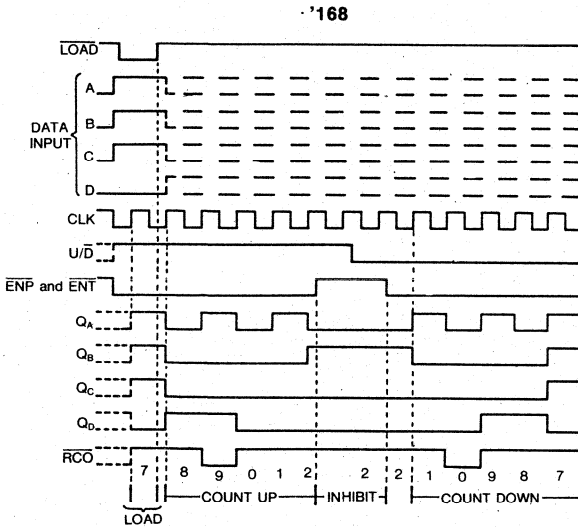


4

LOGIC DIAGRAMS (continued)

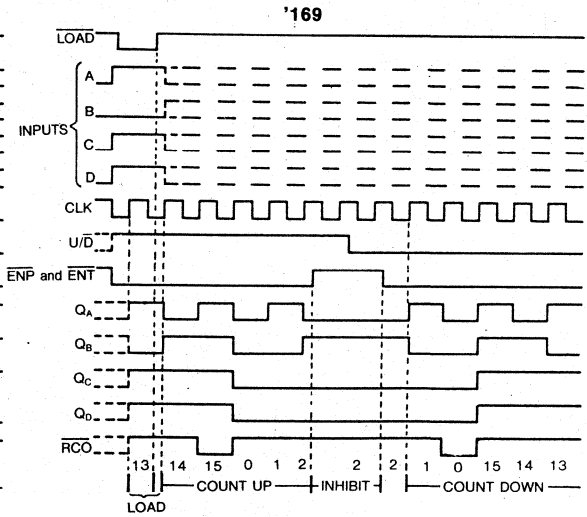
'169





Illustrated above is the following sequence:

1. Load (preset) to BCD seven
2. Count up to eight nine (maximum), zero, one, and two
3. Inhibit
4. Count down to one, zero (minimum), nine, eight, and seven



Illustrated above is the following sequence:

1. Load (preset) to BCD seven
2. Count up to eight nine (maximum), zero, one, and two
3. Inhibit
4. Count down to one, zero (minimum), nine, eight, and seven

4

Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} -0.5V to +7V
- DC Input Diode Current, I_{IK}
 $(V_I < -0.5V \text{ or } V_I > V_{CC} + 0.5V)$ ± 20 mA
- DC Output Diode Current, I_{OK}
 $(V_O < -0.5V \text{ or } V_O > V_{CC} + 0.5V)$ ± 20 mA
- Continuous Output Current Per Pin, I_O
 $(-0.5V < V_O < V_{CC} + 0.5V)$ ± 35 mA
- Continuous Current Through
 V_{CC} or GND pins ± 125 mA
- Storage Temperature Range, T_{Stg} -65°C to +150°C
- Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN}, V_{OUT} . . . 0V to V_{CC}
- Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
- Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|---|--------------------------|------------------------|---|--|--|--|---------------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | | 2.0 | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | | 0.8 | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_o = -20\mu\text{A}$ $I_o = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | | $V_{CC} - 0.1$ 3.7 | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_o = 20\mu\text{A}$ $I_o = 4\text{mA}$ $I_o = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | | 0.1 0.4 | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | | ± 1.0 | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | | 160.0 | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_i = 2.4\text{V}$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | | 3.0 | | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns, AHCT168, AHCT169)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|---|--------------------------------|---------------------|--------------------------|---|-----|--|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $V_{CC} = 5.0\text{V} \pm 10\%$ | | $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Operating Frequency | f_{max} | | 50 | 30 | | 25 | | MHz |
| Propagation Delay, CLK to $\overline{\text{RCO}}$ | t_{PLH} | $C_L = 50\text{pF}$ | 13 | | 28 | | 32 | ns |
| | t_{PHL} | | 19 | | 28 | | 32 | |
| Propagation Delay, CLK to Any Q | t_{PLH} | | 12 | | 18 | | 22 | ns |
| | t_{PHL} | | 12 | | 18 | | 22 | |
| Propagation Delay, ENT to $\overline{\text{RCO}}$ | t_{PLH} | | 10 | | 16 | | 19 | ns |
| | t_{PHL} | | 10 | | 16 | | 19 | |
| Propagation Delay, U/D to $\overline{\text{RCO}}$ | t_{PLH} | | 14 | | 23 | | 25 | ns |
| | t_{PHL} | | 14 | | 23 | | 25 | |
| Pulse Duration, CLK high or low | t_w | | 10 | 16 | | 20 | ns | |
| Setup Time, Before CLK† | A, B, C or D | | 9 | 15 | | 20 | ns | |
| | $\overline{\text{ENP}}$ or ENT | | 12 | 20 | | 25 | | |
| | LOAD | | 9 | 15 | | 20 | | |
| | U/ $\overline{\text{D}}$ | | 9 | 15 | | 20 | | |
| Hold Time, Data after CLK† | t_h | | -3 | 0 | | 0 | ns | |
| Input Capacitance | C_{IN} | | 5 | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.



KS54AHCT 173 4-Bit D-Type Registers with 3-State Outputs

Objective Specifications

FEATURES

- Gated output control lines for enabling or disabling the outputs
- Fully independent clock for operation in parallel-load or hold modes
- For application as bus buffer registers
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5V$ for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

These 4-bit registers contain D-type flip-flops with 3-state outputs, capable of driving highly-capacitive or low-impedance loads. This provides the device with the capability of being connected directly to and driving the bus lines in a bus-organized system without need for interface or pull-up components.

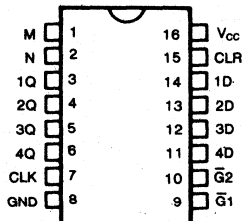
Gated enable inputs are provided for controlling the entry of data into the flip-flops. When both data-enable inputs are low, data at the D inputs are loaded into their respective flip-flops on the next positive transition of the buffered clock input. Gated output control inputs are also provided. When both are low, the normal logic states of the four outputs are available for driving the loads or bus lines. The outputs are disabled independently from the level of the clock by a high logic level at either output control input. The outputs then present a high impedance and neither load nor drive the bus line. Detailed operation is given in the function table.

To minimize the possibility that two outputs will attempt to take a common bus to opposite logic levels, the output control circuitry is designed so that the average output disable times are shorter than the average output enable times.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

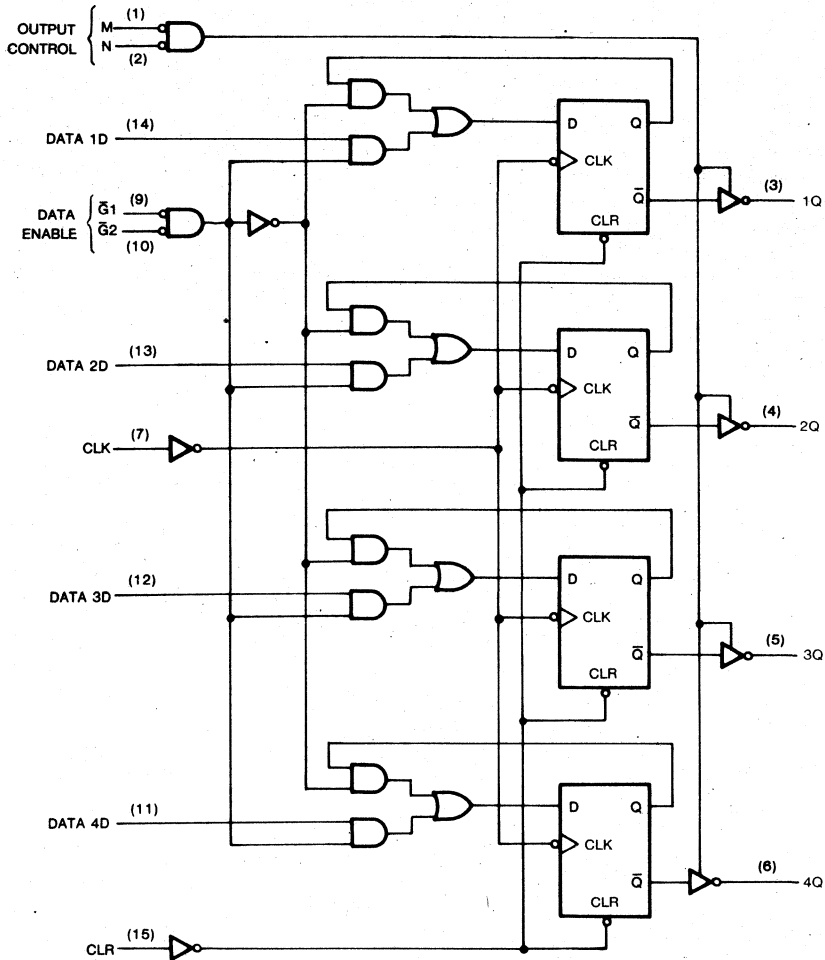


FUNCTION TABLE

| CLR | CLK | Input | | Data D | Output Q |
|-----|------------|-------------|------------|-----------|-------------|
| | | Data Enable | | | |
| | | $\bar{G}1$ | $\bar{G}2$ | | |
| H | X | X | X | X | L |
| L | L | X | X | X | Q_0 |
| L | \uparrow | H | X | X | Q_0 |
| L | \uparrow | X | H | X | Q_0 |
| L | \uparrow | L | L | L | L |
| L | \uparrow | L | L | H | H |

When either M or N (or both) is (are) high the output is disabled to the high-impedance state; however sequential operation of the flip-flops is not affected.

LOGIC DIAGRAM



KS54AHCT 173 4-Bit D-Type Registers with 3-State Outputs

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{Stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range
 KS74AHCT: -40°C to $+85^\circ\text{C}$
 KS54AHCT: -55°C to $+125^\circ\text{C}$

Input Rise & Fall Times, t_r , t_f Max 500 ns
 * Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|----------------------|---------------------|---------------|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

4

KS54AHCT 173 KS74AHCT 4-Bit D-Type Registers with 3-State Outputs

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT173

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|--------------------------------------|-----------------------------|---|--------------------------|---|--|---------------------------------|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Clock Frequency | f_{max} | | 50 | 30 | | 25 | | MHz |
| Propagation Delay, CLK to any Q | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 13 | | 21 | | 25 | ns |
| | | | 16 | | 30 | | 36 | |
| Propagation Delay, CLR to any Q | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 13 | | 21 | | 25 | ns |
| | | | 16 | | 30 | | 36 | |
| Propagation Delay, CLR to any Q | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 15 | | 25 | | 30 | ns |
| | | | 18 | | 34 | | 41 | |
| Output Enable Time, M or N to any Q | t_{pZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | | 20 | | 24 | ns |
| | | | $C_L = 150\text{pF}$ | | 29 | | 35 | |
| | t_{pZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | | 20 | | 24 | |
| | | | $C_L = 150\text{pF}$ | | 29 | | 35 | |
| Output Disable Time, M or N to any Q | t_{pHZ} | $R_L = 1\text{k}\Omega, C_L = 50\text{pF}$ | 10 | | 17 | | 20 | ns |
| | t_{pLZ} | | 10 | | 17 | | 20 | |
| Pulse Width | CLK High or Low | t_w | 7 | 12 | | 15 | | ns |
| | CLR High* | | 7 | 12 | | 15 | | |
| Setup Time, before CLK† | $\bar{G}1$ and $\bar{G}2$ * | t_{su} | 8 | 15 | | 20 | | ns |
| | Data | | 7 | 12 | | 15 | | |
| | CLR Inactive | | 7 | 12 | | 15 | | |
| Hold Time After CLK† | $\bar{G}1$ and $\bar{G}2$ | t_h | -3 | 0 | | 0 | | ns |
| | Data | | -3 | 0 | | 0 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

The '174 contains six, and the '175 contains four D-type flip-flops all sharing a common clock and a common clear. The '174 features single nail outputs for every flip-flops whereas the '175 has complementary outputs.

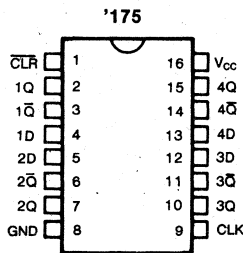
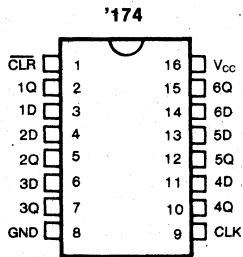
Information at the D inputs meeting the setup time requirements is transferred to the Q outputs on the positive-going edge of the clock pulse. Clock triggering occurs at a particular voltage level and is not directly related to the transition time of the positive-going pulse. When the clock input is at either the high or low level, the D input signal has no effect at the output.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.



PIN CONFIGURATIONS



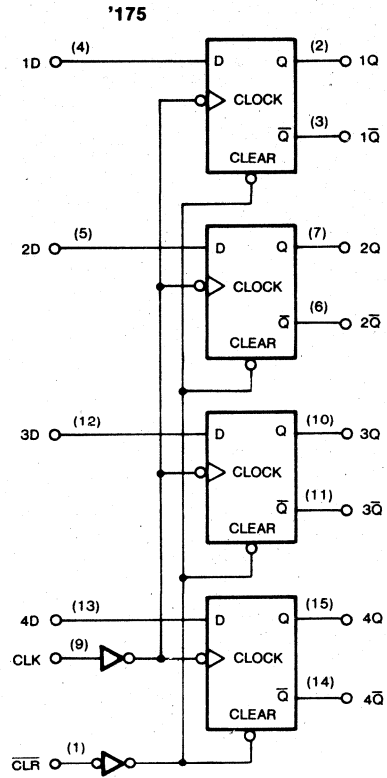
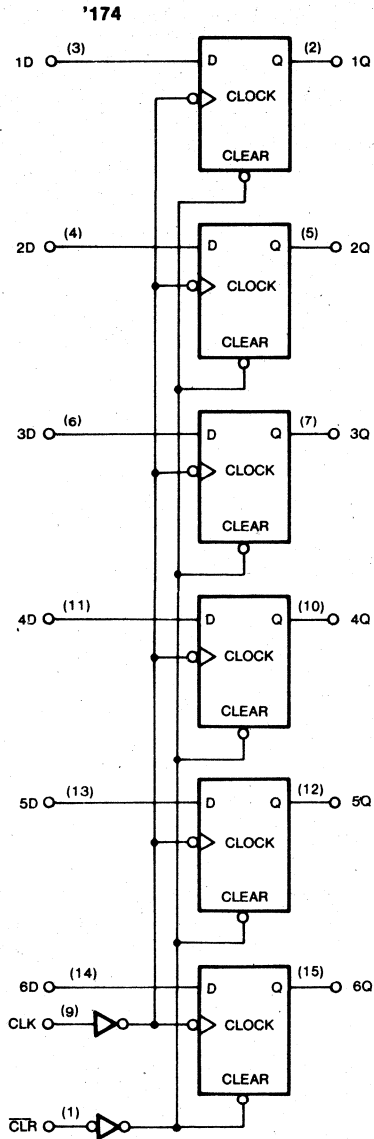
FUNCTION TABLE

(Each Flip-Flop)

| Inputs | | | Outputs | |
|--------|-----|---|----------------|----------------|
| CLR | CLK | D | Q | Q [†] |
| L | X | X | L | H |
| H | ↑ | H | H | L |
| H | ↑ | L | L | H |
| H | L | X | Q ₀ | Q ₀ |

† '175 only

LOGIC DIAGRAMS



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
Continuous Current Through
 V_{CC} or GND pins ± 125 mA
Storage Temperature Range, T_{stg} ... -65°C to +150°C
Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
Operating Temperature
Range KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C
Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|--|---|-----------------------|---------|
| | | | Typ | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| | | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT174, AHCT175

| Characteristic | Symbol | Conditions† | T _A = 25°C | KS74AHCT | | KS54AHCT | | Unit |
|---|----------------------------------|-----------------------|------------------------|---|-----|--|-----|------|
| | | | V _{CC} = 5.0V | T _A = -40°C to +85°C V _{CC} = 5.0V ± 10% | | T _A = -55°C to +125°C V _{CC} = 5.0V ± 10% | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Clock Frequency | f _{max} | C _L = 50pF | 70 | 50 | | 40 | | MHz |
| Propagation Delay, CLK to Q or \bar{Q} | t _{PLH} | | 11 | | 17 | | 20 | ns |
| | t _{PHL} | | 11 | | 17 | | 20 | ns |
| Propagation Delay, $\overline{\text{CLR}}$ to Q or \bar{Q} | t _{PLH} | | 12 | | 21 | | 25 | ns |
| | t _{PHL} | | 12 | | 21 | | 25 | ns |
| Setup Time before CLK† | Data | | t _{su} | 6 | 10 | | 15 | |
| | $\overline{\text{CLR}}$ Inactive | 4 | | 6 | | 8 | | ns |
| Hold Time, Data after CLK† | t _h | | -3 | 0 | | 0 | | ns |
| Pulse Width | CLK High or Low | t _w | 6 | 10 | | 15 | | ns |
| | $\overline{\text{CLR}}$ Low | | 6 | 10 | | 15 | | ns |
| Input Capacitance | C _{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

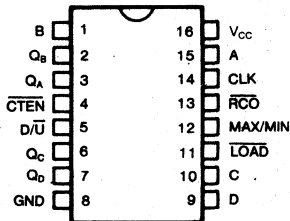
† For AC switching test circuits and timing waveforms see section 2.

Objective Specifications

FEATURES

- Single down/up count control line
- Look-ahead circuitry enhances speed of cascaded counters
- Fully synchronous in count modes
- Asynchronously presettable with load control
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



DESCRIPTION

These are high-speed synchronous, reversible 4-bit binary counters. Synchronous counting operation is provided by having all flip-flops clocked simultaneously so that the outputs change with each other when so instructed by the steering logic. This mode of operation eliminates the output counting spikes normally associated with asynchronous (ripple clock) counters.

The outputs of the four flip-flops are triggered on a low-to-high-level transition of the clock input if the enable input (\overline{CTEN}) is low. A high at \overline{CTEN} inhibits counting. The direction of the count is determined by the level of the down/up (D/\bar{U}) input. When D/\bar{U} is low, the counter counts up and when D/\bar{U} is high, it counts down.

These counters feature a fully independent clock circuit. Changes at the control inputs (\overline{CTEN} and D/\bar{U}) that will modify the operating mode have no effect on the contents of the counter until clocking occurs. The function of the counter will be dictated solely by the condition meeting the stable setup and hold times.

These counters are fully programmable; that is, the outputs may each be preset to either level by placing a low on the load input and entering the desired data at the data inputs. The output will change to agree with the data inputs independently of the level of the clock input. This feature allows the counters to be used as modulo-N dividers by simply modifying the count length with the preset inputs.

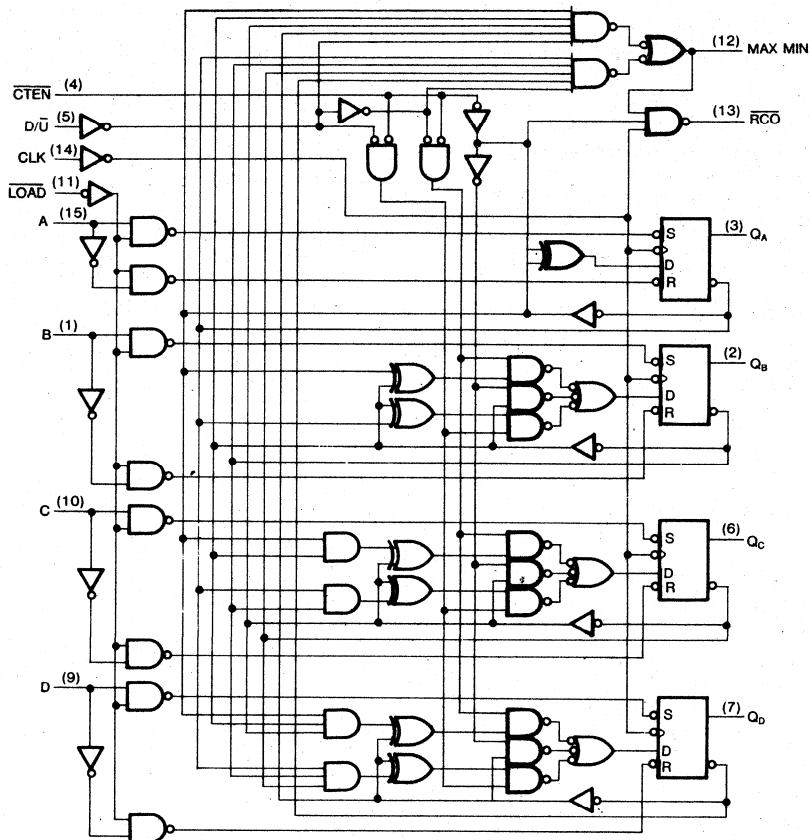
Two outputs have been made available to perform the cascading function: ripple clock and maximum/minimum count. The latter output produces a high-level output pulse with a duration approximately equal to one complete cycle of the clock while the count is zero (all outputs low) counting down or maximum (9 or 15) counting-up. The ripple clock output produces a low-level output pulse under those same conditions but only while the clock output to the enable input of the succeeding counter if parallel clocking is used, or to the clock input if parallel enabling is used. The maximum/minimum count output can be used to accomplish look-ahead for high-speed operation.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

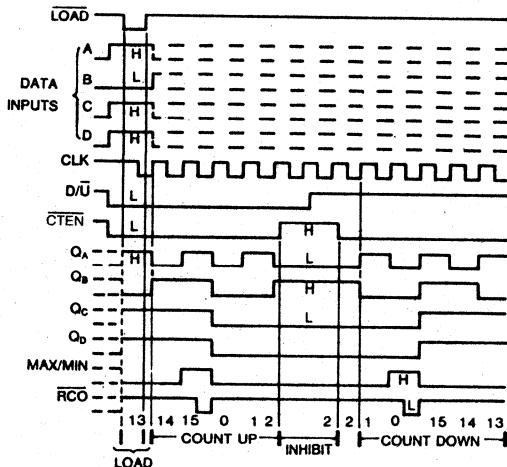
All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

4

LOGIC DIAGRAM



Typical Load, Count, and Inhibit Sequence



- Sequence:
- (1) Load (preset) to binary thirteen
 - (2) Count up to fourteen, fifteen, zero, one, and two
 - (3) Inhibit
 - (4) Count down to one, zero, fifteen, fourteen, and thirteen

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} . . . 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to $+85^\circ\text{C}$
 KS54AHCT: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|--|---|-----------------------|-------------------|
| | | | Typ | KS74AHCT $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | KS54AHCT $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | Guaranteed Limits |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT191

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|---|---|---------------------|--------------------------|--|-----|---|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Clock Frequency | f_{max} | | 50 | 30 | | 25 | | MHz |
| Propagation Delay, LOAD to any Q | t_{PLH} | $C_L = 50\text{pF}$ | 18 | | 30 | | 36 | ns |
| | t_{PHL} | | 18 | | 30 | | 36 | |
| Propagation Delay, A,B,C, D to any Q | t_{PLH} | | 13 | | 21 | | 25 | ns |
| | t_{PHL} | | 13 | | 21 | | 25 | |
| Propagation Delay, CLK to \overline{RCO} | t_{PLH} | | 12 | | 20 | | 24 | ns |
| | t_{PHL} | | 12 | | 20 | | 24 | |
| Propagation Delay, CLK to any Q | t_{PLH} | | 11 | | 18 | | 22 | ns |
| | t_{PHL} | | 11 | | 18 | | 22 | |
| Propagation Delay, CLK to MAX/MIN | t_{PLH} | | 19 | | 31 | | 37 | ns |
| | t_{PHL} | | 19 | | 31 | | 37 | |
| Propagation Delay, D/ \overline{U} to \overline{RCO} | t_{PLH} | | 19 | | 32 | | 38 | ns |
| | t_{PHL} | | 19 | | 32 | | 38 | |
| Propagation Delay, D/ \overline{U} to MAX/MIN | t_{PLH} | | 15 | | 25 | | 30 | |
| | t_{PHL} | | 15 | | 25 | | 30 | |
| Propagation Delay, CTEN to \overline{RCO} | t_{PLH} | | 11 | | 18 | | 22 | ns |
| | t_{PHL} | | 11 | | 18 | | 22 | |
| Pulse Width | CLK High or Low | t_w | 10 | | 17 | | 20 | ns |
| | LOAD Low | | 12 | | 20 | | 25 | |
| Setup Time | Data before $\overline{LOAD}\uparrow$ | t_{su} | 10 | 17 | | 20 | | ns |
| | \overline{CTEN} before $\text{CLK}\uparrow$ | | 10 | 17 | | 20 | | |
| | D/ \overline{U} before $\text{CLK}\uparrow$ | | 10 | 17 | | 20 | | |
| | LOAD Inactive before $\text{CLK}\uparrow$ | | 10 | 17 | | 20 | | |
| Hold Time | Data after $\overline{LOAD}\uparrow$ | t_h | 2 | 4 | | 5 | | ns |
| | \overline{CTEN} after $\text{CLK}\uparrow$ | | -3 | 0 | | 0 | | |
| | D/ \overline{U} after $\text{CLK}\uparrow$ | | -3 | 0 | | 0 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | 80 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

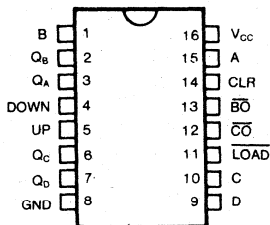
† For AC switching test circuits and timing waveforms see section 2.

Objective Specifications

FEATURES

- Look-ahead circuitry enhances cascaded counters
- Fully synchronous in count modes
- Parallel asynchronous load for modulo-N count lengths
- Asynchronous clear
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



DESCRIPTION

These are high-speed synchronous reversible 4-bit binary counters. Synchronous operation is provided by having all flip-flops clocked simultaneously so that the outputs change coincidentally with each other when so instructed by the steering logic. This mode of operation eliminates the output counting spikes normally associated with asynchronous (ripple clock) counters.

The outputs of the four flip-flops are triggered by a low-to-high-level transition of either count (clock) input (Up or Down). The direction of counting is determined by which count input is pulsed while the other count input is high.

All four counters are fully programmable; that is, each output may be preset to either level by placing a low on the load input and entering the desired data at the data inputs. The output will change to agree with the data inputs independently of the count pulses. This feature allows the counters to be used as modulo-N dividers by simply modifying the count length with the preset inputs.

A clear input has been provided that forces all outputs to the low level when a high level is applied. The clear function is independent of the count and the load inputs.

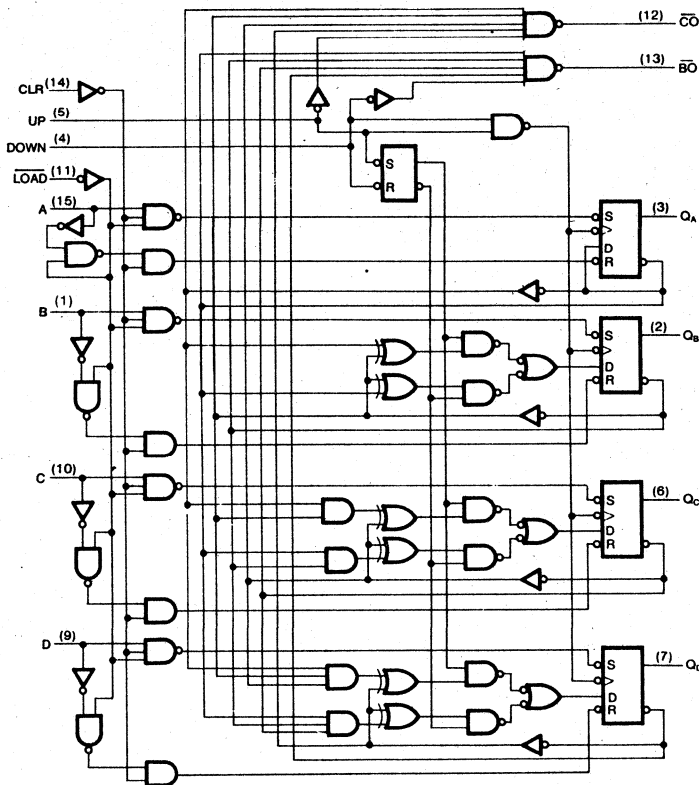
These counters were designed to be cascaded without the need for external circuitry. The borrow output (\overline{BO}) produces a low-level pulse while the count is zero (all outputs low) and the count-down input is low. Similarly, the carry output (\overline{CO}) produces a low-level pulse while the count is maximum (9 or 15) and the count-up input is low. The counters can then be easily cascaded by feeding the borrow and carry outputs to the count-down and count-up inputs, respectively, of the succeeding counter.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

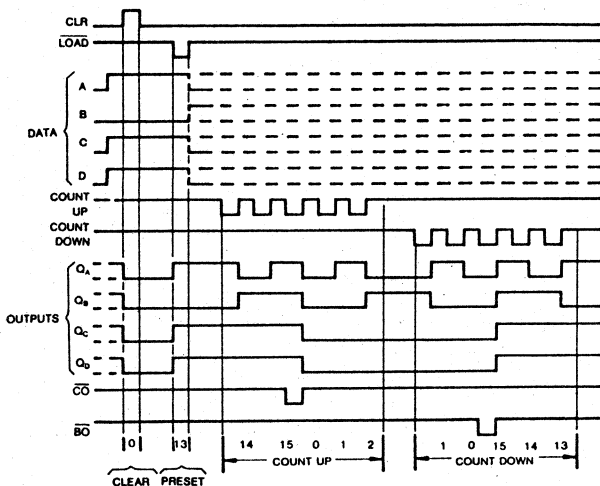
All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

4

LOGIC DIAGRAM



Typical Clear, Load, and Count Sequences



Sequence:

- (1) Clear outputs to zero.
- (2) Load (preset) to binary thirteen.
- (3) Count up to fourteen, fifteen, carry, zero, one and two.
- (4) Count down to one, zero, borrow, fifteen, fourteen, and thirteen.

Note A: Clear overrides load data, and count inputs.

Note B: When counting up, count-down input must be high; when counting down, count-up input must be high.

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} ... -65°C to +150°C
 Power Dissipation Per Package, P_{D1} 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

¹ Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|---|--|---------------------|---------------|
| | | | Typ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-4\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT193

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit | |
|---|---|---------------------|--------------------------|---|-----|--|-----|------|----|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | | |
| | | | Typ | Min | Max | Min | Max | | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 50 | 30 | | 25 | | MHz | |
| Propagation Delay, UP to $\overline{C\bar{O}}$ | t_{PLH} | | 11 | | 18 | | 22 | | ns |
| | t_{PHL} | | 11 | | 18 | | 22 | | |
| Propagation Delay, DOWN to any Q | t_{PLH} | | 11 | | 18 | | 22 | | ns |
| | t_{PHL} | | 11 | | 18 | | 22 | | |
| Propagation Delay, UP or DOWN to any Q | t_{PLH} | | 11 | | 19 | | 23 | | ns |
| | t_{PHL} | | 11 | | 19 | | 23 | | |
| Propagation Delay, \overline{LOAD} to any Q | t_{PLH} | | 17 | | 29 | | 35 | | ns |
| | t_{PHL} | | 17 | | 29 | | 35 | | |
| Propagation Delay, CLR to any Q | t_{PLH} | | 10 | | 17 | | 20 | | ns |
| Pulse Width | CLR High | t_w | 6 | 10 | | 15 | | ns | |
| | \overline{LOAD} Low | | 10 | 17 | | 20 | | | |
| | UP or DOWN High or Low | | 10 | 17 | | 20 | | | |
| Setup Time | Data before $\overline{LOAD}\dagger$ | t_{su} | 10 | 17 | | 29 | | ns | |
| | CLR Inactive before $UP\dagger$ or $DOWN\dagger$ | | 10 | 17 | | 20 | | | |
| | \overline{LOAD} Inactive before $UP\dagger$ or $DOWN\dagger$ | | 10 | 17 | | 20 | | | |
| | UP high before $DOWN\dagger$ | | 10 | 17 | | 17 | | | |
| | Down high before $UP\dagger$ | | 8 | 15 | | 15 | | | |
| Hold Time | Data after $\overline{LOAD}\dagger$ | t_h | -3 | 0 | | 0 | | ns | |
| | UP High after $DOWN\dagger$ | | -3 | 0 | | 0 | | | |
| | DOWN High after $UP\dagger$ | | 3 | 8 | | 6 | | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | 80 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Parallel-to-Serial, Serial-to-Parallel Conversions
- Left or Right Shifts
- Parallel Synchronous Loading
- Direct Overriding Clear
- Temporary Data Latching Capability
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
I_{OL} = 8 mA @ V_{OL} = 0.5V
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C

DESCRIPTION

These bidirectional shift registers feature parallel outputs, right-shift and left-shift serial inputs, operating-mode-control inputs, and a direct overriding clear line. The register has four distinct modes of operation:

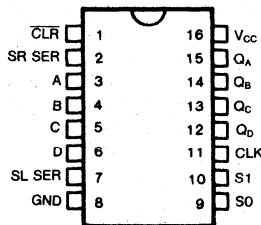
- Inhibit clock (temporary data latch/do nothing)
- Shift-right (in the direction Q_A toward Q_D)
- Shift-left (in the direction Q_D toward Q_A)
- Parallel (broadside) load

Synchronous parallel loading is accomplished by applying the four bits of data and taking both mode control inputs, S0 and S1, high. The data is loaded into the associated flip-flops and appear at the outputs after the positive transition of the clock input. During loading, serial data flow is inhibited.

Shift-right is accomplished synchronously with the rising edge of the clock pulse when S0 is high and S1 is low. Serial data for this mode is entered at the shift-right data input. When S0 is low and S1 is high, data shifts left synchronously and new data is entered at the shift-left serial inputs. Clocking of the flip-flop is inhibited when both mode control inputs are low.



PIN CONFIGURATION

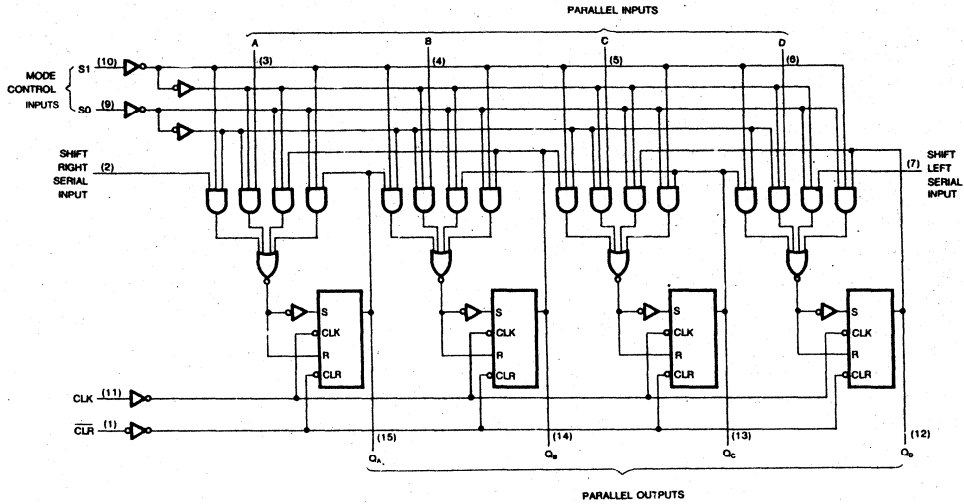


FUNCTION TABLE

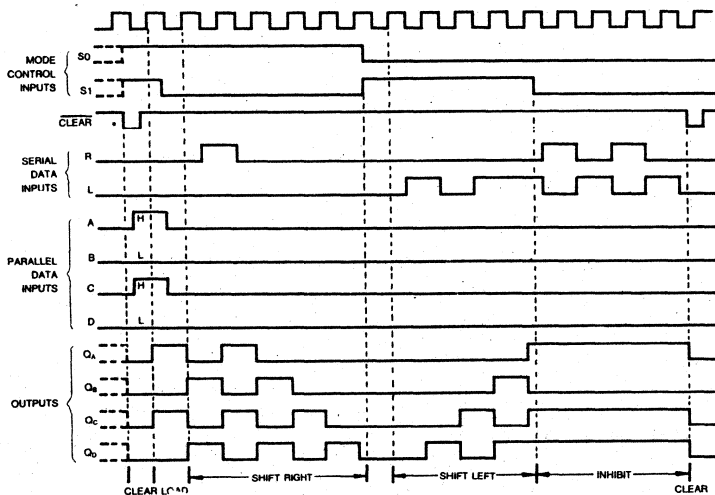
| CLR | MODE | | INPUTS | | | | OUTPUTS | | | | | | |
|-----|------|----|--------|--------|-------|----------|---------|----------------|----------------|-----------------|-----------------|-----------------|-----------------|
| | | | CLK | SERIAL | | PARALLEL | | Q _A | Q _B | Q _C | Q _D | | |
| | S1 | S0 | | LEFT | RIGHT | A | B | | | | | C | D |
| L | X | X | X | X | X | X | X | X | X | L | L | L | L |
| H | X | X | L | X | X | X | X | X | X | Q _{A0} | Q _{B0} | Q _{C0} | Q _{D0} |
| H | H | H | ↑ | X | X | a | b | c | d | a | b | c | d |
| H | L | H | ↑ | X | H | X | X | X | X | H | Q _{An} | Q _{Bn} | Q _{Cn} |
| H | L | H | ↑ | X | L | X | X | X | X | L | Q _{An} | Q _{Bn} | Q _{Cn} |
| H | H | L | ↑ | H | X | X | X | X | X | Q _{Bn} | Q _{Cn} | D _n | H |
| H | H | L | ↑ | L | X | X | X | X | X | Q _{Bn} | Q _{Cn} | Q _{Dn} | L |
| H | L | L | X | X | X | X | X | X | X | Q _{A0} | Q _{B0} | Q _{C0} | Q _{D0} |

H=high level (steady state)
L=low level (steady state)
X=irrelevant (any input, including transitions)
↑=transition from low to high level
a,b,c,d=the level of steady-state input at inputs A,B,C, or D, respectively.
Q_{A0}, Q_{B0}, Q_{C0}, Q_{D0}=the level of Q_A, Q_B, Q_C, or Q_D, respectively, before the indicated steady-state input conditions were established.
Q_{An}, Q_{Bn}, Q_{Cn}, Q_{Dn}=the level of Q_A, Q_B, Q_C, respectively, before the most-recent ↑ transition of the clock.

LOGIC DIAGRAM



typical clear, load, right-shift, inhibit, and clear sequences



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|----------------------|---|---------------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-4\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT194

| Characteristic | Symbol | Conditions† | T _a = 25°C | KS74AHCT | | KS54AHCT | | Unit |
|---|------------------|-----------------------|------------------------|---|-----|--|-----|------|
| | | | V _{CC} = 5.0V | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Clock Frequency | f _{max} | | 60 | 35 | | 30 | | MHz |
| Propagation Delay, CLK to Q _H | t _{PLH} | C _L = 50pF | 10 | | 17 | | 20 | ns |
| | t _{PHL} | | 10 | | 17 | | 20 | |
| Propagation Delay, CLR to Q _H | t _{PHL} | | | 11 | | 19 | | 22 |
| Pulse Width | CLR LOW | t _w | 10 | 17 | | 20 | | ns |
| | CLK High or LOW | | 10 | 17 | | 20 | | |
| Setup Time, Any Input before CLK↑ | t _s | | 10 | 17 | | 20 | | ns |
| Hold Time, Data after CLK↑ | t _s | | -3 | 0 | | 0 | | ns |
| Input Capacitance | C _{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | | 80 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

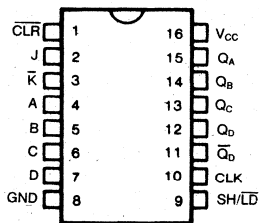
† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Parallel-to-Serial, Serial-to-Parallel Conversions
- Parallel Synchronous Loading
- J and K Inputs to First Stage
- Right-shift Only with Complementary Outputs on Last Stage
- Direct Overriding Clear
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
I_{OL} = 8 mA @ V_{OL} = 0.5V
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C

PIN CONFIGURATION



FUNCTION TABLE

| INPUTS | | | | | OUTPUTS | | | | | | | | |
|--------|-------|-----|--------|---|----------|---|---|---|-----------------|-----------------|-----------------|-----------------|----------------------|
| CLR | SH/LD | CLK | SERIAL | | PARALLEL | | | | Q _A | Q _B | Q _C | Q _D | Q _D -bar |
| | | | J | K | A | B | C | D | | | | | |
| L | X | X | X | X | X | X | X | X | L | L | L | L | H |
| H | L | ↑ | X | X | a | b | c | d | a | b | c | d | d |
| H | H | L | X | X | X | X | X | X | Q _{A0} | Q _{B0} | Q _{C0} | Q _{D0} | Q _{D0} -bar |
| H | H | ↑ | L | H | X | X | X | X | Q _{A0} | Q _{A0} | Q _{Bn} | Q _{Cn} | Q _{Cn} -bar |
| H | H | ↑ | L | L | X | X | X | X | L | Q _{An} | Q _{Bn} | Q _{Cn} | Q _{Cn} -bar |
| H | H | ↑ | H | H | X | X | X | X | H | Q _{An} | Q _{Bn} | Q _{Cn} | Q _{Cn} -bar |
| H | H | ↑ | H | L | X | X | X | X | Q _{An} | Q _{An} | Q _{Bn} | Q _{Cn} | Q _{Cn} -bar |

H=high level (steady state)
L=low level (steady state)
X=irrelevant (any input, including transitions)
↑=transition from low to high level
a,b,c,d=the level of steady-state input at A,B,C, or D, respectively.
Q_{A0}, Q_{B0}, Q_{C0}, Q_{D0}=the level of Q_A, Q_B, Q_C, or Q_D, respectively, before the indicated steady-state input conditions were established.
Q_{An}, Q_{Bn}, Q_{Cn}=the level of Q_A, Q_B or Q_C, respectively, before the mostrecent transition of the clock.

DESCRIPTION

These 4-bit registers feature parallel inputs, parallel outputs, J-K serial inputs, shift/load control input, and a direct overriding clear. The registers have two modes of operation:

- Parallel (broadside) load
- Shift (in the direction A_A toward Q_D)

Parallel loading is accomplished by applying the four bits of data and taking the shift/load control input low. The data are loaded into the associated flip-flops and appear at the outputs after the positive transition of the clock input. During loading serial data flow is inhibited.

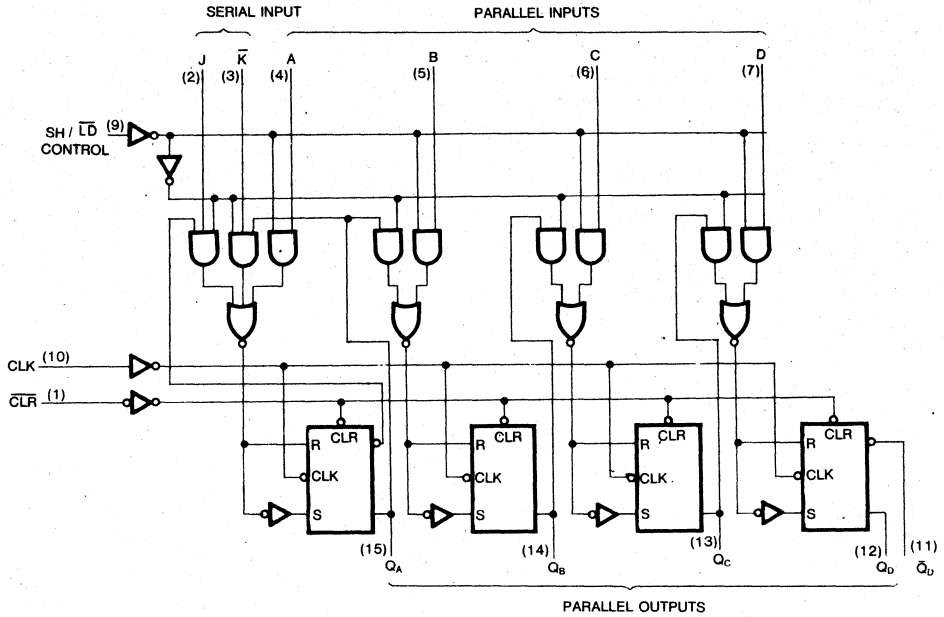
Shifting is accomplished synchronously when the shift/load control input is high. Serial data for this mode is entered at the J-K inputs. These inputs permit the first stage to perform as a J-K, D-, or T-type flip-flop as shown in the function table.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

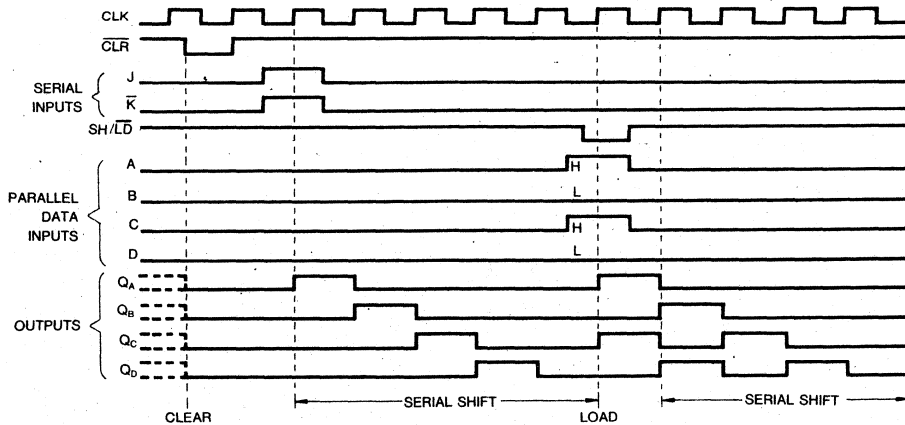
All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.



LOGIC DIAGRAMS



typical clear, shift, and load sequences



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package; P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | | Unit |
|--------------------------------------|-----------------|--|--------------------------------------|------------------------|---------------------------------------|-----------------------|---------|
| | | | Typ | Guaranteed Limits | | | |
| | | | KS74AHCT | | KS54AHCT | | |
| | | | $T_a = -40^\circ C$ to $+85^\circ C$ | | $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT195

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit | |
|--|---------------------------------------|---------------------|--|--|-----|---|-----|------|----|
| | | | Typ | Min | Max | Min | Max | | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 60 | 35 | | 30 | | MHz | |
| Propagation Delay, CLK to Q_H | t_{PLH} | | 10 | | 17 | | 20 | | ns |
| | t_{PHL} | | 10 | | 17 | | 20 | | |
| Propagation Delay, $\overline{\text{CLR}}$ to Q_H | t_{PHL} | | 11 | | 19 | | 22 | ns | |
| Pulse Width | $\overline{\text{CLR}}$ Low | t_w | 10 | 17 | | 20 | | ns | |
| | CLK High or Low | | 10 | 17 | | 20 | | | |
| Setup Time before CLK† | $\text{SH}/\overline{\text{LD}}$ High | t_{su} | 10 | 17 | | 20 | | ns | |
| | Serial or Parallel Data | | 10 | 17 | | 20 | | | |
| | $\overline{\text{CLR}}$ inactive | | 10 | 17 | | 20 | | | |
| Hold Time after CLK† | $\text{SH}/\overline{\text{LD}}$ High | | -3 | 0 | | 0 | | ns | |
| | Serial or Parallel Data | | -3 | 0 | | 0 | | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{\text{PD}} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

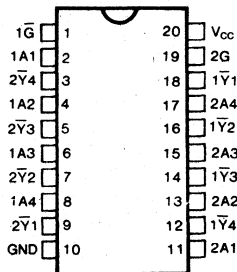
These high-speed octal buffers and line drivers are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

The designer has the choice of combinations of inverting non-inverting outputs and symmetrical complementary input control (both active-low, or one active-low, the other active-high).

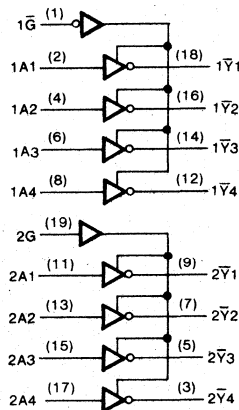
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} .. 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to $+85^\circ\text{C}$
 KS54AHCT: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|-----------------------------------|----------|--|--------------------------|--|---|---------------------|---------------|
| | | | Typ | KS74AHCT $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | KS54AHCT $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | |
| Guaranteed Limits | | | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT210

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|-------------------------------------|-------------------|------------------------|--------------------------|---|-----|--|----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| | | | Typ | $V_{CC} = 5.0\text{V} \pm 10\%$ | | $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Min | Max | Min | Max | | |
| Propagation Delay, A to Y | t _{PLH} | C _L = 50pF | 6 | | 10 | | 12 | ns |
| | | C _L = 150pF | 9 | | 19 | | 23 | |
| | t _{PHL} | C _L = 50pF | 6 | | 10 | | 12 | |
| | | C _L = 150pF | 9 | | 19 | | 23 | |
| Output Enable Time, Enable to Y | t _{PZH} | C _L = 50pF | 12 | | 20 | | 24 | ns |
| | | C _L = 150pF | 18 | | 29 | | 35 | |
| | t _{PZL} | C _L = 50pF | 12 | | 20 | | 24 | |
| | | C _L = 150pF | 18 | | 29 | | 35 | |
| Output Disable Time, Enable to Y | t _{PHZ} | R _L = 1kΩ | 13 | | 18 | | 22 | ns |
| | t _{PLZ} | C _L = 50pF | 13 | | 18 | | 22 | |
| Input Capacitance | C _{IN} | | 5 | | | | | pF |
| Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | | pF |
| Power Dissipation Capacitance* | C _{PD} * | Output Disabled | 5 | | | | | pF |
| | | Output Enabled | 30 | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Designed specifically for high-speed memory decoders and data transmission systems.
- Incorporates 2 enable inputs to simplify cascading and/or data reception
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

These devices are designed to be used in high-performance memory-decoding or data-routing applications requiring very short propagation delay times. In high-performance memory systems, these decoders can be used with high-speed memories utilizing a fast enable circuit, the delay times of these decoders and the enable time of the memory are usually less than the typical access time of the memory. This means that the effective system delay introduced by the decoder is negligible.

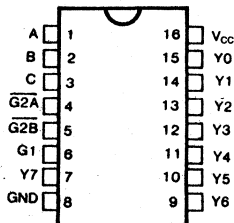
This conditions at the binary select inputs and the three enable inputs select one of eight input lines. Two active-low and one active-high enable inputs reduce the need for external gates or inverters when expanding.

A 24-line decoder can be implemented without external inverters and a 31-line decoder requires only one inverter. An enable input can be used as a data input for demultiplexing applications.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

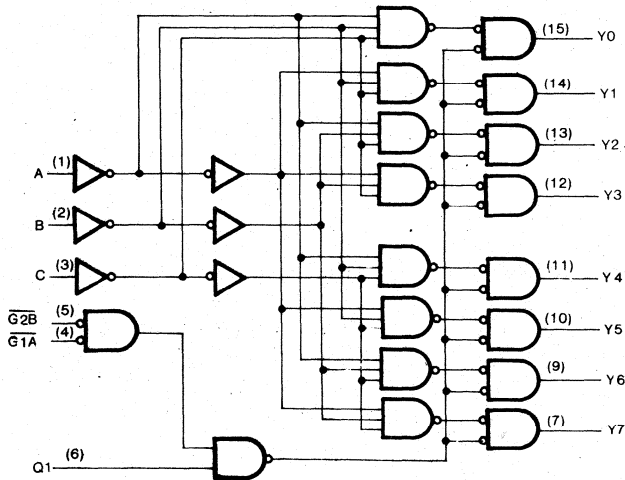


FUNCTION TABLE

| Enable Inputs | | Select Inputs | | | Outputs | | | | | | | |
|---------------|-------------------|---------------|---|---|---------|----|----|----|----|----|----|----|
| G1 | $\overline{G2}^*$ | C | B | A | Y0 | Y1 | Y2 | Y3 | Y4 | Y5 | Y6 | Y7 |
| X | H | X | X | X | L | L | L | L | L | L | L | L |
| L | X | X | X | X | L | L | L | L | L | L | L | L |
| H | L | L | L | L | H | L | L | L | L | L | L | L |
| H | L | L | L | H | L | H | L | L | L | L | L | L |
| H | L | L | H | L | L | L | H | L | L | L | L | L |
| H | L | H | L | L | L | L | L | H | L | L | L | L |
| H | L | H | L | H | L | L | L | L | L | H | L | L |
| H | L | H | H | L | L | L | L | L | L | L | H | L |
| H | L | H | H | H | L | L | L | L | L | L | L | H |

* $\overline{G2} = \overline{G2A} + \overline{G2B}$

LOGIC DIAGRAM



Absolute Maximum Ratings*

| | |
|--|-----------------|
| Supply Voltage Range V_{CC} , | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | |
|---|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} .. | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74AHCT: -40°C to +85°C KS54AHCT: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V\pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_A = 25^\circ\text{C}$ | | | | KS74AHCT | | KS54AHCT | | Unit |
|--------------------------------------|-----------------|---|--------------------------|------------------------|------------------------|-----------------------|---|-----------------------|--|---------------|------|
| | | | | | | | $T_A = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_A = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| | | | Guaranteed Limits | | | | | | | | |
| | | | Typ | | | | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | $V_{CC} - 0.1$ 3.7 | $V_{CC} - 0.1$ 3.7 | $V_{CC} - 0.1$ 3.7 | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.33 0.5 | 0.1 0.33 0.5 | 0.1 0.33 0.5 | 0.1 0.33 0.5 | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | ± 1.0 | ± 1.0 | ± 1.0 | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 80.0 | 160.0 | 160.0 | 160.0 | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 2.9 | 3.0 | 3.0 | 3.0 | mA | |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT238

| Characteristic | Symbol | Conditions† | $T_A = 25^\circ\text{C}$ | | KS74AHCT | | KS54AHCT | | Unit |
|---|-----------|---------------------|--------------------------|-----|---|-----|--|----|------|
| | | | $V_{CC} = 5.0\text{V}$ | | $T_A = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_A = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| | | | | | $V_{CC} = 5.0\text{V} \pm 10\%$ | | $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay, A, B, C or Y | t_{PLH} | $C_L = 50\text{pF}$ | 12 | | 20 | | 24 | ns | |
| | t_{PHL} | | 12 | | 20 | | 24 | | |
| Propagation Delay, G1 to any Y | t_{PLH} | | 10 | | 17 | | 20 | ns | |
| | t_{PHL} | | 10 | | 17 | | 20 | | |
| Propagation Delay, G2A or G2B to any Y | t_{PLH} | | 10 | | 17 | | 20 | ns | |
| | t_{PHL} | | 10 | | 17 | | 20 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | 50 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Designed specifically for high-speed memory decoders and data transmission systems
- Incorporates 2 enable inputs to simplify cascading and/or data reception
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

These devices are designed to be used in high-performance memory-decoding or data-routing applications requiring very short propagation delay times in high-performance memory systems, these decoders can be used to minimize the effects of system decoding. When used with high-speed memories utilizing a fast-enable circuit, the delay times of these decoders and the enable time of the memory are usually less than the typical access time of the memory.

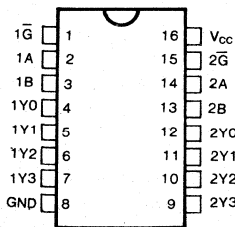
This means that the effective system delay introduced by the decoder is negligible.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

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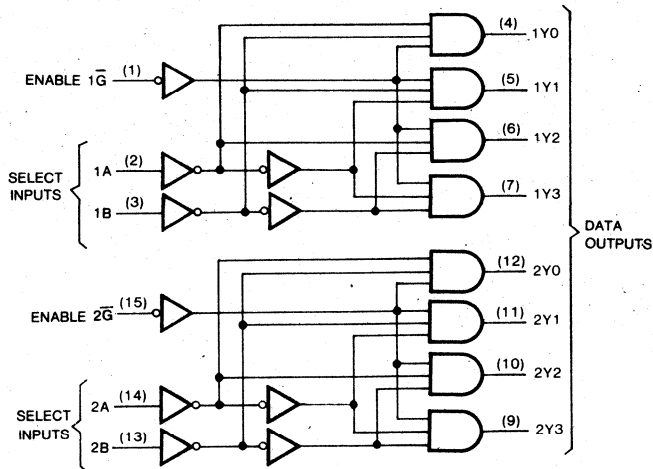
PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | | Outputs | | | |
|-----------|--------|---|---------|----|----|----|
| Enable | Select | | Y0 | Y1 | Y2 | Y3 |
| \bar{G} | B | A | | | | |
| H | X | X | L | L | L | L |
| L | L | L | H | L | L | L |
| L | L | H | L | H | L | L |
| L | H | L | L | L | H | L |
| L | H | H | L | L | L | H |

LOGIC DIAGRAM



Absolute Maximum Ratings*

| | |
|--|---|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74AHCT: -40°C to $+85^\circ\text{C}$ KS54AHCT: -55°C to $+125^\circ\text{C}$ |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | | Unit |
|--------------------------------------|-----------------|---|---|------------------------|--|-----------------------|---------------|
| | | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

4

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT239

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|--|-----------|---------------------|--|--|--|-----|---|-----|------|
| | | | Typ | | Min | Max | Min | Max | |
| Propagation Delay, A or B to any Y | t_{PLH} | $C_L = 50\text{pF}$ | 12 | | | 20 | | 24 | ns |
| | t_{PHL} | | 12 | | | 20 | | 24 | |
| Propagation Delay, \bar{G} to any Y | t_{PLH} | | 10 | | | 17 | | 20 | ns |
| | t_{PHL} | | 10 | | | 17 | | 20 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | 50 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.
† For AC switching test circuits and timing waveforms see section 2.

KS54AHCT 240/241/244 Octal Buffers and Line Drivers with 3-State Outputs

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with drive current ($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

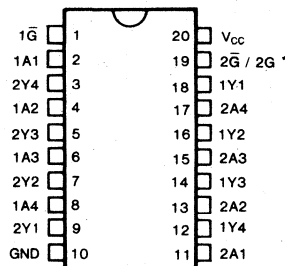
These high-speed octal buffers and line drivers are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

The designer has the choice of combinations of inverting/non-inverting outputs and symmetrical complementary input control (both active-low, or one active-low, the other active-high).

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

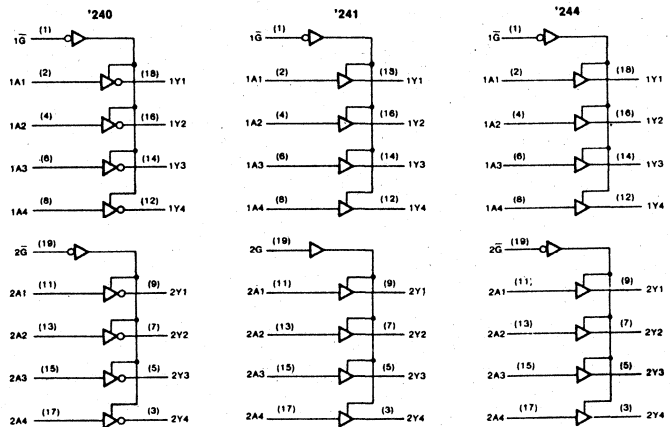
All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



*2G for '240 and '244
2G for '241

LOGIC DIAGRAMS



KS54AHCT 240/241/244 Octal Buffers and Line Drivers KS74AHCT with 3-State Outputs

Absolute Maximum Ratings*

| | |
|---|---|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | $(V_I < -0.5V \text{ or } V_I > V_{CC} + 0.5V)$ ± 20 mA |
| DC Output Diode Current, I_{OK} | $(V_O < -0.5V \text{ or } V_O > V_{CC} + 0.5V)$ ± 20 mA |
| Continuous Output Current Per Pin, I_O | $(-0.5V < V_O < V_{CC} + 0.5V)$ ± 70 mA |
| Continuous Current Through V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74AHCT: -40°C to $+85^\circ\text{C}$ KS54AHCT: -55°C to $+125^\circ\text{C}$ |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|-----------------------------------|----------|--|--------------------------|----------------------|--|---|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |

4

KS54AHCT 240/241/244 Octal Buffers and Line Drivers KS74AHCT with 3-State Outputs

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT240, AHCT241, AHCT244

| Characteristic | Symbol | Conditions† | KS74AHCT | | KS54AHCT | | Unit | | |
|-------------------------------------|-----------|-------------------------|--|-----|--|-----|------|---|----|
| | | | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | Min | Max | Min | | Max | |
| Propagation Delay, A to Y | t_{PLH} | $C_L = 50\text{pF}$ | 6 | | 10 | | 12 | ns | |
| | | $C_L = 150\text{pF}$ | 9 | | 19 | | 23 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 6 | | 10 | | 12 | ns | |
| | | $C_L = 150\text{pF}$ | 9 | | 19 | | 23 | | |
| Output Enable Time, Enable to Y | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 12 | | 20 | | 24 | ns |
| | | | $C_L = 150\text{pF}$ | 18 | | 29 | | 35 | |
| | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 12 | | 20 | | 24 | ns |
| | | | $C_L = 150\text{pF}$ | 18 | | 29 | | 24 | |
| Output Disable Time, Enable to Y | t_{PHZ} | $R_L = 1\text{k}\Omega$ | | 13 | | 18 | | 22 | ns |
| | | | $C_L = 50\text{pF}$ | 13 | | 18 | | 22 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | Output Disabled | 5 | | | | | pF | |
| | | Output Enabled | 30 | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- 2-Way Asynchronous Communication Between Data Buses
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

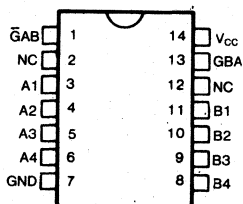
DESCRIPTION

These four-data line transceivers are designed for asynchronous two-way communications between data buses.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

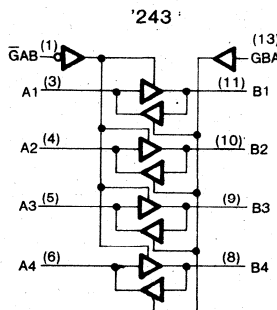
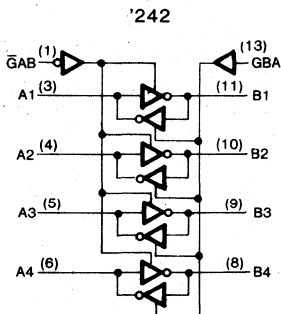
PIN CONFIGURATION



FUNCTION TABLE

| INPUTS | | '242 | '243 |
|-------------|-----|----------------------------------|----------------------------|
| $\bar{G}AB$ | GBA | | |
| L | L | \bar{A} to B | A to B |
| H | H | \bar{B} to A | B to A |
| H | L | Isolation | Isolation |
| L | H | Latch A and B ($A=\bar{B}$) | Latch A and B ($A=B$) |

LOGIC DIAGRAMS



4

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range
 KS74AHCT: -40°C to $+85^\circ\text{C}$
 KS54AHCT: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|----------------------|--|---------------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT242, AHCT243

| Characteristic | Symbol | Conditions† | T _a = 25°C | KS74AHCT | | KS54AHCT | | Unit | |
|--|------------------|---|---|---|----------|--|----------|------|--|
| | | | V _{CC} = 5.0V | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | | |
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay, A to B or B to A | t _{PLH} | C _L = 50pF C _L = 150pF | 7 10 | | 11 20 | | 15 25 | ns | |
| | t _{PHL} | C _L = 50pF C _L = 150pF | 7 10 | | 11 20 | | 15 25 | | |
| Output Enable Time GAB to B, GBA to A | t _{PZH} | R _L = 1kΩ | C _L = 50pF C _L = 150pF | 12 18 | 20 29 | | 25 36 | ns | |
| | t _{PZL} | | C _L = 50pF C _L = 150pF | 12 18 | 20 29 | | 25 36 | | |
| Output Disable Time, GAB to B, GBA to A | t _{PHZ} | R _L = 1kΩ | 12 | | 20 | | 25 | ns | |
| | t _{PLZ} | C _L = 50pF | 12 | | 20 | | 25 | | |
| Input Capacitance | C _{IN} | | 5 | | | | | pF | |
| Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance*(per stage) | C _{PD} | Output Enabled | 30 | | | | | pF | |
| | | Output Disabled | 5 | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

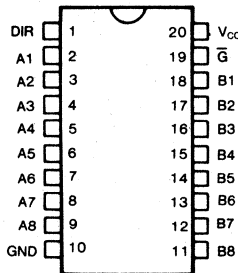
These high-speed octal bus transceivers are designed for synchronous two-way communication between data buses. The control function implementation minimizes external timing requirements.

The devices allow data transmission from the A bus to the B bus or from the B bus to the A bus depending upon the logic level at the direction control (DIR) input. The enable input (\bar{G}) can be used to disable the device so that the buses are effectively isolated.

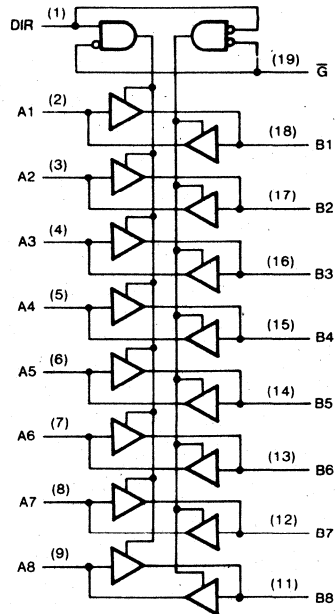
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

| Inputs | | Operation |
|-----------|-----|---------------------|
| \bar{G} | DIR | |
| L | L | Bus B Data to Bus A |
| L | H | Bus A Data to Bus B |
| H | X | Isolation |

Absolute Maximum Ratings*

| | |
|---|---|
| Supply Voltage Range, V_{CC} , | -0.5V to +7V |
| DC Input Diode Current, I_{IK} ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 70 mA |
| Continuous Current Through V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

| | |
|---|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN} , V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74AHCT: -40°C to $+85^\circ\text{C}$ KS54AHCT: -55°C to $+125^\circ\text{C}$ |
| Input Rise & Fall Times, t_r , t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|--|---|-----------------------|-------------------|
| | | | Typ | KS74AHCT $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | KS54AHCT $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | Guaranteed Limits |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $= V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns, AHCT245)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit | |
|---|-----------|---|--|--|-----|---|-----|------|----|
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay, A to B or B to A | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 6 | | 10 | | 14 | ns | |
| | | | 9 | | 19 | | 25 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 6 | | 10 | | 14 | | |
| | | | 9 | | 19 | | 25 | | |
| Output Enable Time \bar{G} to A or B | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 12 | | 20 | | 25 | ns |
| | | | $C_L = 150\text{pF}$ | 18 | | 29 | | 36 | |
| | t_{PZL} | | $C_L = 50\text{pF}$ | 12 | | 20 | | 25 | |
| | | | $C_L = 150\text{pF}$ | 18 | | 29 | | 36 | |
| Output Disable Time, \bar{G} to A or B | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 13 | | 18 | | 22 | ns | |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 13 | | 18 | | 22 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | $\bar{G} = V_{CC}$ | 5 | | | | | pF | |
| | | $\bar{G} = \text{GND}$ (per stage) | 30 | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Three-State Version of '151
- Three-State Outputs Interface Directly with System Bus
- Performs Parallel-to-Serial Conversion
- Complementary Outputs Provide True and Inverted Data
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

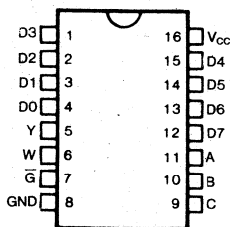
These data selectors/multiplexers contain full binary decoding to select one-of-eight data sources and feature strobe-controlled complementary three-state outputs.

The three-state outputs can interface with and drive data lines of bus-organized systems. With all but one of the common outputs disabled (at a high-impedance state), the low-impedance of the single enabled output will drive the bus line to a high or low logic level. Both outputs are controlled by the strobe (\bar{G}). The outputs are disabled when \bar{G} is high.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

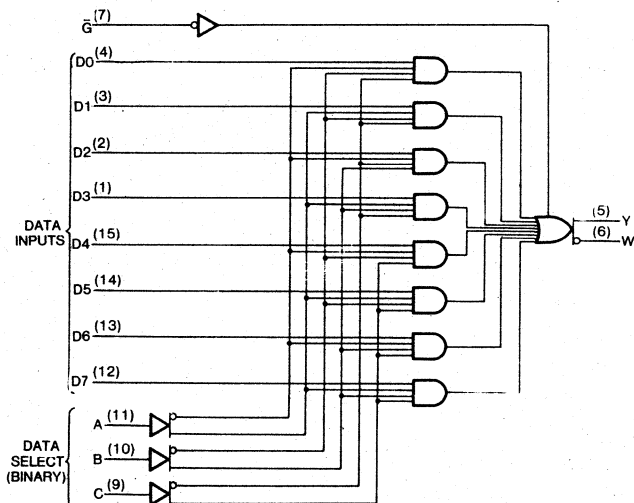
PIN CONFIGURATION



FUNCTION TABLE

| INPUTS | | | | OUTPUTS | |
|--------|---|---|-----------|---------|-------------|
| SELECT | | | STROBE | Y | W |
| C | B | A | \bar{G} | | |
| X | X | X | H | Z | Z |
| L | L | L | L | D0 | \bar{D}_0 |
| L | L | H | L | D1 | \bar{D}_1 |
| L | H | L | L | D2 | \bar{D}_2 |
| L | H | H | L | D3 | \bar{D}_3 |
| H | L | L | L | D4 | \bar{D}_4 |
| H | L | H | L | D5 | \bar{D}_5 |
| H | H | L | L | D6 | \bar{D}_6 |
| H | H | H | L | D7 | \bar{D}_7 |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to $+85^\circ\text{C}$
 KS54AHCT: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|------------------------|--|---------------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT251

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit | |
|---|-----------|-------------------------|--------------------------|--|-----|---|-----|------|--|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | | |
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay, A, B or C to Y | t_{PLH} | $C_L = 50\text{pF}$ | 13 | | 21 | | 25 | ns | |
| | | $C_L = 150\text{pF}$ | 16 | | 30 | | 36 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 13 | | 21 | | 25 | ns | |
| | | $C_L = 150\text{pF}$ | 16 | | 30 | | 36 | | |
| Propagation Delay, A, B or C to W | t_{PLH} | $C_L = 50\text{pF}$ | 15 | | 24 | | 27 | ns | |
| | | $C_L = 150\text{pF}$ | 18 | | 33 | | 38 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 15 | | 24 | | 27 | ns | |
| | | $C_L = 150\text{pF}$ | 18 | | 33 | | 38 | | |
| Propagation Delay, Any D to Y | t_{PLH} | $C_L = 50\text{pF}$ | 9 | | 15 | | 18 | ns | |
| | | $C_L = 150\text{pF}$ | 12 | | 24 | | 27 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 9 | | 15 | | 18 | ns | |
| | | $C_L = 150\text{pF}$ | 12 | | 24 | | 29 | | |
| Propagation Delay, Any D to W | t_{PLH} | $C_L = 50\text{pF}$ | 8 | | 15 | | 18 | ns | |
| | | $C_L = 150\text{pF}$ | 11 | | 24 | | 29 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 8 | | 15 | | 18 | ns | |
| | | $C_L = 150\text{pF}$ | 11 | | 24 | | 29 | | |
| Output Enable Time, \bar{G} to Y or W | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 11 | | 18 | 22 | ns | |
| | | | $C_L = 150\text{pF}$ | 17 | | 27 | 33 | | |
| | t_{PZL} | $C_L = 50\text{pF}$ | 11 | | 18 | 22 | | | |
| | | $C_L = 150\text{pF}$ | 17 | | 27 | 33 | | | |
| Output Disable Time, \bar{G} to Y or W | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 13 | | 18 | 22 | ns | | |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 13 | | 18 | 22 | | | |
| Input Capacitance | C_{IN} | | 5 | | | | pF | | |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF | | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

4

Preliminary Specifications

FEATURES

- Three-State Version of '153
- Permits Multiplexing from N Lines to 1 Line
- Performs Parallel-to-Serial Conversion
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

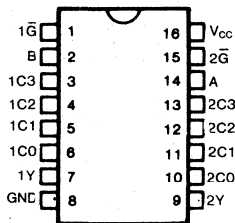
Each of these data selectors/multiplexers contains inverters and drivers to supply full binary decoding data selection to the AND-OR gates. Separate output control inputs are provided for each of the two four-line sections.

The three-state outputs can interface with and drive data lines of bus-organized systems. With all but one of the common outputs disabled (at a high-impedance state) the low-impedance of the single enabled output will drive the bus line to a high or low logic level. Each output has its own strobe (\bar{G}). The output is disabled when its strobe is high.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

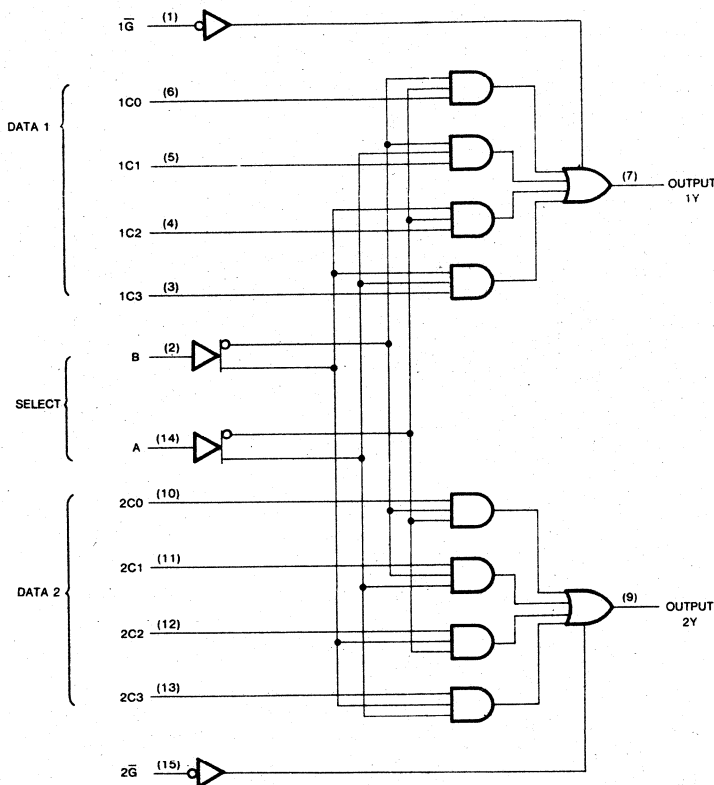


FUNCTION TABLE

| SELECT | | DATA INPUTS | | | | OUTPUT CONTROL | OUTPUT |
|--------|---|-------------|----|----|----|----------------|--------|
| B | A | C0 | C1 | C2 | C3 | \bar{G} | Y |
| X | X | X | X | X | X | H | Z |
| L | L | L | X | X | X | L | L |
| L | L | H | X | X | X | L | H |
| L | H | X | L | X | X | L | L |
| L | H | X | H | X | X | L | H |
| H | L | X | X | L | X | L | L |
| H | L | X | X | H | X | L | H |
| H | H | X | X | X | L | L | L |
| H | H | X | X | X | H | L | H |

Address inputs A and B are common to both sections.

LOGIC DIAGRAM



4

Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} , -0.5V to +7V
- DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
- DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
- Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
- Continuous Current Through
 V_{CC} or GND pins ± 250 mA
- Storage Temperature Range, T_{stg} -65°C to +150°C
- Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN}, V_{OUT} ... 0V to V_{CC}
- Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
- Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|---|--------------------------|----------------------|---|---------------------|--|---------------|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | μA | |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | | mA | |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns, AHCT253)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit | |
|---|-----------|-----------------------|--------------------------|---|-----|--|-----|-------------|----|
| | | | $V_{CC}=5.0\text{V}$ | $V_{CC}=5.0\text{V} \pm 10\%$ | | $V_{CC}=5.0\text{V} \pm 10\%$ | | | |
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay, A or B to any Y | t_{PLH} | $C_L=50\text{pF}$ | 13 | | 21 | | 25 | ns | |
| | | $C_L=150\text{pF}$ | 16 | | 30 | | 30 | | |
| | t_{PHL} | $C_L=50\text{pF}$ | 13 | | 21 | | 25 | ns | |
| | | $C_L=150\text{pF}$ | 16 | | 30 | | 36 | | |
| Propagation Delay, Data (any C) to any Y | t_{PLH} | $C_L=50\text{pF}$ | 9 | | 15 | | 18 | ns | |
| | | $C_L=150\text{pF}$ | 12 | | 24 | | 29 | | |
| | t_{PHL} | $C_L=50\text{pF}$ | 9 | | 15 | | 18 | ns | |
| | | $C_L=150\text{pF}$ | 12 | | 24 | | 29 | | |
| Output Enable Time G to Y | t_{PZH} | $R_L=1\text{k}\Omega$ | $C_L=50\text{pF}$ | 10 | | 16 | | 19 | ns |
| | | | $C_L=150\text{pF}$ | 16 | | 25 | | 30 | |
| | t_{PZL} | $R_L=1\text{k}\Omega$ | $C_L=50\text{pF}$ | 10 | | 16 | | 19 | ns |
| | | | $C_L=150\text{pF}$ | 16 | | 25 | | 30 | |
| Output Disable Time, G to Y | t_{PHZ} | $R_L=1\text{k}\Omega$ | | 13 | | 18 | | 22 | ns |
| | | | $C_L=50\text{pF}$ | 13 | | 18 | | 22 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.



KS54AHCT 257/258 Quad 2-Line to 1-Line Data Selector/ KS74AHCT Multiplexers with 3-State Outputs

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

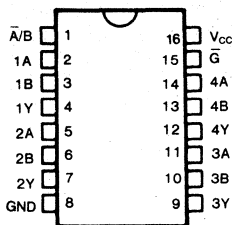
DESCRIPTION

The '257 and '258 multiplex signals from four-bit data sources to four-output data lines in bus organized systems. The data presented at the outputs is non-inverted for the '257, and inverted for the '258.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

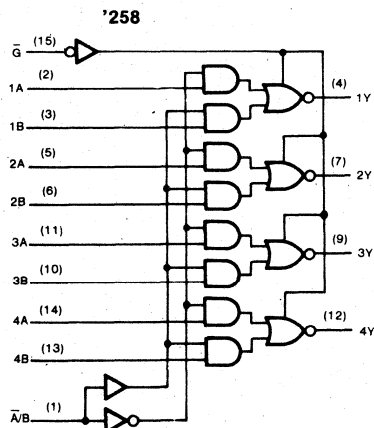
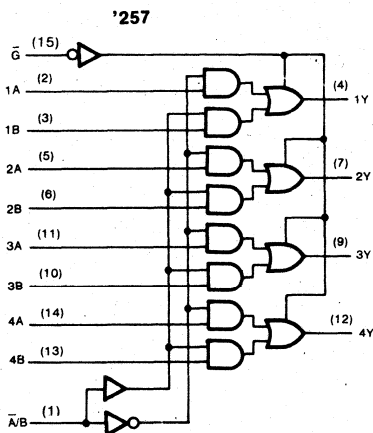


FUNCTION TABLE

| Output Control | Inputs | | Output Y | | |
|----------------|-------------|------|----------|------|------|
| | Select | Data | | '257 | '258 |
| | | A | B | | |
| \bar{G} | $\bar{A/B}$ | A | B | | |
| H | X | X | X | Z | Z |
| L | L | L | X | L | H |
| L | L | H | X | H | L |
| L | H | X | L | L | H |
| L | H | X | H | H | L |

4

LOGIC DIAGRAMS



KS54AHCT 257/258 Quad 2-Line to 1-Line Data Selector/ KS74AHCT Multiplexers with 3-State Outputs

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} ... -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature

Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C

Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|---|--|-----------------------|-------------------|
| | | | Typ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Guaranteed Limits |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

KS54AHCT 257/258 Quad 2-Line to 1-Line Data Selector/ KS74AHCT Multiplexers with 3-State Outputs

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns, AHCT257)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|---------------------------------------|-----------|-------------------------|--------------------------|---|-----|--|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, A or B to any Y | t_{PLH} | $C_L = 50\text{pF}$ | 7 | | 12 | | 14 | ns |
| | | $C_L = 150\text{pF}$ | 10 | | 21 | | 25 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 7 | | 12 | | 14 | ns |
| | | $C_L = 150\text{pF}$ | 10 | | 21 | | 25 | |
| Propagation Delay, A/B to any Y | t_{PLH} | $C_L = 50\text{pF}$ | 12 | | 20 | | 24 | ns |
| | | $C_L = 150\text{pF}$ | 15 | | 29 | | 35 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 12 | | 20 | | 24 | ns |
| | | $C_L = 150\text{pF}$ | 15 | | 29 | | 35 | |
| Output Enable Time, G to any Y | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | | 18 | | 22 | ns |
| | | | $C_L = 150\text{pF}$ | 19 | | 26 | 31 | |
| | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | | 18 | | 22 | ns |
| | | | $C_L = 150\text{pF}$ | 19 | | 27 | 33 | |
| Output Disable Time, G to any Y | t_{PHZ} | $R_L = 1\text{k}\Omega$ | | 13 | 18 | | 22 | ns |
| | | | $C_L = 50\text{pF}$ | 13 | 18 | | 22 | |
| Input Capacitance | C_{IN} | | 5 | | | | pF | |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns, AHCT258)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|---------------------------------------|-----------|-------------------------|--------------------------|---|-----|--|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, A or B to any Y | t_{PLH} | $C_L = 50\text{pF}$ | 7 | | 12 | | 14 | ns |
| | | $C_L = 150\text{pF}$ | 10 | | 21 | | 25 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 9 | | 14 | | 16 | ns |
| | | $C_L = 150\text{pF}$ | 12 | | 23 | | 27 | |
| Propagation Delay, A/B to any Y | t_{PLH} | $C_L = 50\text{pF}$ | 14 | | 23 | | 28 | ns |
| | | $C_L = 150\text{pF}$ | 17 | | 32 | | 39 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 14 | | 23 | | 28 | ns |
| | | $C_L = 150\text{pF}$ | 17 | | 32 | | 39 | |
| Output Enable Time, G to any Y | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | | 18 | | 22 | ns |
| | | | $C_L = 150\text{pF}$ | 17 | | 27 | 33 | |
| | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | | 18 | | 22 | ns |
| | | | $C_L = 150\text{pF}$ | 17 | | 27 | 33 | |
| Output Disable Time, G to any Y | t_{PHZ} | $R_L = 1\text{k}\Omega$ | | 13 | 18 | | 22 | ns |
| | | | $C_L = 50\text{pF}$ | 13 | 18 | | 22 | |
| Input Capacitance | C_{IN} | | 5 | | | | pF | |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF | |

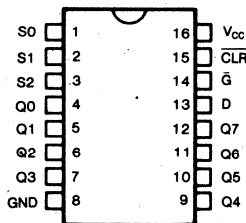
* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- 8-Bit parallel-out storage register performs serial-to-parallel conversion with storage
- Asynchronous parallel clear
- Active high decoder
- Enable/Disable input simplifies expansion
- Expandable for N-bit applications
- Four distinct functional modes
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | Output of Addressed Latch | Each Other Output | Function |
|--------|---|---------------------------|-------------------|----------------------|
| CLR | G | | | |
| H | L | D | Q_{i0} | Addressable Latch |
| H | H | Q_{i0} | Q_{i0} | Memory |
| L | L | D | L | 8-Line Demultiplexer |
| L | H | L | L | Clear |

D = the level at the data input.

Q_{i0} = the level of Q_{i0} ($i = Q, 1, \dots, 7$, as appropriate) before the indicated steady-state input conditions were established.

DESCRIPTION

The '259 is a high-speed addressable latch designed for general purpose storage applications in digital systems. It can be used for implementing working registers, serial-holding registers and active-high decoders or demultiplexers.

The '259 has four distinct modes of operation that are selected via the clear (CLR) and enable (G) inputs: 1) addressable latch; 2) memory; 3) active-high eight-channel demultiplexer; and 4) clear.

In the addressable latch mode, data on the data input (D) is written into the addressed latch. In this mode, data will be written into the addressed latch with all non-addressed latches remaining in their previous states.

In the memory mode, all latches remain in their previous state and are unaffected by the data of address inputs.

In the demultiplexing mode, addressed outputs will follow the state of the D input and all other outputs will remain low.

In the clear mode, all outputs are low and unaffected by the address and data inputs.

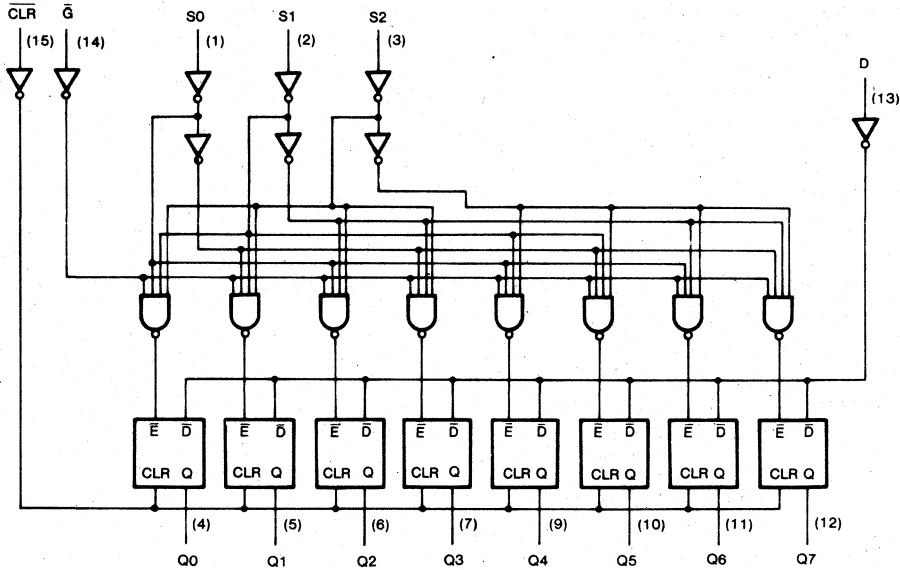
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LATCH SELECTION TABLE

| Select Inputs | | | Latch Addressed |
|---------------|----|----|-----------------|
| S2 | S1 | S0 | |
| L | L | L | 0 |
| L | L | H | 1 |
| L | H | L | 2 |
| L | H | H | 3 |
| H | L | L | 4 |
| H | L | H | 5 |
| H | H | L | 6 |
| H | H | H | 7 |

LOGIC DIAGRAM



4

Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} , -0.5V to +7V
- DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
- DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
- Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
- Continuous Current Through
 V_{CC} or GND pins ± 125 mA
- Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
- Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

- † Power Dissipation temperature derating:
Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN}, V_{OUT} . . . 0V to V_{CC}
- Operating Temperature
Range
KS74AHCT: -40°C to $+85^\circ\text{C}$
KS54AHCT: -55°C to $+125^\circ\text{C}$
- Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|---|--------------------------|----------------------|---|---------------------|--|--|---------------|
| | | | Typ | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-4\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | | | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT259

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--|---------------|-------------------|--------------------------|---|-----|--|-----|------|
| | | | $V_{CC}=5.0\text{V}$ | $V_{CC}=5.0\text{V} \pm 10\%$ | | $V_{CC}=5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay CLR to any Q | t_{PHL} | $C_L=50\text{pF}$ | 9 | | 15 | | 18 | ns |
| Propagation Delay, Data to any Q | t_{PLH} | | 12 | | 19 | | 23 | ns |
| | t_{PHL} | | 12 | | 19 | | 23 | ns |
| Propagation Delay, Address to any Q | t_{PLH} | | 13 | | 22 | | 27 | ns |
| | t_{PHL} | | 13 | | 22 | | 27 | ns |
| Propagation Delay, \bar{G} to any Q | t_{PLH} | | 12 | | 20 | | 24 | ns |
| | t_{PHL} | | 12 | | 20 | | 24 | ns |
| Pulse Width | CLR Low | t_w | 6 | 10 | | 10 | | ns |
| | \bar{G} Low | | 9 | 15 | | 20 | | ns |
| Setup Time Data or Address before $\bar{G}\uparrow$ | t_{su} | | 10 | 15 | | 20 | | ns |
| Hold Time, Data or Address before $\bar{G}\uparrow$ | t_h | | -3 | 0 | | 0 | | ns |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | 80 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74ALS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

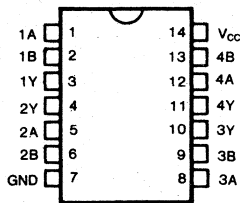
DESCRIPTION

These devices contain four independent exclusive-NOR gates with open-drain outputs. Using a suitable pull-up resistor, these outputs may be connected to other open-drain outputs to implement wired-AND functions.

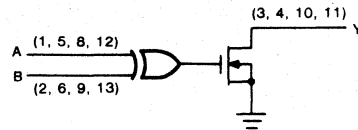
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



4

FUNCTION TABLE

| Inputs | | Output |
|--------|---|--------|
| A | B | Y |
| L | L | H |
| L | H | L |
| H | L | L |
| H | H | H |

Absolute Maximum Ratings*

| | |
|---|---|
| Supply Voltage Range V_{CC} , | -0.5V to +7V |
| DC Input Diode Current, I_{IK} ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74AHCT: -40°C to $+85^\circ\text{C}$ KS54AHCT: -55°C to $+125^\circ\text{C}$ |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit |
|--------------------------------------|-----------------|--|--------------------------|--|---|---------------|
| | | | Typ | KS74AHCT $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | KS54AHCT $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | 0.8 | 0.8 | 0.8 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Output Leakage Current | I_{OZ} | $V_{IN}=V_{IH}$ or V_{IL} $V_{OUT}=V_{CC}$ | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT266

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0V$ | | KS74AHCT $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | | KS54AHCT $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | | Unit |
|--------------------------------|-----------|--|---|-----|--|-----|---|----|------|
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay | t_{PLH} | $C_L = 50\text{pF}$ $R_L = 1\text{k}\Omega$ | 19 | | 29 | | 35 | ns | |
| | t_{PHL} | | 11 | | 18 | | 22 | | |
| Input Capacitance | C_{IN} | | 5 | | | | pF | | |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | pF | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Eight positive-edge-triggered D-type flip-flops with single-rail outputs
- Buffered common clock and asynchronous clear
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
I_{OL} = 24mA @ V_{OL} = 0.5V
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C

DESCRIPTION

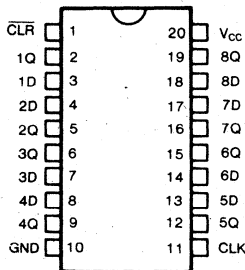
These devices are high-speed octal registers. They consist of eight positive-edge-triggered D-type flip-flops with individual D inputs and Q outputs. All flip flops are loaded and cleared simultaneously by the common buffered clock (CLK) and clear (CLR) inputs.

Information at the D inputs meeting the setup time requirements is transferred to the Q outputs on the positive-going edge of the clock pulse. When the clock input is at either the high or low level, the D input signal has no effect at the output.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

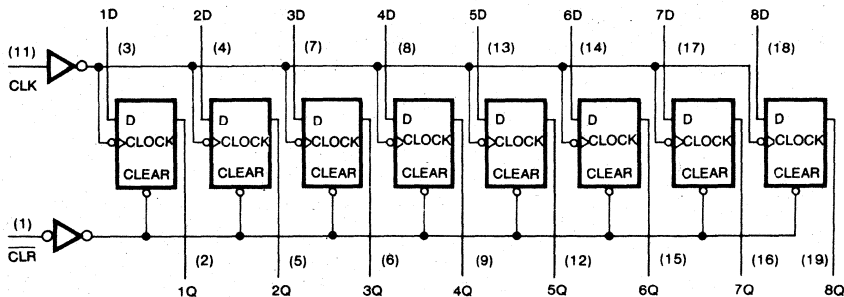


FUNCTION TABLE

(Each Flip-Flop)

| Inputs | | | Output |
|--------|-----|---|----------------|
| CLR | CLK | D | Q |
| L | X | X | L |
| H | ↑ | H | H |
| H | ↑ | L | L |
| H | L | X | Q ₀ |

LOGIC DIAGRAM



Absolute Maximum Ratings*

| | |
|--|-----------------|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 70 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): -12mW/°C from 65°C to 85°C

Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---------------------------|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74AHCT: -40°C to +85°C |
| | KS54AHCT: -55°C to +125°C |

Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|---|--|---------------------|-------------------|
| | | | Typ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Guaranteed Limits |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT273

| Characteristic | Symbol | Conditions† | KS74AHCT | | KS54AHCT | | Unit | |
|------------------------------------|-------------------------|---|--|--|---|-----|----------|-----|
| | | | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 50 | 35 | | 30 | | MHz |
| Propagation Delay, CLK to any | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 10 13 | | 15 24 | | 18 29 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 10 13 | | 15 24 | | 18 29 | |
| Propagation Delay, CLR to any Q | t_{PHL} | $C_L = 50\text{pF}$ | 11 | | 18 | | 22 | ns |
| | | $C_L = 150\text{pF}$ | 14 | | 27 | | 33 | |
| Pulse Width | CLR Low | t_w | 8 | 14 | | 17 | | ns |
| | CLK High or Low | | 8 | 14 | | 17 | | |
| Setup Time before CLK† | Data | t_{su} | 6 | 10 | | 10 | | ns |
| | Clear inactive State | | 9 | 15 | | 15 | | |
| Hold time, Data after CLK† | t_h | | -3 | 0 | | 0 | | ns |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per package) | 150 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Generates Odd or Even Parity for Nine Data Lines
- Cascadable for N-Bits Parity
- Can be used to Upgrade Existing Systems using MSI Parity Circuits
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 (I_{OL} = 24 mA @ V_{OL} = 0.5V) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C

DESCRIPTION

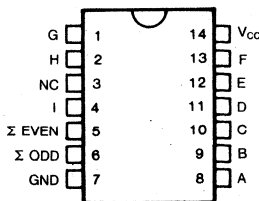
These universal, nine-bit parity generators/checkers feature odd and even outputs to facilitate operation of either odd or even parity application. The word-length capability is easily expanded by cascading.

The devices can be used to upgrade the performance of most systems utilizing the '180 parity generator/checker. Although the '280 is implemented without expander inputs, the corresponding function is provided by the availability of an input at pin 4 and the absence of any internal connection at pin 3. This permits the '280 to be substituted for the '180 in existing designs to produce an identical function even if the devices are mixed with existing '180's.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

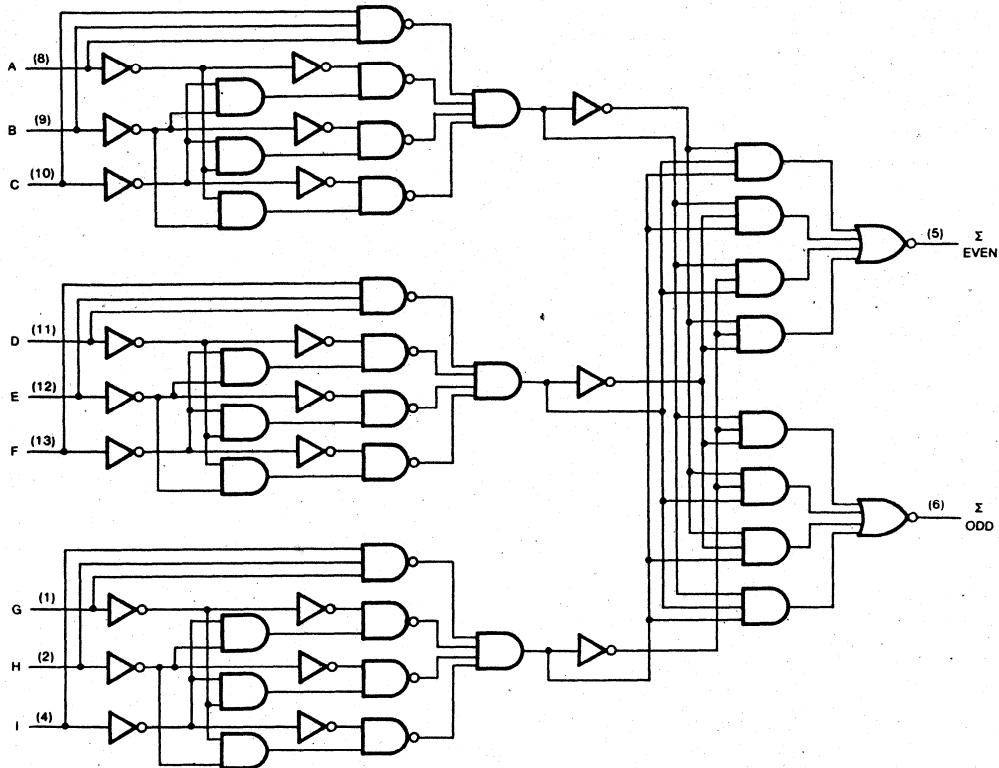
PIN CONFIGURATION



FUNCTION TABLE

| NUMBER OF INPUTS A THRU I THAT ARE HIGH | OUTPUTS | |
|---|---------|-------|
| | Σ EVEN | Σ ODD |
| 0,2,4,6,8 | H | L |
| 1,3,5,7,9 | L | H |

LOGIC DIAGRAM



4

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN}, V_{OUT} . . . 0V to \check{V}_{CC}
 Operating Temperature
 Range KS74AHCT: $-40^\circ C$ to $+85^\circ C$
 KS54AHCT: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r, t_f Max 500 ns
 * Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V\pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|---|--------------------------|----------------------|---|--|--|--|---------------|
| | | | Typ | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | | 2.0 | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | | 0.8 | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | | $V_{CC}-0.1$ 3.7 | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | | 0.1 0.4 | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | | ± 1.0 | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | | 160.0 | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | | 3.0 | | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT280

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--|-----------|---|--------------------------|---|----------|--|----------|------|
| | | | $V_{CC}=5.0\text{V}$ | $V_{CC}=5.0\text{V} \pm 10\%$ | | $V_{CC}=5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, Any input to Σ Even | t_{PLH} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 12 15 | | 20 29 | | 24 35 | ns |
| | t_{PHL} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 12 15 | | 20 29 | | 24 35 | |
| Propagation Delay, Any input to Σ Odd | t_{PLH} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 13 16 | | 22 31 | | 26 37 | ns |
| | t_{PHL} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 13 16 | | 22 31 | | 26 37 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Objective Specifications

FEATURES

- Multiplexed I/O ports provides improved bit density
- Four modes of operation: hold (store), shift right, shift left, and load data
- Operates with outputs enabled or at high impedance
- Can be cascaded for N-bit word lengths
- Direct overriding clear
- Application:
Stacked or push-down registers, buffer storage, and accumulator registers
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with drive current ($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

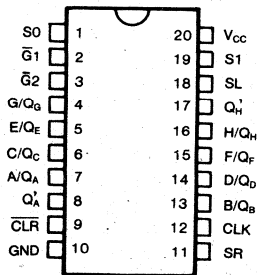
These eight-bit universal registers feature multiplexed I/O ports to achieve full eight-bit data handling. Two function-select inputs and two output-control inputs can be used to choose the modes of operation listed in the function table.

Synchronous parallel loading is accomplished by taking both function-select lines S0 and S1 high. This places the three-state outputs in a high-impedance state and permits data that is applied on the I/O ports to be clocked into the register. Reading out of the register can be accomplished while the outputs are enabled in any mode. Clearing occurs asynchronously when $\overline{\text{CLR}}$ is low. Pulling either of the output controls, $\overline{\text{G1}}$ or $\overline{\text{G2}}$, high disables the outputs but this has no effect on clearing, shifting, or storage of data.

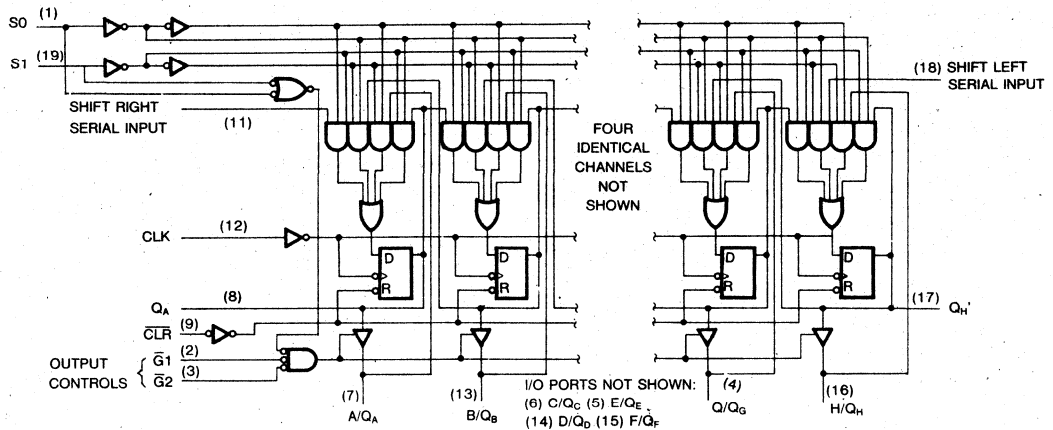
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

| Mode | Inputs | | | | | I/O Ports | | | | | | | | Outputs | | | | |
|-------------|-------------------------|----|----|---|---|-----------|----|----|------------------|------------------|------------------|------------------|------------------|------------------|------------------|------------------|------------------|------------------|
| | $\overline{\text{CLR}}$ | S1 | S0 | Output Control $\overline{\text{G1}}$ $\overline{\text{G2}}$ | | CLK | SL | SR | A/Q _A | B/Q _B | C/Q _C | D/Q _D | E/Q _E | F/Q _F | G/Q _G | H/Q _H | Q _A ' | Q _H ' |
| Clear | L | X | L | L | L | X | X | X | L | L | L | L | L | L | L | L | L | L |
| | L | L | X | L | L | X | X | X | L | L | L | L | L | L | L | L | L | L |
| | L | H | H | X | X | X | X | X | X | X | X | X | X | X | X | X | L | L |
| Hold | H | L | L | L | L | X | X | X | Q _{A0} | Q _{B0} | Q _{C0} | Q _{D0} | Q _{E0} | Q _{F0} | Q _{G0} | Q _{H0} | Q _{A0} | Q _{H0} |
| | H | X | X | L | L | L | X | X | Q _{A0} | Q _{B0} | Q _{C0} | Q _{D0} | Q _{E0} | Q _{F0} | Q _{G0} | Q _{H0} | Q _{A0} | Q _{H0} |
| Shift Right | H | L | H | L | L | ↑ | X | H | H | Q _{An} | Q _{Bn} | Q _{Cn} | Q _{Dn} | Q _{En} | Q _{Fn} | Q _{Gn} | H | Q _{Gn} |
| | H | L | H | L | L | ↑ | X | L | L | Q _{An} | Q _{Bn} | Q _{Cn} | Q _{Dn} | Q _{En} | Q _{Fn} | Q _{Gn} | L | Q _{Gn} |
| Shift Left | H | H | L | L | L | ↑ | H | X | Q _{Bn} | Q _{Cn} | Q _{Dn} | Q _{En} | Q _{Fn} | Q _{Gn} | Q _{Hn} | H | Q _{Bn} | H |
| | H | H | L | L | L | ↑ | L | X | Q _{Bn} | Q _{Cn} | Q _{Dn} | Q _{En} | Q _{Fn} | Q _{Gn} | Q _{Hn} | L | Q _{Bn} | L |
| Load | H | H | H | X | X | ↑ | X | X | a | b | c | d | e | f | g | h | a | h |

When one or both output controls are high the eight input/output terminals are disabled to the high-impedance state; however, sequential operation or clearing of the register is not affected.

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
Continuous Output Current Per Pin, I_O
(-0.5V $< V_O < V_{CC} + 0.5V$) ± 70 mA
Continuous Current Through
 V_{CC} or GND pins ± 250 mA
Storage Temperature Range, T_{stg} -65°C to +150°C
Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
Operating Temperature
Range KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C
Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------------|-------------------|--------------|---|---------------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ Q'_A and Q'_H outputs: $I_O=-4\text{mA}$ | V_{CC} | $V_{CC}-0.1$ | $V_{CC}-0.1$ | $V_{CC}-0.1$ | V |
| | | Q_A thru Q_H outputs: $I_O=-6\text{mA}$ | 4.2 | 3.98 | 3.84 | 3.7 | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ Q'_A and Q'_H outputs: $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 | 0.1 | 0.1 | V |
| | | Q_A thru Q_H outputs: $I_O=12\text{mA}$ $I_O=24\text{mA}$ | | 0.26 0.39 | 0.33 0.5 | 0.4 | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | ± 0.1 | ± 1.0 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IN} $V_{OUT}=V_{CC}$ or GND | ± 0.5 | ± 5.0 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | 8.0 | 80.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | 2.7 | 2.9 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT299

| Characteristic | Symbol | Conditions† | T _a = 25°C | KS74AHCT | | KS54AHCT | | Unit |
|--|-------------------|------------------------|------------------------|---------------------------------|----------------------------------|----------|-----|------|
| | | | V _{CC} = 5.0V | T _a = -40°C to +85°C | T _a = -55°C to +125°C | | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Clock Frequency | f _{max} | | 50 | 30 | | 25 | | MHz |
| Propagation Delay, CLK to Q'A or Q'H | t _{PLH} | C _L = 50pF | 10 | | 17 | | 20 | ns |
| | t _{PHL} | | 10 | | 17 | | 20 | |
| Propagation Delay, CLR to Q'A or Q'H | t _{PHL} | | 13 | | 22 | | 26 | ns |
| Propagation Delay, CLK to Q _A thru Q _H | t _{PLH} | C _L = 50pF | 10 | | 16 | | 19 | ns |
| | t _{PHL} | C _L = 150pF | 13 | | 25 | | 30 | |
| Propagation Delay, CLR to Q _A thru Q _H | t _{PLH} | C _L = 50pF | 10 | | 16 | | 19 | ns |
| | t _{PHL} | C _L = 150pF | 13 | | 26 | | 30 | |
| Output Enable Time, $\bar{G}1, \bar{G}2$, to Q _A thru Q _H | t _{PZH} | R _L = 1kΩ | C _L = 50pF | 11 | | 19 | 23 | ns |
| | t _{PZL} | | C _L = 150pF | 17 | | 28 | 34 | |
| Output Disable Time, $\bar{G}1, \bar{G}2$ to Q _A thru Q _H | t _{PHZ} | R _L = 1kΩ | C _L = 50pF | 11 | | 18 | 22 | ns |
| | t _{PLZ} | | C _L = 150pF | 11 | | 18 | 22 | |
| Pulse Width | CLK High or Low | t _w | | 9 | 15 | | 20 | ns |
| | CLR Low | | | 5 | 8 | | 10 | |
| Setup time before CLK† | S0 and S1 | t _{su} | | 12 | 20 | | 10 | ns |
| | High-Level Inputs | | | 8 | 13 | | 15 | |
| | Low-Level Inputs | | | 8 | 13 | | 15 | |
| | CLR Inactive | | | 8 | 13 | | 15 | |
| Hold Time after CLK† | S0 and S1 | t _h | | 0 | 0 | | 0 | ns |
| | All Inputs | | | 0 | | | | |
| Input Capacitance | C _{IN} | | 5 | | | | | pF |
| Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Inverting Version of '153
- Permits Multiplexing from N Lines to 1 Line
- Performs Parallel-to-Serial Conversion
- Strobe (Enable) Line Provided for Cascading (N Lines to n Lines)
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High drive current outputs
 ($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

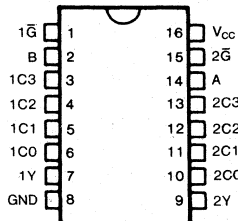
DESCRIPTION

Each of these data selectors/multiplexers contains inverters and drivers to supply fully complementary binary decoding data selection to the AND-OR-invert gates. Separate strobe inputs (\bar{G}) are provided for each of the two four-line sections:

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharging by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

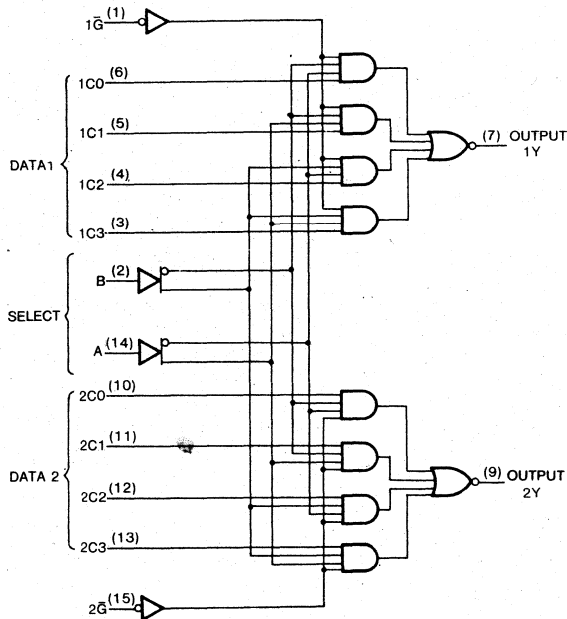


FUNCTION TABLE

| SELECT INPUTS | | DATA INPUTS | | | | STROBE | OUTPUT |
|---------------|---|-------------|----|----|----|-----------|--------|
| B | A | C0 | C1 | C2 | C3 | \bar{G} | Y |
| X | X | X | X | X | X | H | H |
| L | L | L | X | X | X | L | H |
| L | L | H | X | X | X | L | L |
| L | H | X | L | X | X | L | H |
| L | H | X | H | X | X | L | L |
| H | L | X | X | L | X | L | H |
| H | L | X | X | H | X | L | L |
| H | H | X | X | X | L | L | H |
| H | H | X | X | X | H | L | L |

Select inputs A and B are common to both sections.

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to $+85^\circ\text{C}$
 KS54AHCT: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|--|-----------------------|---|--|---------------|
| | | | Typ | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | | | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT352

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|---|-----------|----------------------|--------------------------|---|-----|--|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, A or B to Y | t_{PLH} | $C_L = 50\text{pF}$ | 14 | | 23 | | 28 | ns |
| | | $C_L = 150\text{pF}$ | 17 | | 32 | | 39 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 14 | | 23 | | 28 | |
| | | $C_L = 150\text{pF}$ | 17 | | 32 | | 39 | |
| Propagation Delay, Data (Any C) to Y | t_{PLH} | $C_L = 50\text{pF}$ | 11 | | 18 | | 21 | ns |
| | | $C_L = 150\text{pF}$ | 14 | | 27 | | 32 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 11 | | 18 | | 21 | |
| | | $C_L = 150\text{pF}$ | 14 | | 27 | | 32 | |
| Propagation Delay, G to Y | t_{PLH} | $C_L = 50\text{pF}$ | 12 | | 20 | | 24 | ns |
| | | $C_L = 150\text{pF}$ | 15 | | 29 | | 35 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 12 | | 20 | | 24 | |
| | | $C_L = 150\text{pF}$ | 15 | | 20 | | 35 | |
| Input Capacitance | C_{IN} | | 5 | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

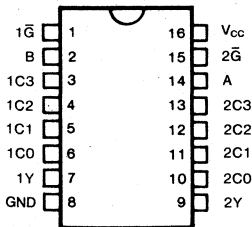
4

Preliminary Specifications

FEATURES

- Inverting Version of '253
- Permits Multiplexing from N lines to 1 line
- Performs Parallel-to-Serial Conversion
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^\circ\text{C}$
KS54AHCT: -55°C to $+125^\circ\text{C}$

PIN CONFIGURATION



FUNCTION TABLE

| SELECT INPUTS | | DATA INPUTS | | | | OUTPUT CONTROL | OUTPUT |
|---------------|---|-------------|----|----|----|----------------|--------|
| B | A | C0 | C1 | C2 | C3 | \bar{G} | Y |
| X | X | X | X | X | X | H | Z |
| L | L | L | X | X | X | L | H |
| L | L | H | X | X | X | L | L |
| L | H | X | L | X | X | L | H |
| L | H | X | H | X | X | L | L |
| H | L | X | X | L | X | L | H |
| H | L | X | X | H | X | L | L |
| H | H | X | X | X | L | L | H |
| H | H | X | X | X | H | L | L |

Select inputs A and B are common to both sections.

DESCRIPTION

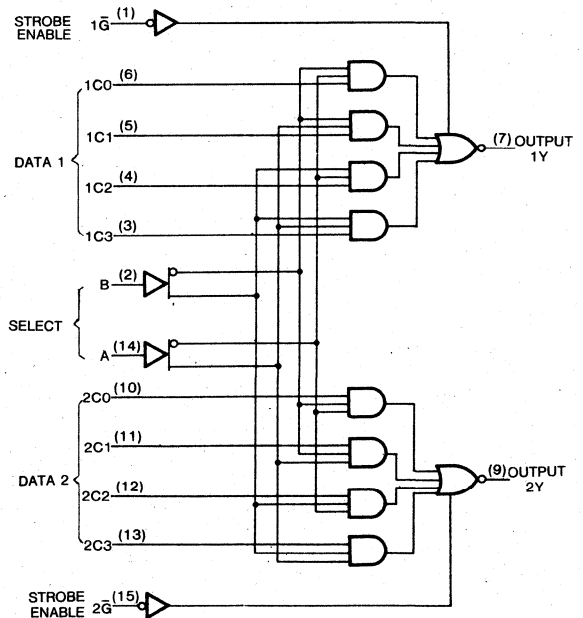
Each of these data selectors/multiplexers contains inverters and drivers to supply full binary decoding data selection to the AND-OR-invert gates. Separate strobe inputs (\bar{G}) are provided for each of the two four-line sections.

The three-state outputs can interface with and drive data lines of bus-organized systems. With all but one of the common outputs disabled (at a high-impedance state) the low-impedance of the single enabled output will drive the bus line to a high or low logic level. Each output has its own strobe (\bar{G}). The output is disabled when its strobe is high.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
Continuous Current Through
 V_{CC} or GND pins ± 250 mA
Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN} , V_{OUT} . . . 0V to V_{CC}
Operating Temperature
Range KS74AHCT: $-40^\circ C$ to $+85^\circ C$
KS54AHCT: $-55^\circ C$ to $+125^\circ C$
Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|------------------------|-----------------------|---------|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -6mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 12mA$ $I_O = 24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

4

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT353

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS64AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit | |
|---|-----------|-------------------------|--|--|-----|---|-----|------|----|
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay, A or B to any Y | t_{PLH} | $C_L = 50\text{pF}$ | 14 | | 24 | | 28 | ns | |
| | | $C_L = 150\text{pF}$ | 17 | | 33 | | 39 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 14 | | 24 | | 28 | ns | |
| | | $C_L = 150\text{pF}$ | 17 | | 33 | | 39 | | |
| Propagation Delay, Data (Any C) to Any Y | t_{PLH} | $C_L = 50\text{pF}$ | 10 | | 18 | | 21 | ns | |
| | | $C_L = 150\text{pF}$ | 13 | | 27 | | 32 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 10 | | 18 | | 21 | ns | |
| | | $C_L = 150\text{pF}$ | 13 | | 27 | | 32 | | |
| Output Enable Time, G to Y | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 10 | | 16 | | 19 | ns |
| | | | $C_L = 150\text{pF}$ | 16 | | 25 | | 30 | |
| | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 10 | | 16 | | 19 | ns |
| | | | $C_L = 150\text{pF}$ | 16 | | 25 | | 30 | |
| Output Disable Time, Ḡ to Y | t_{PHZ} | $R_L = 1\text{k}\Omega$ | | 10 | | 18 | | 22 | ns |
| | | | $C_L = 50\text{pF}$ | 10 | | 18 | | 22 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.



FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

These high-speed Hex bus drivers are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus oriented receivers and transmitters.

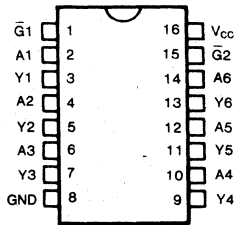
The '365 and '366 have two output enables ($\bar{G}1$ and $\bar{G}2$) NOR'ed together to control all six gates. The '367 and '368 have two output enables which are configured so that one enable ($\bar{G}1$) controls four gates and the other ($\bar{G}2$) controls the remaining two gates. The '366 and '368 have inverting data paths. The '365 and '367 have noninverting data paths.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

4

PIN CONFIGURATION



FUNCTION TABLES

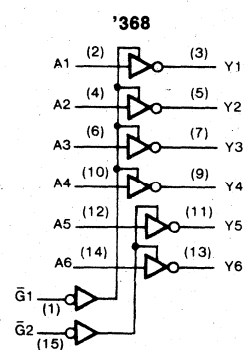
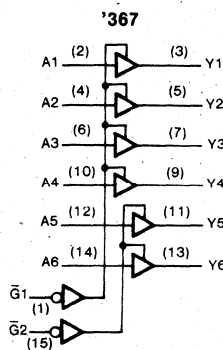
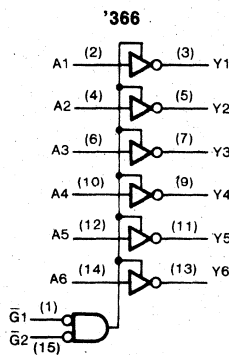
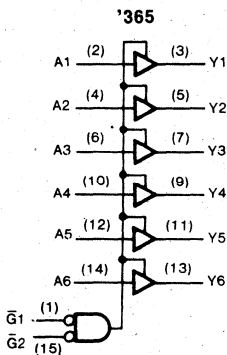
'365 and '356

| Inputs | | Y Outputs | | |
|------------|------------|-----------|------|------|
| $\bar{G}1$ | $\bar{G}2$ | A | '365 | '366 |
| L | L | L | L | H |
| L | L | H | H | L |
| H | X | X | Z | Z |
| X | H | X | Z | Z |

'367 and '368

| Inputs | | Y Outputs | |
|---------|---|-----------|------|
| G1 & G2 | A | '367 | '368 |
| L | L | L | H |
| L | H | H | L |
| H | X | Z | Z |

LOGIC DIAGRAMS



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to $+85^\circ\text{C}$
 KS54AHCT: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|----------------------|---------------------|---------------|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT365, AHCT366,
 AHCT367, AHCT368

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit | |
|--|-----------|--|--|--|-----|---|-----|------|----|
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay, A to Y, | t_{PLH} | $C_L = 50\text{pF}$ | 8 | | 14 | | 17 | ns | |
| | | $C_L = 150\text{pF}$ | 11 | | 23 | | 28 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 8 | | 14 | | 17 | ns | |
| | | $C_L = 150\text{pF}$ | 11 | | 23 | | 28 | | |
| Output Enable Time, \bar{G} to Y | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 14 | | 23 | | 28 | ns |
| | | | $C_L = 150\text{pF}$ | 20 | | 32 | | 39 | |
| | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 14 | | 23 | | 28 | ns |
| | | | $C_L = 150\text{pF}$ | 20 | | 32 | | 39 | |
| Output Disable Time, \bar{G} to Y | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 13 | | 18 | | 22 | ns | |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 13 | | 18 | | 22 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* (per driver) | C_{PD} | $\bar{G} = V_{CC}$ $\bar{G} = \text{GND}$ | 5 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- 8 latches in a single package
- Full parallel access for loading
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

The '373 consists of 8 high-speed D-type latches coupled to 3-state output buffers with high drive current capability. It can be used in implementing buffer registers, I/O ports, bidirectional bus drivers and working registers.

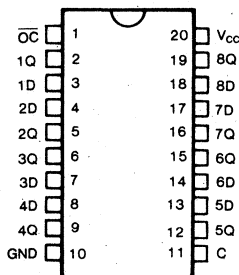
The latches are transparent: when the enable (C) is high, the Q outputs follow the data (D) inputs. When the enable is low, the outputs latch at the levels that were set up at the D inputs.

The output buffers are controlled by a common signal (\overline{OC}) which places the outputs at a high-impedance state when it is taken high. The \overline{OC} signal does not affect the internal operations of the latches. Old data can be retained or new data can be entered while outputs are off.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

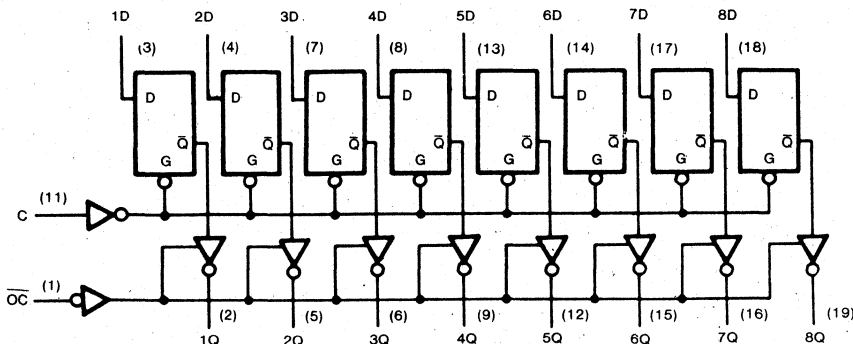


FUNCTION TABLE

(Each Latch)

| Inputs | | | Output |
|-----------------|----------|---|--------|
| \overline{OC} | Enable C | D | Q |
| L | H | H | H |
| L | H | L | L |
| L | L | X | Q_0 |
| H | X | X | Z |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d [†] 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

[†] Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit |
|--------------------------------------|-----------------|--|-------------------------------------|--|---|---------|
| | | | Typ | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ | |
| | | | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -6mA$ | V_{CC} 4.2 $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 12mA$ $I_O = 24mA$ | 0 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT373

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|---|-----------|------------------------------|--------------------------|---|-----|--|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, D to Q | t_{PLH} | $C_L = 50\text{pF}$ | 8 | | 14 | | 17 | ns |
| | | $C_L = 150\text{pF}$ | 11 | | 23 | | 28 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 8 | | 14 | | 17 | ns |
| | | $C_L = 150\text{pF}$ | 11 | | 23 | | 28 | |
| Propagation Delay, C to Q | t_{PLH} | $C_L = 50\text{pF}$ | 14 | | 23 | | 27 | ns |
| | | $C_L = 150\text{pF}$ | 13 | | 32 | | 38 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 14 | | 23 | | 27 | ns |
| | | $C_L = 150\text{pF}$ | 13 | | 32 | | 38 | |
| Output Enable Time, OC to any Q | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | | 20 | | 24 | ns |
| | | | $C_L = 150\text{pF}$ | 12 | | 29 | | |
| | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | | 20 | | 24 | ns |
| | | | $C_L = 150\text{pF}$ | 12 | | 29 | | |
| Output Disable Time, OC to any Q | t_{PHZ} | $R_L = 1\text{k}\Omega$ | | | 18 | | 22 | ns |
| | | | $C_L = 50\text{pF}$ | 13 | | 18 | | |
| Pulse Width, C High | t_w | | 9 | 15 | | 18 | ns | |
| Setup Time, D before C↑ | t_{SU} | | 6 | 10 | | 10 | ns | |
| Hold Time, D after C↓ | t_h | | 3 | 5 | | 7 | ns | |
| Input Capacitance | C_{IN} | | 5 | | | | pF | |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF | |
| Power Dissipation Capacitance* (per latch) | C_{PD} | $\overline{OC} = V_{CC}$ | 5 | | | | pF | |
| | | $\overline{OC} = \text{GND}$ | 30 | | | | pF | |

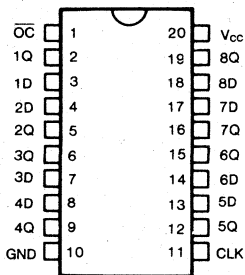
* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

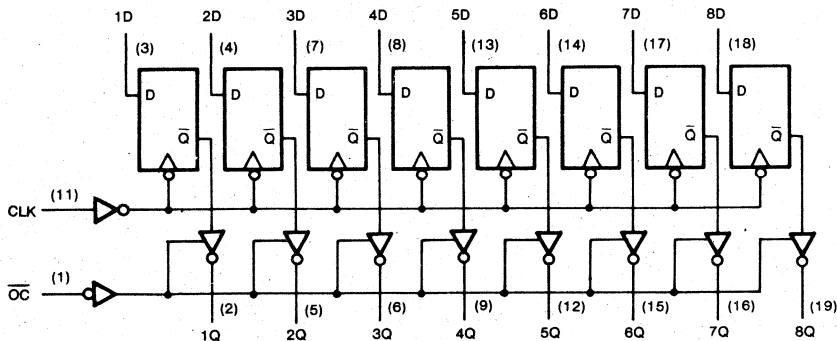
FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



LOGIC DIAGRAM



DESCRIPTION

The '374 consists of 8 high-speed D-type edge-triggered flip-flops coupled to 3-state output buffers with high drive current capability. It can be used in implementing buffer registers, I/O ports, bidirectional bus driver and working registers.

The flip-flops are edge-triggered on the positive transition of the clock. The Q outputs are set to the logic levels that were set up at the D inputs.

The output buffers are controlled by a common signal (\overline{OC}) which places the outputs at a high-impedance state when it is taken high. The OC signal does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while outputs are off.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLE

(Each Flip-Flop)

| Inputs | | Output | |
|-----------------|------------|--------|-------|
| \overline{OC} | CLK | D | Q |
| L | \uparrow | H | H |
| L | \uparrow | L | L |
| L | L | X | Q_0 |
| H | X | X | Z |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
Continuous Current Through
 V_{CC} or GND pins ± 250 mA
Storage Temperature Range, T_{stg} -65°C to +150°C
Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
Operating Temperature

Range KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C

Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|---|--------------------------|---|--|-----------------------|-------------------|
| | | | Typ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Guaranteed Limits |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $= V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4\text{V}$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT374

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|--|-----------|--|--|--|----------|---|----------|------|
| | | | Typ | Min | Max | Min | Max | |
| Maximum Operating Frequency | f_{max} | $C_L = 50\text{pF}$ | 50 | 35 | | 30 | | MHz |
| Propagation Delay, CLK to any Q | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 8 11 | | 14 23 | | 17 28 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 8 11 | | 14 23 | | 17 28 | |
| Output Enable Time, \overline{OC} to any Q | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 11 17 | | 18 27 | 22 31 | ns |
| | t_{PZL} | | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 11 17 | | 18 27 | 22 31 | |
| Output Disable Time, \overline{OC} to any Q | t_{PHZ} | $R_L = 1\text{k}\Omega$ $C_L = 50\text{pF}$ | | 13 | | 18 | 22 | ns |
| | t_{PLZ} | | | 13 | | 18 | 22 | |
| Pulse Width, CLK High or Low | t_w | | 7 | 15 | | 18 | | ns |
| Setup Time, D before CLK† | t_{su} | | 9 | 14 | | 13 | | ns |
| Hold Time, D after CLK† | t_h | | -3 | 0 | | 0 | | ns |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | | pF |
| Power Dissipation Capacitance* | | $\overline{OC} = V_{CC}$ | 5 | | | | | |
| | | $\overline{OC} = \text{GND}$ (per stage) | 30 | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

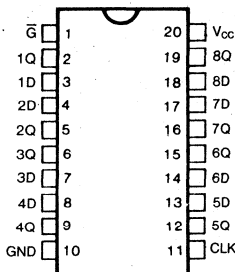
4

Preliminary Specifications

FEATURES

- Can be used for implementing
 - Buffer/Storage Registers
 - Shift Registers
 - Pattern Generators
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



DESCRIPTION

The '377 contains eight positive-edge-triggered D-type flip-flops with an enable input. This part is similar to '273 but features a latched clock enable (\bar{G}) instead of a common clear.

Information at the D inputs meeting the setup time requirements is transferred to the Q outputs on the positive-going edge of the clock pulse if \bar{G} is low. Clock triggering occurs at a particular voltage level and is not directly related to the transition time of the positive-going pulse. When the clock input is at either the high or low level, the D input signal has no effect at the output. The circuits are designed to prevent false clocking by transitions at the \bar{G} input.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

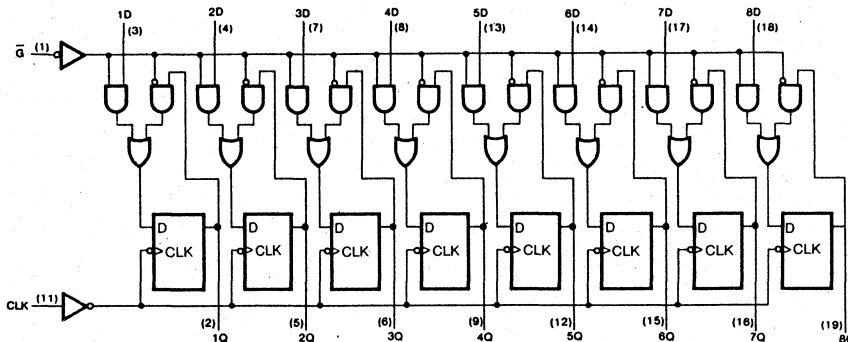
All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLE

(EACH FLIP-FLOP)

| INPUTS | | | OUTPUT |
|-----------|-----|------|--------|
| \bar{G} | CLK | DATA | Q |
| H | X | X | Q_0 |
| L | ↑ | H | H |
| L | ↑ | L | L |
| X | L | X | Q_0 |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
Continuous Current Through
 V_{CC} or GND pins ± 125 mA
Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
Power Dissipation Per Package, P_D^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN}, V_{OUT} . . . 0V to V_{CC}
Operating Temperature
Range KS74AHCT: $-40^\circ C$ to $+85^\circ C$
KS54AHCT: $-55^\circ C$ to $+125^\circ C$
Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|------------------------|--------------------------------------|---------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ C$ to $+85^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN} = V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN} = V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN} = V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN} = V_{CC}$ or GND $I_{OUT} = 0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT} = 0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT377

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|------------------------------------|-----------------------|---------------------|--------------------------|--|-----|---|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Clock Frequency | f_{max} | | 50 | 35 | | 30 | | MHz |
| Propagation Delay, CLK to any Q | t_{PLH} | $C_L = 50\text{pF}$ | 10 | | 16 | | 19 | ns |
| | t_{PHL} | | 10 | | 16 | | 19 | |
| Pulse Width | \bar{G} Low | t_w | 8 | 14 | | 17 | | ns |
| | CLK High or Low | | 8 | 14 | | 17 | | |
| Setup time before CLK† | Data | t_{su} | 6 | 10 | | 10 | | ns |
| | \bar{G} High or Low | | 9 | 15 | | 15 | | |
| Hold Time, Data after CLK† | t_h | | -3 | 0 | | 0 | | ns |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | per package | 50 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

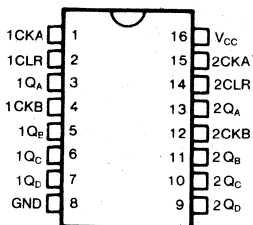
† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Individual clock for A and B flip-flops provide dual +2 and +5 counters
- Direct clear for each 4-bit counter
- Significant improvement in system density through reduced counter package count.
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
($I_{OL} = 8 \text{ mA}$ @ $V_{OL} = 0.5V$)
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



FUNCTION TABLES

**BCD COUNT SEQUENCE
(EACH COUNTER)**
(See Note A)

| COUNT | OUTPUT | | | |
|-------|----------------|----------------|----------------|----------------|
| | Q _D | Q _C | Q _B | Q _A |
| 0 | L | L | L | L |
| 1 | L | L | L | H |
| 2 | L | L | H | L |
| 3 | L | L | H | H |
| 4 | L | H | L | L |
| 5 | L | H | L | H |
| 6 | L | H | H | L |
| 7 | L | H | H | H |
| 8 | H | L | L | L |
| 9 | H | L | L | H |

**BIQUINARY (5-2)
(EACH COUNTER)**
(See Note B)

| COUNT | OUTPUT | | | |
|-------|----------------|----------------|----------------|----------------|
| | Q _D | Q _C | Q _B | Q _A |
| 0 | L | L | L | L |
| 1 | L | L | L | H |
| 2 | L | L | H | L |
| 3 | L | L | H | H |
| 4 | L | H | L | L |
| 5 | H | L | L | L |
| 6 | H | L | L | H |
| 7 | H | L | H | L |
| 8 | H | L | H | H |
| 9 | H | H | L | L |

- NOTES A. Output Q_A is connected to input CKB for BCD count.
B. Output Q_D is connected to input CKA for biquinary count.

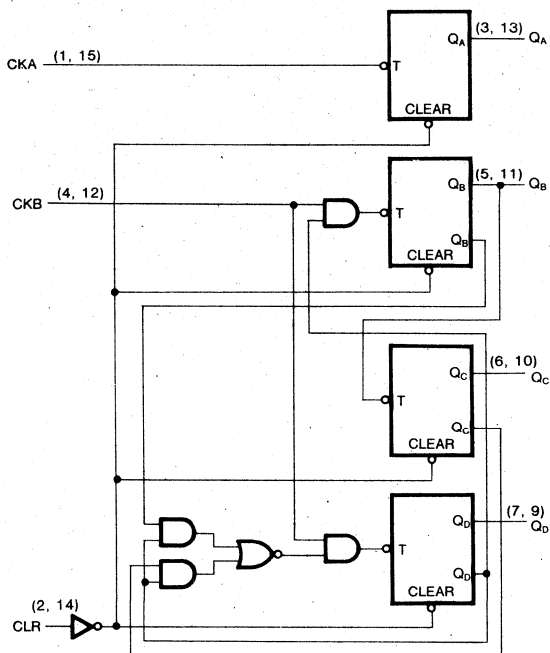
DESCRIPTION

These devices incorporate dual divide-by-two and divide-five counters, which can be used to implement cycle lengths equal to any whole and/or cumulative multiple of 2 and/or 5 up to divide-by-100. When connected as a bi-quinary counter, the separate divide-by-two circuit can be used to provide symmetry (a square wave) at the final output stage. The '390 incorporates dual divide-by-two and divide-by-five counters, which can be used to implement cycle lengths equal to any whole and/or cumulative multiples of 2 and/or 5 up to divide-by-100. When connected as a bi-quinary counter, the separate divide-by-two circuit can be used to provide symmetry (a square wave) at the final output stage. The '390 has parallel outputs from each counter stage so that any submultiple of the input count frequency is available for system-timing signals.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d [†] 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

[†] Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} . . . 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to $+85^\circ\text{C}$
 KS54AHCT: -55°C to $+125^\circ\text{C}$

Input Rise & Fall Times, t_r , t_f Max 500 ns
 * Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS (V_{CC}=5V±10% Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | T _a = 25°C | | KS74AHCT T _a = -40°C to +85°C | | KS54AHCT T _a = -55°C to +125°C | | Unit |
|--------------------------------------|------------------|---|------------------------|------------------------------|---|-----------------------------|--|-------------------|------|
| | | | Typ | Guaranteed Limits | Typ | Guaranteed Limits | Typ | Guaranteed Limits | |
| Minimum High-Level Input Voltage | V _{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V _{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V _{OH} | V _{IN} =V _{IH} or V _{IL} I _O =-20μA I _O =-4mA | V _{CC} 4.2 | V _{CC} -0.1 3.98 | V _{CC} -0.1 3.84 | V _{CC} -0.1 3.7 | V _{CC} -0.1 3.7 | V | |
| Maximum Low-Level Output Voltage | V _{OL} | V _{IN} =V _{IH} or V _{IL} I _O =20μA I _O =4mA I _O =8mA | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | 0.1 0.4 | V | |
| Maximum Input Current | I _{IN} | V _{IN} =V _{CC} or GND | | ±0.1 | ±1.0 | ±1.0 | ±1.0 | μA | |
| Maximum Quiescent Supply Current | I _{CC} | V _{IN} =V _{CC} or GND I _{OUT} =0μA | | 8.0 | 80.0 | 160.0 | 160.0 | μA | |
| Additional Worst Case Supply Current | ΔI _{CC} | per input pin V _I =2.4V other Inputs: at V _{CC} or GND I _{OUT} =0μA | | 2.7 | 2.9 | 3.0 | 3.0 | mA | |

4

AC ELECTRICAL CHARACTERISTICS (Input t_r, t_f ≤ 2 ns, AHCT390)

| Characteristic | Symbol | Conditions† | T _a = 25°C | | KS74AHCT T _a = -40°C to +85°C | | KS54AHCT T _a = -55°C to +125°C | | Unit |
|---|---|-----------------------|------------------------|-----|---|-----|--|-----|------|
| | | | V _{CC} = 5.0V | | V _{CC} = 5.0V ± 10% | | V _{CC} = 5.0V ± 10% | | |
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay, CKA to Q _A or CKB to Q _B | t _{max} | C _L = 50pF | 50 | 30 | | 25 | | MHz | |
| Propagation Delay, CKA to Q _A | t _{PLH} | | 9 | | 15 | | 18 | | ns |
| | t _{PHL} | | 9 | | 15 | | 18 | | ns |
| Propagation Delay, CKA to Q _C | t _{PLH} | | 24 | | 40 | | 48 | | ns |
| | t _{PHL} | | 24 | | 40 | | 48 | | ns |
| Propagation Delay, CKB to Q _B | t _{PLH} | | 10 | | 17 | | 21 | | ns |
| | t _{PHL} | | 10 | | 17 | | 21 | | ns |
| Propagation Delay, CKB to Q _C | t _{PLH} | | 16 | | 27 | | 33 | | ns |
| | t _{PHL} | | 16 | | 27 | | 33 | | ns |
| Propagation Delay, CKB to Q _D | t _{PLH} | | 10 | | 17 | | 21 | | ns |
| | t _{PHL} | | 10 | | 17 | | 21 | | ns |
| Propagation Delay, CLR to Any Q | t _{PHL} | | 14 | | 24 | | 29 | | ns |
| Pulse Width | C _{KA} or C _{KB} High or Low CLR High | | t _w | 7 | 12 | | 15 | | ns |
| | | | t _w | 7 | 12 | | 15 | | ns |
| Minimum Setup Time, CLR inactive before CKA or CKB | t _{SU} | 5 | 8 | | 10 | | ns | | |
| Input Capacitance | C _{IN} | 5 | | | | | pF | | |
| Power Dissipation Capacitance | C _{PD} | | | | | | pF | | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5 \text{ V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

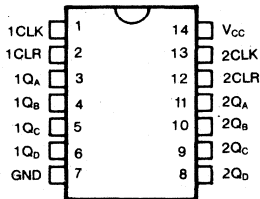
DESCRIPTION

The '393 consists of two independent 4-bit binary counters each with its own clear and clock inputs. N-bit binary counters can be implemented with each package providing the capability of divide-by-256. parallel outputs from each counter stage provided any submultiple of the input count frequency for system timing signals.

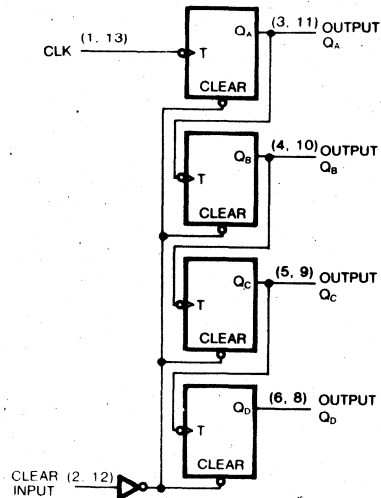
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

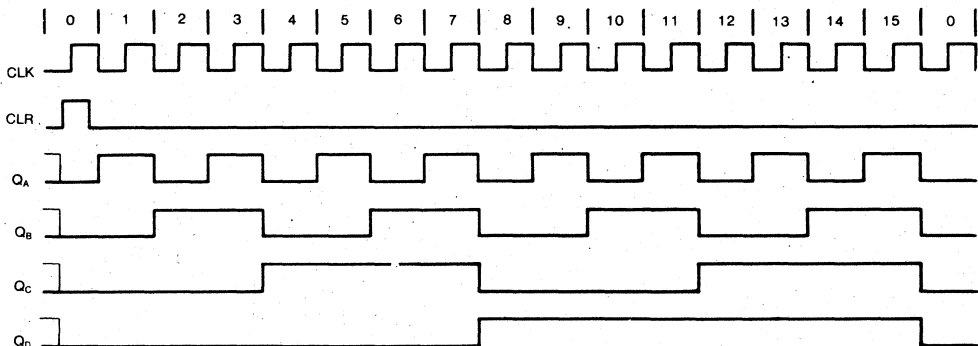
PIN CONFIGURATION



LOGIC DIAGRAM



LOGIC TIMING WAVEFORMS



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} ... -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------|----------------------|----------------------|--------------------------------------|---------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ C$ to $+85^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-4mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT393

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|--------------------------------------|---------------------|---------------------|--------------------------|--|-----|---|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 50 | 30 | | 25 | | MHz |
| Propagation Delay, A to Q_A | t_{PLH} | | 14 | | 22 | | 26 | ns |
| | t_{PHL} | | 14 | | 22 | | 26 | ns |
| Propagation Delay, A to Q_B | t_{PLH} | | 18 | | 27 | | 32 | ns |
| | t_{PHL} | | 18 | | 27 | | 32 | ns |
| Propagation Delay, A to Q_C | t_{PLH} | | 20 | | 33 | | 40 | ns |
| | t_{PHL} | | 20 | | 33 | | 40 | ns |
| Propagation Delay, A to Q_D | t_{PLH} | | 26 | | 40 | | 48 | ns |
| | t_{PHL} | | 26 | | 40 | | 48 | ns |
| Propagation Delay, CLR to any Q | t_{PHL} | | 15 | | 25 | | 30 | ns |
| Pulse Width | A Input High or Low | t_w | 7 | 12 | | 15 | | ns |
| | CLR High | | 7 | 12 | | 15 | | ns |
| Setup Time, CLR Inactive before A | t_{su} | | 5 | 8 | | 10 | ns | |
| Input Capacitance | C_{IN} | | 5 | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | (per counter) | 40 | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Objective Specifications

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74ALS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

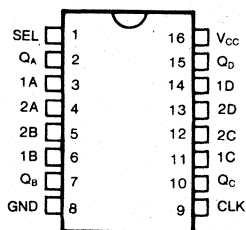
DESCRIPTION

These are high-speed quad 2-port registers. They are the logical equivalent of a quad 2-input multiplexer followed by a quad 4-bit edge-triggered register. A common select input (SEL) selects between two 4-bit input ports. The selected data is transferred to the output register on the low-to-high transition of the clock input.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



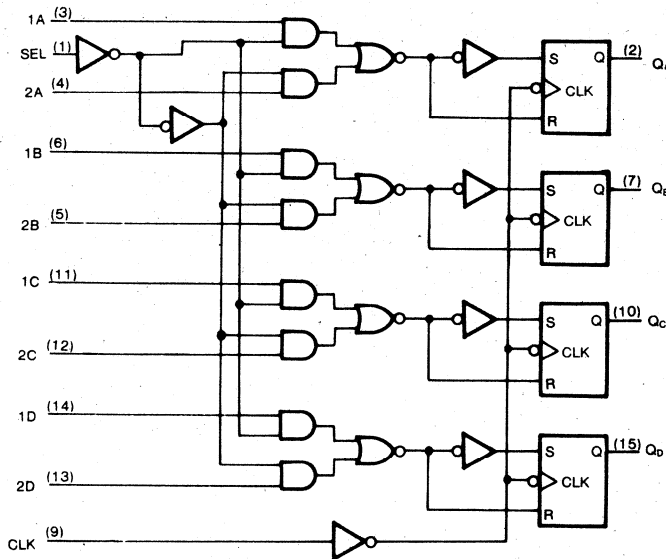
FUNCTION TABLE

| Inputs | | | Output |
|--------|--------|--------|--------|
| SEL | Port 1 | Port 2 | Q |
| l | l | X | L |
| l | h | X | H |
| h | X | l | L |
| h | X | h | H |

- l = Low Voltage Level one setup time prior to the low-to-high clock transition
- h = High Voltage Level one setup time prior to the low-to-high clock transition

4

LOGIC DIAGRAM



Absolute Maximum Ratings*

| | |
|--|-----------------|
| Supply Voltage Range V_{CC} , | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

| | |
|----------------------|------------------------------|
| Plastic Package (N): | -12mW/°C from 65°C to 85°C |
| Ceramic Package (J): | -12mW/°C from 100°C to 125°C |

Recommended Operating Conditions

| | |
|--|---------------------------|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74AHCT: -40°C to +85°C |
| | KS54AHCT: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|---|--------------------------|------------------------|---|-----------------------|--|-----------------------|---------------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | $V_{CC} - 0.1$ 3.7 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | 0.1 0.4 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | 160.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4\text{V}$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | 3.0 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT399

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------|-------------|---------------------|--------------------------|---|-----|--|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $V_{CC} = 5.0\text{V} \pm 10\%$ | | $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, CLK to Q | t_{PLH} | $C_L = 50\text{pF}$ | 12 | | 19 | | 23 | ns |
| | t_{PHL} | | 12 | | 19 | | 23 | |
| Pulse Width, CLK High or Low | t_w | | 6 | 10 | | 15 | | ns |
| Time before CLK† | Data | t_{su} | 6 | 10 | | 15 | | ns |
| | Word Select | | 6 | 10 | | 15 | | |
| Hold Time, Data after CLK† | t_h | | -3 | 0 | | 0 | | ns |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

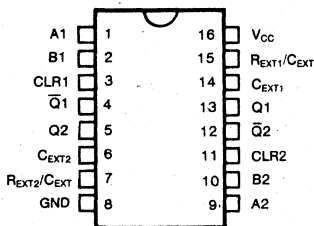
† For AC switching test circuits and timing waveforms see section 2.

Product Preview

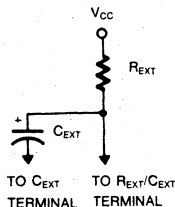
FEATURES

- Simple pulse width formula $T = RC$
- Wide pulse range: 400 ns to ∞ (typ)
- Part to part variation: $\pm 5\%$ (typ)
- Schmitt Trigger A & B Inputs allow infinite rise and fall times on these inputs
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^\circ\text{C}$
KS54AHCT: -55°C to $+125^\circ\text{C}$

PIN CONFIGURATION



TIMING COMPONENT



DESCRIPTION

The '423 contains two retriggerable monostable multivibrators that feature both a negative,(A) and a positive (B) transition triggered input, either or which can be used as an inhibit input. Also included is a clear input that when taken low resets the one shot. The '423 cannot be triggered from clear.

The '423A is retriggerable. That is it may be triggered repeatedly while its outputs are generating a pulse and the pulse will be extended.

Pulse width stability over a wide range of temperature and supply is achieved using linear CMOS techniques. The output pulse equation is simply: $PW = (R_{EXT}) (C_{EXT})$; where PW is in seconds, R is in ohms, and C is in farads.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLE

| CLR | Inputs | | Outputs | |
|-----|--------|---|---------|-----------|
| | A | B | Q | \bar{Q} |
| L | X | X | L | H |
| X | H | X | L | H |
| X | X | L | L | H |
| H | L | ↑ | | |
| H | ↓ | H | | |

KS54AHCT **465/466** KS74AHCT **467/468**

Octal Buffers and Line Drivers with 3-State Outputs

Preliminary Specifications

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

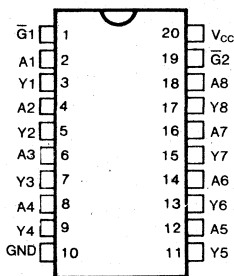
These high-speed octal buffers and drivers are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. The designer has the choice of inverting/noninverting outputs and various types of output controls.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

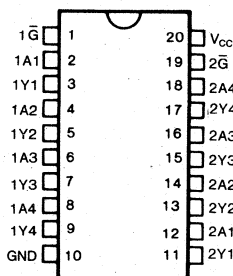
All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATIONS

'465 and '466

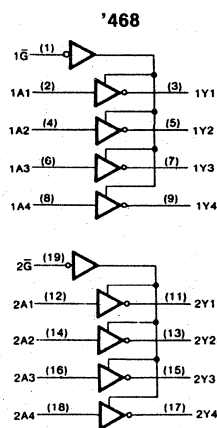
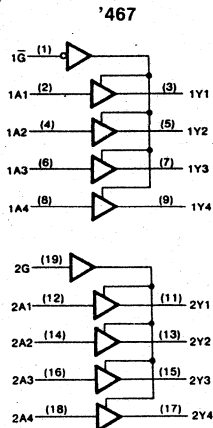
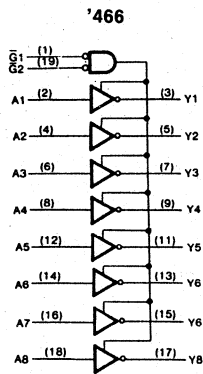
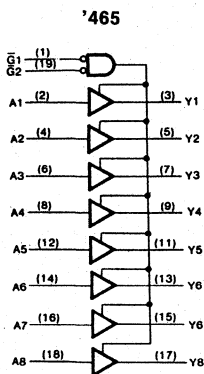


'467 and '468



4

LOGIC DIAGRAMS



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability

† Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: $-40^\circ C$ to $+85^\circ C$
 KS54AHCT: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|------------------------|-----------------------|---------|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -6mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 12mA$ $I_O = 24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT465, AHCT466,
 AHCT467, AHCT468

| Parameter | Symbol | Conditions | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | KS74AHCT $T_a = -40^\circ\text{C to } -85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | 54AHCT $T_a = -55^\circ\text{C to } -125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit | |
|---|-----------|-------------------------|--|--|-----|---|-----|------|----|
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay, A to Y | t_{PLH} | $C_L = 50\text{pF}$ | 7 | | 12 | | 14 | ns | |
| | | $C_L = 150\text{pF}$ | 10 | | 21 | | 25 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 7 | | 12 | | 14 | ns | |
| | | $C_L = 150\text{pF}$ | 10 | | 21 | | 25 | | |
| Output Enable Time, Enable to Y | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 12 | | 20 | | 24 | ns |
| | | | $C_L = 150\text{pF}$ | 18 | | 29 | | 37 | |
| | t_{PZL} | $C_L = 50\text{pF}$ | | 12 | | 20 | | 24 | |
| | | | $C_L = 150\text{pF}$ | 18 | | 29 | | 35 | |
| Output Disable Time, Enable to Y | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 13 | | 18 | | 22 | ns | |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 13 | | 18 | | 22 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C_{PD} | Output Disabled | 5 | | | | | pF | |
| | | Output Enabled | 30 | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Compares two 8-bit words
- '518, '520 and '522 have 20kΩ pull-up Resistors on Q Inputs

| TYPE | INPUT PULL-UP RESISTOR | OUTPUT FUNCTION AND CONFIGURATION |
|------|------------------------|--|
| '518 | Yes | P=Q Open-Drain |
| '519 | No | P=Q Open-Drain |
| '520 | Yes | $\overline{P}=\overline{Q}$ Totem-Pole |
| '521 | No | $\overline{P}=\overline{Q}$ Totem-Pole |
| '522 | Yes | $\overline{P}=\overline{Q}$ Open-Drain |

† '521 is identical to '688

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current (I_{OL} = 24 mA @ V_{OL} = 0.5V) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C

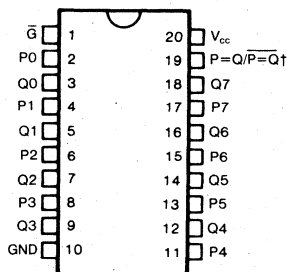
DESCRIPTION

These identity comparators perform comparisons on two eight-bit binary or BCD words. The '518 and '519 provide P=Q outputs, while the '520, '521, and '522 provide $\overline{P}=\overline{Q}$ outputs. The '518, '519, and '522 have open-drain outputs. The '518, '520, and '522 feature 20-kΩ inputs for analog or switch data.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

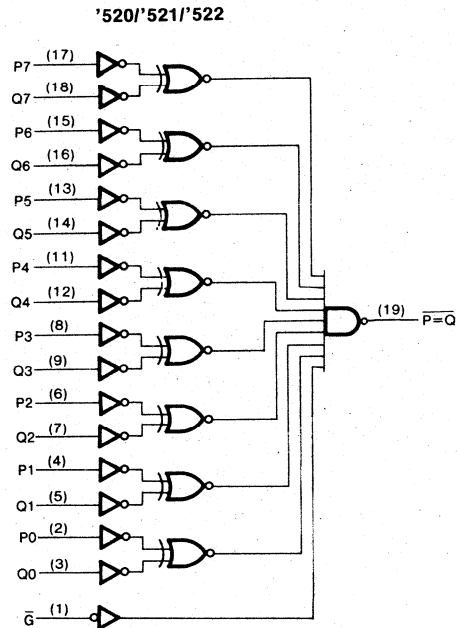
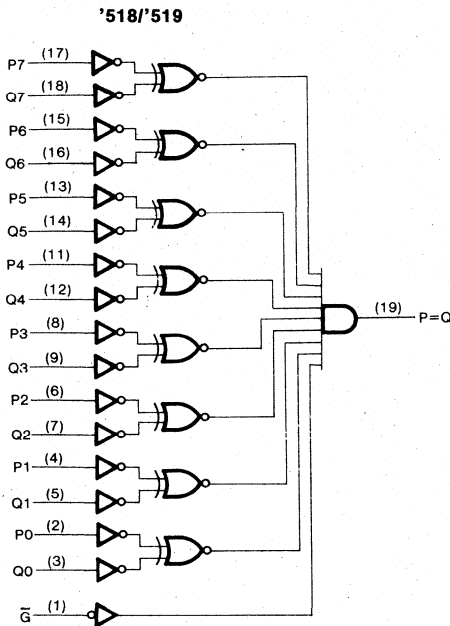


† P=Q for '518 and '519;
 $\overline{P}=\overline{Q}$ for '520, '521, '522.

FUNCTION TABLE

| INPUTS | | OUTPUTS | |
|-----------|-----------------------|---------|-----------------------------|
| DATA P, Q | ENABLE \overline{G} | P=Q | $\overline{P}=\overline{Q}$ |
| P=Q | L | H | L |
| P>Q | L | L | H |
| P<Q | L | L | H |
| X | H | L | H |

LOGIC DIAGRAMS



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} . . . 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)



DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Parameter | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | 54AHCT | Unit |
|--|-----------------|--|--------------------------|----------------------|---|--|---------------|
| | | | Typ | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | |
| Guaranteed Limits | | | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage (Totem-pole Outputs) | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.93 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage (All Outputs) | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current, ('518, '520 and '522 Q input) | | $V_{CC}=\text{Max}$ $V_{IN}=2.7\text{V}$ $V_{IN}=0.4\text{V}$ | | -0.2 -0.4 | -0.2 -0.4 | -0.2 -0.4 | mA |
| Maximum Input Current (All other Inputs) | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Output Leakage Current (Open-Drain Outputs) | I_{OZ} | $V_{IN}=V_{IH}$ or V_{IL} $V_{OUT}=V_{CC}$ | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | For '518, '520 and '522: $V_{IN}=\text{GND (Q0-Q7)}$ $V_{IN}=V_{CC}$ or GND (all other inputs) | | 3.5 | 3.5 | 3.5 | mA |
| | | For '519 and '521: $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4\text{V}$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT518, AHCT519

| Characteristic | Symbol | Conditions | 54/74AHT | KS74AHT | | 54AHT | | Unit |
|--|-----------|---|--------------------------|---|----------|--|----------|------|
| | | | $T_A = 25^\circ\text{C}$ | $T_A = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_A = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| | | | $V_{CC} = 5\text{V}$ | $V_{CC} = 5\text{V} \pm 10\%$ | | $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typical | Min | Max | Min | Max | |
| Propagation Delay, P or Q to $\overline{P=Q}$ | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 20 30 | | 30 40 | | 35 45 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 15 18 | | 25 34 | | 30 41 | |
| Propagation Delay, \overline{G} to $\overline{P=Q}$ | t_{PLH} | $C = 50\text{pF}$ $C_L = 150\text{pF}$ | 16 26 | | 23 33 | | 27 37 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 11 14 | | 18 27 | | 22 33 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT520, AHCT521

| Characteristic | Symbol | Conditions | 54/74AHT | KS74AHT | | 54AHT | | Unit |
|--|-----------|---|--------------------------|---|----------|--|----------|------|
| | | | $T_A = 25^\circ\text{C}$ | $T_A = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_A = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| | | | $V_{CC} = 5\text{V}$ | $V_{CC} = 5\text{V} \pm 10\%$ | | $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typical | Min | Max | Min | Max | |
| Propagation Delay, P or Q to $\overline{P=Q}$ | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 12 15 | | 19 28 | | 23 34 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 12 15 | | 19 28 | | 23 34 | |
| Propagation Delay, \overline{G} to $\overline{P=Q}$ | t_{PLH} | $C = 50\text{pF}$ $C_L = 150\text{pF}$ | 11 14 | | 17 26 | | 20 31 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 11 14 | | 17 26 | | 20 31 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHC522

| Characteristic | Symbol | Conditions | 54/74AHT | KS74AHT | | 54AHT | | Unit |
|--|-----------|---|--------------------------|---|----------|--|----------|------|
| | | | $T_A = 25^\circ\text{C}$ | $T_A = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_A = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| | | | $V_{CC} = 5\text{V}$ | $V_{CC} = 5\text{V} \pm 10\%$ | | $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typical | Min | Max | Min | Max | |
| Propagation Delay, P or Q to $\overline{P=Q}$ | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 19 29 | | 28 38 | | 33 43 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 14 17 | | 23 32 | | 28 39 | |
| Propagation Delay, \overline{G} to $\overline{P=Q}$ | t_{PLH} | $C = 50\text{pF}$ $C_L = 150\text{pF}$ | 16 26 | | 23 33 | | 27 37 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 11 14 | | 18 27 | | 22 33 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF |

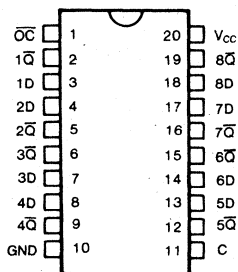
* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

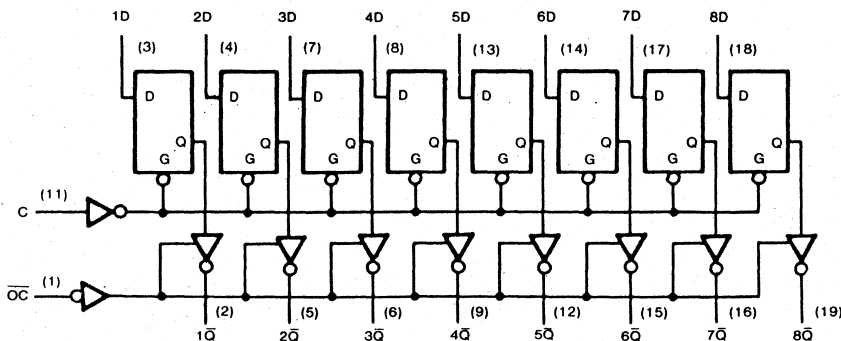
FEATURES

- 8 latches in a single package
- Full parallel access for loading
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



LOGIC DIAGRAM



DESCRIPTION

The '533 consists of 8 high-speed D-type latches coupled to 3-state output buffers with high drive current capability. It can be used in implementing buffer registers, I/O ports, bidirectional bus drivers and working registers.

The latches are transparent: when the enable (C) is high, the \bar{Q} outputs follow the complements of the data (D) inputs. When the enable is low, the outputs latch at the levels that were set up at the D inputs.

The output buffers are controlled by a common signal (\overline{OC}) which places the outputs at high-impedance state when it is taken high. The \overline{OC} signal does not affect the internal operations of the latches. Old data can be retained or new data can be entered while outputs are off.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLE

| (Each Latch) | | | |
|-----------------|----------|---|-------------|
| Inputs | | | Output |
| \overline{OC} | Enable C | D | \bar{Q} |
| L | H | H | L |
| L | H | L | H |
| L | L | X | \bar{Q}_0 |
| H | X | X | Z |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range
 KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|--|---|-----------------------|---------|
| | | | Typ | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| Guaranteed Limits | | | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -6mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 12mA$ $I_O = 24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns, AHCT533)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit | |
|---|-----------|-------------------------|--|--|-----|---|-----|------|----|
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay, D to \bar{Q} | t_{PLH} | $C_L = 50\text{pF}$ | 10 | | 16 | | 19 | ns | |
| | | $C_L = 150\text{pF}$ | 13 | | 25 | | 30 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 10 | | 16 | | 19 | ns | |
| | | $C_L = 150\text{pF}$ | 13 | | 25 | | 30 | | |
| Propagation Delay, C to \bar{Q} | t_{PLH} | $C = 50\text{pF}$ | 13 | | 21 | | 25 | ns | |
| | | $C_L = 150\text{pF}$ | 16 | | 30 | | 36 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 13 | | 21 | | 25 | ns | |
| | | $C_L = 150\text{pF}$ | 16 | | 30 | | 36 | | |
| Output Enable Time, \bar{OC} to any \bar{Q} | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 11 | | 18 | | 22 | ns |
| | | | $C_L = 150\text{pF}$ | 17 | | 27 | | 33 | |
| | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 11 | | 18 | | 22 | ns |
| | | | $C_L = 150\text{pF}$ | 17 | | 27 | | 33 | |
| Output Disable Time, \bar{OC} to any \bar{Q} | t_{PHZ} | $R_L = 1\text{k}\Omega$ | | 13 | | 18 | | 22 | ns |
| | | | $C_L = 50\text{pF}$ | 13 | | 18 | | 22 | |
| Pulse Width, C High | t_w | | 9 | 15 | | 18 | | ns | |
| Setup Time, D before $C\downarrow$ | t_{su} | | 9 | 15 | | 18 | | ns | |
| Hold Time, D after $C\downarrow$ | t_h | | 3 | 5 | | 7 | | ns | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Output Capacitance | C_{out} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C_{PD} | $\bar{OC} = V_{CC}$ | 5 | | | | | pF | |
| | | $\bar{OC} = \text{GND}$ | 30 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

The '534 consists of 8 high-speed D-type edge-triggered flip-flops coupled to 3-state output buffers with high drive current capability. It can be used in implementing buffer registers, I/O ports, bidirectional bus driver and working registers.

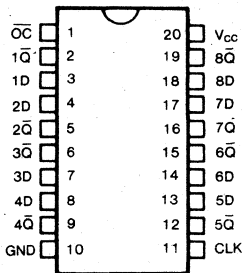
The flip-flops are edge-triggered on the positive transition of the clock; the \bar{Q} outputs are set to the complement of the logic levels that were set up at the D inputs.

The output buffers are controlled by a common signal (\overline{OC}) which places the outputs in high-impedance state when it is taken high, the OC signal does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while outputs are off.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

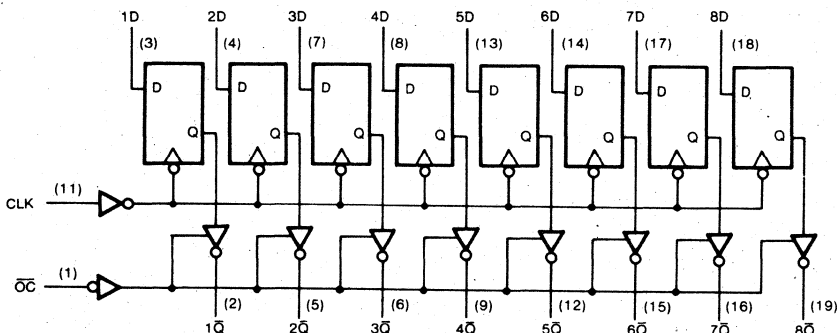


FUNCTION TABLE

(Each Latch)

| Inputs | | Output | |
|-----------------|-----|--------|-------------|
| \overline{OC} | CLK | D | \bar{Q} |
| L | ↑ | H | L |
| L | ↑ | L | H |
| L | L | X | \bar{Q}_0 |
| H | X | X | Z |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
Continuous Current Through
 V_{CC} or GND pins ± 250 mA
Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN} , V_{OUT} . . . 0V to V_{CC}
Operating Temperature
Range KS74AHCT: $-40^\circ C$ to $+85^\circ C$
KS54AHCT: $-55^\circ C$ to $+125^\circ C$
Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|--------------------------------------|---------------------------------------|---------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -6mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 12mA$ $I_O = 24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT534

| Characteristic | Symbol | Conditions† | T _a = 25°C | KS74AHCT | | KS54AHCT | | Unit | |
|--|------------------|------------------------|------------------------|---------------------------------|-----|----------------------------------|----|------|----|
| | | | V _{CC} = 5.0V | T _a = -40°C to +85°C | | T _a = -55°C to +125°C | | | |
| | | | Typ | V _{CC} = 5.0V ± 10% | | V _{CC} = 5.0V ± 10% | | | |
| | | | Min | Max | Min | Max | | | |
| Maximum Operating Frequency | f _{max} | C _L = 50pF | 50 | 35 | | 30 | | MHz | |
| Propagation Delay, CLK to any Q̄ | t _{PLH} | C _L = 50pF | 8 | | 14 | | 17 | ns | |
| | | C _L = 150pF | 11 | | 23 | | 28 | | |
| | t _{PHL} | C _L = 50pF | 8 | | 14 | | 17 | ns | |
| | | C _L = 150pF | 11 | | 23 | | 28 | | |
| Output Enable Time, OC to any Q̄ | t _{pZH} | R _L = 1kΩ | C _L = 50pF | 11 | | 18 | | 22 | ns |
| | | | C _L = 150pF | 14 | | 27 | | 31 | |
| | t _{pZL} | C _L = 50pF | C _L = 50pF | 11 | | 18 | | 22 | |
| | | | C _L = 150pF | 14 | | 27 | | 31 | |
| Output Disable Time, OC to any Q | t _{pHZ} | R _L = 1kΩ | 13 | | 18 | | 22 | ns | |
| | t _{pLZ} | C _L = 50pF | 13 | | 18 | | 22 | | |
| Pulse Width, CLK High or Low | t _w | | 9 | 15 | | 18 | | ns | |
| Setup Time, D before CLK† | t _{su} | | 9 | 14 | | 17 | | ns | |
| Hold Time, D after CLK† | t _h | | -3 | 0 | | 0 | | ns | |
| Input Capacitance | C _{IN} | | 5 | | | | | pF | |
| Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C _{PD} | OC = V _{CC} | 5 | | | | | pF | |
| | | OC = GND | 30 | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

4

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

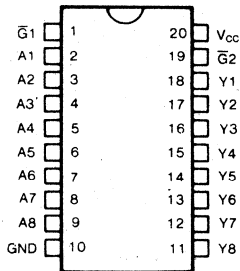
The '540 and '541 are general purpose high-speed octal line drivers/buffers with 3-state outputs. The inputs and outputs are located on opposite sides of the 20-pin package, thus improving circuit board density. The '540 provides inverted data and the '541 provides true data at the outputs.

The three-state control gate is a 2-input NOR such that if either $\bar{G}1$ or $\bar{G}2$ is high, all eight outputs are in the high impedance state.

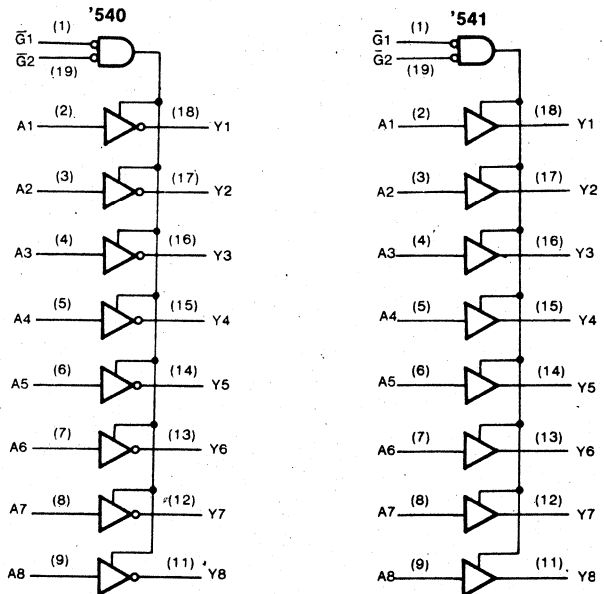
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAMS



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d^1 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

¹ Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: $-40^\circ C$ to $+85^\circ C$
 KS54AHCT: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74AHCT | KS54AHCT | Unit |
|-----------------------------------|----------|--|--------------------|------------------------|------------------------|--------------------------------------|---------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ C$ to $+85^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN} = V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -6mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN} = V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 12mA$ $I_O = 24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN} = V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $= V_{IH}$ $V_{OUT} = V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN} = V_{CC}$ or GND $I_{OUT} = 0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT540, AHCT541

| Characteristic | Symbol | Conditions† | T _a = 25°C | KS74AHCT | | KS54AHCT | | Unit | |
|---|------------------|-----------------------------|------------------------|---|-----|--|-----|------|----|
| | | | V _{CC} = 5.0V | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | | |
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay, A to Y | t _{PLH} | C _L = 50pF | 7 | | 12 | | 14 | ns | |
| | | C _L = 150pF | 10 | | 21 | | 25 | | |
| | t _{PHL} | C _L = 50pF | 7 | | 12 | | 14 | | |
| | | C _L = 150pF | 10 | | 21 | | 25 | | |
| Output Enable Time, \bar{G} to Y | t _{PZH} | R _L = 1kΩ | C _L = 50pF | 12 | | 20 | | 24 | ns |
| | | | C _L = 150pF | 18 | | 29 | | 35 | |
| | t _{PZL} | C _L = 50pF | 12 | | 20 | | 24 | | |
| | | C _L = 50pF | 18 | | 29 | | 35 | | |
| Output Disable Time \bar{G} to Y | t _{PHZ} | R _L = 1kΩ | 14 | | 19 | | 23 | ns | |
| | t _{PLZ} | C _L = 50pF | 14 | | 19 | | 23 | | |
| Input Capacitance | C _{IN} | | 5 | | | | | pF | |
| Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C _{PD} | \bar{G} = V _{CC} | 5 | | | | | pF | |
| | | \bar{G} = GND | 30 | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- 8 latches in a single package
- Full parallel access for loading
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24mA @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: $-40^{\circ}C$ to $+85^{\circ}C$
 KS54AHCT: $-55^{\circ}C$ to $+125^{\circ}C$

DESCRIPTION

The '563 consists of 8 high-speed D-type latches coupled to 3-state output buffers with high drive current capability. It can be used in implementing buffer register, I/O ports, bidirectional bus drivers and working registers.

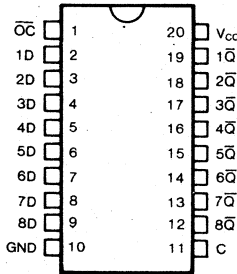
The latches are transparent: when the enable (C) is high, the Q outputs follow complements of the data (D) inputs. When the enable is low, the outputs latch at the levels that were set up at the D inputs.

The output buffers are controlled by a common signal (OC) which places the outputs at a high-impedance stage when it is taken high. The OC signal does not affect the internal operations of the latches. Old data can be retained or new data can be entered while outputs are off.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

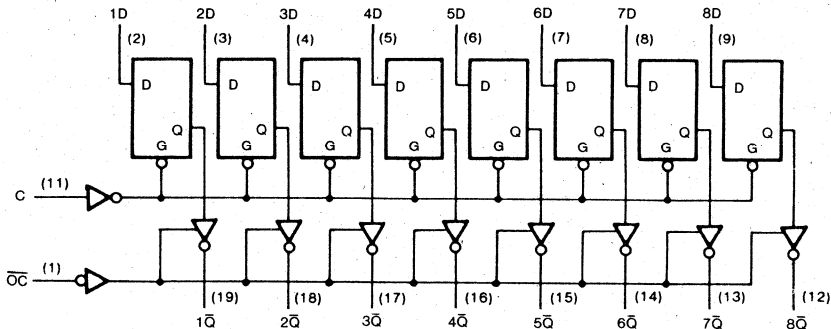


FUNCTION TABLE

(Each Latch)

| Inputs | | Output | |
|-----------------|----------|--------|------------------|
| \overline{OC} | Enable C | D | \overline{Q} |
| L | H | H | L |
| L | H | L | H |
| L | L | X | \overline{Q}_0 |
| H | X | X | Z |

LOGIC DIAGRAM



Absolute Maximum Ratings*

| | |
|---|-----------------|
| Supply Voltage Range V_{CC} , | -0.5V to +7V |
| DC Input Diode Current, I_{IK} ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 70 mA |
| Continuous Current Through V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} , | -65°C to +150°C |
| Power Dissipation Per Package, P_d [†] | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

| |
|---|
| † Power Dissipation temperature derating: |
| Plastic Package (N): -12mW/°C from 65°C to 85°C |
| Ceramic Package (J): -12mW/°C from 100°C to 125°C |

Recommended Operating Conditions

| | |
|---|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} .. | 0V to V_{CC} |
| Operating Temperature Range | KS74AHCT: -40°C to +85°C KS54AHCT: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|---|--|---------------------|-------------------|
| | | | Typ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Guaranteed Limits |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT563

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|---|-----------|--|--------------------------|--|-----|---|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, D to \bar{Q} | t_{PLH} | $C_L = 50\text{pF}$ | 12 | | 18 | | 22 | ns |
| | | $C_L = 150\text{pF}$ | 15 | | 27 | | 33 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 12 | | 18 | | 22 | ns |
| | | $C_L = 150\text{pF}$ | 15 | | 27 | | 33 | |
| Propagation Delay, C to \bar{Q} | t_{PLH} | $C = 50\text{pF}$ | 14 | | 22 | | 27 | ns |
| | | $C_L = 150\text{pF}$ | 17 | | 31 | | 38 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 14 | | 22 | | 27 | ns |
| | | $C_L = 150\text{pF}$ | 17 | | 31 | | 38 | |
| Output Enable Time, \bar{OC} to any \bar{Q} | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | | 18 | | 22 | ns |
| | | | $C_L = 150\text{pF}$ | 11 | | 27 | 33 | |
| | t_{PZL} | $C_L = 50\text{pF}$ | | 11 | | 18 | 22 | |
| | | | $C_L = 150\text{pF}$ | 14 | | 27 | 33 | |
| Output Disable Time, \bar{OC} to any \bar{Q} | t_{PHZ} | $R_L = 1\text{k}\Omega$ $C_L = 50\text{pF}$ | | 13 | | 19 | 22 | ns |
| | t_{PLZ} | | | 13 | | 19 | 22 | |
| Pulse Width, C High | t_w | | 9 | 15 | | 18 | ns | |
| Setup Time, D before $C\downarrow$ | t_{su} | | 6 | 10 | | 10 | ns | |
| Hold Time, D after $C\downarrow$ | t_h | | 3 | 5 | | 7 | ns | |
| Input Capacitance | C_{IN} | | 5 | | | | pF | |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C_{PD} | $\bar{OC} = V_{CC}$ | 5 | | | | | pF |
| | | $\bar{OC} = \text{GND}$ | 30 | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

4

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24mA @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: $-40^{\circ}C + 85^{\circ}C$
KS54AHCT: $-55^{\circ}C + 125^{\circ}C$

DESCRIPTION

The '564 consists of 8 high-speed D-type edge-triggered flip-flops coupled to 3-state output buffers with high drive current capability. It can be used in implementing buffer registers, I/O ports, bidirectional bus driver and working registers.

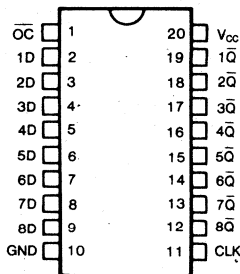
The flip-flops are edge-triggered: on the positive transition of the clock, the \bar{Q} outputs are set to the complement of the logic levels that were set up at the D inputs.

The output buffers are controlled by a common signal (\overline{OC}) which places the outputs at high impedance state when it is taken high. The \overline{OC} signal does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while outputs are off.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

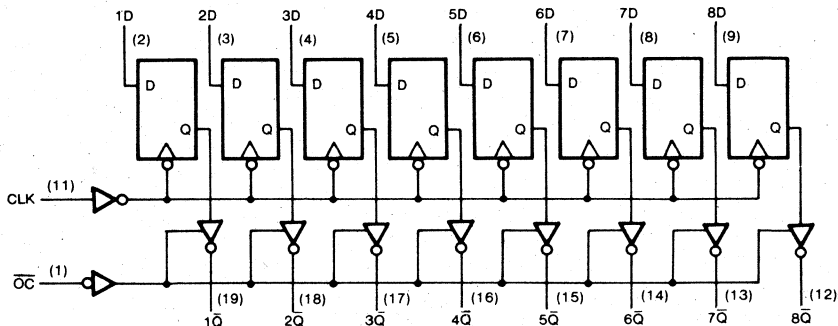


FUNCTION TABLE

(Each Flip-Flop)

| Inputs | | | Output |
|-----------------|-----|---|-------------|
| \overline{OC} | CLK | D | \bar{Q} |
| L | ↑ | H | L |
| L | ↑ | L | H |
| L | L | X | \bar{Q}_0 |
| H | X | X | Z |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
Continuous Current Through
 V_{CC} or GND pins ± 250 mA
Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
Operating Temperature
Range KS74AHCT: -40°C to $+85^\circ\text{C}$
KS54AHCT: -55°C to $+125^\circ\text{C}$
Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|--|---|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT564

| Characteristic | Symbol | Conditions† | T _a = 25°C | KS74AHCT | | KS54AHCT | | Unit |
|---|------------------|---|---|---|----------|--|----------|------|
| | | | V _{CC} = 5.0V | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Operating Frequency | f _{max} | C _L = 50pF | 50 | 35 | | 30 | | MHz |
| Propagation Delay, CLK to any Q | t _{PLH} | C _L = 50pF C _L = 150pF | 8 11 | | 14 23 | | 17 28 | ns |
| | t _{PHL} | C _L = 50pF C _L = 150pF | 8 11 | | 14 23 | | 17 28 | |
| Output Enable Time, OC to any Q | t _{PZH} | R _L = 1kΩ | C _L = 50pF C _L = 150pF | 11 17 | | 18 27 | 22 31 | ns |
| | t _{PZL} | | C _L = 50pF C _L = 150pF | 11 17 | | 18 27 | 22 31 | |
| Output Disable Time, OC to any Q | t _{PHZ} | R _L = 1kΩ | 13 | | 19 | | 22 | ns |
| | t _{PLZ} | C _L = 50pF | 13 | | 19 | | 22 | |
| Pulse Width, CLK High or Low | t _w | | 9 | 15 | | 18 | | ns |
| Setup Time, D before CLK† | t _{su} | | 9 | 14 | | 17 | | ns |
| Hold Time, D after CLK† | t _h | | -3 | 0 | | 0 | | ns |
| Input Capacitance | C _{IN} | | 5 | | | | | pF |
| Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | | pF |
| Power Dissipation Capacitance* (per stage) | C _{PD} | OC = V _{CC} | 5 | | | | | pF |
| | | OC = GND | 30 | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- 8 latches in a single package
- Full parallel access for loading
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -40°C to $+125^{\circ}\text{C}$

DESCRIPTION

The '573 consists of 8 high-speed D-type latches coupled to 3-state output buffers with high drive current capability. It can be used in implementing bufer registers, I/O ports, bidirectional bus drivers and working registers.

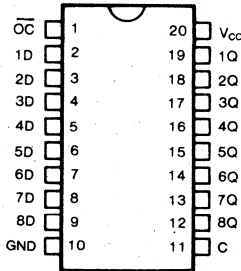
The latches are transparent: when the enable (C) is high, the Q outputs follow the data (D) inputs. When the enable is low, the outputs latch at the levels that were set up at the D inputs.

The output buffers are controlled by a common signal (\overline{OC}) which places the outputs at a high-impedance state when it is taken high. The \overline{OC} signal does not affect the internal operations of the latches. Old data can be retained or new data can be entered while outputs are off.

These devices provide speeds and drive capability equivalent of their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

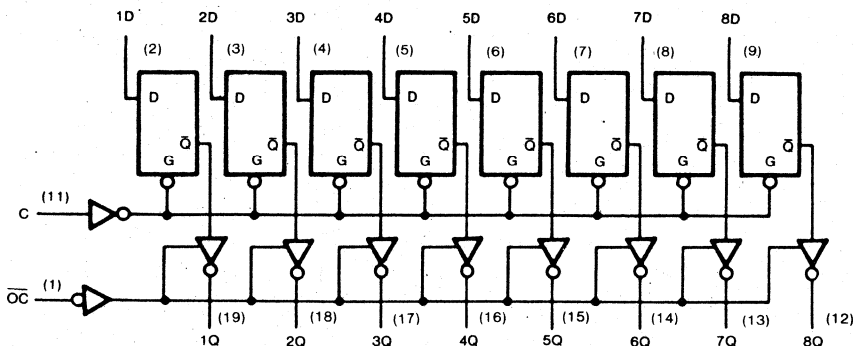


FUNCTION TABLE

(Each Latch)

| Inputs | | | Output |
|-----------------|----------|---|--------|
| \overline{OC} | Enable C | D | Q |
| L | H | H | H |
| L | H | L | L |
| L | L | X | Q_0 |
| H | X | X | Z |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} . . . -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} . . . 0V to V_{CC}
 Operating Temperature

Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C

Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|---|--|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT573

| Characteristic | Symbol | Conditions† | T _a = 25°C | KS74AHCT | | KS54AHCT | | Unit |
|---|------------------|---|------------------------|---------------------------------|----------|----------------------------------|----------|------|
| | | | V _{CC} = 5.0V | T _a = -40°C to +85°C | | T _a = -55°C to +125°C | | |
| | | | Typ | V _{CC} = 5.0V ± 10% | | V _{CC} = 5.0V ± 10% | | |
| | | | Min | Max | Min | Max | | |
| Propagation Delay, D to Q | t _{PLH} | C _L = 50pF C _L = 150pF | 9 12 | | 14 23 | | 17 28 | ns |
| | t _{PHL} | C _L = 50pF C _L = 150pF | 9 12 | | 14 23 | | 17 28 | |
| Propagation Delay, C to Q | t _{PLH} | C = 50pF C _L = 150pF | 12 15 | | 20 29 | | 24 35 | ns |
| | t _{PHL} | C _L = 50pF C _L = 150pF | 12 15 | | 20 29 | | 24 35 | |
| Output Enable Time OC to any Q | t _{PZH} | R _L = 1kΩ C _L = 50pF C _L = 150pF | 11 | | 18 | | 22 | ns |
| | | | 17 | | 27 | | 33 | |
| Output Disable Time OC to any Q | t _{PZL} | R _L = 1kΩ C _L = 50pF C _L = 150pF | 11 | | 18 | | 22 | ns |
| | | | 17 | | 27 | | 33 | |
| Output Disable Time OC to any Q | t _{PHZ} | R _L = 1kΩ | 13 | | 19 | | 22 | ns |
| | t _{PLZ} | C _L = 50pF | 13 | | 19 | | 22 | |
| Pulse Width, C High | t _w | | 9 | 15 | | 18 | ns | |
| Setup Time, D before C↓ | t _{su} | | 6 | 10 | | 12 | ns | |
| Hold Time, D after C↓ | t _h | | 4 | 7 | | 9 | ns | |
| Input Capacitance | C _{IN} | | 5 | | | | pF | |
| Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C _{PD} | $\overline{OC} = V_{CC}$ | 5 | | | | pF | |
| | | $\overline{OC} = GND$ | 30 | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

4

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

The '574 consists of 8 high-speed D-type edge-triggered flip-flops coupled to 3-state output buffers with high drive current capability. It can be used in implementing buffer registers, I/O ports, bidirectional bus drivers and working registers.

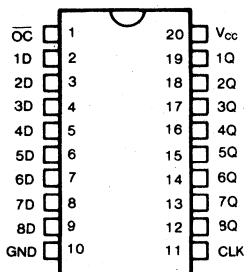
The flip-flops are edge-triggered on the positive transition of the clock. The Q outputs are set to the logic levels that were set up at the D inputs.

The output buffers are controlled by a common signal (\overline{OC}) which places the outputs at a high-impedance state when it is taken high. The \overline{OC} signal does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while outputs are off.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

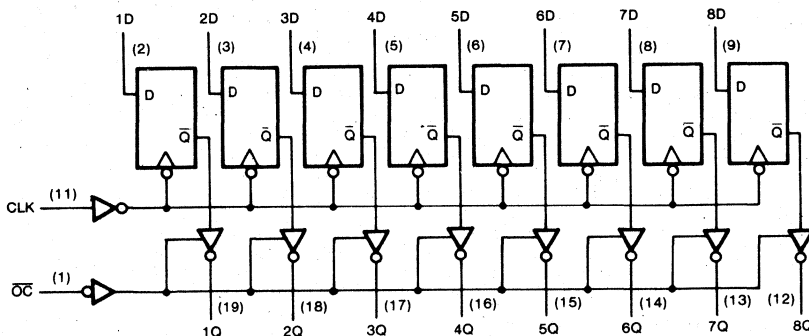


FUNCTION TABLE

(Each Flip-Flop)

| Inputs | | | Output |
|-----------------|-----|---|--------|
| \overline{OC} | CLK | D | Q |
| L | ↑ | H | H |
| L | ↑ | L | L |
| L | L | X | Q_0 |
| H | X | X | Z |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
Continuous Output Current Per Pin, I_O
(-0.5V < V_O < $V_{CC} + 0.5V$) ± 70 mA
Continuous Current Through
 V_{CC} or GND pins ± 250 mA
Storage Temperature Range, T_{stg} -65°C to +150°C
Power Dissipation Per Package, P_d [†] 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

[†] Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
Operating Temperature
Range KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C
Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|--|---|-----------------------|---|
| | | | Typ | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| | | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -6mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 12mA$ $I_O = 24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | ± 0.1 | ± 1.0 | ± 1.0 | μA | |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | ± 0.5 | ± 5.0 | ± 10.0 | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | 8.0 | 80.0 | 160.0 | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | 2.7 | 2.9 | 3.0 | mA | |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT574

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|---|-----------|--|--|--|----------|---|----------|------|
| | | | Typ | Min | Max | Min | Max | |
| Maximum Operating Frequency | f_{max} | $C_L = 50\text{pF}$ | 50 | 35 | | 30 | | MHz |
| Propagation Delay, CLK to any Q | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 8 11 | | 14 23 | | 17 28 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 8 11 | | 14 23 | | 17 28 | |
| Output Enable Time, \overline{OC} to any Q | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 11 17 | 18 27 | | 22 31 | ns |
| | t_{PZL} | | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 11 17 | 18 27 | | 22 31 | |
| Output Disable Time, \overline{OC} to any Q | t_{PHZ} | $R_L = 1\text{k}\Omega$ $C_L = 50\text{pF}$ | | 13 | 18 | | 22 | ns |
| | t_{PLZ} | | | 13 | 18 | | 22 | |
| Pulse Width, CLK High or Low | t_w | | 9 | 15 | | 18 | | ns |
| Setup Time, D before CLK† | t_{su} | | 9 | 14 | | 17 | | ns |
| Hold Time, D after CLK† | t_h | | -3 | 0 | | 0 | | ns |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | | pF |
| Power Dissipation Capacitance* (per stage) | C_{PD} | $\overline{OC} = V_{CC}$ | 5 | | | | | pF |
| | | $\overline{OC} = \text{GND}$ | 30 | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Choice of 3-State ('590) and Open-Drain ('591) Outputs
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

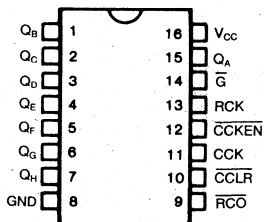
These devices each consist of an 8-bit binary counter which feeds an 8-bit register. The counter is incremented on the rising edge of the CCK input, provided that clock enable, $\overline{\text{CCKEN}}$, is low. When the counter increments to the all ones condition, ripple carry out, $\overline{\text{RCO}}$, will go low. This enables either synchronous cascading of the counters by connecting the $\overline{\text{RCO}}$ of the first stage to the $\overline{\text{CCKEN}}$ of the second, or clocking both circuits in parallel. Ripple cascading is accomplished by connecting the $\overline{\text{RCO}}$ of the first to the CCK of the second stage. A clear input is also provided which will reset the counter to the all zeros state.

The output register is loaded with the contents of the counter on the rising edge of the register clock, RCK. The outputs of this register feed the outputs which are enabled when the enable input, $\overline{\text{G}}$, is taken low. This enables connection of this part to a system bus. The Q outputs of the '590 are 3-State and those for '591 are Open-drain.

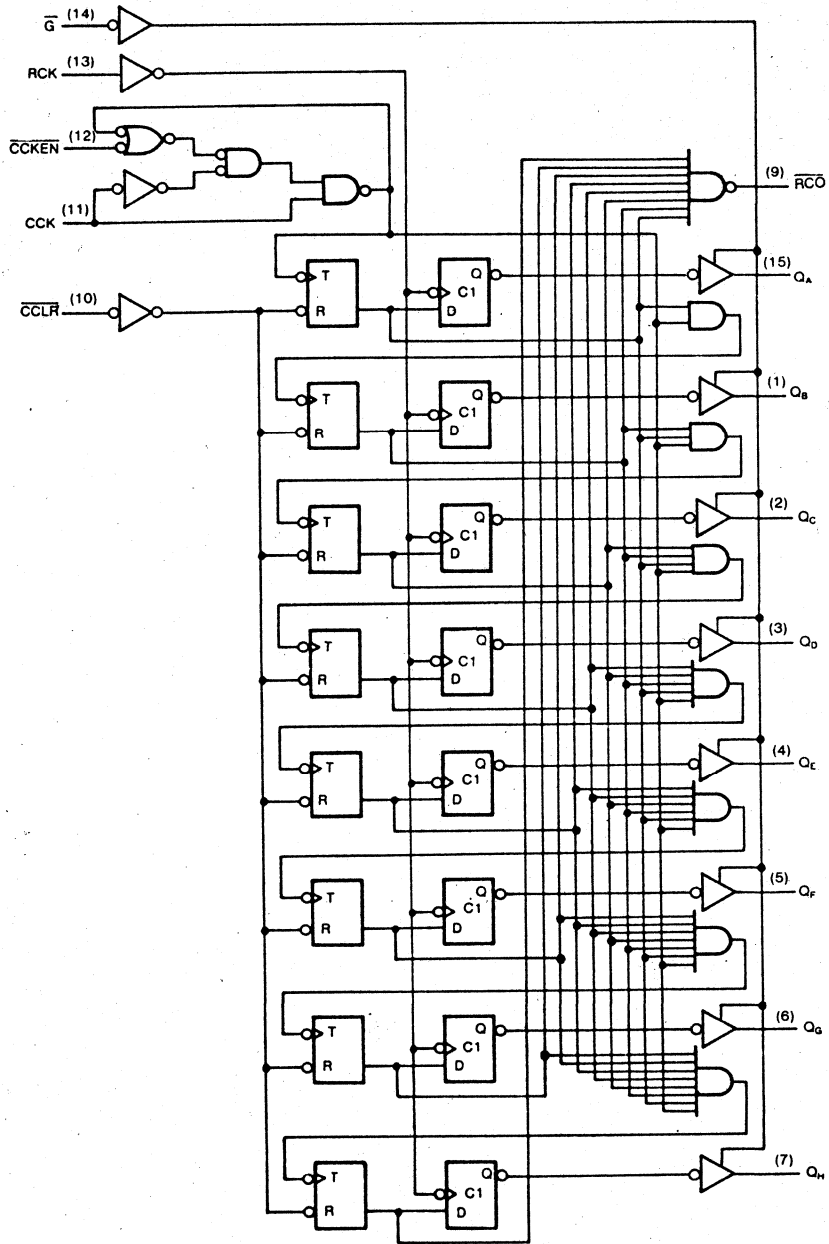
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|--|-----------------|--|--------------------------|----------------------|----------------------|---------------------|---------------|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage (All '590 Outputs and '591 \overline{RCO} Output) | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Output Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT590

| Characteristic | | Symbol | Conditions† | 54/74AHT | KS74AHT | | 54AHT | | Unit |
|--|---------------------------|-----------|---------------------|---|--|-----|---|----|------|
| | | | | $T_a = 25^\circ\text{C}$ $V_{CC} = 5\text{V}$ Typical | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5\text{V} \pm 10\%$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | | Min | Max | Min | Max | | |
| Maximum Clock Frequency | | f_{max} | | 50 | 30 | | 25 | | ns |
| Propagation Delay, CCK↑ to RCO | | t_{PLH} | $C_L = 50\text{pF}$ | 15 | | 25 | | 29 | ns |
| | | t_{PHL} | | 15 | | 25 | | 29 | |
| Propagation Delay, CCLR↓ to RCO | | t_{PHL} | | 17 | | 28 | | 33 | ns |
| Propagation Delay, RCK↑ to Q | | t_{PLH} | | 10 | | 16 | | 19 | ns |
| | | t_{PHL} | | 10 | | 16 | | 19 | |
| Output Enable Time, \bar{G} ↓ to Q | | t_{PZH} | | $C_L = 50\text{pF}$ $R_L = 1\text{K}\Omega$ | 13 | | 18 | | 22 |
| | | t_{PZL} | 13 | | | 18 | | 22 | |
| Output Disable Time, \bar{G} ↑ to Q | | t_{PHZ} | 13 | | | 18 | | 22 | ns |
| | | t_{PLZ} | 13 | | | 18 | | 22 | |
| Pulse Duration | CCK or RCK High or Low | t_w | | | 10 | 15 | | 20 | ns |
| | CCLR Low | | | | 10 | 15 | | 20 | |
| Setup Time | CCKEN↓ before CCK↑ | t_{su} | | | 10 | 15 | | 20 | ns |
| | CCLR↑ before CCK↑ | | | | 6 | 10 | | 10 | |
| | CCK↑ to RCK↑↑↑ | | | | 15 | 20 | | 25 | |
| Input Capacitance | | C_{IN} | | | | 5 | | | |
| Output Capacitance (Q Outputs) | | C_{OUT} | Output Disabled | | 10 | | | | pF |
| Power Dissipation Capacitance* | | C_{PD} | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

†† This setup time ensures the register will see stable data from the counter outputs. The clocks may be tied together in which case the register state will be one clock pulse behind the counter.

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT591

| Characteristic | Symbol | Conditions [†] | 54/74AHT | KS74AHT | | 54AHT | | Unit |
|---|-----------|--|--------------------------|---|-----|--|-----|------|
| | | | $T_a = 25^\circ\text{C}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| | | | $V_{CC} = 5\text{V}$ | $V_{CC} = 5\text{V} \pm 10\%$ | | $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typical | Min | Max | Min | Max | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ $R_L = 1\text{k}\Omega$ | 50 | 30 | | 25 | | MHz |
| Propagation Delay, CCK \uparrow to RCO | t_{PLH} | | 15 | | 25 | | 29 | ns |
| | t_{PHL} | | 15 | | 25 | | 29 | |
| Propagation Delay, CCLR \downarrow to RCO | t_{PHL} | | 17 | | 28 | | 33 | ns |
| Propagation Delay, RCK \uparrow to Q | t_{PLH} | | 18 | | 31 | | 37 | ns |
| | t_{PHL} | | 10 | | 16 | | 19 | |
| Propagation Delay, \bar{G} \uparrow to Q | t_{PHL} | | 14 | | 20 | | 24 | ns |
| Propagation Delay, \bar{G} \uparrow to \bar{Q} | t_{PLH} | 14 | | 20 | | 24 | ns | |
| Pulse Duration | t_w | CCK or RCK High or Low | 10 | 15 | | 20 | | ns |
| | | CCLR Low | 10 | 15 | | 20 | | |
| Setup Time | t_{su} | CCKEN \downarrow Low to CCK \uparrow | 10 | 15 | | 20 | | ns |
| | | CCLR \uparrow High to CCK \uparrow | 6 | 10 | | 10 | | |
| | | CCK \uparrow to RCK \uparrow \uparrow | 15 | 20 | | 25 | | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

[†] For AC switching test circuits and timing waveforms see section 2.

^{††} This setup time ensures the register will see stable data from the counter outputs. The clocks may be tied together in which case the register state will be one clock pulse behind the counter.

4

Objective Specifications

FEATURES

- Parallel Register Inputs ('592)
- Parallel 3-State I/O: Register Inputs/Counter Outputs ('593)
- Counter Has Direct Overriding Load and Clear
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

The '592 and '593 both contain an 8-bit register which feeds an 8-bit binary counter. The counter is incremented on the rising edge of the CCK input, provided that clock enable, $\overline{\text{CCKEN}}$, is low. When the counter increments to the all ones condition, ripple carry out, $\overline{\text{RCO}}$, will go low. This enables either synchronous cascading of the counters by connecting the $\overline{\text{RCO}}$ or the first stage to the $\overline{\text{CCKEN}}$ of the second, or clocking both circuits in parallel. Ripple cascading is accomplished by connecting the $\overline{\text{RCO}}$ of the first to the CCK of the second stage. A clear input is also provided which will reset the counter to the all zeros state.

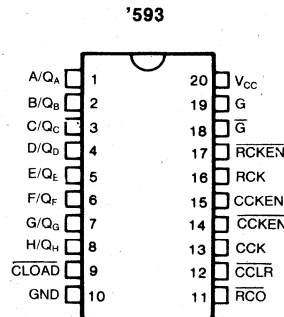
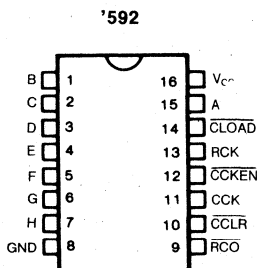
The input register is loaded on the rising edge of the register clock, RCK. The outputs of this register feed the counter. The counter is loaded with the register's contents when the clock load, $\overline{\text{CLOAD}}$, input is taken low.

The '592 differs from the '593 in that the latter device has bidirectional I input/output pins. The 3-state outputs of the counter can be enabled and are active when enable input, $\overline{\text{G}}$, is taken low and input G is taken high. The outputs of the counter then appear on the register inputs. This enables connection of this part to a system bus. The '593 also has a second clock enable pin, $\overline{\text{CCKEN}}$, which is active high and it also has an active low register clock enable, $\overline{\text{RCKEN}}$.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

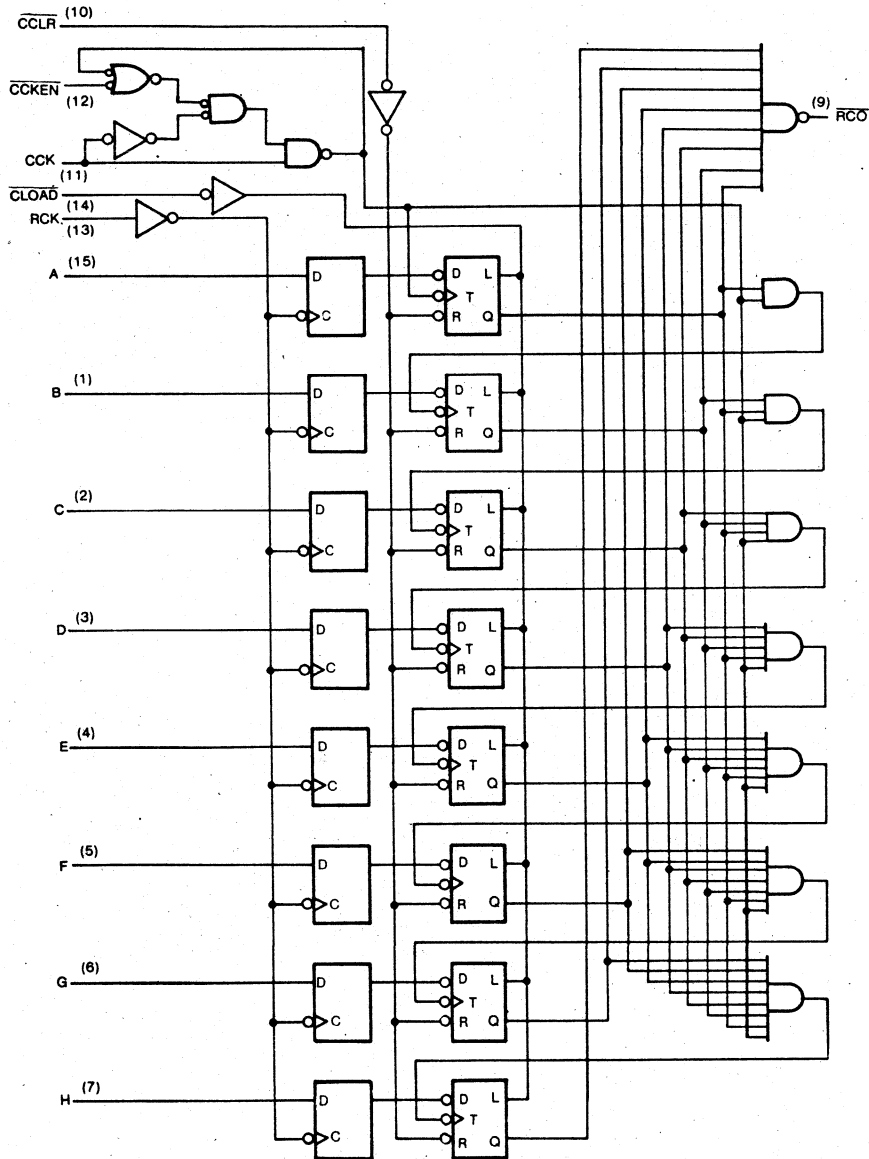
All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATIONS



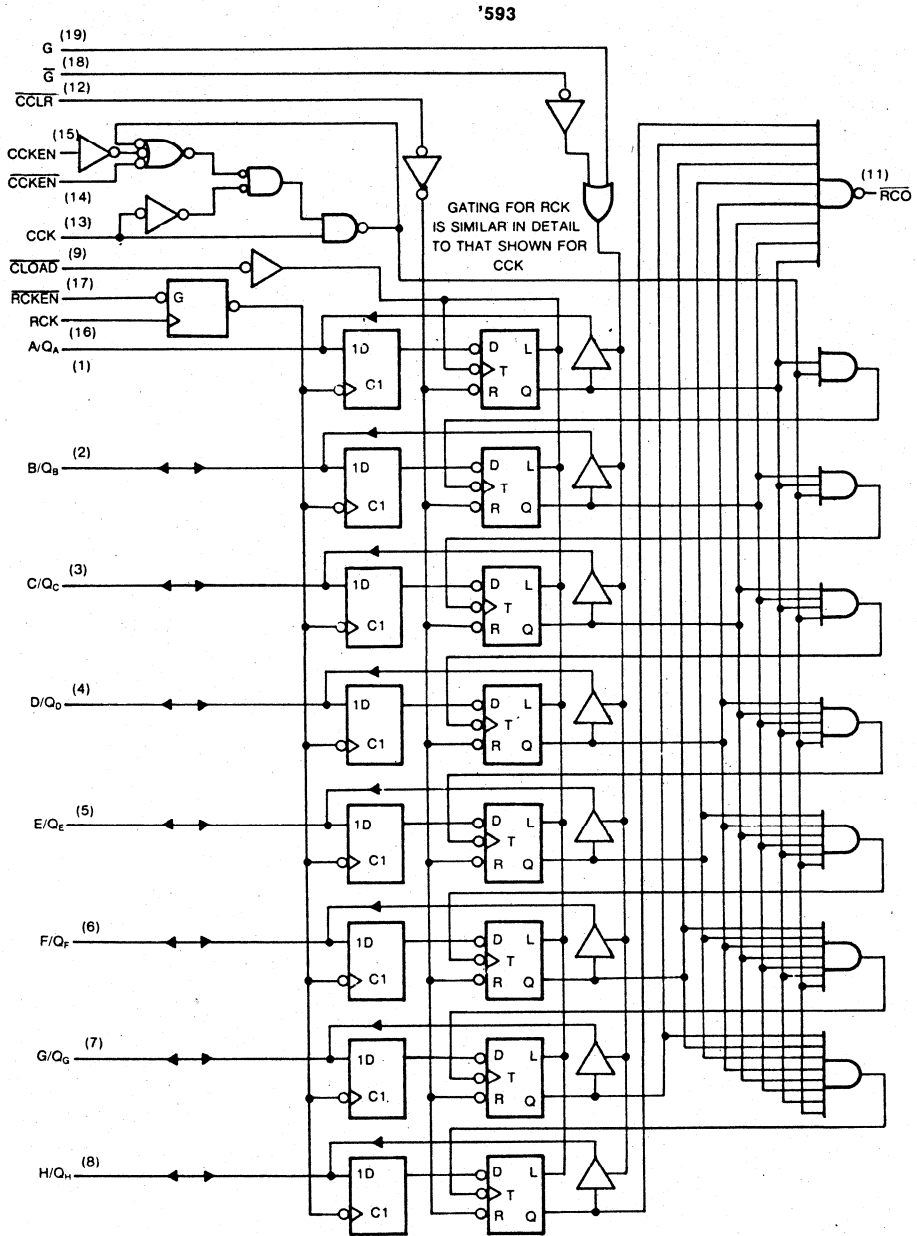
LOGIC DIAGRAMS

'592



4

LOGIC DIAGRAMS (Continued)



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} . . . 0V to V_{CC}
 Operating Temperature
 Range
 KS74AHCT: $-40^\circ C$ to $+85^\circ C$
 KS54AHCT: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------|----------------------|--------------------------------------|---------------------------------------|---------|
| | | | | | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | |
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-6mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=12mA$ $I_O=24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT592

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit | |
|-------------------------------------|---------------------------|---------------------|----------------------------------|---|-----|--|----|------|----|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | | |
| | | | Typ | $V_{CC} = 5.0\text{V} \pm 10\%$ | | $V_{CC} = 5.0\text{V} \pm 10\%$ | | | |
| | | | Min | Max | Min | Max | | | |
| Maximum Clock Frequency | f_{max} | | 50 | 30 | | 25 | | MHz | |
| Propagation Delay, CCK↑ to RCO | t_{PLH} | $C_L = 50\text{pF}$ | 15 | | 25 | | 29 | ns | |
| | t_{PHL} | | 15 | | 25 | | 29 | | |
| Propagation Delay, CLOAD↓ to RCO | t_{PLH} | | 15 | | 15 | | 23 | ns | |
| | t_{PHL} | | 15 | | 25 | | 29 | | |
| Propagation Delay, CCLR↓ to RCO | t_{PHL} | | | 15 | | 25 | | 29 | ns |
| Propagation Delay, RCK↑ to RCO | t_{PLH} | | $C_L = 50\text{pF}$ CLOAD=GND | 18 | | 30 | | 36 | ns |
| | t_{PHL} | 18 | | | 30 | | 36 | | |
| Pulse Width | CCK or RCK High or Low | t_w | 10 | 15 | | 20 | | ns | |
| | | | CCLR Low | 10 | 15 | | 20 | | |
| | | | CLOAD Low | 10 | 15 | | 20 | | |
| Setup Time | CCKEN↓ before CCK↑ | t_{su} | 10 | 15 | | 20 | | ns | |
| | CCLR↑ before CCK↑ | | 6 | 10 | | 10 | | | |
| | RCK↑ before CCK↑†† | | 10 | 15 | | 20 | | | |
| | Data A-H↑ before RCK↑ | | 10 | 15 | | 20 | | | |
| Hold Time | t_h | | -3 | 0 | | 0 | | ns | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

†† The RCK↑ to CCK↑ setup time ensures that the counter will see stable data from the register output.

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT593

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|--|----------------------|---|--------------------------|---|----------|--|----------|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Clock Frequency | f_{max} | | 50 | 30 | | 25 | | MHz |
| Propagation Delay, CCK† to Q | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 15 18 | | 25 34 | | 29 40 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 15 18 | | 25 34 | | 29 40 | |
| Propagation Delay, CCK† to \overline{RCO} | t_{PLH} | $C_L = 50\text{pF}$ | 15 | | 25 | | 29 | ns |
| | t_{PHL} | | 15 | | 25 | | 29 | |
| Propagation Delay, LOAD† to Q | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 15 18 | | 25 34 | | 29 40 | ns |
| | t_{PHL} | | 15 18 | | 25 34 | | 29 40 | |
| Propagation Delay, LOAD† to \overline{RCO} | t_{PLH} | $C_L = 50\text{pF}$ | 15 | | 25 | | 29 | ns |
| | t_{PHL} | | 15 | | 25 | | 29 | |
| Propagation Delay, RCK† to \overline{RCO} | t_{PLH} | $C_L = 50\text{pF}$ CLOAD=GND | 18 | | 30 | | 36 | ns |
| | t_{PHL} | | 18 | | 30 | | | |
| Propagation Delay, $\overline{CCLR}\dagger$ to Q | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 15 18 | | 25 34 | | 29 40 | ns |
| | | | | | | | | |
| Propagation Delay, $\overline{CCLR}\dagger$ to \overline{RCO} | t_{PLH} | $C_L = 50\text{pF}$ | 15 | | 25 | | 29 | ns |
| | | | | | | | | |
| Enable Time, $\overline{G}\dagger$ or $\overline{G}\dagger$ to Q | t_{pZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 13 | 20 | | 24 | ns |
| | | | $C_L = 150\text{pF}$ | 16 | 29 | | 35 | |
| | $C_L = 50\text{pF}$ | | 13 | 20 | | 24 | | |
| | $C_L = 150\text{pF}$ | | 16 | 29 | | 35 | | |
| Disable Time, $\overline{G}\dagger$ or $\overline{G}\dagger$ to Q | t_{pHZ} | $R_L = 1\text{k}\Omega$ | 13 | | 20 | | 24 | ns |
| | t_{pLZ} | $C_L = 50\text{pF}$ | 13 | | 20 | | 24 | |
| Pulse Width | t_w | CCK or RCK High or Low | 10 | 15 | | 20 | ns | |
| | | \overline{CCLR} Low | 10 | 15 | | 20 | | |
| | | CLOAD Low | 10 | 15 | | 20 | | |
| Setup Time | t_{su} | $\overline{CCKEN}\dagger$ before CCK† | 10 | 15 | | 20 | ns | |
| | | $\overline{RCKEN}\dagger$ to RCK† | 10 | 15 | | 20 | | |
| | | $\overline{CCLR}\dagger$ before CCK† | 6 | 10 | | 10 | | |
| | | RCK† before CCK†† | 10 | 15 | | 20 | | |
| | | Data A-H before RCK† | 10 | 15 | | 20 | | |
| Hold Time | t_h | | -3 | 0 | | 0 | ns | |
| Input Capacitance | C_{IN} | | 5 | | | | pF | |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

†† The RCK† to CCK† setup time ensures that the counter will see stable data from the register output.

4

Preliminary Specifications

FEATURES

- 8-Bit Serial-In, Parallel-Out Shift Registers With Storage.
- Choice of 3-State ('595) or Open-Drain ('596) Parallel Outputs.
- Shift Register Has Direct Clear.
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

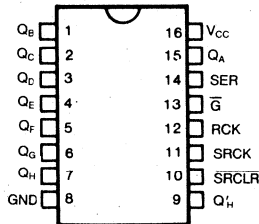
These devices each contain an 8-bit serial-in, parallel-out shift register that feeds an 8-bit D-type storage register. The storage register has parallel 3-state ('595) or open-drain ('596) outputs. Separate clocks are provided for both the shift register and the storage register. The shift register has a direct-overriding clear, serial input, and serial output pins for cascading.

Both the shift register and storage register clocks are positive-edge triggered. If the user wishes to connect both clocks together, the shift register state will always be one clock pulse ahead of the storage register.

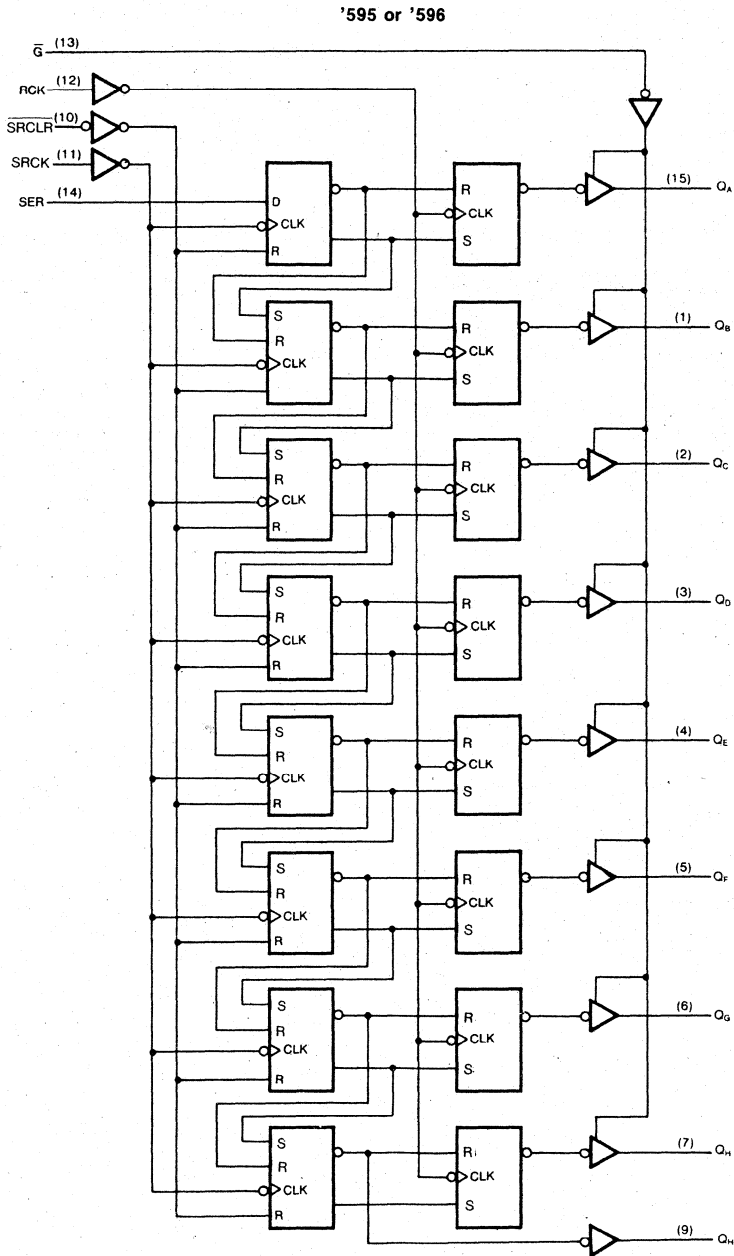
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



4

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|--|-----------------|---|--------------------------|----------------------|---|--|---------------|
| | | | Typ | Guaranteed Limits | | | |
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage (All '595 Outputs and '596 Q _H ' Output) | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_C=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4\text{V}$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT595, AHCT596

| Characteristic | Symbol | Conditions† | KS74AHCT | | KS54AHCT | | Unit | | |
|--|--------------------|------------------------|--|-----|--|-----|------|---|----|
| | | | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | Min | Max | Min | | Max | |
| Propagation Delay, SRCK↑ to Q _H | t _{PLH} | C _L = 50pF | 9 | | 25 | | 18 | ns | |
| | t _{PHL} | | 9 | | 15 | | 18 | | |
| Propagation Delay, RCK↑ to Q _A thru Q _H | t _{PLH} | C _L = 50pF | 11 | | 16 | | 29 | ns | |
| | | C _L = 150pF | 14 | | 26 | | 31 | | |
| | t _{PHL} | C _L = 50pF | 11 | | 17 | | 20 | | |
| | | C _L = 150pF | 14 | | 26 | | 31 | | |
| Output Enable Time, G̅↑ to Q _A thru Q _H (*595 only) | t _{pZH} | R _L = 1kΩ | C _L = 50pF | 14 | | 20 | | 24 | ns |
| | | | C _L = 150pF | 17 | | 29 | | 35 | |
| | t _{pZL} | | C _L = 50pF | 14 | | 20 | | 24 | |
| | | | C _L = 150pF | 17 | | 29 | | 35 | |
| Output Disable Time, G̅↑ to Q _A thru Q _H (*595 only) | t _{PHZ} | R _L = 1kΩ | 14 | | 20 | | 24 | ns | |
| | t _{PLZ} | C _L = 50pF | 14 | | 20 | | 24 | | |
| Propagation Delay, G̅↑ to Q _A thru Q _H (*596 only) | t _{PLH} | C _L = 50pF | 14 | | 20 | | 24 | ns | |
| | | C _L = 150pF | 20 | | 29 | | 35 | | |
| Propagation Delay, G̅↑ to Q _A thru Q _H (*596 only) | t _{PHL} | C _L = 50pF | 14 | | 20 | | 24 | ns | |
| | | C _L = 150pF | 20 | | 29 | | 35 | | |
| Pulse Width | SRCK or RCK | t _w | 10 | 15 | | 20 | | ns | |
| | SRCLR Low | | 10 | 15 | | 20 | | | |
| Setup Time | SRCLR↑ to SRCK↑ | t _{su} | 6 | 10 | | 12 | | ns | |
| | SER to SRCK↑ | | 10 | 15 | | 20 | | | |
| | SRCK↑ to RCK↑† | | 15 | 20 | | 25 | | | |
| Hold Time, | t _h | | -3 | 0 | | 0 | | ns | |
| Input Capacitance | C _{IN} | | 5 | | | | | pF | |
| Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* | C _{PD} | | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

†† The RCK↑ to CCK↑ setup time ensures that the counter will see stable data from the register output.

FEATURES

- 8-Bit Parallel Storage Register Inputs
- shift Register has Direct Overriding Load and Clear.
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

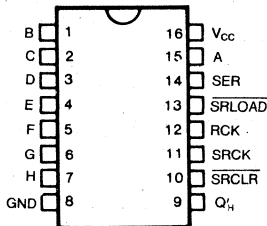
DESCRIPTION

The '597 consists of an 8-bit storage latch feeding a parallel-in, serial-out 8-bit shift register. Both the storage register and the shift register have positive-edge triggered clocks. The shift register also has direct load (from storage) and clear inputs.

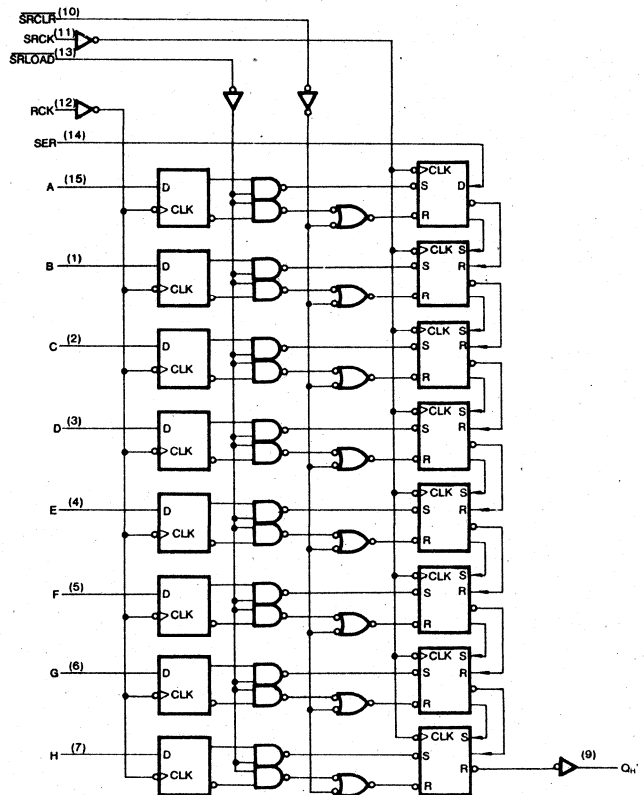
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature

Range
 KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C

Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|---|--|--|--|---------------|
| | | | Typ | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | | 2.0 | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | | 0.8 | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | | $V_{CC} - 0.1$ 3.7 | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | | 0.1 0.4 | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | | ± 1.0 | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | | 160.0 | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | | 3.0 | | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT597

| Characteristic | Symbol | Conditions† | KS74AHCT | | KS54AHCT | | Unit | | |
|--------------------------------------|----------------------------|----------------------------------|--|-----|--|-----|------|---|--|
| | | | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | Min | Max | Min | | Max | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 50 | 30 | | 25 | MHz | | |
| Propagation Delay, SRCK† to Q'H | t_{PLH} | | 9 | | 15 | | 18 | ns | |
| | t_{PHL} | | 9 | | 15 | | 18 | | |
| Propagation Delay, SRLOAD† to Q'H | t_{PLH} | | 14 | | 20 | | 24 | ns | |
| | t_{PHL} | | 14 | | 20 | | 24 | | |
| Propagation Delay, SRCLR† to Q'H | t_{PHL} | 11 | | 18 | | 21 | ns | | |
| Propagation Delay, RCK† to Q'H | t_{PLH} | $C_L = 50\text{pF}$ SLOAD=Low | 15 | | 25 | | 29 | ns | |
| | t_{PHL} | | 15 | | 25 | | 29 | | |
| Pulse Width | RCK or SRCK High or Low | t_w | 10 | 15 | | | 20 | ns | |
| | SRCLR or SRLOAD Low | | 10 | 15 | | 20 | | | |
| Setup Time | SRCLR† before SRCK† | t_{su} | 6 | 10 | | 12 | ns | | |
| | RCK† before SRCK†† | | 15 | 20 | | 25 | | | |
| | SER before SRCK† | | 10 | 15 | | 20 | | | |
| | A thru H before RCK† | | 10 | 15 | | 20 | | | |
| Hold Time | t_h | | -3 | 0 | | 0 | ns | | |
| Input Capacitance | C_{IN} | | 5 | | | | pF | | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

†† The RCK† to CCK† setup time ensures that the counter will see stable data from the register output.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

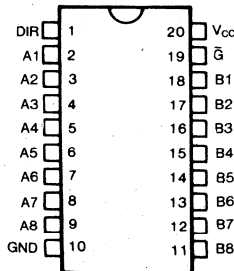
DESCRIPTION

These high-speed octal/bus transceivers are designed for asynchronous two-way communication between data buses. A direction control input (DIR) controls the flow direction of data. When DIR is high, data flows from the A inputs to the B outputs. When DIR is low, data flows from B to A. The '643 transfers inverted data from the A bus to the B bus and non-inverted data from the B bus to the A bus. The '640 transfers inverted data in both directions.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

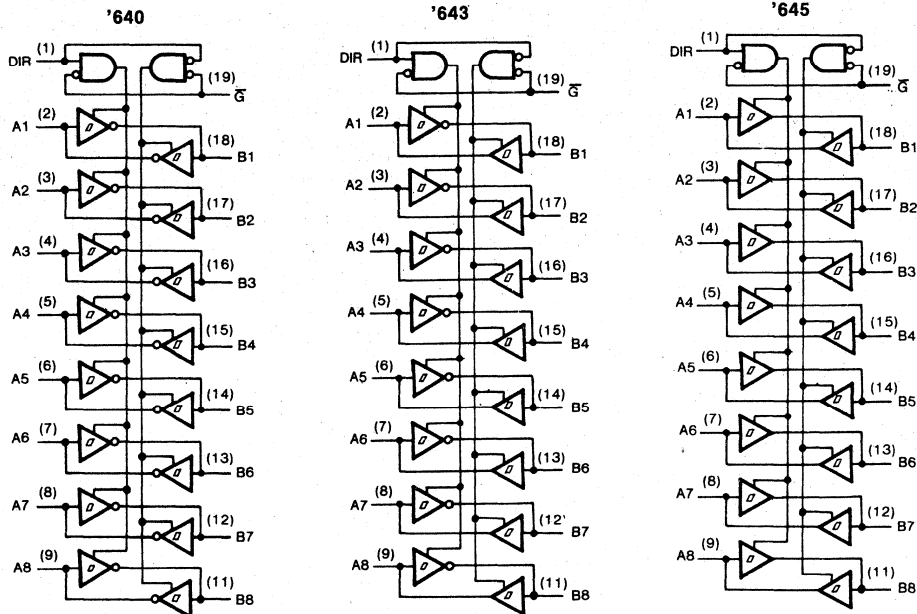
PIN CONFIGURATION



FUNCTION TABLE

| Control Inputs | | Operation | | |
|----------------|-----|---|---|---------------------------------------|
| \bar{G} | DIR | '640 | '643 | '645 |
| L | L | Inverted data transmitted from Bus B to Bus A | Data transmitted from Bus B to Bus A | Data transmitted from Bus B to Bus A |
| L | H | Inverted data transmitted from Bus A to Bus B | Inverted data transmitted from Bus A to Bus B | Data transmitted from Bus A to Bus B |
| H | X | Buses isolated (High-impedance state) | Buses isolated (High-impedance state) | Buses isolated (High-impedance state) |

LOGIC DIAGRAMS



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} . . . 0V to V_{CC}
 Operating Temperature
 Range
 KS74AHCT: $-40^\circ C$ to $+85^\circ C$
 KS54AHCT: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS (V_{CC}=5V±10% Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | T _a = 25°C | KS74AHCT T _a = -40°C to +85°C | | KS54AHCT T _a = -55°C to +125°C | Unit |
|--------------------------------------|------------------|---|------------------------|---|------------------------------|--|------|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V _{IH} | | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V _{IL} | | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V _{OH} | V _{IN} =V _{IH} or V _{IL} I _O =-20μA I _O =-6mA | V _{CC} 4.2 | V _{CC} -0.1 3.98 | V _{CC} -0.1 3.84 | V _{CC} -0.1 3.7 | V |
| Maximum Low-Level Output Voltage | V _{OL} | V _{IN} =V _{IH} or V _{IL} I _O =20μA I _O =12mA I _O =24mA | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I _{IN} | V _{IN} =V _{CC} or GND | ±0.1 | ±1.0 | ±1.0 | μA | |
| Maximum 3-State Leakage Current | I _{OZ} | Output Enable = V _{IH} V _{OUT} =V _{CC} or GND | ±0.5 | ±5.0 | ±10.0 | μA | |
| Maximum Quiescent Supply Current | I _{CC} | V _{IN} =V _{CC} or GND I _{OUT} =0μA | 8.0 | 80.0 | 160.0 | μA | |
| Additional Worst Case Supply Current | ΔI _{CC} | per input pin V _I =2.4V other Inputs: at V _{CC} or GND I _{OUT} =0μA | 2.7 | 2.9 | 3.0 | mA | |

4

AC ELECTRICAL CHARACTERISTICS (Input t_r, t_f ≤ 2 ns), AHCT640, AHCT643

| Characteristic | Symbol | Conditions [†] | T _a = 25°C V _{CC} = 5.0V | KS74AHCT T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | | KS54AHCT T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | Unit | |
|---|-------------------|-------------------------|---|---|-----|--|-----|------|----|
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay, A to B, or B to A | t _{PLH} | C _L = 50pF | 7 | | 12 | | 14 | ns | |
| | | C _L = 150pF | 10 | | 21 | | 25 | | |
| | t _{PHL} | C _L = 50pF | 7 | | 12 | | 14 | ns | |
| | | C _L = 150pF | 10 | | 21 | | 25 | | |
| Output Enable Time, Ḡ to A or B | t _{PZH} | R _L = 1kΩ | C _L = 50pF | 12 | | 20 | | 25 | ns |
| | | | C _L = 150pF | 18 | | 29 | | 36 | |
| | t _{PZL} | C _L = 50pF | 12 | | 20 | | 25 | | |
| | | C _L = 150pF | 18 | | 29 | | 36 | | |
| Output Disable Time, Ḡ to A or B | t _{PHZ} | R _L = 1kΩ | 13 | | 18 | | 22 | ns | |
| | t _{PLZ} | C _L = 50pF | 13 | | 18 | | 22 | | |
| Input Capacitance | C _{IN} | | 5 | | | | pF | | |
| Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | pF | | |
| Power Dissipation Capacitance* | C _{PD} * | Ḡ = V _{CC} | 5 | | | | | pF | |
| | | Ḡ = GND (per stage) | 30 | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT645

| Characteristic | Symbol | Conditions† | T _a = 25°C | KS74AHCT | | KS54AHCT | | Unit | |
|---|-------------------|------------------------|------------------------|---|-----|--|-----|------|----|
| | | | V _{CC} = 5.0V | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | | |
| | | | Typ | Min | Max | Min | Max | | |
| Propagation Delay, A to B, or B to A | t _{PLH} | C _L = 50pF | 6 | | 10 | | 14 | ns | |
| | | C _L = 150pF | 9 | | 19 | | 25 | | |
| | t _{PHL} | C _L = 50pF | 6 | | 10 | | 14 | | |
| | | C _L = 150pF | 9 | | 19 | | 25 | | |
| Output Enable Time G to A or B | t _{PZH} | R _L = 1kΩ | C _L = 50pF | 12 | | 20 | | 25 | ns |
| | | | C _L = 150pF | 18 | | 29 | | 36 | |
| | t _{PZL} | C _L = 50pF | 12 | | 20 | | 25 | | |
| | | C _L = 150pF | 18 | | 29 | | 36 | | |
| Output Disable Time, G to A or B | t _{PHZ} | R _L = 1kΩ | 13 | | 18 | | 22 | ns | |
| | t _{PLZ} | C _L = 50pF | 13 | | 18 | | 22 | | |
| Input Capacitance | C _{IN} | | 5 | | | | | pF | |
| Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* | C _{PD} * | G̅ = V _{CC} | 5 | | | | | pF | |
| | | G̅ = GND | 30 | | | | | | |

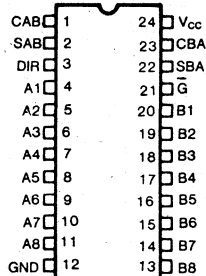
* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- 8 bi-directional data paths
- Transmits direct or stored data in either direction
- 24-pin slim DIP package
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



DESCRIPTION

The '646 and '648 are bi-directional bus transceivers with D-type flip-flops and control circuitry to facilitate high speed multiplexed data transmission. The '648 transmits true data and the '646 transmits inverted data.

Data can be transmitted directly from one port to the other in either direction. It also can be stored in the flip-flops from either or both ports for subsequent transmission to the opposite port. Six control inputs govern the data flow:

\bar{G} (output enable) when high, all outputs are disabled, isolating the A and B ports. When low, one port is enabled at a time as determined by the DIR pin.

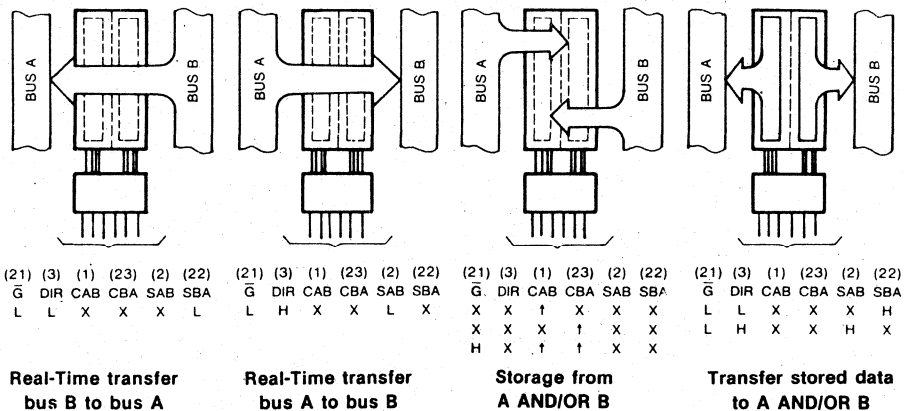
DIR (direction control) disables A or B outputs permitting the pins to be used as inputs thus determining the direction of a data flow. When DIR=high, data flows from A to B.

SAB,SBA (data source AB and BA) determines whether data transmitted is from the data inputs or the registers associated with those inputs.

CAB,CBA (Clock AB and BA) clocks data from the A inputs and the B inputs, respectively, into their associated registers. Since the clocks are not gated with the \bar{G} and DIR pins, data at the A and B pins can be clocked into the flip-flops at any time.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

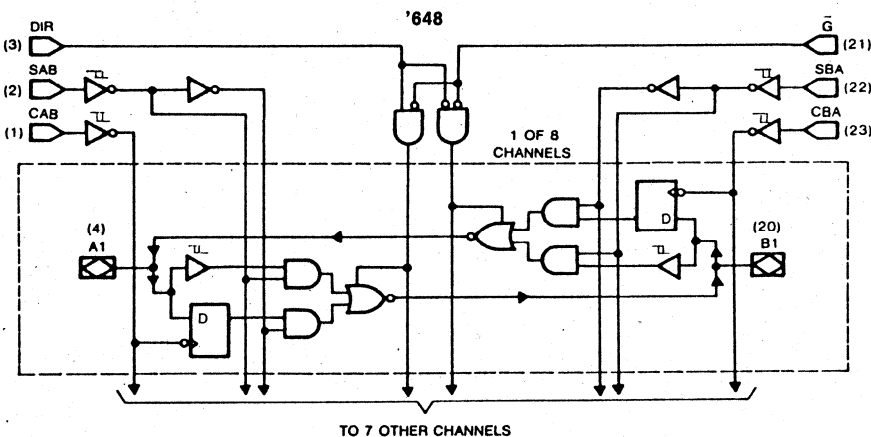
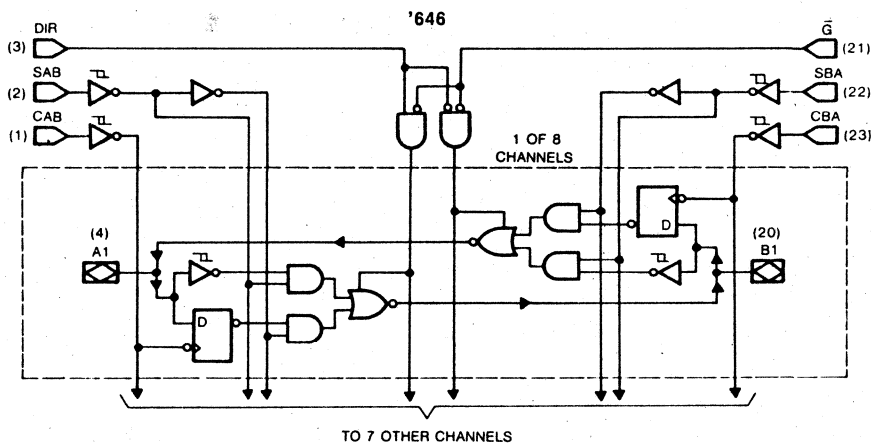


FUNCTION TABLE

| Inputs | | | | | | Data I/O* | | Operation or Function | |
|-----------|-----|--------|--------|-----|-----|---------------|---------------|---------------------------|-----------------------------------|
| \bar{G} | DIR | CAB | CBA | SAB | SBA | A1 thru A8 | B1 thru B8 | '646 | '648 |
| X | X | ↑ | X | X | X | input | input | Store A, B unspecified | Store A, B unspecified |
| X | X | X | ↑ | X | X | Not specified | Not specified | Store B, A unspecified | Store B, A unspecified |
| H | X | ↑ | ↑ | X | X | Input | Input | Store A and B data | Store A and B data |
| H | X | H or L | H or L | X | X | Input | Input | Isolation, hold storage | isolation, hold storage |
| L | L | X | X | X | L | Output | Input | Real-Time B data to A bus | Real-Time \bar{B} data to A bus |
| L | L | X | H or L | X | H | Output | Input | Stored B data to A bus | Stored \bar{B} data to A bus |
| L | H | X | X | L | X | Input | Output | Real-Time A data to B bus | Real-Time \bar{A} data to B bus |
| L | H | H or L | X | H | X | Input | Output | Stored A data to B bus | Stored \bar{A} data to B bus |

*The data output functions may be enabled or disabled by various signals at the \bar{G} and DIR inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every low-to-high transition on the clock inputs.

LOGIC DIAGRAMS



Absolute Maximum Ratings*

| | |
|--|---|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_i < -0.5V$ or $V_i > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_o < -0.5V$ or $V_o > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_o | |
| ($-0.5V < V_o < V_{CC} + 0.5V$) | ± 70 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

| | |
|---|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN} , V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74AHCT: -40°C to $+85^\circ\text{C}$ KS54AHCT: -55°C to $+125^\circ\text{C}$ |
| Input Rise & Fall Times, t_r , t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|--|---|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_o = -20\mu\text{A}$ $I_o = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_o = 20\mu\text{A}$ $I_o = 12\text{mA}$ $I_o = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_i=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT646, AHCT648

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit | |
|--|-----------|-------------------------|--------------------------|---|--|---------------------------------|-----|------|----|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | $V_{CC} = 5.0\text{V} \pm 10\%$ | | | |
| | | | Typ | Min | Max | Min | Max | | |
| Maximum Frequency | f_{max} | $C_L = 50\text{pF}$ | 45 | | 30 | | 25 | MHz | |
| Propagation Delay, A or B Input to B or A Output | t_{PLH} | $C_L = 50\text{pF}$ | 11 | | 18 | | 22 | ns | |
| | | $C_L = 150\text{pF}$ | 14 | | 27 | | 33 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 11 | | 18 | | 22 | ns | |
| | | $C_L = 150\text{pF}$ | 14 | | 27 | | 33 | | |
| Propagation Delay, CBA or CAB Input to A or B Output | t_{PLH} | $C_L = 50\text{pF}$ | 15 | | 25 | | 30 | ns | |
| | | $C_L = 150\text{pF}$ | 18 | | 34 | | 41 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 15 | | 25 | | 30 | ns | |
| | | $C_L = 150\text{pF}$ | 18 | | 34 | | 41 | | |
| Propagation Delay,†† SBA or SAB Input to A or B Output (with A or High) | t_{PLH} | $C_L = 50\text{pF}$ | 16 | | 27 | | 32 | ns | |
| | | $C_L = 150\text{pF}$ | 19 | | 36 | | 43 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 16 | | 27 | | 32 | ns | |
| | | $C_L = 150\text{pF}$ | 19 | | 36 | | 43 | | |
| Propagation Delay,†† SBA or SAB Input to A or B Output (with A or Low) | t_{PLH} | $C_L = 50\text{pF}$ | 15 | | 25 | | 30 | ns | |
| | | $C_L = 150\text{pF}$ | 18 | | 34 | | 41 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 15 | | 25 | | 30 | ns | |
| | | $C_L = 150\text{pF}$ | 18 | | 34 | | 41 | | |
| Out Enable Time, \bar{G} or DIR Input to A or B Output | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 14 | | 22 | | 26 | ns |
| | | | $C_L = 150\text{pF}$ | 17 | | 31 | | 37 | |
| | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 14 | | 22 | | 26 | ns |
| | | | $C_L = 150\text{pF}$ | 17 | | 31 | | 37 | |
| Output Disable Time, \bar{G} or DIR Input to A or B Output | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 13 | | 22 | | 26 | ns | |
| | | $C_L = 50\text{pF}$ | 13 | | 22 | | 26 | | |
| Pulse Duration, Clocks High or low | t_w | | 8 | 12 | | 15 | | ns | |
| Set up Time, A before CAB† or B before CBA† | t_{su} | | 8 | 12 | | 15 | | ns | |
| Hold Time, A after CAB† or B after CBA† | t_h | | -3 | 0 | | 0 | | ns | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

†† These parameters are measured with the internal output state of the storage register opposite to that of the bus input.

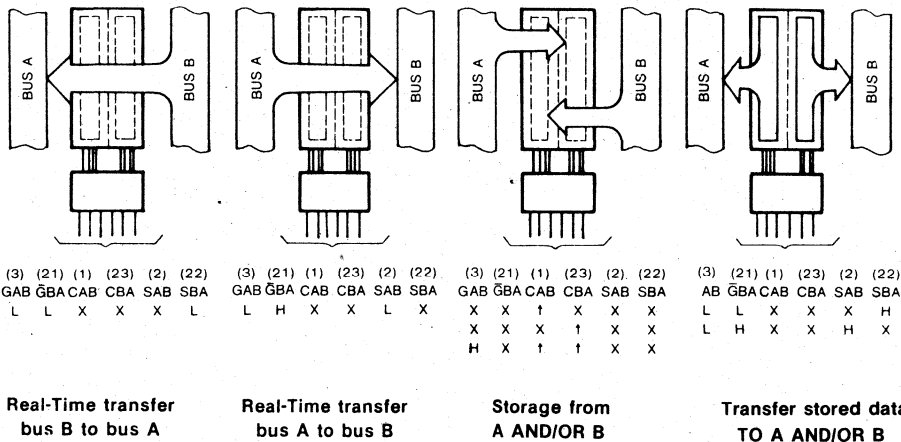
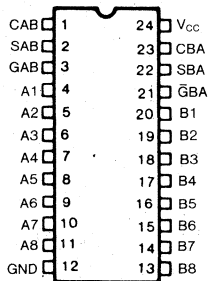


Preliminary Specifications

FEATURES

- Independent Registers and Enables for A and B Buses
- Multiplexed Real-Time and Stored-Data
- Choice of Time and Inverting Data Paths
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^\circ\text{C}$
KS54AHCT: -55°C to $+125^\circ\text{C}$

PIN CONFIGURATION



DESCRIPTION

These devices consist of bus transceiver circuits. D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the data bus or from the internal storage registers. Enable GAB and GBA are provided to control the transceiver functions. SAB and SBA control pins are provided to select whether real-time or stored data is transferred. A low input level selects real-time data, and a high selects stored data. The following examples demonstrate the four fundamental bus-management functions that can be performed with the octal bus transceivers and registers.

Data on the A or B data bus, or both, can be stored in the internal D flip-flops by low-to-high transitions at the appropriate clock pins (CAB or CBA) regardless of the select or enable control pins. When SAB and SBA are in the real-time transfer mode, it is also possible to store data without using the internal D-type flip-flops by simultaneously enabling GAB and GBA. In this configuration each output reinforces its input. Thus, when all other data sources to the two sets of bus lines are at high impedance, each set of bus lines will remain at its last state.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLE

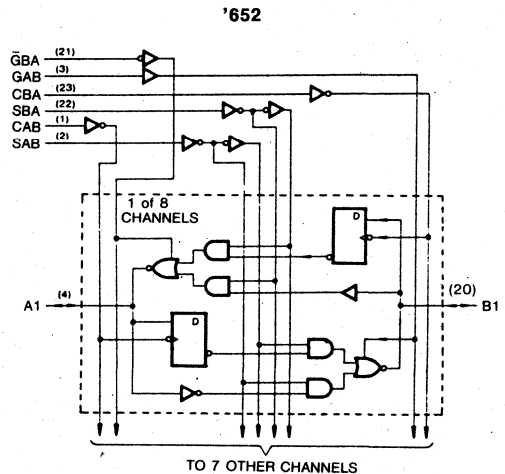
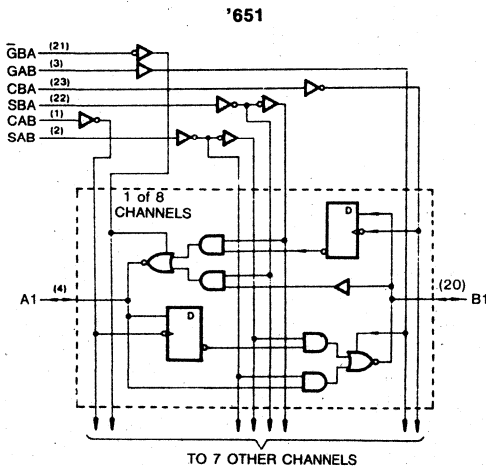
| INPUTS | | | | | DATA I/O* | | OPERATION OR FUNCTION | |
|--------|-------------|--------|--------|---------|---------------|---------------|--|--|
| GAB | $\bar{G}BA$ | CAB | CBA | SAB SBA | A1 THRU A8 | B1 THRU B8 | '651 | '652 |
| L | H | H or L | H or L | X X | Input | Input | Isolation | Isolation |
| L | H | ↑ | ↑ | X X | | | Store A and B Data | Store A and B Data |
| X | H | ↑ | H or L | X X | Input | Not specified | Store A, Hold B | Store A Hold B |
| H | H | ↑ | ↑ | X** X | Input | Output* | Store A in both registers | Store A in both registers |
| L | X | H or L | ↑ | X X | Not specified | Input | Hold A, Store B | Hold A, Store B |
| L | L | ↑ | ↑ | X X** | Output* | Input | Store B in both registers | Store B in both registers |
| L | L | X | X | X L | Output | Input | Real-Time \bar{B} Data to A Bus | Real-Time B Data to a Bus |
| L | L | X | H or L | X H | | | Stored \bar{B} Data to A Bus | Stored B Data to A Bus |
| H | H | X | X | L X | Input | Output | Real-Time \bar{A} Data to B Bus | Real-Time A Data to B Bus |
| H | H | H or L | X | H X | | | Stored \bar{A} Data to Bus | Stored A Data to B Bus |
| H | L | H or L | H or L | H H | Output | Output | Stored \bar{A} Data to B Bus and Stored \bar{B} Data to A Bus | Stored A Data to B Bus and Stored B Data to A Bus |

* The data output functions may be enabled or disabled by various signals at the GAB and $\bar{G}BA$ inputs. Data input functions are always enabled, ie., data at the bus pins will be stored on every low-to-high transition on the clock inputs.

** Select control=L: clocks can occur simultaneously

Select control=H: clocks must be staggered in order to load both registers

LOGIC DIAGRAMS



Absolute Maximum Ratings*

| | |
|--|-----------------|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 70 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74AHCT: -40°C to +85°C KS54AHCT: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|----------------------|---|---------------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT651, AHCT652

| Characteristic | Symbol | Conditions† | KS74AHCT | | KS54AHCT | | Unit | | |
|--|-----------|---|--|----------|--|-----|----------|---|--|
| | | | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | Min | Max | Min | | Max | |
| Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 45 | 30 | | 25 | MHz | | |
| Propagation Delay, A or B Input to B or A Output | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 11 14 | | 18 27 | | 22 33 | ns | |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 11 14 | | 18 27 | | 22 33 | | |
| Propagation Delay, CBA or CAB Input to A or B Output | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 15 18 | | 25 34 | | 30 41 | ns | |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 15 18 | | 25 34 | | 30 41 | | |
| Propagation Delay, SBA or SAB Input to A or B Output (with A or B High) | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 16 19 | | 27 36 | | 32 43 | ns | |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 16 19 | | 27 36 | | 32 43 | | |
| Propagation Delay, SBA or SAB Input to A or B Output (with A or B Low) | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 15 18 | | 25 34 | | 30 41 | ns | |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 15 18 | | 25 34 | | 30 41 | | |
| Output Enable Time, GBA to A or GAB to B | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 19 25 | 32 41 | | 38 49 | ns | |
| | t_{PZH} | | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 19 25 | 32 41 | | 38 49 | | |
| Output Disable Time, GBA to A or GAB to B | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 13 | | 22 | | 26 | ns | |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 13 | | 22 | | 26 | | |
| Pulse Width Clocks High or Low | t_w | | 8 | 12 | | 15 | ns | | |
| Setup Time, A before CAB† or B before CBA† | t_{su} | | 8 | 12 | | 15 | ns | | |
| Hold Time, A after CAB† or B after CBA† | t_h | | -3 | 0 | | 0 | ns | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF | | |
| maximum Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF | | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

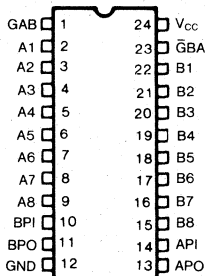
† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Bus Transceivers with Inverting Outputs ('658) or True Outputs ('659)
- Generates a Parity Bit for A Bus and B Bus
- Easily Cascadable
- Internal Active Pull-Ups and Pull-Downs
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^\circ\text{C}$
KS54AHCT: -55°C to $+125^\circ\text{C}$

PIN CONFIGURATION



DESCRIPTION

These octal bus transceivers are designed for asynchronous, bidirectional communication between data buses. The devices transmit data from the A Bus to the B Bus, or from the B Bus to the A Bus, depending on the levels at the direction control inputs, GAB and $\bar{G}BA$. These devices also generate parity outputs, APO and BPO, which reflect the number of high levels at the A Bus and B Bus, respectively, taking into account the parity inputs API and BPI.

The bidirectional I/O ports feature active circuits on the input stage that, when the output shared by that pin is disabled, will maintain the input in the last state taken by the output. This state will be maintained until changed by activity on the bus. The advantage of this arrangement is that when all outputs on the bus are disabled, the inputs will be prevented from floating, resulting in minimum power dissipation and minimum susceptibility to noise. This eliminates any need for external pull-up or pull-down resistors. The parity inputs API and BPI have similar circuits.

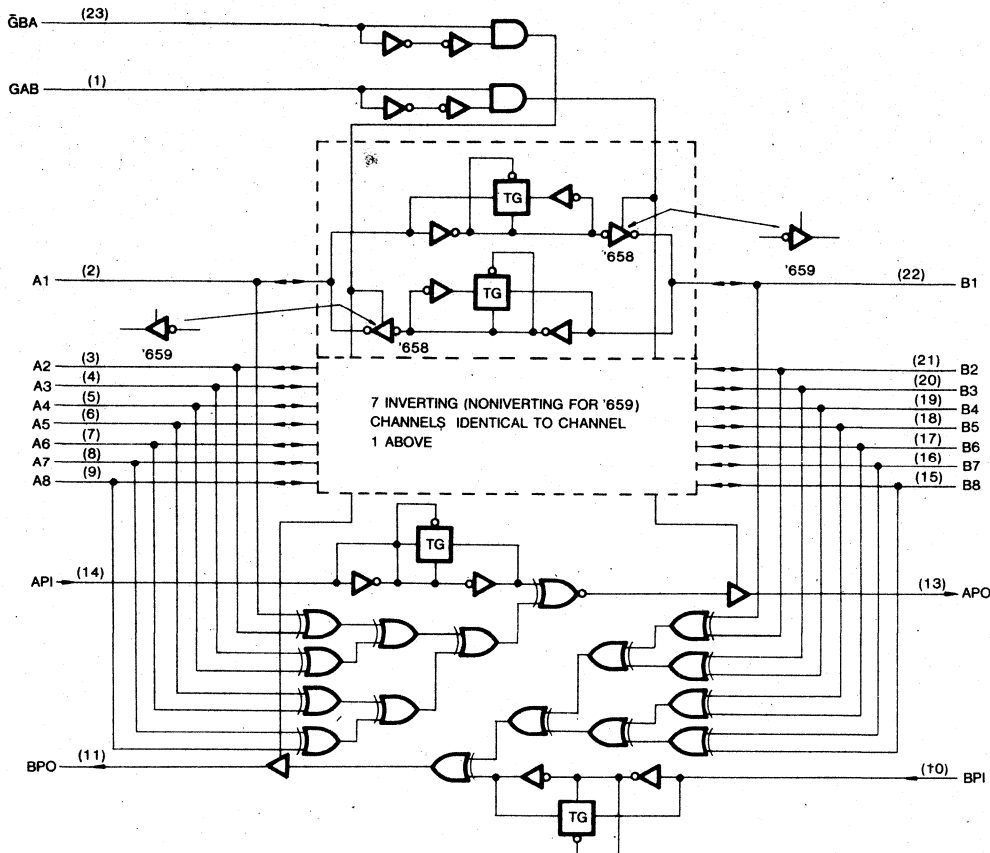
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLE

| CONTROL INPUTS | | NUMBER OF HIGH INPUTS ON A BUS AND API | NUMBER OF HIGH INPUTS ON B BUS AND BPI | OUTPUTS | | OPERATION | |
|----------------|-----|--|--|---------|-----|---|-------------------------------------|
| $\bar{G}BA$ | GAB | | | APO | BPO | '658 | '659 |
| L | L | X | 0, 2, 4, 6, 8 | Z | H | \bar{B} Data to A Bus | B Data to A Bus |
| | | X | 1, 3, 5, 7, 9 | Z | L | | |
| H | H | 0, 2, 4, 6, 8 | X | H | Z | \bar{A} Data to B Bus | A Data to B Bus |
| | | 1, 3, 5, 7, 9 | X | L | Z | | |
| H | L | X | X | Z | Z | Isolation | Isolation |
| L | H | X | 0, 2, 4, 6, 8 | | H | \bar{B} Data to A Bus, \bar{A} Data to B Bus | B Data to A Bus, A Data to B Bus |
| | | X | 1, 3, 5, 7, 9 | | L | | |
| | | 0, 2, 4, 6, 8 | X | | H | | |
| | | 1, 3, 5, 7, 9 | X | | L | | |

LOGIC DIAGRAM



Absolute Maximum Ratings*

| | |
|--|-----------------|
| Supply Voltage Range V_{CC} , | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 70 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

| | |
|----------------------|------------------------------|
| Plastic Package (N): | -12mW/°C from 65°C to 85°C |
| Ceramic Package (J): | -12mW/°C from 100°C to 125°C |

Recommended Operating Conditions

| | |
|--|---------------------------|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN} , V_{OUT} .. | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74AHCT: -40°C to +85°C |
| | KS54AHCT: -55°C to +125°C |
| Input Rise & Fall Times, t_r , t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS (V_{CC}=5V±10% Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | T _a = 25°C | | | | Unit |
|--------------------------------------|------------------|---|---------------------------------|------------------------------|----------------------------------|-----------------------------|------|
| | | | KS74AHCT | | KS54AHCT | | |
| | | | T _a = -40°C to +85°C | | T _a = -55°C to +125°C | | |
| | | | Guaranteed Limits | | | | |
| | | | Typ | | | | |
| Minimum High-Level Input Voltage | V _{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V _{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V _{OH} | V _{IN} =V _{IH} or V _{IL} I _O =-20μA I _O =-6mA | V _{CC} 4.2 | V _{CC} -0.1 3.98 | V _{CC} -0.1 3.84 | V _{CC} -0.1 3.7 | V |
| Maximum Low-Level Output Voltage | V _{OL} | V _{IN} =V _{IH} or V _{IL} I _O =20μA I _O =12mA I _O =24mA | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I _{IN} | V _{IN} =V _{CC} or GND | | ±0.1 | ±1.0 | ±1.0 | μA |
| Maximum 3-State Leakage Current | I _{OZ} | Output Enable = V _{IH} V _{OUT} =V _{CC} or GND | | ±0.5 | ±5.0 | ±10.0 | μA |
| Maximum Quiescent Supply Current | I _{CC} | V _{IN} =V _{CC} or GND I _{OUT} =0μA | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI _{CC} | per input pin V _I =2.4V other Inputs: at V _{CC} or GND I _{OUT} =0μA | | 2.7 | 2.9 | 3.0 | mA |

4

AC ELECTRICAL CHARACTERISTICS (Input t_r, t_f ≤ 2 ns, AHCT658, AHCT659)

| Characteristic | Symbol | Conditions† | T _a = 25°C | | | | Unit | |
|---|------------------|-----------------------|---------------------------------|-----|----------------------------------|-----|------|----|
| | | | KS74AHCT | | KS54AHCT | | | |
| | | | T _a = -40°C to +85°C | | T _a = -55°C to +125°C | | | |
| | | | V _{CC} = 5.0V | | V _{CC} = 5.0V ± 10% | | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, A or B to B or A | t _{PLH} | C _L =50pF | 11 | | 18 | | 22 | ns |
| | | C _L =150pF | 14 | | 27 | | 33 | |
| | t _{PHL} | C _L =50pF | 11 | | 18 | | 22 | ns |
| | | C _L =150pF | 14 | | 27 | | 33 | |
| Propagation Delay, A or B to APO or BPO | t _{PLH} | C _L =50pF | 16 | | 27 | | 32 | ns |
| | | C _L =150pF | 19 | | 36 | | 43 | |
| | t _{PHL} | C _L =50pF | 16 | | 27 | | 32 | ns |
| | | C _L =150pF | 19 | | 36 | | 43 | |
| Propagation Delay, API or BPI to APO or BPO | t _{PLH} | C _L =50pF | 11 | | 18 | | 22 | ns |
| | | C _L =150pF | 14 | | 27 | | 33 | |
| | t _{PHL} | C _L =50pF | 11 | | 18 | | 32 | ns |
| | | C _L =150pF | 14 | | 27 | | 33 | |
| Enable Time, GAB or GBA to APO or BPO | t _{PZH} | R _L =1kΩ | C _L =50pF | | 16 | | 27 | ns |
| | | | C _L =150pF | | 22 | | 36 | |
| | t _{PZL} | C _L =50pF | | 16 | | 27 | 32 | |
| | | C _L =150pF | | 22 | | 36 | 43 | |
| Disable Time, GAB or GBA to APO or BPO | t _{PLZ} | R _L =1kΩ | | 16 | | 27 | 32 | ns |
| | t _{PHZ} | C _L =50pF | | 16 | | 27 | 32 | |
| Input Capacitance | C _{IN} | | 5 | | | | pF | |
| Output Capacitance | C _{OUT} | | | | | | pF | |
| Power Dissipation Capacitance* | C _{PD} | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: P_D=C_{PD} V_{CC}² f + I_{CC} V_{CC}.

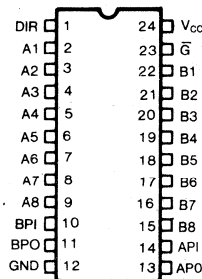
† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Bus Transceivers with Inverting Outputs ('664) or True Outputs ('665)
- Generates a Parity Bit for A Bus and B Bus
- Easily Cascadable
- Internal Active Pull-Ups and Pull-Downs
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^\circ\text{C}$
KS54AHCT: -55°C to $+125^\circ\text{C}$

PIN CONFIGURATION



FUNCTION TABLE

| CONTROL INPUTS | | NUMBER OF HIGH INPUTS ON A BUS AND API | NUMBER OF HIGH INPUTS ON B BUS AND BPI | OUTPUTS | | OPERATION | |
|----------------|-----|--|--|---------|-----|-------------------------|-----------------|
| \bar{G} | DIR | | | APO | BPO | '664 | '665 |
| L | L | X | 0, 2, 4, 6, 8 | Z | H | \bar{B} Data to A Bus | B Data to A Bus |
| L | L | X | 1, 3, 5, 7, 9 | Z | L | \bar{A} Data to B Bus | A Data to B Bus |
| L | H | 0, 2, 4, 6, 8 | X | H | Z | \bar{A} Data to B Bus | A Data to B Bus |
| L | H | 1, 3, 5, 7, 9 | X | L | Z | \bar{A} Data to B Bus | A Data to B Bus |
| H | X | X | X | Z | Z | Isolation | Isolation |

DESCRIPTION

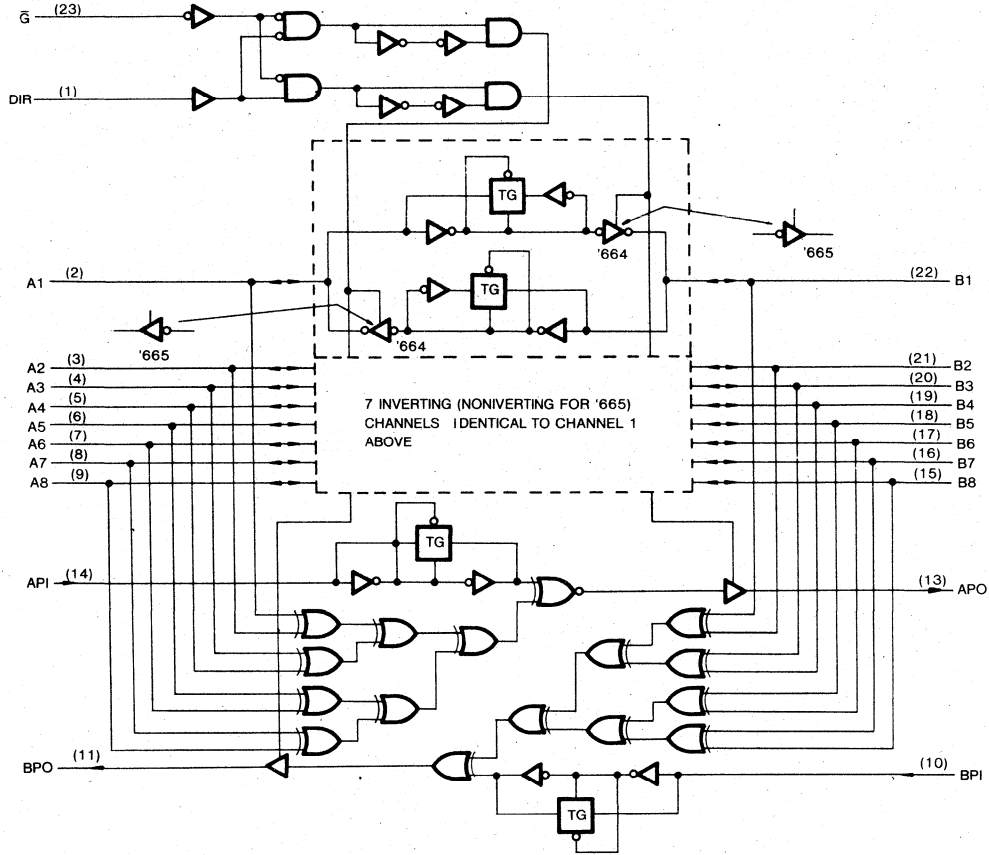
These octal bus transceivers are designed for asynchronous, bidirectional communication between data buses. The devices transmit data from the A Bus to the B Bus or from the B Bus to the A Bus, depending on the level at the direction control input, DIR. The enable input, \bar{G} , can be used to disable the device so that the buses are isolated. These devices will also generate parity outputs, APO and BPO, which reflect the number of high levels at the A Bus and B Bus, respectively, taking into account the parity inputs API and BPI.

The bidirectional I/O ports feature active circuitry on the input stage that, when the output shared by that pin is disabled, will maintain the input in the last state taken by the output. This state will be maintained until changed by the activity on the bus. The advantage of this arrangement is that when all outputs on the bus are disabled, the inputs will be prevented from floating, resulting in minimum power dissipation and minimum susceptibility to noise. This eliminates any need for external pull-up or pull-down resistors. The parity inputs API and BPI have similar circuitry.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAM



4

Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} , -0.5V to +7V
- DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
- DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
- Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
- Continuous Current Through
 V_{CC} or GND pins ± 250 mA
- Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
- Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

- † Power Dissipation temperature derating:
Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN} , V_{OUT} . . 0V to V_{CC}
- Operating Temperature
Range
KS74AHCT: $-40^\circ C$ to $+85^\circ C$
KS54AHCT: $-55^\circ C$ to $+125^\circ C$
- Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V\pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|---|--------------------------|----------------------|----------------------|---|---------------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT664, AHCT665

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ Typ | KS74AHCT | | KS54AHCT | | Unit |
|--|-----------|--|---|--|----------|---|----------|------|
| | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | | Min | Max | Min | Max | |
| Propagation Delay, A or B to B or A | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 11 14 | | 18 27 | | 22 33 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 11 14 | | 18 27 | | 22 33 | ns |
| Propagation Delay, A or B to APO or BPO | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 16 19 | | 27 36 | | 32 43 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 16 19 | | 27 36 | | 32 43 | ns |
| Propagation Delay, API or BPI to APO or BPO | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 11 14 | | 18 27 | | 22 33 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 11 14 | | 18 27 | | 32 33 | ns |
| Output Enable Time, G to A or B | t_{PZH} | $R_L = 1\text{k}\Omega$ $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 16 22 | | 27 36 | | 32 43 | ns |
| | t_{PZL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 16 22 | | 27 36 | | 32 43 | ns |
| Output Disable Time, G to A or B | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 16 | | 27 | | 32 | ns |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 16 | | 27 | | 32 | ns |
| Output Enable Time, DIR to A or B | t_{PZH} | $R_L = 1\text{k}\Omega$ $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 16 22 | | 27 36 | | 32 43 | ns |
| | t_{PZL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 16 22 | | 27 36 | | 32 43 | ns |
| Output Disable Time, DIR to A or B | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 16 | | 27 | | 32 | ns |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 16 | | 27 | | 32 | ns |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Output Capacitance | C_{OUT} | Output Disabled | | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

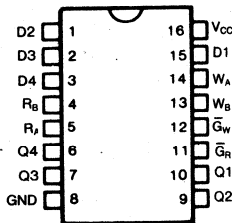
4

Preliminary Specifications

FEATURES

- Separate Read Write Addressing Permits Simultaneous Reading and Writing
- Expandable to 512 Words of 7-bits
- For use as:
 - Scratch pad memory
 - Buffer Storage between processors
 - Bit storage in fast multiplication designs
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with drive current ($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 - KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 - KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



FUNCTION TABLES

WRITE MODE SELECT TABLE

| OPERATING MODE | INPUTS | | INTERNAL LATCHES ^(a) |
|----------------|-------------|-------|---------------------------------|
| | \bar{G}_W | D_n | |
| Write Data | L | L | L |
| | L | H | H |
| Data Latched | H | X | no change |

NOTE:

- a. The Write Address (W_A and \bar{W}_B) to the "Internal Latches" must be stable while \bar{G}_W is LOW for conventional operation.

DESCRIPTION

The '670 is a 16-bit 3-State Register File organized as 4 words of 4 bits each. Separate Read and Write Address and enable inputs are available, permitting simultaneous writing into one word location and reading from another location. The 4-bit word to be stored is presented to four Data inputs. The Write Address inputs (W_A and W_B) determine the location of the stored word. When the Write Enable (\bar{G}_W) input is LOW, the data is entered into the addressed location. The addressed location remains transparent to the data while the \bar{G}_W is LOW. Data supplied at the inputs will be read out in true (non-inverting) form from the 3-State outputs. Data and Write Address inputs are inhibited when \bar{G}_W is HIGH.

Direct acquisition of data stored in any of the four registers is made possible by individual Read Address inputs (R_A and R_B). The addressed word appears at the four outputs when the Read Enable (\bar{G}_R) is LOW. Data outputs are in the HIGH impedance "off" state when the read enable input is HIGH. This permits outputs to be tied together to increase the word capacity to very large numbers.

Up to 128 devices can be stacked to increase the word size to 512 locations by tying the 3-State outputs together. Since the limiting factor for expansion is the output HIGH current, further stacking is possible by tying pull-up resistors to the outputs to increase the I_{OH} current available. Design of the read enable signals for the stacked devices must ensure that there is no overlap in the LOW levels which would cause more than one output to be active at the same time. Parallel expansion to generate n-bit words is accomplished by driving the enable and address inputs of each device in parallel.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

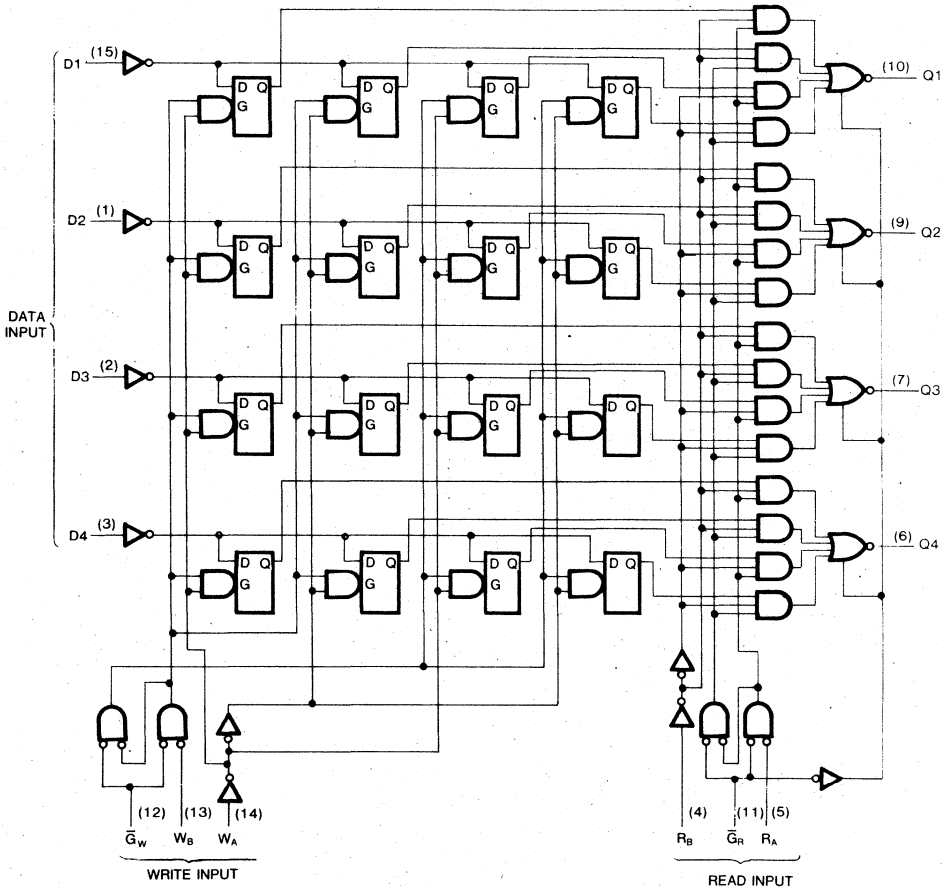
READ MODE SELECT TABLE

| OPERATING MODE | INPUTS | | OUTPUT Q_n |
|----------------|-------------|---------------------------------|--------------|
| | \bar{G}_R | INTERNAL LATCHES ^(b) | |
| Read | L | L | L |
| | L | H | H |
| Disabled | H | H | (Z) |

NOTE:

- b. The selection of the "internal latches" by Read Address (\bar{R}_A and R_B) are not constrained by \bar{G}_W or \bar{G}_R operation.

LOGIC DIAGRAM



4

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{STG} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN}, V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: $-40^\circ C$ to $+85^\circ C$
 KS54AHCT: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|---|--------------------------|----------------------|---|---------------------|--|---------------|------|
| | | | Typ | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | $V_{CC}-0.1$ 3.7 | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | 0.1 0.4 | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | ± 1.0 | μA | |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | ± 10.0 | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | 160.0 | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | 3.0 | mA | |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns, AHCT670)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--|-----------|-----------------------|--------------------------|---|-----|--|-----|------|
| | | | $V_{CC}=5.0\text{V}$ | $V_{CC}=5.0\text{V} \pm 10\%$ | | $V_{CC}=5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Propagation Delay, R_A or R_B to Output | t_{PLH} | $C_L=50\text{pF}$ | 14 | 23 | 23 | 23 | ns | |
| | | $C_L=150\text{pF}$ | 17 | 32 | 32 | 39 | | |
| Propagation Delay, \bar{G}_W to Output | t_{PLH} | $C_L=50\text{pF}$ | 14 | 23 | 23 | 28 | ns | |
| | | $C_L=150\text{pF}$ | 17 | 32 | 32 | 39 | | |
| Propagation Delay, Data to Output | t_{PHL} | $C_L=50\text{pF}$ | 15 | 25 | 25 | 30 | ns | |
| | | $C_L=150\text{pF}$ | 18 | 34 | 34 | 41 | | |
| Output Enable Time \bar{G}_R to Output | t_{PZH} | $C_L=50\text{pF}$ | 13 | 21 | 21 | 25 | ns | |
| | | $C_L=150\text{pF}$ | 19 | 30 | 30 | 36 | | |
| Output Disable Time \bar{G}_R to Output | t_{PZL} | $C_L=50\text{pF}$ | 13 | 21 | 21 | 25 | ns | |
| | | $C_L=150\text{pF}$ | 19 | 30 | 30 | 36 | | |
| Input Capacitance | C_{IN} | $R_L=1\text{k}\Omega$ | 17 | 28 | 28 | 34 | pF | |
| | | $C_L=150\text{pF}$ | 17 | 28 | 28 | 39 | | |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- '679: 12-bit to 4-bit comparator with enable
- '680: 12-bit to 4-bit comparator with latch
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

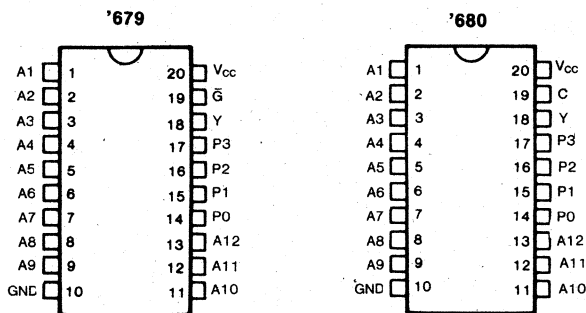
The '679 and '680 address comparators simplify addressing of memory boards and/or other peripheral devices. The four P inputs are normally hard wired with a preprogrammed address. An internal decoder determines what input information applied to the 12 A inputs must be low or high to cause a low state at the output (Y). For example, a positive-logic bit combination of 0111 (decimal 7) at the P input determines that inputs A1 through A7 must be low and that inputs A8 through A12 must be high to cause the output to go low. Equality of the address applied at the A inputs to the preprogrammed address is indicated by the output being low.

The '679 features an enable input (\bar{G}). When \bar{G} is low, the device is enabled. When \bar{G} is high, the device is disabled and the output is high regardless of the A and P inputs. The '680 features a transparent latch and a latch enable input (C). When C is high, the device is in the transparent mode. When C is low, the previous logical state of Y is latched.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode-clamps to V_{CC} and ground.

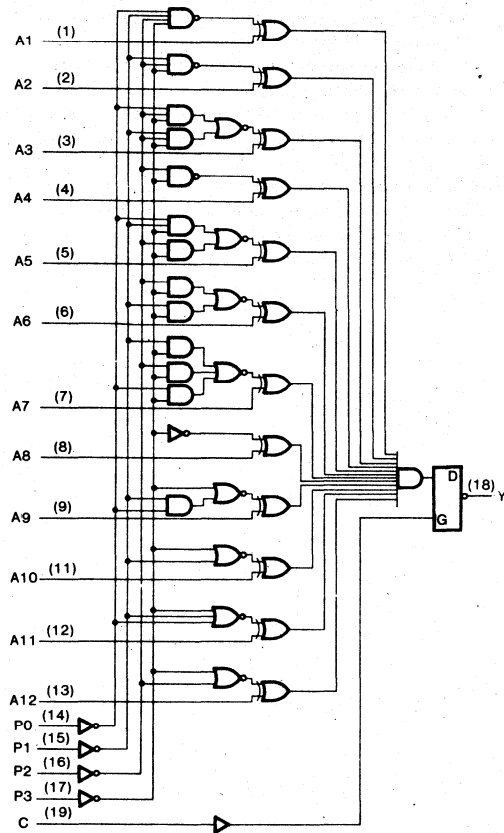
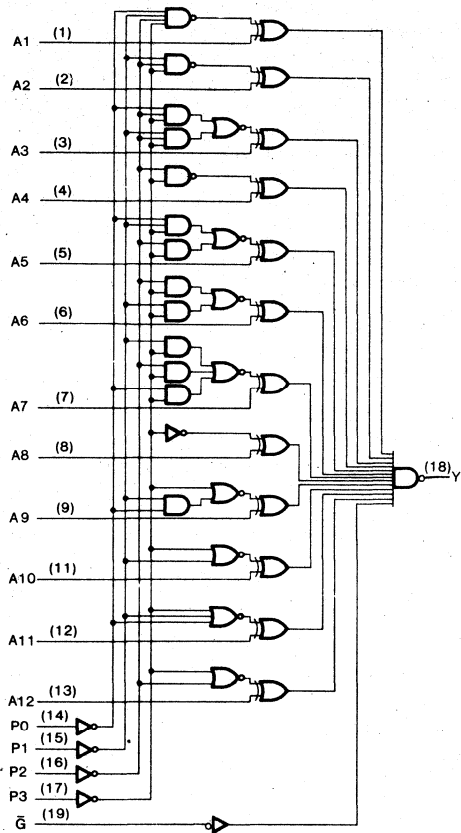
PIN CONFIGURATIONS



LOGIC DIAGRAMS

'679

'680



DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|---|--------------------------|----------------------|---|-------------------|--|-------------------|------|
| | | | Typ | Guaranteed Limits | Typ | Guaranteed Limits | Typ | Guaranteed Limits | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | | $V_{CC}-0.1$ 3.7 | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | | 0.1 0.4 | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | | ± 1.0 | μA | |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | | ± 10.0 | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | | 160.0 | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4\text{V}$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | | 3.0 | mA | |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2\text{ ns}$, AHCT679)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|----------------------------------|-----------|---|--------------------------|---|----------|--|----------|-------------|
| | | | $V_{CC}=5.0\text{V}$ | $V_{CC}=5.0\text{V} \pm 10\%$ | | $V_{CC}=5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, Any P to Y | t_{PLH} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 18 21 | | 30 35 | | 36 47 | ns |
| | t_{PHL} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 18 27 | | 30 39 | | 36 47 | |
| Propagation Delay, Any A to Y | t_{PLH} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 16 19 | | 26 35 | | 31 42 | ns |
| | t_{PHL} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 16 19 | | 26 35 | | 31 42 | |
| Propagation Delay, G to Y | t_{PLH} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 12 15 | | 19 27 | | 23 34 | ns |
| | t_{PHL} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 12 15 | | 19 27 | | 23 34 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT680

| Characteristic | Symbol | Conditions [†] | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|----------------------------------|-----------|-------------------------|--------------------------|---|--|---------------------------------|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, Any P to Y | t_{PLH} | $C_L = 50\text{pF}$ | 21 | | 35 | | 42 | ns |
| | | $C_L = 150\text{pF}$ | 24 | | 44 | | 53 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 21 | | 35 | | 42 | ns |
| | | $C_L = 150\text{pF}$ | 24 | | 44 | | 53 | |
| Propagation Delay, Any A to Y | t_{PLH} | $C_L = 50\text{pF}$ | 18 | | 30 | | 36 | ns |
| | | $C_L = 150\text{pF}$ | 21 | | 39 | | 42 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 18 | | 30 | | 36 | ns |
| | | $C_L = 150\text{pF}$ | 21 | | 39 | | 47 | |
| Propagation Delay, C to Y | t_{PLH} | $C_L = 50\text{pF}$ | 13 | | 21 | | 25 | ns |
| | | $C_L = 150\text{pF}$ | 16 | | 30 | | 36 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 13 | | 21 | | 25 | ns |
| | | $C_L = 150\text{pF}$ | 16 | | 30 | | 36 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

[†] For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Compares Two 8-Bit Words
- '682 has 20kΩ pullup Resistors on the Q Inputs
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

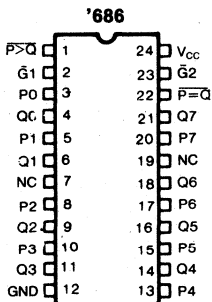
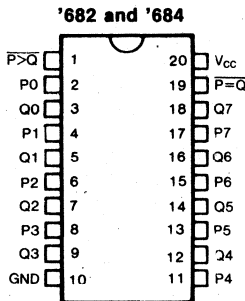
DESCRIPTION

These magnitude comparators perform comparisons of two eight-bit binary or BCD words. All types provide $\overline{P=Q}$ and $\overline{P>Q}$ outputs. The '682 features 20-kΩ pullup termination resistors on the Q inputs for analog or switch data.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATIONS



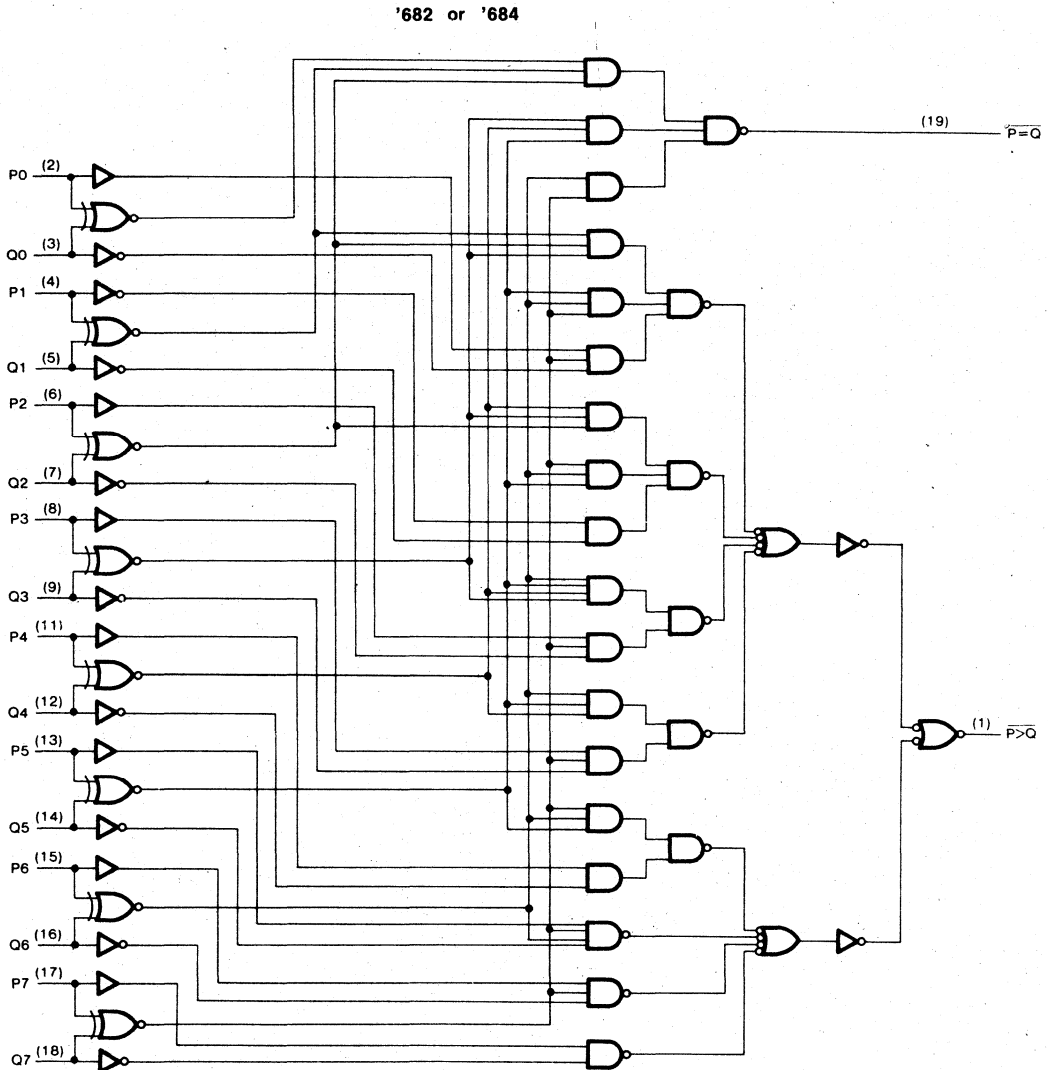
NC—No internal connection

FUNCTION TABLE

| DATA | INPUTS | | OUTPUTS | |
|-------|-----------------|-----------------|------------------|------------------|
| | $\overline{G1}$ | $\overline{G2}$ | $\overline{P=Q}$ | $\overline{P>Q}$ |
| P = Q | L | X | L | H |
| P > Q | X | L | H | L |
| P < Q | X | X | H | H |
| P = Q | H | X | H | H |
| P > Q | X | H | H | H |
| X | H | H | H | H |

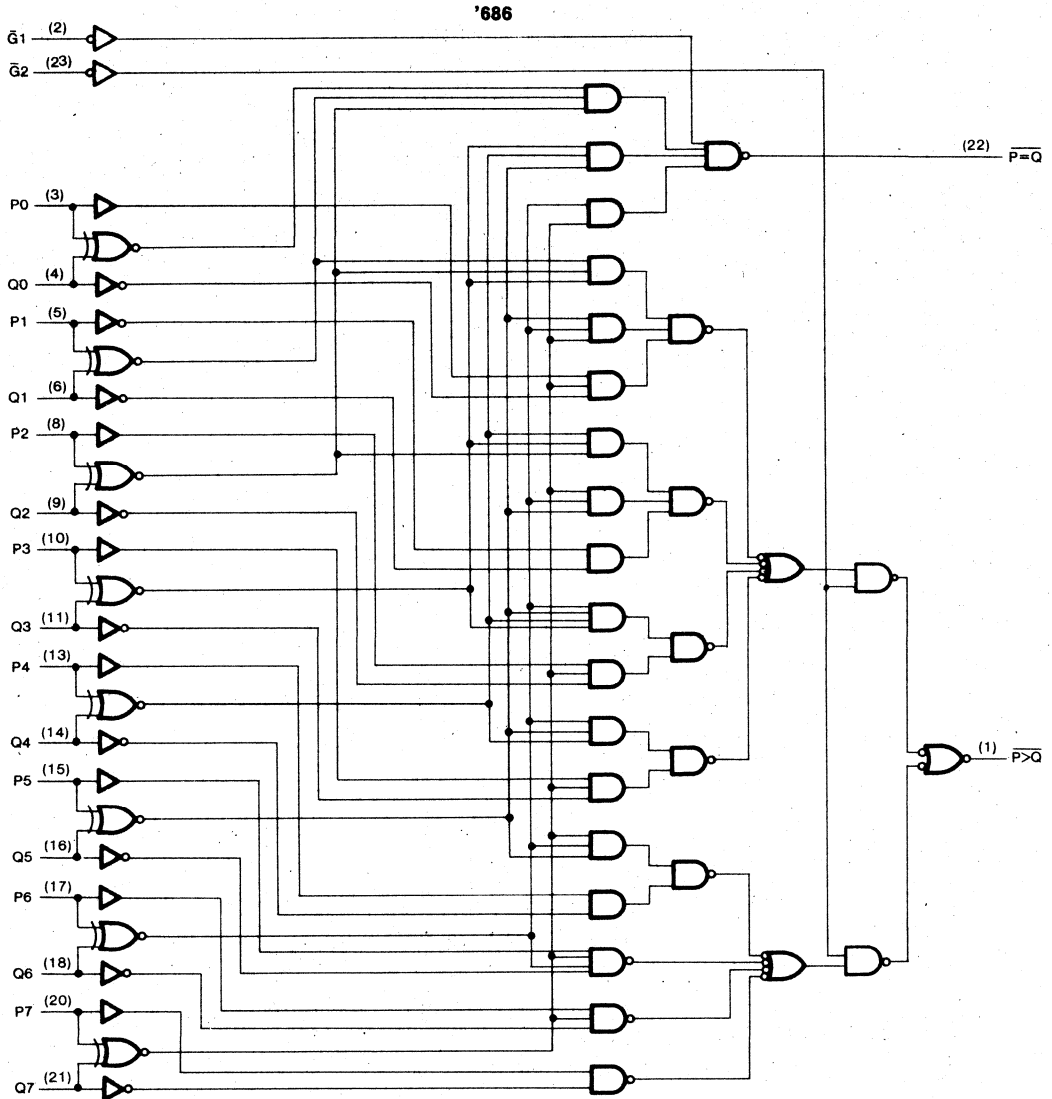
- NOTES:
1. The last 3 lines of the function table apply only to the device having enable inputs, i.e., '686.
 2. The $\overline{P<Q}$ function can be generated by applying the $\overline{P=Q}$ and $\overline{P>Q}$ outputs to a 2-input NAND gate.

LOGIC DIAGRAMS



4

LOGIC DIAGRAMS (continued)



Absolute Maximum Ratings*

| | | |
|--|-------|-----------------|
| Supply Voltage Range V_{CC} | | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | | ± 20 mA |
| DC Output Diode Current, I_{OK} | | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | | ± 20 mA |
| Continuous Output Current Per Pin, I_O | | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | | ± 35 mA |
| Continuous Current Through | | |
| V_{CC} or GND pins | | ± 125 mA |
| Storage Temperature Range, T_{stg} | | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

| | |
|----------------------|------------------------------|
| Plastic Package (N): | -12mW/°C from 65°C to 85°C |
| Ceramic Package (J): | -12mW/°C from 100°C to 125°C |

Recommended Operating Conditions

| | |
|--|---------------------------|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74AHCT: -40°C to +85°C |
| | KS54AHCT: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Parameter | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | 54AHCT | Unit |
|--|-----------------|--|--------------------------|------------------------|---|--|---------------|
| | | | Typ | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | |
| | | | | | Guaranteed Limits | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage (Totem-pole Outputs) | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.93 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage (All Outputs) | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current, ('682 Q Inputs) | | $V_{CC}=\text{Max}$ $V_{IN}=2.7V$ $V_{IN}=0.4V$ | | -0.2 -0.4 | -0.2 -0.4 | -0.2 -0.4 | mA |
| Maximum Input Current (All other Inputs) | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | For '682: $V_{IN}=\text{GND}$ (Q0-Q7) $V_{IN}=V_{CC}$ or GND (all other inputs) | | 3.5 | 3.5 | 3.5 | mA |
| | | For '684 and '688 $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT682, AHCT684, AHCT686

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|---|-----------|----------------------|--------------------------|---|-----|--|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Propagation Delay, P or Q to $\bar{P}=Q$ | t_{PLH} | $C_L = 50\text{pF}$ | 13 | | 22 | | 27 | ns |
| | | $C_L = 150\text{pF}$ | 16 | | 31 | | 38 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 13 | | 22 | | 27 | ns |
| | | $C_L = 150\text{pF}$ | 16 | | 31 | | 38 | |
| Propagation Delay, P or Q to $\bar{P}>Q$ | t_{PLH} | $C_L = 50\text{pF}$ | 16 | | 27 | | 32 | ns |
| | | $C_L = 150\text{pF}$ | 19 | | 36 | | 43 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 16 | | 27 | | 32 | ns |
| | | $C_L = 150\text{pF}$ | 19 | | 36 | | 43 | |
| Propagation Delay, G1 to $\bar{P}=Q$ ('686 Only) | t_{PLH} | $C_L = 50\text{pF}$ | 10 | | 16 | | 19 | ns |
| | | $C_L = 150\text{pF}$ | 13 | | 25 | | 30 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 10 | | 16 | | 19 | ns |
| | | $C_L = 150\text{pF}$ | 13 | | 25 | | 30 | |
| Propagation Delay, G2 to $\bar{P}<Q$ ('686 Only) | t_{PLH} | $C_L = 50\text{pF}$ | 11 | | 19 | | 23 | ns |
| | | $C_L = 150\text{pF}$ | 14 | | 28 | | 34 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 11 | | 19 | | 23 | ns |
| | | $C_L = 150\text{pF}$ | 14 | | 28 | | 34 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Compares Two 8-Bit Words
- Choice of Totem-pole ('688) and open-drain ('689) outputs ('686 is identical to '521)
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High output drive
 ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

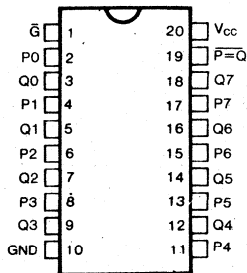
DESCRIPTION

These identity comparators perform comparisons of two 8-bit binary or BCD words. The outputs of the '688 are totempole, while '688's are open-drain.

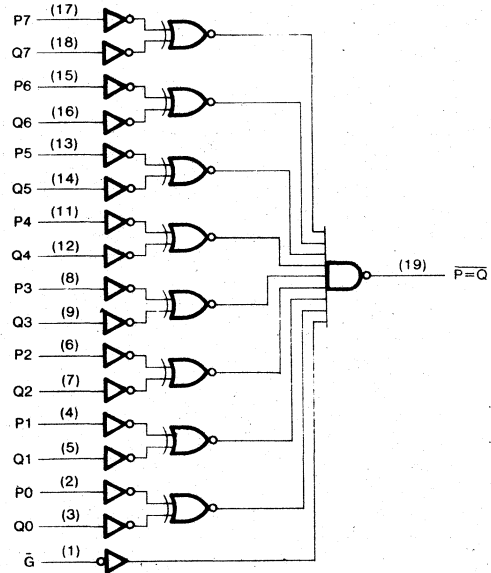
These devices provide speed^o and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

| INPUTS | | OUTPUT |
|--------|----------------|------------------|
| DATA | ENABLE | $\overline{P=Q}$ |
| P, Q | \overline{G} | |
| P=Q | L | L |
| P>Q | L | H |
| P<Q | L | H |
| X | H | H |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN}, V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | | Unit |
|---|-----------------|--|--|----------------------|---|---------------------|---------|
| | | | Typ | Guaranteed Limits | | | |
| | | | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ | | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage ('688 only) | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-6mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=12mA$ $I_O=24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Output Leakage Current ('689 only) | I_{OZ} | $V_{IN}=V_{IH}$ or V_{IL} $V_{OUT}=V_{CC}$ | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns, AHCT688)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|--|-----------|---|--|--|----------|---|----------|------|
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, P to $\bar{P}=Q$ | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 12 15 | | 19 28 | | 23 34 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 12 15 | | 19 28 | | 23 34 | |
| Propagation Delay, Q to $\bar{P}=Q$ | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 12 15 | | 19 28 | | 23 34 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 12 15 | | 19 28 | | 23 34 | |
| Propagation Delay, \bar{G} to $\bar{P}=Q$ | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 11 14 | | 17 26 | | 20 31 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 11 14 | | 17 26 | | 20 31 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns, AHCT689)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|--|-----------|---|--|--|----------|---|----------|------|
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay, P to $\bar{P}=Q$ | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 19 29 | | 28 38 | | 33 43 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 14 17 | | 23 20 | | 28 39 | |
| Propagation Delay, Q to $\bar{P}=Q$ | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 19 29 | | 28 38 | | 33 43 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 14 17 | | 23 27 | | 28 39 | |
| Propagation Delay, \bar{G} to $\bar{P}=Q$ | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 16 26 | | 23 33 | | 27 37 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 11 16 | | 18 27 | | 22 33 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

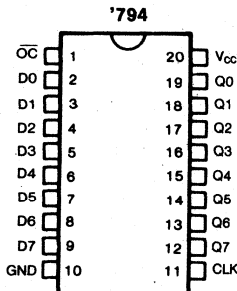
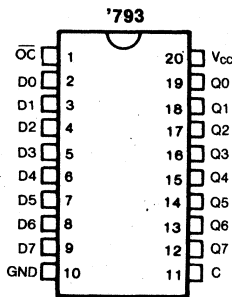
† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- I/O port configuration enables output data back onto input bus
- Latch ('793) and Register ('794) options
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATIONS



DESCRIPTION

These are 8-bit latches/registers that allow temporary storage and retrieval of data on a bus. This operation is important in control algorithms which make decisions based on the previous status of output controls. Rather than storing a redundant copy of the output data in memory, simply reading the register as an I/O port allows the data to be retrieved from where it has been stored in a '793 or '794, for verification and/or updating.

The Data is loaded in the registers on the positive-edge of the clock (CLK) for the '794. The data is passed through the '793 when C is high, and it is latched when C goes low. The output control (\overline{OC}) is used to enable data on the D0-D7 pins. when \overline{OC} is low the output of the latches/registers is enabled on D0-D7, enabling D as an output bus so that the host can perform a read operation. When \overline{OC} is high, D0-D7 are inputs to the latches/registers configuring D as an input bus.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLES

'793

| C | \overline{OC} | Q | D |
|----|-----------------|------------|---------------|
| L | L | Q_0^{**} | Output, Q |
| L | H | Q_0^{**} | Input |
| H† | L | D^* | Output, Q^* |
| H | H | D | Input |

* In this case the output of the latch feeds the input, and a "race" condition results.

** Q_0 represents the previous "latched" state.

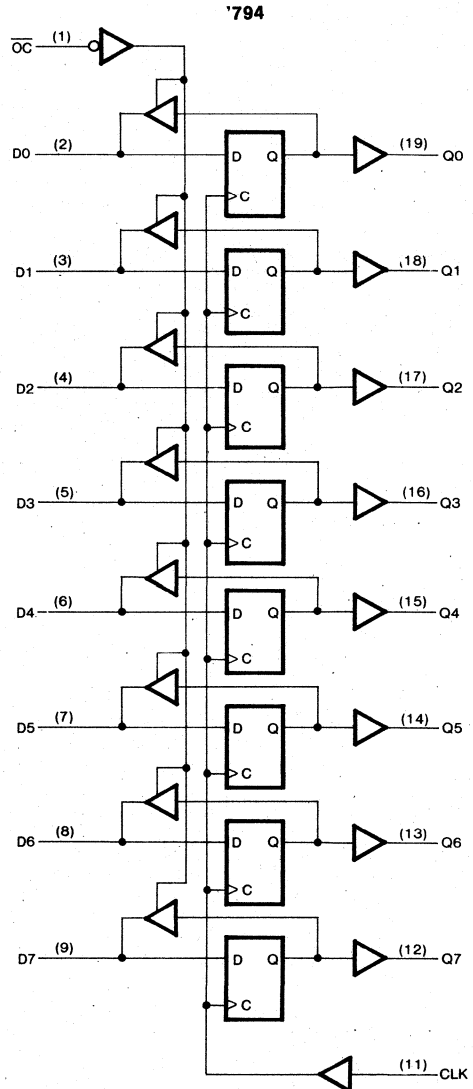
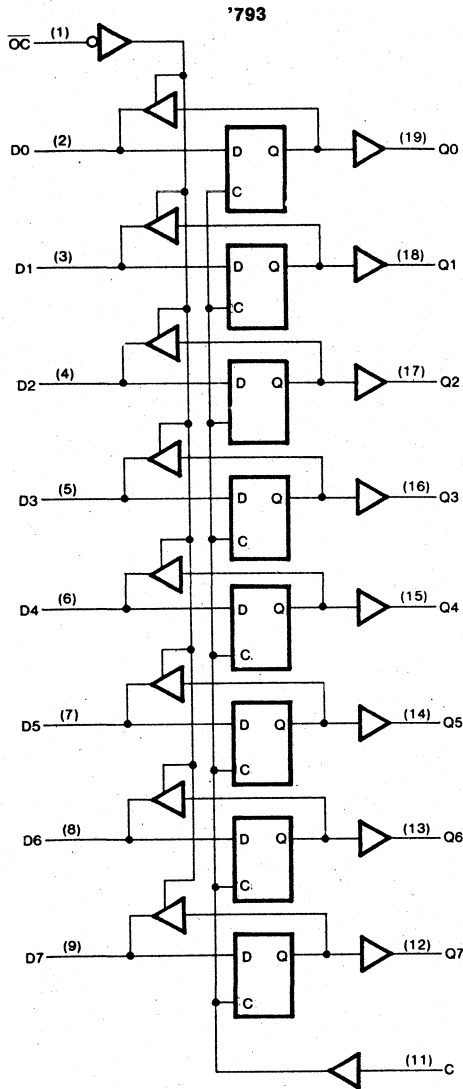
† This transition is not a normal mode of operation and may produce hazards.

'794

| CLK | \overline{OC} | Q | D |
|-------------|-----------------|-------|---------------|
| L or H or ↓ | L | Q_0 | Output, Q |
| L or H or ↓ | H | Q_0 | Input |
| ↑ | L | Q_0 | Output, Q^* |
| ↑ | H | D | Input |

* In this case the output of the register is clocked to the inputs and the overall Q output is unchanged at Q_0 .

LOGIC DIAGRAMS



Absolute Maximum Ratings*

| | |
|--|-----------------|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 70 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74AHCT: -40°C to +85°C KS54AHCT: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|---|--|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT793, AHCT794

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit |
|---|-----------|-------------------------------|--------------------------|---|-----|--|-----|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Maximum Operating Frequency ('794 only) | t_{max} | $C_L = 50\text{pF}$ | 60 | 40 | | 35 | | MHz |
| Propagation Delay D to Any Q ('793 only) | t_{PLH} | $C_L = 50\text{pF}$ | 10 | | 16 | | 19 | ns |
| | | $C_L = 150\text{pF}$ | 13 | | 25 | | 30 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 13 | | 16 | | 19 | ns |
| | | $C_L = 150\text{pF}$ | 13 | | 25 | | 30 | |
| Propagation Delay CLK/C to Any Q | t_{PLH} | $C_L = 50\text{pF}$ | 12 | | 20 | | 24 | ns |
| | | $C_L = 150\text{pF}$ | 15 | | 29 | | 35 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 12 | | 20 | | 24 | ns |
| | | $C_L = 150\text{pF}$ | 15 | | 29 | | 35 | |
| Enable Time, \overline{OC} to D | t_{PZH} | $R_L = 1\text{k}\Omega$ | 11 | | 18 | | 22 | ns |
| | | $C_L = 150\text{pF}$ | 17 | | 27 | | 33 | |
| | t_{PZL} | $C_L = 50\text{pF}$ | 11 | | 18 | | 22 | ns |
| | | $C_L = 150\text{pF}$ | 13 | | 18 | | 22 | |
| Disable Time \overline{OC} to D | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 11 | | 18 | | 22 | ns |
| | | $C_L = 50\text{pF}$ | 11 | | 18 | | 22 | |
| | t_{PLZ} | $C = \text{Low for '793}$ | 11 | | 18 | | 22 | ns |
| Pulse Width, CLK/C High or low | t_w | | 9 | 14 | | 19 | | ns |
| Setup time | t_{su} | D before $C\downarrow$ ('793) | 6 | 10 | | 12 | | ns |
| | | D before $CLK\uparrow$ ('794) | 10 | 15 | | 20 | | ns |
| Hold Time | t_h | D after $C\downarrow$ ('793) | 9 | 10 | | 12 | | ns |
| | | D after $CLK\uparrow$ ('794) | -3 | 0 | | 0 | | ns |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Output Capacitance | C_{OUT} | $\overline{OC} = \text{GND}$ | 10 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | ns |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.
† For AC switching test circuits and timing waveforms see section 2.

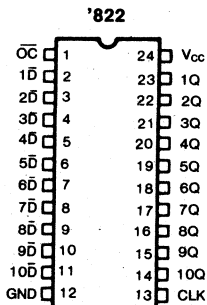
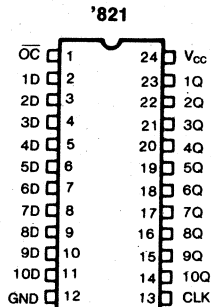


Preliminary Specifications

FEATURES

- Functionally Equivalent to AMD's Am29821 and Am29822
- Provides Extra Data Width Necessary for Wider Address/Data Paths or Buses with Parity
- Power-Up-High-Impedance State
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATIONS



DESCRIPTION

These 10-bit bus-interface flip-flops feature three-state outputs designed specifically for driving highly-capacitive or relatively low-impedance loads. They are suitable for implementing wider buffer registers, I/O ports, bidirectional bus drivers with parity, and working registers.

All of the flip-flops are edge-triggered and D-type. On the positive transition of the clock the Q outputs on the '821 will be true, and on the '822 will be complementary to the data input.

A buffered output-control input can be used to place the ten outputs in either a normal logic state (high or low levels) or a high-impedance state. The high-impedance state and increased drive provide the capability to drive the bus lines in a bus-organized system without need for interface or pull-up components. The output control (\overline{OC}) does not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLES

(Each Flip-Flop)

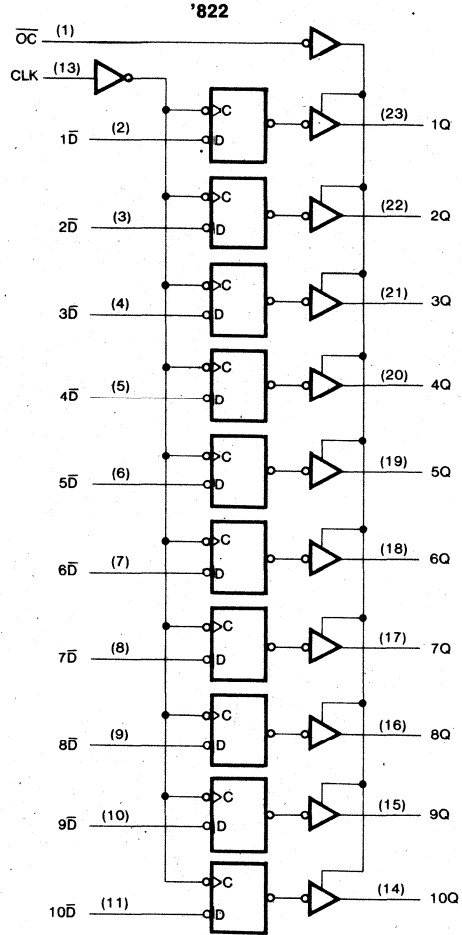
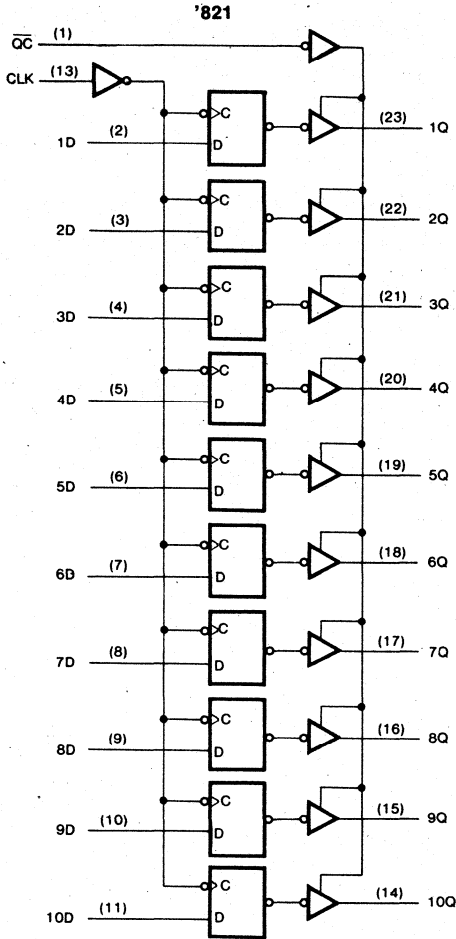
'821

| Inputs | | | Output |
|-----------------|------------|---|--------|
| \overline{OC} | CLK | D | Q |
| L | \uparrow | H | H |
| L | \uparrow | L | L |
| L | L | X | Q_0 |
| L | H | X | Q_0 |
| H | X | X | Z |

'822

| Inputs | | | Output |
|-----------------|------------|----------------|--------|
| \overline{OC} | CLK | \overline{D} | Q |
| L | \uparrow | H | L |
| L | \uparrow | L | H |
| L | L | X | Q_0 |
| L | H | X | Q_0 |
| H | X | X | Z |

LOGIC DIAGRAMS



4

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
Continuous Current Through
 V_{CC} or GND pins ± 250 mA
Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN} , V_{OUT} . . 0V to V_{CC}
Operating Temperature
Range
KS74AHCT: -40°C to $+85^\circ\text{C}$
KS54AHCT: -55°C to $+125^\circ\text{C}$
Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|--|---|-----------------------|-------------------|
| | | | Typ | KS74AHCT $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | KS54AHCT $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | Guaranteed Limits |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT821, AHCT822

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit | |
|---|-----------|--------------------------|--------------------------|---|-----|--|-----|------|----|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | | |
| | | | • Typ | Min | Max | Min | Max | | |
| Maximum Operating Frequency | f_{max} | $C_L = 50\text{pF}$ | 50 | 35 | | 30 | | MHz | |
| Propagation Delay CLK to any Q | t_{PLH} | $C_L = 50\text{pF}$ | 8 | | 14 | | 17 | ns | |
| | | $C_L = 150\text{pF}$ | 11 | | 23 | | 28 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 8 | | 14 | | 17 | ns | |
| | | $C_L = 150\text{pF}$ | 11 | | 23 | | 28 | | |
| Output Enable Time, OC to any Q | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 11 | | 18 | | 22 | ns |
| | | | $C_L = 150\text{pF}$ | 17 | | 27 | | 31 | |
| | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 11 | | 18 | | 22 | ns |
| | | | $C_L = 150\text{pF}$ | 17 | | 27 | | 31 | |
| Output Disable Time, OC to any Q | t_{PHZ} | $R_L = 1\text{k}\Omega$ | | 13 | | 18 | | 22 | ns |
| | | | $C_L = 50\text{pF}$ | 13 | | 18 | | 22 | |
| Pulse Width, CLK High or Low | t_w | | 9 | 15 | | 18 | | ns | |
| Setup Time, Data before CLK† | t_{su} | | 9 | 14 | | 17 | | ns | |
| Hold Time, Data after CLK† | t_h | | -3 | 0 | | 0 | | ns | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C_{PD} | $\overline{OC} = V_{CC}$ | 5 | | | | | pF | |
| | | $\overline{OC} = GND$ | 30 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

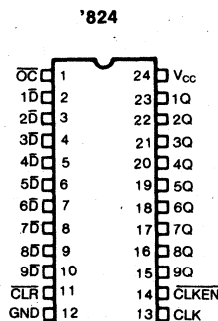
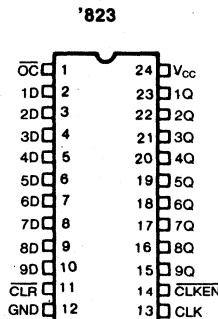
4

Preliminary Specifications

FEATURES

- Functionally Equivalent to AMD's Am29823 and Am29824
- Provides Extra Data Width Necessary for Wider Address/Data Paths or Buses with Parity
- Power-Up-High-Impedance State
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATIONS



DESCRIPTION

These 9-bit bus interface flip-flops feature three-state outputs designed specifically for driving highly-capacitive or relatively low-impedance loads. They are suitable for implementing wider buffer registers, I/O ports, bidirectional bus drivers, parity bus interfacing and working registers.

With the clock enable ($\overline{\text{CLKEN}}$) low, the D-type edge-triggered flip-flops enter data on the low-to-high transitions of the clock. Taking $\overline{\text{CLKEN}}$ high will disable the clock buffer, thus latching the outputs. The '823 has noninverting D inputs and the '824 has inverting $\overline{\text{D}}$ inputs. Taking the $\overline{\text{CLR}}$ input low causes the nine Q outputs to go low independently of the clock.

A buffered output-control input ($\overline{\text{OC}}$) can be used to place the ten outputs in either a normal logic state (high or low levels) or a high-impedance state. The high-impedance state and increased drive provide the capability to drive the bus lines in a bus-organized system without need for interface or pull-up components. The output control does not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLES

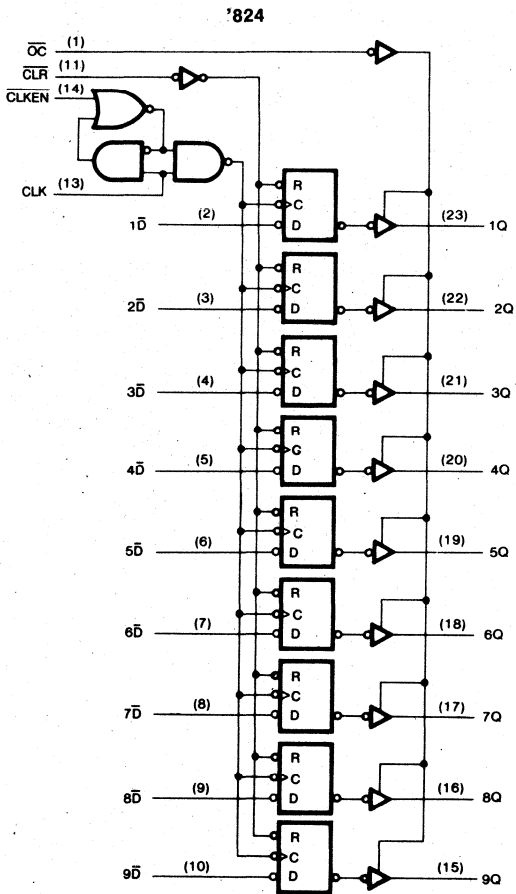
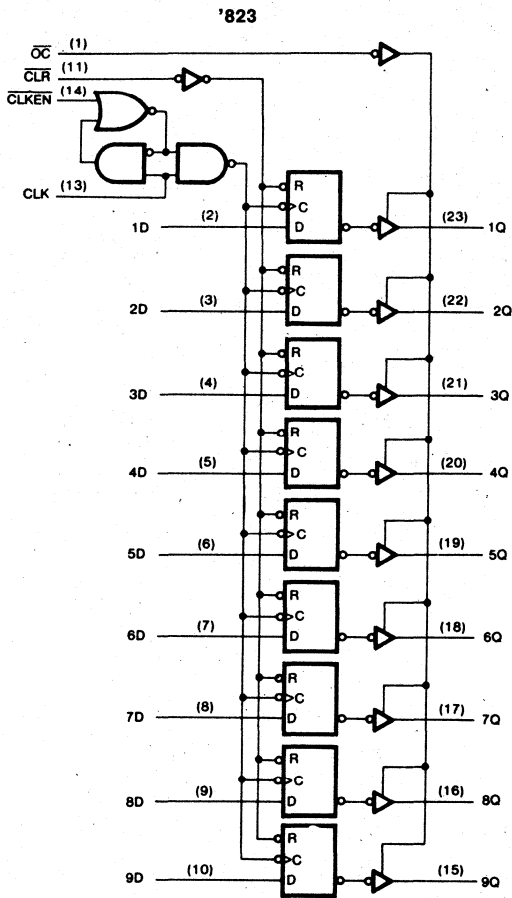
'823

| INPUT | | | | | OUTPUT |
|------------------------|-------------------------|---------------------------|------------|---|--------|
| $\overline{\text{OC}}$ | $\overline{\text{CLR}}$ | $\overline{\text{CLKEN}}$ | CLK | D | Q |
| L | L | X | X | X | L |
| L | H | L | \uparrow | H | H |
| L | H | L | \uparrow | L | L |
| L | H | H | X | X | Q_0 |
| H | X | X | X | X | Z |

'824

| INPUTS | | | | | OUTPUT |
|------------------------|-------------------------|---------------------------|------------|-----------------------|--------|
| $\overline{\text{OC}}$ | $\overline{\text{CLR}}$ | $\overline{\text{CLKEN}}$ | CLK | $\overline{\text{D}}$ | Q |
| L | L | X | X | X | L |
| L | H | L | \uparrow | H | H |
| L | H | L | \uparrow | L | L |
| L | H | H | X | X | Q_0 |
| H | X | X | X | X | Z |

LOGIC DIAGRAMS



4

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
Continuous Current Through
 V_{CC} or GND pins ± 250 mA
Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
Power Dissipation Per Package, P_d [†] 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

[†] Power Dissipation temperature derating:
Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN} , V_{OUT} . . . 0V to V_{CC}
Operating Temperature
Range KS74AHCT: -40°C to $+85^\circ\text{C}$
KS54AHCT: -55°C to $+125^\circ\text{C}$

Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|----------------------|---------------------|---------------|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT823, AHCT824

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit | |
|---|-----------|-------------------------------------|----------------------------------|--|-----|---|-----|------|----|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | | |
| | | | Typ | Min | Max | Min | Max | | |
| Maximum Operating Frequency | f_{max} | $C_L = 50\text{pF}$ | 50 | 35 | | 30 | | MHz | |
| Propagation Delay CLK to any Q | t_{PLH} | $C_L = 50\text{pF}$ | 8 | | 14 | | 17 | ns | |
| | | $C_L = 150\text{pF}$ | 11 | | 23 | | 28 | | |
| Propagation Delay, CLR to Any Q | t_{PHL} | $C_L = 50\text{pF}$ | 8 | | 14 | | 17 | ns | |
| | | $C_L = 150\text{pF}$ | 11 | | 23 | | 28 | | |
| Output Enable Time, OC to any Q | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 11 | | 18 | | 22 | ns |
| | | | $C_L = 150\text{pF}$ | 17 | | 27 | | 31 | |
| Output Disable Time, OC to any Q | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 11 | | 18 | | 22 | ns |
| | | | $C_L = 150\text{pF}$ | 17 | | 27 | | 31 | |
| Output Disable Time, OC to any Q | t_{PHZ} | $R_L = 1\text{k}\Omega$ | | 13 | | 18 | | 22 | ns |
| | | | $C_L = 50\text{pF}$ | 13 | | 18 | | 22 | |
| Pulse Width | t_w | | $\overline{\text{CLR}}$ low | 9 | 15 | | 18 | ns | |
| | | | CLK high or low | 9 | 15 | | 18 | | |
| Setup Time before CLK† | t_{su} | | $\overline{\text{CLR}}$ inactive | 9 | 14 | | 17 | ns | |
| | | | Data | 9 | 14 | | 17 | | |
| | | | CLKEN high or low | 9 | 14 | | 17 | | |
| Hold Time, CLKEN or data after CLK† | t_h | | -3 | 0 | | 0 | | ns | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C_{PD} | $\overline{\text{OC}} = V_{CC}$ | 5 | | | | | pF | |
| | | $\overline{\text{OC}} = \text{GND}$ | 30 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

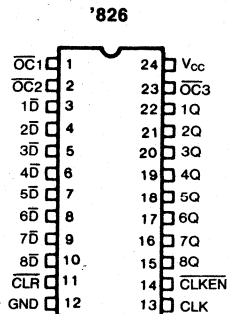
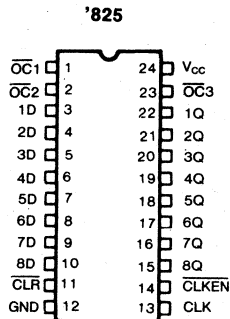
4

Preliminary Specifications

FEATURES

- Functionally Equivalent to AMD's Am29825 and Am29826
- Improved I_{OH} Specifications
- Multiple Output Enables Allow Multiuser Control of the Interface
- Power-Up High-Impedance State
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA}$ @ $V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATIONS



DESCRIPTION

These 8-bit flip-flops feature three-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are suitable for implementing multiuser buffer registers, I/O ports, bus drivers and working registers.

With the clock enable ($\overline{\text{CLKEN}}$) low, all D-type edge-triggered flip-flops enter data on the low-to-high transition of the clock. Taking $\overline{\text{CLKEN}}$ high will disable the clock buffer, thus latching the outputs. The '825 has non-inverting D inputs and the '826 has inverting $\overline{\text{D}}$ inputs. Taking the $\overline{\text{CLR}}$ inputs low causes the eight Q outputs to go low independently of the clock.

Multiuser buffered output-control inputs ($\overline{\text{OC1}}$, $\overline{\text{OC2}}$, and $\overline{\text{OC3}}$) can be used to place the eight outputs in either a normal logic state (high or low level) or a high-impedance state. The high-impedance state and increased drive provide the capability to drive the bus lines in a bus-organized system without need for interface or pull-up components. The output controls do not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

KS54AHCT 825/826 KS74AHCT

8-Bit Bus Interface Flip-Flops with 3-State Outputs

FUNCTION TABLES

'825

| Inputs | | | | | Output |
|--------|-----|-------|-----|---|----------------|
| OC* | CLR | CLKEN | CLK | D | Q |
| L | L | X | X | X | L |
| L | H | L | ↑ | X | H |
| L | H | L | ↑ | L | L |
| L | H | H | X | X | Q ₀ |
| H | X | X | X | X | Z |

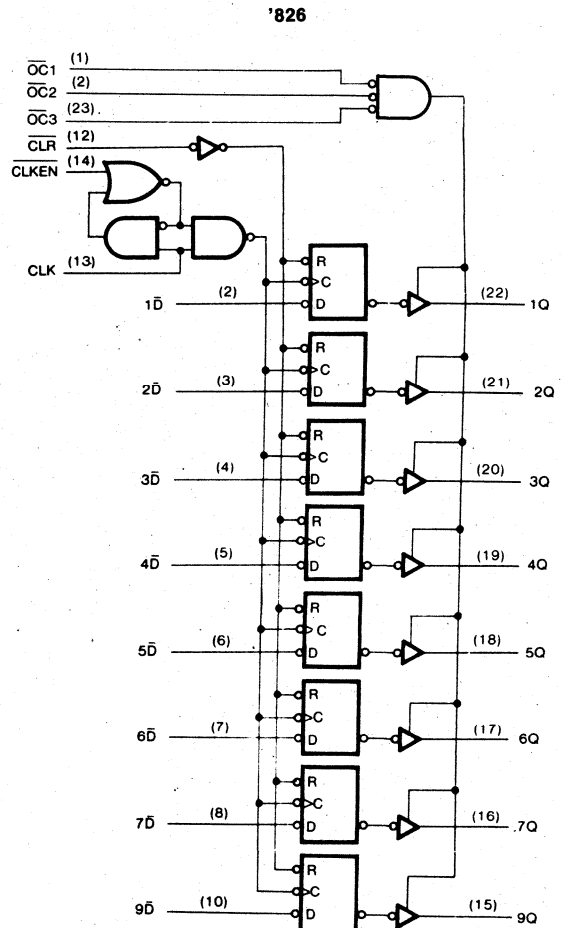
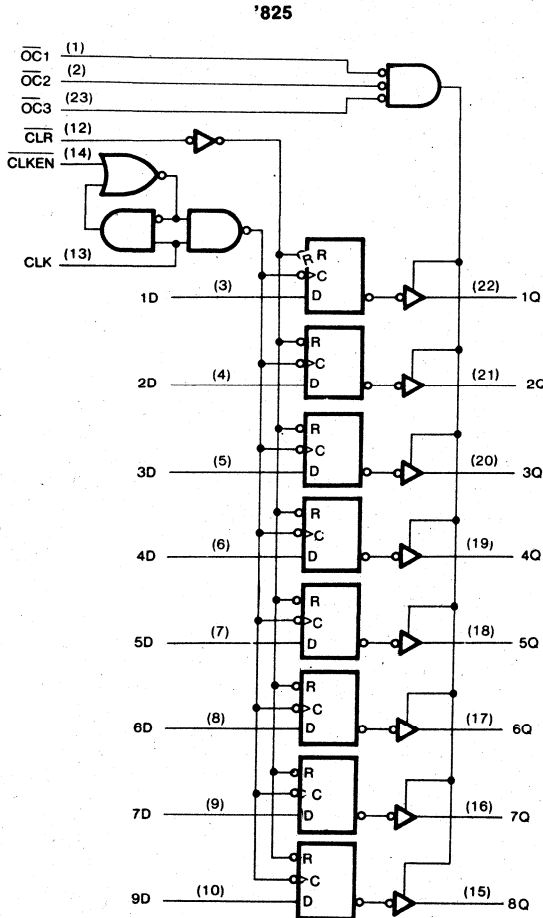
* OC = H if any of $\overline{OC1}$, $\overline{OC2}$, or $\overline{OC3}$ are high.
OC = L if all of $\overline{OC1}$, $\overline{OC2}$, and $\overline{OC3}$ are low.

'826

| Inputs | | | | | Output |
|--------|-----|-------|-----|----------------|----------------|
| OC* | CLR | CLKEN | CLK | \overline{D} | Q |
| L | L | X | X | X | L |
| L | H | L | ↑ | X | H |
| L | H | L | ↑ | L | L |
| L | H | H | X | X | Q ₀ |
| H | X | X | X | X | Z |

* OC = H if any of $\overline{OC1}$, $\overline{OC2}$, or $\overline{OC3}$ are high.
OC = L if all of $\overline{OC1}$, $\overline{OC2}$, and $\overline{OC3}$ are low.

LOGIC DIAGRAMS



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KS54AHCT 825/826

KS74AHCT

8-Bit Bus Interface Flip-Flops with 3-State Outputs

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range
 KS74AHCT: $-40^\circ C$ to $+85^\circ C$
 KS54AHCT: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74AHCT | KS54AHCT | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|------------------------|--------------------------------------|---------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ C$ to $+85^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -6mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 12mA$ $I_O = 24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns, AHCT825, AHCT826)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit | |
|---|-----------|-------------------------|--------------------------|---|-----|--|-----|------|----|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | | |
| | | | Typ | Min | Max | Min | Max | | |
| Maximum Operating Frequency | f_{max} | $C_L = 50\text{pF}$ | 50 | 35 | | 30 | | MHz | |
| Propagation Delay CLK to any Q | t_{PLH} | $C_L = 50\text{pF}$ | 8 | | 14 | | 17 | ns | |
| | | $C_L = 150\text{pF}$ | 11 | | 23 | | 28 | | |
| Propagation Delay, CLR to Any Q | t_{PHL} | $C_L = 50\text{pF}$ | 8 | | 14 | | 17 | ns | |
| | | $C_L = 150\text{pF}$ | 11 | | 23 | | 28 | | |
| Propagation Delay, CLR to Any Q | t_{PHL} | $C_L = 50\text{pF}$ | 10 | | 17 | | 21 | ns | |
| | | $C_L = 150\text{pF}$ | 13 | | 26 | | 32 | | |
| Output Enable Time, OC to any Q | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 11 | | 18 | | 22 | ns |
| | | | $C_L = 150\text{pF}$ | 17 | | 27 | | -31 | |
| Output Disable Time, OC to any Q | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 11 | | 18 | | 22 | ns |
| | | | $C_L = 150\text{pF}$ | 17 | | 27 | | 31 | |
| Output Disable Time, OC to any Q | t_{PHZ} | $R_L = 1\text{k}\Omega$ | | 13 | | 18 | | 22 | ns |
| | | | t_{PLZ} | $C_L = 50\text{pF}$ | 13 | | 18 | | |
| Pulse Width | t_w | | CLR low | 9 | 15 | | 18 | ns | |
| | | | CLK high or low | 9 | 15 | | 18 | | |
| Setup Time before CLK↑ | t_{su} | | CLR inactive | 9 | 14 | | 17 | ns | |
| | | | Data | 9 | 14 | | 17 | | |
| | | | CLKEN high or low | 9 | 14 | | 17 | | |
| Hold Time, CLKEN or data after CLK↑ | t_h | | -3 | 0 | | 0 | | ns | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C_{PD} | OC = V_{CC} | 5 | | | | | pF | |
| | | OC = GND | 30 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

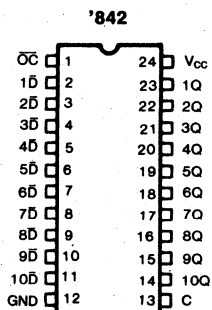
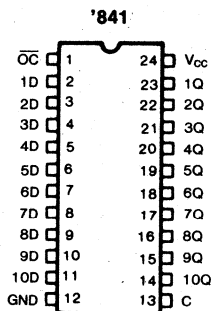
4

Preliminary Specifications

FEATURES

- Bus-Structured Pinout
- Provides Extra Bus Driving Latches
- Necessary for Wider Address/Data Paths or Buses with Parity
- Power-Up High-Impedance State
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATIONS



DESCRIPTION

These 10-bit bus interface latches feature three-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are suitable for implementing wider buffer registers, I/O ports, bidirectional bus drivers, and working registers.

The ten latches are transparent D-type. The '841 has noninverting data (D) inputs and the '842 has inverting (D) inputs.

A buffered output control (\overline{OC}) input can be used to place the ten outputs in either a normal logic state (high or low levels) or a high-impedance state. The high-impedance state and increased drive provide the capability to drive the bus lines in a bus-organized system without need for interface or pull-up components.

The output control does not affect the internal operation of the latches. Old data can be retained or new data can be entered while the outputs are off.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLES

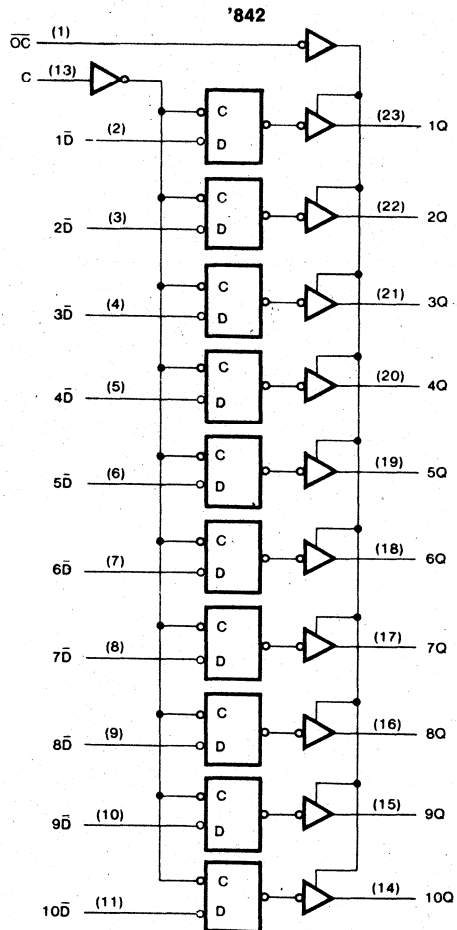
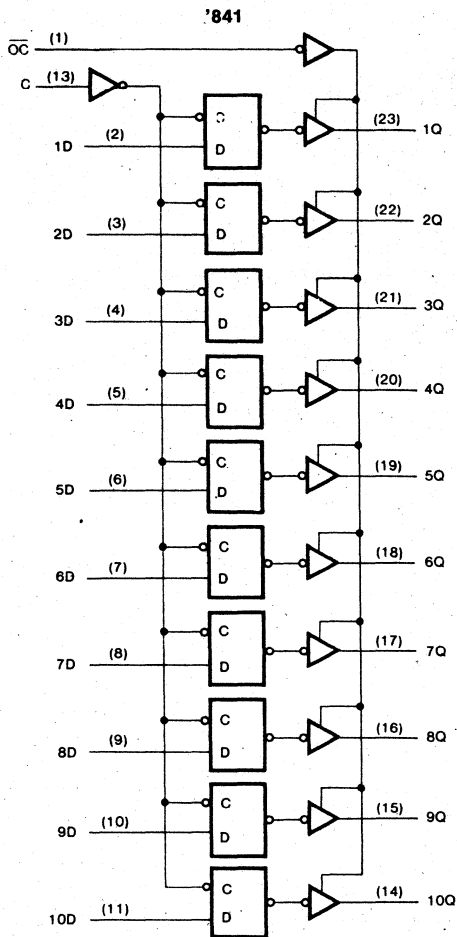
'841

| Inputs | | | Output |
|-----------------|---|---|--------|
| \overline{OC} | C | D | Q |
| L | H | H | H |
| L | H | L | L |
| L | L | X | Q_0 |
| H | X | X | Z |

'842

| Inputs | | | Output |
|-----------------|---|----------------|--------|
| \overline{OC} | C | \overline{D} | Q |
| L | H | H | L |
| L | H | L | H |
| L | L | X | Q_0 |
| H | X | X | Z |

LOGIC DIAGRAM S



4

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d [†] 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

[†] Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} . . . 0V to V_{CC}
 Operating Temperature

Range KS74AHCT: $-40^\circ C$ to $+85^\circ C$
 KS54AHCT: $-55^\circ C$ to $+125^\circ C$

Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|--|---|-----------------------|---------|
| | | | Typ | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -6mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 12mA$ $I_O = 24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT841, AHCT842

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | KS74AHCT | | KS54AHCT | | Unit | |
|--|-----------|------------------------------|--------------------------|---|-----|--|----|------|----|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | | |
| | | | Typ | $V_{CC} = 5.0\text{V} \pm 10\%$ | | $V_{CC} = 5.0\text{V} \pm 10\%$ | | | |
| | | | Min | Max | Min | Max | | | |
| Propagation Delay, Data to Q | t_{PLH} | $C_L = 50\text{pF}$ | 10 | | 16 | | 19 | ns | |
| | | $C_L = 150\text{pF}$ | 13 | | 25 | | 30 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 10 | | 16 | | 19 | ns | |
| | | $C_L = 150\text{pF}$ | 13 | | 25 | | 30 | | |
| Propagation Delay, C to any Q | t_{PLH} | $C_L = 50\text{pF}$ | 15 | | 24 | | 29 | ns | |
| | | $C_L = 150\text{pF}$ | 18 | | 33 | | 40 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 15 | | 24 | | 29 | ns | |
| | | $C_L = 150\text{pF}$ | 18 | | 33 | | 40 | | |
| Output Enable Time, \overline{OC} to any Q | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 13 | | 18 | | 22 | ns |
| | | | $C_L = 150\text{pF}$ | 19 | | 27 | | 33 | |
| | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 13 | | 18 | | 22 | ns |
| | | | $C_L = 150\text{pF}$ | 19 | | 27 | | 33 | |
| Output Disable Time, \overline{OC} to any Q | t_{PHZ} | $R_L = 1\text{k}\Omega$ | | 13 | | 18 | | 22 | ns |
| | | | $C_L = 50\text{pF}$ | | | 18 | | 22 | |
| Pulse Width, C High | t_w | | | 12 | 20 | | 25 | ns | |
| | | | | | | | | | |
| Setup Time, Data before $C\downarrow$ | t_{su} | | 6 | 10 | | 12 | ns | | |
| Hold Time, Data after $C\downarrow$ | t_h | | 3 | 5 | | 7 | ns | | |
| Input Capacitance | C_{IN} | | 5 | | | | pF | | |
| Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF | | |
| Power Dissipation Capacitance* (per stage) | C_{PD} | $\overline{OC} = V_{CC}$ | 5 | | | | pF | | |
| | | $\overline{OC} = \text{GND}$ | 30 | | | | pF | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

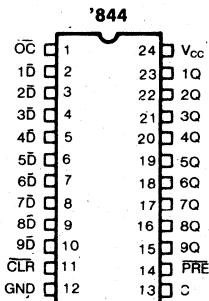
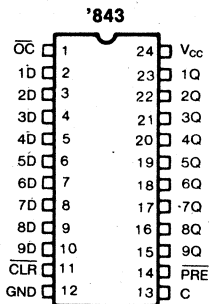
4

Preliminary Specifications

FEATURES

- Bus-Structured Pinout
- Provide Extra Bus Driving Latches Necessary for Wider Address/Data Paths or Buses with Parity
- Power-Up High Impedance
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATIONS



DESCRIPTION

These 9-bit bus interface latches feature three-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are suitable for implementing wider buffer registers, I/O ports, bidirectional bus drivers and working registers.

The nine latches are transparent D-type. The '843 has noninverting data (D) inputs and the '844 has inverting \bar{D} inputs.

A buffered output control (\overline{OC}) input can be used to place the nine outputs in either a normal logic state (high or low levels) or a high-impedance state. The high-impedance state and increased drive provide the capability to drive the bus lines in a bus-organized system without need for interface or pull-up components.

The output control (\overline{OC}) does not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are off.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLES

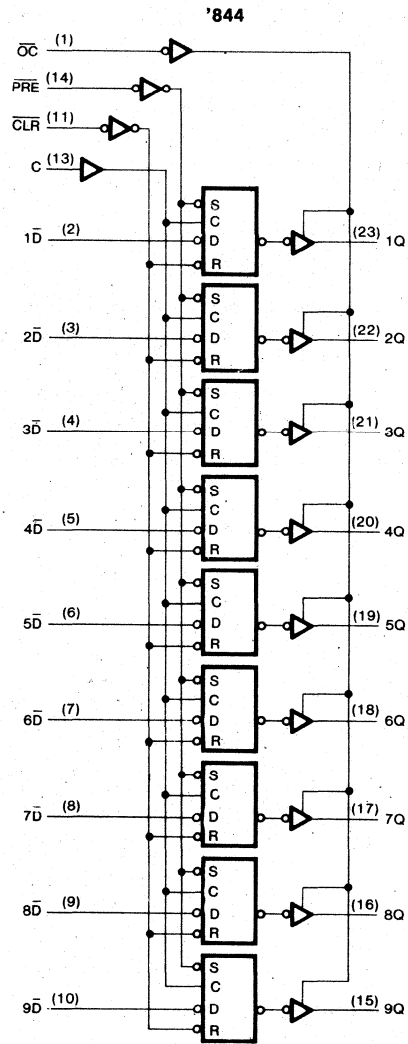
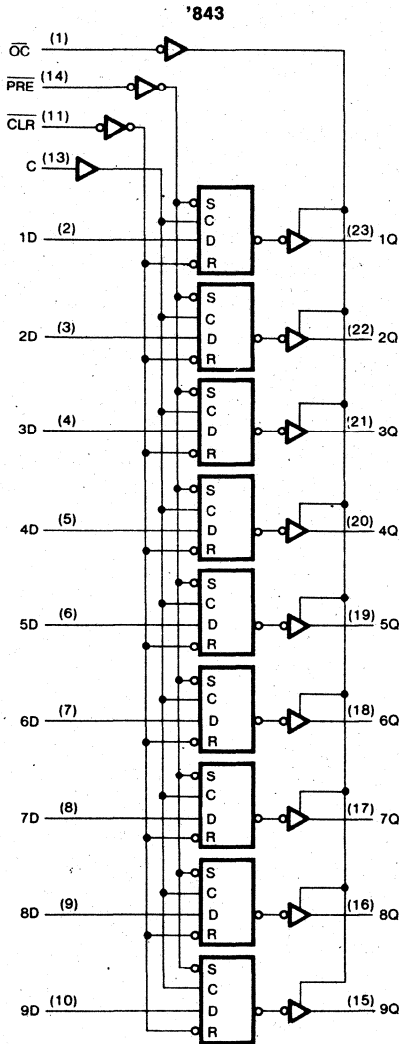
'843

| INPUTS | | | | | OUTPUT |
|------------------|------------------|-----------------|---|---|--------|
| \overline{PRE} | \overline{CLR} | \overline{OC} | C | D | Q |
| L | X | L | X | X | H |
| H | L | L | X | X | L |
| H | H | L | H | L | L |
| H | H | L | H | H | H |
| H | H | L | L | X | Q_0 |
| X | X | H | X | X | Z |

'844

| INPUTS | | | | | OUTPUT |
|------------------|------------------|-----------------|---|-----------|--------|
| \overline{PRE} | \overline{CLR} | \overline{OC} | C | \bar{D} | Q |
| L | X | L | X | X | H |
| H | L | L | X | X | L |
| H | H | L | H | L | H |
| H | H | L | H | H | L |
| H | H | L | L | X | Q_0 |
| X | X | H | X | X | Z |

LOGIC DIAGRAMS



4

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} ... -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74AHCT: -40°C to +85°C
 KS54AHCT: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------------------|------------------------|---------------------------------------|-----------------------|---------|--|
| | | | Typ | Guaranteed Limits | | | | |
| | | | KS74AHCT | | KS54AHCT | | | |
| | | | $T_a = -40^\circ C$ to $+85^\circ C$ | | $T_a = -55^\circ C$ to $+125^\circ C$ | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -6mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 12mA$ $I_O = 24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA | |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA | |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT843, AHCT844

| Characteristic | Symbol | Conditions† | T _a = 25°C V _{CC} = 5.0V | | KS74AHCT T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | | KS54AHCT T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | Unit |
|---|------------------|---|---|------------------|---|----------|--|----------|----------|
| | | | Typ | Min | Max | Min | Max | | |
| | | | Propagation Delay, Data to Q | t _{PLH} | C _L = 50pF C _L = 150pF | 13 16 | | 18 27 | |
| | t _{PHL} | C _L = 50pF C _L = 150pF | 13 16 | | 18 27 | | 22 33 | | |
| Propagation Delay, C to any Q | t _{PLH} | C _L = 50pF C _L = 150pF | 16 19 | | 26 35 | | 31 42 | ns | |
| | t _{PHL} | C _L = 50pF C _L = 150pF | 16 19 | | 26 35 | | 31 42 | | |
| Propagation Delay, PRE to Q | t _{PLH} | C _L = 50pF C _L = 150pF | 17 20 | | 27 36 | | 32 43 | ns | |
| Propagation Delay, CLR to Q | t _{PHL} | C _L = 50pF C _L = 150pF | 17 20 | | 27 36 | | 32 43 | ns | |
| Output Enable Time, OC to any Q | t _{PZL} | R _L = 1kΩ C _L = 50pF C _L = 150pF | 11 17 | | 18 27 | | 22 33 | ns | |
| | t _{PZL} | | C _L = 50pF C _L = 150pF | 11 17 | | 18 27 | | | 22 33 |
| Output Disable Time, OC to any Q | t _{PHZ} | R _L = 1kΩ C _L = 50pF | 13 | | 18 | | 22 | ns | |
| | t _{PLZ} | | C _L = 50pF | 13 | | 18 | | | 22 |
| Pulse Width, C High | t _w | | 12 | 20 | | 25 | | ns | |
| Setup Time, Data before C↓ | t _{SU} | | 8 | 10 | | 12 | | ns | |
| Hold Time, Data after C↓ | t _H | | 3 | 5 | | 7 | | ns | |
| Input Capacitance | C _{IN} | | 5 | | | | | pF | |
| Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C _{PD} | OC = V _{CC} | 5 | | | | | pF | |
| | | OC = GND | 30 | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.



Preliminary Specifications

FEATURES

- Modified input structure allows voltages up to 15V
- High-Drive-current Outputs:
 $I_{OL} = 8\text{mA} @ V_{OL} = 0.5\text{V}$
- Low power consumption characteristic of CMOS
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

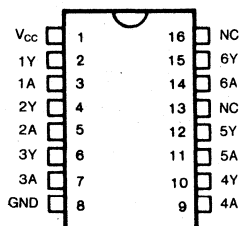
DESCRIPTION

The '4049 and '4050 have a modified input protection structure that enable them to be used as logic level translators which will convert high level logic to a low level logic while operating from the low logic supply. For example, 0-15V logic can be converted to 0-5V logic when using a 5V supply. The modified input protection has no diode connected to V_{CC} , thus allowing the input voltage to exceed the supply. The lower zener diode protects the input from both positive and negative static voltages. In addition the '4049 and '4050 can be used as simple buffers or inverters without level translation.

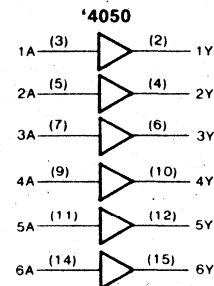
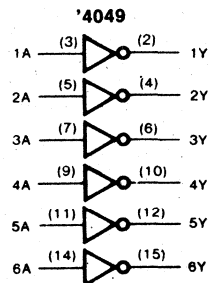
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAMS



FUNCTION TABLE

| Input A | Output Y | |
|------------|----------|-------|
| | '4049 | '4050 |
| H | L | H |
| L | H | L |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
Continuous Output Current Per Pin, I_O
(-0.5V < $V_O < V_{CC} + 0.5V$) ± 35 mA
Continuous Current Through
 V_{CC} or GND pins ± 125 mA
Storage Temperature Range, T_{stg} -65°C to +150°C
Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN} , V_{OUT} . . . 0V to V_{CC}
Operating Temperature
Range
KS74AHCT: -40°C to +85°C
KS54AHCT: -55°C to +125°C
Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ | | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ | | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|--|--|---|--|---------|
| | | | Typ | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | | 2.0 | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | | 0.8 | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | | $V_{CC} - 0.1$ 3.7 | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | | 0.1 0.4 | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | | ± 1.0 | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 2.0 | 20.0 | | 40.0 | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | | 3.0 | | mA |



AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 2$ ns), AHCT4049, AHCT4050

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ | KS74AHCT $T_a = -40^\circ C$ to $+85^\circ C$ | | KS54AHCT $T_a = -55^\circ C$ to $+125^\circ C$ | | Unit |
|--------------------------------|-----------|--------------|--------------------|--|-----|---|-----|------|
| | | | $V_{CC} = 5.0V$ | $V_{CC} = 5.0V \pm 10\%$ | | $V_{CC} = 5.0V \pm 10\%$ | | |
| | | | Typ | Min | Max | Min | Max | |
| Propagation Delay | t_{PLH} | $C_L = 50pF$ | 7 | | 12 | | 14 | ns |
| | t_{PHL} | | 7 | | 12 | | 14 | |
| Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

NOTE



KS54/74HCTLS DATA SHEETS 5



FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8mA @ V_{OL} = 0.5V$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
 KS74HCTLS: $-40^{\circ}C$ to $+85^{\circ}C$
 KS54HCTLS: $-55^{\circ}C$ to $+125^{\circ}C$

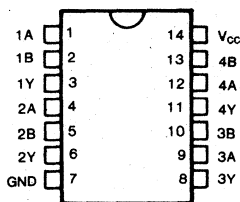
DESCRIPTION

These devices contain four independent 2-input NAND gates that perform the Boolean functions $Y = \overline{A \cdot B}$ or $Y = \overline{A + B}$.

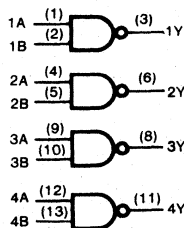
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



5

FUNCTION TABLE

(Each Gate)

| Inputs | | Output |
|--------|---|--------|
| A | B | Y |
| H | H | L |
| L | X | H |
| X | L | H |

Absolute Maximum Ratings*

| | |
|--|-----------------|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74HCTLS: -40°C to +85°C KS54HCTLS: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|--|-----------------------|---|---------------|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | | mA | |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS00

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0V$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | | Unit |
|--------------------------------|-----------|---------------------|---|-------------------|--|----|---|--|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay | t_{PLH} | $C_L = 50\text{pF}$ | 10 | 15 | 18 | 22 | ns | | |
| | t_{PHL} | | 10 | 15 | 18 | 22 | | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | pF | | | |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | pF | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8mA @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: $-40^{\circ}C$ to $+85^{\circ}C$
KS54HCTLS: $-55^{\circ}C$ to $+125^{\circ}C$

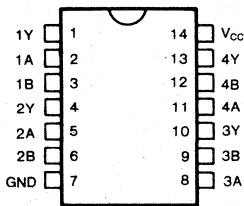
DESCRIPTION

These devices contain four independent 2-input NAND gates with open-drain outputs. Using a suitable pull-up resistor, these outputs may be connected to other open-drain outputs to implement wired-AND functions.

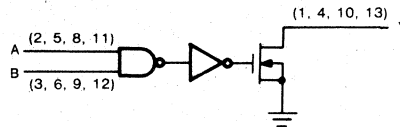
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| Inputs | | Output |
|--------|---|--------|
| A | B | Y |
| H | H | L |
| L | X | H |
| X | L | H |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------|---------------------|--------------------|--------------------------------------|---------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ C$ to $+85^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Output Leakage Current | I_{OZ} | $V_{IN}=V_{IH}$ or V_{IL} $V_{OUT}=V_{CC}$ | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns, HCTLS01)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------|-----------|----------------|--------------------|----|--------------------------------------|---------------------------------------|------|
| | | | $V_{CC} = 5.0V$ | | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Propagation Delay | t_{PLH} | $C_L=50pF$ | 24 | 30 | 36 | 43 | ns |
| | t_{PHL} | $R_L=1k\Omega$ | 15 | 20 | 25 | 30 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8mA @ V_{OL} = 0.5V$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
 KS74HCTLS: $-40^{\circ}C$ to $+85^{\circ}C$
 KS54HCTLS: $-55^{\circ}C$ to $+125^{\circ}C$

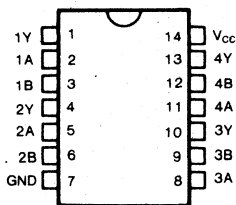
DESCRIPTION

These devices contain four independent 2-input NOR gates that perform the Boolean functions $Y = \overline{A+B}$ or $Y = \overline{A \cdot B}$.

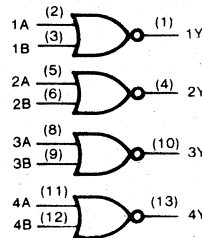
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



5

FUNCTION TABLE

(Each Gate)

| Inputs | | Output |
|--------|---|--------|
| A | B | Y |
| H | X | L |
| X | H | L |
| L | L | H |

Absolute Maximum Ratings*

| | |
|---|---|
| Supply Voltage Range V_{CC} , | -0.5V to +7V |
| DC Input Diode Current, I_{IK} ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_d^\dagger | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

| | |
|----------------------|---|
| Plastic Package (N): | $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C |
| Ceramic Package (J): | $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C |

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74HCTLS: -40°C to $+85^\circ\text{C}$ KS54HCTLS: -55°C to $+125^\circ\text{C}$ |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|--|---|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-4\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS02

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------|-----------|-------------------|--------------------------|-------------------|--|---|------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ $V_{CC}=5.0V \pm 10\%$ | $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ $V_{CC}=5.0V \pm 10\%$ | |
| Maximum Propagation Delay | t_{PLH} | $C_L=50\text{pF}$ | 9 | 15 | 18 | 22 | ns |
| | t_{PHL} | | 10 | 15 | 18 | 22 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current Outputs:
 $I_{OL} = 8\text{mA} @ V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

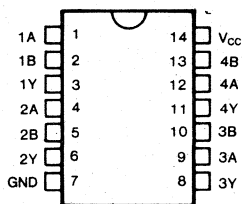
DESCRIPTION

These devices contain four independent 2-input NAND gates with open-drain outputs. Using a suitable pull-up resistor, these outputs may be connected to other open-drain outputs to implement wired-AND functions.

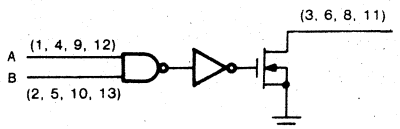
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| Inputs | | Output |
|--------|---|--------|
| A | B | Y |
| H | H | L |
| L | X | H |
| X | L | H |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} ... -65°C to +150°C
 Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|---|--|------------|---------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ | KS54HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Output Leakage Current | I_{OZ} | $V_{IN}=V_{IH}$ or V_{IL} $V_{OUT}=V_{CC}$ | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns), HCTLS03

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ $V_{CC} = 5.0V$ | | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ $V_{CC} = 5.0V \pm 10\%$ | KS54HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ $V_{CC} = 5.0V \pm 10\%$ | Unit |
|--------------------------------|-----------|------------------------------|---------------------------------------|-------------------|---|--|------|
| | | | Typ | Guaranteed Limits | | | |
| Maximum Propagation Delay | t_{PLH} | $C_L=50pF$ $R_L=1k\Omega$ | 24 | 30 | 36 | 43 | ns |
| | t_{PHL} | | 15 | 20 | 25 | 30 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

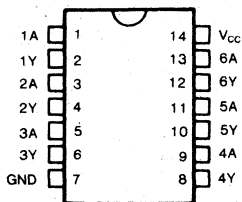
DESCRIPTION

These devices contain six independent inverters. They perform the Boolean function $Y = \bar{A}$.

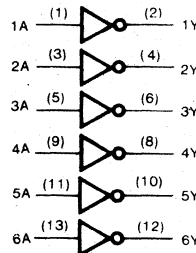
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Inverter)

| Input | Output |
|-------|--------|
| A | Y |
| H | L |
| L | H |

5

Absolute Maximum Ratings*

| | |
|---|-----------------|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74HCTLS: -40°C to +85°C KS54HCTLS: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|---------------------------------------|-----------------|--|--------------------------|------------------------|---|--|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current* | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns, HCTLS04)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------|-----------|---------------------|--------------------------|-------------------|---|--|------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | |
| Maximum Propagation Delay | t_{PLH} | $C_L = 50\text{pF}$ | 9 | 15 | 18 | 22 | ns |
| | t_{PHL} | | 10 | 15 | 18 | 22 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

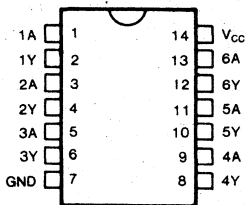
DESCRIPTION

These devices contain six independent inverters with open-drain outputs. Using a suitable pull-up resistor, these outputs may be connected to other open-drain outputs to implement wired-AND functions.

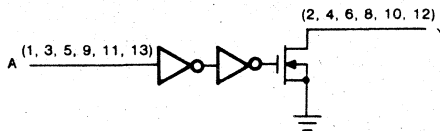
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Inverter)

| Input | Output |
|-------|--------|
| A | Y |
| H | L |
| L | H |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|---|--|------------|---------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ | KS54HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Output Leakage Current | I_{OZ} | $V_{IN}=V_{IH}$ or V_{IL} $V_{OUT}=V_{CC}$ | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns), HCTLS05

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ $V_{CC} = 5.0V$ | | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ $V_{CC} = 5.0V \pm 10\%$ | KS54 HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ $V_{CC} = 5.0V \pm 10\%$ | Unit |
|--------------------------------|-----------|------------------|---------------------------------------|-------------------|---|---|------|
| | | | Typ | Guaranteed Limits | | | |
| Maximum Propagation Delay | t_{PLH} | $C_L = 50pF$ | 24 | 30 | 36 | 43 | ns |
| | t_{PHL} | $R_L = 1k\Omega$ | 16 | 22 | 28 | 33 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
 KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
 KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

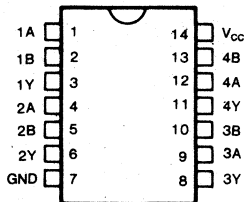
DESCRIPTION

These devices contain four independent 2-input AND gates. They perform the Boolean functions $Y = A \cdot B$ or $Y = \overline{A + B}$.

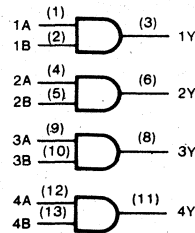
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| Inputs | | Output |
|--------|---|--------|
| A | B | Y |
| H | H | H |
| L | X | L |
| X | L | L |

5

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} ... -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|---|--|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns), HCTLS08

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------|-----------|---------------------|--------------------------|-------------------|---|--|------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | |
| Maximum Propagation Delay | t_{PLH} | $C_L = 50\text{pF}$ | 10 | 15 | 18 | 22 | ns |
| | t_{PHL} | | 10 | 20 | 25 | 30 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

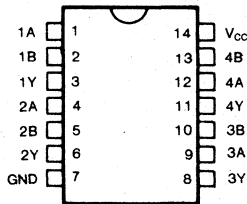
DESCRIPTION

These devices contain four independent 2-input AND gates with open-drain outputs. Using a suitable pull-up resistor, these outputs may be connected to other open-drain outputs to implement wired-AND functions.

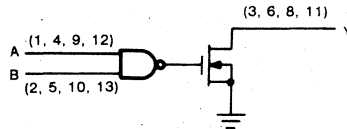
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| Inputs | | Output |
|--------|---|--------|
| A | B | Y |
| H | H | H |
| L | X | L |
| X | L | L |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ | | KS54HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ | | Unit |
|--------------------------------------|-----------------|--|--------------------|---------------------|---|--|--|--|---------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | | 2.0 | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | | 0.8 | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | | 0.1 0.4 | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | | ± 1.0 | | μA |
| Maximum Output Leakage Current | I_{OZ} | $V_{IN}=V_{IH}$ or V_{IL} $V_{OUT}=V_{CC}$ | | ± 0.5 | ± 5.0 | | ± 10.0 | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 2.0 | 20.0 | | 40.0 | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | | 3.0 | | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns), HCTLS09

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ $V_{CC}=5.0V$ | | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ $V_{CC}=5.0V \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ $V_{CC}=5.0V \pm 10\%$ | | Unit |
|--------------------------------|-----------|------------------------------|-------------------------------------|-------------------|---|--|--|--|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay | t_{PLH} | $C_L=50pF$ $R_L=1k\Omega$ | 26 | 32 | 38 | | 45 | | ns |
| | t_{PHL} | | 16 | 22 | 28 | | 33 | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

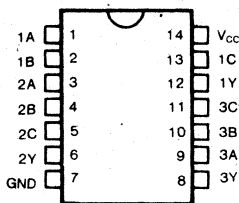
DESCRIPTION

These devices contain three independent 3-input NAND gates. They perform the Boolean functions $Y = \overline{A \cdot B \cdot C}$ or $Y = \overline{A + B + C}$.

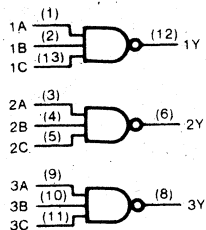
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| Inputs | | | Output |
|--------|---|---|--------|
| A | B | C | Y |
| H | H | H | L |
| L | X | X | H |
| X | L | X | H |
| X | X | L | H |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ | | KS54HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ | | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|---|-----------------------|--|---------|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | $V_{CC} - 0.1$ 3.7 | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | 0.1 0.4 | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | ± 1.0 | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 2.0 | 20.0 | 40.0 | 40.0 | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | 3.0 | mA | |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns), HCTLS10

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ $V_{CC} = 5.0V$ | | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ $V_{CC} = 5.0V \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ $V_{CC} = 5.0V \pm 10\%$ | | Unit |
|--------------------------------|-----------|--------------|---------------------------------------|-------------------|---|----|--|----|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay | t_{PLH} | $C_L = 50pF$ | 11 | 15 | 19 | 19 | 23 | 23 | ns |
| | t_{PHL} | | 11 | 15 | 19 | 19 | 23 | 23 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
 KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
 KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

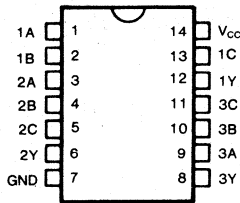
DESCRIPTION

These devices contain three independent 3-input AND gates. They perform the Boolean functions $Y = A \cdot B \cdot C$ or $Y = \overline{A + B + C}$.

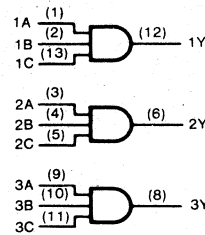
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



5

FUNCTION TABLE

(Each Gate)

| Inputs | | | Output |
|--------|---|---|--------|
| A | B | C | Y |
| H | H | H | H |
| L | X | X | L |
| X | L | X | L |
| X | X | L | L |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} $4.5V$ to $5.5V$
 DC Input & Output Voltages*, V_{IN} , V_{OUT} $0V$ to V_{CC}
 Operating Temperature
 Range KS74HCTLS: $-40^\circ C$ to $+85^\circ C$
 KS54HCTLS: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------|----------------------|--------------------------------------|---------------------------------------|---------|
| | | | | | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | |
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-4mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns, HCTLS11)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------|-----------|--------------|--------------------|-------------------|--------------------------------------|---------------------------------------|------|
| | | | $V_{CC} = 5.0V$ | | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | |
| | | | Typ | Guaranteed Limits | | | |
| Maximum Propagation Delay | t_{PLH} | $C_L = 50pF$ | 13 | 18 | 22 | 26 | ns |
| | t_{PHL} | | 13 | 18 | 22 | 26 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
 KS74HCTLS: $-40^{\circ}\text{C to } +85^{\circ}\text{C}$
 KS54HCTLS: $-55^{\circ}\text{C to } +125^{\circ}\text{C}$

DESCRIPTION

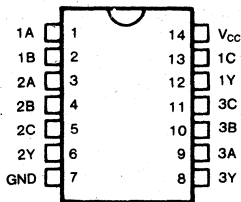
These devices contain three independent 3-input NAND gates with open-drain outputs. They perform the Boolean functions $Y = \overline{A \cdot B \cdot C}$ or $Y = \overline{\overline{A} + \overline{B} + \overline{C}}$.

Using a suitable pull-up resistor, these outputs may be connected to other open-drain outputs to implement wired-AND functions.

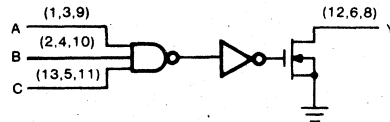
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| Inputs | | | Output |
|--------|---|---|--------|
| A | B | C | Y |
| H | H | H | L |
| L | X | X | H |
| X | L | X | H |
| X | X | L | H |

5

Absolute Maximum Ratings*

| | |
|---|---|
| Supply Voltage Range V_{CC} , | -0.5V to +7V |
| DC Input Diode Current, I_{IK} ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_{d1} † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

| | |
|---|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN} , V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74HCTLS: -40°C to $+85^\circ\text{C}$ KS54HCTLS: -55°C to $+125^\circ\text{C}$ |
| Input Rise & Fall Times, t_r , t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|---|--|------------|---------------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | KS54HCTLS $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Output Leakage Current | I_{OZ} | $V_{IN}=V_{IH}$ or V_{IL} $V_{OUT}=V_{CC}$ | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns, HCTLS12)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0V$ | | KS74HCTLS $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | KS54HCTLS $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | Unit |
|--------------------------------|-----------|-----------------------|---|-------------------|---|--|------|
| | | | Typ | Guaranteed Limits | | | |
| Maximum Propagation Delay | t_{PLH} | $C_L=50\text{pF}$ | 26 | 32 | 38 | 45 | ns |
| | t_{PHL} | $R_L=1\text{k}\Omega$ | 16 | 22 | 28 | 33 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

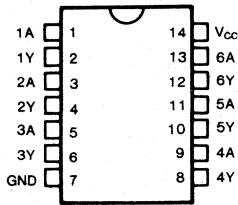
† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



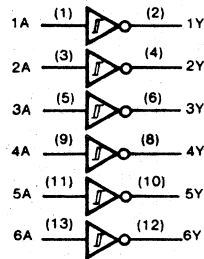
DESCRIPTION

These Schmitt-trigger devices contain six independent inverters. They perform the Boolean function $Y = \bar{A}$.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAM



FUNCTION TABLE

(Each Inverter)

| Input A | Output Y |
|------------|-------------|
| H | L |
| L | H |

Absolute Maximum Ratings*

| | |
|---|-----------------|
| Supply Voltage Range V_{CC} , | -0.5V to +7V |
| DC Input Diode Current, I_{IK} ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

| | |
|----------------------|------------------------------|
| Plastic Package (N): | -12mW/°C from 65°C to 85°C |
| Ceramic Package (J): | -12mW/°C from 100°C to 125°C |

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74HCTLS: -40°C to +85°C KS54HCTLS: -55°C to +125°C |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--|-----------------|--|--------------------------|------------------------|---|--|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | |
| Minimum Positive-Going Threshold Voltage | V_{T+} | | 1.6 | 1.9 | 1.9 | 1.9 | V |
| Maximum Negative-Going Threshold Voltage | V_{T-} | | 0.8 | 0.5 | 0.5 | 0.5 | V |
| Hysteresis ($V_{T+} - V_{T-}$) | V_H | Min | 0.8 | 0.4 | 0.4 | 0.4 | V |
| | | Max | 0.8 | 1.4 | 1.4 | 1.4 | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS14

| Characteristic | Symbol | Conditions† | T _a = 25°C V _{CC} = 5.0V | | KS74 HCTLS | KS54 HCTLS | Unit |
|--------------------------------|------------------|-----------------------|---|----|---|--|------|
| | | | | | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Propagation Delay | t _{PLH} | C _L = 50pF | 16 | 22 | 28 | 33 | ns |
| | t _{PHL} | | 16 | 22 | 28 | 33 | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | (per gate) | 15 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
 KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
 KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

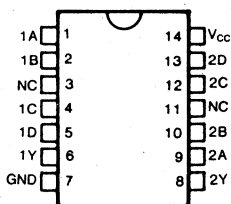
DESCRIPTION

These devices contain two independent 4-input NAND gates. They perform the Boolean functions $Y = \overline{A \cdot B \cdot C \cdot D}$ or $Y = \overline{A + B + C + D}$ in positive logic.

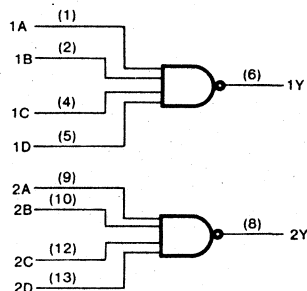
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each gate)

| INPUTS | | | | OUTPUT |
|--------|---|---|---|--------|
| A | B | C | D | Y |
| H | H | H | H | L |
| L | X | X | X | H |
| X | L | X | X | H |
| X | X | L | X | H |
| X | X | X | L | H |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_{Df} † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to $+85^\circ\text{C}$
 KS54HCTLS: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|------------------------|--|---------------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns), HCTLS20

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0V$ | | KS74HCTLS | KS54HCTLS | Unit |
|--|-----------|---------------------|---|-------------------|-----------|--|------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | |
| Maximum Propagation Delay Any Input to Y | t_{PLH} | $C_L = 50\text{pF}$ | 11 | 15 | 19 | 23 | ns |
| | t_{PHL} | | 11 | 15 | 19 | 23 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
I_{OL} = 8 mA @ V_{OL} = 0.5V
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C

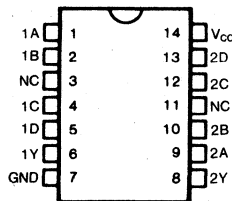
DESCRIPTION

These devices contain two independent 4-input AND gates. They perform the Boolean functions $Y = A \cdot B \cdot C \cdot D$ or $Y = \overline{A + B + C + D}$ in positive logic.

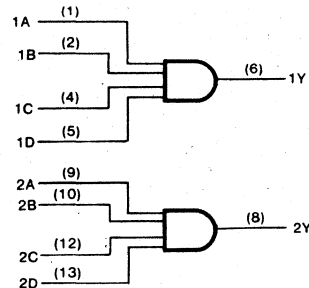
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each gate)

| INPUTS | | | | OUTPUT Y |
|--------|---|---|---|-------------|
| A | B | C | D | |
| H | H | H | H | H |
| L | X | X | X | L |
| X | L | X | X | L |
| X | X | L | X | L |
| X | X | X | L | L |

Absolute Maximum Ratings*

| | |
|--|-----------------|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74HCTLS: -40°C to +85°C KS54HCTLS: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit | |
|--------------------------------------|-----------------|--|--------------------|----------------------|--------------------------------------|---------------------------------------|-------------------|--|
| | | | | | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| | | | Typ | | | | Guaranteed Limits | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-4mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 2.0 | 20.0 | 40.0 | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA | |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS21

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--|-----------|-------------|--------------------|----|--------------------------------------|---------------------------------------|------|
| | | | $V_{CC}=5.0V$ | | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Propagation Delay Any Input to Y | t_{PLH} | $C_L=50pF$ | 12 | 18 | 22 | 27 | ns |
| | t_{PHL} | | 12 | 18 | 22 | 27 | |
| Maximum Input Capacitance | C_{IN} | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^\circ\text{C}$
KS54HCTLS: -55°C to $+125^\circ\text{C}$

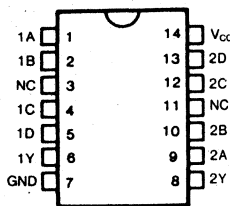
DESCRIPTION

These devices contain two independent 3-input NOR gates. These gates perform the Boolean functions $Y = \overline{A \cdot B \cdot C \cdot D}$ or $Y = \overline{A + B + C + D}$ in positive logic. The open-drain outputs require pull-up resistors to perform correctly. They may be connected to other open-drain outputs to implement active low wired-OR or active high wired-AND functions.

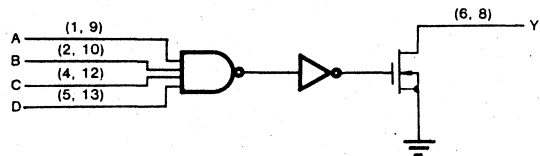
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each gate)

| INPUTS | | | | OUTPUT |
|--------|---|---|---|--------|
| A | B | C | D | Y |
| H | H | H | H | L |
| L | X | X | X | H |
| X | L | X | X | H |
| X | X | L | X | H |
| X | X | X | L | H |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to $+85^\circ\text{C}$
 KS54HCTLS: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | | Unit |
|--------------------------------------|-----------------|--|--------------------------|---------------------|--------------------|------------|---------------|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Output Leakage Current | I_{OZ} | $V_{IN}=V_{IH}$ or V_{IL} $V_{OUT}=V_{CC}$ | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns), HCTLS22

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | | | | Unit |
|---|-----------|-------------------|--------------------------|-------------------|----|----|------|
| | | | Typ | Guaranteed Limits | | | |
| Maximum Propagation Delay Any Input to Y | t_{PLH} | $C_L=50\text{pF}$ | 26 | 33 | 40 | 47 | ns |
| | t_{PHL} | | 15 | 20 | 25 | 30 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
 KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
 KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

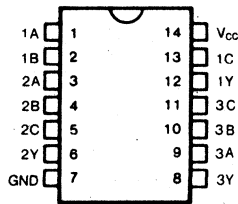
DESCRIPTION

These devices contain two independent 3-input NOR gates. They perform the Boolean functions $\bar{Y}=A+B+C$ or $Y=\bar{A}\cdot\bar{B}\cdot\bar{C}$ in positive logic.

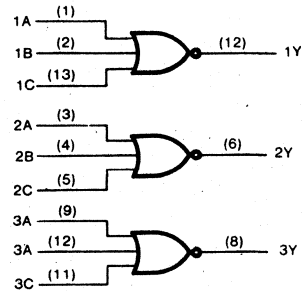
These devices provide speeds, and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| INPUTS | | | OUTPUT |
|--------|---|---|--------|
| A | B | C | Y |
| H | X | X | L |
| X | H | X | L |
| X | X | H | L |
| L | L | L | H |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to $+85^\circ\text{C}$
 KS54HCTLS: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|---|--|--|--|---------------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | | 2.0 | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | | 0.8 | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | | $V_{CC} - 0.1$ 3.7 | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | | 0.1 0.4 | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | | ± 1.0 | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | | 40.0 | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | | 3.0 | | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns), HCTLS27

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0V$ | | KS74HCTLS $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | | Unit |
|---|-----------|---------------------|---|-------------------|---|--|--|--|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay Any Input to Y | t_{PLH} | $C_L = 50\text{pF}$ | 11 | 15 | 19 | | 23 | | ns |
| | t_{PHL} | | 11 | 15 | 19 | | 23 | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

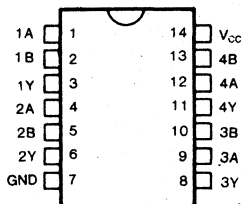
DESCRIPTION

These devices contain four independent 2-input OR gates. They perform the Boolean functions $Y = A + B$ or $Y = \overline{A} \cdot \overline{B}$.

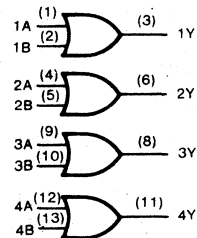
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damaged due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| Inputs | | Output |
|--------|---|--------|
| A | B | Y |
| H | X | H |
| X | H | H |
| L | L | L |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 (-0.5V $< V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} ... -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range
 KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|--------------------------------------|---------------------------------------|---------|
| | | | | | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | |
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns), HCTLS32

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------|-----------|--------------|--------------------|-------------------|--------------------------------------|---------------------------------------|------|
| | | | $V_{CC} = 5.0V$ | | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | |
| | | | Typ | Guaranteed Limits | | | |
| Maximum Propagation Delay | t_{PLH} | $C_L = 50pF$ | 13 | 17 | 22 | 26 | ns |
| | t_{PHL} | | 13 | 17 | | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

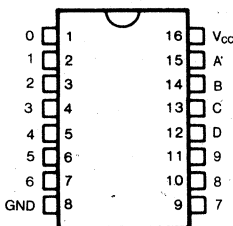
† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Full decoding of Input Logic
- All outputs are High for Invalid BCD Conditions
- Also for application as 3-Line to 8-Line Decoders
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



FUNCTION TABLE

| No. | Inputs | | | | Outputs | | | | | | | | | | |
|---------|--------|---|---|---|---------|---|---|---|---|---|---|---|---|---|---|
| | D | C | B | A | 0 | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | |
| 0 | L | L | L | L | L | H | H | H | H | H | H | H | H | H | H |
| 1 | L | L | L | H | H | L | H | H | H | H | H | H | H | H | H |
| 2 | L | L | H | L | H | H | L | H | H | H | H | H | H | H | H |
| 3 | L | L | H | H | H | H | L | H | H | H | H | H | H | H | H |
| 4 | L | H | L | L | H | H | H | H | L | H | H | H | H | H | H |
| 5 | L | H | L | H | H | H | H | H | L | H | H | H | H | H | H |
| 6 | L | H | H | L | H | H | H | H | H | L | H | H | H | H | H |
| 7 | L | H | H | H | H | H | H | H | H | H | L | H | H | H | H |
| 8 | H | L | L | L | H | H | H | H | H | H | L | H | H | H | H |
| 9 | H | L | L | H | H | H | H | H | H | H | H | L | H | H | H |
| INVALID | H | L | H | L | H | H | H | H | H | H | H | H | H | H | H |
| | H | L | H | H | H | H | H | H | H | H | H | H | H | H | H |
| | H | H | L | L | H | H | H | H | H | H | H | H | H | H | H |
| | H | H | H | L | H | H | H | H | H | H | H | H | H | H | H |
| | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H |

DESCRIPTION

The '42 decoder accepts for active-high BCD inputs and provides 10 mutually exclusive active-low outputs, as shown by logic symbol or diagram. The active-low outputs facilitate addressing other MSI units with active-low input enables.

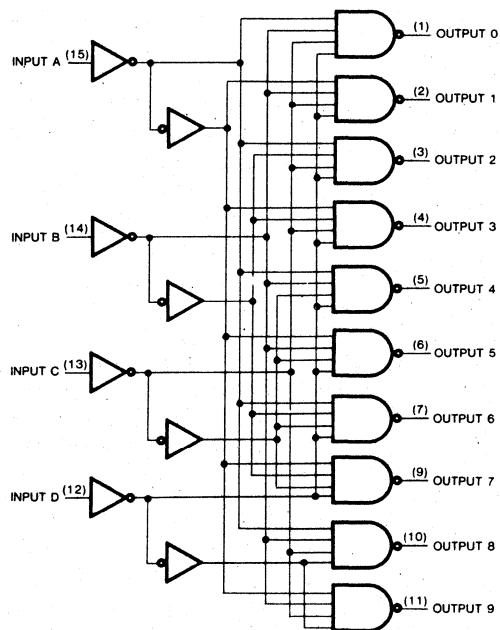
The logic design of the '42 ensures that all outputs are high when binary codes greater than nine are applied to the inputs.

The most significant input, D, produces a useful inhibit function when the '42 is used as a 1-of-8 decoder. The D input can also be used as the Data input in an 8-output demultiplexer application.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_D † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature Range
 KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|------------------------|-----------------------|---------|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns), HCTLS42

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ | | KS74 HCTLS | KS54 HCTLS | Unit |
|--|-----------|-------------|--------------------|-------------------|------------|------------|------|
| | | | $V_{CC}=5.0V$ | Guaranteed Limits | | | |
| Maximum Propagation Delay Any Input to Y | t_{PLH} | $C_L=50pF$ | 19 | 25 | 32 | 38 | ns |
| | t_{PHL} | | 19 | 25 | 32 | 38 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
I_{OL} = 8 mA @ V_{OL} = 0.5V
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C

DESCRIPTION

The '51 performs the following Boolean functions:

$$1Y = (1A \cdot 1B \cdot 1C) + (1D \cdot 1E \cdot 1F)$$

$$2Y = (2A \cdot 2B) + (2C \cdot 2D)$$

The '58 performs:

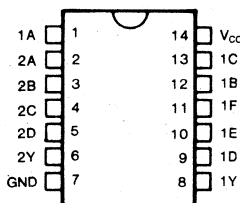
$$1Y = (1A \cdot 1B \cdot 1C) + (1D \cdot 1E \cdot 1F)$$

$$2Y = (2A \cdot 2B) + (2C \cdot 2D)$$

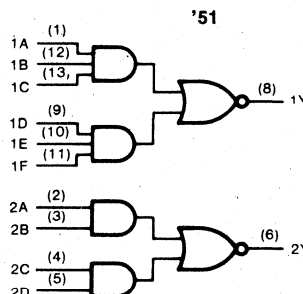
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



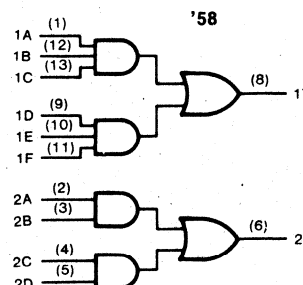
LOGIC DIAGRAMS



FUNCTION TABLES

| Inputs | | | | | | Output 1Y | |
|-----------------------|----|----|----|----|----|-----------|-----|
| 1A | 1B | 1C | 1D | 1E | 1F | '51 | '58 |
| H | H | H | X | X | X | L | H |
| X | X | X | H | H | H | L | H |
| Any other combination | | | | | | H | L |

| Inputs | | | | Output 2Y | |
|-----------------------|----|----|----|-----------|-----|
| 2A | 2B | 2C | 2D | '51 | '58 |
| H | H | X | X | L | H |
| X | X | H | H | L | H |
| Any other combination | | | | H | L |



Absolute Maximum Ratings*

| | |
|---|---|
| Supply Voltage Range V_{CC} , | -0.5V to +7V |
| DC Input Diode Current, I_{IK} ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 85°C to 125°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74HCTLS: -40°C to $+85^\circ\text{C}$ KS54HCTLS: -55°C to $+125^\circ\text{C}$ |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|---|--|-----------------------|-------------------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | KS54HCTLS $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | Guaranteed Limits |
| Minimum High-Level Input Voltage | V_{IH} | | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | ± 0.1 | ± 1.0 | ± 1.0 | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | 2.0 | 20.0 | 40.0 | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | 2.7 | 2.9 | 3.0 | mA | |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS51, HCTLS58

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0V$ | | | Unit |
|--------------------------------|-----------|---------------------|---|---|--|------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | KS54HCTLS $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | |
| Maximum Propagation Delay | t_{PLH} | $C_L = 50\text{pF}$ | 13 | 18 | 23 | ns |
| | t_{PHL} | | 13 | 18 | 23 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Objective Specifications

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
 KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
 KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

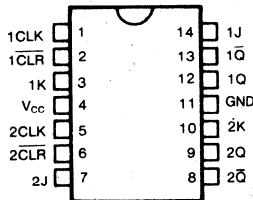
DESCRIPTION

These devices contain two independent J-K negative-edge-triggered flip-flops. A low level at CLR input resets the outputs regardless of the levels of the other inputs. When CLR is inactive (high), data at the J and K inputs meeting the setup time requirements are transferred to the outputs on the negative-going edge of the clock pulse. Clock triggering occurs at a voltage level and is not directly related to the rise time of the clock pulse. Following the hold time interval, data at the J and K inputs may be changed without affecting the levels at the outputs. These versatile flip-flops can perform as toggle flip-flops by tying J and K high.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | | | Outputs | |
|--------|-----|---|---|---------|-------------|
| CLR | CLK | J | K | Q | \bar{Q} |
| L | X | X | X | L | H |
| H | ↓ | L | L | Q_0 | \bar{Q}_0 |
| H | ↓ | H | L | H | L |
| H | ↓ | L | H | L | H |
| H | ↓ | H | H | TOGGLE | |
| H | H | X | X | Q_0 | \bar{Q}_0 |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} ... -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|---|--|-----------------------|---------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ | KS54HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 4.0 | 40.0 | 80.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS73A

| Characteristic | Symbol | Conditions [†] | T _a = 25°C V _{CC} = 5.0V | | KS74HCTLS | KS54HCTLS | Unit |
|---|----------------------|-------------------------|---|----|---|--|------|
| | | | | | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Clock Frequency | f _{max} | C _L = 50pF | 40 | 30 | 25 | 21 | MHz |
| Maximum Propagation Delay, CLK to Q or \bar{Q} | t _{PLH} | | 15 | 20 | 25 | 30 | ns |
| | t _{PHL} | | 15 | 20 | 25 | 30 | |
| Maximum Propagation Delay, CLR to Q or \bar{Q} | t _{PLH} | | 15 | 20 | 25 | 30 | ns |
| | t _{PHL} | 15 | 20 | 25 | 30 | | |
| Minimum Setup Time before CLK↓ | J or K | t _{su} | 10 | 13 | 17 | 20 | ns |
| | \bar{CLR} Inactive | | 10 | 13 | 17 | 20 | |
| Minimum Hold Time, J or K after CLK↓ | t _h | | -3 | 0 | 0 | 0 | ns |
| Minimum Pulse Width | CLK High or Low | t _w | 10 | 13 | 17 | 20 | ns |
| | \bar{CLR} Low | | 10 | 13 | 17 | 20 | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | (per flip-flop) | 40 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
 KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

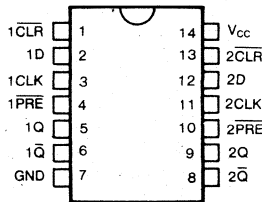
DESCRIPTION

These devices contain two independent positive-edge-triggered D-type flip-flops. Each flip-flop has its own data, clock, preset and clear inputs and complementary Q and \bar{Q} outputs. The preset and clear inputs are active-low and operate independently of the clock. Data at the D input is transferred to the Q outputs on the positive transition of the clock, provided setup requirements have been met.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | | | Outputs | |
|-------------------------|-------------------------|-----|---|-----------|-----------|
| $\overline{\text{PRE}}$ | $\overline{\text{CLR}}$ | CLK | D | Q | \bar{Q} |
| L | H | X | X | H | L |
| H | L | X | X | L | H |
| L | L | X | X | H* | H* |
| H | H | ↑ | H | H | L |
| H | H | ↑ | L | L | H |
| H | H | L | X | No Change | No Change |
| H | H | H | X | No Change | No Change |
| H | H | ↓ | X | No Change | No Change |

* Both outputs will remain high as long as $\overline{\text{PRE}}$ and $\overline{\text{CLR}}$ are low, but the output states are unpredictable if $\overline{\text{PRE}}$ and $\overline{\text{CLR}}$ go high simultaneously.

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d [†] 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

[†] Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range
 KS74HCTLS: -40°C to $+85^\circ\text{C}$
 KS54HCTLS: -55°C to $+125^\circ\text{C}$

Input Rise & Fall Times, t_r , t_f Max 500 ns
 * Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|---|---------------------|--|--|---------------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-4\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 4.0 | 40.0 | 80.0 | | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | | | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns, HCTLS74A)

| Characteristic | Symbol | Conditions† | T _a = 25°C V _{CC} = 5.0V | | KS74HCTLS | KS54HCTLS | Unit | |
|--|---|-----------------------|---|-------------------|---|--|------|----|
| | | | | | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | |
| | | | Typ | Guaranteed Limits | | | | |
| Maximum Clock Frequency | f _{max} | C _L = 50pF | 40 | 30 | 25 | 20 | MHz | |
| Maximum Propagation Delay, CLK to Q or \bar{Q} | t _{PLH} | | 18 | 25 | 31 | 37 | ns | |
| | t _{PHL} | | 30 | 40 | 50 | 60 | | |
| Maximum Propagation Delay, \overline{PRE} or \overline{CLR} to Q or \bar{Q} | t _{PLH} | | 18 | 25 | 31 | 37 | ns | |
| | t _{PHL} | | 30 | 40 | 50 | 60 | | |
| Minimum Setup Time before CLK↑ | Data | | t _{su} | 10 | 13 | 17 | 20 | ns |
| | \overline{PRE} or \overline{CLR} Inactive | | | 10 | 13 | 17 | 20 | |
| Minimum Hold Time, J or K after CLK↓ | t _h | | | -3 | 0 | 0 | 0 | ns |
| Minimum Pulse Width | CLK High or Low | t _w | 8 | 15 | 20 | 25 | ns | |
| | \overline{PRE} or \overline{CLR} Low | | 8 | 15 | 20 | 25 | | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF | |
| Power Dissipation Capacitance* | C _{PD} | (per flip-flop) | 40 | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

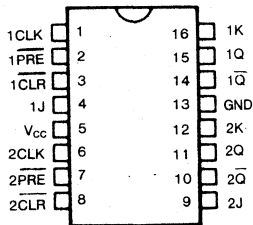
KS54HCTLS 76A Dual J-K Flip-Flops with Preset and Clear

Objective Specifications

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



DESCRIPTION

These parts consist of two negative-edge-triggered J-K flip-flops with independent J, K, preset, clear and clock inputs and complementary outputs. The J-K inputs at each flip-flop are enabled when the clock goes high. The input data are transferred to the outputs on the negative-going edge of the clock pulse, provided the setup requirements have been met.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLE

| Inputs | | | | | Outputs | |
|--------|-----|-----|---|---|---------|-------------|
| PRE | CLR | CLK | J | K | Q | \bar{Q} |
| L | H | X | X | X | H | L |
| H | L | X | X | X | L | H |
| L | L | X | X | X | Q_0 | \bar{Q}_0 |
| H | H | ↓ | L | L | Q_0 | \bar{Q}_0 |
| H | H | ↓ | H | L | H | L |
| H | H | ↓ | L | H | L | H |
| H | H | ↓ | H | H | TOGGLE | TOGGLE |
| H | H | H | X | X | Q_0 | \bar{Q}_0 |

* Both outputs will remain high as long as preset and clear are low, but the output states are unpredictable if preset and clear go high simultaneously.

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d [†] 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: $-40^\circ C$ to $+85^\circ C$
 KS54HCTLS: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------|----------------------|--------------------------------------|---------------------------------------|---------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-4mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 4.0 | 40.0 | 80.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

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AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS76A

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--|---------------------|---------------------|--|----|--|---|------|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Clock Frequency | f_{\max} | $C_L = 50\text{pF}$ | 40 | 30 | 25 | 21 | MHz |
| Maximum Propagation Delay, CLK to Q or \bar{Q} | t_{PLH} | | 15 | 20 | 25 | 30 | ns |
| | t_{PHL} | | 15 | 20 | 25 | 30 | |
| Maximum Propagation Delay, PRE or CLR to Q or \bar{Q} | t_{PLH} | | 15 | 20 | 25 | 30 | ns |
| | t_{PHL} | 15 | 20 | 25 | 30 | | |
| Minimum Setup Time before CLK↓ | Data | t_{su} | 10 | 13 | 17 | 20 | ns |
| | PRE or CLR Inactive | | 10 | 13 | 17 | 20 | |
| Minimum Hold Time, J or K after CLK↓ | t_h | | -3 | 0 | 0 | 0 | ns |
| Minimum Pulse Width | CLK High or Low | t_w | 10 | 13 | 17 | 20 | ns |
| | PRE or CLR Low | | 10 | 13 | 17 | 20 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per flip-flop) | 40 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.



KS54HCTLS 78A KS74HCTLS

Dual J-K Flip-Flops with Preset, Common Clear & Common Clock

Objective Specifications

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5\text{V}$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

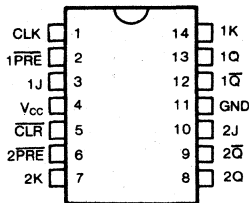
DESCRIPTION

These parts consist of two negative-edge-triggered J-K flip-flops with independent J, K and preset inputs and complementary outputs. The clear and clock inputs are common to both flip-flops. The J-K inputs are enabled when the clock goes high. The input data are transferred to the outputs on the negative-going edge of the clock pulse, provided the setup requirements have been met.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | | | | Outputs | |
|--------|-----|-----|---|---|----------------|-----------------|
| PRE | CLR | CLK | J | K | Q | Q̄ |
| L | H | X | X | X | H | L |
| H | L | X | X | X | L | H |
| L | L | X | X | X | H• | H• |
| H | H | ↓ | L | L | Q ₀ | Q̄ ₀ |
| H | H | ↓ | H | L | H | L |
| H | H | ↓ | L | H | L | H |
| H | H | ↓ | H | H | TOGGLE | |
| H | H | H | X | X | Q ₀ | Q̄ ₀ |

*Both outputs will remain high as long as preset and clear are low, but the output states are unpredictable if preset and clear go high simultaneously.

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range
 KS74HCTLS: -40°C to $+85^\circ\text{C}$
 KS54HCTLS: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|--|---|---------------|
| | | | Typ | Guaranteed Limits | | | |
| | | | | | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 4.0 | 40.0 | 80.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS78A

| Characteristic | Symbol | Conditions [†] | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--|---|-------------------------|--|----|--|---|------|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 40 | 30 | 25 | 21 | MHz |
| Maximum Propagation Delay, CLK to Q or \bar{Q} | t_{PLH} | | 15 | 20 | 25 | 30 | ns |
| | t_{PHL} | | 15 | 20 | 25 | 30 | |
| Maximum Propagation Delay, \overline{PRE} or \overline{CLR} to Q or \bar{Q} | t_{PLH} | | 15 | 20 | 25 | 30 | ns |
| | t_{PHL} | | 15 | 20 | 25 | 30 | |
| Minimum Setup Time before CLK \downarrow | J or K | | t_{su} | 10 | 13 | 17 | 20 |
| | \overline{PRE} or \overline{CLR} Inactive | 10 | | 13 | 17 | 20 | |
| Minimum Hold Time, J or K after CLK \downarrow | t_h | | -3 | 0 | 0 | 0 | ns |
| Minimum Pulse Width | CLK High or Low | t_w | 10 | 13 | 17 | 20 | ns |
| | \overline{PRE} or \overline{CLR} Low | | 10 | 13 | 17 | 20 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} (per flip-flop) | 40 | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

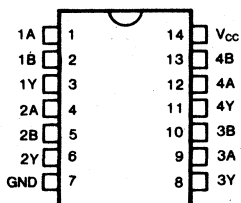
DESCRIPTION

These devices contain four independent 2-input Exclusive-OR gates. They perform the Boolean functions $Y = A \oplus B$ or $Y = \overline{A}B + A\overline{B}$.

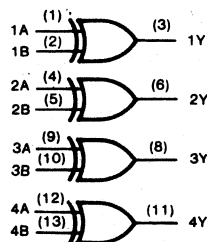
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

(Each Gate)

| Inputs | | Output |
|--------|---|--------|
| A | B | Y |
| L | L | L |
| L | H | H |
| H | L | H |
| H | H | L |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to $+85^\circ\text{C}$
 KS54HCTLS: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|--|---|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-4\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

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AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS86

| Characteristic | Symbol | Conditions† | T _a = 25°C V _{CC} = 5.0V | | KS74 HCTLS | KS54 HCTLS | Unit |
|--|------------------|-----------------------|---|----|---|--|------|
| | | | | | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Propagation Delay, A or B to Y (Other Input Low) | t _{PLH} | C _L = 50pF | 15 | 20 | 25 | 30 | ns |
| | t _{PHL} | | 15 | 20 | 25 | 30 | |
| Maximum Propagation Delay, A or B to Y (Other Input High) | t _{PLH} | | 18 | 25 | 31 | 37 | ns |
| | t _{PHL} | | 18 | 25 | 31 | 37 | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | (per gate) | 15 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current Outputs:
 $I_{OL} = 8\text{mA} @ V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

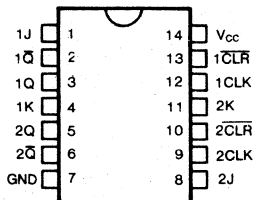
DESCRIPTION

These devices contain two independent J-K negative-edge-triggered flip-flops. A low level at the CLR input resets the outputs regardless of the levels of the other inputs. When CLR is inactive (high), data at the J and K inputs meeting the setup time requirements are transferred to the outputs on the negative-going edge of the clock pulse. Clock triggering occurs at a voltage level and is not directly related to the rise time of the clock pulse. Following the hold time interval, data at the J and K inputs may be changed without affecting the levels at the outputs. These versatile flip-flops can perform as toggle flip-flops by tying J and K high.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | | | Outputs | |
|--------|-----|---|---|---------|-------------|
| CLR | CLK | J | K | Q | Q-bar |
| L | X | X | X | L | H |
| H | ↓ | L | L | Q_0 | \bar{Q}_0 |
| H | ↓ | H | L | H | L |
| H | ↓ | L | H | L | H |
| H | ↓ | H | H | TOGGLE | |
| H | H | X | X | Q_0 | \bar{Q}_0 |

Absolute Maximum Ratings*

| | |
|--|-----------------|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_{Df} | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

| | |
|----------------------|------------------------------|
| Plastic Package (N): | -12mW/°C from 65°C to 85°C |
| Ceramic Package (J): | -12mW/°C from 100°C to 125°C |

Recommended Operating Conditions

| | |
|--|----------------------------|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74HCTLS: -40°C to +85°C |
| | KS54HCTLS: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|--|---|---------------------|---------------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-4\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 4.0 | 40.0 | 80.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS107A

| Characteristic | Symbol | Conditions [†] | T _a = 25°C V _{CC} = 5.0V | | KS74HCTLS | KS54HCTLS | Unit |
|---|----------------------|-------------------------|---|----|---|--|------|
| | | | | | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Clock Frequency | f _{max} | C _L = 50pF | 40 | 30 | 25 | 21 | MHz |
| Maximum Propagation Delay, CLK to Q or \bar{Q} | t _{PLH} | | 15 | 20 | 25 | 30 | ns |
| | t _{PHL} | | 15 | 20 | 25 | 30 | |
| Maximum Propagation Delay, \bar{CLR} to Q or \bar{Q} | t _{PLH} | | 15 | 20 | 25 | 30 | ns |
| | t _{PHL} | | 15 | 20 | 25 | 30 | |
| Minimum Setup Time before CLK↓ | J or K | | t _{su} | 10 | 13 | 17 | 20 |
| | \bar{CLR} Inactive | 10 | | 13 | 17 | 20 | |
| Minimum Hold Time, J or K after CLK↓ | t _h | | -3 | 0 | 0 | 0 | ns |
| Minimum Pulse Width | CLK High or Low | t _w | 10 | 13 | 17 | 20 | ns |
| | \bar{CLR} Low | | 10 | 13 | 17 | 20 | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | (per flip-flop) | 40 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current Outputs:
I_{OL} = 8mA @ V_{OL} = 0.5V
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C

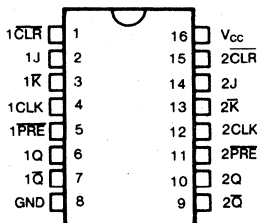
DESCRIPTION

These devices contain two positive-edge-triggered J-K flip-flops with independent preset and clear inputs and complementary Q and \bar{Q} outputs. The present and clear inputs are active-low and operate independently of the clock Data at the J and K inputs are transferred to the outputs on the positive transition of the clock provided setup requirements have been met. These versatile flip-flops can perform as toggle flip-flops by grounding \bar{K} and tying J high. They can also perform as D-type flops if J and K are tied together.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | | | | Outputs | |
|--------|-----|-----|---|-----------|----------------|------------------------|
| PRE | CLR | CLK | J | \bar{K} | Q | \bar{Q} |
| L | H | X | X | X | H | L |
| H | L | X | X | X | L | H |
| L | L | X | X | X | H* | H* |
| H | H | ↑ | L | L | L | H |
| H | H | ↑ | H | L | TOGGLE | |
| H | H | ↑ | L | H | Q ₀ | \bar{Q} ₀ |
| H | H | ↑ | H | H | H | L |
| H | H | L | X | X | Q ₀ | \bar{Q} ₀ |

*Both outputs will remain high as long as PRE and CLR are low, but the output states are unpredictable if PRE and CLR go high simultaneously.

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} ... -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN}, V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|---|--|-----------------------|---------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ | KS54HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4:2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 4.0 | 40.0 | 80.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS109A

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--|---------------------|---------------------|--|----|--|---|------|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Clock Frequency | f_{\max} | $C_L = 50\text{pF}$ | 40 | 30 | 25 | 20 | MHz |
| Maximum Propagation Delay, CLK to Q or \bar{Q} | t_{PLH} | | 18 | 25 | 31 | 37 | ns |
| | t_{PHL} | | 30 | 40 | 50 | 60 | |
| Maximum Propagation Delay, PRE or CLR to Q or \bar{Q} | t_{PLH} | | 18 | 25 | 31 | 37 | ns |
| | t_{PHL} | 30 | 40 | 50 | 60 | | |
| Minimum Setup Time before CLK† | Data | t_{su} | 10 | 13 | 17 | 20 | ns |
| | PRE or CLR Inactive | | 10 | 13 | 17 | 20 | |
| Minimum Hold Time, Data after CLK↓ | t_h | | -3 | 0 | 0 | 0 | ns |
| Minimum Pulse Width | CLK High or Low | t_w | 8 | 15 | 20 | 25 | ns |
| | PRE or CLR Low | | 8 | 15 | 20 | 25 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per flip-flop) | 40 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current Outputs:
 $I_{OL} = 8mA @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74HCTLS: $-40^{\circ}C$ to $+85^{\circ}C$
 KS54HCTLS: $-55^{\circ}C$ to $+125^{\circ}C$

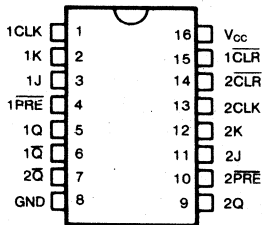
DESCRIPTION

These parts consist of two negative-edge-triggered J-K flip-flops with independent J, K, preset, clear and clock inputs and complementary outputs. The J-K inputs at each flip-flop are enabled when the clock goes high. The input data are transferred to the outputs on the negative-going edge of the clock pulse, provided the setup requirements have been met.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | | | | Outputs | |
|--------|-----|-----|---|---|----------------|---------------------|
| PRE | CLR | CLK | J | K | Q | Q-bar |
| L | H | X | X | X | H | L |
| H | L | X | X | X | L | H |
| L | L | X | X | X | H* | H* |
| H | H | ↓ | L | L | Q ₀ | Q ₀ -bar |
| H | H | ↓ | H | L | H | L |
| H | H | ↓ | L | H | L | H |
| H | H | ↓ | H | H | TOGGLE | |
| H | H | H | X | X | Q ₀ | Q ₀ -bar |

*Both outputs will remain high as long as PRE and CLR are low, but the output states are unpredictable if PRE and CLR go high simultaneously.

Absolute Maximum Ratings*

| | |
|---|---|
| Supply Voltage Range V_{CC} , | -0.5V to +7V |
| DC Input Diode Current, I_{IK} ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

| | |
|---|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN} , V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74HCTLS: -40°C to $+85^\circ\text{C}$ KS54HCTLS: -55°C to $+125^\circ\text{C}$ |
| Input Rise & Fall Times, t_r , t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|--|---|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 4.0 | 40.0 | 80.0 | μA |
| Additional Worst-Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS112A

| Characteristic | Symbol | Conditions† | T _a = 25°C V _{CC} = 5.0V | | KS74HCTLS | KS54HCTLS | Unit |
|---|------------------|-----------------------|---|----|---|--|------|
| | | | | | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Clock Frequency | f _{max} | C _L = 50pF | 40 | 30 | 25 | 21 | MHz |
| Maximum Propagation Delay, CLK to Q or \bar{Q} | t _{PLH} | | 15 | 20 | 25 | 30 | ns |
| | t _{PHL} | | 15 | 20 | 25 | 30 | |
| Maximum Propagation Delay, CLR to Q or \bar{Q} | t _{PLH} | | 15 | 20 | 25 | 30 | ns |
| | t _{PHL} | | 15 | 20 | 25 | 30 | |
| Minimum Setup Time before CLK‡ | J or K | | t _{su} | 10 | 13 | 17 | 20 |
| | CLR Inactive | 10 | | 13 | 17 | 20 | |
| Minimum Hold Time, Data after CLK ↓ | t _h | | -3 | 0 | 0 | 0 | ns |
| Minimum Pulse Width | CLK High or Low | t _w | 10 | 13 | 17 | 20 | ns |
| | PRE or CLR Low | | 10 | 13 | 17 | 20 | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | (per flip-flop) | 40 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

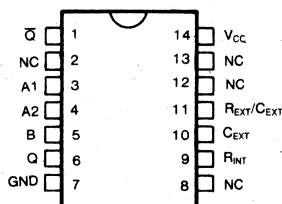
† For AC switching test circuits and timing waveforms see section 2.

Product Preview

FEATURES

- Schmitt-trigger for slow Input transitions
- Internal timing resistor
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | | Outputs | |
|--------|----|---|---------|-----------|
| A1 | A2 | B | Q | \bar{Q} |
| L | X | H | L | H |
| X | L | H | L | H |
| X | X | L | L | H |
| H | H | X | L | H |
| H | ↓ | H | ⌋ | ⌋ |
| ↓ | H | H | ⌋ | ⌋ |
| ↓ | ↓ | H | ⌋ | ⌋ |
| L | X | ↑ | ⌋ | ⌋ |
| X | L | ↑ | ⌋ | ⌋ |

DESCRIPTION

These multivibrators feature dual negative-transition-triggered inputs and a single positive-transition-triggered input which can be used as an inhibit input. Complementary output pulses are provided.

Pulse triggering occurs at a particular voltage level and is not directly related to the transition time of the input pulse. Schmitt-trigger input circuitry for the B input allows jitter-free triggering from inputs with transition rates as slow as 1 volt/second, providing the circuit with excellent noise immunity.

Once fired, the outputs are independent of further transitions of the inputs and are a function only of the timing components. Input pulses may be of any duration relative to the output pulse. Output pulse length may be varied from 40 nanoseconds to 28 seconds by choosing appropriate timing components. With no external timing components (i.e., R_{INT} connected to V_{CC} , C_{EXT} and C_{EXT}/C_{EXT} open), an output pulse of typically 30 or 35 nanoseconds is achieved which may be used as a d-c triggered reset signal.

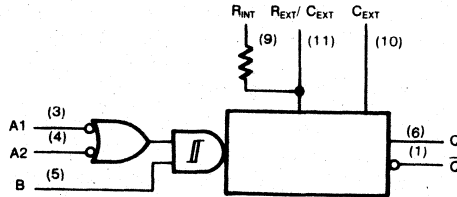
Pulse width stability is achieved through internal compensation and is virtually independent of V_{CC} and temperature. In most applications, pulse stability will only be limited by the accuracy of external timing components.

Jitter-free operation is maintained over the full temperature and V_{CC} ranges for more than six decades of timing capacitance (10 pF to 10 μF) and more than one decade of timing resistance (2 k Ω to 40 k Ω). Throughout these ranges, pulse width is defined by the relationship $tw_{(out)} = C_{EXT} R_T \ln 2 = 0.7 C_{EXT} R_T$. In circuits where pulse cutoff is not critical, timing capacitance up to 1000 μF and timing resistance as low as 1.4 k Ω may be used. Also, the range of jitter-free output pulse widths is extended if V_{CC} is held to 5 volts and free-air temperature is 25 $^{\circ}\text{C}$. Duty cycles as high as 90% are achieved when using maximum recommended R_T . Higher duty cycles are available if a certain amount of pulse-width jitter is allowed.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAM



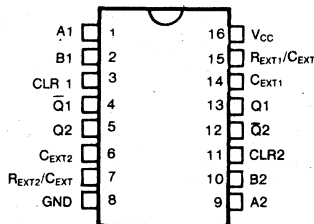
- Notes:**
1. An external capacitor may be connected between C_{EXT} (positive) and R_{EXT}/C_{EXT}.
 2. To use the internal timing resistor, connect R_{INT} to V_{CC}. For improved pulse width accuracy and repeatability connect on external resistor between R_{EXT}/C_{EXT} V_{CC} with R_{INT} open-circuited.

Product Preview

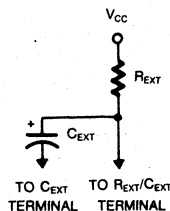
FEATURES

- Simple pulse width formula $T = RC$
- Wide pulse range: 40 ns to ∞ (typ)
- Part to part variation: $\pm 5\%$ (typ)
- Schmitt Trigger A & B Inputs enable infinite signal input rise and fall times
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



TIMING COMPONENT



DESCRIPTION

The '123 consists of two independent monostable multivibrators that feature both a negative, A, and a positive, B, transition triggered input, either of which can be used as an inhibit input. Also included is a clear input that when taken low resets the one shot. The '123 can be triggered on the positive transition of the clear while A is held low and B is held high.

The '123 is retriggerable. That is, it may be triggered repeatedly while their outputs are generating a pulse and the pulse will be extended.

Pulse width stability over a wide range of temperature and supply is achieved using linear CMOS techniques. The output pulse equation is simply: $PW = (R_{EXT}) (C_{EXT})$; where PW is in seconds, R is ohms, and C is in farads.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLE

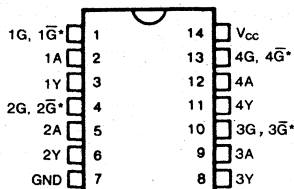
| Inputs | | | Outputs | |
|------------|--------------|------------|---------|-----------|
| CLR | A | B | Q | \bar{Q} |
| L | X | X | L | H |
| X | H | X | L | H |
| X | X | L | L | H |
| H | L | \uparrow | | |
| H | \downarrow | H | | |
| \uparrow | L | H | | |

Preliminary Specifications

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface**
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
KS74HCTLS: -40°C to $+85^\circ\text{C}$
KS54HCTLS: -55°C to $+125^\circ\text{C}$

PIN CONFIGURATION



* \bar{G} for '125; G for '126

FUNCTION TABLES

'125

| Inputs | | Output |
|--------|-----------|--------|
| A | \bar{G} | Y |
| H | L | H |
| L | L | L |
| X | H | Z |

'126

| Inputs | | Output |
|--------|---|--------|
| A | G | Y |
| H | H | H |
| L | H | L |
| X | L | Z |

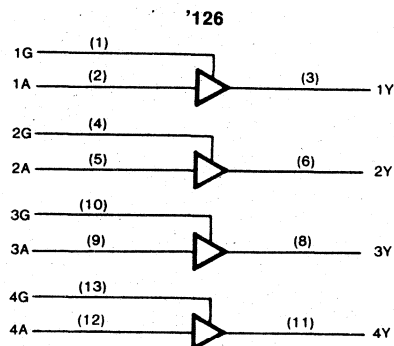
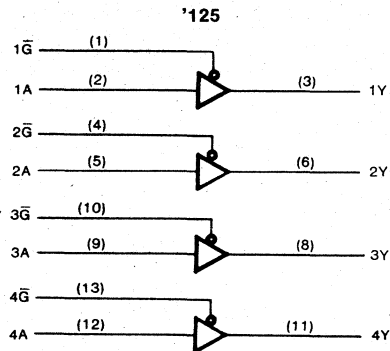
DESCRIPTION

These bus buffers feature four independent line drivers with 3-state outputs. The output enable functions for the '125 buffers are active-low, while those for '126 are active high.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAMS



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to $+85^\circ\text{C}$
 KS54HCTLS: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|---|--|-----------------------|---|
| | | | Typ | KS74HCTLS $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | KS54HCTLS $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | ± 0.1 | ± 1.0 | ± 1.0 | μA | |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | ± 0.5 | ± 5.0 | ± 10.0 | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | 8.0 | 80.0 | 160.0 | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | 2.7 | 2.9 | 3.0 | mA | |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS125, HCTLS126

| Characteristic | Symbol | Conditions† | T _a = 25°C | KS74HCTLS | | KS54HCTLS | | Unit |
|---|-------------------|------------------------|------------------------|---------------------------------|----|----------------------------------|--|------|
| | | | V _{CC} = 5.0V | T _a = -40°C to +85°C | | T _a = -55°C to +125°C | | |
| | | | Typ | Guaranteed Limits | | | | |
| Maximum Propagation Delay, A to Y | t _{PLH} | C _L = 50pF | 13 | 22 | 27 | | | ns |
| | | C _L = 150pF | 16 | 31 | 38 | | | |
| | t _{PHL} | C _L = 50pF | 13 | 22 | 27 | | | |
| | | C _L = 150pF | 16 | 31 | 38 | | | |
| Maximum Output Enable Time, Enable to Y | t _{PZH} | R _L = 1kΩ | | | | | | ns |
| | | C _L = 50pF | 17 | 29 | 34 | | | |
| | t _{PZL} | C _L = 50pF | 17 | 29 | 34 | | | |
| | | C _L = 150pF | 23 | 38 | 45 | | | |
| Maximum Output Disable Time, Enable to Y | t _{PHZ} | R _L = 1kΩ | 16 | 26 | 32 | | | ns |
| | t _{PLZ} | C _L = 50pF | 16 | 26 | 32 | | | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | | pF |
| Maximum Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | | pF |
| Power Dissipation Capacitance* (per stage) | C _{PD} * | Output Disabled | 5 | | | | | pF |
| | | Output Enabled | 30 | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
 KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
 KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

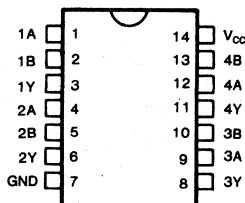
These Schmitt-trigger devices contain four independent NAND gates. They perform the Boolean function $Y = \overline{A \cdot B} = \overline{A} + \overline{B}$ in positive logic.

The input threshold levels are temperature compensated and can be triggered from the slowest of input ranges and still give jitter-free output signals.

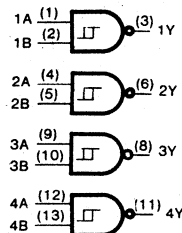
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

| INPUTS | | OUTPUTS |
|--------|---|---------|
| A | B | Y |
| L | L | H |
| L | H | H |
| H | L | H |
| H | H | L |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_D † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to $+85^\circ\text{C}$
 KS54HCTLS: -55°C to $+125^\circ\text{C}$

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--|-----------------|--|--------------------------|----------------------|----------------------|--|---------------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | |
| Minimum Positive-Going Threshold Voltage | V_{T+} | | 1.6 | 1.9 | 1.9 | 1.9 | V |
| Maximum Negative-Going Threshold Voltage | V_{T-} | | 0.8 | 0.5 | 0.5 | 0.5 | V |
| Hysteresis ($V_{T+} - V_{T-}$) | V_H | Min | 0.8 | 0.4 | 0.4 | 0.4 | V |
| | | Max | 0.8 | 1.4 | 1.4 | 1.4 | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-4\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS132

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74 HCTLS | KS54 HCTLS | Unit |
|---|-----------|---------------------|--|----|--|---|------|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Propagation Delay Any Input to Y | t_{PLH} | $C_L = 50\text{pF}$ | 17 | 22 | 28 | 33 | ns |
| | t_{PHL} | | 17 | 22 | 28 | 33 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
 KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
 KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

The '133 contains a single 13-input NAND gate. It performs the Boolean functions (in positive logic):

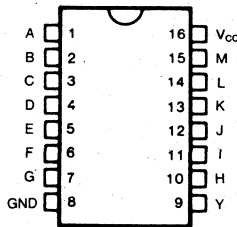
$$Y = \overline{A \cdot B \cdot C \cdot D \cdot E \cdot F \cdot G \cdot H \cdot I \cdot J \cdot K \cdot L \cdot M}$$

$$Y = \overline{\overline{A} + \overline{B} + \overline{C} + \overline{D} + \overline{E} + \overline{F} + \overline{G} + \overline{H} + \overline{I} + \overline{J} + \overline{K} + \overline{L} + \overline{M}}$$

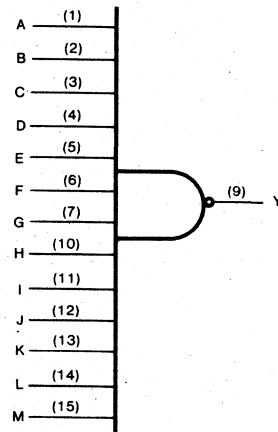
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

| INPUTS A THRU M | | OUTPUT Y |
|--------------------|---|----------|
| All inputs | H | L |
| One or more inputs | L | H |

5

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to $+85^\circ\text{C}$
 KS54HCTLS: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|---|-----------------------|--|-----------------------|---------------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | $V_{CC} - 0.1$ 3.7 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | 0.1 0.4 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | 40.0 | 40.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | 3.0 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns), HCTLS133

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC}=5.0V$ | | KS74HCTLS $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ $V_{CC}=5.0V \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ $V_{CC}=5.0V \pm 10\%$ | | Unit |
|---|-----------|---------------------|---|-------------------|---|----|--|-------------|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay Any Input to Y | t_{PLH} | $C_L = 50\text{pF}$ | 18 | 24 | 30 | 36 | 36 | 36 | ns |
| | t_{PHL} | | 18 | 25 | 30 | 36 | 36 | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | | | | | | pF | |

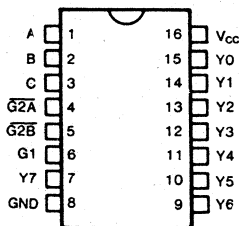
* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Designed specifically for high-speed memory decoders and data transmission systems
- Incorporates 3 enable inputs to simplify cascading and/or data reception
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



FUNCTION TABLE

| Enable Inputs | | Select Inputs | | | Outputs | | | | | | | |
|---------------|-------------------|---------------|---|---|---------|----|----|----|----|----|----|----|
| G1 | $\overline{G2}^*$ | C | B | A | Y0 | Y1 | Y2 | Y3 | Y4 | Y5 | Y6 | Y7 |
| X | H | X | X | X | H | H | H | H | H | H | H | H |
| L | X | X | X | X | H | H | H | H | H | H | H | H |
| H | L | L | L | L | L | L | H | H | H | H | H | H |
| H | L | L | L | H | H | L | H | H | H | H | H | H |
| H | L | L | H | L | H | H | L | H | H | H | H | H |
| H | L | H | L | L | H | H | H | H | L | H | H | H |
| H | L | H | L | H | H | H | H | H | H | L | H | H |
| H | L | H | H | L | H | H | H | H | H | H | L | H |
| H | L | H | H | H | H | H | H | H | H | H | H | L |

* $G2 = G2A + G2B$

DESCRIPTION

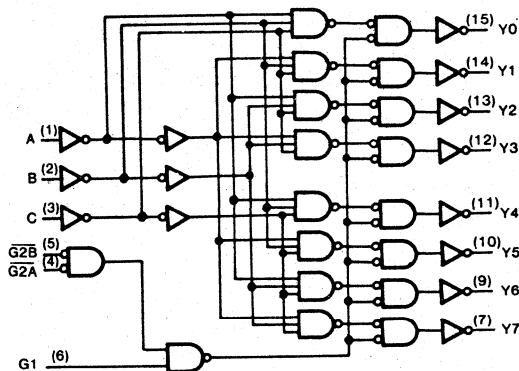
These devices are designed to be used in high-performance memory-decoding or data-routing applications requiring very short propagation delay times. In high-performance memory systems, these decoders can be used to minimize the effects of system decoding. When used with high-speed memories utilizing a fast-enable circuit, the delay times of these decoders and the enable time of the memory are usually less than the typical access time of the memory. This means that the effective system delay introduced by the decoder is negligible.

The conditions at the binary select inputs and the three enable inputs select one of eight input lines. Two active-low and one active-high enable inputs reduce the need for external gates or inverters when expanding. A 24-line decoder can be implemented without external inverters and a 32-line decoder requires only one inverter. An enable input can be used as a data input for demultiplexing applications.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} ... -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|---|--|---------------------|---------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ | KS54HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| | | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-4mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS138

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74 HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54 HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|---|------------------|-----------------------|--|-------------------|--|----|---|--|------|
| | | | Typ | Guaranteed Limits | Guaranteed Limits | | | | |
| Maximum Propagation Delay, A or B to Y | t _{PLH} | C _L = 50pF | 22 | 30 | 37 | 45 | ns | | |
| | t _{PHL} | | 22 | 30 | 37 | 45 | | | |
| Maximum Propagation Delay, G1 to any Y | t _{PLH} | | 24 | 32 | 40 | 48 | ns | | |
| | t _{PHL} | | 24 | 32 | 40 | 48 | | | |
| Maximum Propagation Delay, G2A or G2B to any Y | t _{PLH} | | 18 | 25 | 31 | 37 | ns | | |
| | t _{PHL} | | 18 | 25 | 31 | 37 | | | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | pF | | | |
| Power Dissipation Capacitance* | C _{PD} |) | 50 | | | pF | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Designed specifically for high-speed memory decoders and data transmission systems
- Incorporates 2 enable inputs to simplify cascading and/or data reception
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
I_{OL} = 8 mA @ V_{OL} = 0.5V
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C

DESCRIPTION

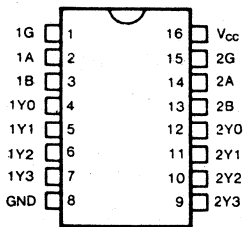
These devices are designed to be used in high-performance memory-decoding or data-routing applications requiring very short propagation delay times. In high-performance memory systems, these decoders can be used to minimize the effects of system decoding. When used with high-speed memories utilizing a fast-enable circuit, the delay times of these decoders and the enable time of the memory are usually less than the typical access time of the memory. This means that the effective system delay introduced by the decoder is negligible.

The '139 consists of two individual two-line to four-line decoders in a single package. The active-low enable input can be used as a data line in demultiplexing applications.

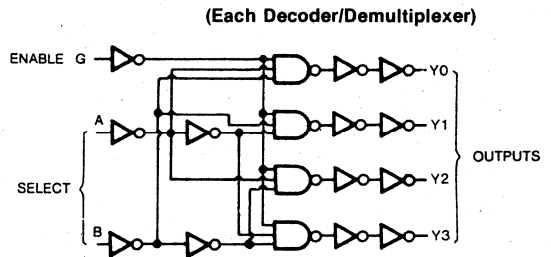
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

| Inputs | | | Outputs | | | |
|-------------|-------------|---|---------|----|----|----|
| Enable G | Select B | A | Y0 | Y1 | Y2 | Y3 |
| H | X | X | H | H | H | H |
| L | L | L | L | H | H | H |
| L | L | H | H | L | H | H |
| L | H | L | H | H | L | H |
| L | H | H | H | H | H | L |

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} . . 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: $-40^\circ C$ to $+85^\circ C$
 KS54HCTLS: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------|----------------------|----------------------|--------------------------------------|---------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ C$ to $+85^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-4mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS139

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit |
|---|-----------|---------------------|--|----|--|---|------|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Propagation Delay, A or B to Y | t_{PLH} | $C_L = 50\text{pF}$ | 22 | 30 | 37 | 45 | ns |
| | t_{PHL} | | 22 | 30 | 37 | 45 | |
| Maximum Propagation Delay, G to any Y | t_{PLH} | | 21 | 28 | 35 | 42 | ns |
| | t_{PHL} | | 21 | 28 | 35 | 42 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF* |
| Power Dissipation Capacitance* | C_{PD} | | 50 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Objective Specifications

FEATURES

- Encodes eight data lines in priority
- Provides 3-bit binary priority code
- Input enable capability
- Easily cascadable
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
 KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

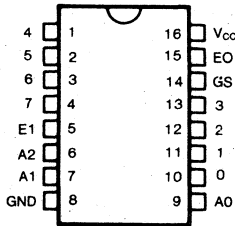
DESCRIPTION

The '148 provides three bits of binary coded output representing the position of the highest order active input, along with an output indicating the presence of any active input. It is easily expanded via input and output enables to provide priority encoding over many bits.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

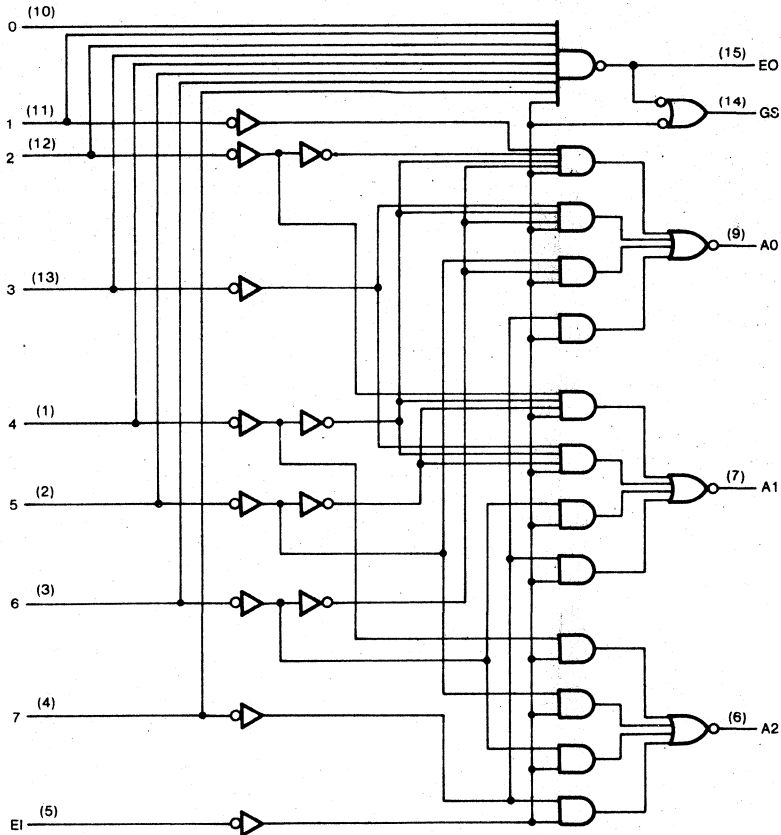
PIN CONFIGURATION



FUNCTION TABLE

| EI | Inputs | | | | | | | Outputs | | | | | |
|----|--------|---|---|---|---|---|---|---------|----|----|----|----|----|
| | 0 | 1 | 2 | 3 | 4 | 5 | 6 | 7 | A2 | A1 | A0 | GS | EO |
| H | X | X | X | X | X | X | X | X | H | H | H | H | H |
| L | H | H | H | H | H | H | H | H | H | H | H | H | L |
| L | X | X | X | X | X | X | L | H | L | L | L | L | H |
| L | X | X | X | X | X | L | H | H | L | L | H | L | H |
| L | X | X | X | X | L | H | H | H | L | H | H | L | H |
| L | X | X | X | L | H | H | H | H | H | L | L | L | H |
| L | X | X | L | H | H | H | H | H | H | L | H | L | H |
| L | X | L | H | H | H | H | H | H | H | H | L | L | H |
| L | L | H | H | H | H | H | H | H | H | H | H | L | H |

LOGIC DIAGRAM



Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} , -0.5V to +7V
- DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
- DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
- Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
- Continuous Current Through
 V_{CC} or GND pins ± 125 mA
- Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
- Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

- Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
- Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN}, V_{OUT} . . . 0V to V_{CC}
- Operating Temperature
Range
KS74HCTLS: $-40^\circ C$ to $+85^\circ C$
KS54HCTLS: $-55^\circ C$ to $+125^\circ C$
- Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ | | KS54HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ | | Unit |
|--------------------------------------|-----------------|--|--------------------|----------------------|---|-----|--|--|---------|
| | | | Typ | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-4mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | | $V_{CC}-0.1$ 3.7 | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | | 0.1 0.4 | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | | ± 1.0 | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | | 160.0 | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_i=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | | 3.0 | | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS148

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ $V_{CC}=5.0V$ | | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ $V_{CC}=5.0V \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ $V_{CC}=5.0V \pm 10\%$ | | Unit |
|---|-----------|-------------|-------------------------------------|----|---|--|--|----|------|
| | | | Typ | | Guaranteed Limits | | | | |
| Maximum Propagation Delay, 1-7 to A0, A1 or A2 | t_{PLH} | $C_L=50pF$ | 20 | 27 | 34 | | 41 | ns | |
| | t_{PHL} | | 20 | 27 | 34 | | 41 | | |
| Maximum Propagation Delay, 0-7 to EO | t_{PLH} | | 22 | 29 | 36 | | 44 | ns | |
| | t_{PHL} | | 22 | 29 | 36 | | 44 | | |
| Maximum Propagation Delay, 0-7 to GS | t_{PLH} | | 28 | 38 | 47 | | 57 | ns | |
| | t_{PHL} | | 28 | 38 | 47 | | 57 | | |
| Maximum Propagation Delay, E1 to A0, A1 or A2 | t_{PLH} | | 19 | 25 | 31 | | 38 | ns | |
| | t_{PHL} | | 19 | 25 | 31 | | 38 | | |
| Maximum Propagation Delay, E1 to GS | t_{PLH} | | 20 | 26 | 33 | | 39 | ns | |
| | t_{PHL} | | 20 | 26 | 33 | | 39 | | |
| Maximum Propagation Delay, E1 to EO | t_{PLH} | | 21 | 28 | 35 | | 42 | ns | |
| | t_{PHL} | | 21 | 28 | 35 | | 42 | | |
| Maximum Input Capacitance | C_{IN} | | | 5 | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | (per gate) | 50 | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

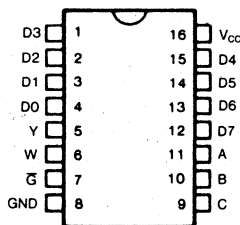
† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Can perform as:
 - Boolean Function Generators
 - Parallel-to-Serial Converters
 - Data Source Selectors
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



DESCRIPTION

These monolithic data selectors/multiplexers provide full binary decoding to select one of eight data sources. The strobe input (\bar{G}) must be at a low logic level to enable the inputs. A high level at the strobe terminal forces the W output high and the Y output low.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLE

| INPUTS | | | | OUTPUTS | |
|--------|---|---|---------------------|---------|-----------------|
| SELECT | | | STROBE \bar{G} | Y | W |
| C | B | A | | | |
| X | X | X | H | L | H |
| L | L | L | L | D0 | $\overline{D0}$ |
| L | L | H | L | D1 | $\overline{D1}$ |
| L | H | L | L | D2 | $\overline{D2}$ |
| L | H | H | L | D3 | $\overline{D3}$ |
| H | L | L | L | D4 | $\overline{D4}$ |
| H | L | H | L | D5 | $\overline{D5}$ |
| H | H | L | L | D6 | $\overline{D6}$ |
| H | H | H | L | D7 | $\overline{D7}$ |

H = high level, L = low level, X = irrelevant
D0, D1 ... D7 = the level of the D respective input

Absolute Maximum Ratings*

| | |
|---|---|
| Supply Voltage Range V_{CC} , | $-0.5V$ to $+7V$ |
| DC Input Diode Current, I_{IK} ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | $\pm 20 \text{ mA}$ |
| DC Output Diode Current, I_{OK} ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | $\pm 20 \text{ mA}$ |
| Continuous Output Current Per Pin, I_O ($-0.5V < V_O < V_{CC} + 0.5V$) | $\pm 70 \text{ mA}$ |
| Continuous Current Through V_{CC} or GND pins | $\pm 250 \text{ mA}$ |
| Storage Temperature Range, T_{stg} | -65°C to $+150^{\circ}\text{C}$ |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

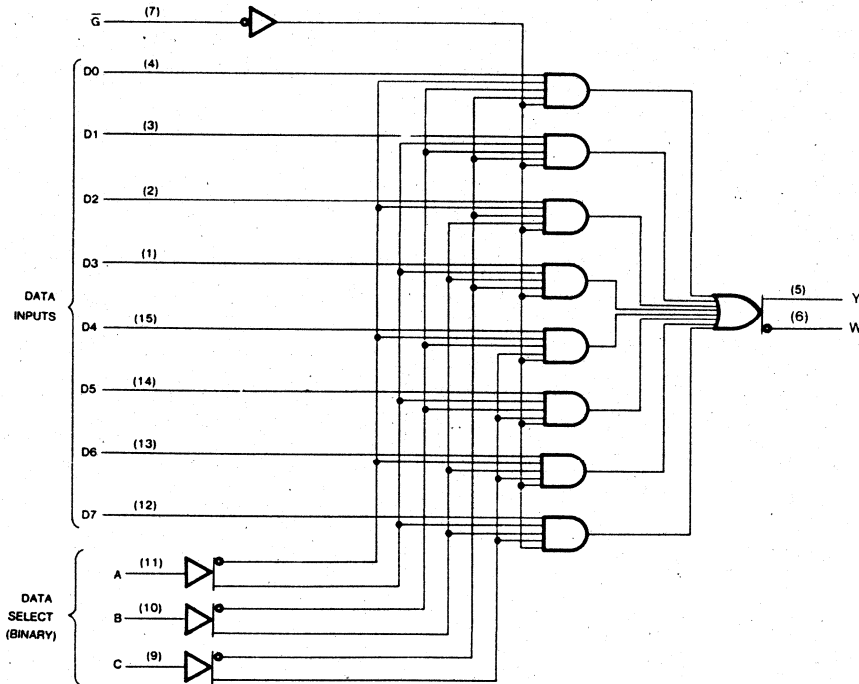
Plastic Package (N): $-12\text{mW}/^{\circ}\text{C}$ from 65°C to 85°C
Ceramic Package (J): $-12\text{mW}/^{\circ}\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74HCTLS: -40°C to $+85^{\circ}\text{C}$ KS54HCTLS: -55°C to $+125^{\circ}\text{C}$ |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

LOGIC DIAGRAM



5

DC ELECTRICAL CHARACTERISTICS (V_{CC}=5V±10% Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | T _a = 25°C | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|------------------|---|------------------------|-------------------------------|---------------------------------|----------------------------------|------|
| | | | Typ | | T _a = -40°C to +85°C | T _a = -55°C to +125°C | |
| | | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V _{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V _{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V _{OH} | V _{IN} =V _{IH} or V _{IL} I _O =-20μA I _O =-6mA | V _{CC} 4.2 | V _{CC} - 0.1 3.98 | V _{CC} - 0.1 3.84 | V _{CC} - 0.1 3.7 | V |
| Maximum Low-Level Output Voltage | V _{OL} | V _{IN} =V _{IH} or V _{IL} I _O =20μA I _O =12mA I _O =24mA | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I _{IN} | V _{IN} =V _{CC} or GND | | ±0.1 | ±1.0 | ±1.0 | μA |
| Maximum Quiescent Supply Current | I _{CC} | V _{IN} =V _{CC} or GND I _{OUT} =0μA | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI _{CC} | per input pin V _I =2.4V other Inputs: at V _{CC} or GND I _{OUT} =0μA | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS151

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|--|-----------|----------------------|--|----|---|----|--|--|------|
| | | | Typ | | Guaranteed Limits | | | | |
| Maximum Propagation Delay, A, B or C to Y | t_{PLH} | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | ns | | |
| | | $C_L = 150\text{pF}$ | 27 | 39 | 49 | 59 | | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | ns | | |
| | | $C_L = 150\text{pF}$ | 27 | 39 | 49 | 59 | | | |
| Maximum Propagation Delay, A, B or C to W | t_{PLH} | $C_L = 50\text{pF}$ | 27 | 36 | 45 | 54 | ns | | |
| | | $C_L = 150\text{pF}$ | 30 | 43 | 54 | 65 | | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 27 | 36 | 45 | 54 | ns | | |
| | | $C_L = 150\text{pF}$ | 30 | 43 | 54 | 65 | | | |
| Maximum Propagation Delay, Any D to Y | t_{PLH} | $C_L = 50\text{pF}$ | 20 | 26 | 33 | 39 | ns | | |
| | | $C_L = 150\text{pF}$ | 23 | 33 | 42 | 50 | | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 20 | 26 | 33 | 39 | ns | | |
| | | $C_L = 150\text{pF}$ | 23 | 33 | 42 | 50 | | | |
| Maximum Propagation Delay, Any D to W | t_{PLH} | $C_L = 50\text{pF}$ | 16 | 21 | 26 | 32 | ns | | |
| | | $C_L = 150\text{pF}$ | 19 | 28 | 35 | 43 | | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 16 | 21 | 26 | 32 | ns | | |
| | | $C_L = 150\text{pF}$ | 19 | 28 | 35 | 43 | | | |
| Maximum Propagation Delay, \bar{G} to Y | t_{PLH} | $C_L = 50\text{pF}$ | 20 | 26 | 33 | 39 | ns | | |
| | | $C_L = 150\text{pF}$ | 23 | 33 | 42 | 50 | | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 20 | 26 | 33 | 39 | ns | | |
| | | $C_L = 150\text{pF}$ | 23 | 33 | 42 | 50 | | | |
| Maximum Propagation Delay, \bar{G} to W | t_{PLH} | $C_L = 50\text{pF}$ | 20 | 26 | 33 | 39 | ns | | |
| | | $C_L = 150\text{pF}$ | 23 | 33 | 42 | 50 | | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 20 | 26 | 33 | 39 | ns | | |
| | | $C_L = 150\text{pF}$ | 23 | 33 | 42 | 50 | | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF | | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Allows Multiplexing from N Lines to 1 Line
- Performs Parallel-to-Serial Conversion
- Strobe (Enable) Line Provided for Cascading (N lines to n lines)
- '253 is the 3-State Version of this port
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 (I_{OL} = 24 mA @ V_{OL} = 0.5V) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C

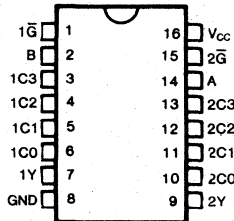
DESCRIPTION

Each of these data selectors/multiplexers contains inverters and drivers to supply full binary decoding data selection to the AND-OR gates. Separate strobe inputs (\bar{G}) are provided for each of the two four-line sections.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

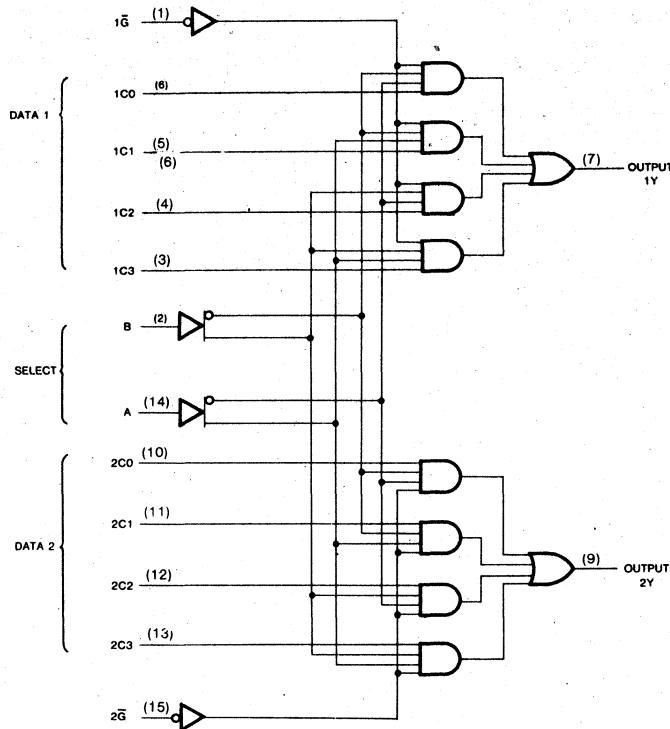
PIN CONFIGURATION



FUNCTION TABLE

| SELECT INPUTS | | DATA INPUTS | | | | STROBE | OUTPUT |
|---------------|---|-------------|----|----|----|-----------|--------|
| B | A | C0 | C1 | C2 | C3 | \bar{G} | Y |
| X | X | X | X | X | X | H | L |
| L | L | L | X | X | X | L | L |
| L | L | H | X | X | X | L | H |
| L | H | X | L | X | X | L | L |
| L | H | X | H | X | X | L | H |
| H | L | X | X | L | X | L | L |
| H | L | X | X | H | X | L | H |
| H | H | X | X | X | L | L | L |
| H | H | X | X | X | H | L | H |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|---|--------------------------|------------------------|--|-----------------------|---|-----------------------|---------------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | $V_{CC} - 0.1$ 3.7 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | 0.1 0.4 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | 160.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4\text{V}$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | 3.0 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns), HCTLS153

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|--|-----------|---|--|-------------------|---|----------|--|----------|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay, A or B to Y | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 23 26 | 30 37 | 38 47 | 38 47 | 45 56 | 45 56 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 23 26 | 30 37 | 38 47 | 38 47 | 45 56 | 45 56 | |
| Maximum Propagation Delay, Data (Any C) to Y | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 15 18 | 20 27 | 25 34 | 25 34 | 30 41 | 30 41 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 15 18 | 20 27 | 25 34 | 25 34 | 30 41 | 30 41 | |
| Maximum Propagation Delay, \bar{G} to Y | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 21 24 | 28 35 | 35 44 | 35 44 | 42 53 | 42 53 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 21 24 | 28 35 | 35 44 | 35 44 | 42 53 | 42 53 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

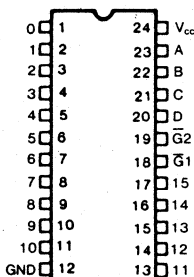
† For AC switching test circuits and timing waveforms see section 2.

Objective Specifications

FEATURES

- Decodes 4 Binary-Coded Inputs into One of 16 Mutually Exclusive Outputs
- Performs the Demultiplexing Function by Distributing Data From One Input to Any One of 16 Outputs
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
 KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



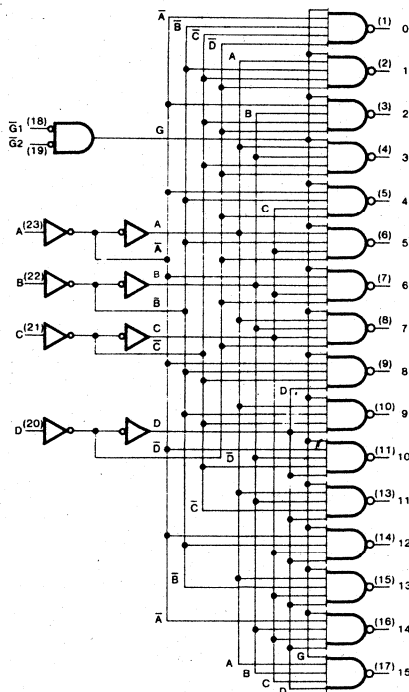
DESCRIPTION

These monolithic, 4-line to 16-line decoders decode four binary-coded inputs into one of sixteen mutually exclusive outputs when both the strobe inputs, \bar{G}_1 and \bar{G}_2 , are low. The demultiplexing function is performed by using the 4 input lines to address the output line, passing data from one of the strobe inputs with the other strobe input low. When either strobe input is high, all outputs are high. These demultiplexers are ideally suited for implementing high-performance memory decoders.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAM



FUNCTION TABLE

| Inputs | | | | | Outputs | | | | | | | | | | | | | | | | | |
|------------|------------|---|---|---|---------|---|---|---|---|---|---|---|---|---|---|----|----|----|----|----|----|---|
| $\bar{G}1$ | $\bar{G}2$ | D | C | B | A | 0 | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 13 | 14 | 15 | |
| L | L | L | L | L | L | L | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H |
| L | L | L | L | L | H | L | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H |
| L | L | L | L | H | L | H | H | L | H | H | H | H | H | H | H | H | H | H | H | H | H | H |
| L | L | L | H | L | L | H | H | H | H | L | H | H | H | H | H | H | H | H | H | H | H | H |
| L | L | L | H | L | H | L | H | H | H | H | L | H | H | H | H | H | H | H | H | H | H | H |
| L | L | L | H | H | L | L | H | H | H | H | H | L | H | H | H | H | H | H | H | H | H | H |
| L | L | L | H | H | H | H | H | H | H | H | H | L | H | H | H | H | H | H | H | H | H | H |
| L | L | H | L | L | L | H | H | H | H | H | H | H | L | H | H | H | H | H | H | H | H | H |
| L | L | H | L | L | H | L | H | H | H | H | H | H | L | H | H | H | H | H | H | H | H | H |
| L | L | H | L | H | L | H | H | H | H | H | H | H | H | H | L | H | H | H | H | H | H | H |
| L | L | H | H | L | L | H | H | H | H | H | H | H | H | H | H | H | L | H | H | H | H | H |
| L | L | H | H | L | H | L | H | H | H | H | H | H | H | H | H | H | H | L | H | H | H | H |
| L | L | H | H | H | L | L | H | H | H | H | H | H | H | H | H | H | H | H | H | L | H | H |
| L | L | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | L |
| L | H | X | X | X | X | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H |
| H | L | X | X | X | X | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H |
| H | H | X | X | X | X | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H | H |

Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} , -0.5V to +7V
- DC Input Diode Current, I_{IK}
 $(V_I < -0.5V \text{ or } V_I > V_{CC} + 0.5V)$ ± 20 mA
- DC Output Diode Current, I_{OK}
 $(V_O < -0.5V \text{ or } V_O > V_{CC} + 0.5V)$ ± 20 mA
- Continuous Output Current Per Pin, I_O
 $(-0.5V < V_O < V_{CC} + 0.5V)$ ± 35 mA
- Continuous Current Through
 V_{CC} or GND pins ± 125 mA
- Storage Temperature Range, T_{stg} -65°C to +150°C
- Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

- † Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN}, V_{OUT} 0V to V_{CC}
- Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
- Input Rise & Fall Times, t_r, t_f Max 500 ns
- * Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

KS54HCTLS 154 4-Line to 16-Line Decoders/Demultiplexers

DC ELECTRICAL CHARACTERISTICS (V_{CC}=5V±10% Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | T _a = 25°C | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|------------------|---|------------------------|------------------------------|------------------------------|-----------------------------|------|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V _{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V _{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V _{OH} | V _{IN} =V _{IH} or V _{IL} I _O =-20μA I _O =-4mA | V _{CC} 4.2 | V _{CC} -0.1 3.98 | V _{CC} -0.1 3.84 | V _{CC} -0.1 3.7 | V |
| Maximum Low-Level Output Voltage | V _{OL} | V _{IN} =V _{IH} or V _{IL} I _O =20μA I _O =4mA I _O =8mA | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I _{IN} | V _{IN} =V _{CC} or GND | | ±0.1 | ±1.0 | ±1.0 | μA |
| Maximum Quiescent Supply Current | I _{CC} | V _{IN} =V _{CC} or GND I _{OUT} =0μA | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI _{CC} | per input pin V _I =2.4V other Inputs: at V _{CC} or GND I _{OUT} =0μA | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r, t_f ≤ 6 ns, HCTLS154)

| Characteristic | Symbol | Conditions† | T _a = 25°C | | KS74 HCTLS | KS54HCTLS | Unit |
|---|------------------|----------------------|------------------------|-------------------|---------------------------------|----------------------------------|------|
| | | | V _{CC} = 5.0V | | T _a = -40°C to +85°C | T _a = -55°C to +125°C | |
| | | | Typ | Guaranteed Limits | | | |
| Maximum Propagation Delay, A, B, C or D to Any Output | t _{PLH} | C _L =50pF | 21 | 28 | 35 | 42 | ns |
| | t _{PHL} | | 21 | 28 | 35 | 42 | |
| Maximum Propagation Delay, G1 or G2 to Any Output | t _{PLH} | | 21 | 28 | 35 | 42 | ns |
| | t _{PHL} | | 21 | 28 | 35 | 42 | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D=C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- **Typical applications:**
Dual 2-to-4 line decoder
Dual 1-to-4 line demultiplexer
3-to-8 line decoder
1-to-8 line demultiplexer
- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
I_{OL} = 8 mA @ V_{OL} = 0.5V
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C

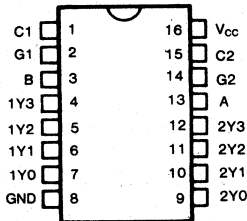
DESCRIPTION

The '155 consists of two 1-to-4 line demultiplexers with independent strobes and common binary address inputs. When both sections are enabled by the strobes, the common address inputs sequentially select and route associated input data to the appropriate output of each section. The individual strobes permit activating or inhibiting each of the 4-bit sections as desired. Data applied to input C1 is inverted at its outputs and data applied to C2 is true through its outputs. The inverter following the C1 data input permits use as a 3-to-8 line decoder, or 1-to-8 line demultiplexer, without gating.

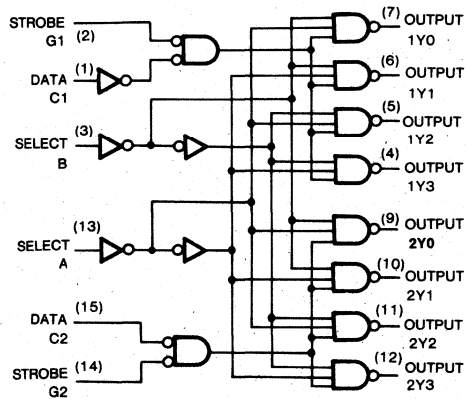
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLES

2-to-4 Line Decoder or 1-to-4 Line Demultiplexer

| Inputs | | | | Outputs | | | |
|--------|--------|------|----|---------|-----|-----|-----|
| Select | Strobe | Data | | | | | |
| B | A | G1 | C1 | 1Y0 | 1Y1 | 1Y2 | 1Y3 |
| X | X | H | X | H | H | H | H |
| L | L | L | H | L | H | H | H |
| L | H | L | H | H | L | H | H |
| H | L | L | H | H | H | L | H |
| H | H | L | H | H | H | H | L |
| X | X | X | L | H | H | H | H |

| Inputs | | | | Outputs | | | |
|--------|--------|------|----|---------|-----|-----|-----|
| Select | Strobe | Data | | | | | |
| B | A | G2 | C2 | 2Y0 | 2Y1 | 2Y2 | 2Y3 |
| X | X | H | X | H | H | H | H |
| L | L | L | L | L | H | H | H |
| L | H | L | L | H | L | H | H |
| H | L | L | L | H | H | L | H |
| H | H | L | L | H | H | H | L |
| X | X | X | H | H | H | H | H |

3-to-8 Line Decoder or 1-to-8 Line Demultiplexer

| Inputs | | | Outputs | | | | | | | |
|--------|----------------|--|---------|-----|-----|-----|-----|-----|-----|-----|
| Select | Strobe or Data | | (0) | (1) | (2) | (3) | (4) | (5) | (6) | (7) |
| IC B A | IG | | 2Y0 | 2Y1 | 2Y2 | 2Y3 | 1Y0 | 1Y1 | 1Y2 | 1Y3 |
| X X X | H | | H | H | H | H | H | H | H | H |
| L L L | L | | L | H | H | H | H | H | H | H |
| L L H | L | | H | L | H | H | H | H | H | H |
| L H L | L | | H | H | L | H | H | H | H | H |
| L H H | L | | H | H | H | L | H | H | H | H |
| H L L | L | | H | H | H | H | L | H | H | H |
| H L H | L | | H | H | H | H | H | L | H | H |
| H H L | L | | H | H | H | H | H | H | L | H |
| H H H | L | | H | H | H | H | H | H | H | L |

IC = Inputs C1 and C2 connected together
IG = Inputs G1 and G2 connected together

Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} , -0.5V to +7V
- DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
- DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
- Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
- Continuous Current Through
 V_{CC} or GND pins ± 125 mA
- Storage Temperature Range, T_{stg} -65°C to +150°C
- Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

- † Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN} , V_{OUT} . . . 0V to V_{CC}
- Operating Temperature
Range
KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C
- Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|---|--------------------------|----------------------|--|---------------------|---|---------------------|---------------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-4\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | $V_{CC}-0.1$ 3.7 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | 0.1 0.4 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | 160.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | 3.0 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS155

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74 HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54 HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|---|-----------|---------------------|--|-------------------|--|----|---|----|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay, A, B, C2, G1 or G2 to any Output (2 levels of logic) | t_{PLH} | $C_L = 50\text{pF}$ | 17 | 23 | 29 | 35 | 35 | 35 | ns |
| | t_{PHL} | | 17 | 23 | 29 | 35 | 35 | | |
| Maximum Propagation Delay, A or B to any Y (3 levels of logic) | t_{PLH} | | 21 | 28 | 35 | 42 | 42 | ns | |
| | t_{PHL} | | 21 | 28 | 35 | 42 | 42 | | |
| Maximum Propagation Delay, C1 to any Y | t_{PHL} | | 20 | 27 | 34 | 41 | 41 | ns | |
| | t_{PHL} | | 20 | 27 | 34 | 41 | 41 | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
I_{OL} = 8 mA @ V_{OL} = 0.5V
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C

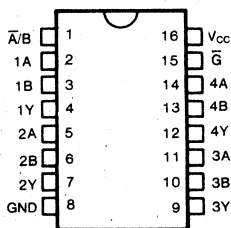
DESCRIPTION

These are data selectors/multiplexers which select a 4-bit word from one of two sources via the control of a common select input (\bar{A}/B). A separate strobe input (\bar{G}) is provided. The '157 presents true data whereas the '158 presents inverted data at the outputs.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

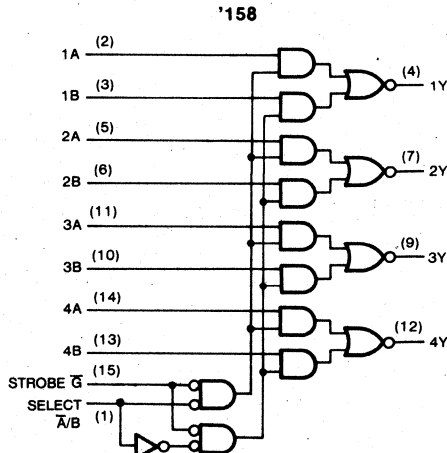
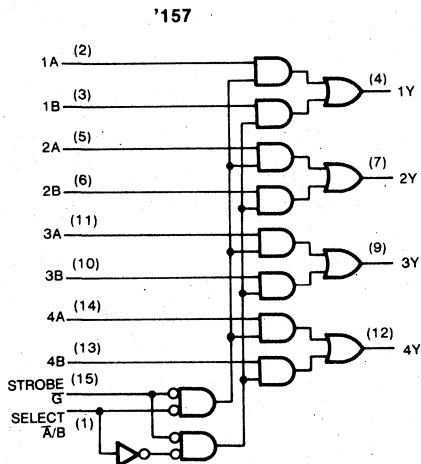
PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | Output Y | | | |
|---------------------|-----------------------|----------|---|------|------|
| Strobe \bar{G} | Select \bar{A}/B | Data | | '157 | '158 |
| | | A | B | | |
| H | X | X | X | L | H |
| L | L | L | X | L | H |
| L | L | H | X | H | L |
| L | H | X | L | L | H |
| L | H | X | H | H | L |

LOGIC DIAGRAMS



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} ... -65°C to +150°C
 Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|--|---|-----------------------|---------------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS157, HCTLS158

| Characteristic | Symbol | Conditions [†] | T _a = 25°C V _{CC} = 5.0V | | KS74HCTLS | KS54 HCTLS | Unit |
|---|------------------|-------------------------|---|----|---|--|------|
| | | | | | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Propagation Delay, A or B to Y | t _{PLH} | | 11 | 15 | 19 | 22 | ns |
| | t _{PHL} | | 11 | 15 | 19 | 22 | |
| Maximum Propagation Delay, A/B to Y | t _{PLH} | | 17 | 23 | 29 | 34 | ns |
| | t _{PHL} | | 17 | 23 | 29 | 34 | |
| Maximum Propagation Delay, G̅ to Y | t _{PLH} | | 15 | 20 | 25 | 30 | ns |
| | t _{PHL} | | 15 | 20 | 25 | 30 | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | (per gate) | | | | | pF |

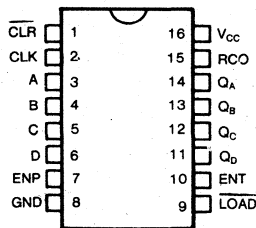
* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Internal Look Ahead for Fast Counting
- Carry Output for n-bit cascading
- Synchronous Counting
- Synchronously Programmable
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
 KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



FUNCTION TABLES

'160, '161

| CLK | CLR | ENP | ENT | LOAD | Function |
|-----|-----|-----|-----|------|---------------------|
| X | L | X | X | X | Clear |
| X | H | H | L | H | Count & RC disabled |
| X | H | L | H | H | Count disabled |
| X | H | L | L | H | Count & RC disabled |
| ↑ | H | X | X | L | Load |
| ↑ | H | H | H | H | Increment Counter |

'162, '163

| CLK | CLR | ENP | ENT | LOAD | Function |
|-----|-----|-----|-----|------|---------------------|
| ↑ | L | X | X | X | Clear |
| X | H | H | L | H | Count & RC disabled |
| X | H | L | H | H | Count disabled |
| X | H | L | L | H | Count & RC disabled |
| ↑ | H | X | X | L | Load |
| ↑ | H | H | H | H | Increment Counter |

DESCRIPTION

These are synchronous, presettable 4-bit binary counters featuring internal carry-look-ahead for high-speed counting. The '160 and '162 are decade counters, and the '161 and '163 are 4-bit binary counters. The buffered clock input triggers all flip-flops simultaneously on the rising edge of the input waveform. This eliminates the output counting spikes normally associated with asynchronous counters.

These counters are fully programmable; that is, the outputs may be preset to either level. As presetting is synchronous, setting up a low level at the load input disables the counter and causes the outputs to agree with the setup data after the next clock pulse regardless of the levels of the enable inputs.

The clear function for the '160 and '161 is asynchronous and a low level at the clear input sets all four of the flip-flop outputs low regardless of the levels of the clock, load or enable inputs.

The clear function for the '162 and '163 is synchronous and a low level at the clear input sets all four of the flip-flop outputs low after the next clock pulse, regardless of the levels of the enable inputs. This synchronous clear allows the count length to be modified easily as decoding the maximum count desired can be accomplished with one external NAND gate. The gate output is connected to the clear input to synchronously clear the counter.

Two enable inputs and a ripple carry output allow easy cascading of the counters. Both count-enable inputs (ENP and ENT) must be high to count, and ENT is fed forward to enable the ripple carry output. The ripple carry output (RCO) thus enabled will produce a high-level pulse while the count is maximum (9 or 15 with Q_A high). This high-level overflow ripple carry pulse can be used to enable successive cascaded stages. Transitions at the ENP or ENT are allowed regardless of the level of the clock input.

These counters feature a fully independent clock circuit. Changes at control inputs (ENP, ENT, or LOAD) that will modify the operating model have no effect on the contents of the counter until clocking occurs. The function of the counter (whether enabled, disabled, loading, or counting) will be dictated solely by the conditions meeting the stable setup and hold times.

These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

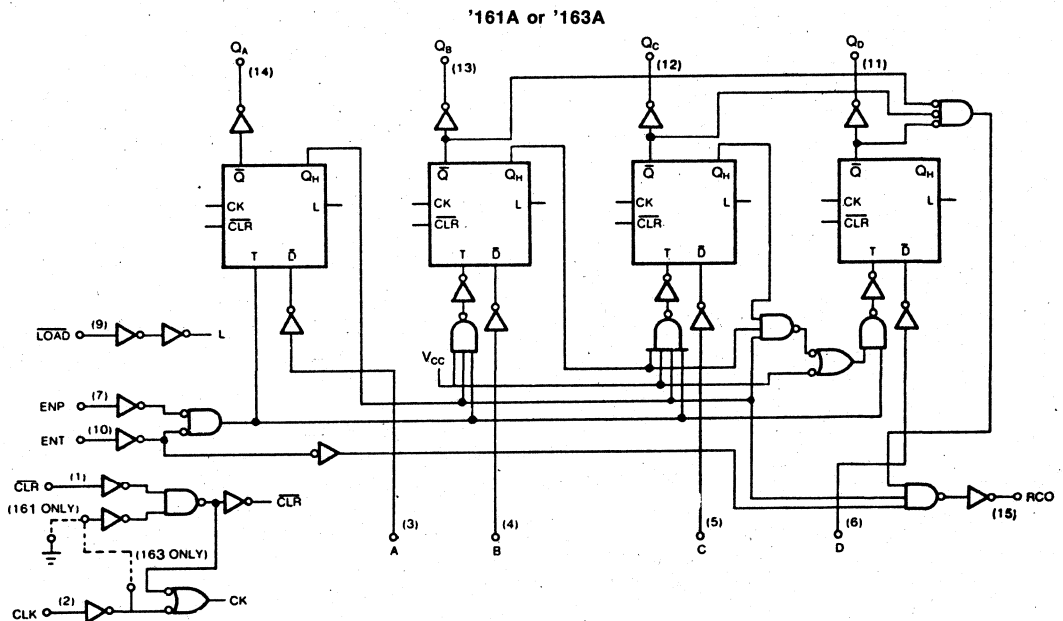
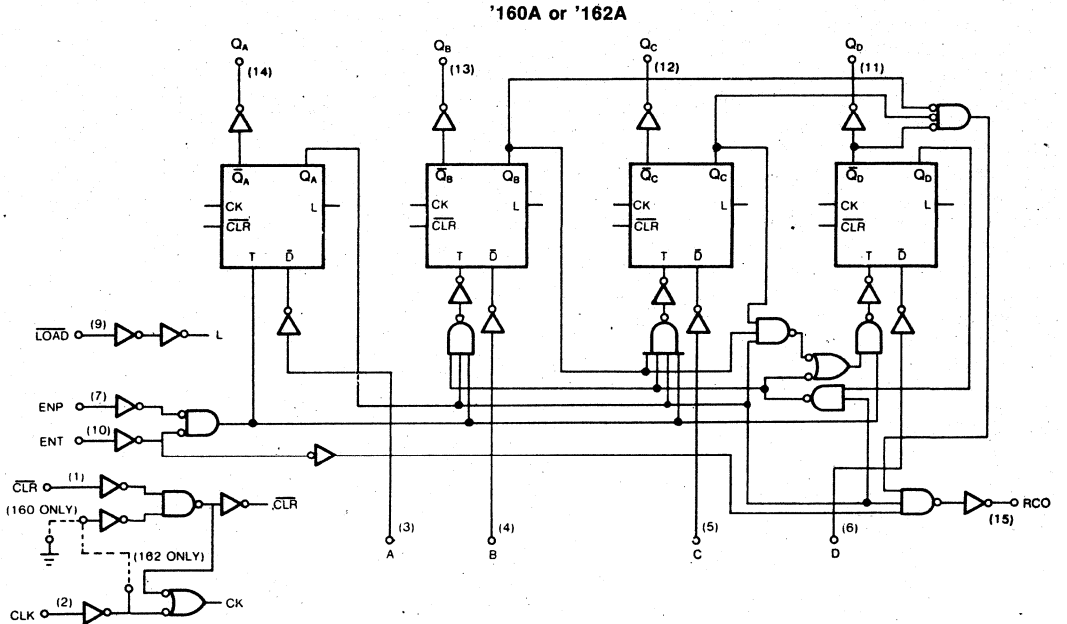
All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.



KS54HCTL5 **160A/161A** KS74HCTL5 **162A/163A**

Synchronous 4-Bit Decade and Binary Counters

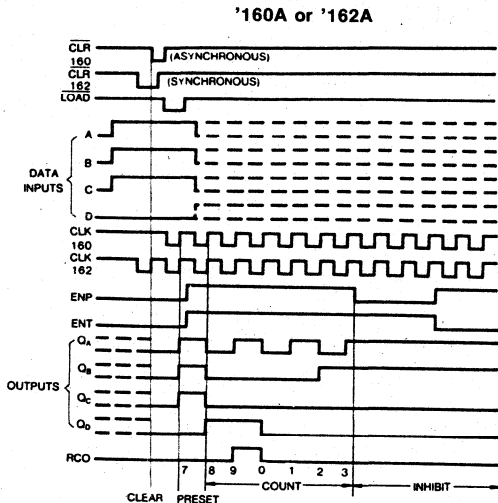
LOGIC DIAGRAMS



KS54HCTLS 160A/161A KS74HCTLS 162A/163A

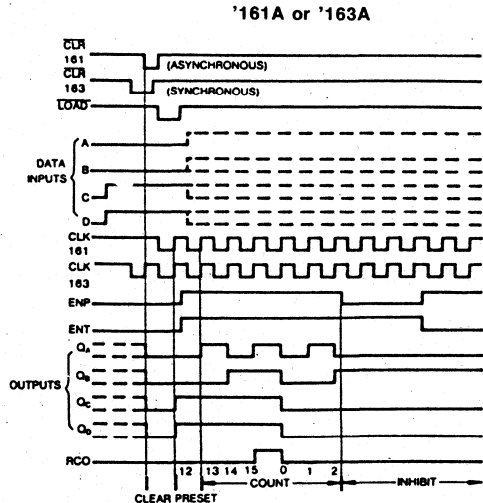
Synchronous 4-Bit Decade and Binary Counters

Typical Clear, Preset, Count and Inhibit Sequences



Sequence:

- (1) Clear outputs to zero
- (2) Preset to BCD seven
- (3) Count to eight, nine, zero, one, two, and three
- (4) Inhibit



Sequence:

- (1) Clear outputs to zero
- (2) Preset to binary twelve
- (3) Count to thirteen, fourteen, fifteen, zero, one and two
- (4) Inhibit

5

Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} , -0.5V to +7V
- DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
- DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
- Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
- Continuous Current Through
 V_{CC} or GND pins ± 125 mA
- Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
- Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

- Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
- Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
- Operating Temperature
Range
KS74HCTLS: -40°C to $+85^\circ\text{C}$
KS54HCTLS: -55°C to $+125^\circ\text{C}$
- Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

KS54HCTLS 160A/161A KS74HCTLS 162A/163A

Synchronous 4-Bit Decade and Binary Counters

DC ELECTRICAL CHARACTERISTICS (V_{CC}=5V±10% Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | T _a = 25°C | | KS74HCTLS T _a = -40°C to +85°C | | KS54HCTLS T _a = -55°C to +125°C | | Unit |
|--------------------------------------|------------------|---|------------------------|------------------------------|--|-----------------------------|---|----|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V _{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V _{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V _{OH} | V _{IN} =V _{IH} or V _{IL} I _O =-20μA I _O =-4mA | V _{CC} 4.2 | V _{CC} -0.1 3.98 | V _{CC} -0.1 3.84 | V _{CC} -0.1 3.7 | | V | |
| Maximum Low-Level Output Voltage | V _{OL} | V _{IN} =V _{IH} or V _{IL} I _O =20μA I _O =4mA I _O =8mA | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | V | |
| Maximum Input Current | I _{IN} | V _{IN} =V _{CC} or GND | | ±0.1 | ±1.0 | ±1.0 | | μA | |
| Maximum Quiescent Supply Current | I _{CC} | V _{IN} =V _{CC} or GND I _{OUT} =0μA | | 8.0 | 80.0 | 160.0 | | μA | |
| Additional Worst Case Supply Current | ΔI _{CC} | per input pin V _I =2.4V other inputs: at V _{CC} or GND I _{OUT} =0μA | | 2.7 | 2.9 | 3.0 | | mA | |

AC ELECTRICAL CHARACTERISTICS (Input t_r, t_f≤6 ns, HCTLS160A, HCTLS161A)

| Characteristic | Symbol | Conditions† | T _a = 25°C V _{CC} = 5.0V | | KS74HCTLS T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | | KS54HCTLS T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | Unit |
|---|------------------|-----------------------|---|-------------------|--|----|---|-----|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Clock Frequency | f _{max} | C _L = 50pF | 40 | 30 | 25 | 20 | | MHz | |
| Maximum Propagation Delay, CLK to RCO | t _{PLH} | | 26 | 35 | 44 | 53 | | ns | |
| | t _{PHL} | | 26 | 35 | 44 | 53 | | ns | |
| Maximum Propagation Delay, CLK to any Q | t _{PLH} | | 20 | 26 | 33 | 39 | | ns | |
| | t _{PHL} | | 20 | 26 | 33 | 39 | | ns | |
| Maximum Propagation Delay, ENT to RCO | t _{PLH} | | 11 | 14 | 18 | 21 | | ns | |
| | t _{PHL} | | 11 | 14 | 18 | 21 | | ns | |
| Maximum Propagation Delay, CLR to any Q | t _{PHL} | | 21 | 28 | 35 | 42 | | ns | |
| Maximum Propagation Delay, CLR to RCO | t _{PHL} | | 21 | 28 | 35 | 42 | | ns | |
| Minimum Pulse Width | CLK High or Low | | t _w | 10 | 13 | 17 | 20 | | ns |
| | CLR Low | 10 | | 13 | 17 | 20 | | ns | |
| Minimum Setup Time before CLK† | A, B, C, D | t _{su} | 10 | 13 | 17 | 20 | | ns | |
| | LOAD* | | 10 | 13 | 17 | 20 | | ns | |
| | ENP, ENT | | 10 | 13 | 17 | 20 | | ns | |
| | CLR inactive | | 10 | 13 | 17 | 20 | | ns | |
| Minimum Hold Time, All Synchronous Inputs after CLK† | t _h | | 0 | 0 | 0 | 0 | | ns | |
| Input Capacitance | C _{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C _{PD} | | 80 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: P_D=C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns), HCTLS162A, HCTLS163A

| Characteristic | Symbol | Conditions [†] | T _a = 25°C V _{CC} = 5.0V | | KS74HCTLS T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | | KS54HCTLS T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | Unit |
|---|------------------|-------------------------|---|-------------------|--|----|---|--|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Clock Frequency | f _{max} | C _L = 50pF | 40 | 30 | 25 | 20 | | | MHz |
| Maximum Propagation Delay, CLK to RCO | t _{PLH} | | 26 | 35 | 44 | 53 | | | ns |
| | t _{PHL} | | 26 | 35 | 44 | 53 | | | |
| Maximum Propagation Delay, CLK to any Q | t _{PLH} | | 20 | 26 | 33 | 39 | | | ns |
| | t _{PHL} | | 20 | 26 | 33 | 39 | | | |
| Maximum Propagation Delay, ENT to RCO | t _{PLH} | | 11 | 14 | 18 | 21 | | | ns |
| | t _{PHL} | | 11 | 14 | 18 | 21 | | | |
| Maximum Propagation Delay, CLR to any Q | t _{PHL} | | 21 | 28 | 35 | 42 | | | ns |
| Maximum Propagation Delay, CLR to RCO | t _{PHL} | | 21 | 28 | 35 | 42 | | | ns |
| Minimum Pulse Width | CLK High or Low | | t _w | 10 | 13 | 17 | 20 | | |
| | CLR Low | 10 | | 13 | 17 | 20 | | | |
| Minimum Setup Time before CLK [†] | A, B, C, D | t _{su} | 10 | 13 | 17 | 20 | | | ns |
| | LOAD | | 10 | 13 | 17 | 20 | | | |
| | ENP, ENT | | 10 | 13 | 17 | 20 | | | |
| | CLR inactive | | 10 | 13 | 17 | 20 | | | |
| | CLR Low | | 10 | 13 | 17 | 20 | | | |
| Minimum Hold Time, All Synchronous Inputs after CLK [†] | t _h | | -3 | 0 | 0 | 0 | | | ns |
| Input Capacitance | C _{IN} | | 5 | | | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | | 80 | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

5

FEATURES

- **AND—Gated (enable/disable) serial inputs**
- **Fully buffered clock and serial inputs**
- **Direct clear**
- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
I_{OL} = 8 mA @ V_{OL} = 0.5V
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C

DESCRIPTION

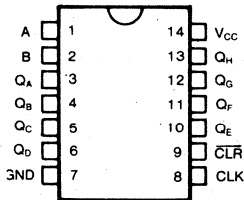
These are high-speed 8-bit registers with AND-gated serial inputs and an asynchronous clear. Data is entered serially through either one of the two inputs, A and B. A high on one input enables the other one, which will then determine the state of the first flip-flop. A low at either or both inputs inhibits data entry and resets the first flip-flop to a low level at the next positive clock transition.

Data at the serial inputs may be changed while the clock is high or low, provided the minimum setup time requirements are met. Clocking occurs on the low-to-high-level transition of their clock input.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

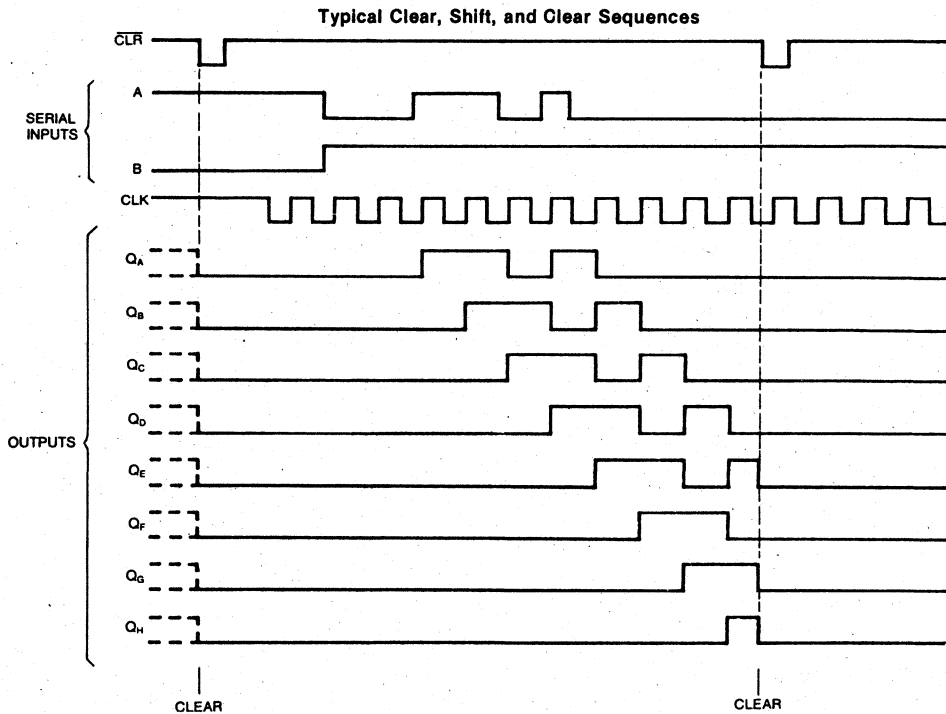
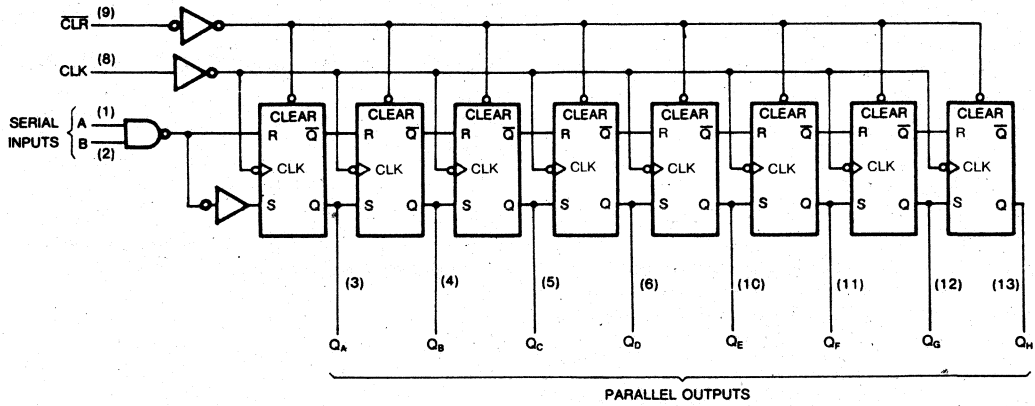


FUNCTION TABLE

| | | Inputs | | Outputs | | |
|-------|-------|--------|---|-----------------|----------------------|-----------------|
| Clear | Clock | A | B | Q _A | Q _B . . . | Q _H |
| L | X | X | X | L | L | L |
| H | L | X | X | Q _{A0} | Q _{B0} | Q _{H0} |
| H | ↑ | H | H | H | Q _{An} | Q _{Gn} |
| H | ↑ | L | X | L | Q _{An} | Q _{Gn} |
| H | ↑ | X | L | L | Q _{An} | Q _{Gn} |

H = high level (steady state), L = low level (steady state)
 X = irrelevant (any input, including transitions)
 ↑ = transition from low to high level.
 Q_{A0}, Q_{B0}, Q_{H0} = the level of Q_A, Q_B or Q_H, respectively, before the indicate steady-state input conditions were established.
 Q_{An}, Q_{Gn} = the level of Q_A or Q_G before the most-recent ↑ transition of the clock; indicates a one-bit shift.

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_D^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to $+85^\circ\text{C}$
 KS54HCTLS: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|--|---|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS164

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--|-----------------|---------------------|--|----|--|---|------|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 40 | 30 | 25 | 20 | MHz |
| Maximum Propagation Delay, CLR to any Q | t_{PLH} | | 27 | 36 | 45 | 54 | ns |
| Maximum Propagation Delay, CLK to any Q | t_{PLH} | | 22 | 30 | 37 | 45 | ns |
| | t_{PHL} | | 22 | 30 | 37 | 45 | ns |
| Minimum Pulse Width | CLR Low | t_w | 10 | 13 | 17 | 20 | ns |
| | CLK High or Low | | 10 | 13 | 17 | 20 | |
| Minimum Setup Time before CLK† | Data | t_{su} | 8 | 10 | 13 | 15 | ns |
| | CLR Inactive | | 8 | 10 | 13 | 15 | |
| Minimum Hold Time Data after CLK† | t_h | | 0 | 5 | 5 | 5 | ns |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per package) | 120 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Complementary outputs
- Direct overriding load (data) inputs
- Gated clock inputs
- Parallel-to-Serial data conversion
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
 KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

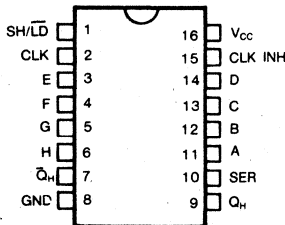
These are high-speed 8-bit parallel-load or serial-in shift registers with complementary serial outputs available from the last stage. Parallel-in access is asynchronous and is enabled by pulling the SH/LD input low. When SH/LD is high, data is entered serially at the SER input and shifted one place to the right with each positive clock transition.

Clocking is accomplished through a 2-input NOR gate which permits one of the clocks to be used as a clock inhibit function. Holding either clock input high inhibits clocking. Either clock input is enabled by holding the other clock input low while the SH/LD input is high.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

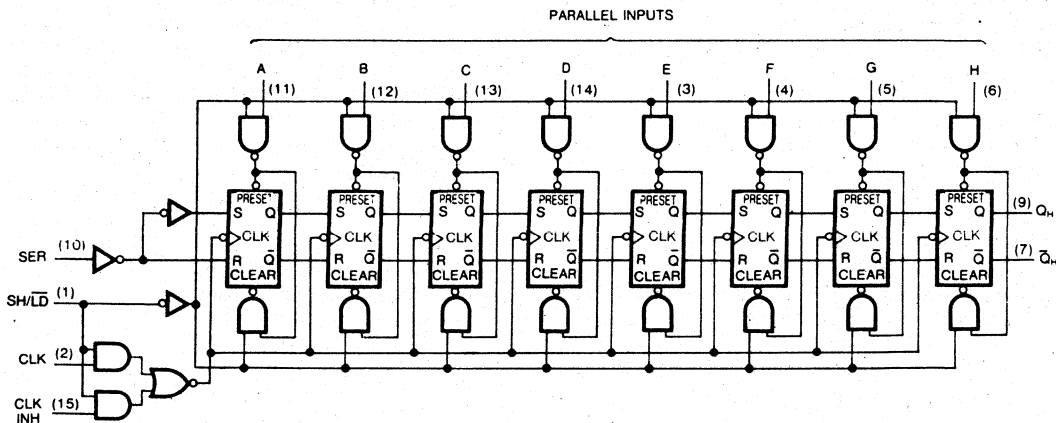


FUNCTION TABLE

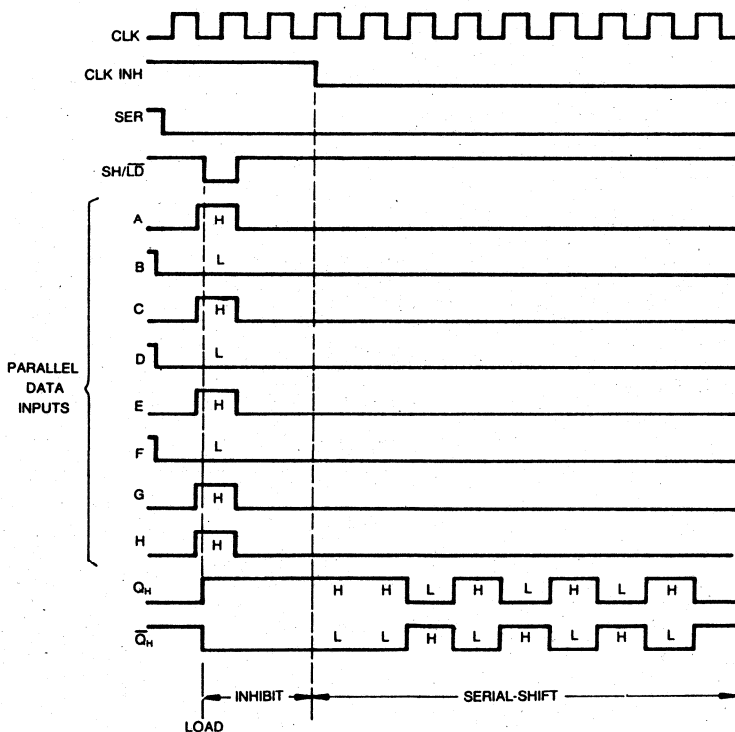
| SH/LD | Inputs | | Function |
|-------|--------|---------|---------------|
| | CLK | CLK INH | |
| L | X | X | PARALLEL LOAD |
| H | H | X | NO CHANGE |
| H | X | H | NO CHANGE |
| H | L | ↑ | SHIFT* |
| H | ↑ | L | SHIFT* |

* Content of each internal register shifts toward output Q_H . Data at serial input is shifted into first register.

LOGIC DIAGRAM



Typical Shift, Load and Inhibit Sequences



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , $-0.5V$ to $+7V$.
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: $-40^\circ C$ to $+85^\circ C$
 KS54HCTLS: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ | | KS54HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ | | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|---|-----------------------|--|-----------------------|---------|
| | | | Typ | Guaranteed Limits | Guaranteed Limits | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | $V_{CC} - 0.1$ 3.7 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | 0.1 0.4 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | 160.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | 3.0 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS165

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|---|--------------------------|---------------------|--|----|---|----|--|----|------|
| | | | Typ | | Guaranteed Limits | | | | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 40 | 30 | 25 | | 20 | | MHz |
| Maximum Propagation Delay, SH/LD to Q_H or \bar{Q}_H | t_{PLH} | | 26 | 35 | 44 | | 53 | | ns |
| | t_{PHL} | | 26 | 35 | 44 | | 53 | | |
| Maximum Propagation Delay, CLK to Q_H or \bar{Q}_H | t_{PHL} | | 30 | 40 | 50 | | 60 | | ns |
| | t_{PLH} | | 30 | 40 | 50 | | 60 | | |
| Maximum Propagation Delay, H to Q_H or \bar{Q}_H | t_{PLH} | | 20 | 27 | 34 | | 41 | | ns |
| | t_{PHL} | | 20 | 27 | 34 | | 41 | | |
| Minimum Pulse Width | SH/LD Low | | t_w | 7 | 10 | 13 | | 15 | |
| | CLK High or Low | 13 | | 16 | 20 | | 25 | | |
| Minimum Setup Time | SH/LD High before CLK† | t_{su} | 13 | 16 | 20 | | 25 | | ns |
| | SER before CLK† | | 10 | 13 | 17 | | 20 | | |
| | CLK INH Low before CLK† | | 13 | 16 | 20 | | 25 | | |
| | CLK INH High before CLK† | | 13 | 16 | 20 | | 25 | | |
| | Data before SH/LD† | | 5 | 7 | 8 | | 10 | | |
| Minimum Hold Time | SER Data after CLK† | t_h | -3 | 0 | 0 | | 0 | | ns |
| | PAR Data after SH/LD† | | -3 | 0 | 0 | | 0 | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | 100 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Synchronous load
- Direct overriding clear
- Parallel to serial conversion
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
I_{OL} = 8 mA @ V_{OL} = 0.5V
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C

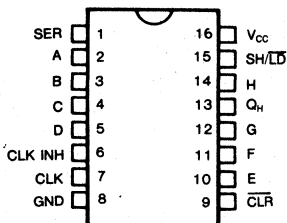
DESCRIPTION

These devices feature parallel-in or serial-in, serial-out registers, gated clock inputs and an overriding clear input. The parallel-in or serial-in modes are established by the shift/load input. When high, the input enables the serial data input and couples the eight fill-flops for serial shifting with each clock pulse. When low, the parallel data inputs are enabled and synchronous loading occurs on the next clock pulse. During parallel loading, serial data flow is inhibited. Clocking is accomplished on the low-to-high edge of the clock pulse through a two-input positive NOR gate permitting one input to be used as a clock-enable or clock-inhibit function. Holding either of the clock inputs high inhibits clocking; holding either low enables the other clock input. This allows the system clock to be free-running and the register can be stopped on command with the clock input. The clock-inhibit input should be changed to the high level only when the clock input is high. A buffered direct clear input overrides all other inputs, including the clock, and sets all flip-flops to zero.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

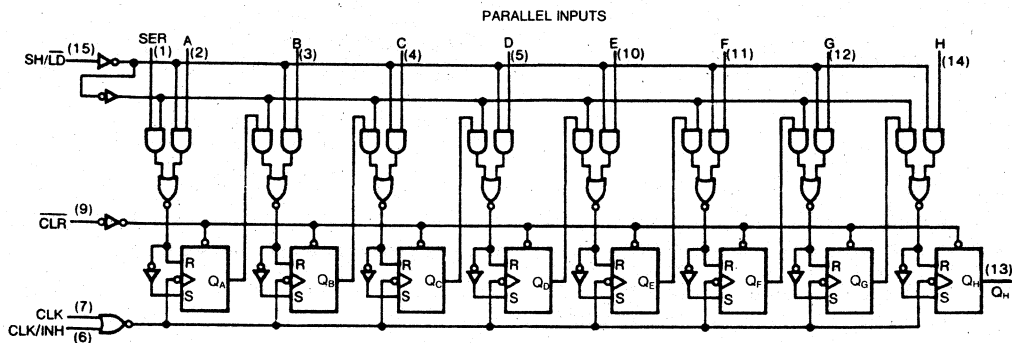
PIN CONFIGURATION



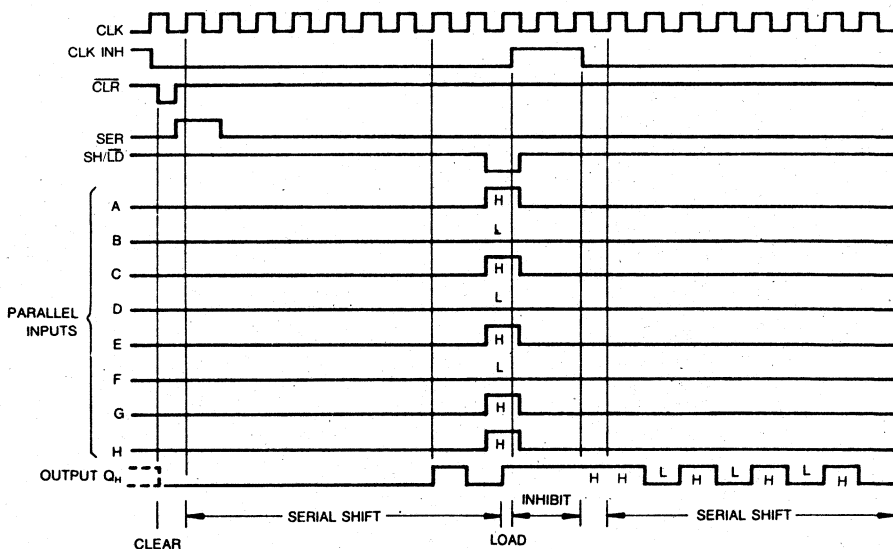
FUNCTION TABLE

| CLR | SH/LD | Inputs | | | | SER | Internal Outputs | | Output Q _H |
|-----|-------|---------|-----|------------------|----------------|-----------------|------------------|-----------------|-----------------------|
| | | CLK INH | CLK | Parallel A ... H | Q _A | | Q _B | | |
| L | X | X | X | X | X | L | L | L | |
| H | X | L | L | X | X | Q _{A0} | Q _{B0} | Q _{H0} | |
| H | L | L | ↑ | X | a ... h | a | b | h | |
| H | H | L | ↑ | H | X | H | Q _{An} | Q _{Gn} | |
| H | H | L | ↑ | L | X | L | Q _{An} | Q _{Gn} | |
| H | X | H | ↑ | X | X | G _{A0} | Q _{B0} | Q _{H0} | |

LOGIC DIAGRAM



Typical Clear, Shift, Load, Inhibit, and Shift Sequences



5

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS | | KS54HCTLS | | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|--------------------------------------|---------------------------------------|-----------|--|---------|
| | | | Typ | Min | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | | | |
| Guaranteed Limits | | | | | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | | | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS166

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--|---|---------------------|--|-------------------|--|---|------|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | Guaranteed Limits | | | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 40 | 30 | 25 | 20 | MHz |
| Maximum Propagation Delay, CLR to Q_H | t_{PHL} | | 22 | 30 | 37 | 45 | ns |
| Maximum Propagation Delay, CLK to Q_H | t_{PLH} | | 26 | 36 | 44 | 53 | ns |
| | t_{PHL} | | 26 | 35 | 44 | 53 | ns |
| Minimum Pulse Width | $\overline{\text{CLR}}$ Low | | t_w | 10 | 13 | 17 | 20 |
| | CLK High or Low | 10 | | 13 | 17 | 20 | |
| Minimum Setup Time | SH/ $\overline{\text{LD}}$ High before CLK† | t_{su} | 10 | 13 | 17 | 20 | ns |
| | SER before CLK† | | 10 | 13 | 17 | 20 | |
| | CLK INH before CLK† | | 10 | 13 | 17 | 20 | |
| | Data before SH/ $\overline{\text{LD}}$ † | | 10 | 13 | 17 | 20 | |
| | $\overline{\text{CLR}}$ Inactive before CLK † | | 10 | 13 | 17 | 20 | |
| Minimum Hold Time | SH/ $\overline{\text{LD}}$ High after CLK† | t_h | 7 | 10 | 12 | 15 | ns |
| | SER after CLK† | | 7 | 10 | 12 | 15 | |
| | CLK INH after CLK† | | 7 | 10 | 12 | 15 | |
| | Data after SH/ $\overline{\text{LD}}$ † | | 7 | 10 | 12 | 15 | |
| | $\overline{\text{CLR}}$ Active after CLK† | | 7 | 10 | 12 | 15 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

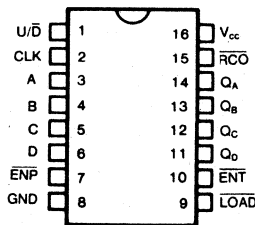
5

Preliminary Specifications

FEATURES

- Fully Synchronous Operation for Counting and Programming
- Internal Look Ahead for Fast Counting
- Carry Output for N-bit Cascading
- Fully Independent Clock Circuit
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



DESCRIPTION

These synchronous presettable counters feature an internal carry look-ahead for cascading in high-speed counting applications. The '168 is a decade counter and the '169 is a 4-bit binary counter. Synchronous operation is provided by having all flip-flops clocked simultaneously so that the outputs change coincident with each other when so instructed by the count enable inputs and internal gating. This mode of operation helps eliminate the output counting spikes that are normally associated with asynchronous (ripple clock) counters. A buffered clock input triggers the four flip-flops on the rising (positive-going) edge of the clock waveform.

These counters are fully programmable; that is, the outputs may each be preset to either level. The load input circuitry allows loading with the carry-enable output of cascaded counters. As loading is synchronous, setting up a low level at the load input disables the counter and causes the outputs to agree with the data inputs after the next clock pulse.

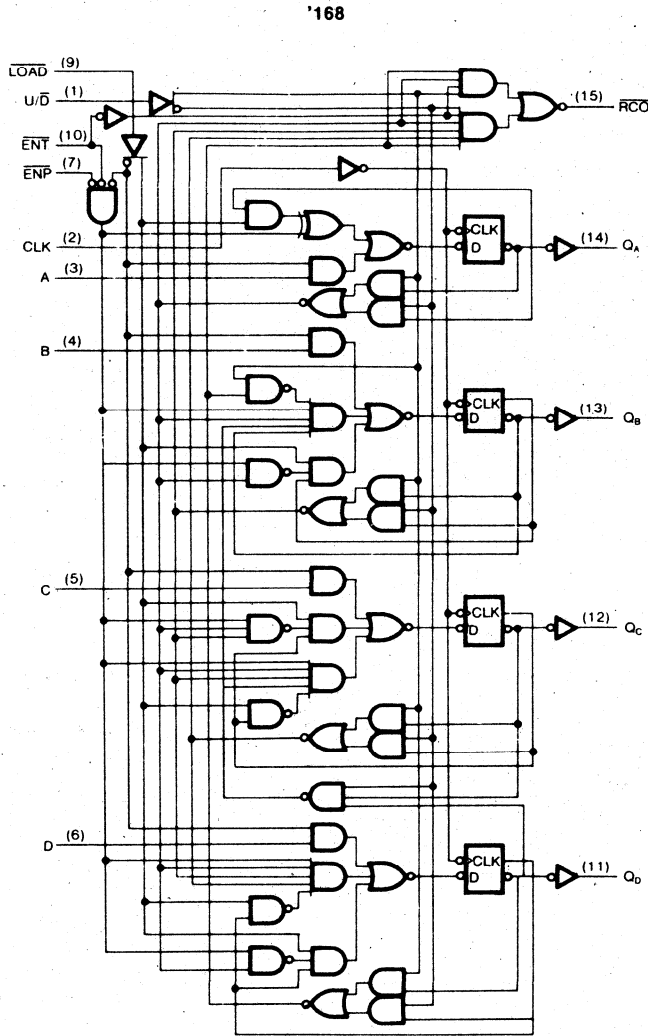
The carry look-ahead circuitry provides for cascading counters for n-bit synchronous application without additional gating. Instrumental in accomplishing this function are two count-enable inputs and a carry output. Both count enable inputs ($\overline{\text{ENP}}$ and $\overline{\text{ENT}}$) must be low to count. The direction of the count is determined by the level of the U/D input. When U/D is high, the counter counts up; when low, it counts down. Input $\overline{\text{ENT}}$ is fed forward to enable the carry output. The ripple carry output ($\overline{\text{RCO}}$) thus enabled will produce a low-level pulse while the count is zero (all inputs low) counting down or maximum (9 or 15) counting up. This low-level overflow carry pulse can be used to enable successive cascaded stages. Transition at $\overline{\text{ENP}}$ or $\overline{\text{ENT}}$ are allowed regardless of the level of the clock input.

These counters feature a fully independent clock circuit. Changes at control inputs ($\overline{\text{ENP}}$, $\overline{\text{ENT}}$, $\overline{\text{LOAD}}$, U/D) that will modify the operating mode have no effect on the contents of the counter until clocking occurs. The function of the counter (whether enabled, disabled, loading, or counting) will be dictated solely by the conditions meeting the stable setup and hold times.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

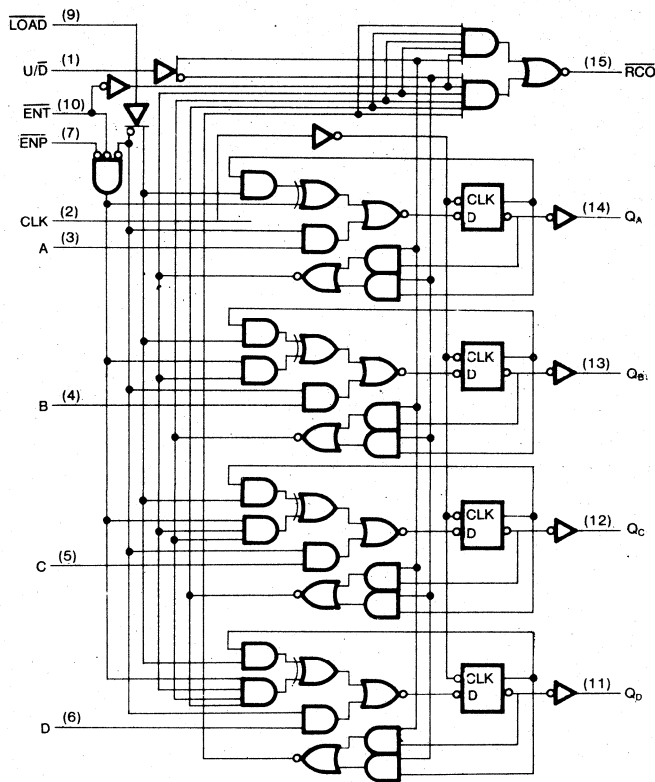
LOGIC DIAGRAMS



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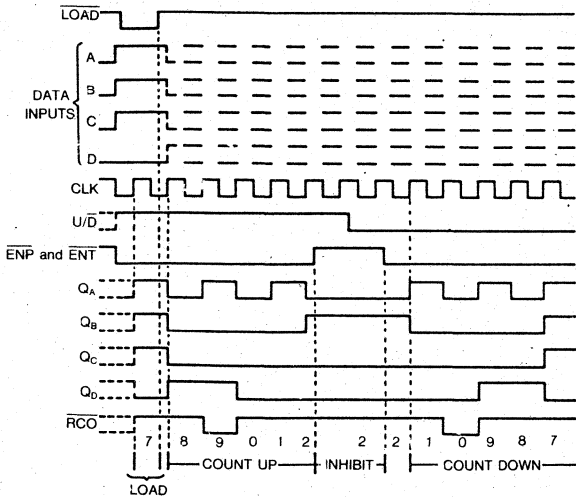
LOGIC DIAGRAMS (Continued)

'169



TIMING DIAGRAM

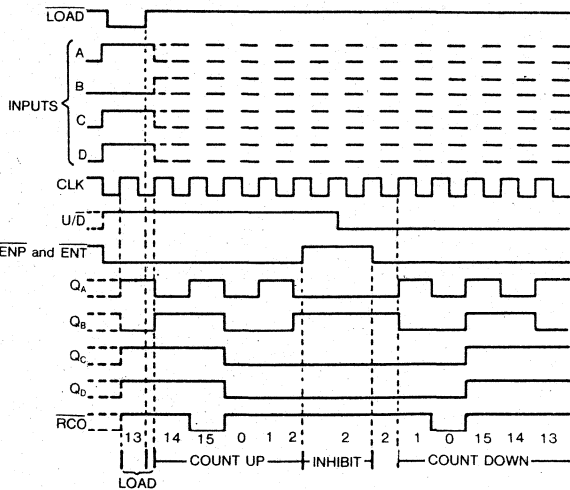
'168



Illustrated above is the following sequence:

1. Load (preset) to BCD seven
2. Count up to eight nine (maximum), zero, one, and two
3. Inhibit
4. Count down to one, zero (minimum), nine, eight, and seven

'169



Illustrated above is the following sequence:

1. Load (preset) to BCD seven
2. Count up to eight nine (maximum), zero, one, and two
3. Inhibit
4. Count down to one, zero (minimum), nine, eight, and seven

Absolute Maximum Ratings*

| | |
|--|---|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{STG} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_D^\dagger | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

| | |
|----------------------|---|
| Plastic Package (N): | $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C |
| Ceramic Package (J): | $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C |

Recommended Operating Conditions

| | |
|--|----------------|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |

| | |
|-------|--|
| Range | KS74HCTLS: -40°C to $+85^\circ\text{C}$ |
| | KS54HCTLS: -55°C to $+125^\circ\text{C}$ |

Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS (V_{CC}=5V±10% Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | T _a = 25°C | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|------------------|---|------------------------|-------------------------------|-------------------------------|------------------------------|------|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V _{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V _{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V _{OH} | V _{IN} =V _{IH} or V _{IL} I _O =-20μA I _O =-4mA | V _{CC} 4.2 | V _{CC} - 0.1 3.98 | V _{CC} - 0.1 3.84 | V _{CC} - 0.1 3.7 | V |
| Maximum Low-Level Output Voltage | V _{OL} | V _{IN} =V _{IH} or V _{IL} I _O =20μA I _O =4mA I _O =8mA | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I _{IN} | V _{IN} =V _{CC} or GND | | ±0.1 | ±1.0 | ±1.0 | μA |
| Maximum Quiescent Supply Current | I _{CC} | V _{IN} =V _{CC} or GND I _{OUT} =0μA | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI _{CC} | per input pin V _I =2.4V other Inputs: at V _{CC} or GND I _{OUT} =0μA | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r, t_f≤6 ns, HCTLS168, HCTLS169)

| Characteristic | Symbol | Conditions† | T _a = 25°C | | KS74HCTLS | KS54HCTLS | Unit | |
|---|------------------|-----------------------|------------------------|-------------------|---|--|------|----|
| | | | V _{CC} = 5.0V | | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | |
| | | | Typ | Guaranteed Limits | | | | |
| Maximum Operating Frequency | f _{max} | C _L = 50pF | 35 | 30 | 25 | 20 | MHz | |
| Maximum Propagation Delay, CLK to RCO | t _{PLH} | | 26 | 35 | 44 | 52 | ns | |
| | t _{PHL} | | 26 | 35 | 44 | 52 | | |
| Maximum Propagation Delay, CLK to Ary Q | t _{PLH} | | 17 | 22 | 28 | 33 | ns | |
| | t _{PHL} | | 17 | 22 | 28 | 33 | | |
| Maximum Propagation Delay, ENT to RCO | t _{PLH} | | 15 | 20 | 25 | 30 | ns | |
| | t _{PHL} | | 15 | 20 | 25 | 30 | | |
| Maximum Propagation Delay, U/D to RCO | t _{PLH} | | 20 | 27 | 34 | 40 | ns | |
| | t _{PHL} | | 20 | 27 | 34 | 40 | | |
| Minimum Pulse Duration, CLK high or low | t _w | | 12 | 16 | 20 | 24 | ns | |
| Minimum Setup Time Before CLK† | A, B, C or D | | t _{su} | 12 | 16 | 20 | 24 | ns |
| | ENP or ENT | | | 12 | 16 | 20 | 24 | ns |
| | LOAD | | | 12 | 16 | 20 | 24 | ns |
| | U/D | | | 12 | 16 | 20 | 24 | ns |
| Minimum Hold Time, Data after CLK† | t _h | | -3 | 0 | 0 | 0 | ns | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF | |
| Power Dissipation Capacitance* | C _{PD} | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

KS54HCTLS 173 4-Bit D-Type Registers with 3-State Outputs

Objective Specifications

FEATURES

- Gated output control lines for enabling or disabling the outputs
- Fully independent clock for operation in parallel-load or hold modes
- For application as bus buffer registers
- Function, pin-out, speed and drive compatibility with 54174LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$ for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
 KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

These 4-bit registers contain D-type flip-flops with 3-state outputs, capable of driving highly-capacitive or low-impedance loads. This provides the device with the capability of being connected directly to and driving the bus lines in a bus-organized system without need for interface or pull-up components.

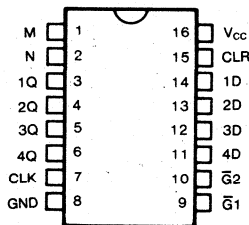
Gated enable inputs are provided for controlling the entry of data into the flip-flops. When both data-enable inputs are low, data at the D inputs are loaded into their respective flip-flops on the next positive transition of the buffered clock input. Gated output control inputs are also provided. When both are low, the normal logic states of the four outputs are available for driving the loads or bus lines. The outputs are disabled independently from the level of the clock by a high logic level at either output control input. The outputs then present a high impedance and neither load nor drive the bus line. Detailed operation is given in the function table.

To minimize the possibility that two outputs will attempt to take a common bus to opposite logic levels, the output control circuitry is designed so that the average output disable times are shorter than the average output enable times.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



FUNCTION TABLE

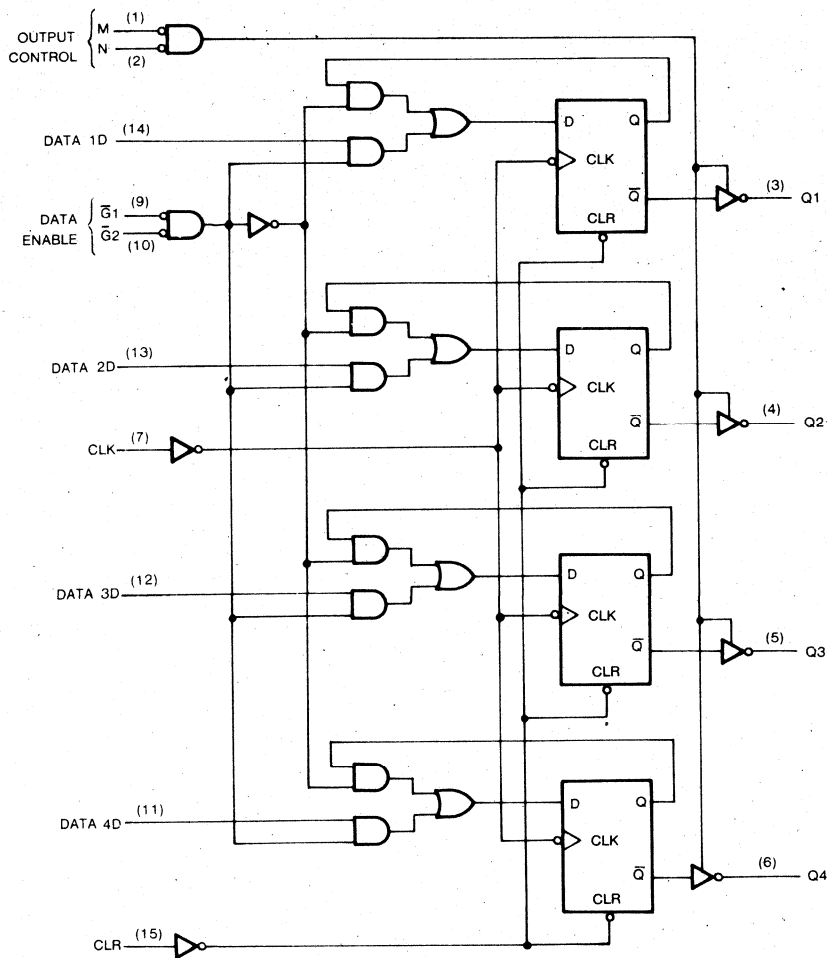
| Clear | Clock | Input | | | Output Q |
|-------|-------|-------------|------------|-----------|-------------|
| | | Data Enable | | Data D | |
| | | $\bar{G}1$ | $\bar{G}2$ | | |
| H | X | X | X | X | L |
| L | L | X | X | X | Q_0 |
| L | ↑ | H | X | X | Q_0 |
| L | ↑ | X | H | X | Q_0 |
| L | ↑ | L | L | L | L |
| L | ↑ | L | L | H | H |

When either \bar{M} or N (or both) is (are) high the output is disabled to the high-impedance state; however sequential operation of the flip-flops is not affected.

KS54HCTL5 173 4-Bit D-Type Registers with 3-State Outputs

KS74HCTL5

LOGIC DIAGRAM



KS54HCTLS 173 4-Bit D-Type Registers with 3-State Outputs

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} . . . 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: $-40^\circ C$ to $+85^\circ C$
 KS54HCTLS: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|--------------------------------------|---------------------------------------|---------|
| | | | Typ | | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | |
| Guaranteed Limits | | | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -6mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 12mA$ $I_O = 24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

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KS54HCTLS 173 4-Bit D-Type Registers with 3-State Outputs

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS173

| Characteristic | Symbol | Conditions† | T _a = 25°C V _{CC} = 5.0V | | KS74HCTLS T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | | KS54HCTLS T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | Unit |
|--|---------------------------|---|---|----------|--|--|---|--|------|
| | | | Typ | | Guaranteed Limits | | | | |
| Maximum Clock Frequency | f _{max} | | 45 | 30 | 25 | | 20 | | MHz |
| Maximum Propagation Delay, CLK to any Q | t _{PLH} | C _L = 50pF C _L = 150pF | 20 23 | 27 34 | 34 43 | | 41 52 | | ns |
| | t _{PHL} | C _L = 50pF C _L = 150pF | 20 23 | 27 34 | 34 43 | | 41 52 | | |
| Maximum Propagation Delay, CLR to any Q | t _{PHL} | C _L = 50pF C _L = 150pF | 22 25 | 30 37 | 37 46 | | 45 56 | | ns |
| Maximum Output Enable Time, M or N to any Q | t _{PZH} | R _L = 1kΩ C _L = 50pF C _L = 150pF | 18 24 | 25 32 | 31 40 | | 37 48 | | ns |
| | t _{PZL} | | 18 24 | 25 32 | 31 40 | | 37 48 | | |
| Maximum Output Disable Time, M or N to any Q | t _{PHZ} | R _L = 1kΩ, C _L = 50pF | 15 | 20 | 25 | | 30 | | ns |
| | t _{PLZ} | | 15 | 20 | 25 | | 30 | | |
| Minimum Pulse Width | CLK High or Low | t _w | 10 | 13 | 17 | | 20 | | ns |
| | CLR High | | 10 | 13 | 17 | | 20 | | |
| Minimum before CLK† | $\bar{G}1$ and $\bar{G}2$ | t _{su} | 15 | 20 | 25 | | 30 | | ns |
| | Data | | 8 | 11 | 14 | | 17 | | |
| | CLR Inactive | | 5 | 7 | 8 | | 10 | | |
| Minimum Hold Time After CLK† | $\bar{G}1$ and $\bar{G}2$ | t _h | -3 | 0 | 0 | | 0 | | ns |
| | Data | | -3 | 0 | 0 | | 0 | | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | | | pF |
| Maximum Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

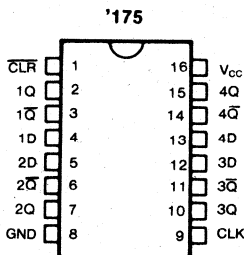
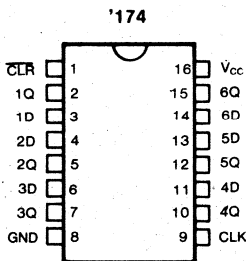
The '174 contains six, and the '175 contains four D-type flip-flops all sharing a common clock and a common clear. The '174 features single rail outputs for every flip-flops whereas the '175 has complementary outputs.

Information at the D inputs meeting the setup time requirements is transferred to the Q outputs on the positive-going edge of the clock pulse. Clock triggering occurs at a particular voltage level and is not directly related to the transition time of the positive-going pulse. When the clock input is at either the high or low level, the D input signal has no effect at the output.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATIONS



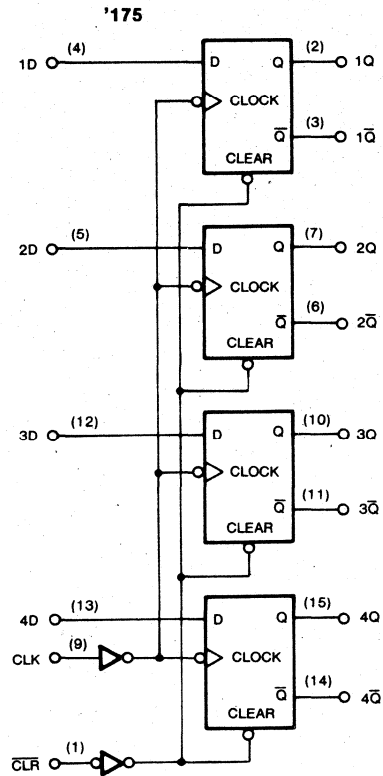
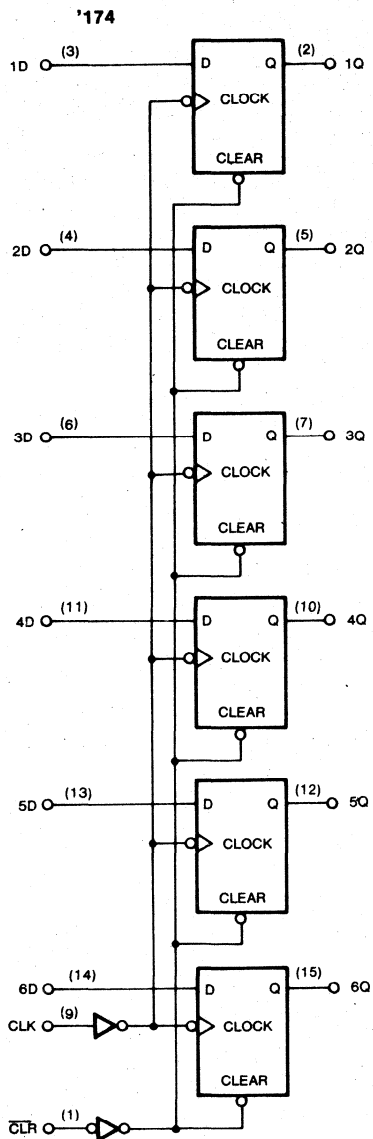
FUNCTION TABLE

(Each Flip-Flop)

| Inputs | | | Outputs | |
|--------|-----|---|----------------|-----------------|
| CLR | CLK | D | Q | Q̄† |
| L | X | X | L | H |
| H | ↑ | H | H | L |
| H | ↑ | L | L | H |
| H | L | X | Q ₀ | Q̄ ₀ |

† '175 only

LOGIC DIAGRAMS



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
Continuous Current Through
 V_{CC} or GND pins ± 125 mA
Storage Temperature Range, T_{stg} ... -65°C to +150°C
Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
Operating Temperature
Range KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C
Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|---|--|-----------------------|---------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ | KS54HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| Guaranteed Limits | | | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

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AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS174, HCTLS175

| Characteristic | Symbol | Conditions† | T _A = 25°C V _{CC} = 5.0V | | KS74HCTLS T _A = -40°C to +85°C V _{CC} = 5.0V ± 10% | | T _A = -55°C to +125°C V _{CC} = 5.0V ± 10% | | Unit |
|---|----------------------|-----------------------|---|-------------------|--|-------------------|--|-----|------|
| | | | Typ | Guaranteed Limits | Guaranteed Limits | Guaranteed Limits | | | |
| Maximum Clock Frequency | f _{max} | C _L = 50pF | 40 | 30 | 25 | 20 | | MHz | |
| Maximum Propagation Delay, CLK to Q or \bar{Q} | t _{PLH} | | 22 | 30 | 37 | 45 | | ns | |
| | t _{PHL} | | 22 | 30 | 37 | 35 | | | |
| Maximum Propagation Delay, CLR to Q or \bar{Q} | t _{PLH} | | 26 | 35 | 43 | 52 | | | |
| | t _{PHL} | | 26 | 35 | 43 | 52 | | | |
| Minimum Setup Time before CLK† | Data | | t _{su} | 10 | 13 | 17 | 20 | ns | |
| | \bar{CLR} Inactive | 12 | | 16 | 20 | 25 | | | |
| Minimum Hold Time, Data after CLK† | t _h | | -3 | 0 | 0 | 0 | ns | | |
| Minimum Pulse Width | CLK High or Low | t _w | 10 | 13 | 17 | 20 | ns | | |
| | \bar{CLR} Low | | 10 | 13 | 17 | 20 | | | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF | | |
| Power Dissipation Capacitance* | C _{PD} | | | | | | pF | | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

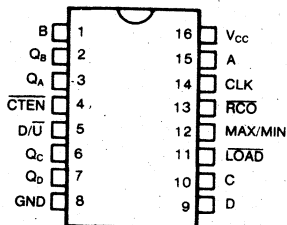


Objective Specifications

FEATURES

- Single down/up count control line
- Look-ahead circuitry enhances speed of cascaded counters
- Fully synchronous in count modes
- Asynchronously presettable with load control
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
I_{OL} = 8 mA @ V_{OL} = 0.5V
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C

PIN CONFIGURATION



DESCRIPTION

These are high-speed synchronous, reversible 4-bit binary counters. Synchronous counting operation is provided by having all flip-flops clocked simultaneously so that the outputs change with each other when so instructed by the steering logic. This mode of operation eliminates the output counting spikes normally associated with a synchronous (ripple clock) counters.

The outputs of the four flip-flops are triggered on a low-to-high-level transition of the clock input if the enable input (\overline{CTEN}) is low. A high at \overline{CTEN} inhibits counting. The direction of the count is determined by the level of the down/up (D/\overline{U}) input. When D/\overline{U} is low, the counter counts up and when D/\overline{U} is high, it counts down.

These counters feature a fully independent clock circuit. Changes at the control inputs (\overline{CTEN} and D/\overline{U}) that will modify the operating mode have no effect on the contents of the counter until clocking occurs. The function of the counter will be dictated solely by the condition meeting the stable setup and hold times.

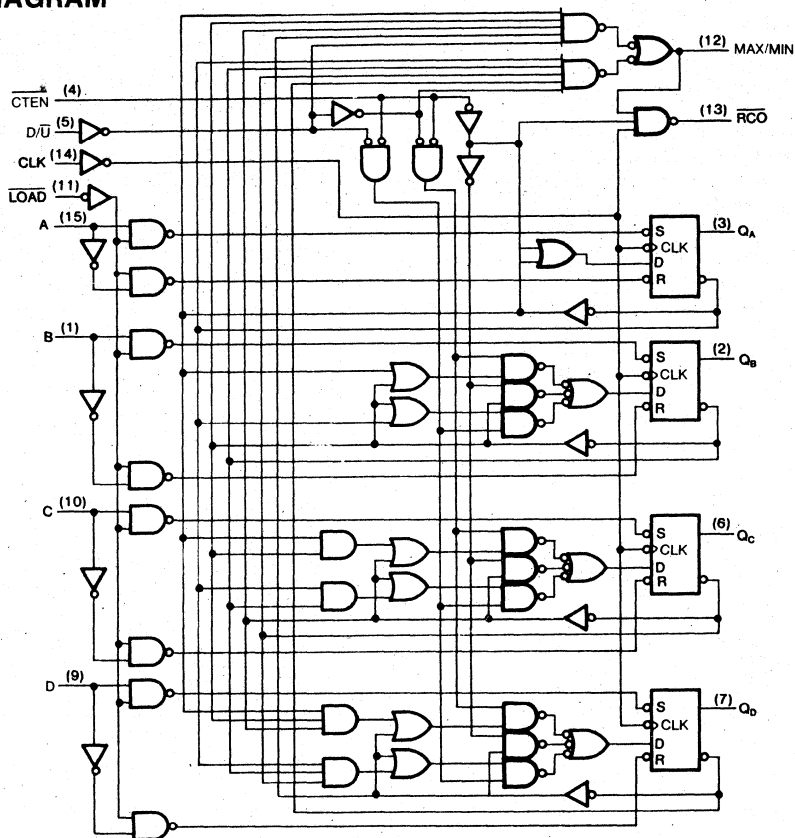
These counters are fully programmable; that is, the outputs may each be preset to either level by placing a low on the load input and entering the desired data at the data inputs. The output will change to agree with the data inputs independently of the level of the clock input. This feature allows the counters to be used as modulo-N dividers by simply modifying the count length with the preset inputs.

Two outputs have been made available to perform the cascading function: ripple clock and maximum/minimum count. The latter output produces a high-level output pulse with a duration approximately equal to one complete cycle of the clock while the count is zero (all outputs low) counting down or maximum (9 or 15) counting up. The ripple clock output produces a low-level output pulse under those same conditions but only while the clock output to the enable input of the succeeding counter if parallel clocking is used, or to the clock input if parallel enabling is used. The maximum/minimum count output can be used to accomplish look-ahead for high-speed operation.

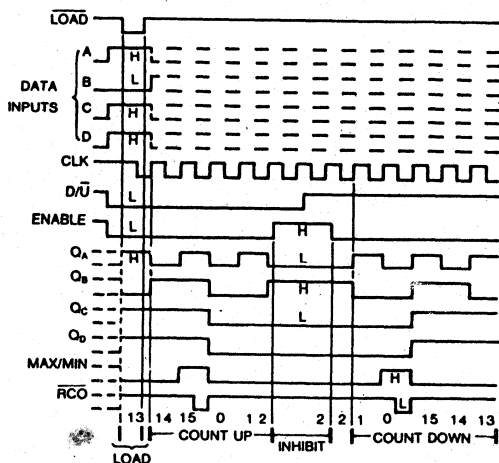
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAM



Typical Load, Count, and Inhibit Sequence



Sequence:
 (1) Load (preset) to binary thirteen
 (2) Count up to fourteen, fifteen, zero, one, and two
 (3) Inhibit
 (4) Count down to one, zero, fifteen, fourteen, and thirteen

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range
 KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------|----------------------|----------------------|--------------------------------------|---------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ C$ to $+85^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-4mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=4mA$ $I_O=8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

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AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS191

| Characteristic | Symbol | Conditions† | T _a = 25°C V _{CC} = 5.0V | | KS74HCTLS | KS54HCTLS | Unit |
|---|-------------------------------|-----------------------|---|-------------------|---|--|------|
| | | | | | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | |
| | | | Typ | Guaranteed Limits | | | |
| Maximum Clock Frequency | f _{max} | C _L = 50pF | 30 | 20 | 16 | 14 | MHz |
| Maximum Propagation Delay, LOAD to any Q | t _{PLH} | | 30 | 40 | 50 | 60 | ns |
| | t _{PHL} | | 30 | 40 | 50 | 60 | |
| Maximum Propagation Delay, A,B,C, D to any Q | t _{PLH} | | 27 | 36 | 45 | 64 | ns |
| | t _{PHL} | | 27 | 36 | 45 | 54 | |
| Maximum Propagation Delay, CLK to \overline{RCO} | T _{PLH} | | 17 | 22 | 28 | 33 | ns |
| | t _{PHL} | | 17 | 22 | 28 | 33 | |
| Maximum Propagation Delay, CLK to any Q | t _{PLH} | | 23 | 30 | 37 | 45 | ns |
| | t _{PHL} | | 23 | 30 | 37 | 45 | |
| Maximum Propagation Delay, CLK to MAX/MIN | t _{PLH} | | 35 | 47 | 59 | 70 | ns |
| | t _{PHL} | | 35 | 47 | 59 | 70 | |
| Maximum Propagation Delay, D/ \overline{U} to \overline{RCO} | t _{PLH} | | 33 | 45 | 56 | 67 | ns |
| | t _{PHL} | | 33 | 45 | 56 | 67 | |
| Maximum Propagation Delay, D/ \overline{U} to MAX/MIN | t _{PLH} | | 25 | 33 | 41 | 50 | |
| | t _{PHL} | 25 | 33 | 41 | 50 | | |
| Maximum Propagation Delay, CTEN to \overline{RCO} | t _{PLH} | 25 | 33 | 41 | 50 | ns | |
| | t _{PHL} | 25 | 33 | 41 | 50 | | |
| Minimum Pulse Width | CLK High or Low | t _w | 13 | 17 | 21 | 25 | ns |
| | LOAD Low | | 13 | 17 | 21 | 25 | |
| Minimum Setup Time | Data before LOAD† | t _{su} | 10 | 13 | 17 | 20 | ns |
| | CTEN before CLK† | | 20 | 26 | 34 | 40 | |
| | D/ \overline{U} before CLK† | | 10 | 13 | 17 | 20 | |
| | LOAD Inactive before CLK† | | 15 | 20 | 25 | 30 | |
| Minimum Hold Time | Data after LOAD† | t _h | 1 | 3 | 5 | 5 | ns |
| | CTEN after CLK† | | -3 | 0 | 0 | 0 | |
| | D/ \overline{U} after CLK† | | -3 | 0 | 0 | 0 | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | | 80 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

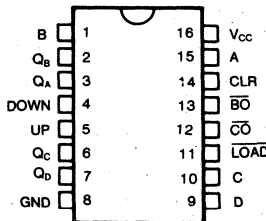
† For AC switching test circuits and timing waveforms see section 2.

Objective Specifications

FEATURES

- Look-ahead circuitry enhances cascaded counters
- Fully synchronous in count modes
- Parallel asynchronous load for modulo-N count lengths
- Asynchronous clear
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
 KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



DESCRIPTION

These are high-speed synchronous reversible 4-bit binary counters. Synchronous operation is provided by having all flip-flops clocked simultaneously so that the outputs change coincidentally with each other when so instructed by the steering logic. This mode of operation eliminates the output counting spikes normally associated with asynchronous (ripple clock) counters.

The outputs of the four flip-flops are triggered by a low-to-high-level transition of either count (clock) input (Up or Down). The direction of counting is determined by which count input is pulsed while the other count input is high.

All four counters are fully programmable; that is, each output may be preset to either level by placing a low on the load input and entering the desired data at the data inputs. The output will change to agree with the data inputs independently of the count pulses. This feature allows the counters to be used as modulo-N dividers by simply modifying the count length with the preset inputs.

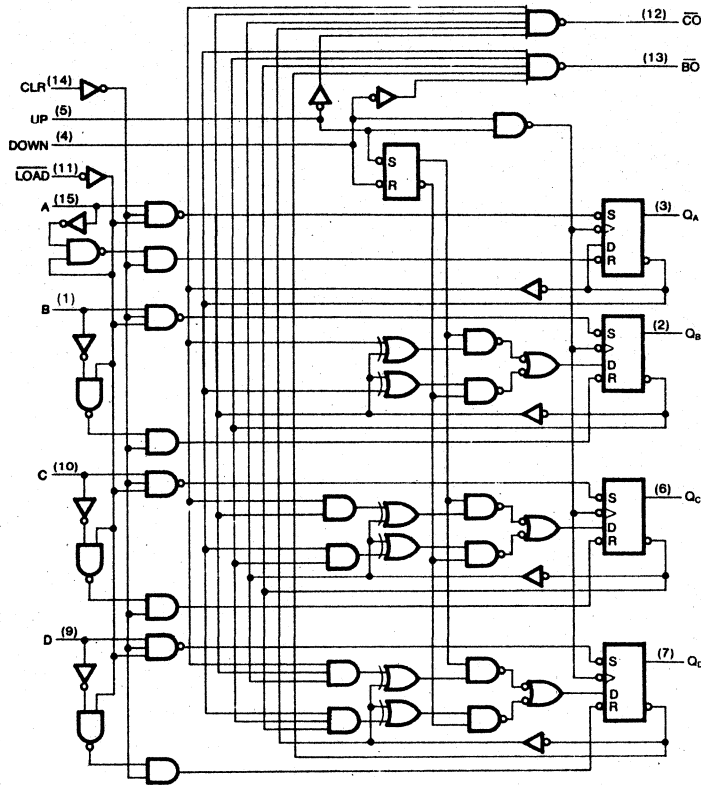
A clear input has been provided that forces all outputs to the low level when a high level is applied. The clear function is independent of the count and the load inputs.

These counters were designed to be cascaded without the need for external circuitry. The borrow output (\overline{BO}) produces a low-level pulse while the count is zero (all outputs low) and the count-down input is low. Similarly, the carry output (\overline{CO}) produces a low-level pulse while the count is maximum (9 or 15) and the count-up input is low. The counters can then be easily cascaded by feeding the borrow and carry outputs to the count-down and count-up inputs, respectively, of the succeeding counter.

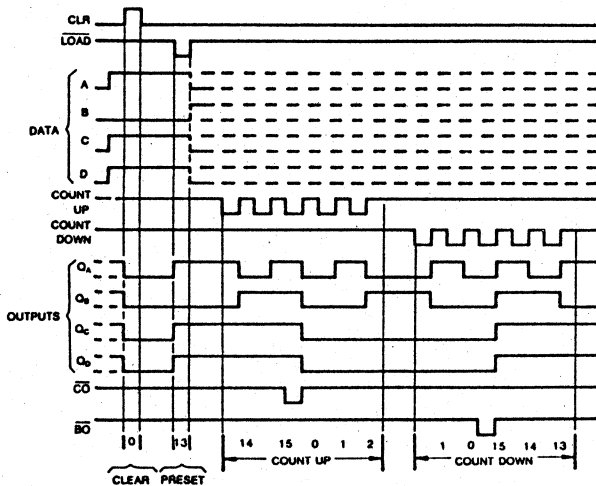
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAM



Typical Clear, Load, and Count Sequences



Sequence:
 (1) Clear outputs to zero.
 (2) Load (preset) to binary thirteen.
 (3) Count up to fourteen, fifteen, carry, zero, one, and two.
 (4) Count down to one, zero, borrow, fifteen, fourteen, and thirteen.
 Note A: Clear overrides load data, and count inputs.
 Note B: When counting up, count-down input must be high; when counting down, count-up input must be high.

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN}, V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: $-40^\circ C$ to $+85^\circ C$
 KS54HCTLS: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|--------------------------------------|---------------------------------------|---------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns, HCTLS193)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|---|--|---------------------|--|-------------------|---|----|--|-----|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 35 | 25 | 20 | 18 | | MHz | |
| Maximum Propagation Delay, UP to \overline{CO} | t_{PLH} | | 18 | 25 | 31 | 37 | | ns | |
| | t_{PHL} | | 18 | 25 | 31 | 37 | | | |
| Maximum Propagation Delay, DOWN to \overline{BO} | t_{PLH} | | 18 | 24 | 30 | 36 | | ns | |
| | t_{PHL} | | 18 | 24 | 30 | 36 | | | |
| Maximum Propagation Delay, UP or DOWN to any Q | t_{PLH} | | 32 | 42 | 52 | 63 | | ns | |
| | t_{PHL} | | 32 | 42 | 52 | 63 | | | |
| Maximum Propagation Delay, LOAD to any Q | t_{PLH} | | 30 | 40 | 50 | 60 | | ns | |
| | t_{PHL} | | 30 | 40 | 50 | 60 | | | |
| Maximum Propagation Delay, CLR to any Q | t_{PHL} | | 18 | 24 | 30 | 36 | | ns | |
| Minimum Pulse Width | CLR High | t_w | 10 | 13 | 17 | 20 | | ns | |
| | LOAD Low | | 10 | 13 | 17 | 20 | | | |
| | UP or DOWN High or Low | | 10 | 13 | 17 | 20 | | | |
| Minimum Setup Width | Data before $\overline{LOAD}\dagger$ | t_{su} | 10 | 13 | 17 | 20 | | ns | |
| | CLR Inactive before $UP\dagger$ or $DOWN\dagger$ | | 10 | 13 | 17 | 20 | | | |
| | LOAD Inactive before $UP\dagger$ or $DOWN\dagger$ | | 10 | 13 | 17 | 20 | | | |
| | UP high before $DOWN\dagger$ | | 10 | 13 | 17 | 20 | | | |
| | DOWN high before $UP\dagger$ | | 10 | 13 | 17 | 20 | | | |
| Minimum Hold Time | Data after $\overline{LOAD}\dagger$ | t_h | 1 | 3 | 5 | 5 | | ns | |
| | UP High after $DOWN\dagger$ | | -3 | 0 | 0 | 0 | | | |
| | DOWN High after $UP\dagger$ | | -3 | 0 | 0 | 0 | | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF | | |
| Power Dissipation Capacitance* | C_{PD} | | 80 | | | | pF | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.



Preliminary Specifications

FEATURES

- Parallel-to-Serial, Serial-to-Parallel Conversions
- Left or Right Shifts
- Parallel Synchronous Loading
- Direct Overriding Clear
- Temporary Data Latching Capability
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
I_{OL} = 8 mA @ V_{OL} = 0.5V
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C

DESCRIPTION

These bidirectional shift registers feature parallel outputs, right-shift and left-shift serial inputs, operating-mode-control inputs, and a direct overriding clear line. The register has four distinct modes of operation:

- Inhibit clock (temporary data latch/do nothing)
- Shift-right (in the direction Q_A toward Q_D)
- Shift-left (in the direction Q_D toward Q_A)
- Parallel (broadside) load

Synchronous parallel loading is accomplished by applying the four bits of data and taking both mode control inputs, S₀ and S₁, high. The data is loaded into the associated flip-flops and appear at the outputs after the positive transition of the clock input. During loading, serial data flow is inhibited.

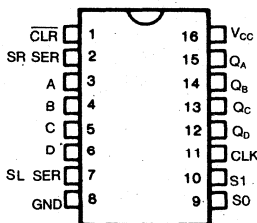
Shift-right is accomplished synchronously with the rising edge of the clock pulse when S₀ is high and S₁ is low. Serial data for this mode is entered at the shift-right data input. When S₀ is low and S₁ is high, data shifts left synchronously and new data is entered at the shift-left serial inputs. Clocking of the flip-flop is inhibited when both mode control inputs are low.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

5

PIN CONFIGURATION



FUNCTION TABLE

| CLR | MODE | | INPUTS | | | | OUTPUTS | | | | | | |
|-----|----------------|----------------|--------|--------|-------|----------|---------|----------------|----------------|-----------------|-----------------|-----------------|-----------------|
| | | | CLK | SERIAL | | PARALLEL | | Q _A | Q _B | Q _C | Q _D | | |
| | S ₁ | S ₀ | | LEFT | RIGHT | A | B | | | | | C | D |
| L | X | X | X | X | X | X | X | X | X | L | L | L | L |
| H | X | X | L | X | X | X | X | X | X | Q _{A0} | Q _{B0} | Q _{C0} | Q _{D0} |
| H | H | H | ↑ | X | X | a | b | c | d | a | b | c | d |
| H | L | H | ↑ | X | H | X | X | X | X | H | Q _{An} | Q _{Bn} | Q _{Cn} |
| H | L | H | ↑ | X | L | X | X | X | X | L | Q _{An} | Q _{Bn} | Q _{Cn} |
| H | H | L | ↑ | H | X | X | X | X | X | Q _{Bn} | Q _{Cn} | Q _{Dn} | H |
| H | H | L | ↑ | L | X | X | X | X | X | Q _{Bn} | Q _{Cn} | Q _{Dn} | L |
| H | L | L | X | X | X | X | X | X | X | Q _{A0} | Q _{B0} | Q _{C0} | Q _{D0} |

H=high level (steady state)

L=low level (steady state)

X=irrelevant (any input, including transitions)

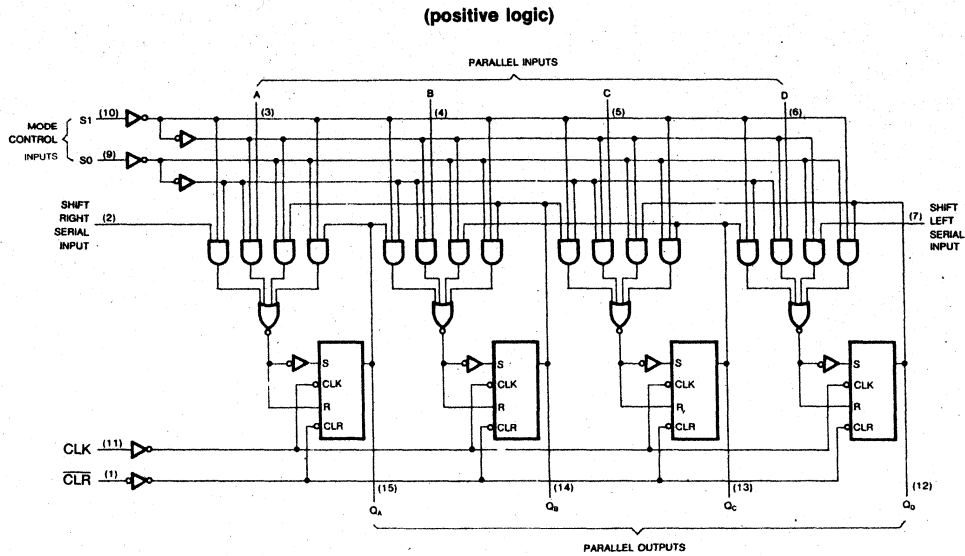
↑=transition from low to high level

a,b,c,d=the level of steady-state input at inputs, A,B,C, or D, respectively.

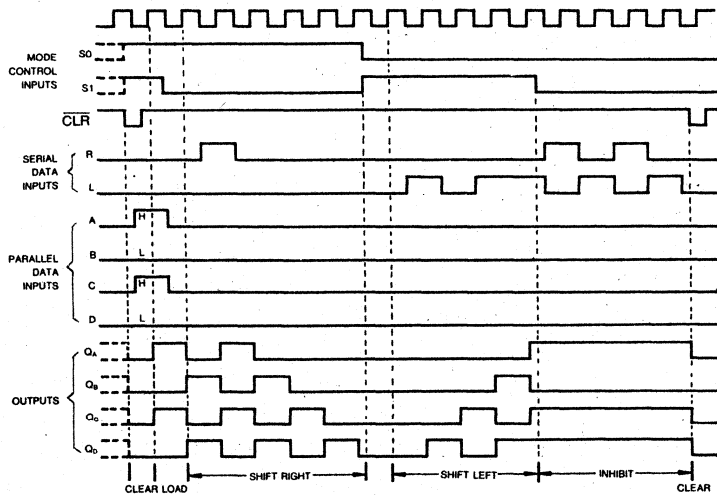
Q_{A0}, Q_{B0}, Q_{C0}, Q_{D0}=the level of Q_A, Q_B, Q_C, or Q_D, respectively, before the indicated steady-state input conditions were established.

Q_{An}, Q_{Bn}, Q_{Cn}, Q_{Dn}=the level of Q_A, Q_B, Q_C, respectively, before the most-recent ↑ transition of the clock.

LOGIC DIAGRAM



typical clear, load, right-shift, inhibit, and clear sequences



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN}, V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|---|--|-----------------------|---------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ | KS54HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| Guaranteed Limits | | | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | $\pm 1.0^*$ | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS194

| Characteristic | Symbol | Conditions† | T _a = 25°C V _{CC} = 5.0V | | KS74HCTLS | KS54HCTLS | Unit |
|---|------------------|-----------------------|---|----|---|--|------|
| | | | | | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Clock Frequency | f _{max} | C _L = 50pF | 40 | 30 | 25 | 20 | MHz |
| Maximum Propagation Delay, CLK to Q _H | t _{PLH} | | 18 | 24 | 30 | 36 | ns |
| | t _{PHL} | | 18 | 24 | 30 | 36 | |
| Maximum Propagation Delay, CLR to Q _H | t _{PHL} | | 21 | 28 | 35 | 42 | ns |
| Minimum Pulse Width | CLR to Low | t _w | 12 | 16 | 20 | 24 | ns |
| | CLK High or Low | | 12 | 16 | 20 | 24 | |
| Minimum Setup Time, Any Input before CLK† | t _s | | 10 | 17 | 20 | 20 | ns |
| Minimum Hold Time, Data after CLK† | t _s | | -3 | 0 | 0 | 0 | ns |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

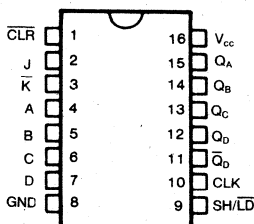
† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Parallel-to-Serial, Serial-to-Parallel Conversions
- Parallel Synchronous Loading
- J and K Inputs to First Stage
- Right-shift Only with Complementary Outputs on Last Stage
- Direct Overriding Clear
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



FUNCTION TABLE

| CLR | SHIFT/LOAD | INPUTS | | | | OUTPUTS | | | | | | | |
|-----|------------|--------|--------|-------|----------|---------|----|----|---------|-----|--------|-----|---------|
| | | CLK | SERIAL | | PARALLEL | | QA | QB | QC | QD | QD-bar | | |
| | | | J | K-bar | A | B | | | | | | C | D |
| L | X | X | X | X | X | X | X | X | L | L | L | L | H |
| H | L | ↑ | X | X | a | b | c | d | a | b | c | d | d-bar |
| H | H | L | X | X | X | X | X | X | QA0 | QB0 | QC0 | QD0 | QD0-bar |
| H | H | ↑ | L | H | X | X | X | X | QA0 | QA0 | QBn | QCn | QCn-bar |
| H | H | ↑ | L | L | X | X | X | X | L | QAn | QBn | QCn | QCn-bar |
| H | H | ↑ | H | H | X | X | X | X | H | QAn | QBn | QCn | QCn-bar |
| H | H | ↑ | H | L | X | X | X | X | QAn-bar | QAn | QBn | QCn | QCn-bar |

H=high level (steady state)
L=low level (steady state)
X=irrelevant (any input, including transitions)
↑=transition from low to high level
a,b,c,d=the level of steady-state input at A,B,C, or D, respectively.
QA0, QB0, QC0, QD0=the level of QA, QB, QC, or QD, respectively, before the indicated steady-state input conditions were established.
QAn, QBn, QCn=the level of QA, QB or QC, respectively, before the mostrecent transition of the clock.

DESCRIPTION

These 4-bit registers feature parallel inputs, parallel outputs, J-K serial inputs, shift/load control input, and a direct overriding clear. The registers have two modes of operation:

- Parallel (broadside) load
- Shift (in the direction A_n toward Q_D)

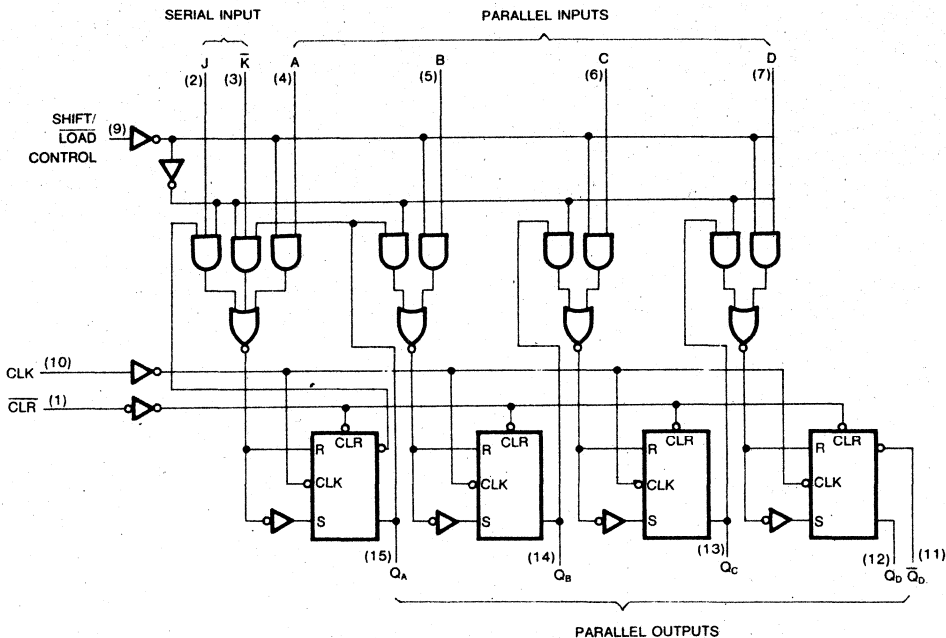
Parallel loading is accomplished by applying the four bits of data and taking the shift/load control input low. The data is loaded into the associate flip-flops and appears at the outputs after the positive transition of the clock input. During loading serial data flow is inhibited.

Shifting is accomplished synchronously when the shift/load control input is high. Serial data for this mode is entered at the J-K inputs. These inputs permit the first stage to perform as a J-K, D-, or T-type flip-flop as shown in the function table.

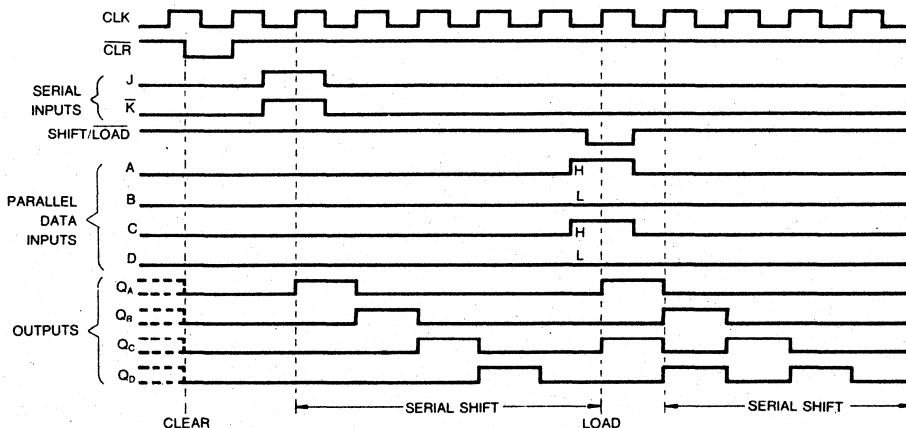
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAM



typical clear, shift, and load sequences



Absolute Maximum Ratings*

| | |
|---|-----------------|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | |
|---|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN} , V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74HCTLS: -40°C to +85°C KS54HCTLS: -55°C to +125°C |
| Input Rise & Fall Times, t_r , t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|--|-----------------------|---|---------------|------|
| | | | Typ | Guaranteed Limits | Guaranteed Limits | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | | mA | |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS195

| Characteristic | Symbol | Conditions† | T _a = 25°C V _{CC} = 5.0V | | KS74HCTLS | KS54HCTLS | Unit |
|---|----------------------------|-----------------------|---|----|---|--|------|
| | | | | | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Clock Frequency | f _{max} | C _L = 50pF | 50 | 30 | 25 | 20 | MHz |
| Maximum Propagation Delay, CLK to Q _H | t _{PLH} | | 18 | 24 | 30 | 36 | ns |
| | t _{PHL} | | 18 | 24 | 30 | 36 | ns |
| Maximum Propagation Delay, CLR to Q _H | t _{PHL} | | 21 | 28 | 35 | 42 | ns |
| Maximum Pulse Width | CLR Low | t _w | 10 | 12 | 15 | 20 | ns |
| | CLK High or Low | | 12 | 16 | 20 | 24 | |
| Minimum Setup Time before CLK† | SH/LD High | t _{su} | 15 | 20 | 25 | 25 | ns |
| | Serial or Parallel | | 12 | 15 | 20 | 24 | |
| | CLR inactive | | 15 | 20 | 25 | 25 | |
| Minimum Hold Time after CLK† | SH/LD High | t _h | -3 | 0 | | 0 | ns |
| | Serial or Parallel Data | | -3 | 0 | | 0 | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
I_{OL} = 24mA @ V_{OL} = 0.5V
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C

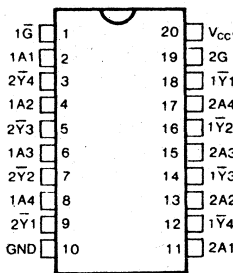
DESCRIPTION

These high-speed octal buffers and line drivers are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

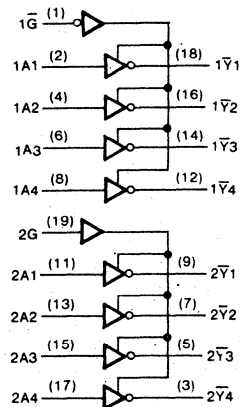
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



Absolute Maximum Ratings*

| | |
|---|-----------------|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 70 mA |
| Continuous Current Through V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | |
|---|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN} , V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74HCTLS: -40°C to +85°C KS54HCTLS: -55°C to +125°C |
| Input Rise & Fall Times, t_r , t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|-----------------------------------|----------|--|--------------------------|----------------------|---|--|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS210

| Characteristic | Symbol | Conditions [†] | T _a = 25°C V _{CC} = 5.0V | | KS74HCTLS T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | | KS54HCTLS T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | Unit |
|---|------------------|-------------------------|---|-------------------|--|----|---|----|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay, A to Y | t _{PLH} | C _L = 50pF | 13 | 18 | 22 | 27 | | | ns |
| | | C _L = 150pF | 16 | 25 | 31 | 38 | | | |
| | t _{PHL} | C _L = 50pF | 13 | 18 | 22 | 27 | | | ns |
| | | C _L = 150pF | 16 | 25 | 31 | 38 | | | |
| Maximum Output Enable Time, Enable to Y | t _{PZH} | R _L = 1kΩ | C _L = 50pF | 17 | 23 | 29 | 34 | | ns |
| | | | C _L = 150pF | 23 | 30 | 28 | 45 | | |
| | t _{PZL} | C _L = 50pF | 17 | 23 | 29 | 34 | | | |
| | | C _L = 150pF | 23 | 30 | 38 | 45 | | | |
| Maximum Output Disable Time, Enable to Y | t _{PHZ} | R _L = 1kΩ | 16 | 21 | 26 | 32 | | ns | |
| | t _{PLZ} | C _L = 50pF | 16 | 21 | 26 | 32 | | | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | | pF | |
| Maximum Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C _{PD} | Output Disabled | 5 | | | | | pF | |
| | | Output Enabled | 30 | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Designed specifically for high-speed memory decoders and data transmission systems
- Incorporates 2 enable inputs to simplify cascading and/or data reception
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
I_{OL} = 8 mA @ V_{OL} = 0.5V
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C

DESCRIPTION

These devices are designed to be used in high-performance memory-decoding or data-routing applications requiring very short propagation delay times. In high-performance memory systems, these decoders can be used with high-speed memories utilizing a fast enable circuit. The delay times of these decoders and the enable time of the memory are usually less than the typical access time of the memory. This means that the effective system delay introduced by the decoder is negligible.

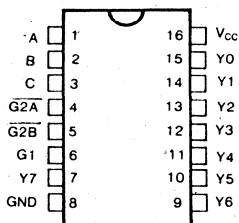
The conditions at the binary select inputs and the three enable inputs select one of eight input lines. Two active-low and one active-high enable inputs reduce the need for external gates or inverters when expanding.

A 24-line decoder can be implemented without external inverters and a 31-line decoder requires only one inverter. An enable input can be used as a data input for demultiplexing applications.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

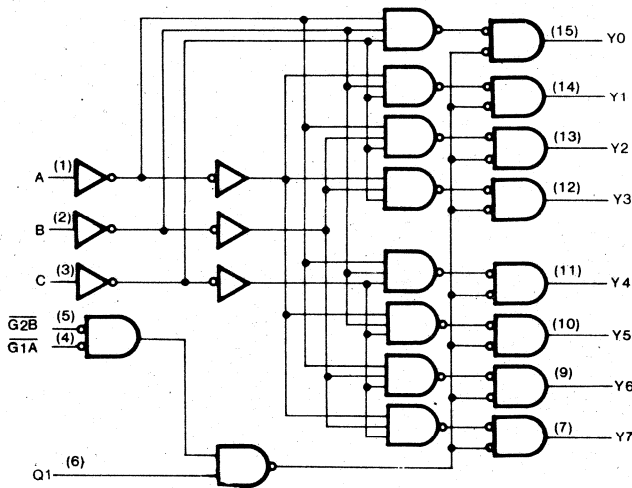


FUNCTION TABLE

| Enable Inputs | | Select Inputs | | | Outputs | | | | | | | |
|---------------|-----|---------------|---|---|---------|----|----|----|----|----|----|----|
| G1 | G2* | C | B | A | Y0 | Y1 | Y2 | Y3 | Y4 | Y5 | Y6 | Y7 |
| X | H | X | X | X | L | L | L | L | L | L | L | L |
| L | X | X | X | X | L | L | L | L | L | L | L | L |
| H | L | L | L | L | H | L | L | L | L | L | L | L |
| H | L | L | L | H | L | H | L | L | L | L | L | L |
| H | L | L | H | L | L | L | H | L | L | L | L | L |
| H | L | H | L | L | L | L | L | L | H | L | L | L |
| H | L | H | L | H | L | L | L | L | L | H | L | L |
| H | L | H | H | L | L | L | L | L | L | L | H | L |
| H | L | H | H | H | L | L | L | L | L | L | L | H |

* G2 = G2A + G2B

LOGIC DIAGRAM



Absolute Maximum Ratings*

| | |
|--|---|
| Supply Voltage Range V_{CC} , | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{STG} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

| | |
|----------------------|---|
| Plastic Package (N): | $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C |
| Ceramic Package (J): | $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C |

Recommended Operating Conditions

| | |
|---|--|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} .. | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74HCTLS: -40°C to $+85^\circ\text{C}$ |
| | KS54HCTLS: -55°C to $+125^\circ\text{C}$ |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V\pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|--|---------------------|---|---------------|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-4\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_Z=2.4\text{V}$ Other Inputs: At V_{CC} or GND $I_O=0$ | | 2.7 | 2.9 | 3.0 | | mA | |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS238

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|---|-----------|---------------------|--|-------------------|---|----|--|----|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay, A, B, C or any Y | t_{PLH} | $C_L = 50\text{pF}$ | 22 | 30 | 37 | 45 | 45 | ns | |
| | t_{PHL} | | 22 | 30 | 37 | 45 | | | |
| Maximum Propagation Delay, G1 to any Y | t_{PLH} | | 24 | 32 | 40 | 48 | | | |
| | t_{PHL} | | 24 | 32 | 40 | 48 | | | |
| Maximum Propagation Delay, G2A or G2B to any Y | t_{PLH} | | 18 | 25 | 31 | 37 | | | |
| | t_{PHL} | | 18 | 25 | 31 | 37 | | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF | | |
| Power Dissipation Capacitance* | C_{PD} | | 50 | | | | pF | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Designed specifically for high-speed memory decoders and data transmission systems
- Incorporates 2 enable inputs to simplify cascading and/or data reception
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

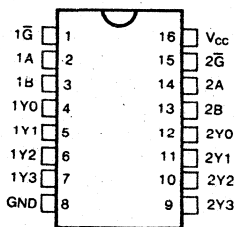
These devices are designed to be used in high-performance memory-decoding or data-routing applications requiring very short propagation delay times. In high-performance memory systems, these decoders can be used to minimize the effects of system decoding. When used with high-speed memories utilizing a fast-enable circuit, the delay times of these decoders and the enable time of the memory are usually less than the typical access time of the memory.

This means that the effective system delay introduced by the decoder is negligible.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

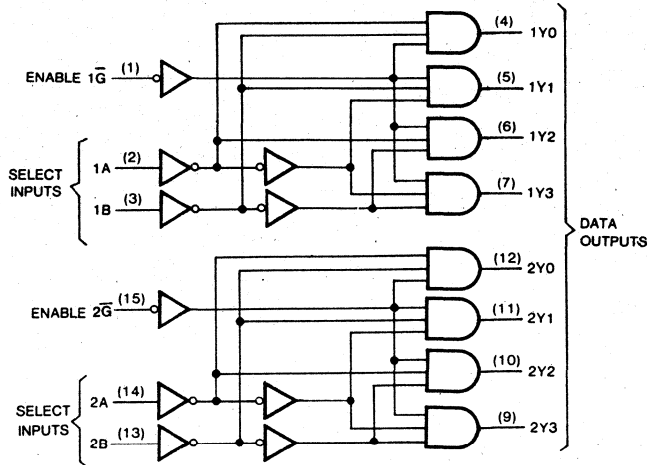
PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | | Outputs | | | |
|-----------|--------|---|---------|----|----|----|
| Enable | Select | | Y0 | Y1 | Y2 | Y3 |
| \bar{G} | B | A | | | | |
| H | X | X | L | L | L | L |
| L | L | L | H | L | L | L |
| L | L | H | L | H | L | L |
| L | H | L | L | L | H | L |
| L | H | H | L | L | L | H |

LOGIC DIAGRAM



Absolute Maximum Ratings*

| | |
|--|---|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 70 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_d^\dagger | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74HCTLS: -40°C to $+85^\circ\text{C}$ KS54HCTLS: -55°C to $+125^\circ\text{C}$ |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V\pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|---|--------------------------|------------------------|---|--|---------------|
| | | | Typ | Guaranteed Limits | | | |
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS239

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|---|-----------|---------------------|--------------------------|-------------------|---|--|------|
| | | | $V_{CC} = 5.0\text{V}$ | Guaranteed Limits | | | |
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | |
| | | | | | $V_{CC} = 5.0\text{V} \pm 10\%$ | $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| Maximum Propagation Delay, A or B any Y : | t_{PLH} | $C_L = 50\text{pF}$ | 22 | 30 | 37 | 45 | ns |
| | t_{PHL} | | 22 | 30 | 37 | 45 | |
| Maximum Propagation Delay, \bar{G} to any Y | t_{PLH} | | 21 | 8 | 35 | 42 | ns |
| | t_{PHL} | | 22 | 8 | 35 | 42 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | 50 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

KS54HCTLS 240/241/244 Octal Buffers and Line Drivers with 3-State Outputs

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

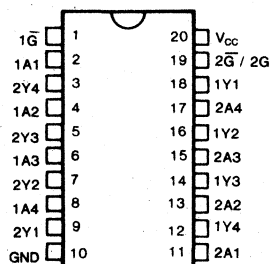
These high-speed octal buffers and line drivers are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

The designer has the choice of combinations of inverting/non-inverting outputs and symmetrical complementary input control (both active-low, or one active-low, the other active-high).

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

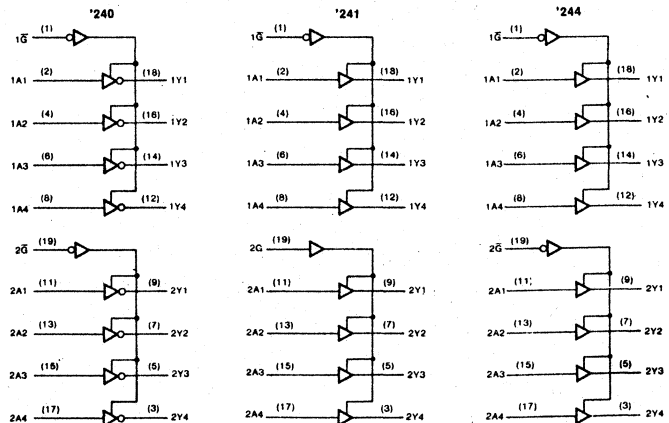
All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



*2G for '240 and '244
2G for '241

LOGIC DIAGRAMS



KS54HCTLS 240/241/244 Octal Buffers and Line Drivers with 3-State Outputs

Absolute Maximum Ratings*

| | |
|---|---|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | $(V_I < -0.5V \text{ or } V_I > V_{CC} + 0.5V)$ ± 20 mA |
| DC Output Diode Current, I_{OK} | $(V_O < -0.5V \text{ or } V_O > V_{CC} + 0.5V)$ ± 20 mA |
| Continuous Output Current Per Pin, I_O | $(-0.5V < V_O < V_{CC} + 0.5V)$ ± 70 mA |
| Continuous Current Through V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74HCTLS: -40°C to +85°C KS54HCTLS: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|-----------------------------------|----------|--|--------------------------|----------------------|---|--|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |

5

KS54HCTLS 240/241/244 Octal Buffers and Line Drivers with 3-State Outputs

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS240, HCTLS241, HCTLS244

| Characteristic | Symbol | Conditions† | T _a = 25°C V _{CC} = 5.0V | | KS74HCTLS | KS54HCTLS | Unit | |
|---|------------------|---|---|----|---|--|------|----|
| | | | | | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | |
| | | | Typ | | Guaranteed Limits | | | |
| Maximum Propagation Delay, A to Y | t _{PLH} | C _L = 50pF C _L = 150pF | 13 | 18 | 22 | 27 | ns | |
| | | | 16 | 25 | 31 | 38 | | |
| | t _{PHL} | C _L = 50pF C _L = 150pF | 13 | 18 | 22 | 27 | ns | |
| | | | 16 | 25 | 31 | 38 | | |
| Maximum Output Enable Time, Enable to Y | t _{PZH} | R _L = 1kΩ | C _L = 50pF | 17 | 23 | 29 | 34 | ns |
| | | | C _L = 150pF | 23 | 30 | 28 | 45 | |
| | t _{PZL} | C _L = 50pF C _L = 150pF | 17 | 23 | 29 | 34 | | |
| | | | 23 | 30 | 38 | 45 | | |
| Maximum Output Disable Time, Enable to Y | t _{PHZ} | R _L = 1kΩ | 16 | 21 | 26 | 32 | ns | |
| | t _{PLZ} | C _L = 50pF | 16 | 21 | 26 | 32 | | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF | |
| Maximum Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C _{PD} | Output Disabled | 5 | | | | pF | |
| | | Output Enabled | 30 | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

KS54HCTLS 242/243 KS74HCTLS

Quad Bus Transceivers with 3-State Outputs

Preliminary Specifications

FEATURES

- 2-Way Asynchronous Communication Between Data Buses
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

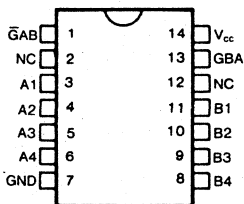
DESCRIPTION

These four-data line transceivers are designed for asynchronous two-way communications between data buses.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

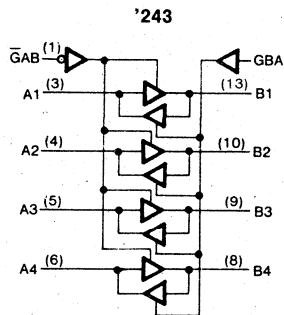
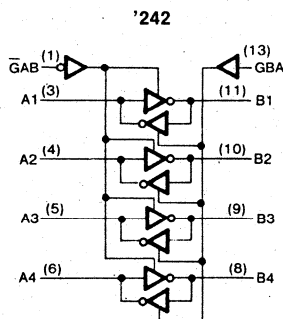
PIN CONFIGURATION



FUNCTION TABLE

| INPUTS | | '242 | '243 |
|-------------|-----|----------------------------|----------------------------|
| $\bar{G}AB$ | GBA | | |
| L | L | \bar{A} to B | A to B |
| H | H | \bar{B} to A | B to A |
| H | L | Isolation | Isolation |
| L | H | Latch A and B ($A=B$) | Latch A and B ($A=B$) |

LOGIC DIAGRAMS



Absolute Maximum Ratings*

| | |
|--|---|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 70 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74HCTLS: -40°C to $+85^\circ\text{C}$ KS54HCTLS: -55°C to $+125^\circ\text{C}$ |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|--|---|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS242, HCTLS243

| Characteristic | Symbol | Conditions [†] | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--|-----------|-------------------------|--|----|--|---|------|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Propagation Delay, A to B or B to A | t_{PLH} | $C_L = 50\text{pF}$ | 14 | 18 | 22 | 27 | ns |
| | | $C_L = 150\text{pF}$ | 17 | 25 | 31 | 38 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 14 | 18 | 22 | 27 | |
| | | $C_L = 150\text{pF}$ | 17 | 25 | 31 | 38 | |
| Maximum Output Enable Time $\bar{G}AB$ to B, GBA to A | t_{PZH} | $C_L = 50\text{pF}$ | 23 | 30 | 38 | 45 | ns |
| | | $C_L = 150\text{pF}$ | 39 | 37 | 47 | 56 | |
| | t_{PZL} | $C_L = 50\text{pF}$ | 23 | 30 | 38 | 45 | |
| | | $C_L = 150\text{pF}$ | 29 | 37 | 47 | 56 | |
| Maximum Output Disable Time, $\bar{G}AB$ to B, GBA to A | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 18 | 25 | 31 | 37 | ns |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 18 | 25 | 31 | 37 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Maximum Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF |
| Power Dissipation Capacitance* (per stage) | C_{PD} | Output Disabled | 5 | | | | pF |
| | | Output Enabled | 30 | | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-state outputs with high drive current ($I_{OL} = 24\text{mA}$ @ $V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

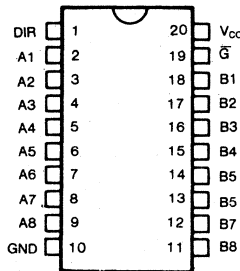
These high-speed octal bus transceivers are designed for synchronous two-way communication between data buses. The control function implementation minimizes external timing requirements.

The devices allow data transmission from the A bus to the B bus or from the B bus to the A bus depending upon the logic level at the direction control (DIR) input. The enable input (\bar{G}) can be used to disable the device so that the buses are effectively isolated.

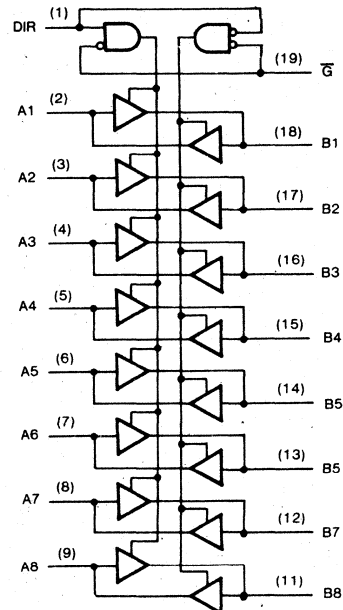
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



FUNCTION TABLE

| Inputs | | Operation |
|-----------|-----|---------------------|
| \bar{G} | DIR | |
| L | L | Bus B Data to Bus A |
| L | H | Bus A Data to Bus B |
| H | X | Isolation |

Absolute Maximum Ratings*

| | |
|---|---|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 70 mA |
| Continuous Current Through V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74HCTLS: -40°C to $+85^\circ\text{C}$ KS54HCTLS: -55°C to $+125^\circ\text{C}$ |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|---|--|---------------------|-------------------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | KS54HCTLS $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | Guaranteed Limits |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS245

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit |
|---|-----------|--|--|----|---|--|------|
| | | | | | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Propagation Delay, A to B or B to A | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 9 | 12 | 15 | 18 | ns |
| | | | 15 | 19 | 24 | 29 | |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 9 | 12 | 15 | 18 | |
| | | | 15 | 19 | 24 | 29 | |
| Maximum Output Enable Time, \bar{G} to A or B | t_{PZH} | $R_L = 1\text{k}\Omega$ $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 30 | 40 | 50 | 60 | ns |
| | | | 36 | 47 | 59 | 71 | |
| | t_{PZL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 30 | 40 | 50 | 60 | |
| | | | 36 | 47 | 59 | 71 | |
| Maximum Output Disable Time, \bar{G} to A or B | t_{PHZ} | $R_L = 1\text{k}\Omega$ $C_L = 50\text{pF}$ | 18 | 25 | 31 | 37 | ns |
| | | | 18 | 25 | 31 | 37 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Maximum Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF |
| Power Dissipation Capacitance* (per stage) | C_{PD} | $\bar{G} = V_{CC}$ $\bar{G} = \text{GND}$ | 5 | | | | pF |
| | | | 30 | | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Three-State Version of '151
- Three-State Outputs Interface Directly with System Bus
- Performs Parallel-to-Serial Conversion
- Complementary Outputs Provide True and Inverted Data
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

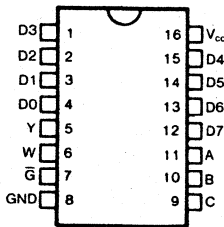
These data selectors/multiplexers contain full binary decoding to select one-of-eight data sources and feature strobe-controlled complementary three-state outputs.

The three-state outputs can interface with and drive data lines of bus-organized systems. With all but one of the common outputs disabled (at a high-impedance state), the low-impedance of the single enabled output will drive the bus line to a high or low logic level. Both outputs are controlled by the strobe (\bar{G}). The outputs are disabled when \bar{G} is high.

These devices provide speed and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

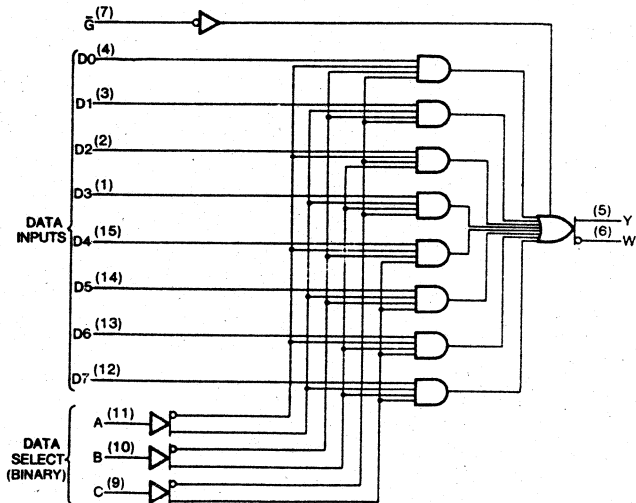
PIN CONFIGURATION



FUNCTION TABLE

| INPUTS | | | | OUTPUTS | |
|--------|---|---|-----------|---------|------------|
| SELECT | | | STROBE | Y | W |
| C | B | A | \bar{G} | | |
| X | X | X | H | Z | Z |
| L | L | L | L | D0 | $\bar{D}0$ |
| L | L | H | L | D1 | $\bar{D}1$ |
| L | H | L | L | D2 | $\bar{D}2$ |
| L | H | H | L | D3 | $\bar{D}3$ |
| H | L | L | L | D4 | $\bar{D}4$ |
| H | L | H | L | D5 | $\bar{D}5$ |
| H | H | L | L | D6 | $\bar{D}6$ |
| H | H | H | L | D7 | $\bar{D}7$ |

LOGIC DIAGRAM



Absolute Maximum Ratings*

| | |
|--|-----------------|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 70 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

| | |
|----------------------|------------------------------|
| Plastic Package (N): | -12mW/°C from 65°C to 85°C |
| Ceramic Package (J): | -12mW/°C from 100°C to 125°C |

Recommended Operating Conditions

| | |
|--|----------------------------|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74HCTLS: -40°C to +85°C |
| | KS54HCTLS: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|--|---|-----------------------|---------------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS251

| Characteristic | Symbol | Conditions† | T _a = 25°C | | KS74HCTLS | | KS54HCTLS | | Unit |
|--|------------------|---|------------------------|-------------------|---------------------------------|----|----------------------------------|----|------|
| | | | V _{CC} = 5.0V | | T _a = -40°C to +85°C | | T _a = -55°C to +125°C | | |
| | | | | | V _{CC} = 5.0V ± 10% | | V _{CC} = 5.0V ± 10% | | |
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay, A, B or C to Y | t _{PLH} | C _L = 50pF C _L = 150pF | 20 | 26 | 33 | 40 | 40 | 51 | ns |
| | | | 23 | 33 | 42 | 51 | 51 | | |
| | t _{PHL} | C _L = 50pF C _L = 150pF | 20 | 26 | 33 | 40 | 40 | 51 | ns |
| | | | 23 | 33 | 42 | 51 | 51 | | |
| Maximum Propagation Delay, A, B or C to W | t _{PLH} | C _L = 50pF C _L = 150pF | 25 | 34 | 42 | 50 | 50 | 61 | ns |
| | | | 28 | 41 | 51 | 61 | 61 | | |
| | t _{PHL} | C _L = 50pF C _L = 150pF | 25 | 34 | 42 | 50 | 50 | 61 | ns |
| | | | 28 | 41 | 51 | 61 | 61 | | |
| Maximum Propagation Delay, Any D to Y | t _{PLH} | C _L = 50pF C _L = 150pF | 11 | 15 | 19 | 22 | 22 | 33 | ns |
| | | | 14 | 22 | 28 | 33 | 33 | | |
| | t _{PHL} | C _L = 50pF C _L = 150pF | 11 | 15 | 19 | 22 | 22 | 33 | ns |
| | | | 14 | 22 | 28 | 33 | 33 | | |
| Maximum Propagation Delay, Any D to W | t _{PLH} | C _L = 50pF C _L = 150pF | 17 | 22 | 28 | 33 | 33 | 44 | ns |
| | | | 30 | 29 | 37 | 44 | 44 | | |
| | t _{PHL} | C _L = 50pF C _L = 150pF | 17 | 22 | 28 | 33 | 33 | 44 | ns |
| | | | 20 | 29 | 37 | 44 | 44 | | |
| Maximum Output Enable Time, G to Y or W | t _{PZH} | R _L = 1kΩ | C _L = 50pF | 24 | 32 | 40 | 48 | 48 | ns |
| | | | C _L = 150pF | 30 | 39 | 49 | 59 | 59 | |
| | t _{PZL} | R _L = 1kΩ | C _L = 50pF | 24 | 32 | 40 | 48 | 48 | ns |
| | | | C _L = 150pF | 30 | 39 | 49 | 59 | 59 | |
| Maximum Output Disable Time, G to Y or W | t _{PHZ} | R _L = 1kΩ | C _L = 50pF | 24 | 32 | 40 | 48 | 48 | ns |
| | | | C _L = 150pF | 30 | 39 | 49 | 59 | 59 | |
| | t _{PLZ} | R _L = 1kΩ | C _L = 50pF | 24 | 32 | 40 | 48 | 48 | ns |
| | | | C _L = 150pF | 30 | 39 | 49 | 59 | 59 | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | | pF | |
| Maximum Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* | C _{PD} | | 0 | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

5

Preliminary Specifications

FEATURES

- Three-State Version of '153
- Permits Multiplexing from N Lines to 1 Line
- Performs Parallel-to—Serial Conversion
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

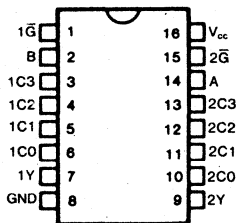
Each of these data selectors/multiplexers contains inverters and drivers to supply full binary decoding data selection to the AND-OR gates. Separate output control inputs are provided for each of the two four-line sections.

The three-state outputs can interface with and drive data lines of bus-organized systems. With all but one of the common outputs disabled (at a high-impedance state) the low-impedance of the single enabled output will drive the bus line to a high or low logic level. Each output has its own strobe (\bar{G}). The output is disabled when its strobe is high.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

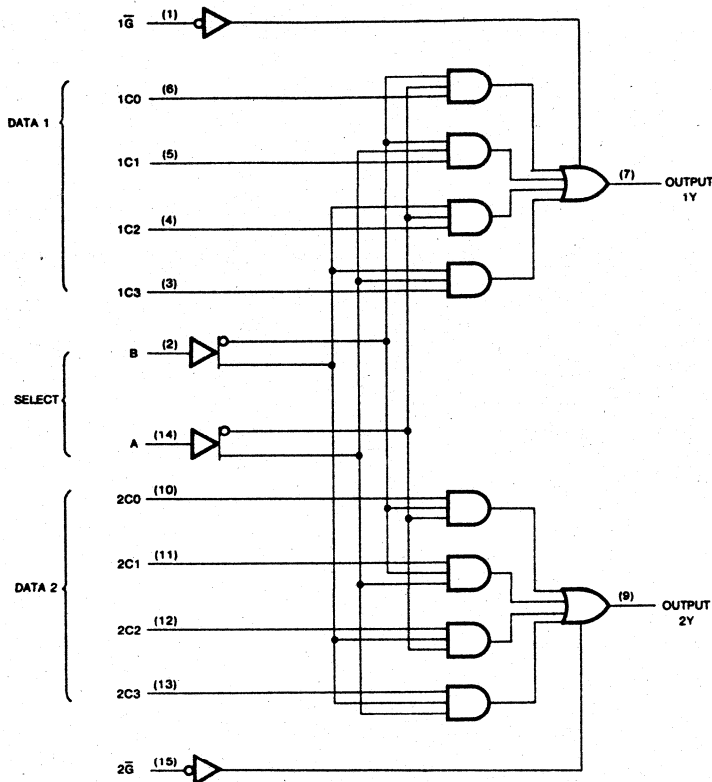


FUNCTION TABLE

| SELECT | | DATA INPUTS | | | | OUTPUT CONTROL | OUTPUT |
|--------|---|-------------|----|----|----|----------------|--------|
| B | A | C0 | C1 | C2 | C3 | \bar{G} | Y |
| X | X | X | X | X | X | H | Z |
| L | L | L | X | X | X | L | L |
| L | L | H | X | X | X | L | H |
| L | H | X | L | X | X | L | L |
| L | H | X | H | X | X | L | H |
| H | L | X | X | L | X | L | L |
| H | L | X | X | H | X | L | H |
| H | H | X | X | X | L | L | L |
| H | H | X | X | X | H | L | H |

Address inputs A and B are common to both sections.

LOGIC DIAGRAM



5

Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} -0.5V to +7V
- DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
- DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
- Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
- Continuous Current Through
 V_{CC} or GND pins ± 125 mA
- Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
- Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

- † Power Dissipation temperature derating:
Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
- Operating Temperature
 Range KS74HCTLS: -40°C to $+85^\circ\text{C}$
 KS54HCTLS: -55°C to $+125^\circ\text{C}$
- Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|---|--------------------------|----------------------|--|---------------------|---|---------------------|---------------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | $V_{CC}-0.1$ 3.7 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.33 0.5 | 0.1 0.4 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 5.0 | ± 10.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 80.0 | 160.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 2.9 | 3.0 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns, HCTLS253)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC}=5.0\text{V}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC}=5.0\text{V} \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC}=5.0\text{V} \pm 10\%$ | | Unit |
|---|-----------|---|--|-------------------|---|----|--|----|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay, A or B to Any Y | t_{PLH} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 24 | 32 | 40 | 48 | 48 | 59 | ns |
| | t_{PHL} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 24 | 32 | 40 | 48 | 48 | 59 | |
| Maximum Propagation Delay, Data (any C) to any Y | t_{PLH} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 15 | 20 | 25 | 30 | 25 | 30 | ns |
| | t_{PHL} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 15 | 20 | 25 | 30 | 25 | 30 | |
| Maximum Output Enable Time, \bar{G} to Y | t_{PZH} | $R_L=1\text{k}\Omega$ | $C_L=50\text{pF}$ | 17 | 22 | 28 | 33 | 33 | ns |
| | t_{PZL} | | $C_L=150\text{pF}$ | 23 | 29 | 37 | 44 | 44 | |
| Maximum Output Disable Time, \bar{G} to Y | t_{PHZ} | $R_L=1\text{k}\Omega$ | $C_L=50\text{pF}$ | 17 | 22 | 28 | 33 | 33 | ns |
| | t_{PLZ} | | $C_L=150\text{pF}$ | 23 | 29 | 37 | 44 | 44 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Maximum Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

KS54HCTLS 257/258 Quad 2-Line to 1-Line Data Selectors/ KS74HCTLS Multiplexers with 3-State Outputs

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^\circ\text{C}$
KS54HCTLS: -55°C to $+125^\circ\text{C}$

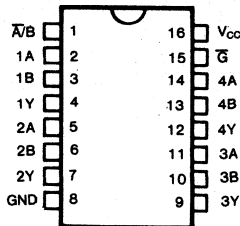
DESCRIPTION

The '257 and '258 multiplex signals from for-bit data sources to four-output data lines in bus organized systems. The data presented at the outputs is non-inverted for the '257 and inverted for the '258.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

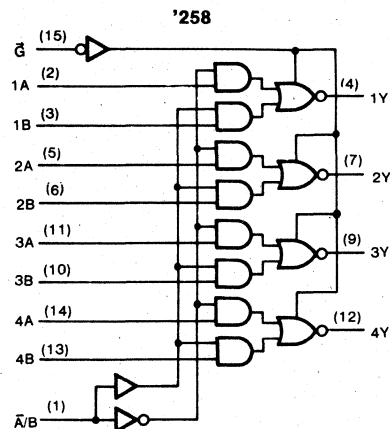
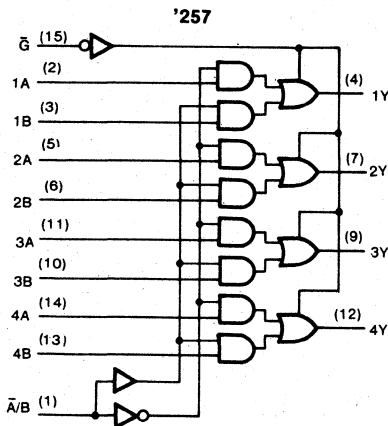


FUNCTION TABLE

| | | Inputs | | Output Y | |
|----------------|--------|--------|---|----------|------|
| Output Control | select | Data | | '257 | '258 |
| | | A | B | | |
| H | X | X | X | Z | Z |
| L | L | L | X | L | H |
| L | L | H | X | H | L |
| L | H | X | L | L | H |
| L | H | X | H | H | L |

5

LOGIC DIAGRAMS



KS54HCTLS 257/258 Quad 2-Line to 1-Line Data Selectors/ KS74HCTLS Multiplexers with 3-State Outputs

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature

Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C

Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|----------------------|--|---------------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

KS54HCTLS 257/258 Quad 2-Line to 1-Line Data Selectors/ KS74HCTLS Multiplexers with 3-State Outputs

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS257, HCTLS258

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|--|------------------|------------------------------|--|----|---|----|--|----|------|
| | | | Typ | | Guaranteed Limits | | Guaranteed Limits | | |
| | | | | | | | | | |
| Maximum Propagation Delay, A to B to any Y | t _{PLH} | C _L = 50pF | 14 | 18 | 23 | 27 | ns | | |
| | | C _L = 150pF | 17 | 25 | 32 | 38 | | | |
| | t _{PHL} | C _L = 50pF | 14 | 18 | 23 | 27 | ns | | |
| | | C _L = 150pF | 17 | 25 | 32 | 38 | | | |
| Maximum Propagation Delay, A/B to any Y | t _{PLH} | C _L = 50pF | 16 | 21 | 26 | 31 | ns | | |
| | | C _L = 150pF | 19 | 28 | 35 | 42 | | | |
| | t _{PHL} | C _L = 50pF | 16 | 21 | 26 | 31 | ns | | |
| | | C _L = 150pF | 19 | 28 | 35 | 42 | | | |
| Maximum Output Enable Time, \bar{G} to any Y | t _{PZH} | R _L = 1k Ω | C _L = 50pF | 22 | 30 | 37 | 45 | ns | |
| | | | C _L = 150pF | 28 | 37 | 46 | 56 | | |
| | t _{PZL} | C _L = 50pF | 22 | 30 | 37 | 45 | | | |
| | | C _L = 150pF | 28 | 37 | 46 | 56 | | | |
| Maximum Output Disable Time, \bar{G} to any Y | t _{PHZ} | R _L = 1k Ω | 20 | 27 | 34 | 41 | ns | | |
| | t _{PLZ} | C _L = 50pF | 20 | 27 | 34 | 41 | | | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF | | |
| Maximum Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | pF | | |
| Power Dissipation Capacitance* | C _{PD} | | | | | | pF | | |

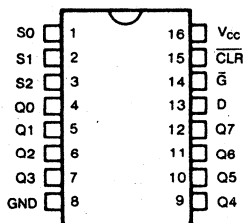
* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- 8-Bit parallel-out storage register performs serial-to-parallel conversion with storage
- Asynchronous parallel clear
- Active high decoder
- Enable/Disable input simplifies expansion
- Expandable for N-bit applications
- Four distinct functional modes
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



FUNCTION TABLE

| Inputs | | Output of Addressed Latch | Each Other Output | Function |
|--------|---|---------------------------|-------------------|----------------------|
| CLR | G | | | |
| H | L | D | Q_{i0} | Addressable Latch |
| H | H | Q_{i0} | Q_{i0} | Memory |
| L | L | D | L | 8-Line Demultiplexer |
| L | H | L | L | Clear |

D = the level at the data input.
 Q_{i0} = the level of Q_{i0} ($i = Q, 1, \dots, 7$, as appropriate) before the indicated steady-state input conditions were established.

DESCRIPTION

The '259 is a high-speed addressable latch designed for general purpose storage applications in digital systems. It can be used for implementing working registers, serial-holding registers and active-high decoders or demultiplexers.

The '259 has four distinct modes of operation that are selected via the clear (CLR) and enable (\bar{G}) inputs: 1) addressable latch; 2) memory; 3) active-high eight-channel demultiplexer; and 4) clear.

In the addressable latch mode, data on the data input (D) is written into the addressed latch. In this mode, data will be written into the addressed latch with all non-addressed latches remaining in their previous states.

In the memory mode, all latches remain in their previous state and are unaffected by the data of address inputs.

In the demultiplexing mode, addressed outputs will follow the state of the D input and all other outputs will remain low.

In the clear mode, all outputs are low and unaffected by the address and data inputs.

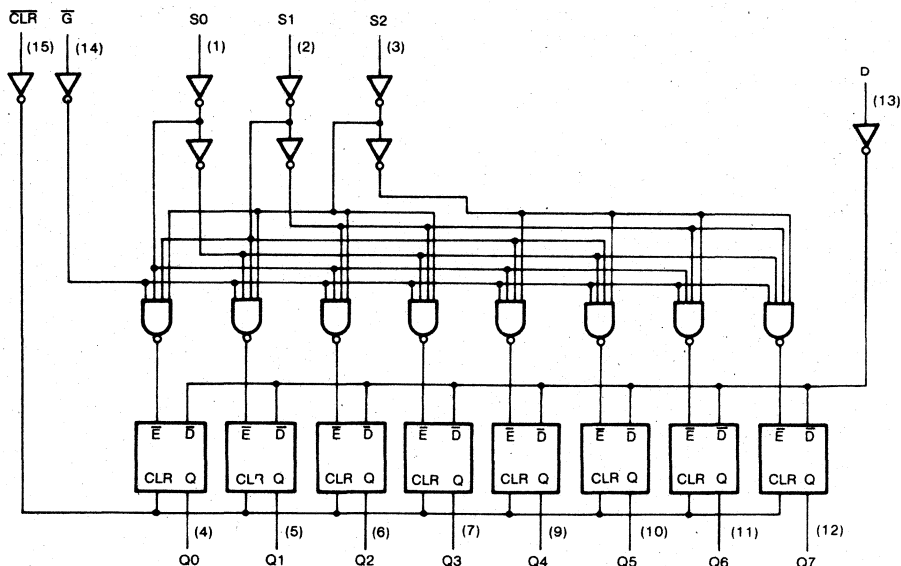
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LATCH SELECTION TABLE

| Select Inputs | | | Latch Addressed |
|---------------|----|----|-----------------|
| S2 | S1 | S0 | |
| L | L | L | 0 |
| L | L | H | 1 |
| L | H | L | 2 |
| L | H | H | 3 |
| H | L | L | 4 |
| H | L | H | 5 |
| H | H | L | 6 |
| H | H | H | 7 |

LOGIC DIAGRAM



5

Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} , -0.5V to +7V
- DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
- DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
- Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
- Continuous Current Through
 V_{CC} or GND pins ± 125 mA
- Storage Temperature Range, T_{stg} -65°C to +150°C
- Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

Power Dissipation temperature derating:

- Plastic Package (N): -12mW/°C from 65°C to 85°C
- Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN}, V_{OUT} ... 0V to V_{CC}
- Operating Temperature
Range KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C
- Input Rise & Fall Times, t_r, t_f Max 500 ns
- * Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|----------------------|--|-----|---|---------------|------|
| | | | Typ | Guaranteed Limits | | Guaranteed Limits | | Guaranteed Limits | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-4\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | | | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ per input pin | | 8.0 | 80.0 | 160.0 | | | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | $V_1=2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | | | mA | |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS259

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC}=5.0\text{V}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC}=5.0\text{V} \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC}=5.0\text{V} \pm 10\%$ | | Unit |
|---|---------------|-------------------|--|-------------------|---|-------------------|--|-------------------|------|
| | | | Typ | Guaranteed Limits | | Guaranteed Limits | | Guaranteed Limits | |
| Maximum Propagation Delay CLR to any Q | t_{PHL} | $C_L=50\text{pF}$ | 22 | 30 | 37 | 45 | | | ns |
| Maximum Propagation Delay, Data to Any Q | t_{PLH} | | 20 | 27 | 34 | 41 | | | ns |
| | t_{PHL} | | 20 | 27 | 34 | 41 | | | ns |
| Maximum Propagation Delay, Address to any Q | t_{PLH} | | 26 | 34 | 43 | 51 | | | ns |
| | t_{PHL} | | 26 | 34 | 43 | 51 | | | ns |
| Maximum Propagation Delay, \bar{G} to any Q | t_{PLH} | | 22 | 30 | 37 | 45 | | | ns |
| | t_{PHL} | | 22 | 30 | 37 | 45 | | | ns |
| Minimum Pulse Width | CLR LOW | | t_w | 8 | 10 | 13 | 15 | | |
| | \bar{G} Low | | 8 | 10 | 13 | 15 | | | ns |
| Minimum Setup Time, Data or Address before $\bar{G}\uparrow$ | t_{su} | | 8 | 10 | 13 | 15 | | | ns |
| Minimum Hold Time, Data or Address before $\bar{G}\uparrow$ | t_h | | -3 | 0 | 0 | 0 | | | ns |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | 80 | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
 KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

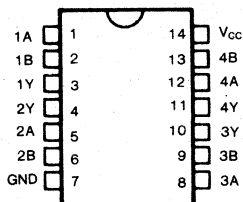
DESCRIPTION

These devices contain four independent exclusive-NOR gates with open-drain outputs. Using a suitable pull-up resistor, these outputs may be connected to other open-drain outputs to implement wired-AND functions.

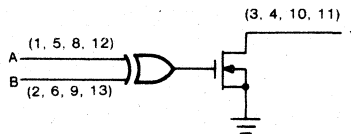
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



5

FUNCTION TABLE

| Inputs | | Output |
|--------|---|--------|
| A | B | Y |
| L | L | H |
| L | H | L |
| H | L | L |
| H | H | H |

Absolute Maximum Ratings*

| | |
|---|-----------------|
| Supply Voltage Range V_{CC} , | -0.5V to +7V |
| DC Input Diode Current, I_{IK} ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} ... | 0V to V_{CC} |
| Operating Temperature Range | KS74HCTLS: -40°C to +85°C KS54HCTLS: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|---------------------|--|------------|---|--|---------------|
| | | | Typ | Guaranteed Limits | Guaranteed Limits | | Guaranteed Limits | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | | μA |
| Maximum Output Leakage Current | I_{OZ} | $V_{IN}=V_{IH}$ or V_{IL} $V_{OUT}=V_{CC}$ | | ± 0.5 | ± 5.0 | ± 10.0 | | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | 40.0 | | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | | | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS266

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0V$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | | Unit |
|--------------------------------|-----------|--|---|-------------------|--|----|---|--|------|
| | | | Typ | Guaranteed Limits | Guaranteed Limits | | Guaranteed Limits | | |
| Maximum Propagation Delay | t_{PLH} | $C_L = 50\text{pF}$ $R_L = 1\text{k}\Omega$ | 18 | 25 | 31 | 37 | | | ns |
| | t_{PHL} | | 16 | 22 | 28 | 33 | | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | 15 | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Eight positive-edge-triggered D-type flip-flops with single-rail outputs
- Buffered common clock and asynchronous clear
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
($I_{OL} = 24\text{mA}$ @ $V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

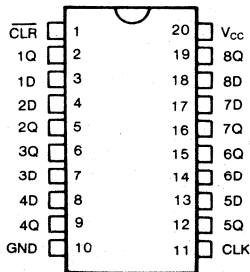
These devices are high-speed octal registers. They consist of eight positive-edge-triggered D-type flip-flops with individual D inputs and Q outputs. All flip flops are loaded and cleared simultaneously by the common buffered clock (CLK) and clear (CLR) inputs.

Information at the D inputs meeting the setup time requirements is transferred to the Q outputs on the positive-going edge of the clock pulse. When the clock input is at either the high or low level, the D input signal has no effect at the output.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

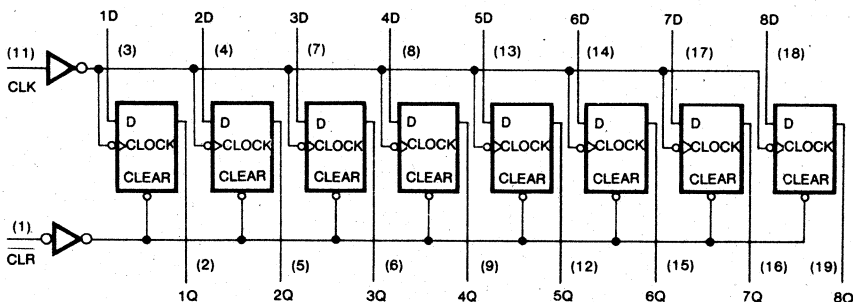


FUNCTION TABLE

(Each Flip-Flop)

| Inputs | | | Output |
|--------|-----|---|--------|
| CLR | CLK | D | Q |
| L | X | X | L |
| H | ↑ | H | H |
| H | ↑ | L | L |
| H | L | X | Q_0 |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} . . . 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: $-40^\circ C$ to $+85^\circ C$
 KS54HCTLS: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|------------------------|--------------------------------------|---------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ C$ to $+85^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -6mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 12mA$ $I_O = 24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS273

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit |
|---|----------------------|----------------------|--|----|--|---|------|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 40 | 30 | 25 | 20 | MHz |
| Maximum Propagation Delay, CLK to any | t_{PLH} | $C_L = 50\text{pF}$ | 20 | 27 | 33 | 40 | ns |
| | | $C_L = 150\text{pF}$ | 23 | 34 | 42 | 51 | |
| Maximum Propagation Delay, CLK to any | t_{PHL} | $C_L = 50\text{pF}$ | 20 | 27 | 33 | 40 | ns |
| | | $C_L = 150\text{pF}$ | 23 | 34 | 42 | 51 | |
| Maximum Propagation Delay, CLR to any Q | t_{PHL} | $C_L = 50\text{pF}$ | 20 | 27 | 33 | 40 | ns |
| | | $C_L = 150\text{pF}$ | 23 | 34 | 42 | 51 | |
| Minimum Pulse Width | CLR Low | t_w | 10 | 13 | 17 | 20 | ns |
| | CLK High or Low | | 10 | 13 | 17 | 20 | |
| Minimum Setup Time before CLK† | Data | t_{su} | 10 | 13 | 17 | 20 | ns |
| | Clear inactive State | | 13 | 17 | 21 | 25 | |
| Minimum Hold Time, Data after CLK† | t_h | | -3 | 0 | 0 | 0 | ns |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per package) | 150 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Generates Odd or Even Parity for Nine Data Lines
- Cascadable for N-Bits Parity
- Can be used to Upgrade Existing Systems using MSI Parity Circuits
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

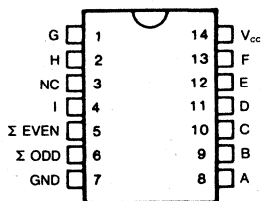
These universal, nine-bit parity generators/checkers feature odd and even outputs to facilitate operation of either odd or even parity application. The word-length capability is easily expanded by cascading.

The devices can be used to upgrade the performance of most systems utilizing the '180 parity generator/checker. Although the '280 is implemented without expander inputs, the corresponding function is provided by the availability of an input at pin 4 and the absence of any internal connection at pin 3. This permits the '280 to be substituted for the '180 in existing designs to produce an identical function even if the devices are mixed with existing '180's.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

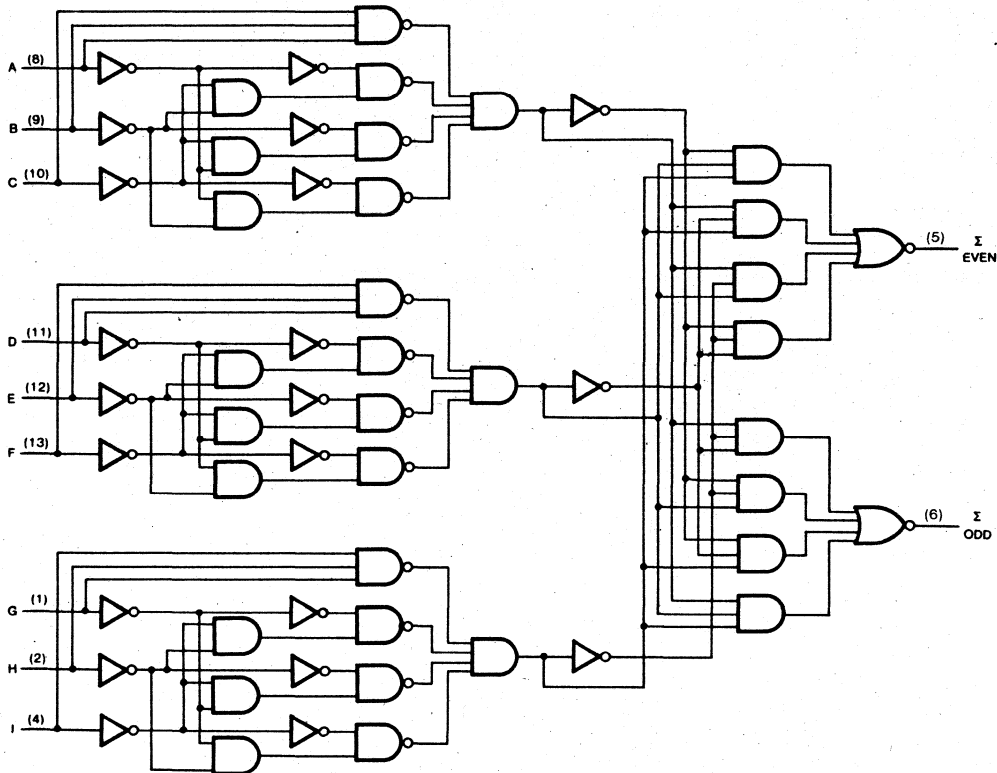


FUNCTION TABLE

| NUMBER OF INPUTS A THRU I THAT ARE HIGH | OUTPUTS | |
|--|---------------|--------------|
| | Σ EVEN | Σ ODD |
| 0, 2, 4, 6, 8 | H | L |
| 1, 3, 4, 5, 9 | L | H |



LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{STG} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to $+85^\circ\text{C}$
 KS54HCTLS: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS (V_{CC}=5V±10% Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | T _a = 25°C | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|------------------|---|------------------------|------------------------------|---------------------------------|----------------------------------|------|
| | | | Typ | Guaranteed Limits | T _a = -40°C to +85°C | T _a = -55°C to +125°C | |
| Minimum High-Level Input Voltage | V _{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V _{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V _{OH} | V _{IN} =V _{IH} or V _{IL} I _O =-20μA I _O =-6mA | V _{CC} 4.2 | V _{CC} -0.1 3.98 | V _{CC} -0.1 3.84 | V _{CC} -0.1 3.7 | V |
| Maximum Low-Level Output Voltage | V _{OL} | V _{IN} =V _{IH} or V _{IL} I _O =20μA I _O =12mA I _O =24mA | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I _{IN} | V _{IN} =V _{CC} or GND | | ±0.1 | ±1.0 | ±1.0 | μA |
| Maximum Quiescent Supply Current | I _{CC} | V _{IN} =V _{CC} or GND I _{OUT} =0μA | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI _{CC} | per input pin V _I =2.4V other inputs: at V _{CC} or GND I _{OUT} =0μA | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r, t_f ≤ 6 ns), HCTLS280

| Characteristic | Symbol | Conditions† | T _a = 25°C | | KS74HCTLS | KS54HCTLS | Unit |
|---|------------------|-----------------------|-----------------------|-------------------|---------------------------------|----------------------------------|------|
| | | | Typ | Guaranteed Limits | T _a = -40°C to +85°C | T _a = -55°C to +125°C | |
| Maximum Propagation Delay, Any input to Σ Even | PLH | C _L =50pF | 30 | 40 | 50 | 60 | ns |
| | | C _L =150pF | 33 | 47 | 59 | 71 | |
| | t _{PHL} | C _L =50pF | 30 | 40 | 50 | 60 | |
| | | C _L =150pF | 33 | 47 | 59 | 71 | |
| Maximum Propagation Delay, Any input to ΣOdd | t _{PLH} | C _L =50pF | 30 | 40 | 50 | 60 | ns |
| | | C _L =150pF | 33 | 47 | 59 | 71 | |
| | t _{PHL} | C _L =50pF | 30 | 40 | 50 | 60 | |
| | | C _L =150pF | 33 | 47 | 59 | 71 | |
| Minimum Input Capacitance | C _{IN} | | 5 | | | pF | |
| Power Dissipation Capacitance* | C _{PD} | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: P_D=C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

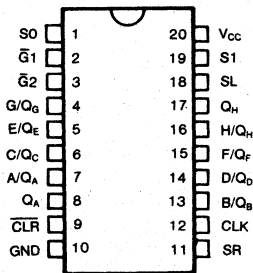


Objective Specifications

FEATURES

- Multiplexed I/O ports provides improved bit density
- Four modes of operation: hold (store), shift, shift left, and load data
- Operates with outputs enabled or at high impedance
- Can be cascaded for N-bit word lengths
- Direct overriding clear
- Application:
Stacked or push-down registers, buffer storage, and accumulator registers
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with drive current
($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



DESCRIPTION

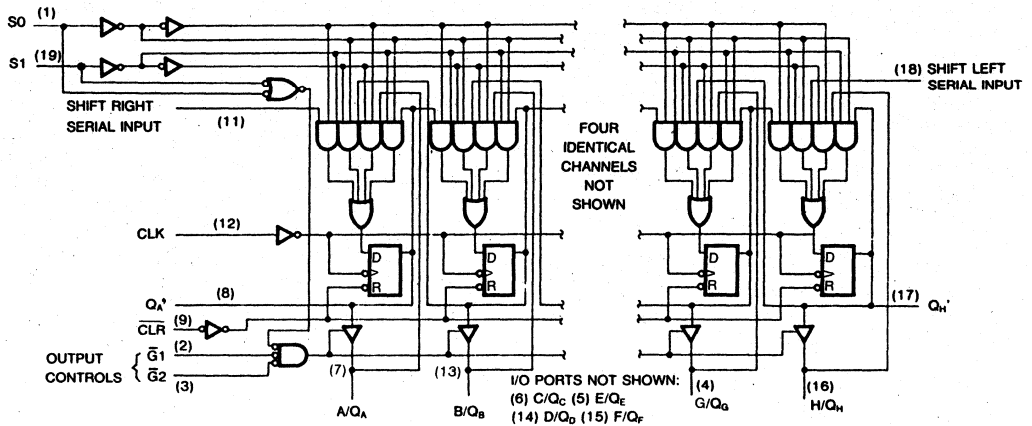
These eight-bit universal registers feature multiplexed I/O ports to achieve full eight-bit data handling. Two function-select inputs and two output-control inputs can be used to choose the modes of operation listed in the function table.

Synchronous parallel loading is accomplished by taking both function-select lines S0 and S1 high. This places the three-state outputs in a high-impedance state and permits data that is applied on the I/O ports to be clocked into the register. Reading out of the register can be accomplished while the outputs are enabled in any mode. Clearing occurs asynchronously when CLR is low. Pulling either of the output controls, G₁ or G₂, high disables the outputs but this has no effect on clearing, shifting, or storage of data.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{cc} and ground.

LOGIC DIAGRAM



FUNCTION TABLE

| Mode | Inputs | | | | | | | I/O Ports | | | | | | | | Outputs | | |
|-------------|--------|----|----|---|---|-----|----|-----------|------------------|------------------|------------------|------------------|------------------|------------------|------------------|------------------|------------------|------------------|
| | CLR | S1 | S0 | Output Control G ₁ G ₂ | | CLK | SL | SR | A/Q _A | B/Q _B | C/Q _C | D/Q _D | E/Q _E | F/Q _F | G/Q _G | H/Q _H | Q _A ' | Q _H ' |
| Clear | L | X | L | L | L | X | X | X | L | L | L | L | L | L | L | L | L | L |
| | L | L | X | L | L | X | X | X | L | L | L | L | L | L | L | L | L | L |
| | L | H | H | X | X | X | X | X | X | X | X | X | X | X | X | X | X | X |
| Hold | H | L | L | L | L | X | X | X | Q _{A0} | Q _{B0} | Q _{C0} | Q _{D0} | Q _{E0} | Q _{F0} | Q _{G0} | Q _{H0} | Q _{A0} | Q _{H0} |
| | H | X | X | L | L | L | X | X | Q _{A0} | Q _{B0} | Q _{C0} | Q _{D0} | Q _{E0} | Q _{F0} | Q _{G0} | Q _{H0} | Q _{A0} | Q _{H0} |
| Shift Right | H | L | H | L | L | ↑ | X | H | H | Q _{An} | Q _{Bn} | Q _{Cn} | Q _{Dn} | Q _{En} | Q _{Fn} | Q _{Gn} | H | Q _{Gn} |
| | H | L | H | L | L | ↑ | X | L | L | Q _{An} | Q _{Bn} | Q _{Cn} | Q _{Dn} | Q _{En} | Q _{Fn} | Q _{Gn} | L | Q _{Gn} |
| Shift Left | H | H | L | L | L | ↑ | H | X | Q _{Bn} | Q _{Cn} | Q _{Dn} | Q _{En} | Q _{Fn} | Q _{Gn} | Q _{Hn} | H | Q _{Bn} | H |
| | H | H | L | L | L | ↑ | L | X | Q _{Bn} | Q _{Cn} | Q _{Dn} | Q _{En} | Q _{Fn} | Q _{Gn} | Q _{Hn} | L | Q _{Bn} | L |
| Load | H | H | H | X | X | ↑ | X | X | a | b | c | d | e | f | g | h | a | h |

When one or both output controls are high the eight input/output terminals are disabled to the high-impedance state; however, sequential operation or clearing of the register is not affected.

Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} -0.5V to +7V
- DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
- DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
- Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
- Continuous Current Through
 V_{CC} or GND pins ± 250 mA
- Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
- Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

- † Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
- Operating Temperature
 Range KS74HCTLS: -40°C to $+85^\circ\text{C}$
 KS54HCTLS: -55°C to $+125^\circ\text{C}$
- Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|---|--------------------------|-------------------|--------------|--|---------------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ Q'_A and Q'_H outputs: $I_O=-4\text{mA}$ Q_A thru Q_H outputs: $I_O=-6\text{mA}$ | V_{CC} | $V_{CC}-0.1$ | $V_{CC}-0.1$ | $V_{CC}-0.1$ | V |
| | | | 4.2 | 3.98 | 3.84 | 3.7 | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ Q'_A and Q'_H outputs: $I_O=4\text{mA}$ $I_O=8\text{mA}$ Q_A thru Q_H outputs: $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 | 0.1 | 0.1 | V |
| | | | | 0.26 0.39 | 0.33 0.5 | 0.4 0.4 | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IN} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS299

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit | |
|---|-------------------|--|--|-------------------|--|---|------|----|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Guaranteed Limits | | | | |
| Maximum Clock Frequency | f_{max} | | 35 | 25 | 20 | 18 | MHz | |
| Maximum Propagation Delay, CLK to Q'_A or Q'_H | t_{PLH} | $C_L = 50\text{pF}$ | 26 | 35 | 4 | 53 | ns | |
| | t_{PHL} | | 26 | 35 | 44 | 53 | | |
| Maximum Propagation Delay, CLR to Q'_A or Q'_H | t_{PHL} | | | 30 | 40 | 50 | 60 | ns |
| Maximum Propagation Delay, CLK to Q_A thru Q_H | t_{PLH} | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | ns | |
| | | $C_L = 50\text{pF}$ | 30 | 39 | 49 | 59 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | | |
| | | $C_L = 150\text{pF}$ | 30 | 39 | 49 | 59 | | |
| Maximum Propagation Delay, CLR to Q_A thru Q_H | t_{PHL} | $C_L = 50\text{pF}$ | 30 | 40 | 50 | 60 | ns | |
| | | $C_L = 150\text{pF}$ | 36 | 47 | 59 | 71 | | |
| Maximum Output Enable Time, \bar{G}_1, \bar{G}_2 , to Q_A thru Q_H | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 20 | 26 | 33 | 39 | ns |
| | | | $C_L = 150\text{pF}$ | 26 | 33 | 42 | 50 | |
| | t_{PZL} | | $C_L = 50\text{pF}$ | 20 | 26 | 33 | 39 | |
| | | | $C_L = 150\text{pF}$ | 26 | 33 | 42 | 50 | |
| Maximum Output Disable Time, \bar{G}_1, \bar{G}_2 to Q_A thru Q_H | t_{PHZ} | $R_L = 1\text{k}\Omega$ $C_L = 50\text{pF}$ | 13 | 17 | 21 | 26 | ns | |
| | t_{PLZ} | | 13 | 17 | 21 | 26 | | |
| Minimum Pulse Width | CLK High or Low | t_w | 10 | 13 | 17 | 20 | ns | |
| | CLR Low | | 10 | 13 | 17 | 20 | | |
| Minimum Setup time before CLK† | S0 and S1 | t_{su} | 13 | 17 | 21 | 25 | ns | |
| | High-Level Inputs | | 10 | 13 | 17 | 20 | | |
| | High-Level Inputs | | 10 | 13 | 17 | 20 | | |
| | CLR Inactive | | 10 | 13 | 17 | 20 | | |
| Minimum Hold Time after CLK† | S0 and S1 | t_h | 5 | 7 | 8 | 10 | ns | |
| | All Inputs | | -3 | 0 | 0 | 0 | | |
| Maximum Input Capacitance | C_{IN} | | | 5 | | | pF | |
| Maximum Output Capacitance | C_{OUT} | Output Disabled | | 10 | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

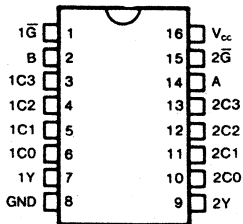
† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Inverting Version of '153
- Permits Multiplexing from N Lines to 1 Line
- Performs Parallel-to-Serial Conversion
- Strobe (Enable) Line Provided for Cascading (N Lines to n Lines)
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



FUNCTION TABLE

| SELECT | | DATA INPUTS | | | | STROBE | OUTPUT |
|--------|---|-------------|----|----|----|-----------|--------|
| B | A | C0 | C1 | C2 | C3 | \bar{G} | Y |
| X | X | X | X | X | X | H | H |
| L | L | L | X | X | X | L | H |
| L | L | H | X | X | X | L | L |
| L | H | X | L | X | X | L | H |
| L | H | X | H | X | X | L | L |
| H | L | X | X | L | X | L | H |
| H | L | X | X | H | X | L | L |
| H | H | X | X | X | L | L | H |
| H | H | X | X | X | H | L | L |

Select inputs A and B are common to both sections.

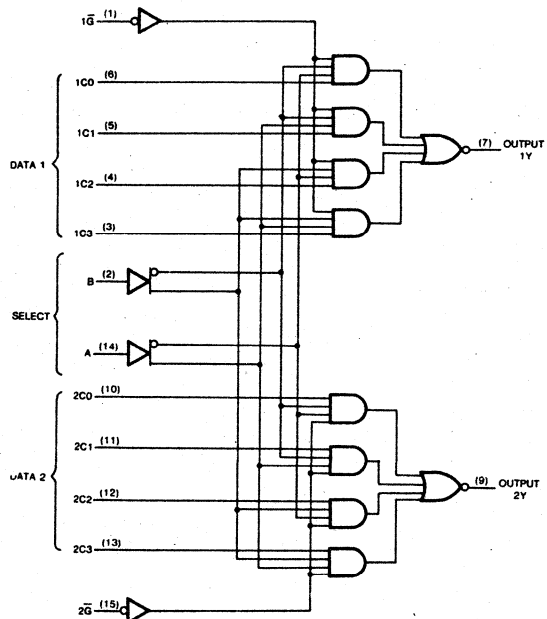
DESCRIPTION

Each of these data selectors/multiplexers contains inverters and drivers to supply fully complementary binary decoding data selection to the AND-OR-invert gates. Separate strobe inputs (\bar{G}) are provided for each of the two four-line sections.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} ... -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature

Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C

Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|--|-----------------------|---|--|---------------|
| | | | Typ | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | | | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS352

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit |
|---|-----------|----------------------|--|----|--|---|------|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Propagation Delay, A or B to Y | t_{PLH} | $C_L = 50\text{pF}$ | 23 | 30 | 38 | 45 | ns |
| | | $C_L = 150\text{pF}$ | 26 | 37 | 47 | 56 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 23 | 30 | 38 | 45 | |
| | | $C_L = 150\text{pF}$ | 26 | 37 | 47 | 56 | |
| Maximum Propagation Delay, Data (Any C) to Y | t_{PLH} | $C_L = 50\text{pF}$ | 19 | 26 | 32 | 39 | ns |
| | | $C_L = 150\text{pF}$ | 21 | 33 | 41 | 50 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 19 | 26 | 32 | 39 | |
| | | $C_L = 150\text{pF}$ | 21 | 33 | 41 | 50 | |
| Maximum Propagation Delay, G to Y | t_{PLH} | $C_L = 50\text{pF}$ | 19 | 26 | 32 | 39 | ns |
| | | $C_L = 150\text{pF}$ | 21 | 33 | 41 | 50 | |
| | | | 19 | 26 | 32 | 39 | |
| | | | 21 | 33 | 41 | 50 | |
| Maximum Input Capacitance | C_{IN} | | | 5 | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Inverting Version of '253
- Permits Multiplexing from N lines to 1 line
- Performs Parallel-to-Serial Conversion
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

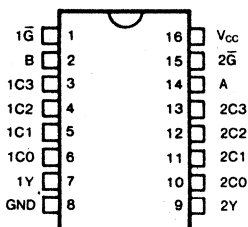
Each of these data selectors/multiplexers contains inverters and drivers to supply full binary decoding data selection to the AND-OR-invert gates. Separate strobe inputs (\bar{G}) are provided for each of the two four-line sections.

The three-state outputs can interface with and drive data lines of bus-organized systems. With all but one of the common outputs disabled (at a high-impedance state) the low-impedance of the single enabled output will drive the bus line to a high or low logic level. Each output has its own strobe (\bar{G}). The output is disabled when its strobe is high.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

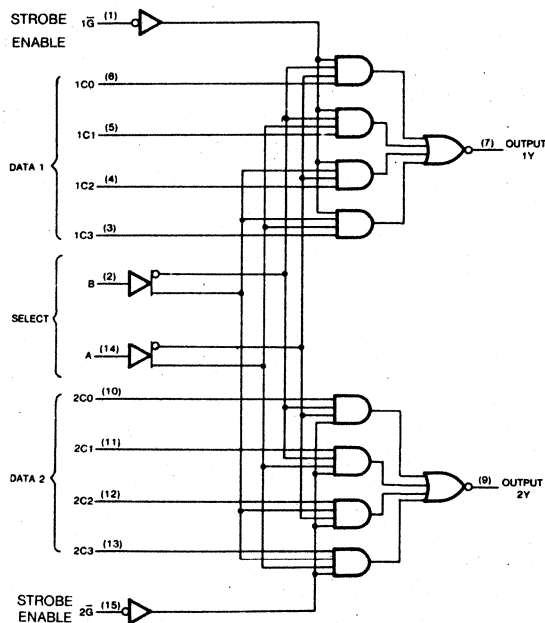


FUNCTION TABLE

| SELECT | | DATA INPUTS | | | | OUTPUT CONTROL | OUTPUT |
|--------|---|-------------|----|----|----|----------------|--------|
| B | A | C0 | C1 | C2 | C3 | \bar{G} | Y |
| X | X | X | X | X | X | H | Z |
| L | L | L | X | X | X | L | H |
| L | L | H | X | X | X | L | L |
| L | H | X | L | X | X | L | H |
| L | H | X | H | X | X | L | L |
| H | L | X | X | L | X | L | H |
| H | L | X | X | H | X | L | L |
| H | H | X | X | X | L | L | H |
| H | H | X | X | X | H | L | L |

Select inputs A and B are common to both sections.

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
Continuous Current Through
 V_{CC} or GND pins ± 250 mA
Storage Temperature Range, T_{stg} -65°C to +150°C
Power Dissipation Per Package, P_d [†] 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
Operating Temperature
Range KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C

Input Rise & Fall Times, t_r , t_f Max 500 ns
* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|------------------------|--------------------------------------|---------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ C$ to $+85^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -6mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 12mA$ $I_O = 24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS353

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit | |
|---|-----------|-------------------------|--|-----------|--|---|------|----|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | | Guaranteed Limits | | | |
| Maximum Propagation Delay, A or B to Any Y | t_{PLH} | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | ns | |
| | | $C_L = 150\text{pF}$ | 27 | 39 | 49 | 59 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | ns | |
| | | $C_L = 150\text{pF}$ | 27 | 39 | 49 | 59 | | |
| Maximum Propagation Delay, Data (any C) to any Y | t_{PLH} | $C_L = 50\text{pF}$ | 15 | 20 | 25 | 30 | ns | |
| | | $C_L = 150\text{pF}$ | 18 | 27 | 35 | 42 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 15 | 20 | 26 | 31 | ns | |
| | | $C_L = 150\text{pF}$ | 18 | 27 | 35 | 42 | | |
| Maximum Output Enable Time, \bar{G} to Y | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 17 | 23 | 29 | 35 | ns |
| | | | $C_L = 150\text{pF}$ | 23 | 30 | 38 | 46 | |
| | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 17 | 23 | 29 | 35 | ns |
| | | | $C_L = 150\text{pF}$ | 23 | 30 | 38 | 46 | |
| Maximum Output Disable Time, \bar{G} to Y | t_{PHZ} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 20 | 27 | 34 | 41 | ns |
| | | | | t_{PLZ} | 20 | 27 | 34 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF | |
| Maximum Output Capacitance | C_{OUT} | | 10 | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.
† For AC switching test circuits and timing waveforms see section 2.

KS54HCTL5 365A/366A KS74HCTL5 367A/368A

Hex Bus-Drivers with 3-State Outputs

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current-
($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTL5: -40°C to $+85^{\circ}\text{C}$
KS54HCTL5: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

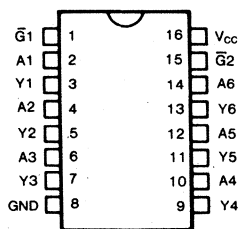
These high-speed Hex bus drivers are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus oriented receivers and transmitters.

The '365 and '366 have two output enables ($\bar{G}1$ and $\bar{G}2$) NOR'ed together to control all six gates. The '367 and '368 have two output enables which are configured so that one enable ($\bar{G}1$) controls four gates and the other ($\bar{G}2$) controls the remaining two gates. The '366 and '368 have inverting data paths. The '365 and '367 have noninverting data paths.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



FUNCTION TABLES

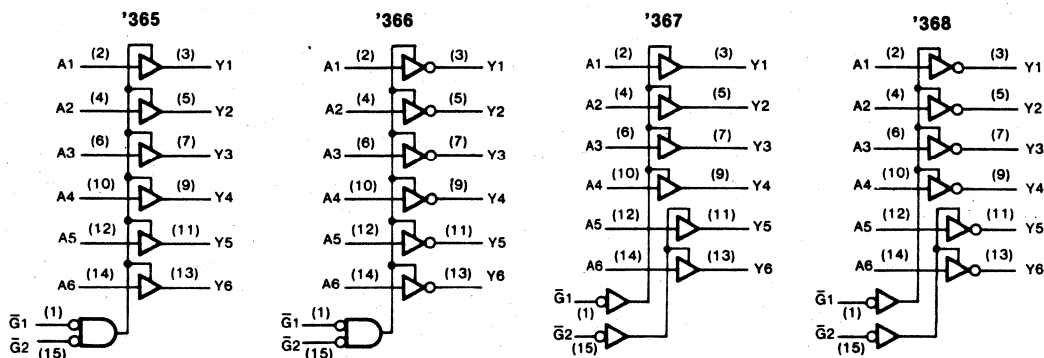
'365 and '366

| Inputs | | Y Outputs | | |
|------------|------------|-----------|------|------|
| $\bar{G}1$ | $\bar{G}2$ | A | '365 | '366 |
| L | L | L | L | H |
| L | L | H | H | L |
| H | X | X | Z | Z |
| X | H | X | Z | Z |

'367 and '368

| Inputs | | Y Outputs | |
|-------------------------|---|-----------|------|
| $\bar{G}1$ & $\bar{G}2$ | A | '367 | '368 |
| L | L | L | H |
| L | H | H | L |
| H | X | Z | Z |

LOGIC DIAGRAMS



KS54HCTLS **365A/366A** KS74HCTLS **367A/368A**

Hex Bus-Drivers with 3-State Outputs

Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} -0.5V to +7V
- DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
- DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
- Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
- Continuous Current Through
 V_{CC} or GND pins ± 250 mA
- Storage Temperature Range, T_{stg} ... -65°C to +150°C
- Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

- † Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
- Operating Temperature
Range
KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C
- Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|------------------------|---|---------------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS365A, HCTLS367A

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit | |
|--|-----------|-------------------------|--|----|--|---|------|----|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | | Guaranteed Limits | | | |
| Maximum Propagation Delay, A to Y | t_{PLH} | $C_L = 50\text{pF}$ | 14 | 19 | 24 | 28 | ns | |
| | | $C_L = 150\text{pF}$ | 17 | 26 | 33 | 39 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 14 | 19 | 24 | 28 | | |
| | | $C_L = 150\text{pF}$ | 17 | 26 | 33 | 39 | | |
| Maximum Output Enable Time, \bar{G} to Y | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 26 | 35 | 44 | 52 | ns |
| | | | $C_L = 150\text{pF}$ | 32 | 42 | 53 | 63 | |
| | t_{PZL} | $C_L = 50\text{pF}$ | 26 | 35 | 44 | 52 | | |
| | | $C_L = 150\text{pF}$ | 32 | 42 | 53 | 63 | | |
| Maximum Output Disable Time, \bar{G} to Y | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 26 | 35 | 44 | 52 | ns | |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 26 | 35 | 44 | 52 | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF | |
| Maximum Output Capacitance | C_{OUT} | Output disabled | 10 | | | | pF | |
| Power Dissipation Capacitance* (per driver) | C_{PD} | $\bar{G} = V_{CC}$ | 5 | | | | pF | |
| | | $\bar{G} = \text{GND}$ | 30 | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS366A, HCTLS368A

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit | |
|--|-----------|-------------------------|--|----|--|---|------|----|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | | Guaranteed Limits | | | |
| Maximum Propagation Delay, A to Y | t_{PLH} | $C_L = 50\text{pF}$ | 13 | 17 | 21 | 25 | ns | |
| | | $C_L = 150\text{pF}$ | 16 | 24 | 30 | 36 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 13 | 17 | 21 | 25 | | |
| | | $C_L = 150\text{pF}$ | 16 | 24 | 30 | 36 | | |
| Maximum Output Enable Time, \bar{G} to Y | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 26 | 35 | 44 | 52 | ns |
| | | | $C_L = 150\text{pF}$ | 32 | 42 | 53 | 63 | |
| | t_{PZL} | $C_L = 50\text{pF}$ | 26 | 35 | 44 | 52 | | |
| | | $C_L = 150\text{pF}$ | 32 | 42 | 53 | 63 | | |
| Maximum Output Disable Time, \bar{G} to Y | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 26 | 35 | 44 | 52 | ns | |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 26 | 35 | 44 | 52 | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF | |
| Maximum Output Capacitance | C_{OUT} | Output disabled | 10 | | | | pF | |
| Power Dissipation Capacitance* (per driver) | C_{PD} | $\bar{G} = V_{CC}$ | 5 | | | | pF | |
| | | $\bar{G} = \text{GND}$ | 30 | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

5

FEATURES

- 8 latches in a single package
- Full parallel access for loading
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
 KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

The '373 consists of 8 high-speed D-type latches coupled to 3-state output buffers with high drive current capability. It can be used in implementing buffer registers, I/O ports, bidirectional bus drivers and working registers.

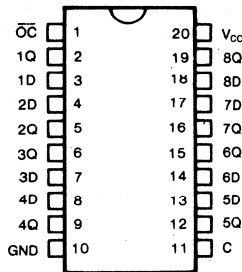
The latches are transparent: when the enable (C) is high, the Q outputs follow the data (D) inputs. When the enable is low, the outputs latch at the levels that were set up at the D inputs.

The output buffers are controlled by a common signal (\overline{OC}) which places the outputs at a high-impedance state when it is taken high. The \overline{OC} signal does not affect the internal operations of the latches. Old data can be retained or new data can be entered while outputs are off.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

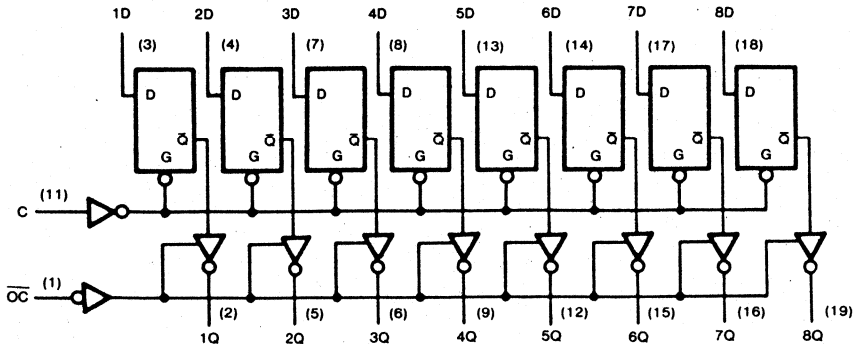


FUNCTION TABLE

(Each Latch)

| Inputs | | | Output |
|-----------------|----------|---|--------|
| \overline{OC} | Enable C | D | Q |
| L | H | H | H |
| L | H | L | L |
| L | L | X | Q_0 |
| H | X | X | Z |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d [†] 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_A = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|---|--|-----------------------|---------|
| | | | Typ | KS74HCTLS $T_A = -40^\circ C$ to $+85^\circ C$ | KS54HCTLS $T_A = -55^\circ C$ to $+125^\circ C$ | | |
| Guaranteed Limits | | | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -6mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 12mA$ $I_O = 24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_Z=2.4V$ Other Inputs: At V_{CC} or GND $I_O=0$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS373

| Characteristic | Symbol | Conditions [†] | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit | |
|--|-----------|---|--|----|--|---|------|----|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | | Guaranteed Limits | | | |
| Maximum Propagation Delay, D to Q | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 14 | 18 | 23 | 27 | ns | |
| | | | 17 | 25 | 32 | 38 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 14 | 18 | 23 | 27 | ns | |
| | | | 17 | 25 | 32 | 38 | | |
| Maximum Propagation Delay, C to any Q | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 22 | 30 | 37 | 45 | ns | |
| | | | 25 | 37 | 46 | 56 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 22 | 30 | 37 | 45 | ns | |
| | | | 25 | 37 | 46 | 56 | | |
| Maximum Output Enable Time, \overline{OC} to any Q | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | ns |
| | | | $C_L = 150\text{pF}$ | 30 | 39 | 49 | 59 | |
| | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | ns |
| | | | $C_L = 150\text{pF}$ | 30 | 39 | 49 | 59 | |
| Maximum Output Disable Time, \overline{OC} to any Q | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 19 | 25 | 31 | 37 | ns | |
| | | | $C_L = 50\text{pF}$ | 19 | 25 | 31 | | 37 |
| Minimum Pulse Width, C High | t_w | | 6 | 10 | 12 | 15 | ns | |
| Minimum Setup Time, D before C \downarrow | t_{su} | | 2 | 3 | 4 | 5 | ns | |
| Minimum Hold Time, D after C \downarrow | t_h | | 6 | 10 | 12 | 15 | ns | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF | |
| Maximum Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF | |
| Power Dissipation Capacitance* (per latch) | C_{PD} | $\overline{OC} = V_{CC}$ | 5 | | | | pF | |
| | | $\overline{OC} = \text{GND}$ | 30 | | | | | |

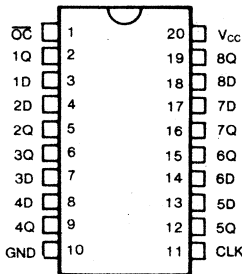
* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



DESCRIPTION

The '374 consists of 8 high-speed D-type edge-triggered flip-flops coupled to 3-state output buffers with high drive current capability. It can be used in implementing buffer registers, I/O ports, bidirectional bus driver and working registers.

The flip-flops are edge-triggered on the positive transition of the clock. The Q outputs are set to the logic levels that were set up at the D inputs.

The output buffers are controlled by a common signal (\overline{OC}) which places the outputs at a high-impedance state when it is taken high. The \overline{OC} signal does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while outputs are off.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

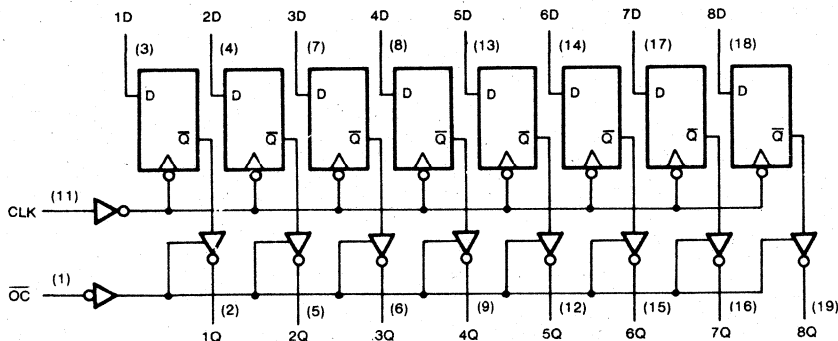
All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLE

(Each Flip-Flop)

| Inputs | | | Output |
|-----------------|-----|---|--------|
| \overline{OC} | CLK | D | Q |
| L | ↑ | H | H |
| L | ↑ | L | L |
| L | L | X | Q_0 |
| H | X | X | Z |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | | Unit |
|--------------------------------------|-----------------|--|--------------------------------------|------------------------|---------------------------------------|-----------------------|---------|
| | | | Typ | Guaranteed Limits | | | |
| | | | KS74HCTLS | | KS54HCTLS | | |
| | | | $T_a = -40^\circ C$ to $+85^\circ C$ | | $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -6mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 12mA$ $I_O = 24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS374

| Characteristic | Symbol | Conditions† | T _a = 25°C V _{CC} = 5.0V | | KS74HCTLS T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | | KS54HCTLS T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | Unit | | |
|--|------------------|--------------------------|---|----|--|----|---|----|------|----|--|
| | | | Typ | | Guaranteed Limits | | | | | | |
| | | | | | | | | | | | |
| Maximum Operating Frequency | f _{max} | C _L = 50pF | 45 | 35 | 30 | | 25 | | MHz | | |
| Maximum Propagation Delay, CLK to any Q | t _{PLH} | C _L = 50pF | 21 | 28 | 35 | | 42 | | ns | | |
| | | C _L = 150pF | 24 | 35 | 44 | | 53 | | | | |
| | t _{PHL} | C _L = 50pF | 21 | 28 | 35 | | 42 | | ns | | |
| | | C _L = 150pF | 24 | 35 | 44 | | 53 | | | | |
| Maximum Output Disable Time, \overline{OC} to any Q | t _{PZH} | R _L = 1kΩ | C _L = 50pF | 21 | 28 | 35 | | 42 | | ns | |
| | | | C _L = 150pF | 27 | 35 | 44 | | 53 | | | |
| | t _{PZL} | C _L = 50pF | 21 | 28 | 35 | | 42 | | | | |
| | | | C _L = 150pF | 27 | 35 | 44 | | 53 | | | |
| Maximum Output Disable Time, \overline{OC} to any Q | t _{PHZ} | R _L = 1kΩ | 19 | 25 | 31 | | 37 | | ns | | |
| | t _{PLZ} | C _L = 50pF | 19 | 25 | 31 | | 37 | | | | |
| Minimum Pulse Width, CLK High or Low | t _w | | 7 | 10 | 12 | | 15 | | ns | | |
| Minimum Setup Time, D before CLK† | t _{su} | | 10 | 13 | 17 | | 20 | | ns | | |
| Minimum Hold Time, D after CLK† | t _h | | -3 | 0 | 0 | | 0 | | ns | | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | | | pF | | |
| Maximum Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | | | pF | | |
| Power Dissipation Capacitance* (per stage) | C _{PD} | $\overline{OC} = V_{CC}$ | 5 | | | | | | pF | | |
| | | $\overline{OC} = GND$ | 30 | | | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

5

Preliminary Specifications

FEATURES

- Can be used for implementing
 - Buffer/Storage Registers
 - Shift Registers
 - Pattern Generators
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

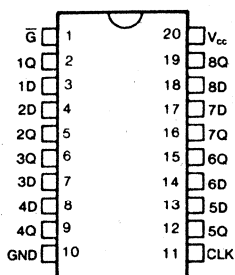
The '377 contains eight positive-edge-triggered D-type flip-flops with an enable input. This part is similar to '273 but features a latched clock enable (\bar{G}) instead of a common clear.

Information at the D inputs meeting the setup time requirements is transferred to the Q outputs on the positive-going edge of the clock pulse if \bar{G} is low. Clock triggering occurs at a particular voltage level and is not directly related to the transition time of the positive-going pulse. When the clock input is at either the high or low level, the D input signal has no effect at the output. The circuits are designed to prevent false clocking by transitions at the \bar{G} input.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

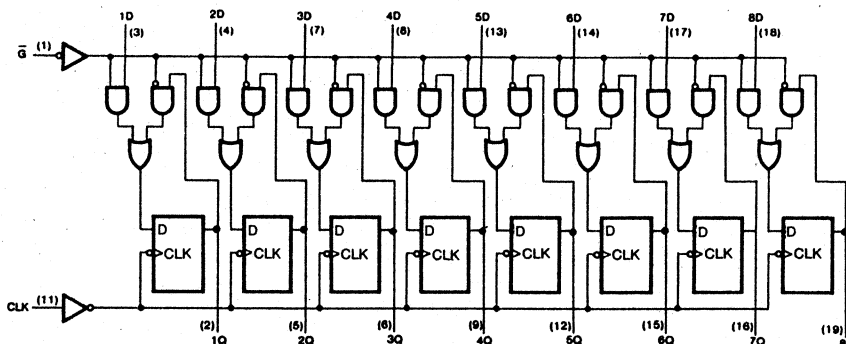


FUNCTION TABLE

(EACH FLIP-FLOP)

| INPUTS | | | OUTPUT |
|-----------|-----|------|--------|
| \bar{G} | CLK | DATA | Q |
| H | X | X | Q_0 |
| L | ↑ | H | H |
| L | ↑ | L | L |
| X | L | X | Q_0 |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
Continuous Current Through
 V_{CC} or GND pins ± 125 mA
Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN}, V_{OUT} . . . 0V to V_{CC}
Operating Temperature
Range KS74HCTLS: $-40^\circ C$ to $+85^\circ C$
KS54HCTLS: $-55^\circ C$ to $+125^\circ C$
Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|--------------------------------------|---------------------------------------|---------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -4mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 4mA$ $I_O = 8mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS377

| Characteristic | Symbol | Conditions† | T _a = 25°C V _{CC} = 5.0V | | KS74HCTLS | KS54HCTLS | Unit |
|--|-----------------------|-----------------------|---|-------------------|---|--|------|
| | | | | | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | |
| | | | Typ | Guaranteed Limits | | | |
| Maximum Clock Frequency | f _{max} | | 45 | 35 | 30 | 25 | MHz |
| Maximum Propagation Delay, CLK to Any Q | t _{PLH} | C _L = 50pF | 18 | 27 | 32 | 38 | ns |
| | t _{PHL} | | 18 | 27 | 32 | 38 | |
| Minimum Pulse Width | \bar{G} Low | t _w | 12 | 16 | 20 | 25 | ns |
| | CLK high or Low | | 12 | 16 | 20 | 25 | |
| Minimum Setup Time before CLK† | Data | t _{su} | 6 | 10 | 15 | 20 | ns |
| | \bar{G} high or LOW | | 15 | 20 | 25 | 25 | |
| Minimum Hold Time, Data after CLK† | t _h | | -3 | 0 | 0 | 0 | ns |
| Maximum Input Capacitance | C _{iN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | | | | | | pF |

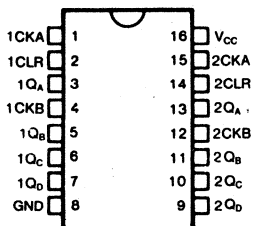
* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Individual clock for A and B flip-flops provide dual +2 and +5 counters
- Direct clear for each 4-bit counter
- Significant improvement in system density through reduced counter package count.
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $i_{OL} = 8 \text{ mA} @ V_{OL} = 0.5V$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



DESCRIPTION

These devices incorporate dual divide-by-two and divide-five counters, which can be used to implement cycle lengths equal to any whole and/or cumulative multiple of 2 and/or 5 up to divide-by-100. When connected as a bi-quinary counter, the separate divide-by-two circuit can be used to provide symmetry (a square wave) at the final output stage. The '390 incorporates dual divide-by-two and divide-by-five counters, which can be used to implement cycle lengths equal to any whole and/or cumulative multiples of 2 and/or 5 up to divide-by-100. When connected as a bi-quinary counter, the separate divide-by-two circuit can be used to provide symmetry (a square wave) at the final output stage. The '390 has parallel outputs from each counter stage so that any submultiple of the input count frequency is available for system-timing signals.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLES

BCD COUNT SEQUENCE
(Each Counter)
(See Note A)

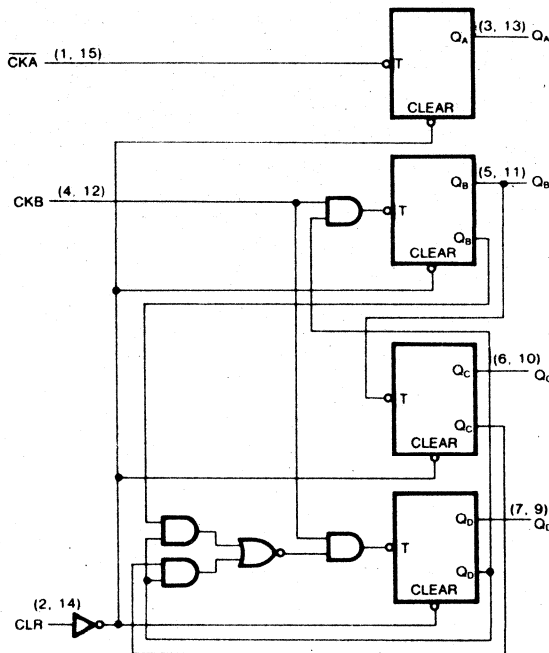
| COUNT | OUTPUT | | | |
|-------|----------------|----------------|----------------|----------------|
| | Q _D | Q _C | Q _B | Q _A |
| 0 | L | L | L | L |
| 1 | L | L | L | H |
| 2 | L | L | H | L |
| 3 | L | L | H | H |
| 4 | L | H | L | L |
| 5 | L | H | L | H |
| 6 | L | H | H | L |
| 7 | L | H | H | H |
| 8 | H | L | L | L |
| 9 | H | L | L | H |

BIQUINARY (5-2)
(Each Counter)
(See Note B)

| COUNT | OUTPUT | | | |
|-------|----------------|----------------|----------------|----------------|
| | Q _D | Q _C | Q _B | Q _A |
| 0 | L | L | L | L |
| 1 | L | L | L | H |
| 2 | L | L | H | L |
| 3 | L | L | H | H |
| 4 | L | H | L | L |
| 5 | H | L | L | L |
| 6 | H | L | L | H |
| 7 | H | L | H | L |
| 8 | H | L | H | H |
| 9 | H | H | L | L |

NOTES A. Output Q_A is connected to input CKB for BCD count.
B. Output Q_D is connected to input CKA for biquinary count.

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 * DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS (V_{CC}=5V±10% Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | T _a = 25°C | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|------------------|---|------------------------|------------------------------|------------------------------|-----------------------------|------|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V _{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V _{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V _{OH} | V _{IN} =V _{IH} or V _{IL} I _O =-20μA I _O =-4mA | V _{CC} 4.2 | V _{CC} -0.1 3.98 | V _{CC} -0.1 3.84 | V _{CC} -0.1 3.7 | V |
| Maximum Low-Level Output Voltage | V _{OL} | V _{IN} =V _{IH} or V _{IL} I _O =20μA I _O =4mA I _O =8mA | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I _{IN} | V _{IN} =V _{CC} or GND | | ±0.1 | ±1.0 | ±1.0 | μA |
| Maximum Quiescent Supply Current | I _{CC} | V _{IN} =V _{CC} or GND I _{OUT} =0μA | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI _{CC} | per input pin V _I =2.4V other Inputs: at V _{CC} or GND I _{OUT} =0μA | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r, t_f≤6 ns, HCTLS390)

| Characteristic | Symbol | Conditions† | T _a = 25°C | | KS74HCTLS | KS54HCTLS | Unit |
|---|------------------|----------------------|------------------------|----|---|--|------|
| | | | V _{CC} = 5.0V | | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Clock Frequency CKA to Q _A or CKB to Q _B | f _{max} | | 35 | 25 | 20 | 20 | MHz |
| Maximum Propagation Delay, CKA to Q _A | t _{PLH} | C _L =50pF | 15 | 20 | 25 | 30 | ns |
| | t _{PHL} | | 15 | 20 | 25 | 30 | |
| Maximum Propagation Delay, CKA to Q _C | t _{PLH} | | 36 | 48 | 60 | 72 | ns |
| | t _{PHL} | | 36 | 48 | 60 | 72 | |
| Maximum Propagation Delay, CKB to Q _B | t _{PLH} | | 16 | 21 | 26 | 31 | ns |
| | t _{PHL} | | 16 | 21 | 26 | 31 | |
| Maximum Propagation Delay, CKB to Q _C | t _{PLH} | | 24 | 32 | 40 | 48 | ns |
| | t _{PHL} | | 24 | 32 | 40 | 48 | |
| Maximum Propagation Delay, CKB to Q _D | t _{PLH} | | 16 | 21 | 26 | 31 | ns |
| | t _{PHL} | | 16 | 21 | 26 | 31 | |
| Maximum Propagation Delay, CLR to Any Q | t _{PHL} | | 24 | 32 | 40 | 48 | ns |
| Minimum Pulse Width CKA or CKB high or low CLR high | t _{su} | | 12 | 16 | 20 | 24 | ns |
| | | | 12 | 16 | 20 | 24 | |
| Minimum Setup Time, CLR inactive before CKA or CKB | t _{su} | | 15 | 20 | 25 | 30 | ns |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance | C _{PD} | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D=C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5 \text{ V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

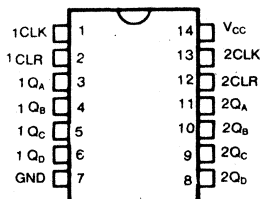
DESCRIPTION

The '393 consists of two independent 4-bit binary counters each with its own clear and clock inputs. N-bit binary counters can be implemented with each package providing the capability of divide-by-256. Parallel outputs from each counter stage provide any submultiple of the input count frequency for system timing signals.

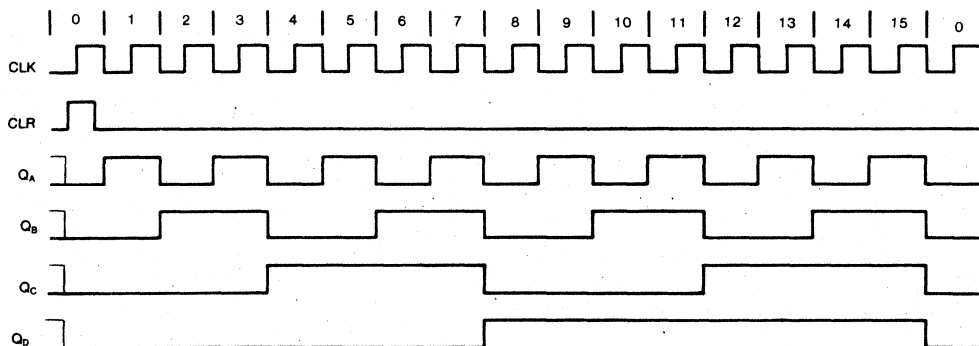
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

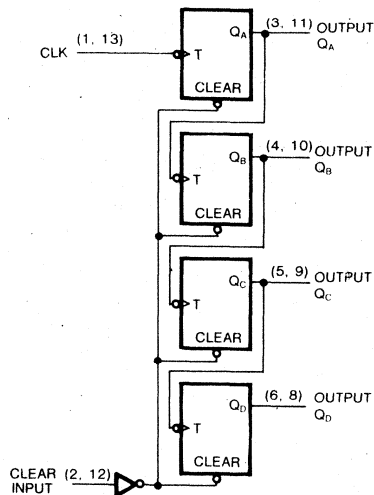
PIN CONFIGURATION



LOGIC TIMING WAVEFORMS



LOGIC DIAGRAMS



Absolute Maximum Ratings*

| | |
|--|---|
| Supply Voltage Range V_{CC} , | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74HCTLS: -40°C to $+85^\circ\text{C}$ KS54HCTLS: -55°C to $+125^\circ\text{C}$ |

Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | | KS54HCTLS | | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|--|---|-----------|---------------|------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-4\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | | mA | |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS393

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit |
|---|---------------------|---------------------|--|-------------------|--|---|------|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | Guaranteed Limits | | | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 40 | 30 | 25 | 20 | MHz |
| Maximum Propagation Delay, A to Q_A | t_{PLH} | | 15 | 20 | 25 | 30 | ns |
| | t_{PHL} | | 15 | 20 | 25 | 30 | |
| Maximum Propagation Delay, A to Q_B | t_{PLH} | | 26 | 35 | 44 | 53 | ns |
| | t_{PHL} | | 26 | 35 | 44 | 53 | |
| Maximum Propagation Delay, A to Q_C | t_{PLH} | | 34 | 45 | 56 | 67 | ns |
| | t_{PHL} | | 34 | 45 | 56 | 67 | |
| Maximum Propagation Delay, A to Q_D | t_{PLH} | | 45 | 60 | 75 | 90 | ns |
| | t_{PHL} | | 45 | 60 | 75 | 90 | |
| Maximum Propagation Delay, CLR to any Q | t_{PHL} | | 29 | 39 | 49 | 58 | ns |
| Minimum Pulse Width | A Input High or Low | t_w | 10 | 13 | 17 | 20 | ns |
| | CLR High | | 10 | 13 | 17 | 20 | |
| Minimum Hold Time, CLR Inactive before A | t_{su} | | 10 | 13 | 17 | 20 | ns |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per counter) | 40 | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.
 † For AC switching test circuits and timing waveforms see section 2.

Objective Specifications

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

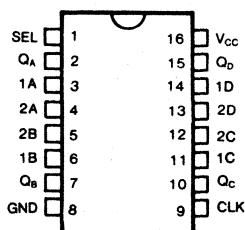
DESCRIPTION

These are high-speed quad 2-port registers. They are the logical equivalent of a quad 2-input multiplexer followed by a quad 4-bit edge-triggered register. A common select input (SEL) selects between two 4-bit input ports. The selected data is transferred to the output register on the low-to-high transition of the clock input.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

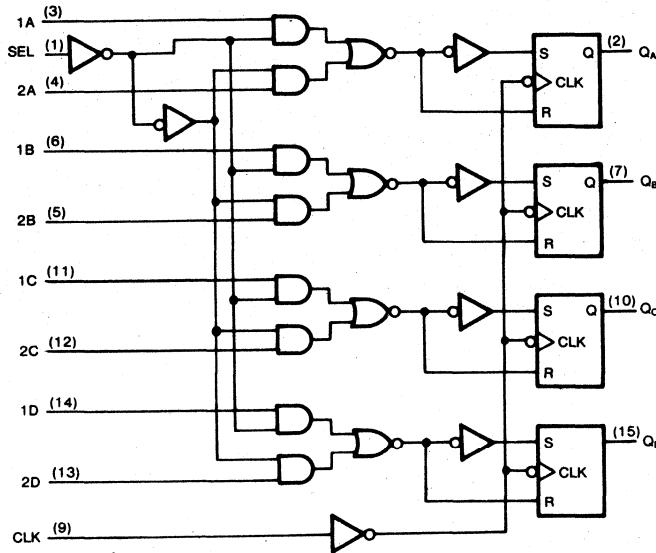


FUNCTION TABLE

| SEL | Inputs | | Output |
|-----|--------|--------|--------|
| | Port 1 | Port 2 | Q |
| l | l | X | L |
| l | h | X | H |
| h | X | l | L |
| h | X | h | H |

- l = Low Voltage Level one setup time prior to the low-to-high clock transition
h = High Voltage Level one setup time prior to the low-to-high clock transition

LOGIC DIAGRAM



Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} , -0.5V to +7V
- DC Input Diode Current, I_{IK}
 $(V_I < -0.5V \text{ or } V_I > V_{CC} + 0.5V)$ ± 20 mA
- DC Output Diode Current, I_{OK}
 $(V_O < -0.5V \text{ or } V_O > V_{CC} + 0.5V)$ ± 20 mA
- Continuous Output Current Per Pin, I_O
 $(-0.5V < V_O < V_{CC} + 0.5V)$ ± 35 mA
- Continuous Current Through
 V_{CC} or GND pins ± 125 mA
- Storage Temperature Range, T_{stg} -65°C to +150°C
- Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

- † Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN}, V_{OUT} . . . 0V to V_{CC}
- Operating Temperature
 Range
 KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
- Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|---|--------------------------|------------------------|--|-----------------------|---|---------------|------|
| | | | Typ | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | | mA | |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS399

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|---|-------------|---------------------|--|----|---|----|--|--|------|
| | | | Typ | | Guaranteed Limits | | | | |
| Propagation Delay, CLK to Q or \bar{Q} | t_{PLH} | $C_L = 50\text{pF}$ | 22 | 30 | 37 | 45 | ns | | |
| | t_{PHL} | | 22 | 30 | 37 | 45 | | | |
| Minimum Pulse Width, CLK High or Low | t_w | | 10 | 13 | 17 | 20 | ns | | |
| Minimum Setup Time before CLK† | Data | t_{su} | 10 | 13 | 17 | 20 | ns | | |
| | Word Select | | 10 | 13 | 17 | 20 | | | |
| Minimum Hold Time after CLK† | Data | t_h | -3 | 0 | 0 | 0 | ns | | |
| | Word Select | | -3 | 0 | 0 | 0 | | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF | | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

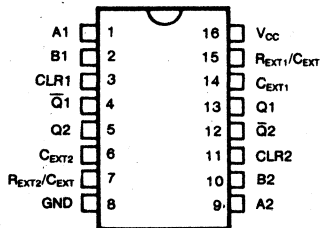
† For AC switching test circuits and timing waveforms see section 2.

Product Preview

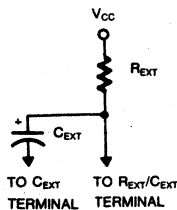
FEATURES

- Simple pulse width formula $T = RC$
- Wide pulse range: 400 ns to ∞ (typ)
- Part to part variation: $\pm 5\%$ (typ)
- Schmitt Trigger A & B Inputs allow infinite rise and fall times on these inputs
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA @ } V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^\circ\text{C}$
KS54HCTLS: -55°C to $+125^\circ\text{C}$

PIN CONFIGURATION



TIMING COMPONENT



DESCRIPTION

The '423 contains two retriggerable monostable multivibrators that feature both a negative (A) and a positive (B) transition triggered input, either or which can be used as an inhibit input. Also included is a clear input that when taken low resets the one shot. The '423 cannot be triggered from clear.

The '423A is retriggerable. That is, it may be triggered repeatedly while its outputs are generating a pulse and the pulse will be extended.

Pulse width stability over a wide range of temperature and supply is achieved using linear CMOS techniques. The output pulse equation is simply: $PW = (R_{EXT}) (C_{EXT})$; where PW is in seconds, R is in ohms, and C is in farads.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLE

| Inputs | | | Outputs | |
|--------|---|---|---------|-----------|
| Clear | A | B | Q | \bar{Q} |
| L | X | X | L | H |
| X | H | X | L | H |
| X | X | L | L | H |
| H | L | ↑ | | |
| H | ↓ | H | | |

KS54HCTLS **465/466** KS74HCTLS **467/468**

Octal Buffers and Line Drivers with 3-State Outputs

Preliminary Specifications

FEATURES

- Function, pin-out, speed and drive compatibility with 54174LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

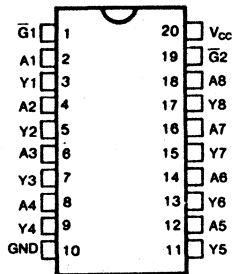
These high-speed octal buffers and drivers are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. The designer has the choice of inverting/noninverting outputs and various types of output controls.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

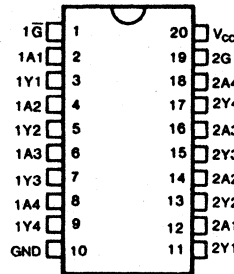
All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATIONS

'465 and '466

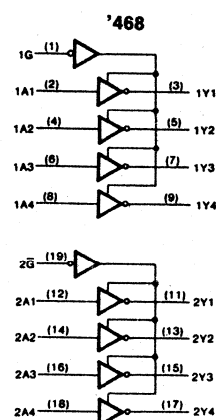
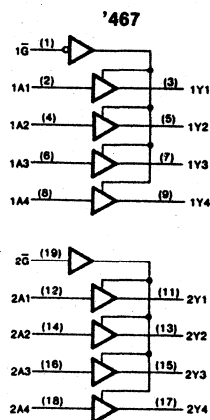
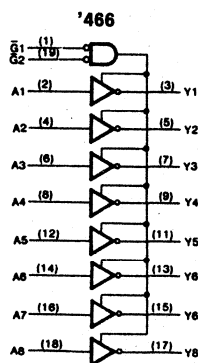
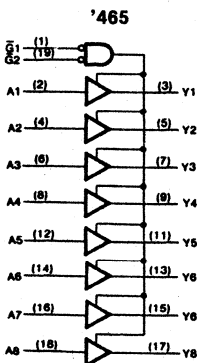


'467 and '468



5

LOGIC DIAGRAMS



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN}, V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|---|--|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS465, HCTLS466,
 HCTLS467, HCTLS468

| Characteristic | Symbol | Conditions | 54/74AHT | | KS74HCTLS | | 54HCTLS | | Unit |
|---|-----------|-------------------------|--|----|--|----|---|----|------|
| | | | $T_a = 25^\circ\text{C}$ $V_{CC} = 5\text{V}$ | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5\text{V} \pm 10\%$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | | Guaranteed Limits | | | | |
| Maximum Propagation Delay, A to Y | t_{PLH} | $C_L = 50\text{pF}$ | 11 | 15 | 19 | 22 | ns | | |
| | | $C_L = 150\text{pF}$ | 14 | 22 | 28 | 33 | | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 11 | 15 | 19 | 22 | ns | | |
| | | $C_L = 150\text{pF}$ | 14 | 22 | 28 | 33 | | | |
| Maximum Output Enable Time, Enable to Y | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | ns | |
| | | | $C_L = 150\text{pF}$ | 30 | 39 | 49 | 59 | | |
| | t_{PZL} | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | | | |
| | | $C_L = 150\text{pF}$ | 30 | 39 | 49 | 59 | | | |
| Maximum Output disable Time, Enable to Y | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 24 | 32 | 40 | 48 | ns | | |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | | | |
| Maximum Input Capacitance | C_{IN} | | 4 | | | | pF | | |
| Maximum Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF | | |
| Power Dissipation Capacitance* (per stage) | C_{PD} | Output Disabled | 5 | | | | pF | | |
| | | Output Enabled | 30 | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Compares two 8-bit words
- '518, '520 and '522 have 20KΩ Pull-up resistors on Q inputs

| TYPE | INPUT PULL-UP RESISTOR | OUTPUT FUNCTION AND CONFIGURATION |
|------|------------------------|--|
| '518 | Yes | P=Q open-drain |
| '519 | No | P=Q open-drain |
| '520 | Yes | $\overline{P}=\overline{Q}$ totem-pole |
| '521 | No | $\overline{P}=\overline{Q}$ totem-pole |
| '522 | Yes | $\overline{P}=\overline{Q}$ open-drain |

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

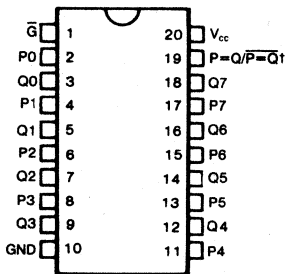
DESCRIPTION

These identity comparators perform comparisons on two eight-bit binary or BCD words. The '518 and '519 provide P=Q outputs, while the '520, '521, and '522 provide $\overline{P}=\overline{Q}$ outputs. The '518, '519, and '522 have open-drain outputs. The '518, '520, and '522 feature 20-kΩ inputs for analog or switch data.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

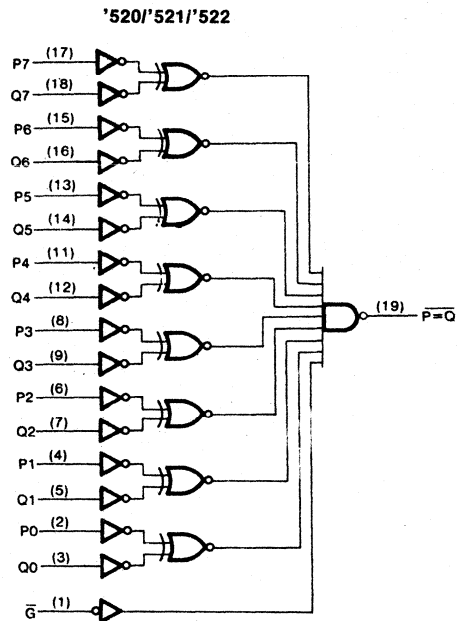
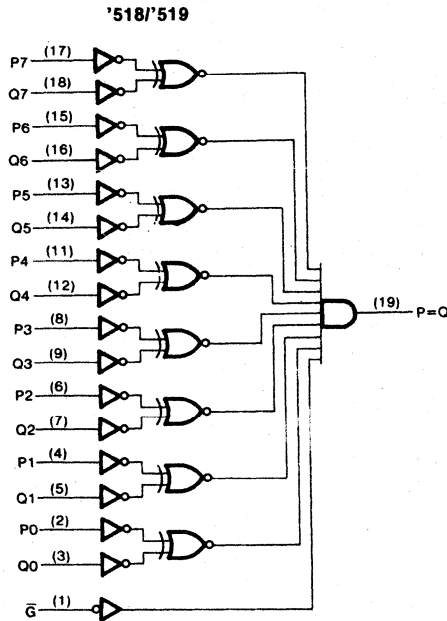


† P=Q for '518 and '519; $\overline{P}=\overline{Q}$ for '520, '521, '522.

FUNCTION TABLE

| INPUTS | | OUTPUTS | |
|-----------|-----------------------|---------|-----------------------------|
| DATA P, Q | ENABLE \overline{G} | P=Q | $\overline{P}=\overline{Q}$ |
| P=Q | L | H | L |
| P>Q | L | L | H |
| P<Q | L | L | H |
| X | H | L | H |

LOGIC DIAGRAMS



5

Absolute Maximum Ratings*

| | |
|---|---|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 70 mA |
| Continuous Current Through V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{Stg} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_d [†] | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

[†] Power Dissipation temperature derating:

| | |
|----------------------|---|
| Plastic Package (N): | $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C |
| Ceramic Package (J): | $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C |

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74HCTL5: -40°C to $+85^\circ\text{C}$ KS54HCTL5: -55°C to $+125^\circ\text{C}$ |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V=10\%$ Unless Otherwise Specified)

| Parameter | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--|-----------------|--|--------------------------|---|--|-----------------------|---------------|
| | | | Typ | Guaranteed Limits | | | |
| | | | | $T_A = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_A = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage (Totem-pole Outputs) | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.93 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage (All Outputs) | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | C | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current (‘518, ‘520 and ‘522 Q input) | | $V_{CC} = \text{Max}$ $V_{IN} = 2.7\text{V}$ $V_{IN} = 0.4\text{V}$ | | -0.2 -0.4 | -0.2 -0.4 | -0.2 -0.4 | mA |
| Maximum Input Current (All other Inputs) | I_{IN} | $V_{IN} = V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Output Leakage Current (Open-Drain Outputs) | I_{OZ} | $V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = V_{CC}$ | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | For ‘518, ‘520 and ‘522: $V_{IN} = \text{GND}$ (Q0-Q7) $V_{IN} = V_{CC}$ or GND (all other inputs) | | 3.5 | 3.5 | 3.5 | mA |
| | | For ‘519 and ‘521: $V_{IN} = V_{CC}$ or GND $I_{OUT} = 0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT} = 0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTL518, HCTL519

| Characteristic | Symbol | Conditions | 54/74AUGHT $T_a = 25^\circ\text{C}$ $V_{CC} = 5\text{V}$ | | KS74HCTL5 $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5\text{V} \pm 10\%$ | | 54HCTL5 $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|---|-----------|----------------------|--|-------------------|---|--|--|--|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay, from P or Q to P=Q | t_{PLH} | $C_L = 50\text{pF}$ | 26 | 33 | 40 | | 47 | | ns |
| | | $C_L = 150\text{pF}$ | 36 | 43 | 50 | | 57 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 21 | 28 | 35 | | 42 | | ns |
| | | $C_L = 150\text{pF}$ | 24 | 35 | 44 | | 53 | | |
| Maximum Propagation Delay, from \bar{G} to P=Q | t_{PLH} | $C = 50\text{pF}$ | 23 | 29 | 35 | | 41 | | ns |
| | | $C_L = 150\text{pF}$ | 33 | 39 | 45 | | 51 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 18 | 24 | 30 | | 36 | | ns |
| | | $C_L = 150\text{pF}$ | 21 | 31 | 39 | | 47 | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | | pF |
| Maximum Output Capacitance | C_{OUT} | | | | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | | pF |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTL520, HCTL521

| Characteristic | Symbol | Conditions | 54/74AUGHT $T_a = 25^\circ\text{C}$ $V_{CC} = 5\text{V}$ | | KS74HCTL5 $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5\text{V} \pm 10\%$ | | 54HCTL5 $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|---|-----------|----------------------|--|-------------------|---|--|--|--|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay, from P or Q to $\bar{P}=\bar{Q}$ | t_{PLH} | $C_L = 50\text{pF}$ | 12 | 22 | 28 | | 33 | | ns |
| | | $C_L = 150\text{pF}$ | 19 | 29 | 37 | | 44 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 16 | 22 | 28 | | 33 | | ns |
| | | $C_L = 150\text{pF}$ | 19 | 29 | 37 | | 44 | | |
| Maximum Propagation Delay, from \bar{G} to $\bar{P}=\bar{Q}$ | t_{PLH} | $C = 50\text{pF}$ | 15 | 20 | 25 | | 30 | | ns |
| | | $C_L = 150\text{pF}$ | 18 | 27 | 34 | | 41 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 15 | 20 | 25 | | 30 | | ns |
| | | $C_L = 150\text{pF}$ | 18 | 27 | 34 | | 41 | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | | pF |
| Maximum Output Capacitance | C_{OUT} | | | | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | | pF |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTL522

| Characteristic | Symbol | Conditions | 54/74AUGHT $T_a = 25^\circ\text{C}$ $V_{CC} = 5\text{V}$ | | KS74HCTL5 $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5\text{V} \pm 10\%$ | | 54HCTL5 $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|---|-----------|----------------------|--|-------------------|---|--|--|--|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay, from P or Q to $\bar{P}=\bar{Q}$ | t_{PLH} | $C_L = 50\text{pF}$ | 24 | 31 | 37 | | 43 | | ns |
| | | $C_L = 150\text{pF}$ | 34 | 41 | 47 | | 53 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 19 | 26 | 32 | | 38 | | ns |
| | | $C_L = 150\text{pF}$ | 22 | 33 | 41 | | 49 | | |
| Maximum Propagation Delay, from \bar{G} to $\bar{P}=\bar{Q}$ | t_{PLH} | $C = 50\text{pF}$ | 23 | 29 | 35 | | 41 | | ns |
| | | $C_L = 150\text{pF}$ | 33 | 39 | 45 | | 51 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 18 | 24 | 30 | | 36 | | ns |
| | | $C_L = 150\text{pF}$ | 21 | 31 | 39 | | 47 | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- 8 latches in a single package
- Full parallel access for loading
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^\circ\text{C}$
KS54HCTLS: -55°C to $+125^\circ\text{C}$

DESCRIPTION

The '533 consists of 8 high-speed D-type latches coupled to 3-state output buffers with high drive current capability. It can be used in implementing buffer registers, I/O ports, bidirectional bus drivers and working registers.

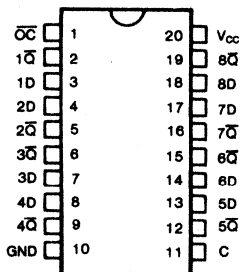
The latches are transparent: when the enable (C) is high, the \bar{Q} outputs follow the complements of the data (D) inputs. When the enable is low, the outputs latch at the levels that were set up at the D inputs.

The output buffers are controlled by a common signal (\overline{OC}) which places the outputs at high-impedance state when it is taken high. The \overline{OC} signal does not affect the internal operations of the latches. Old data can be retained or new data can be entered while outputs are off.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

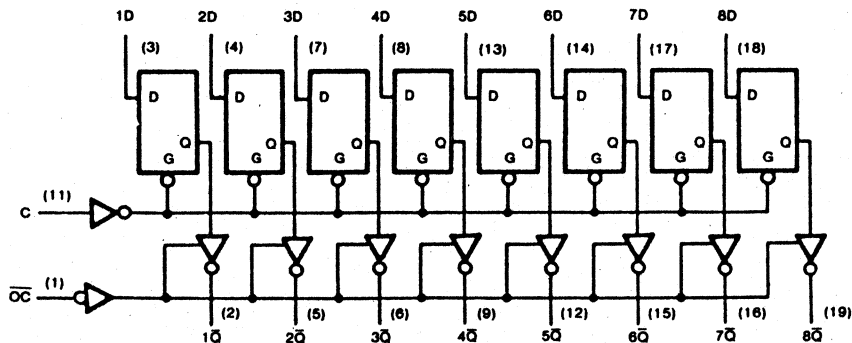


FUNCTION TABLE

(Each Latch)

| Inputs | | | Output |
|-----------------|----------|---|-------------|
| \overline{OC} | Enable C | D | \bar{Q} |
| L | H | H | L |
| L | H | L | H |
| L | L | X | \bar{Q}_0 |
| H | X | X | Z |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range
 KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$, Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------|------------------------|------------------------|--------------------------------------|---------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ C$ to $+85^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -6mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 12mA$ $I_O = 24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS533

| Characteristic | Symbol | Conditions† | T _a = 25°C V _{CC} = 5.0V | | | | KS74HCTLS T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | | KS54HCTLS T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | Unit |
|--|------------------|---|---|----------|-------------------|----------|--|--|---|--|------|
| | | | Typ | | Guaranteed Limits | | | | | | |
| | | | | | | | | | | | |
| Maximum Propagation Delay, D to \bar{Q} | t _{PLH} | C _L = 50pF C _L = 150pF | 14 17 | 18 18 | 23 23 | 27 27 | | | ns | | |
| | t _{PHL} | C _L = 50pF C _L = 150pF | 14 17 | 18 25 | 23 32 | 27 38 | | | | | |
| Maximum Propagation Delay C to \bar{Q} | t _{PLH} | C = 50pF C _L = 150pF | 22 25 | 30 37 | 37 46 | 45 56 | | | ns | | |
| | t _{PHL} | C _L = 50pF C _L = 150pF | 22 25 | 30 37 | 37 46 | 48 56 | | | | | |
| Maximum Output Enable Time, \bar{OC} to any \bar{Q} | t _{PZH} | R _L = 1kΩ C _L = 50pF C _L = 150pF | 24 30 | 32 39 | 40 49 | 48 59 | | | ns | | |
| | t _{PZL} | | 24 30 | 32 39 | 40 49 | 48 59 | | | | | |
| Maximum Output Disable Time, \bar{OC} to any \bar{Q} | t _{PHZ} | R _L = 1kΩ | 19 | 25 | 31 | 37 | | | ns | | |
| | t _{PLZ} | C _L = 50pF | 19 | 25 | 31 | 37 | | | | | |
| Minimum Pulse Width, C High | t _w | | 6 | 10 | 12 | 15 | | | ns | | |
| Minimum Setup Time, D before C↓ | t _{su} | | 2 | 3 | 4 | 5 | | | ns | | |
| Minimum Hold Time, D after C↓ | t _h | | 6 | 10 | 12 | 15 | | | ns | | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | | | pF | | |
| Maximum Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | | | pF | | |
| Power Dissipation Capacitance* (per stage) | C _{PD} | $\bar{OC} = V_{CC}$ | 5 | | | | | | pF | | |
| | | $\bar{OC} = GND$ | 30 | | | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

The '534 consists of 8 high-speed D-type edge-triggered flip-flops coupled to 3-state output buffers with high drive current capability. It can be used in implementing buffer registers, I/O ports, bidirectional bus driver and working registers.

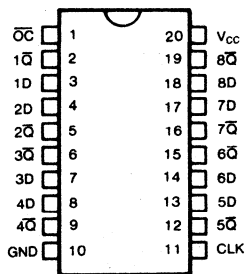
The flip-flops are edge-triggered on the positive transition of the clock: the \bar{Q} outputs are set to the complement of the logic levels that were set up at the D inputs.

The output buffers are controlled by a common signal (\overline{OC}) which places the outputs in high-impedance state when it is taken high. The OC signal does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while outputs are off.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

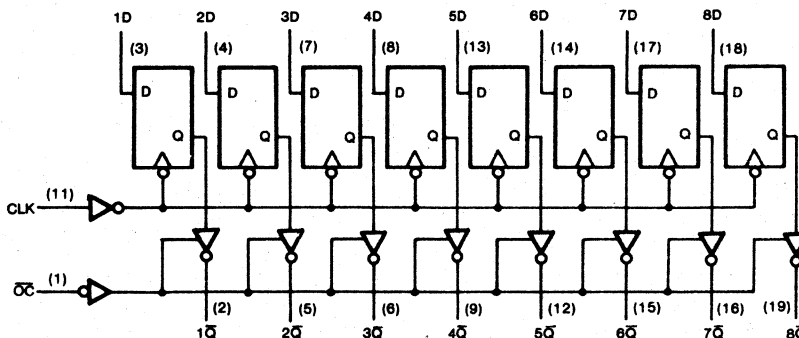


FUNCTION TABLE

(Each Latch)

| Inputs | | | Output |
|-----------------|-----|---|-------------|
| \overline{OC} | CLK | D | \bar{Q} |
| L | ↑ | H | L |
| L | ↑ | L | H |
| L | L | X | \bar{Q}_0 |
| H | X | X | Z |

LOGIC DIAGRAM



Absolute Maximum Ratings*

| | |
|---|-----------------|
| Supply Voltage Range V_{CC} , | -0.5V to +7V |
| DC Input Diode Current, I_{IK} ($V_i < -0.5V$ or $V_i > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} ($V_o < -0.5V$ or $V_o > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_o ($-0.5V < V_o < V_{CC} + 0.5V$) | ± 70 mA |
| Continuous Current Through V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74HCTLS: -40°C to +85°C KS54HCTLS: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|--|-----------------------|---|-----------------------|---------------|
| | | | Typ | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | $V_{CC} - 0.1$ 3.7 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | 0.1 0.4 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | ± 10.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | 160.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_i = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | 3.0 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS534

| Characteristic | Symbol | Conditions† | T _a = 25°C V _{CC} = 5.0V | | | | KS74HCTLS T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | | KS54HCTLS T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | Unit |
|--|------------------|---|---|----------|-------------------|----------|--|----------|---|-----|------|
| | | | Typ | | Guaranteed Limits | | | | | | |
| | | | | | | | | | | | |
| Maximum Operating Frequency | f _{max} | C _L = 50pF | 50 | 35 | 30 | | | 25 | | MHz | |
| Maximum Propagation Delay, CLK to any Q | t _{PLH} | C _L = 50pF C _L = 150pF | 21 24 | 28 35 | 35 44 | | | 42 53 | | ns | |
| | t _{PHL} | C _L = 50pF C _L = 150pF | 21 24 | 28 35 | 35 44 | | | 42 53 | | | |
| Maximum Output Enable Time, OC to any Q | t _{pZH} | R _L = 1kΩ | C _L = 50pF C _L = 150pF | 21 27 | 28 35 | 35 44 | | | 42 53 | ns | |
| | t _{pZL} | | C _L = 50pF C _L = 150pF | 21 27 | 28 35 | 35 44 | | | 42 53 | | |
| Maximum Output Disable Time, OC to any Q | t _{PHZ} | R _L = 1kΩ | 19 | 25 | 31 | | | 37 | | ns | |
| | t _{PLZ} | C _L = 50pF | 19 | 25 | 31 | | | 37 | | | |
| Minimum Pulse Width, CLK High or Low | t _w | | 9 | 13 | 15 | | | 18 | | ns | |
| Minimum Setup Time, D before CLK† | t _{su} | | 10 | 13 | 17 | | | 20 | | ns | |
| Minimum Hold Time, D after CLK† | t _h | | -3 | 0 | 0 | | | 0 | | ns | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | | | | pF | |
| Maximum Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C _{PD} | OC = V _{CC} | 5 | | | | | | | pF | |
| | | OC = GND | 30 | | | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

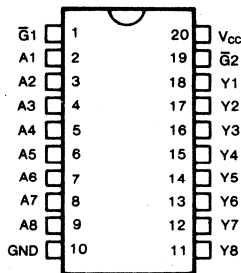
The '540 and '541 are general purpose high-speed octal line drivers/buffers with 3-state outputs. The inputs and outputs are located on opposite sides of the 20-pin package, thus improving circuit board density. The '540 provides inverted data and the '541 provides true data at the outputs.

The three-state control gate is a 2-input NOR such that if either $\overline{G1}$ or $\overline{G2}$ is high, all eight outputs are in the high impedance state.

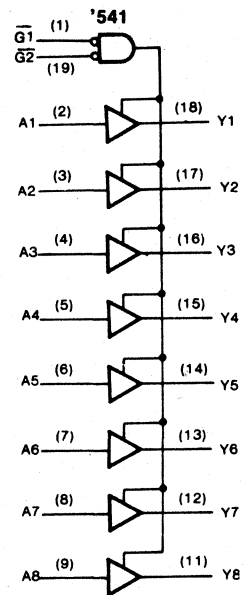
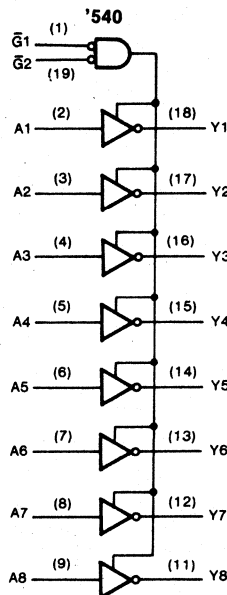
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground

PIN CONFIGURATION



LOGIC DIAGRAMS



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|-----------------------------------|----------|--|--------------------------|--|---|---------------------|---------------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns), HCTLS540, HCTLS541

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit |
|---|-----------|-------------------------|--|-------------------|--|---|------|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | Guaranteed Limits | | | |
| Maximum Propagation Delay, A to Y | t_{PLH} | $C_L = 50\text{pF}$ | 11 | 15 | 19 | 23 | ns |
| | | $C_L = 150\text{pF}$ | 14 | 22 | 28 | 34 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 11 | 15 | 19 | 23 | |
| | | $C_L = 150\text{pF}$ | 14 | 22 | 28 | 34 | |
| Maximum Output Enable Time, \bar{G} to Y | t_{PZH} | $C_L = 50\text{pF}$ | 18 | 25 | 25 | 37 | ns |
| | | $C_L = 150\text{pF}$ | 24 | 32 | 40 | 48 | |
| | t_{PZL} | $C_L = 50\text{pF}$ | 18 | 25 | 31 | 37 | |
| | | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | |
| Maximum Output Disable Time, \bar{G} to Y | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 13 | 18 | 23 | 27 | ns |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 13 | 18 | 23 | 27 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Maximum Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF |
| Power Dissipation Capacitance* (per stage) | C_{PD} | $\bar{G} = V_{CC}$ | 5 | | | | pF |
| | | $\bar{G} = \text{GND}$ | 30 | | | | |

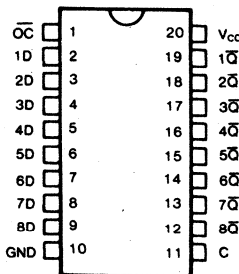
* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- 8 latches in a single package
- Full parallel access for loading
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24\text{mA}$ @ $V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



DESCRIPTION

The '563 consists of 8 high-speed D-type latches coupled to 3-state output buffers with high drive current capability. It can be used in implementing buffer register, I/O ports, bidirectional bus drivers and working registers.

The latches are transparent: when the enable (C) is high, the Q outputs follow complements of the data (D) inputs. When the enable is low, the outputs latch at the levels that were set up at the D inputs.

The output buffers are controlled by a common signal (OC) which places the outputs at a high-impedance stage when it is taken high. The OC signal does not affect the internal operations of the latches. Old data can be retained or new data can be entered while outputs are off.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

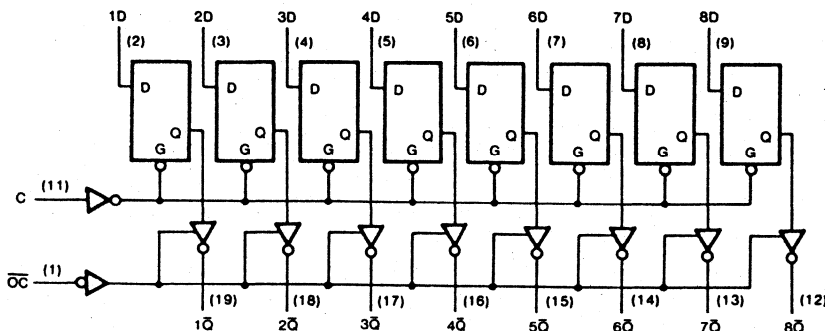
All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLE

(Each Latch)

| Inputs | | | Output |
|------------------------|----------|---|-------------------------|
| $\overline{\text{OC}}$ | Enable C | D | $\overline{\text{Q}}$ |
| L | H | H | L |
| L | H | L | H |
| L | L | X | $\overline{\text{Q}}_0$ |
| H | X | X | Z |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range
 KS74HCTLS: -40°C to $+85^\circ\text{C}$
 KS54HCTLS: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|---|--|-----------------------|-------------------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | KS54HCTLS $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | Guaranteed Limits |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $= V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS563

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|--|-----------|---|--|-------------------|---|----------|--|----|------|
| | | | Typ | Guaranteed Limits | | | | | |
| | | | | | | | | | |
| Maximum Propagation Delay, D to \bar{Q} | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 14 17 | 18 25 | 23 32 | 27 38 | ns | | |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 14 17 | 18 25 | 23 32 | 27 38 | | | |
| Maximum Propagation Delay C to \bar{Q} | t_{PLH} | $C = 50\text{pF}$ $C_L = 150\text{pF}$ | 22 25 | 30 37 | 37 46 | 45 56 | ns | | |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 22 25 | 30 37 | 37 46 | 45 56 | | | |
| Maximum Output Enable Time, \bar{OC} to any \bar{Q} | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 24 30 | 32 39 | 40 49 | 48 59 | ns | |
| | t_{PZL} | | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 24 30 | 32 39 | 40 49 | 48 59 | | |
| Maximum Output Disable Time, \bar{OC} to any \bar{Q} | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 19 | 25 | 31 | 37 | ns | | |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 19 | 25 | 31 | 37 | | | |
| Minimum Pulse Width, C High | t_w | | 9 | 13 | 15 | 18 | ns | | |
| Minimum Setup Time, D before $C\downarrow$ | t_{su} | | 6 | 8 | 10 | 10 | ns | | |
| Minimum Hold Time, D after $C\downarrow$ | t_h | | 6 | 10 | 12 | 15 | ns | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF | | |
| Maximum Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF | | |
| Power Dissipation Capacitance* (per stage) | C_{PD} | $\bar{OC} = V_{CC}$ | 5 | | | | pF | | |
| | | $\bar{OC} = \text{GND}$ | 30 | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

The '564 consists of 8 high-speed D-type edge-triggered flip-flops coupled to 3-state output buffers with high drive current capability. It can be used in implementing buffer registers, I/O ports, bidirectional bus driver and working registers.

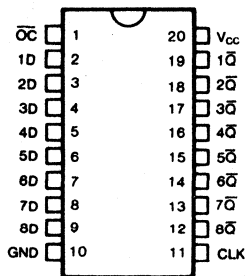
The flip-flops are edge-triggered: on the positive transition of the clock, the \bar{Q} outputs are set to the complement of the logic levels that were set up at the D inputs.

The output buffers are controlled by a common signal (\overline{OC}) which places the outputs at high impedance state when it is taken high. The \overline{OC} signal does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while outputs are off.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

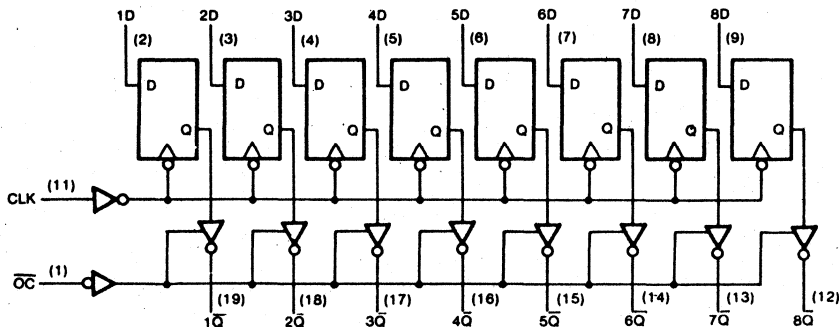


FUNCTION TABLE

(Each Flip-Flop)

| Inputs | | | Output |
|-----------------|-----|---|-------------|
| \overline{OC} | CLK | D | \bar{Q} |
| L | ↑ | H | L |
| L | ↑ | L | H |
| L | L | X | \bar{Q}_0 |
| H | X | X | Z |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN}, V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|--|-----------------------|---|-----------------------|---------------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | $V_{CC} - 0.1$ 3.7 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | 0.1 0.4 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 5.0 | ± 10.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 80.0 | 160.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 2.9 | 3.0 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns, HCTLS564)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit | |
|--|-----------|---|--|-------------------|--|----------|---|----------|------|--|
| | | | Typ | Guaranteed Limits | | | | | | |
| | | | | | | | | | | |
| Maximum Operating Frequency | f_{max} | $C_L = 50\text{pF}$ | 45 | 35 | 30 | | 25 | | MHz | |
| Maximum Propagation Delay, CLK to any \bar{Q} | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 21 24 | 28 35 | 35 44 | | 42 53 | | ns | |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 21 24 | 28 35 | 35 44 | | 42 53 | | | |
| Maximum Output Enable Time, \bar{OC} to any \bar{Q} | t_{pZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 21 27 | 28 35 | 35 44 | | 42 53 | ns | |
| | t_{pZL} | | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 21 27 | 28 35 | 35 44 | | 42 53 | | |
| Maximum Output Disable Time, \bar{OC} to any \bar{Q} | t_{pHZ} | $R_L = 1\text{k}\Omega$ | 19 | 25 | 31 | | 37 | | ns | |
| | t_{pLZ} | $C_L = 50\text{pF}$ | 19 | 25 | 31 | | 37 | | | |
| Minimum Pulse Width, CLK High or Low | t_w | | 9 | 12 | 15 | | 18 | | ns | |
| Minimum Setup Time, D before CLK† | t_{su} | | 10 | 13 | 17 | | 20 | | ns | |
| Minimum Hold Time, D after CLK† | t_h | | -3 | 0 | 0 | | 0 | | ns | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | | pF | |
| Maximum Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C_{PD} | $\bar{OC} = V_{CC}$ | 5 | | | | | | pF | |
| | | $\bar{OC} = \text{GND}$ | 30 | | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- 8 latches in a single package
- Full parallel access for loading
- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54HACT: -40°C to $+125^{\circ}\text{C}$

DESCRIPTION

The '573 consists of 8 high-speed D-type latches coupled to 3-state output buffers with high drive current capability. It can be used in implementing buffer registers, I/O ports, bidirectional bus drivers and working registers.

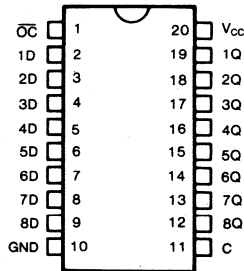
The latches are transparent: when the enable (C) is high, the Q outputs follow the data (D) inputs. When the enable is low, the outputs latch at the levels that were set up at the D inputs.

The output buffers are controlled by a common signal (\overline{OC}) which places the outputs at a high-impedance state when it is taken high. The \overline{OC} signal does not affect the internal operations of the latches. Old data can be retained or new data can be entered while outputs are off.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

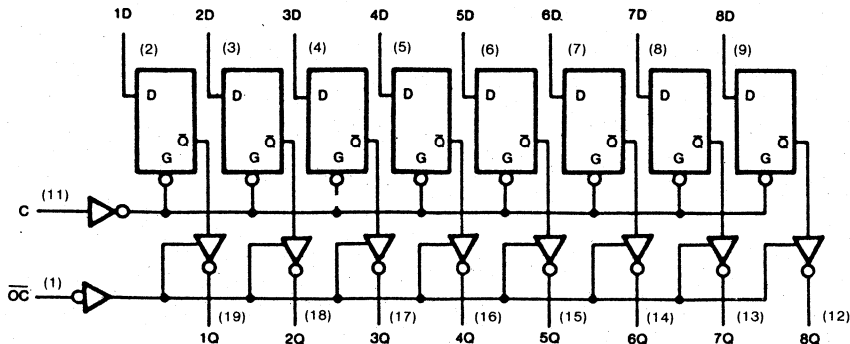


FUNCTION TABLE

(Each Latch)

| Inputs | | | Output |
|-----------------|----------|---|--------|
| \overline{OC} | Enable C | D | Q |
| L | H | H | H |
| L | H | L | L |
| L | L | X | Q_0 |
| H | X | X | Z |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | | Unit |
|--------------------------------------|-----------------|--|--|------------------------|---|-----------------------|---------------|
| | | | KS74HCTLS | | KS54HCTLS | | |
| | | | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | | $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | |
| | | | Typ | | | | |
| | | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS573

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|---|-----------|--------------------------------------|--|-------------------|---|----|--|----|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay, D to Q | t_{PLH} | $C_L = 50\text{pF}$ | 14 | 18 | 23 | 27 | ns | | |
| | | $C_L = 150\text{pF}$ | 17 | 25 | 32 | 38 | | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 14 | 18 | 23 | 27 | ns | | |
| | | $C_L = 150\text{pF}$ | 17 | 25 | 32 | 38 | | | |
| Maximum Propagation Delay C to Q | t_{PLH} | $C = 50\text{pF}$ | 22 | 30 | 37 | 45 | ns | | |
| | | $C_L = 150\text{pF}$ | 25 | 37 | 46 | 56 | | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 22 | 30 | 37 | 45 | ns | | |
| | | $C_L = 150\text{pF}$ | 25 | 37 | 46 | 56 | | | |
| Maximum Output Enable Time, \overline{OC} to any Q | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | ns | |
| | | | $C_L = 150\text{pF}$ | 30 | 39 | 49 | 59 | | |
| | t_{PZL} | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | | | |
| | | $C_L = 150\text{pF}$ | 30 | 39 | 49 | 59 | | | |
| Maximum Output Disable Time, \overline{OC} to any Q | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 19 | 25 | 31 | 37 | ns | | |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 19 | 25 | 31 | 37 | | | |
| Minimum Pulse Width, C High | t_w | | 9 | 12 | 15 | 18 | ns | | |
| Minimum Setup Time, D before $C\downarrow$ | t_{su} | | 6 | 8 | 10 | 12 | ns | | |
| Minimum Hold Time, D after $C\downarrow$ | t_h | | 6 | 10 | 12 | 15 | ns | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF | | |
| Maximum Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF | | |
| Power Dissipation Capacitance* | C_{PD} | $\overline{OC} = V_{CC}$ (per stage) | 5 | | | | pF | | |
| | | $\overline{OC} = \text{GND}$ | 30 | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

5

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

The '574 consists of 8 high-speed D-type edge-triggered flip-flops coupled to 3-state output buffers with high drive current capability. It can be used in implementing buffer registers, I/O ports, bidirectional bus drivers and working registers.

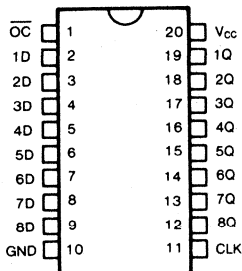
The flip-flops are edge-triggered on the positive transition of the clock. The Q outputs are set to the logic levels that were set up at the D inputs.

The output buffers are controlled by a common signal (\overline{OC}) which places the outputs at a high-impedance state when it is taken high. The \overline{OC} signal does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while outputs are off.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION

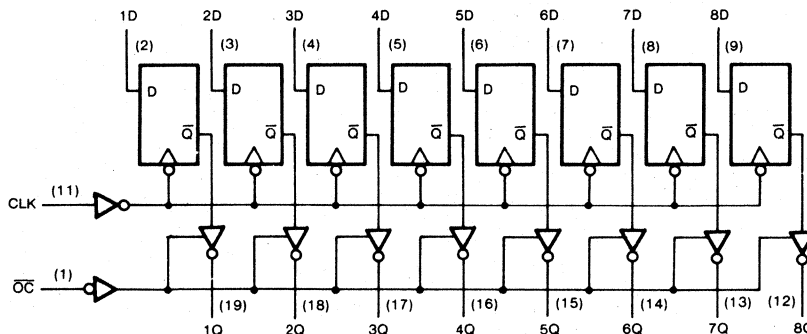


FUNCTION TABLE

(Each Flip-Flop)

| Inputs | | | Output |
|-----------------|-----|---|--------|
| \overline{OC} | CLK | D | Q |
| L | ↑ | H | H |
| L | ↑ | L | L |
| L | L | X | Q_0 |
| H | X | X | Z |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
Continuous Output Current Per Pin, I_O
(-0.5V < V_O < $V_{CC} + 0.5V$) ± 70 mA
Continuous Current Through
 V_{CC} or GND pins ± 250 mA
Storage Temperature Range, T_{stg} , -65°C to +150°C
Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
Operating Temperature
Range KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C
Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------|----------------------|--------------------------------------|---------------------------------------|---------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-6mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=12mA$ $I_O=24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns, HCTLS574)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit | |
|---|-----------|------------------------------|--|----|---|----|--|----|------|----|
| | | | Typ | | Guaranteed Limits | | | | | |
| | | | | | | | | | | |
| Maximum Operating Frequency | f_{max} | $C_L = 50\text{pF}$ | 45 | 35 | 30 | | 25 | | MHz | |
| Maximum Propagation Delay, CLK to any Q | t_{PLH} | $C_L = 50\text{pF}$ | 21 | 28 | 35 | | 42 | | ns | |
| | | $C_L = 150\text{pF}$ | 24 | 35 | 44 | | 53 | | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 21 | 28 | 35 | | 42 | | ns | |
| | | $C_L = 150\text{pF}$ | 24 | 35 | 44 | | 53 | | | |
| Maximum Output Enable Time, \overline{OC} to any Q | t_{pZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 21 | 28 | 35 | | 42 | | ns |
| | | | $C_L = 150\text{pF}$ | 27 | 35 | 44 | | 53 | | |
| | t_{pZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 21 | 28 | 35 | | 42 | | ns |
| | | | $C_L = 150\text{pF}$ | 27 | 35 | 44 | | 53 | | |
| Maximum Output Disable Time, \overline{OC} to any Q | t_{pHZ} | $R_L = 1\text{k}\Omega$ | | | 19 | | 25 | | ns | |
| | | | $C_L = 50\text{pF}$ | | | 19 | | 25 | | |
| | t_{pLZ} | $C_L = 50\text{pF}$ | | | | 19 | | 25 | | ns |
| | | | | | 19 | | 25 | | | |
| Minimum Pulse Width, CLK High or Low | t_w | | 9 | 12 | 15 | | 18 | | ns | |
| Minimum Setup Time, D before CLK† | t_{su} | | 10 | 13 | 17 | | 20 | | ns | |
| Minimum Hold Time, D after CLK† | t_h | | -3 | 0 | 0 | | 0 | | ns | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | | pF | |
| Maximum Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C_{PD} | $\overline{OC} = V_{CC}$ | 5 | | | | | | pF | |
| | | $\overline{OC} = \text{GND}$ | 30 | | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Choice of 3-State ('590) and Open-Drain ('591) Outputs
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs
($I_{OL} = 24\text{mA}$ @ $V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

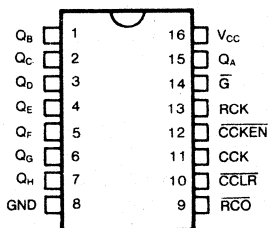
These devices each consist of an 8-bit counter which feeds an 8-bit register. The counter is incremented on the rising edge of the CCK input, provided that clock enable, $\overline{\text{CCKEN}}$, is low. When the counter increments to the all ones condition, ripple carry out, $\overline{\text{RCO}}$, will go low. This enables either synchronous cascading of the counters by connecting the $\overline{\text{RCO}}$ of the first stage to the $\overline{\text{CCKEN}}$ of the second, or clocking both circuits in parallel. Ripple cascading is accomplished by connecting the $\overline{\text{RCO}}$ of the first to the CCK of the second stage. A clear input is also provided which will reset the counter to the all zeros state.

The output register is loaded with the contents of the counter on the rising edge of the register clock, RCK. The outputs of this register feed the outputs which are enabled when the enable input, G, is taken low. This enables connection of this part to a system bus. The Q outputs of the '590 are 3-State and those for '591 are Open-drain.

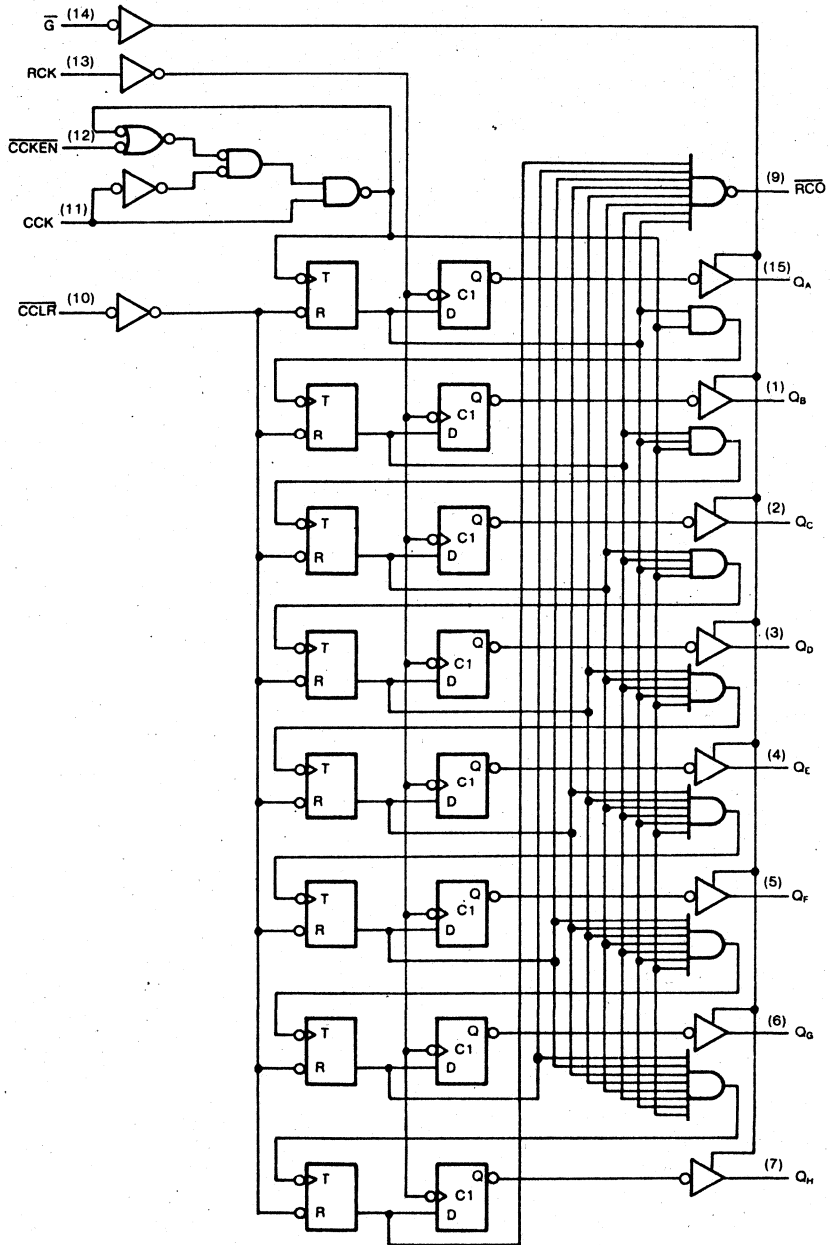
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} , -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--|-----------------|--|--------------------------|--|---|---------------------|---------------|
| | | | Typ | Guaranteed Limits | | | |
| | | | | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage (All '590 Outputs and '591 RCO Outputs) | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns), HCTLS590

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit | |
|--|---------------------------|---------------------|--|-------------------|--|---|------|----|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Guaranteed Limits | | | | |
| Maximum Clock Frequency | f_{max} | | 35 | 25 | 20 | 20 | ns | |
| Maximum Propagation Delay, CCK↑ to RCO | t_{PLH} | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | ns | |
| | t_{PHL} | | 24 | 32 | 40 | 48 | | |
| Maximum Propagation Delay, CCLR↓ to RCO | t_{PLH} | | 26 | 35 | 44 | 52 | ns | |
| Maximum Propagation Delay, RCK↑ to Q | t_{PLH} | | 16 | 21 | 26 | 31 | ns | |
| | t_{PHL} | | 16 | 21 | 26 | 31 | | |
| Maximum Output Enable Time, \bar{G} ↓ to Q | t_{PZH} | | $R_L = 1\text{k}\Omega$ $C_L = 50\text{pF}$ | 18 | 24 | 30 | 36 | ns |
| | t_{PZL} | 18 | | 24 | 30 | 36 | | |
| Maximum Output Disable Time, \bar{G} ↑ to Q | t_{PHZ} | 18 | | 24 | 30 | 36 | ns | |
| | t_{PLZ} | 18 | | 24 | 30 | 36 | | |
| Minimum Pulse Width | CCK or RCK High or Low | t_w | | 12 | 16 | 20 | 24 | ns |
| | CCLR Low | | | 12 | 16 | 20 | 24 | |
| Minimum Setup Time | CCKEN↓ before CCK↑ | t_{su} | 12 | 16 | 20 | 24 | ns | |
| | CCLR↑ before CCK↑ | | 12 | 16 | 20 | 24 | | |
| | CCK↑ to RCK↑↑ | | 24 | 32 | 40 | 48 | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF | |
| Maximum Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

†† The RCK↑ to CCK↑ setup time ensures that the counter will see stable data from the register output.

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS591

| Characteristic | Symbol† | Conditions† | $T_a = 25^\circ\text{C}$ | KS74HCTLS | | KS54HCTLS | | Unit |
|--|---------------------------|--|--------------------------|---|--|---------------------------------|---------------------------------|------|
| | | | $V_{CC} = 5.0\text{V}$ | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | $V_{CC} = 5.0\text{V} \pm 10\%$ | $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | Guaranteed Limits | | | | |
| Maximum Clock Frequency | f_{max} | | 35 | 25 | 20 | | 20 | ns |
| Maximum Propagation Delay, CCK† to RCO | t_{PLH} | $C_L = 50\text{pF}$ $R_L = 1\text{k}\Omega$ | 24 | 32 | 40 | | 48 | ns |
| | t_{PHL} | | 24 | 32 | 40 | | 48 | |
| Maximum Propagation Delay, CCLR‡ to RCO | t_{PLH} | | 26 | 35 | 44 | | 52 | ns |
| Maximum Propagation Delay, RCK† to Q | t_{PLH} | | 27 | 37 | 46 | | 55 | ns |
| | t_{PHL} | | 16 | 21 | 26 | | 31 | |
| Maximum Output Enable Time, \bar{G} ‡ to Q | t_{PZL} | | | 18 | 24 | 30 | | 36 |
| Maximum Output Disable Time, \bar{G} † to Q | t_{PLZ} | | 18 | 24 | 30 | | 36 | ns |
| Minimum Pulse Duration | CCK or RCK High or Low | t_w | 12 | 16 | 20 | | 24 | ns |
| | CCLR‡ Low | | 12 | 16 | 20 | | 24 | |
| Minimum Setup Time | CCKEN‡ before CCK† | t_{su} | 12 | 16 | 20 | | 24 | ns |
| | CCLR† before CCK† | | 12 | 16 | 20 | | 24 | |
| | CCK† to RCK††† | | 24 | 32 | 40 | | 48 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | pF |
| Maximum Output Capacitance | C_{OUT} | Output Disabled | | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

†† The clocks may be tied together, in which case the register state will be one clock pulse behind the counter.

Objective Specifications

FEATURES

- Parallel Register Inputs ('592)
- Parallel 3-State I/O: Register Inputs/Counter Outputs ('593)
- Counter Has Direct Overriding Load and Clear
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

The '592 and '593 both contain an 8-bit register which feeds an 8-bit binary counter. The counter is incremented on the rising edge of the CCK input, provided that clock enable, $\overline{\text{CCKEN}}$, is low. When the counter increments to the all ones condition, ripple carry out, $\overline{\text{RCO}}$, will go low. This enables either synchronous cascading of the counters by connecting the $\overline{\text{RCO}}$ of the first stage to the $\overline{\text{CCKEN}}$ of the second, or clocking both circuits in parallel. Ripple cascading is accomplished by connecting the $\overline{\text{RCO}}$ of the first to the CCK of the second stage. A clear input is also provided which will reset the counter to the all zeros state.

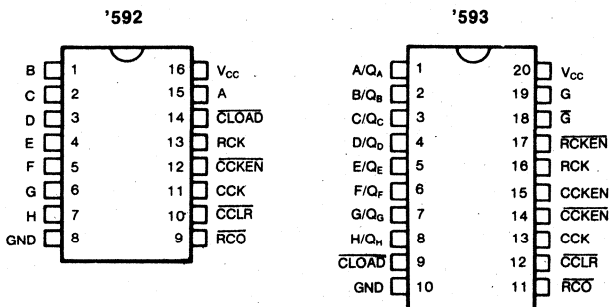
The input register is loaded on the rising edge of the register clock, RCK. The outputs of this register feed the counter. The counter is loaded with the register's contents when the clock load, $\overline{\text{CLOAD}}$, input is taken low.

The '592 differs from the '593 in that the latter device has bidirectional input/output pins. The 3-state outputs of the counter can be enabled and are active when enable input, $\overline{\text{G}}$, is taken low and input G is taken high. The outputs of the counter then appear on the register inputs. This enables connection of this part to a system bus. The '593 also has a second clock enable pin, $\overline{\text{CCKEN}}$, which is active high and it also has an active low register clock enable, $\overline{\text{RCKEN}}$.

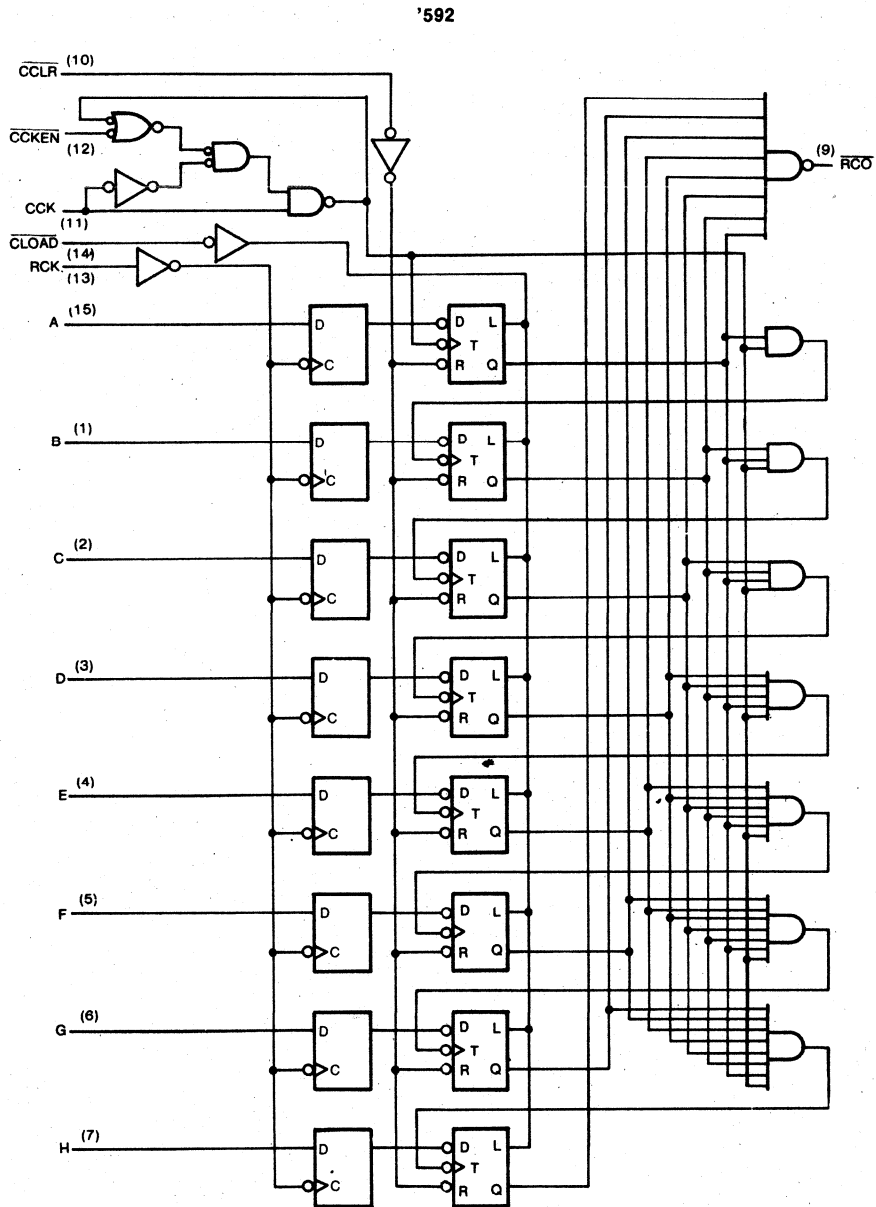
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATIONS

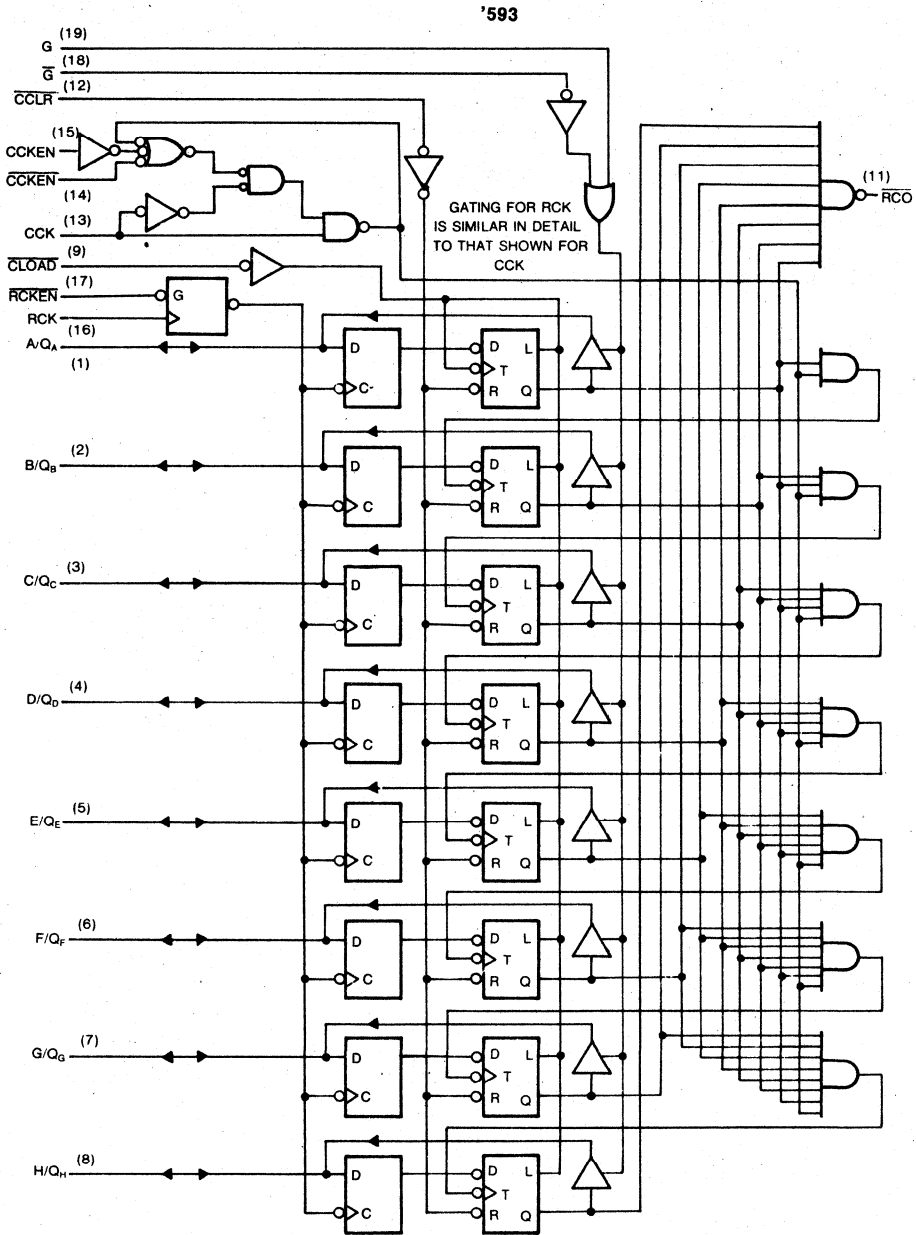


LOGIC DIAGRAMS



5

LOGIC DIAGRAMS (Continued)



Absolute Maximum Ratings*

| | |
|--|-----------------|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 70 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74HCTLS: -40°C to +85°C KS54HCTLS: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS | | KS54HCTLS | | Unit |
|--------------------------------------|-----------------|--|--------------------|----------------------|--------------------------------------|---------------------------------------|-------------------|-------------------|------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ C$ to $+85^\circ C$ | $T_a = -55^\circ C$ to $+125^\circ C$ | Guaranteed Limits | Guaranteed Limits | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-6mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=12mA$ $I_O=24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | μA | |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | | mA | |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), HCTLS592

| Characteristic | Symbol | Conditions† | T _a = 25°C V _{CC} = 5.0V | | KS74HCTLS | KS54HCTLS | Unit |
|---|---------------------------|--------------------------------------|---|----|---|--|------|
| | | | | | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Clock Frequency | f _{max} | | 35 | 25 | 20 | 20 | MHz |
| Maximum Propagation Delay, CCK↑ to RCO | t _{PLH} | C _L = 50pF | 24 | 32 | 40 | 48 | ns |
| | t _{PHL} | | 24 | 32 | 40 | 48 | |
| Maximum Propagation Delay, CLOAD↓ to RCO | t _{PLH} | | 24 | 32 | 40 | 48 | ns |
| | t _{PHL} | | 24 | 32 | 40 | 48 | |
| Maximum Propagation Delay, CCLR↓ to RCO | t _{PHL} | | 24 | 32 | 40 | 48 | ns |
| Maximum Propagation Delay, RCK↑ to RCO | t _{PLH} | C _L = 50pF CLOAD = GND | 26 | 35 | 44 | 52 | ns |
| | t _{PHL} | | 26 | 35 | 44 | 52 | |
| Minimum Pulse Width | CCK or RCK High or Low | t _w | 12 | 16 | 20 | 24 | ns |
| | CCLR Low | | 12 | 16 | 20 | 24 | |
| | CLOAD Low | | 12 | 16 | 20 | 24 | |
| Minimum Setup Time | CCKEN↓ before CCK↑ | t _{su} | 12 | 16 | 20 | 24 | ns |
| | CCLR↑ before CCK↑ | | 12 | 16 | 20 | 24 | |
| | RCK↑ before CCK↑†† | | 24 | 32 | 40 | 48 | |
| | Data A-H† before RCK↑ | | 12 | 16 | 20 | 24 | |
| Minimum Hold Time | t _h | | -3 | 0 | 0 | 0 | ns |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

†† The RCK↑ to CCK↑ setup time ensures that the counter will see stable data from the register output.

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS593

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit | |
|---|-----------|---|--|-------------------|--|----|---|----|------|----|
| | | | Typ | Guaranteed Limits | | | | | | |
| Maximum Clock Frequency | f_{max} | | 35 | 25 | 20 | | 20 | | MHz | |
| Maximum Propagation Delay, CCK† to Q | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 24 | 32 | 40 | | 48 | | ns | |
| | | | 27 | 39 | 49 | | 59 | | | |
| Maximum Propagation Delay, CCK† to \overline{RCO} | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 24 | 32 | 40 | | 48 | | ns | |
| | | | 27 | 39 | 49 | | 59 | | | |
| Maximum Propagation Delay, CCK† to \overline{RCO} | t_{PLH} | $C_L = 50\text{pF}$ | 24 | 32 | 40 | | 48 | | ns | |
| | | | 27 | 39 | 49 | | 59 | | | |
| Maximum Propagation Delay, CLOAD† to Q | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 24 | 32 | 40 | | 48 | | ns | |
| | | | 27 | 39 | 49 | | 59 | | | |
| Maximum Propagation Delay, CLOAD† to \overline{RCO} | t_{PHL} | $C_L = 50\text{pF}$ | 24 | 32 | 40 | | 48 | | ns | |
| | | | 27 | 39 | 49 | | 59 | | | |
| Maximum Propagation Delay, RCK† to \overline{RCO} | t_{PLH} | $C_L = 50\text{pF}$ CLOAD=GND | 26 | 35 | 44 | | 52 | | ns | |
| | | | 26 | 35 | 44 | | 52 | | | |
| Maximum Propagation Delay, \overline{CCLR} † to Q | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 24 | 32 | 40 | | 48 | | ns | |
| | | | 27 | 39 | 49 | | 59 | | | |
| Maximum Propagation Delay, \overline{CCLR} † to \overline{RCO} | t_{PLH} | $C_L = 50\text{pF}$ | 24 | 32 | 40 | | 48 | | ns | |
| | | | 27 | 39 | 49 | | 59 | | | |
| Maximum Enable Time, $G\uparrow$ or $\overline{G}\downarrow$ to Q | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 21 | 28 | 39 | | 42 | | ns |
| | | | $C_L = 150\text{pF}$ | 24 | 35 | 44 | | 53 | | |
| | t_{PZL} | | $C_L = 50\text{pF}$ | 21 | 28 | 35 | | 42 | | ns |
| | | | $C_L = 150\text{pF}$ | 24 | 28 | 44 | | 53 | | |
| Maximum Disable Time $G\downarrow$ or $G\uparrow$ to Q | t_{PLH} | $R_L = 1\text{k}\Omega$ | 24 | 28 | 35 | | 42 | | ns | |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 21 | 28 | 35 | | 42 | | | |
| Minimum Pulse Width | t_w | | CCK or RCK High or Low | 12 | 16 | 20 | | 24 | | ns |
| | | | \overline{CCLR} Low | 12 | 16 | 20 | | 24 | | |
| | | | CLOAD Low | 12 | 16 | 20 | | 24 | | |
| Minimum Setup Time | t_{su} | | $\overline{CCKEN}\downarrow$ before CCK† | 12 | 16 | 20 | | 24 | | ns |
| | | | $\overline{RCKEN}\downarrow$ to RCK† | | 12 | 16 | | 24 | | |
| | | | $\overline{CCLR}\downarrow$ before CCK† | 12 | 16 | 20 | | 24 | | |
| | | | RCK† before CCK†† | 24 | 32 | 40 | | 48 | | |
| | | | Data A-H before RCK† | 12 | 16 | 20 | | 24 | | |
| Hold Time | t_h | | -3 | 0 | 0 | | 0 | | ns | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | | pF | |
| Maximum Output Capacitance | C_{OUT} | Output Disabled | 10 | 10 | | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

†† The RCK† to CCK† setup time ensures that the counter will see stable data from the register output.

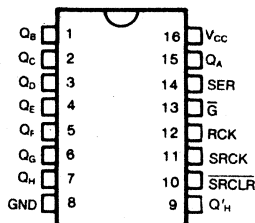
5

Preliminary Specifications

FEATURES

- 8-Bit Serial-In, Parallel-Out Shift Registers With Storage
- Choice of 3-State ('595) or Open-Drain ('596) Parallel Outputs
- Shift Register Has Direct Clear
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



DESCRIPTION

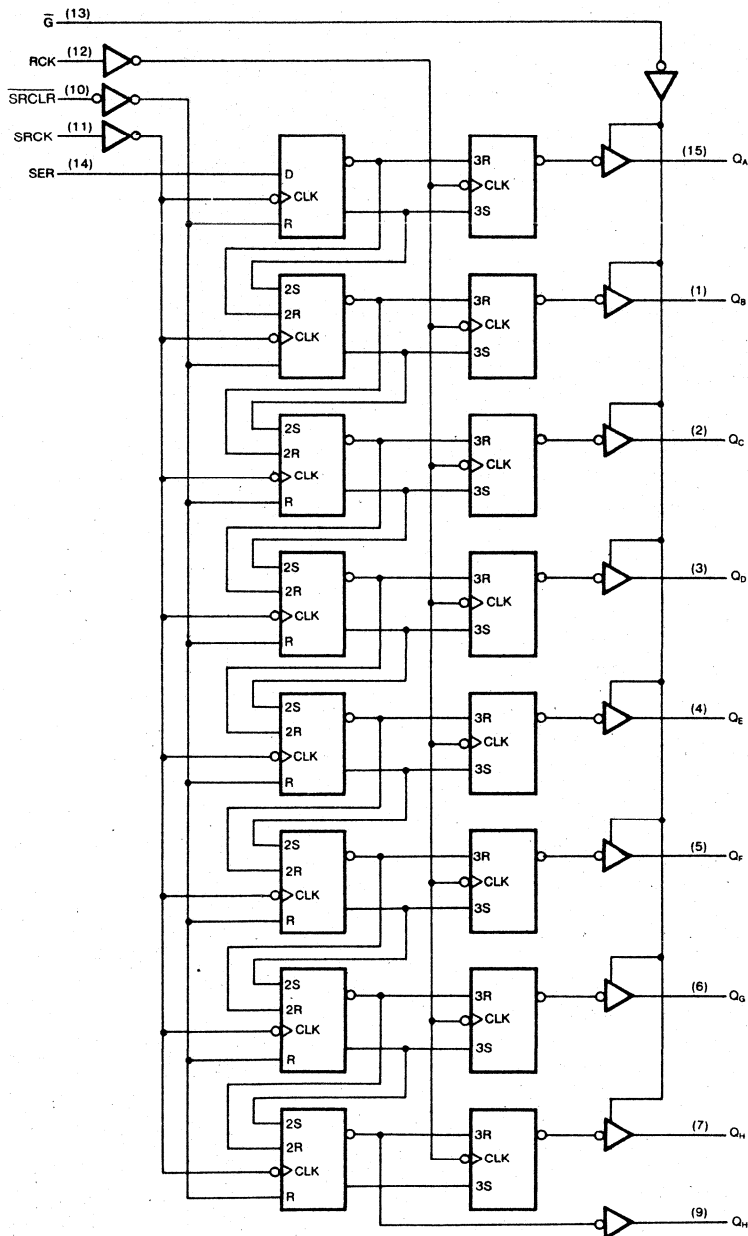
These devices each contain an 8-bit serial-in, parallel-out shift register that feeds an 8-bit D-type storage register. The storage register has parallel 3-state ('595) or open-drain ('596) outputs. Separate clocks are provided for both the shift register and the storage register. The shift register has a direct-overriding clear, serial input, and serial output pins for cascading.

Both the shift register and storage register clocks are positive-edge triggered. If the user wishes to connect both clocks together, the shift register state will always be one clock pulse ahead of the storage register.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAM



5

Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to +150°C
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--|-----------------|--|--------------------------|------------------------|--|-----------------------|---|---------------|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage (All '595 Outputs and '596 Q _H Output) | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | μA | |
| Maximum Output Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | | mA | |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS595, HCTLS596

| Characteristic | Symbol | Conditions† | T _a = 25°C V _{CC} = 5.0V | | KS74HCTLS T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | | KS54HCTLS T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | | Unit |
|--|------------------|---|---|-------------------|--|----|---|--|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay, SRCK↑ to Q _H | t _{PLH} | C _L = 50pF | 15 | 18 | 25 | 30 | ns | | |
| | t _{PHL} | | 15 | 18 | 25 | 30 | | | |
| Maximum Propagation Delay, RCK↑ to Q _A thru Q _H | t _{PLH} | C _L = 50pF C _L = 150pF | 17 | 22 | 28 | 33 | ns | | |
| | | | 20 | 29 | 37 | 44 | | | |
| | t _{PHL} | C _L = 50pF C _L = 150pF | 17 | 22 | 28 | 33 | | | |
| | | | 20 | 29 | 37 | 44 | | | |
| Maximum Output Enable Time, \bar{G} ↑ to Q _A thru Q _H ('595 only) | t _{PZH} | R _L = 1kΩ C _L = 50pF C _L = 150pF | 18 | 24 | 30 | 36 | ns | | |
| | | | 21 | 31 | 39 | 47 | | | |
| | t _{PZL} | C _L = 50pF C _L = 150pF | 18 | 24 | 30 | 36 | | | |
| | | | 21 | 31 | 39 | 47 | | | |
| Maximum Output Disable Time, \bar{G} ↑ to Q _A thru Q _H ('595 only) | t _{PHZ} | R _L = 1kΩ | 18 | 24 | 30 | 36 | ns | | |
| | | | 21 | 31 | 39 | 47 | | | |
| | t _{PLZ} | C _L = 50pF | 18 | 24 | 30 | 36 | | | |
| | | | 21 | 31 | 39 | 47 | | | |
| Maximum Propagation Delay, \bar{G} ↑ to Q _A thru Q _H ('596 only) | t _{PLH} | C _L = 50pF | 18 | 24 | 30 | 36 | ns | | |
| | | C _L = 150pF | 24 | 31 | 39 | 47 | | | |
| Maximum Propagation Delay, \bar{G} ↓ to Q _A thru Q _H ('596 only) | t _{PHL} | C _L = 50pF | 18 | 24 | 30 | 36 | ns | | |
| | | C _L = 150pF | 24 | 31 | 39 | 47 | | | |
| Minimum Pulse Width | SRCK or RCK | t _w | 12 | 16 | 20 | 24 | ns | | |
| | SRCLR Low | | 12 | 16 | 20 | 24 | | | |
| Minimum Setup Time | SRCLR↑ to SRCK↑ | t _{su} | 12 | 16 | 20 | 24 | ns | | |
| | SER to SRCK↑ | | 12 | 16 | 20 | 24 | | | |
| | SRCK↑ to RCK↑†† | | 24 | 32 | 40 | 48 | | | |
| Minimum Hold Time | t _h | | -3 | 0 | 0 | 0 | ns | | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF | | |
| Maximum Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | pF | | |
| Power Dissipation Capacitance * | C _{PD} | | | | | | pF | | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

†† This setup time ensures the register will see stable data from the register output.

Preliminary Specifications

FEATURES

- 8-Bit Parallel Storage Register Inputs
- shift Register has Direct Overriding Load and Clear
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
I_{OL} = 8 mA @ V_{OL} = 0.5V
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C

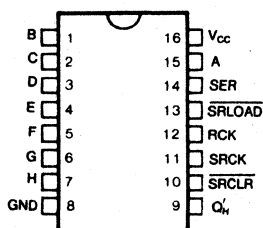
DESCRIPTION

The '597 consists of an 8-bit storage latch feeding a parallel-in, serial-out 8-bit shift register. Both the storage register and the shift register have positive-edge triggered clocks. The shift register also has direct load (from storage) and clear inputs.

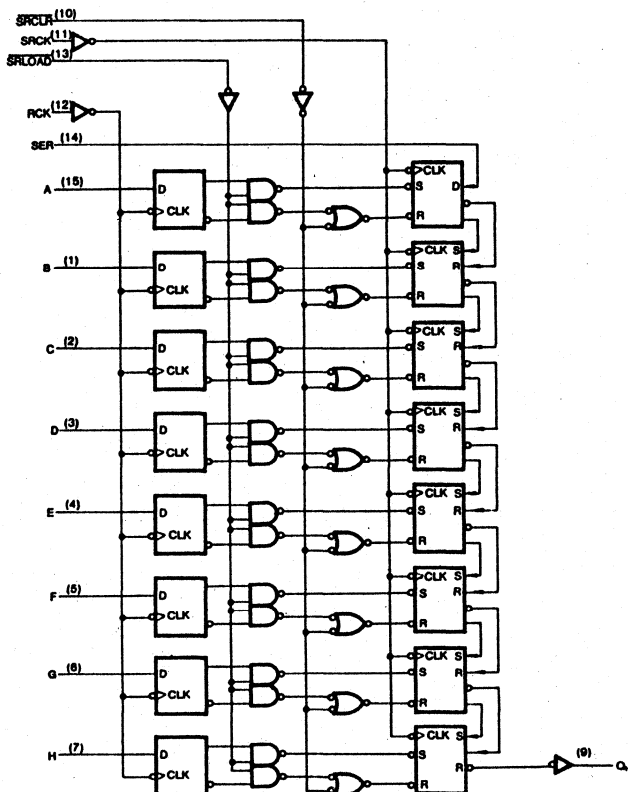
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



LOGIC DIAGRAM



Absolute Maximum Ratings*

| | | |
|--|-------|-----------------|
| Supply Voltage Range V_{CC} | | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | | ± 20 mA |
| DC Output Diode Current, I_{OK} | | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | | ± 20 mA |
| Continuous Output Current Per Pin, I_O | | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | | ± 35 mA |
| Continuous Current Through | | |
| V_{CC} or GND pins | | ± 125 mA |
| Storage Temperature Range, T_{stg} | | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | | |
|--|------------|-----------------|
| Supply Voltage, V_{CC} | | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | | 0V to V_{CC} |
| Operating Temperature | | |
| Range | KS74HCTLS: | -40°C to +85°C |
| | KS54HCTLS: | -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|----------------------|---------------------|---------------|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-4\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=4\text{mA}$ $I_O=8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS597

| Characteristic | Symbol | Conditions [†] | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit | |
|--|---|-------------------------|--|-------------------|--|---|------|----|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Guaranteed Limits | | | | |
| Maximum Clock Frequency | f_{\max} | | 35 | 25 | 20 | 20 | MHz | |
| Maximum Propagation Delay, SRCK \uparrow to Q' $_H$ | t_{PLH} | $C_L = 50\text{pF}$ | 15 | 18 | 25 | 30 | ns | |
| | t_{PHL} | | 15 | 18 | 25 | 30 | | |
| Maximum Propagation Delay, SRLOAD \downarrow to Q' $_H$ | t_{PLH} | | 18 | 29 | 30 | 36 | ns | |
| | t_{PHL} | | 18 | 24 | 30 | 36 | | |
| Maximum Propagation Delay, SRCLR \downarrow to Q' $_H$ | t_{PHL} | | | 17 | 22 | 28 | 33 | ns |
| Maximum Propagation Delay, RCK \uparrow to Q' $_H$ | t_{PLH} | | $C_L = 50\text{pF}$ SLOAD=Low | 21 | 29 | 35 | 42 | ns |
| | t_{PHL} | 21 | | 29 | 35 | 42 | | |
| Minimum Pulse Width | RCK or SRCK High or Low | t_w | 12 | 16 | 20 | 24 | ns | |
| | SRCLR or SRLOAD Low | | 12 | 16 | 20 | 24 | | |
| | SRCLR \uparrow before SRCK \uparrow | | 12 | 16 | 20 | 24 | | |
| Minimum Setup Time | RCK \uparrow before SRCK \uparrow \uparrow | t_{su} | 24 | 32 | 40 | 48 | ns | |
| | SER before SRCK \uparrow | | 12 | 16 | 20 | 24 | | |
| | A thru H before RCK \uparrow | | 12 | 16 | 20 | 24 | | |
| Minimum Hold Time | t_h | | -3 | 0 | 0 | 0 | ns | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

[†] For AC switching test circuits and timing waveforms see section 2.

$\uparrow\uparrow$ The RCK \uparrow before SRCK \uparrow setup time ensures that shift register will see stable data coming from the register output.

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface**
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
 KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
 KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

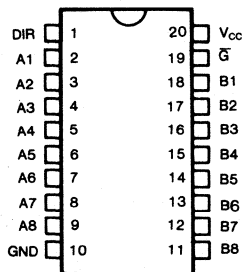
DESCRIPTION

These high-speed octal/bus transceivers are designed for asynchronous two-way communication between data buses. A direction control input (DIR) controls the flow direction of data. When DIR is high, data flows from the A inputs to the B outputs. When DIR is low, data flows from B to A. The '643 transfers inverted data from the A bus to the B bus and non-inverted data from the B bus to the A bus. The '640 transfers inverted data in both directions.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

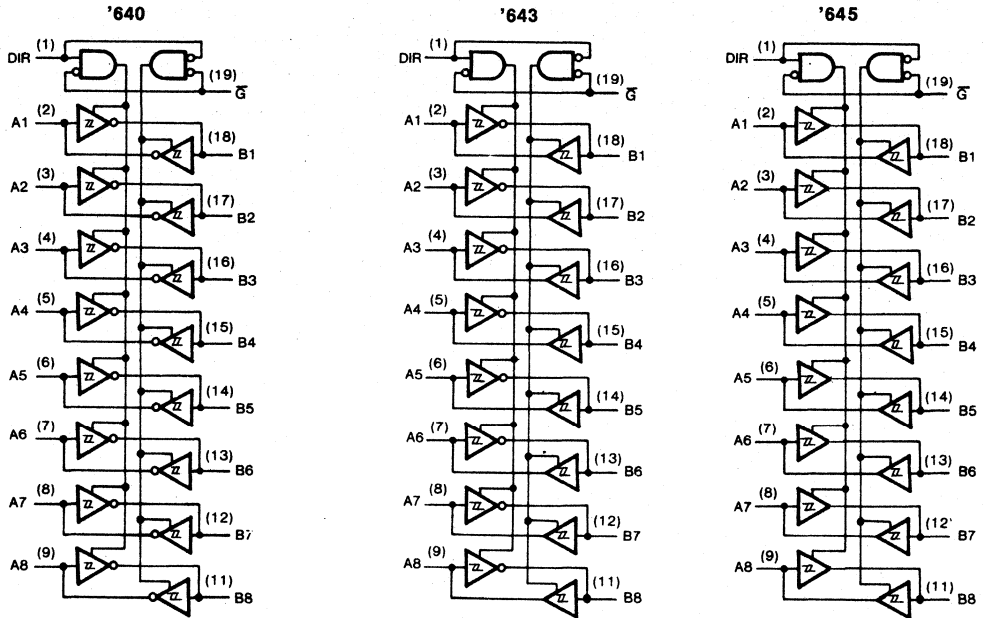
PIN CONFIGURATION



FUNCTION TABLE

| Control Inputs | | Operation | | |
|----------------|-----|---|---|---------------------------------------|
| \bar{G} | DIR | '640 | '643 | '645 |
| L | L | Inverted data transmitted from Bus B to Bus A | Data transmitted from Bus B to Bus A | Data transmitted from Bus B to Bus A |
| L | H | Inverted data transmitted from Bus A to Bus B | Inverted data transmitted from Bus A to Bus B | Data transmitted from Bus A to Bus B |
| H | X | Buses isolated (High-impedance state) | Buses isolated (High-impedance state) | Buses isolated (High-impedance state) |

LOGIC DIAGRAMS



Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} , -0.5V to +7V
- DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
- DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
- Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
- Continuous Current Through
 V_{CC} or GND pins ± 250 mA
- Storage Temperature Range, T_{stg} -65°C to +150°C
- Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

- † Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
- Operating Temperature
Range
KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C
- Input Rise & Fall Times, t_r , t_f Max 500 ns
- * Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|---|--------------------------|----------------------|--|---------------------|---|---------------------|---------------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | $V_{CC}-0.1$ 3.7 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.33 0.5 | 0.1 0.4 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 5.0 | ± 10.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 80.0 | 160.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 2.9 | 3.0 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS640, HCTLS643, HCTLS645

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC}=5.0\text{V}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC}=5.0\text{V} \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC}=5.0\text{V} \pm 10\%$ | | Unit | |
|---|-----------|---|--|-------------------|---|----|--|----|------|----|
| | | | Typ | Guaranteed Limits | | | | | | |
| Maximum Propagation Delay, A to B, or B to A | t_{PLH} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 9 | 12 | 16 | 19 | 16 | 19 | ns | |
| | | | 12 | 19 | 25 | 30 | 25 | 30 | | |
| | t_{PHL} | $C_L=50\text{pF}$ $C_L=150\text{pF}$ | 9 | 12 | 16 | 19 | 16 | 19 | ns | |
| | | | 12 | 19 | 25 | 30 | 25 | 30 | | |
| Maximum Output Enable Time, \bar{G} or DIR to A or B | t_{PZH} | $R_L=1\text{k}\Omega$ | $C_L=50\text{pF}$ | 30 | 40 | 50 | 60 | 50 | 60 | ns |
| | | | $C_L=150\text{pF}$ | 36 | 47 | 59 | 71 | 59 | 71 | |
| | t_{PZL} | $R_L=1\text{k}\Omega$ | $C_L=50\text{pF}$ | 3 | 40 | 50 | 60 | 50 | 60 | ns |
| | | | $C_L=150\text{pF}$ | 36 | 47 | 59 | 71 | 59 | 71 | |
| Maximum Output Disable Time, \bar{G} or DIR to A or B | t_{PHZ} | $R_L=1\text{k}\Omega$ | 20 | 27 | 34 | 40 | 34 | 40 | ns | |
| | | | 20 | 27 | 34 | 40 | 34 | 40 | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | | pF | |
| Maximum Output Capacitance | C_{OUT} | Output disabled | 10 | | | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C_{PD} | $\bar{G}=V_{CC}$ $\bar{G}=GND$ | 5 | | | | | | pF | |
| | | | 30 | | | | | | | |

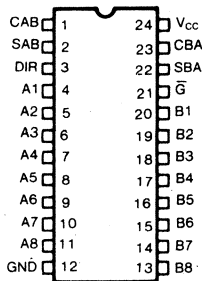
* C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

FEATURES

- 8 bi-directional data paths
- Transmits direct or stored data in either direction
- 24-pin 0.3" slim DIP package
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
 KS74AHCT: -40°C to $+85^{\circ}\text{C}$
 KS54HACT: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



DESCRIPTION

The '646 and '648 are bi-directional bus transceivers with D-type flip-flops and control circuitry to facilitate high speed multiplexed data transmission. The '648 transmits true data and the '646 transmits inverted data.

Data can be transmitted directly from one port to the other in either direction. It also can be stored in the flip-flops from either or both ports for subsequent transmission to the opposite port. Six control inputs govern the data flow:

\bar{G} (output enable) when high, all outputs are disabled, isolating the A and B ports. When low, one port is enabled at a time as determined by the DIR pin.

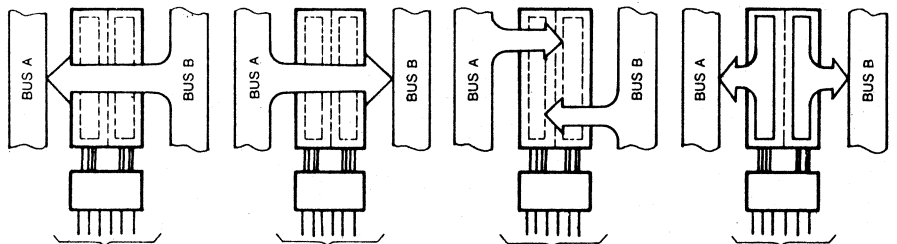
DIR (direction control) disables A or B outputs permitting the pins to be used as inputs thus determining the direction of a data flow. When DIR=high, data flows from A to B.

SAB,SBA (data source AB and BA) determines whether data transmitted is from the data inputs or the registers associated with those inputs.

CAB,CBA (Clock AB and BA) clocks data from the A inputs and the B inputs, respectively, into their associated registers. Since the clocks are not gated with the \bar{G} and DIR pins, data at the A and B pins can be clocked into the flip-flops at any time.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.



| | | | | | |
|-----------|-----|-----|------|-----|------|
| (21) | (3) | (1) | (23) | (2) | (22) |
| \bar{G} | DIR | CAB | CBA | SAB | SBA |
| L | L | X | X | X | L |

Real-Time transfer bus B to bus A

| | | | | | |
|-----------|-----|-----|------|-----|------|
| (21) | (3) | (1) | (23) | (2) | (22) |
| \bar{G} | DIR | CAB | CBA | SAB | SBA |
| L | H | X | X | L | X |

Real-Time transfer bus A to bus B

| | | | | | |
|-----------|-----|-----|------|-----|------|
| (21) | (3) | (1) | (23) | (2) | (22) |
| \bar{G} | DIR | CAB | CBA | SAB | SBA |
| X | X | X | X | X | X |
| X | X | X | X | X | X |
| H | X | X | X | X | X |

Storage from A AND/OR B

| | | | | | |
|-----------|-----|-----|------|-----|------|
| (21) | (3) | (1) | (23) | (2) | (22) |
| \bar{G} | DIR | CAB | CBA | SAB | SBA |
| L | L | X | X | X | H |
| L | H | X | X | H | X |

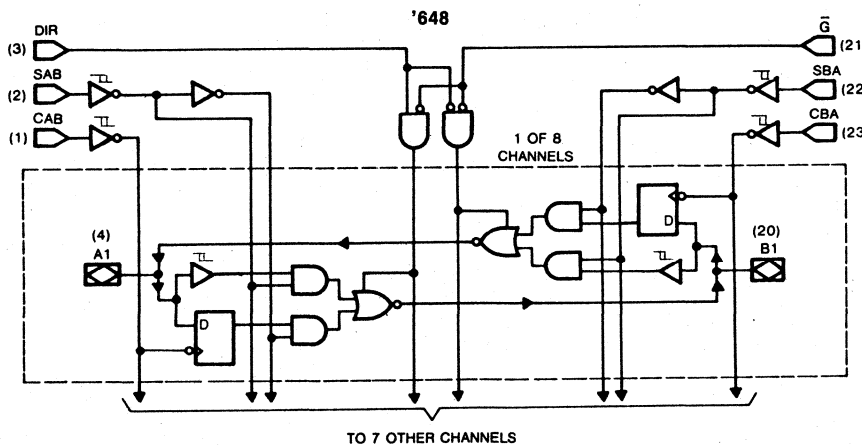
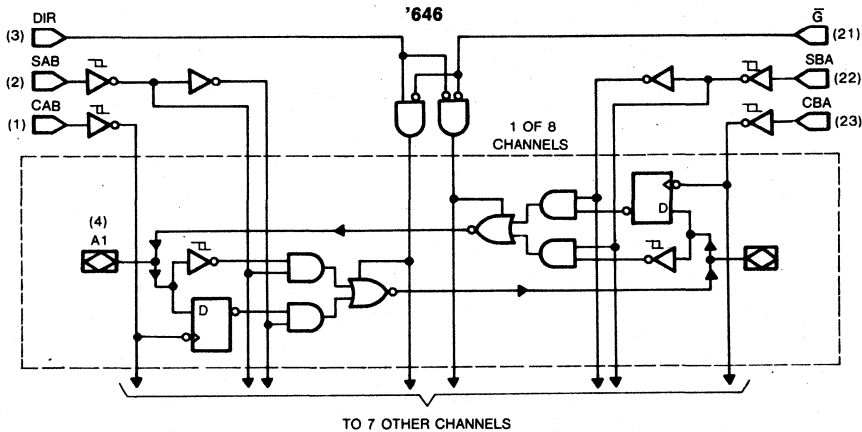
Transfer stored data to A AND/OR B

FUNCTION TABLE

| Inputs | | | | | | Data I/O* | | Operation or Function | |
|-----------|-----|--------|--------|-----|-----|---------------|---------------|---------------------------|-----------------------------------|
| \bar{G} | DIR | CAB | CBA | SAB | SBA | A1 thru A8 | B1 thru B8 | '646 | '648 |
| X | X | ↑ | X | X | X | input | input | Store A, B unspecified | Store A, B unspecified |
| X | X | X | ↑ | X | X | Not specified | Not specified | Store B, A unspecified | Store B, A unspecified |
| H | X | ↑ | ↑ | X | X | Input | Input | Store A and B data | Store A and B data |
| H | X | H or L | H or L | X | X | Input | Input | Isolation, hold storage | isolation, hold storage |
| L | L | X | X | X | L | Output | Input | Real-Time B data to A bus | Real-Time \bar{B} data to A bus |
| L | L | X | H or L | X | H | Output | Input | Stored B data to A bus | Stored \bar{B} data to A bus |
| L | H | X | X | L | X | Input | Output | Real-Time A data to B bus | Real-Time \bar{A} data to B bus |
| L | H | H or L | X | H | X | Input | Output | Stored A data to B bus | Stored \bar{A} data to B bus |

*The data output functions may be enabled or disabled by various signals at the \bar{G} and DIR inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every low-to-high transition on the clock inputs.

LOGIC DIAGRAMS



Absolute Maximum Ratings*

| | |
|--|-----------------|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 70 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

| | |
|----------------------|------------------------------|
| Plastic Package (N): | -12mW/°C from 65°C to 85°C |
| Ceramic Package (J): | -12mW/°C from 100°C to 125°C |

Recommended Operating Conditions

| | |
|--|----------------------------|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74HCTLS: -40°C to +85°C |
| | KS54HCTLS: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|--|---|---------------------|-------------------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Guaranteed Limits |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS646, HCTLS648

| Characteristic | Symbol | Conditions ¹ | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit | |
|--|-----------|-------------------------|--|-------------------|--|---|------|----|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Guaranteed Limits | | | | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 40 | 30 | 25 | 20 | MHz | |
| Maximum Propagation Delay, A or B Input to B or A Output | t_{PHL} | $C_L = 50\text{pF}$ | 14 | 19 | 24 | 29 | ns | |
| | | $C_L = 150\text{pF}$ | 12 | 26 | 33 | 40 | | |
| Maximum Propagation Delay, CBA or CAB Input to A or B Output | t_{PLH} | $C_L = 50\text{pF}$ | 14 | 19 | 24 | 29 | ns | |
| | | $C_L = 150\text{pF}$ | 17 | 26 | 33 | 40 | | |
| Maximum Propagation Delay, SBA or SAB input to A or B Output | t_{PLH} | $C_L = 50\text{pF}$ | 22 | 30 | 37 | 45 | ns | |
| | | $C_L = 150\text{pF}$ | 25 | 37 | 46 | 56 | | |
| Maximum Propagation Delay, $\uparrow\uparrow$ SBA or SAB input to A or B Output (with A or B High) | t_{PHL} | $C_L = 50\text{pF}$ | 26 | 35 | 44 | 53 | ns | |
| | | $C_L = 150\text{pF}$ | 29 | 42 | 53 | 64 | | |
| Maximum Propagation Delay, SBA or SAB Input to A or B Output (with A or B Low) | t_{PHL} | $C_L = 50\text{pF}$ | 26 | 35 | 44 | 53 | ns | |
| | | $C_L = 150\text{pF}$ | 29 | 42 | 53 | 64 | | |
| Maximum Output Enable Time, \bar{G} or DIR Input to A or B Output | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 33 | 45 | 56 | 67 | ns |
| | | | $C_L = 150\text{pF}$ | 39 | 52 | 65 | 78 | |
| Maximum Output Disable Time, \bar{G} or DIR Input to A or B Output | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 33 | 45 | 56 | 67 | ns |
| | | | $C_L = 150\text{pF}$ | 39 | 52 | 65 | 78 | |
| Maximum Output Disable Time, \bar{G} or DIR Input to A or B Output | t_{PHZ} | $R_L = 1\text{k}\Omega$ | | 26 | 35 | 44 | 53 | ns |
| | | | $C_L = 50\text{pF}$ | 26 | 35 | 44 | 53 | |
| Pulse Duration, Clocks High or Low | t_w | | 10 | 13 | 17 | 20 | ns | |
| Setup Time, A before CAB \uparrow or B before CBA \uparrow | t_{su} | | 10 | 13 | 17 | 20 | ns | |
| Hold Time, A after CAB \uparrow or B after CBA \uparrow | t_h | | -3 | 0 | | 0 | ns | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF | |
| Maximum Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

[†] For AC switching test circuits and timing waveforms see section 2.

^{††} These parameters are measured with the internal output state of the storage register opposite to that of the bus input.

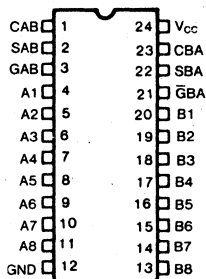
5

Preliminary Specifications

FEATURES

- Independent Registers and Enables for A and B Buses
- Multiplexed Real-Time and Stored Data
- Choice of Time and Inverting Data Paths
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



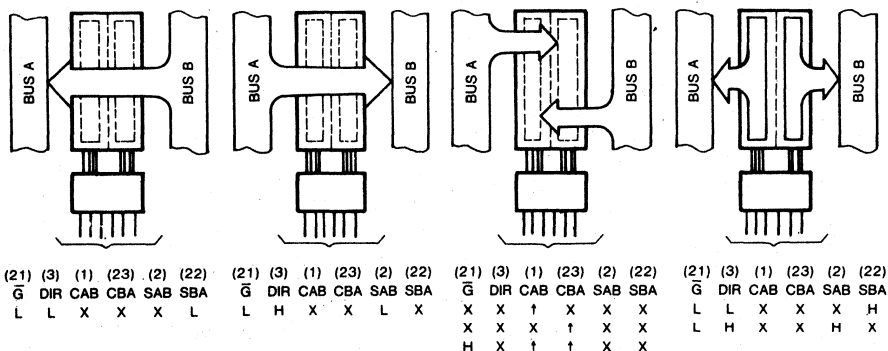
DESCRIPTION

These devices consist of bus transceiver circuits, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the data bus or from the internal storage registers. Enable GAB and $\bar{G}BA$ are provided to control the transceiver functions. SAB and SBA control pins are provided to select whether real-time or stored data is transferred. A low input level selects real-time data, and a high selects stored data. The following examples demonstrate the four fundamental bus-management functions that can be performed with the octal bus transceivers and registers.

Data on the A or B data bus, or both, can be stored in the internal D flip-flops by low-to-high transitions at the appropriate clock pins (CAB or CBA) regardless of the select or enable control pins. When SAB and SBA are in the real-time transfer mode, it is also possible to store data without using the internal D-type flip-flops by simultaneously enabling GAB and $\bar{G}BA$. In this configuration each output reinforces its input. Thus, when all other data sources to the two sets of bus lines are at high impedance, each set of bus lines will remain at its last state.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.



Real-Time transfer
bus B to bus A

Real-Time transfer
bus A to bus B

Storage from
A AND/OR B

Transfer stored data
to A and/or B

FUNCTION TABLE

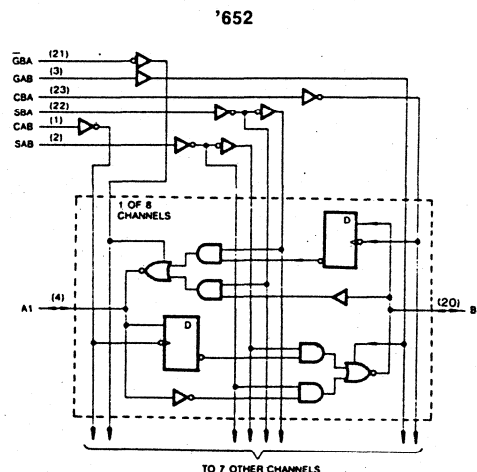
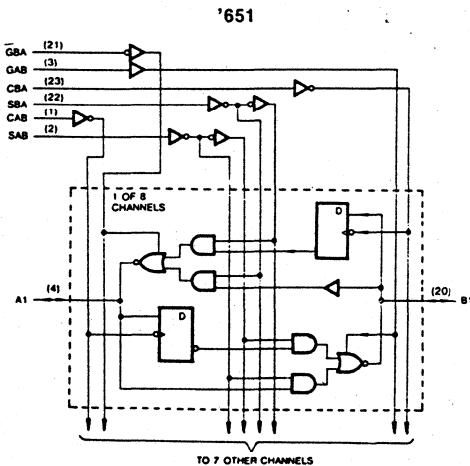
| INPUTS | | | | DATA I/O* | | OPERATION OR FUNCTION | | |
|--------|-------------|--------|--------|-----------|---------------|-----------------------|--|--|
| GAB | $\bar{G}BA$ | CAB | CBA | SAB SBA | A1 THRU A8 | B1 THRU B8 | '651 | '652 |
| L | H | H or L | H or L | X X | Input | Input | Isolation Store A and B Data | Isolation Store A and B Data |
| L | H | ↑ | ↑ | X X | Input | Not specified | Store A, Hold B Store A in both registers | Store A Hold B Store A in both registers |
| X | H | ↑ | H or L | X X | Input | Output* | Store A, Hold B Store A in both registers | Store A Hold B Store A in both registers |
| H | H | ↑ | ↑ | X** X | Input | Input | Store A, Hold B Store A in both registers | Store A Hold B Store A in both registers |
| L | X | H or L | ↑ | X X | Not specified | Input | Hold A, Store B Store B in both registers | Hold A, Store B Store B in both registers |
| L | L | ↑ | ↑ | X X** | Output* | Input | Hold A, Store B Store B in both registers | Hold A, Store B Store B in both registers |
| L | L | X | X | X L | Output | Input | Real-Time \bar{B} Data to A Bus Stored \bar{B} Data to A Bus | Real-Time B Data to a Bus Stored B Data to A Bus |
| L | L | X | H or L | X H | Output | Input | Real-Time \bar{B} Data to A Bus Stored \bar{B} Data to A Bus | Real-Time B Data to a Bus Stored B Data to A Bus |
| H | H | X | X | L X | Input | Output | Real-Time \bar{A} Data to B Bus Stored \bar{A} Data to B Bus | Real-Time A Data to B Bus Stored A Data to B Bus |
| H | H | H or L | X | H X | Input | Output | Real-Time \bar{A} Data to B Bus Stored \bar{A} Data to B Bus | Real-Time A Data to B Bus Stored A Data to B Bus |
| H | L | H or L | H or L | H H | Output | Output | Stored \bar{A} Data to B Bus and Stored \bar{B} Data to A Bus | Stored A Data to B Bus and Stored B Data to A Bus |

* The data output functions may be enabled or disabled by various signals at the GAB and $\bar{G}BA$ inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every low-to-high transition on the clock inputs.

** Select control=L: clocks can occur simultaneously

Select control=H: clocks must be staggered in order to load both registers

LOGIC DIAGRAMS



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to $+85^\circ\text{C}$
 KS54HCTLS: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------------|---|--|-----------------------|-------------------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | KS54HCTLS $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | Guaranteed Limits |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $= V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS651, HCTLS652

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit | | |
|---|-----------|-------------------------|--|---------------------|---|----|--|----|------|----|--|
| | | | Typ | | Guaranteed Limits | | | | | | |
| | | | | | | | | | | | |
| Maximum Clock Frequency | f_{max} | $C_L = 50\text{pF}$ | 40 | 30 | 25 | | 20 | | MHz | | |
| Maximum Propagation Delay, A or B Input to B or A Output | t_{PLH} | $C_L = 50\text{pF}$ | 14 | 19 | 24 | | 29 | | ns | | |
| | | $C_L = 150\text{pF}$ | 17 | 26 | 33 | | 20 | | | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 14 | 19 | 21 | | 20 | | ns | | |
| | | $C_L = 150\text{pF}$ | 17 | 26 | 33 | | 40 | | | | |
| Maximum Propagation Delay, CBA or CAB Input to A or B Output | t_{PLH} | $C_L = 50\text{pF}$ | 22 | 30 | 37 | | 45 | | ns | | |
| | | $C_L = 150\text{pF}$ | 25 | 37 | 46 | | 56 | | | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 22 | 30 | 37 | | 45 | | ns | | |
| | | $C_L = 150\text{pF}$ | 25 | 27 | 46 | | 56 | | | | |
| Maximum Propagation Delay, SBA or SAB Input to A or B Output (with A or B High) | t_{PLH} | $C_L = 50\text{pF}$ | 26 | 35 | 44 | | 53 | | ns | | |
| | | $C_L = 150\text{pF}$ | 29 | 42 | 53 | | 64 | | | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 26 | 35 | 44 | | 53 | | ns | | |
| | | $C_L = 150\text{pF}$ | 29 | 42 | 53 | | 64 | | | | |
| Maximum Propagation Delay, SBA or SAB Input to A or B Output (with A or B Low) | t_{PLH} | $C_L = 50\text{pF}$ | 26 | 35 | 44 | | 53 | | ns | | |
| | | $C_L = 150\text{pF}$ | 29 | 42 | 53 | | 64 | | | | |
| Maximum Output Enable Time, $\bar{G}BA$ to A or GAB to B | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 33 | 45 | 56 | | 67 | | ns | |
| | | | $C_L = 150\text{pF}$ | 39 | 52 | 65 | | 78 | | | |
| | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 33 | 45 | 56 | | 67 | | ns | |
| | | | $C_L = 150\text{pF}$ | 39 | 52 | 65 | | 78 | | | |
| Maximum Output Disable Time, $\bar{G}BA$ to A or GAB to B | t_{PHZ} | $R_L = 1\text{k}\Omega$ | | 26 | 35 | 44 | | 53 | | ns | |
| | | | t_{PLZ} | $C_L = 50\text{pF}$ | 26 | 35 | 44 | | 53 | | |
| Minimum Pulse Width Clocks High or Low | t_w | | 10 | 13 | 17 | | 20 | | ns | | |
| Minimum Setup Time, A before $CAB\uparrow$ or B before $CBA\uparrow$ | t_{su} | | 10 | 13 | 17 | | 20 | | ns | | |
| Minimum Hold Time, A after $CAB\downarrow$ or B after $CBA\downarrow$ | t_h | | -3 | 0 | 0 | | 0 | | ns | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | | pF | | |
| Maximum Output Capacitance | C_{OUT} | Output Disabled | | 10 | | | | | pF | | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | | pF | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

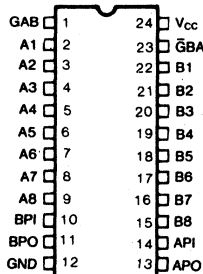
5

Preliminary Specifications

FEATURES

- Bus Transceivers with Inverting Outputs ('658) or True Outputs ('659)
- Generates a Parity Bit for A Bus and B Bus
- Easily Cascadable
- Internal Active Pull-Ups and Pull-Downs
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



DESCRIPTION

These octal bus transceivers are designed for asynchronous, bidirectional communication between data buses. The devices transmit data from the A Bus to the B Bus, or from the B Bus to the A Bus, depending on the levels at the direction control inputs, GAB and $\bar{G}BA$. These devices also generate parity outputs, APO and BPO, which reflect the number of high levels at the A Bus and B Bus, respectively, taking into account the parity inputs API and BPI.

The bidirectional I/O ports feature active circuits on the input stage that, when the output shared by that pin is disabled, will maintain the input in the last state taken by the output. This state will be maintained until changed by activity on the bus. The advantage of this arrangement is that when all outputs on the bus are disabled, the inputs will be prevented from floating, resulting in minimum power dissipation and minimum susceptibility to noise. This eliminates any need for external pull-up or pull-down resistors. The parity inputs API and BPI have similar circuits.

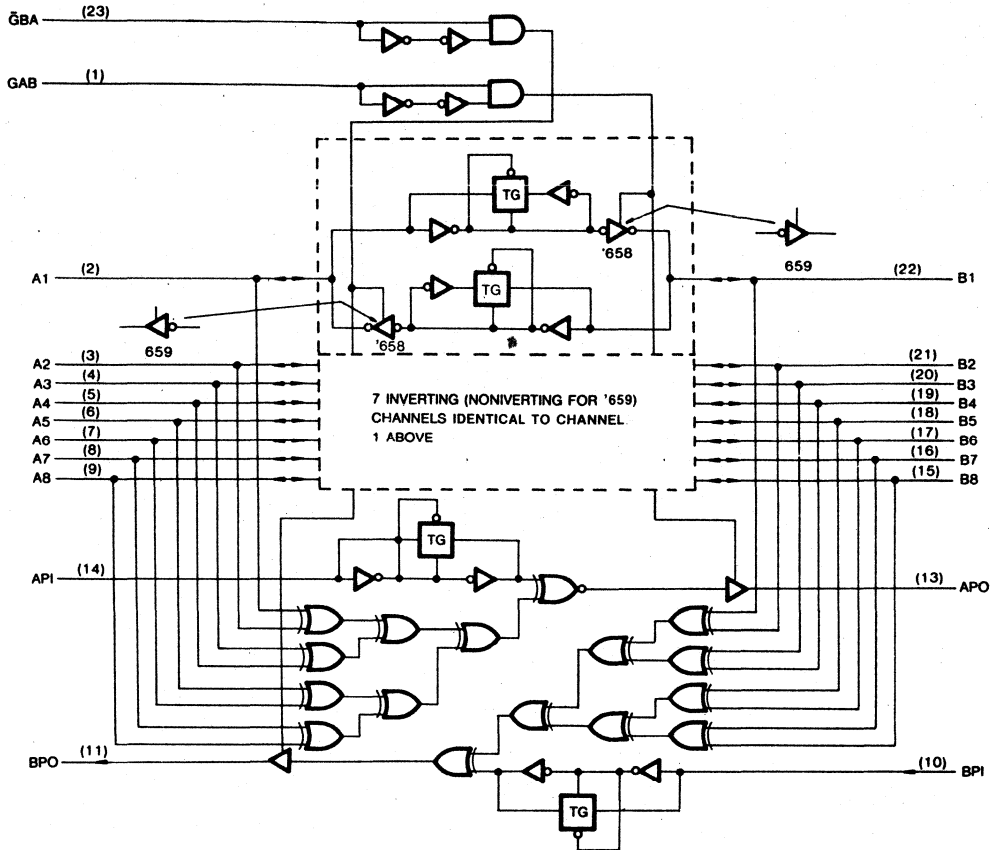
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLE

| CONTROL INPUTS | | NUMBER OF HIGH INPUTS ON A BUS AND API | NUMBER OF HIGH INPUTS ON B BUS AND BPI | OUTPUTS | | OPERATION | |
|----------------|-----|--|--|---------|-----|---|-------------------------------------|
| $\bar{G}BA$ | GAB | | | APO | BPO | HCTLS658 | HCTLS659 |
| L | L | X | 0, 2, 4, 6, 8 | Z | H | B Data to A Bus | B Data to A Bus |
| | | X | 1, 3, 5, 7, 9 | Z | L | | |
| H | H | 0, 2, 4, 6, 8 | X | H | Z | A Data to B Bus | A Data to B Bus |
| | | 1, 3, 5, 7, 9 | X | L | Z | | |
| H | L | X | X | Z | Z | Isolation | Isolation |
| L | H | X | 0, 2, 4, 6, 8 | | H | \bar{B} Data to A Bus, \bar{A} Data to B Bus | B Data to A Bus, A Data to B Bus |
| | | X | 1, 3, 5, 7, 9 | | L | | |
| | | 0, 2, 4, 6, 8 | X | H | | | |
| | | 1, 3, 5, 7, 9 | X | L | | | |

LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
 Operating Temperature
 Range
 KS74HCTLS: -40°C to $+85^\circ\text{C}$
 KS54HCTLS: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit | |
|--------------------------------------|-----------------|---|--------------------------|------------------------|---|--|---------------|--|
| | | | Typ | Guaranteed Limits | | | | |
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V | |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V | |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA | |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA | |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS658, HCTLS659

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--|-------------------------|-------------------------|--|-------------------|--|---|------|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | Guaranteed Limits | | | |
| Maximum Propagation Delay, A or B to B or A | t_{PLH} | $C_L = 50\text{pF}$ | 20 | 25 | 30 | 39 | ns |
| | | $C_L = 150\text{pF}$ | 23 | 31 | 39 | 50 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 20 | 25 | 30 | 39 | ns |
| | | $C_L = 150\text{pF}$ | 23 | 31 | 39 | 50 | |
| Maximum Propagation Delay, A or B to A | t_{PLH} | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | ns |
| | | $C_L = 150\text{pF}$ | 27 | 39 | 40 | 59 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | ns |
| | | $C_L = 150\text{pF}$ | 27 | 39 | 49 | 59 | |
| Maximum Propagation Delay A or B to APO or BPO | t_{PLH} | $C_L = 50\text{pF}$ | 20 | 25 | 30 | 39 | ns |
| | | $C_L = 150\text{pF}$ | 23 | 31 | 39 | 50 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 20 | 25 | 30 | 39 | ns |
| | | $C_L = 150\text{pF}$ | 23 | 31 | 39 | 50 | |
| Maximum Enable Time, GAB or $\bar{G}BA$ to APO or BPO | t_{PZH} | $C_L = 50\text{pF}$ | 20 | 25 | 30 | 39 | ns |
| | | $C_L = 150\text{pF}$ | 26 | 31 | 39 | 50 | |
| | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 20 | 25 | 30 | 39 | |
| | | $C_L = 150\text{pF}$ | 26 | 31 | 39 | 50 | |
| Maximum Disable Time, GAB or $\bar{G}BA$ to APO or BPO | t_{PLZ} | $R_L = 1\text{k}\Omega$ | 20 | 25 | 30 | 39 | ns |
| | | $C_L = 50\text{pF}$ | 20 | 25 | 30 | 39 | ns |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Maximum Output Capacitance | C_{OUT} | | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

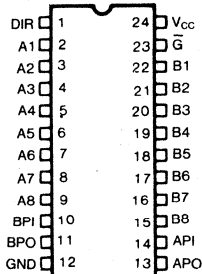
† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Bus Transceivers with Inverting Outputs ('664) or True Outputs ('665)
- Generates a Parity Bit for A Bus and B Bus
- Easily Cascadable
- Internal Active Pull-Ups and Pull-Downs
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATION



FUNCTION TABLE

| CONTROL INPUTS | | NUMBER OF HIGH INPUTS ON A BUS AND API | NUMBER OF HIGH INPUTS ON B BUS AND BPI | OUTPUTS | | OPERATION | |
|----------------|-----|--|--|---------|-----|-------------------------|-----------------|
| \bar{G} | DIR | | | APO | BPO | '664 | '665 |
| L | L | X | 0, 2, 4, 6, 8 | Z | H | \bar{B} Data to A Bus | B Data to A Bus |
| | | X | 1, 3, 5, 7, 9 | Z | L | | |
| L | H | 0, 2, 4, 6, 8 | X | H | Z | \bar{A} Data to B Bus | A Data to B Bus |
| | | 1, 3, 5, 7, 9 | X | L | Z | | |
| H | X | X | X | Z | Z | Isolation | Isolation |

DESCRIPTION

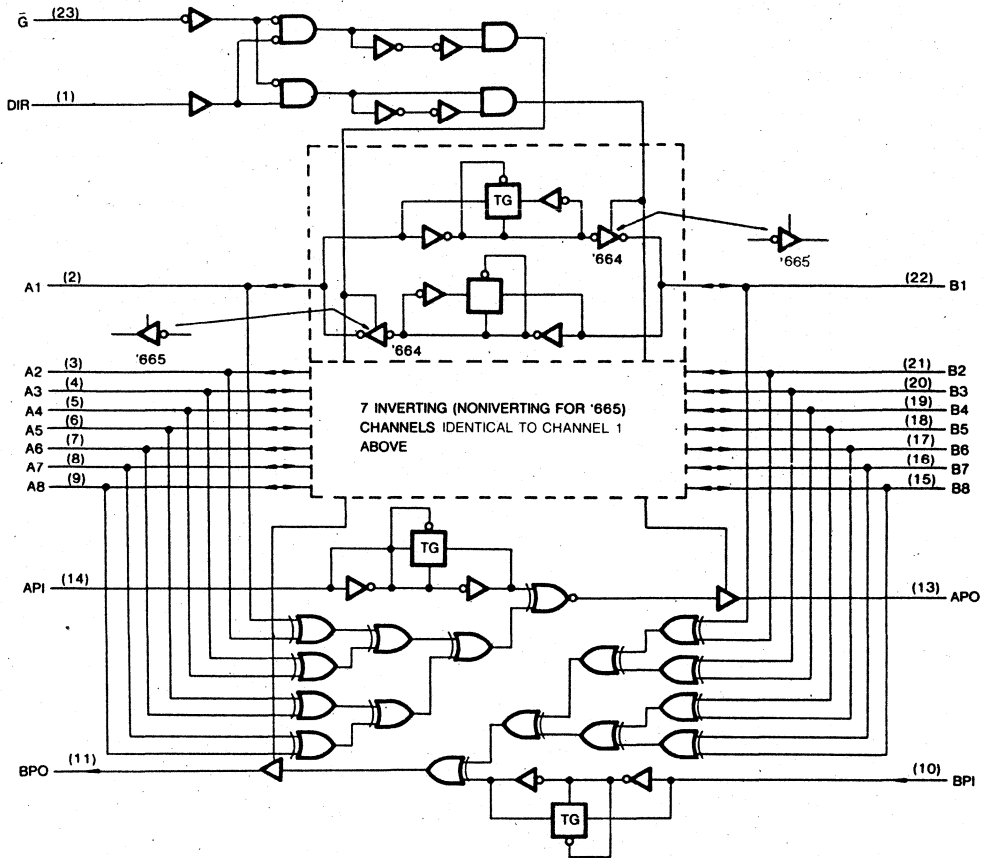
These octal bus transceivers are designed for asynchronous, bidirectional communication between data buses. The devices transmit data from the A Bus to the B Bus or from the B Bus to the A Bus, depending on the level at the direction control input, DIR. The enable input, \bar{G} can be used to disable the device so that the buses are isolated. These devices will also generate parity outputs, APO and BPO, which reflect the number of high levels at the A Bus and B Bus, respectively, taking into account the parity inputs API and BPI.

The bidirectional I/O ports feature active circuitry on the input stage that, when the output shared by that pin is disabled, will maintain the input in the last state taken by the output. This state will be maintained until changed by the activity on the bus. The advantage of this arrangement is that when all outputs on the bus are disabled, the inputs will be prevented from floating, resulting in minimum power dissipation and minimum susceptibility to noise. This eliminates any need for external pull-up or pull-down resistors. The parity inputs API and BPI have similar circuitry.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

LOGIC DIAGRAM



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Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V.
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to $+85^\circ\text{C}$
 KS54HCTLS: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V\pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|---|--------------------------|------------------------|--|-----------------------|---|-----------------------|---------------|
| | | | Typ | Guaranteed Limits | | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | $V_{CC} - 0.1$ 3.7 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.33 0.5 | 0.1 0.4 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $= V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 5.0 | ± 10.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 80.0 | 160.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4\text{V}$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 2.9 | 3.0 | 3.0 | mA |



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns, HCTLS664/655)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit | |
|---|-----------|---|--|-------------------|--|---|------|----|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | |
| | | | Typ | Guaranteed Limits | | | | |
| Maximum Propagation Delay, A or B to B or A | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 20 | 25 | 30 | 39 | ns | |
| | | | 23 | 32 | 39 | 50 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 20 | 25 | 30 | 39 | ns | |
| | | | 23 | 32 | 39 | 50 | | |
| Maximum Propagation Delay, A or B to APO or BPO | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 24 | 32 | 40 | 48 | ns | |
| | | | 27 | 39 | 49 | 50 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 24 | 32 | 40 | 48 | ns | |
| | | | 27 | 30 | 49 | 59 | | |
| Maximum Propagation Delay, API or BPI to APO or BPO | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 20 | 25 | 30 | 39 | ns | |
| | | | 23 | 32 | 39 | 50 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 20 | 25 | 30 | 39 | ns | |
| | | | 23 | 32 | 39 | 50 | | |
| Maximum Output Enable Time, \bar{G} to A or B | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | ns |
| | | | $C_L = 150\text{pF}$ | 30 | 38 | 49 | 59 | |
| | t_{PZL} | | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | |
| | | | $C_L = 150\text{pF}$ | 30 | 39 | 49 | 59 | |
| Maximum Output Delay Time, \bar{G} to A or B | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 24 | 32 | 40 | 48 | ns | |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 24 | 22 | 40 | 50 | | |
| Maximum Output Enable Time DIR to A or B | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | ns |
| | | | $C_L = 150\text{pF}$ | 30 | 39 | 49 | 59 | |
| | t_{PZH} | | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | |
| | | | $C_L = 150\text{pF}$ | 30 | 30 | 40 | 50 | |
| Maximum Output Disable Time, DIR to A or B | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 20 | 32 | 40 | 48 | ns | |
| | t_{HLZ} | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF | |
| Maximum Output Capacitance | C_{OUT} | Output Disabled | 10 | | | | pF | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

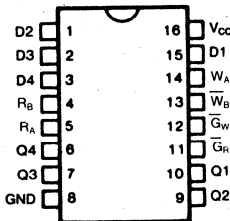
5

Preliminary Specifications

FEATURES

- Separate Read/Write Addressing Permits Simultaneous Reading and Writing
- Expandable to 512 Words of N-bits
- For use as:
 - Scratch pad memory
 - Buffer storage between processors
 - Bit storage in fast multiplication designs
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^\circ\text{C}$
KS54HCTLS: -55°C to $+125^\circ\text{C}$

PIN CONFIGURATION



FUNCTION TABLES

WRITE MODE SELECT TABLE

| OPERATING MODE | INPUTS | | INTERNAL LATCHES ^(a) |
|----------------|-------------|-------|---------------------------------|
| | \bar{G}_W | D_n | |
| Write Data | L | L | L |
| | L | H | H |
| Data Latched | H | X | no change |

NOTE:

- a. The Write Address (W_A and W_B) to the "Internal latches" must be stable while \bar{G}_W is LOW for conventional operation.

DESCRIPTION

The '670 is a 16-bit 3-State Register File organized as 4 words of 4 bits each. Separate Read and Write Address and Enable Inputs are available, permitting simultaneous writing into one word location and reading from another location. The 4-bit word to be stored is presented to four Data inputs. The Write Address inputs (W_A and W_B) determine the location of the stored word. When the write enable (\bar{G}_W) input is LOW, the data is entered into the addressed location. The addressed location remains transparent to the data while the \bar{G}_W is LOW. Data supplied at the inputs will be read out in true (non-inverting) form from the 3-State outputs. Data and Write Address inputs are inhibited when \bar{G}_W is HIGH.

Direct acquisition of data stored in any of the four registers is made possible by individual Read Address inputs (R_A and R_B). The addressed word appears at the four outputs when the read enable (\bar{G}_R) is LOW. Data outputs are in the HIGH impedance "off" state when the read enable input is HIGH. This permits outputs to be tied together to increase the word capacity to very large numbers.

Up to 128 devices can be stacked to increase the word size to 512 locations by tying the 3-State outputs together. Since the limiting factor for expansion is the output HIGH current, further stacking is possible by tying pull-up resistors to the outputs to increase the I_{OH} current available. Design of the read enable signals for the stacked devices must ensure that there is no overlap in the LOW levels which would cause more than one output to be active at the same time. Parallel expansion to generate n-bit words is accomplished by driving the Enable and Address inputs of each device in parallel.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

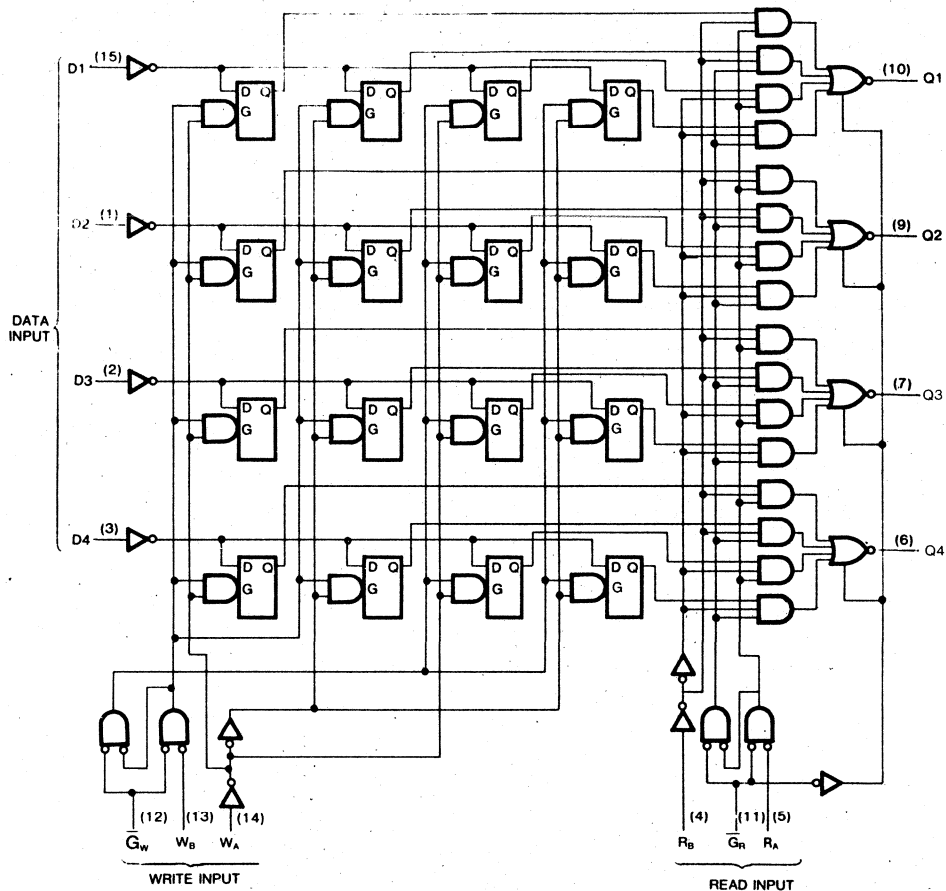
READ MODE SELECT TABLE

| OPERATING MODE | INPUTS | | OUTPUT Q_n |
|----------------|-------------|---------------------------------|--------------|
| | \bar{G}_R | INTERNAL LATCHES ^(b) | |
| Read | L | L | L |
| | L | H | H |
| Disabled | H | H | (Z) |

NOTE:

- b. The selection of the "internal latches" by Read Address (R_A and R_B) are not constrained by \bar{G}_W or \bar{G}_R operation.

LOGIC DIAGRAM



5

Absolute Maximum Ratings*

- Supply Voltage Range V_{CC} -0.5V to +7V
- DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
- DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
- Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
- Continuous Current Through
 V_{CC} or GND pins ± 250 mA
- Storage Temperature Range, T_{stg} -65°C to +150°C
- Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

- † Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

- Supply Voltage, V_{CC} 4.5V to 5.5V
- DC Input & Output Voltages*, V_{IN}, V_{OUT} ... 0V to V_{CC}
- Operating Temperature
 Range KS74HCTLS: -40°C to +85°C
 KS54HCTLS: -55°C to +125°C
- Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|---|--------------------------|----------------------|----------------------|---------------------|---------------|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4\text{V}$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTL5670

| Characteristic | Symbol | Conditions [†] | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTL5 | KS54HCTL5 | Unit |
|--|-----------|---|--|----------|--|---|------|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Propagation Delay, R_A or R_B to Output | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 20 27 | 32 39 | 40 49 | 48 59 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 20 27 | 32 39 | 40 49 | 48 59 | |
| Maximum Propagation Delay, G_W to Output | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 36 30 | 45 43 | 54 54 | 65 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 27 30 | 36 48 | 45 54 | 59 65 | |
| Maximum Propagation Delay, Data to Output | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 27 30 | 36 43 | 45 54 | 59 65 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 27 30 | 36 43 | 45 59 | 54 65 | |
| Maximum Output Enable Time, \overline{G}_R to Output | t_{PZH} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 24 | 32 | 40 | ns |
| | | | $C_L = 150\text{pF}$ | 30 | 39 | 49 | |
| | t_{PZL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 24 30 | 32 39 | 40 49 | 48 59 | |
| Maximum Output Disable Time, \overline{G}_R to Output | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 24 | 32 | 40 | 48 | ns |
| | t_{PLZ} | $C_L = 150\text{pF}$ | 24 | 32 | 40 | 48 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Maximum Output Capacitance | C_{OUT} | Output disabled | 10 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- '679: 12-bit to 4-bit comparator with enable
- '680: 12-bit to 4-bit comparator with latch
- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

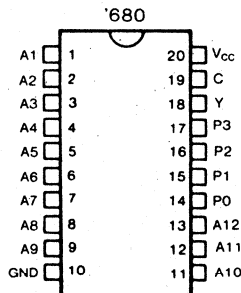
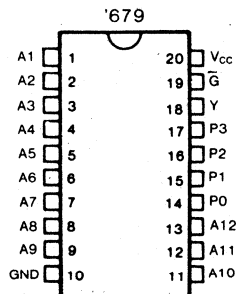
The '679 and '680 address comparators simplify addressing of memory boards and/or other peripheral devices. The four P inputs are normally hard wired with a preprogrammed address. An internal decoder determines what input information applied to the 12 A inputs must be low or high to cause a low state at the output (Y). For example, a positive-logic bit combination of 0111 (decimal 7) at the P input determines that inputs A1 through A7 must be low and that inputs A8 through A12 must be high to cause the output to go low. Equality of the address applied at the A inputs to the preprogrammed address is indicated by the output being low.

The '679 features an enable input (\bar{G}). When \bar{G} is low, the device is enabled. When \bar{G} is high, the device is disabled and the output is high regardless of the A and P inputs. The '680 features a transparent latch and a latch enable input (C). When C is high, the device is in the transparent mode. When C is low, the previous logical state of Y is latched.

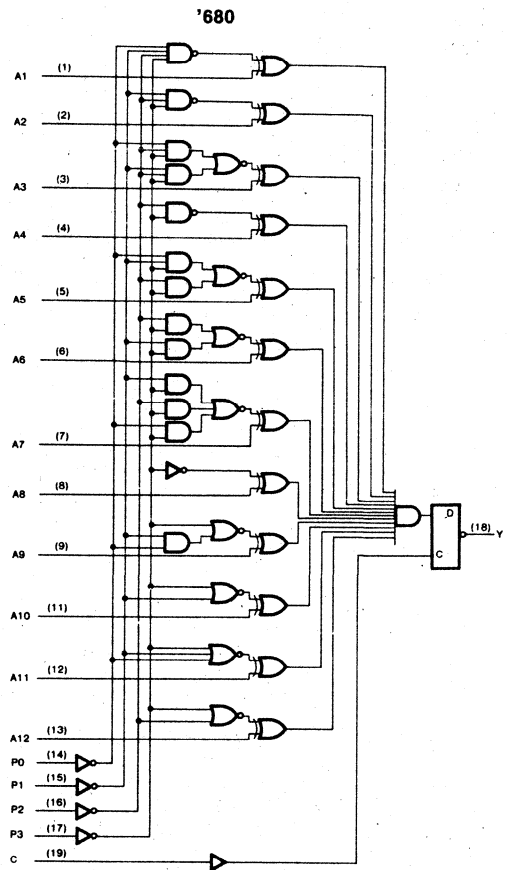
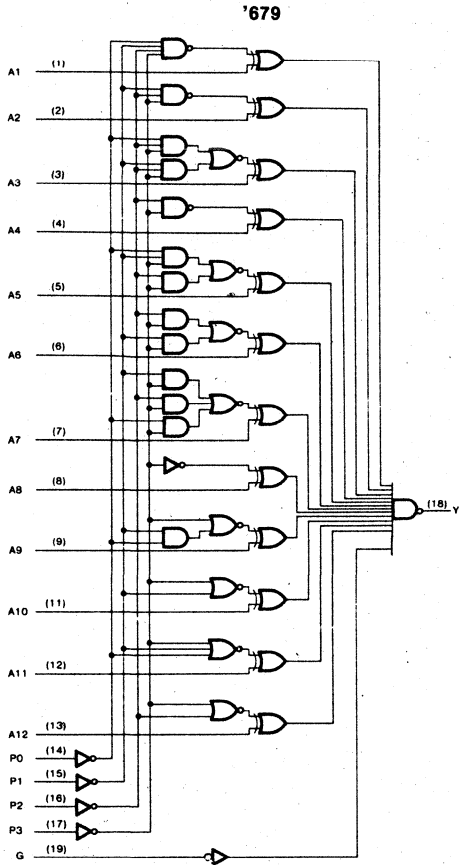
These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATIONS



LOGIC DIAGRAMS



5

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------|----------------------|----------------------|--------------------------------------|---------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ C$ to $+85^\circ C$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-6mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=12mA$ $I_O=24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS679

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ C$ | | KS74HCTLS | KS54HCTLS | Unit |
|---------------------------------------|-----------|-------------|--------------------|-------------------|-----------|--------------------------------------|------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ C$ to $+85^\circ C$ | |
| Maximum Propagation Delay, Any P to Y | t_{PLH} | $C_L=50pF$ | 24 | 32 | 40 | 48 | ns |
| | | $C_L=150pF$ | 27 | 39 | 49 | 50 | |
| | t_{PHL} | $C_L=50pF$ | 27 | 32 | 40 | 48 | ns |
| | | $C_L=150pF$ | 30 | 39 | 49 | 59 | |
| Maximum Propagation Delay, Any A to Y | t_{PLH} | $C_L=50pF$ | 21 | 28 | 35 | 42 | ns |
| | | $C_L=150pF$ | 24 | 35 | 44 | 53 | |
| | t_{PHL} | $C_L=50pF$ | 21 | 28 | 35 | 42 | ns |
| | | $C_L=150pF$ | 24 | 35 | 44 | 53 | |
| Maximum Propagation Delay, G to Y | t_{PLH} | $C_L=50pF$ | 18 | 24 | 30 | 36 | ns |
| | | $C_L=150pF$ | 21 | 31 | 39 | 47 | |
| | t_{PHL} | $C_L=50pF$ | 18 | 24 | 30 | 36 | ns |
| | | $C_L=150pF$ | 21 | 31 | 39 | 47 | |
| Maximum Input Capacitance | C_{IN} | | | 5 | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

AC ELECTRICAL CHARACTERISTICS (Input t_r , $t_f \leq 6$ ns), HCTLS680

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--|-----------|----------------------|--|----|--|---|------|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Propagation Delay, Any P to Y | t_{PLH} | $C_L = 50\text{pF}$ | 27 | 36 | 45 | 54 | ns |
| | | $C_L = 150\text{pF}$ | 30 | 43 | 54 | 65 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 27 | 32 | 40 | 48 | |
| | | $C_L = 150\text{pF}$ | 30 | 39 | 49 | 59 | |
| Maximum Propagation Delay, Any A to Y | t_{PLH} | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | ns |
| | | $C_L = 150\text{pF}$ | 27 | 39 | 49 | 59 | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 24 | 32 | 40 | 48 | |
| | | $C_L = 150\text{pF}$ | 27 | 30 | 49 | 59 | |
| Maximum Propagation Delay, C to Y | t_{PLH} | $C_L = 50\text{pF}$ | 19 | 26 | 32 | 38 | ns |
| | | $C_L = 150\text{pF}$ | 22 | 33 | 39 | 49 | |
| | | | 19 | 26 | 32 | 38 | |
| | | | 22 | 33 | 39 | 49 | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Compares Two 8-Bit Words
- '682 has 20k Ω pull-up Resistors on the Q Inputs
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High drive current outputs:
($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

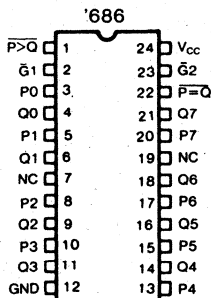
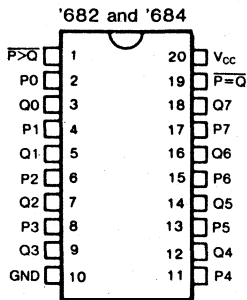
DESCRIPTION

These magnitude comparators perform comparisons of two eight-bit binary or BCD words. All types provide $\overline{P=Q}$ and $\overline{P>Q}$ outputs. The '682 features 20-k Ω pull-up termination resistors on the Q inputs for analog or switch data.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge, by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATIONS



NC—No internal connection

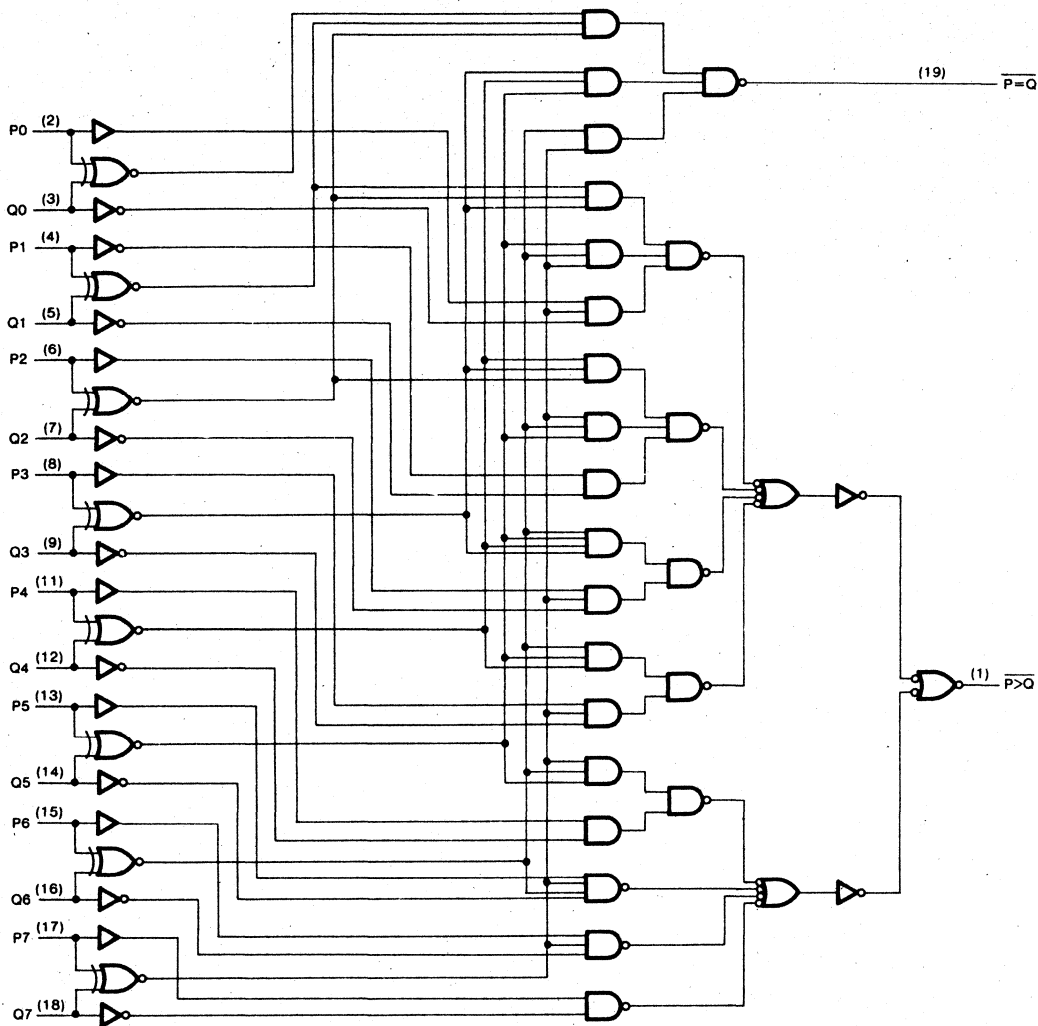
FUNCTION TABLE

| DATA | INPUTS | | OUTPUTS | |
|------|-----------------|-----------------|------------------|------------------|
| | $\overline{G}1$ | $\overline{G}2$ | $\overline{P=Q}$ | $\overline{P>Q}$ |
| P=Q | L | X | L | H |
| P>Q | X | L | H | L |
| P<Q | X | X | H | H |
| P=Q | H | X | H | H |
| P>Q | X | H | H | H |
| X | H | H | H | H |

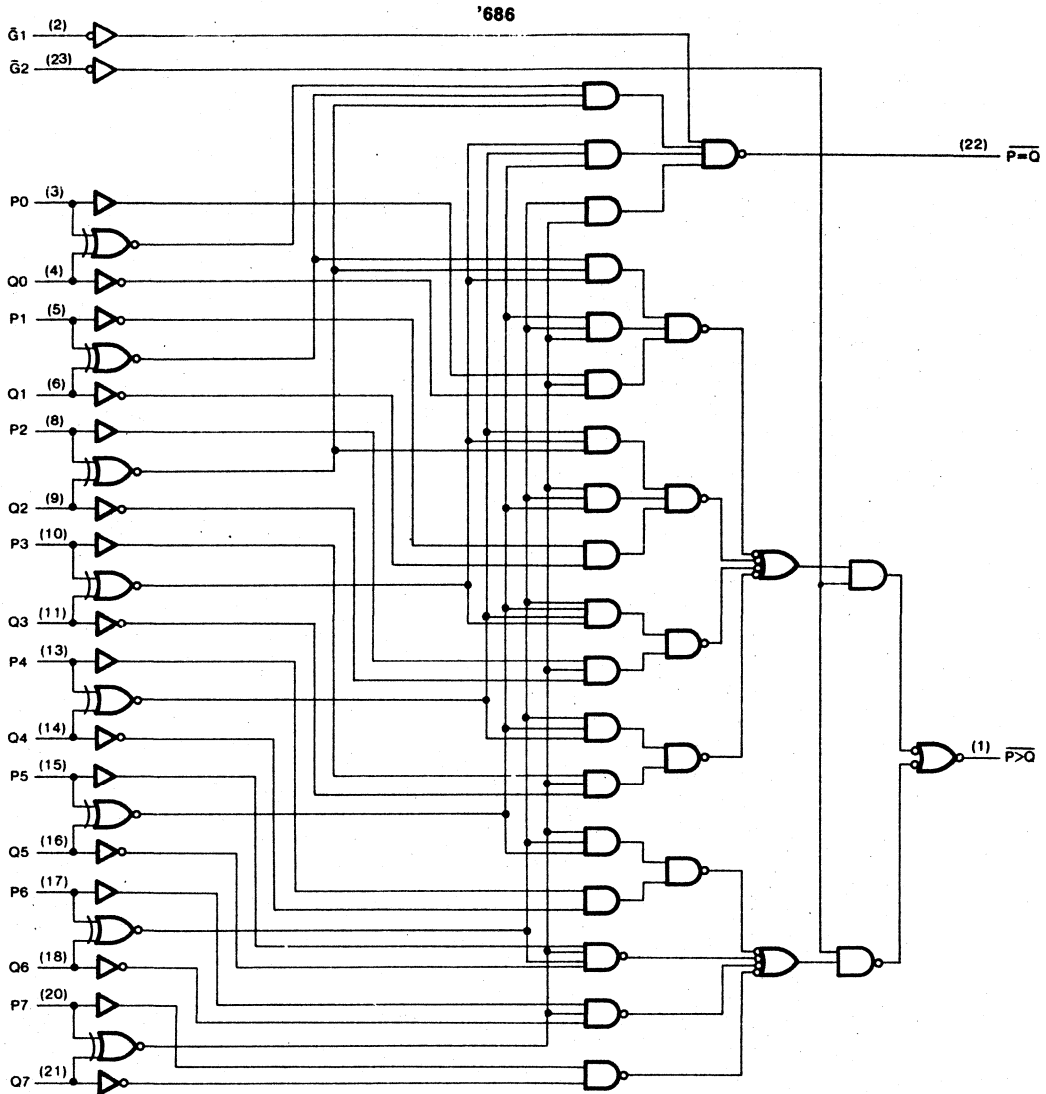
- NOTES: 1. The last 3 lines of the function table apply only to the device having enable inputs, i.e., '686.
2. The $\overline{P<Q}$ function can be generated by applying the $\overline{P=Q}$ and $\overline{P>Q}$ outputs to a 2-input NAND gate.

LOGIC DIAGRAMS

'682 or '684



LOGIC DIAGRAMS (continued)



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} . . . 0V to V_{CC}
 Operating Temperature

Range KS74HCTLS: $-40^\circ C$ to $+85^\circ C$
 KS54HCTLS: $-55^\circ C$ to $+125^\circ C$

Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Parameter | Symbol | Test Conditions | $T_A = 25^\circ C$ | | KS74AHCT $T_A = -40^\circ C$ to $+85^\circ C$ | | 54AHCT $T_A = -55^\circ C$ to $+125^\circ C$ | | Unit |
|--|-----------------|--|--------------------|------------------------|--|-----------------------|---|---------|------|
| | | | Typ | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage (Totem-pole Outputs) | V_{OH} | $V_{IN} = V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -6mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.93 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | | V | |
| Maximum Low-Level Output Voltage (All Outputs) | V_{OL} | $V_{IN} = V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 12mA$ $I_O = 24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | | V | |
| Maximum Input Current (682 Q Inputs) | | $V_{CC} = \text{Max}$ $V_{IN} = 2.7V$ $V_{IN} = 0.4V$ | | -0.2 -0.4 | -0.2 -0.4 | -0.2 -0.4 | | mA | |
| Maximum Input Current (All other Inputs) | I_{IN} | $V_{IN} = V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | | μA | |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT} = V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | | μA | |
| Maximum Quiescent Supply Current | I_{CC} | For '682: $V_{IN} = \text{GND}$ (Q0-Q7) $V_{IN} = V_{CC}$ or GND (all other inputs) | | 3.5 | 3.5 | 3.5 | | mA | |
| | | For '684 and '688 $V_{IN} = V_{CC}$ or GND $I_{OUT} = 0\mu A$ | | 8.0 | 80.0 | 160.0 | | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other Inputs: at V_{CC} or GND $I_{OUT} = 0\mu A$ | | 2.7 | 2.9 | 3.0 | | mA | |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS682, HCTLS684, HCTLS686

| Characteristic | Symbol | Conditions† | T _a = 25°C V _{CC} = 5.0V | | KS74HCTLS | KS54HCTLS | Unit |
|---|------------------|------------------------|---|----|---|--|------|
| | | | | | T _a = -40°C to +85°C V _{CC} = 5.0V ± 10% | T _a = -55°C to +125°C V _{CC} = 5.0V ± 10% | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Propagation Delay, P or Q to $\overline{P=Q}$ | t _{PLH} | C _L = 50pF | 18 | 25 | 31 | 38 | ns |
| | | C _L = 150pF | 21 | 32 | 40 | 49 | |
| Maximum Propagation Delay, P or Q to $\overline{P>Q}$ | t _{PHL} | C _L = 50pF | 18 | 25 | 31 | 38 | ns |
| | | C _L = 150pF | 21 | 32 | 40 | 49 | |
| Maximum Propagation Delay, P or Q to $\overline{P<Q}$ | t _{PLH} | C _L = 50pF | 22 | 32 | 38 | 45 | ns |
| | | C _L = 150pF | 25 | 37 | 49 | 56 | |
| Maximum Propagation Delay, P or Q to $\overline{P>Q}$ | t _{PHL} | C _L = 50pF | 22 | 30 | 38 | 45 | ns |
| | | C _L = 150pF | 25 | 37 | 47 | 56 | |
| Maximum Propagation Delay, $\overline{G1}$ to $\overline{P=Q}$ ('686 Only) | t _{PLH} | C _L = 50pF | 15 | 20 | 25 | 30 | ns |
| | | C _L = 150pF | 18 | 27 | 34 | 41 | |
| Maximum Propagation Delay, $\overline{G2}$ to $\overline{P<Q}$ ('686 Only) | t _{PHL} | C _L = 50pF | 15 | 20 | 25 | 30 | ns |
| | | C _L = 150pF | 18 | 27 | 34 | 41 | |
| Maximum Propagation Delay, $\overline{G1}$ to $\overline{P<Q}$ ('686 Only) | t _{PLH} | C _L = 50pF | 18 | 25 | 31 | 38 | ns |
| | | C _L = 150pF | 21 | 32 | 40 | 49 | |
| Maximum Propagation Delay, $\overline{G2}$ to $\overline{P<Q}$ ('686 Only) | t _{PHL} | C _L = 50pF | 18 | 25 | 31 | 38 | ns |
| | | C _L = 150pF | 21 | 32 | 40 | 49 | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF |
| Power Dissipation Capacitance* | C _{PD} | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Compares Two 8-Bit Words
- Choice of Totem-pole ('688) and open-drain ('689) outputs ('688 is identical to '521)
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High drive current outputs:
($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

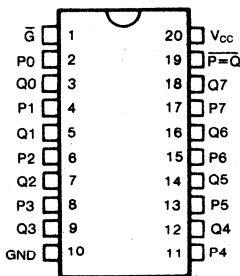
DESCRIPTION

These identity comparators perform comparisons of two 8-bit binary or BCD words. The output of '688 is totem-pole while '689's are open-drain.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

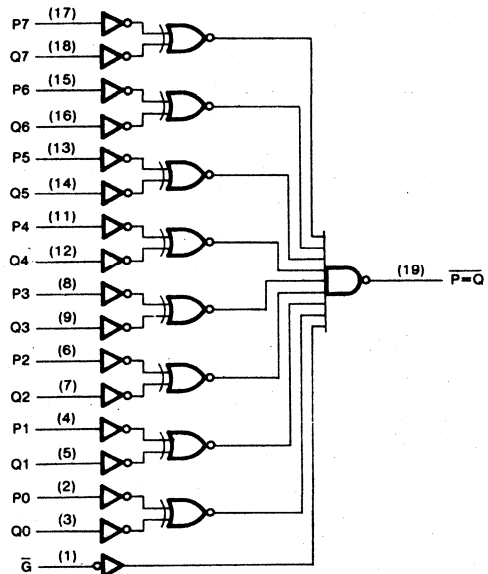
PIN CONFIGURATION



FUNCTION TABLE

| INPUTS | | OUTPUT $\overline{P=Q}$ |
|-------------|--------------------------|----------------------------|
| DATA P,Q | ENABLE \overline{G} | |
| P=Q | L | L |
| P>Q | L | H |
| P<Q | L | H |
| X | H | H |

LOGIC DIAGRAM (Positive Logic)



Absolute Maximum Ratings*

| | |
|---|---|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | $(V_I < -0.5V \text{ or } V_I > V_{CC} + 0.5V)$ ± 20 mA |
| DC Output Diode Current, I_{OK} | $(V_O < -0.5V \text{ or } V_O > V_{CC} + 0.5V)$ ± 20 mA |
| Continuous Output Current Per Pin, I_O | $(-0.5V < V_O < V_{CC} + 0.5V)$ ± 70 mA |
| Continuous Current Through V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): -12mW/°C from 65°C to 85°C
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature Range | KS74HCTLS: -40°C to +85°C KS54HCTLS: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | | Unit | |
|---|-----------------|--|--------------------------|--|---|---------------------|-------------------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ | | Guaranteed Limits |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage ('688 only) | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current ('689 only) | I_{OZ} | $V_{IN}=V_{IH}$ or V_{IL} $V_{OUT}=V_{CC}$ | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (input $t_r, t_f \leq 6$ ns), HCTLS688

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|--|-----------|----------------------|--|-------------------|--|----|---|----|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay, P to P=Q | t_{PLH} | $C_L = 50\text{pF}$ | 16 | 22 | 28 | 33 | 33 | 44 | ns |
| | | $C_L = 150\text{pF}$ | 19 | 29 | 37 | 44 | 44 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 16 | 22 | 28 | 33 | 33 | 44 | ns |
| | | $C_L = 150\text{pF}$ | 19 | 29 | 37 | 44 | 44 | | |
| Maximum Propagation Delay, Q to P=Q | t_{PLH} | $C_L = 50\text{pF}$ | 16 | 22 | 28 | 33 | 33 | 44 | ns |
| | | $C_L = 150\text{pF}$ | 19 | 29 | 37 | 44 | 44 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 16 | 22 | 28 | 33 | 33 | 44 | ns |
| | | $C_L = 150\text{pF}$ | 19 | 29 | 37 | 44 | 44 | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS689

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|--|-----------|----------------------|--|-------------------|--|----|---|----|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay, P to P=Q | t_{PLH} | $C_L = 50\text{pF}$ | 24 | 31 | 37 | 43 | 43 | 53 | ns |
| | | $C_L = 150\text{pF}$ | 34 | 41 | 47 | 53 | 53 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 19 | 26 | 32 | 38 | 38 | 49 | ns |
| | | $C_L = 150\text{pF}$ | 25 | 33 | 41 | 49 | 49 | | |
| Maximum Propagation Delay, Q to P=Q | t_{PLH} | $C_L = 50\text{pF}$ | 24 | 31 | 37 | 43 | 43 | 53 | ns |
| | | $C_L = 150\text{pF}$ | 34 | 41 | 47 | 53 | 53 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 19 | 26 | 32 | 38 | 38 | 49 | ns |
| | | $C_L = 150\text{pF}$ | 25 | 33 | 41 | 49 | 49 | | |
| Maximum Propagation Delay, G to P=Q | t_{PLH} | $C_L = 50\text{pF}$ | 23 | 29 | 35 | 41 | 41 | 51 | ns |
| | | $C_L = 150\text{pF}$ | 33 | 39 | 45 | 51 | 51 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 18 | 24 | 30 | 36 | 36 | 47 | ns |
| | | $C_L = 150\text{pF}$ | 24 | 31 | 39 | 47 | 47 | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.



Preliminary Specifications

FEATURES

- I/O port configuration enables output data back onto input bus
- Latch ('793) and Register ('794) options
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA}$ @ $V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

These are 8-bit latches/registers that allow temporary storage and retrieval of data on a bus. This operation is important in control algorithms which make decisions based on the previous status of output controls. Rather than storing a redundant copy of the output data in memory, simply reading the register as an I/O port allows the data to be retrieved from where it has been stored in a '793 or '794, for verification and/or updating.

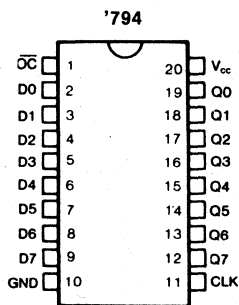
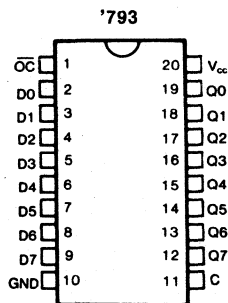
The data is loaded in the registers on the positive-edge of the clock (CLK) for the '794. The data is passed through the '793 when C is high, and it is latched when C goes low. The output control (\overline{OC}) is used to enable data on the D0-D7 pins. when \overline{OC} is low the output of the latches/registers is enabled on D0-D7, enabling D as an output bus so that the host can perform a read operation. When \overline{OC} is high, D0-D7 are inputs to the latches/registers configuring D as an input bus.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

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PIN CONFIGURATIONS



FUNCTION TABLES

'793

| C | \overline{OC} | Q | D |
|----|-----------------|------------|------------|
| L | L | Q_0^{**} | Output, Q |
| L | H | Q_0^{**} | Input |
| H† | L | D* | Output, Q* |
| H | H | D | Input |

* In this case the output of the latch feeds the input, and a "race" condition results.

** Q_0 represents the previous "latched" state.

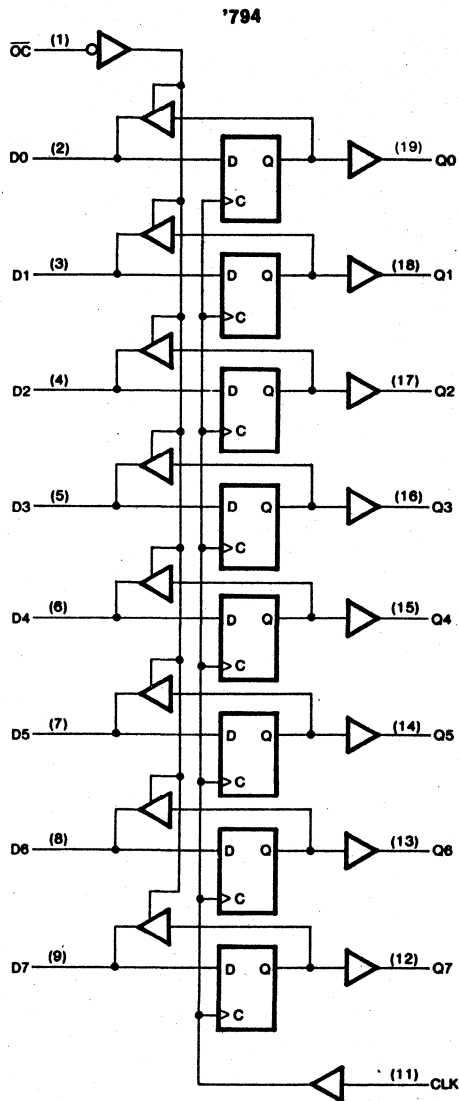
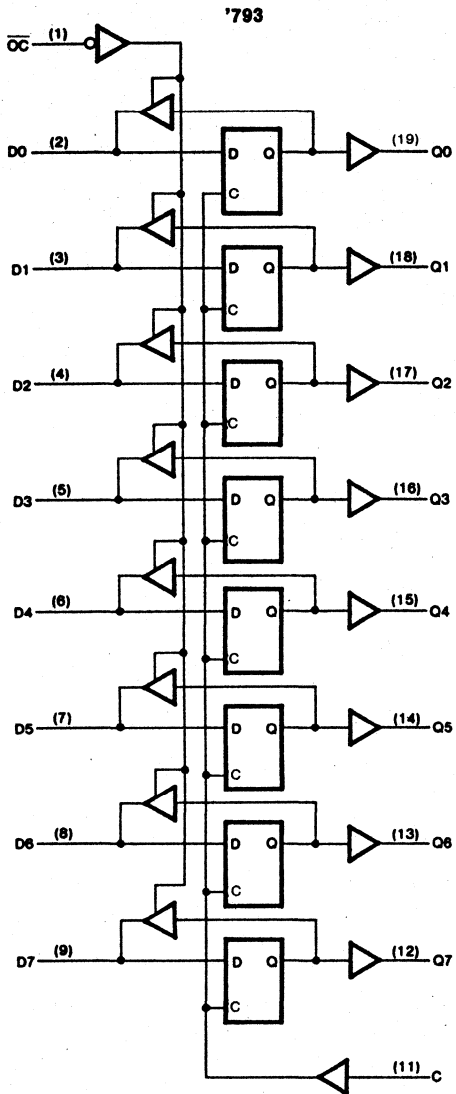
† This transition is not a normal mode of operation and may produce hazards.

'794

| CLK | \overline{OC} | Q | D |
|-------------|-----------------|-------|------------|
| L or H or ↓ | L | Q_0 | Output, Q |
| L or H or ↓ | H | Q_0 | Input |
| ↑ | L | Q_0 | Output, Q* |
| ↑ | H | D | Input |

* In this case the output of the register is clocked to the inputs and the overall Q output is unchanged at Q_0 .

LOGIC DIAGRAMS



AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS793, 794

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit | | |
|---|-------------------------------|---|--|----|---|----|--|----|------|----|--|
| | | | Typ | | Guaranteed Limits | | | | | | |
| | | | | | | | | | | | |
| Maximum Clock Frequency ('794 only) | t_{max} | $C_L = 50\text{pF}$ | 50 | 40 | 35 | | 30 | | MHz | | |
| Maximum Propagation Delay, D to Any Q ('793 only) | t_{PLH} | $C_L = 50\text{pF}$ | 14 | 18 | 23 | | 27 | | ns | | |
| | | $C_L = 150\text{pF}$ | 17 | 25 | 32 | | 38 | | | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 14 | 18 | 23 | | 27 | | | | |
| | | $C_L = 150\text{pF}$ | 17 | 25 | 32 | | 38 | | | | |
| Maximum Propagation Delay, CLK/C to Any Q | t_{PLH} | $C_L = 50\text{pF}$ | 15 | 20 | 25 | | 30 | | ns | | |
| | | $C_L = 150\text{pF}$ | 18 | 27 | 34 | | 41 | | | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 15 | 20 | 25 | | 30 | | | | |
| | | $C_L = 150\text{pF}$ | 18 | 27 | 34 | | 41 | | | | |
| Maximum Enable Time, OC to D | t_{PZH} | $C_L = 50\text{pF}$ | 15 | 20 | 25 | | 30 | | ns | | |
| | | $C_L = 150\text{pF}$ | 21 | 27 | 34 | | 41 | | | | |
| | t_{PZL} | $R_L = 1\text{k}\Omega$ (C=Low for '793) | $C_L = 50\text{pF}$ | 15 | 20 | 25 | | 30 | | | |
| | | $C_L = 150\text{pF}$ | 21 | 27 | 34 | | 41 | | | | |
| Maximum Disable Time, OC to D | t_{PHZ} | $R_L = 1\text{k}\Omega, C_L = 50\text{pF}$ | 15 | 20 | 25 | | 30 | | ns | | |
| | t_{PLZ} | (C=Low for '793) | 15 | 20 | 25 | | 30 | | | | |
| Minimum Pulse Width, CLK/C High or low | t_w | | 10 | 15 | 18 | | 20 | | ns | | |
| Minimum Setup Time | D before $C\downarrow$ ('793) | t_{su} | | 8 | 10 | 13 | | 15 | | ns | |
| | D before $CLK\uparrow$ ('794) | | | 10 | 15 | 18 | | 20 | | | |
| Minimum Hold Time | D after $C\downarrow$ ('793) | t_h | | 8 | 10 | 13 | | 15 | | ns | |
| | D after $CLK\uparrow$ ('794) | | | -3 | 0 | 0 | | 0 | | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | | pF | | |
| Maximum Output Capacitance | C_{OUT} | | 10 | | | | | | pF | | |
| Power Dissipation Capacitance* | C_{PD} | | | | | | | | ns | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

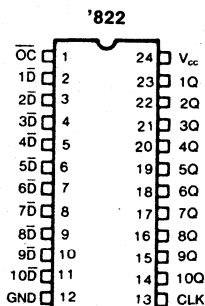
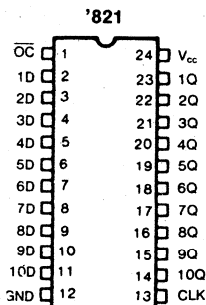
† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Functionally Equivalent to AMD's Am29821 and Am29822
- Provides Extra Data Width Necessary for Wider Address/Data Paths or Buses with Parity
- Power-Up High-Impedance State
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATIONS



DESCRIPTION

These 10-bit bus-interface flip-flops feature three-state outputs designed specifically for driving highly-capacitive or relatively low-impedance loads. They are suitable for implementing wider buffer registers, I/O ports, bidirectional bus drivers with parity, and working registers.

All of the flip-flops are edge-triggered and D-type. On the positive transition of the clock the Q outputs on the '821 will be true, and on the '822 will be complementary to the data input.

A buffered output-control input can be used to place the ten outputs in either a normal logic state (high or low levels) or a high-impedance state. The high-impedance state and increased drive provide the capability to drive the bus lines in a bus-organized system without need for interface or pull-up components. The output control (\overline{OC}) does not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLES

(Each Flip-Flop)

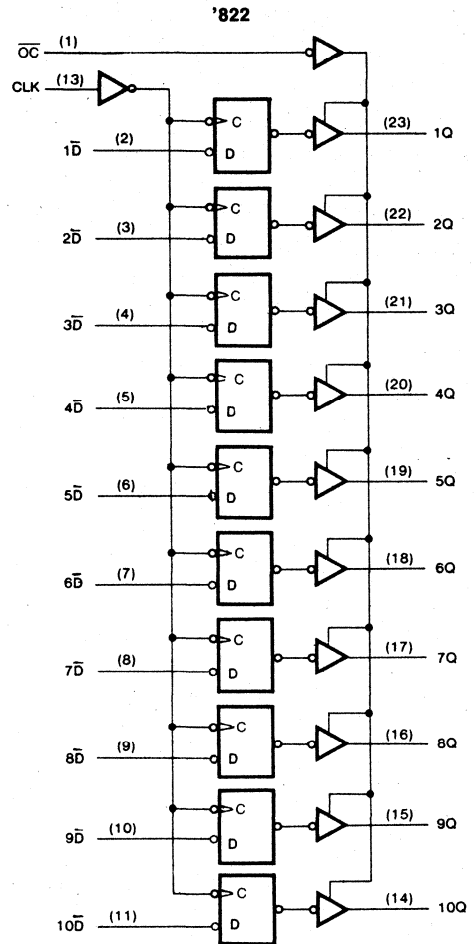
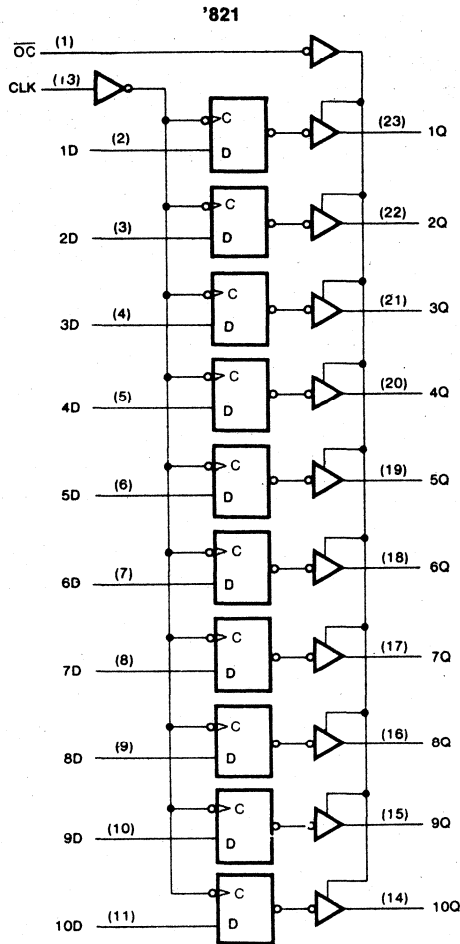
'821

| Inputs | | | Output Q |
|-----------------|-----|---|-------------|
| \overline{OC} | CLK | D | |
| L | ↑ | H | H |
| L | ↑ | L | L |
| L | L | X | Q_0 |
| L | H | X | Q_0 |
| H | X | X | Z |

'822

| Inputs | | | Output Q |
|-----------------|-----|----------------|-------------|
| \overline{OC} | CLK | \overline{D} | |
| L | ↑ | H | L |
| L | ↑ | L | H |
| L | L | X | Q_0 |
| L | H | X | Q_0 |
| H | X | X | Z |

LOGIC DIAGRAMS



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
Continuous Current Through
 V_{CC} or GND pins ± 250 mA
Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
Operating Temperature
Range KS74HCTLS: $-40^\circ C$ to $+85^\circ C$
KS54HCTLS: $-55^\circ C$ to $+125^\circ C$
Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|---|--|-----------------------|---|
| | | | Typ | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ | KS54HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| | | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | 2.0 | 2.0 | 2.0 | V | |
| Maximum Low-Level Input Voltage | V_{IL} | | 0.8 | 0.8 | 0.8 | V | |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu A$ $I_O = -6mA$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu A$ $I_O = 12mA$ $I_O = 24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | ± 0.1 | ± 1.0 | ± 1.0 | μA | |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | ± 0.5 | ± 5.0 | ± 10.0 | μA | |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | 8.0 | 80.0 | 180.0 | μA | |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | 2.7 | 2.9 | 3.0 | mA | |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns, HCTLS821, HCTLS822)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit | | |
|--|-----------|--|--|----|--|----|---|----|------|----|--|
| | | | Typ | | Guaranteed Limits | | | | | | |
| | | | | | | | | | | | |
| Maximum Operating Frequency | f_{max} | $C_L = 50\text{pF}$ | 40 | 35 | 30 | | 25 | | MHz | | |
| Maximum Propagation Delay, CLK to any Q | t_{PLH} | $C_L = 50\text{pF}$ | 15 | 70 | 25 | | 30 | | ns | | |
| | | $C_L = 150\text{pF}$ | 18 | 27 | 34 | | 41 | | | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 15 | 20 | 25 | | 30 | | | | |
| | | $C_L = 150\text{pF}$ | 18 | 27 | 34 | | 41 | | | | |
| Maximum Output Enable Time, \overline{OC} to any Q | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 18 | 24 | 30 | | 36 | | ns | |
| | | | $C_L = 150\text{pF}$ | 24 | 31 | 39 | | 47 | | | |
| | t_{PZL} | $C_L = 50\text{pF}$ | 18 | 24 | 30 | | 36 | | | | |
| | | $C_L = 150\text{pF}$ | 24 | 31 | 39 | | 47 | | | | |
| Maximum Output Disable Time, \overline{OC} to any Q | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 18 | 24 | 30 | | 36 | | ns | | |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 18 | 24 | 30 | | 36 | | | | |
| Minimum Pulse Width, CLK High or Low | t_w | | 12 | 16 | 20 | | 24 | | ns | | |
| Minimum Setup Time, Data before CLK† | t_{su} | | 12 | 16 | 20 | | 24 | | ns | | |
| Minimum Hold Time, Data after CLK† | t_h | | -3 | 0 | 0 | | 0 | | ns | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | | pF | | |
| Maximum Output Capacitance | C_{OUT} | $\overline{OC} = V_{CC}$ | 10 | | | | | | pF | | |
| Power Dissipation Capacitance* (per stage) | C_{PD} | $\overline{OC} = V_{CC}$ $\overline{OC} = \text{GND}$ | 5 | | | | | | pF | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

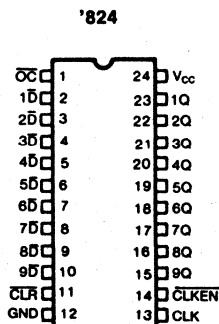
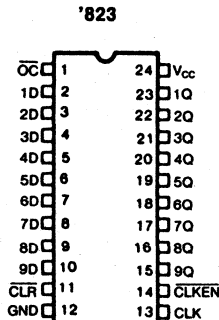
† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Functionally Equivalent to AMD's Am29823 and Am29824
- Provides Extra Data Width Necessary for Wider Address/Data Paths or Buses with Parity
- Power-Up High-Impedance State
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5V$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATIONS



DESCRIPTION

These 9-bit bus interface flip-flops feature three-state outputs designed specifically for driving highly-capacitive or relatively low-impedance loads. They are suitable for implementing wider buffer registers, I/O ports, bidirectional bus drivers, parity bus interfacing and working registers.

With the clock enable ($\overline{\text{CLKEN}}$) low, the D-type edge-triggered flip-flops enter data on the low-to-high transitions of the clock. Taking $\overline{\text{CLKEN}}$ high will disable the clock buffer, thus latching the outputs. The '823 has noninverting D inputs and the '824 has inverting D inputs. Taking the $\overline{\text{CLR}}$ input low causes the nine Q outputs to go low independently of the clock.

A buffered output-control input ($\overline{\text{OC}}$) can be used to place the ten outputs in either a normal logic state (high or low levels) or a high-impedance state. The high-impedance state and increased drive provide the capability to drive the bus lines in a bus-organized system without need for interface or pull-up components. The output control does not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLES

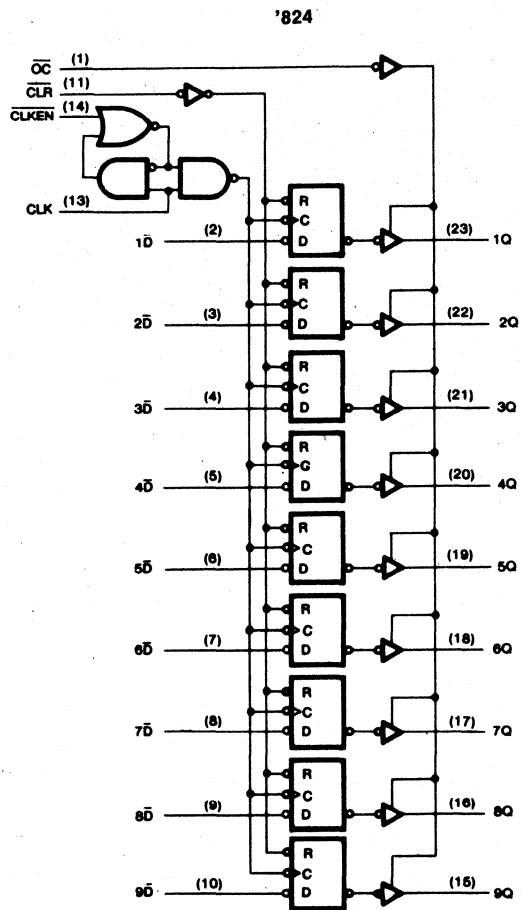
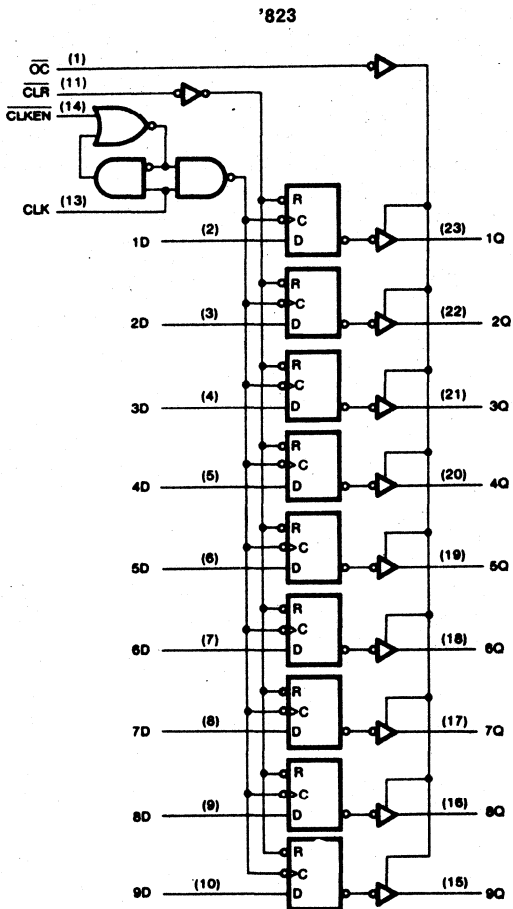
'823

| INPUT | | | | | OUTPUT |
|------------------------|-------------------------|---------------------------|------------|---|--------|
| $\overline{\text{OC}}$ | $\overline{\text{CLR}}$ | $\overline{\text{CLKEN}}$ | CLK | D | Q |
| L | L | X | X | X | L |
| L | H | L | \uparrow | H | H |
| L | H | L | \uparrow | L | L |
| L | H | H | X | X | Q_0 |
| H | X | X | X | X | Z |

'824

| INPUTS | | | | | OUTPUT |
|------------------------|-------------------------|---------------------------|------------|-----------------------|--------|
| $\overline{\text{OC}}$ | $\overline{\text{CLR}}$ | $\overline{\text{CLKEN}}$ | CLK | $\overline{\text{D}}$ | Q |
| L | L | X | X | X | L |
| L | H | L | \uparrow | H | L |
| L | H | L | \uparrow | L | H |
| L | H | H | X | X | Q_0 |
| H | X | X | X | X | Z |

LOGIC DIAGRAMS



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5 to +7V
DC Input Diode Current, I_{IK}
($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
DC Output Diode Current, I_{OK}
($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
Continuous Output Current Per Pin, I_O
($-0.5V < V_O < V_{CC} + 0.5$) ± 70 mA
Continuous Current Through
 V_{CC} or GND pins ± 250 mA
Storage Temperature Range, T_{stg} -65°C to +150°C
Power Dissipation Per Package, P_d † 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN} , V_{OUT} 0V to V_{CC}
Operating Temperature
Range KS74HCTLS: -40°C to +85°C
KS54HCTLS: -55°C to +125°C
Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ C$ | | | Unit | |
|--------------------------------------|-----------------|--|--------------------|---|--|---------------------|---------|
| | | | Typ | KS74HCTLS $T_a = -40^\circ C$ to $+85^\circ C$ | KS54HCTLS $T_a = -55^\circ C$ to $+125^\circ C$ | | |
| | | | Guaranteed Limits | | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu A$ $I_O=-6mA$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu A$ $I_O=12mA$ $I_O=24mA$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu A$ | | 2.7 | 2.9 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS823, HCTLS824

| Characteristic | Symbol | Conditions† | TA = 25°C VCC = 5.0V | | KS74HCTLS | KS54HCTLS | Unit | |
|--|---|------------------------|-------------------------|-------------------|---|--|------|----|
| | | | | | TA = -40°C to +85°C VCC = 5.0V ± 10% | TA = -55°C to +125°C VCC = 5.0V ± 10% | | |
| | | | Typ | Guaranteed Limits | | | | |
| Maximum Operating Frequency | f _{max} | C _L = 50pF | 40 | 35 | 30 | 25 | MHz | |
| Maximum Propagation Delay, CLK to any Q | t _{PLH} | C _L = 50pF | 15 | 70 | 25 | 30 | ns | |
| | | C _L = 150pF | 18 | 27 | 34 | 41 | | |
| Maximum Propagation Delay, CLK to any Q | t _{PHL} | C _L = 50pF | 15 | 20 | 25 | 30 | ns | |
| | | C _L = 150pF | 18 | 27 | 34 | 41 | | |
| Maximum Propagation Delay, CLR to Any Q | t _{PLH} | C _L = 50pF | 17 | 22 | 28 | 34 | ns | |
| | | C _L = 150pF | 20 | 29 | 37 | 45 | | |
| Maximum Output Enable Time, \overline{OC} to any Q | t _{PZL} | R _L = 1kΩ | C _L = 50pF | 18 | 24 | 30 | 36 | ns |
| | | | C _L = 150pF | 24 | 31 | 39 | 47 | |
| | t _{PZL} | R _L = 1kΩ | C _L = 50pF | 18 | 24 | 30 | 36 | |
| | | | C _L = 150pF | 24 | 31 | 39 | 47 | |
| Maximum Output Disable Time, \overline{OC} to any Q | t _{PHZ} | R _L = 1kΩ | 18 | 24 | 30 | 36 | ns | |
| | t _{PLZ} | C _L = 50pF | 18 | 24 | 30 | 36 | | |
| Minimum Pulse Width | \overline{CLR} Low CLK high or Low | t _w | 12 | 16 | 20 | 24 | ns | |
| | | | 12 | 16 | 20 | 24 | | |
| Minimum Setup Time Before CLK† | \overline{CLR} Inactive | t _{su} | 12 | 16 | 20 | 24 | ns | |
| | Data | | 12 | 16 | 20 | 24 | | |
| | CLKEN high or Low | | 12 | 16 | 20 | 24 | | |
| Minimum Hold Time, CLKEN or data after CLK† | t _h | | -3 | 0 | 0 | 0 | ns | |
| Maximum Input Capacitance | C _{IN} | | 5 | | | | pF | |
| Maximum Output Capacitance | C _{OUT} | Output Disabled | 10 | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C _{PD} | OC = V _{CC} | 5 | | | | pF | |
| | | OC = GND | 30 | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}.

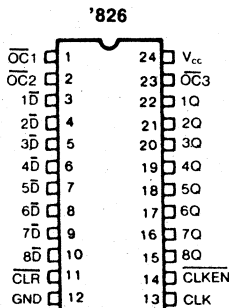
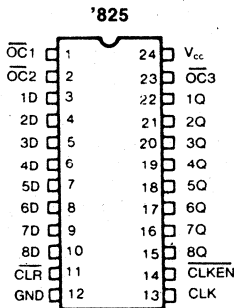
† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Functionally Equivalent to AMD's Am29825 and Am29826
- Improved I_{OH} Specifications
- Multiple Output Enables Allow Multiuser Control of the Interface
- Power-Up High-Impedance State
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATIONS



DESCRIPTION

These 8-bit bus interface flip-flops feature three-state outputs designed specifically for driving highly-capacitive or relatively low-impedance loads. They are suitable for implementing multiuser buffer registers, I/O ports, bidirectional bus drivers and working registers.

With the clock enable (\overline{CLKEN}) low, all D-type edge-triggered flip-flops enter data on the low-to-high transitions of the clock. Taking \overline{CLKEN} high will disable the clock buffer, thus latching the outputs. The '825 has non-inverting D inputs and the '826 has inverting \overline{D} inputs. Taking the \overline{CLR} inputs low causes the eight Q outputs to go low independently of the clock.

Multiuser buffered output-control inputs ($\overline{OC1}$, $\overline{OC2}$, and $\overline{OC3}$) can be used to place the eight outputs in either a normal logic state (high or low level) or a high-impedance state. The high-impedance state and increased drive provide the capability to drive the bus lines in a bus-organized system without need for interface or pull-up components. The output controls do not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLES

'825

| Inputs | | | | | Output Q |
|-------------------|------------------|--------------------|-----|---|-------------|
| \overline{OC}^* | \overline{CLR} | \overline{CLKEN} | CLK | D | |
| L | L | X | X | X | L |
| L | H | L | ↑ | H | H |
| L | H | L | ↑ | L | L |
| L | H | H | X | X | Q_0 |
| H | X | X | X | X | Z |

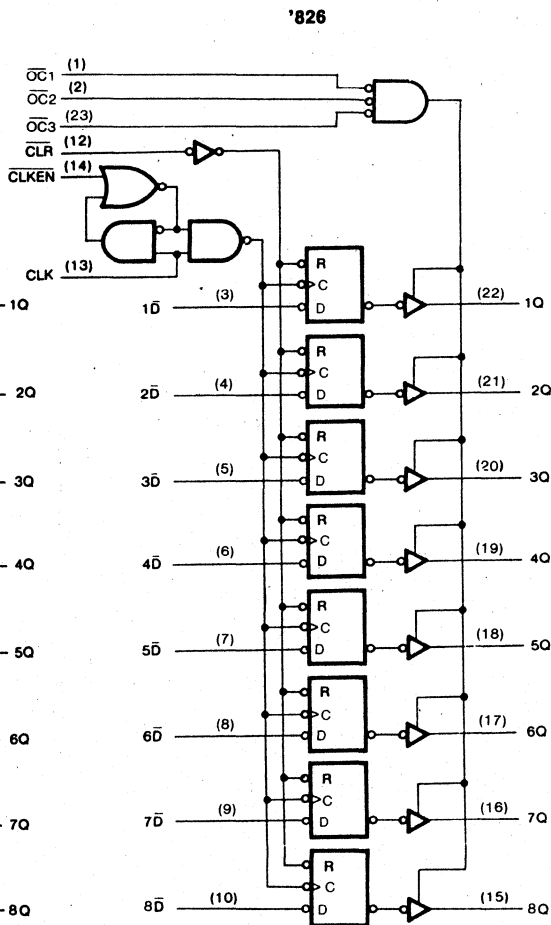
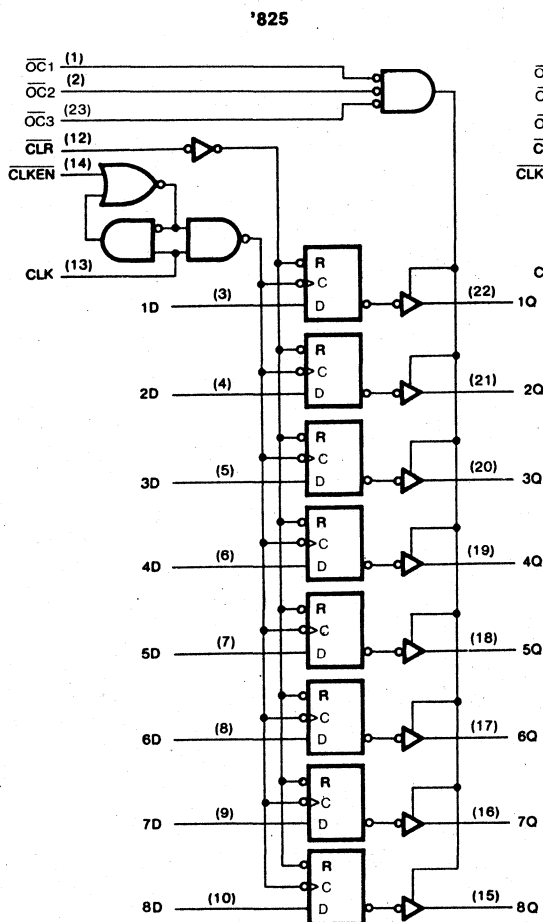
* $OC = H$ if any of $OC1$, $OC2$, or $OC3$ are high.
 $OC = L$ if $OC1$, $OC2$, and $OC3$ are low.

'826

| Inputs | | | | | Output Q |
|-------------------|------------------|--------------------|-----|----------------|-------------|
| \overline{OC}^* | \overline{CLR} | \overline{CLKEN} | CLK | \overline{D} | |
| L | L | X | X | X | L |
| L | H | L | ↑ | H | L |
| L | H | L | ↑ | L | H |
| L | H | H | X | X | Q_0 |
| H | X | X | X | X | Z |

* $OC = H$ if any of $OC1$, $OC2$, or $OC3$ are high.
 $OC = L$ if $OC1$, $OC2$, and $OC3$ are low.

LOGIC DIAGRAMS



Absolute Maximum Ratings*

| | | |
|--|-------|-----------------|
| Supply Voltage Range V_{CC} | | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | | ± 20 mA |
| DC Output Diode Current, I_{OK} | | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | | ± 20 mA |
| Continuous Output Current Per Pin, I_O | | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | | ± 70 mA |
| Continuous Current Through | | |
| V_{CC} or GND pins | | ± 250 mA |
| Storage Temperature Range, T_{stg} | | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): -12mW/°C from 65°C to 85°C

Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V

DC Input & Output Voltages*, V_{IN}, V_{OUT} ... 0V to V_{CC}

Operating Temperature

Range KS74HCTLS: -40°C to +85°C

KS54HCTLS: -55°C to +125°C

Input Rise & Fall Times, t_r, t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|------------------------|-----------------------|---------------|
| | | | Typ | Guaranteed Limits | | | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable = V_{IH} $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS825, HCTLS826

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|---|-----------|---------------------------|--|----|---|----|--|----|------|
| | | | Typ | | Guaranteed Limits | | | | |
| | | | | | | | | | |
| Maximum Operating Frequency | f_{max} | $C_L = 50\text{pF}$ | 40 | 35 | 30 | | 25 | | MHz |
| Maximum Propagation Delay, CLK to any Q | t_{PLH} | $C_L = 50\text{pF}$ | 15 | 70 | 25 | | 30 | | ns |
| | | $C_L = 150\text{pF}$ | 18 | 27 | 34 | | 41 | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 15 | 20 | 25 | | 30 | | |
| | | $C_L = 150\text{pF}$ | 18 | 27 | 34 | | 41 | | |
| Maximum Propagation Delay, CLR to Any Q | t_{PLH} | $C_L = 50\text{pF}$ | 17 | 22 | 28 | | 34 | | ns |
| | | $C_L = 150\text{pF}$ | 20 | 29 | 37 | | 45 | | |
| Maximum Output Enable Time, \overline{OC} to any Q | t_{PZL} | $R_L = 1\text{k}\Omega$ | $C_L = 50\text{pF}$ | 18 | 24 | 30 | | 36 | ns |
| | | | $C_L = 150\text{pF}$ | 24 | 31 | 39 | | 47 | |
| | t_{PZL} | $C_L = 50\text{pF}$ | | 18 | 24 | 30 | | 36 | |
| | | | $C_L = 150\text{pF}$ | 24 | 31 | 39 | | 47 | |
| Maximum Output Disable Time, \overline{OC} to any Q | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 18 | 24 | 30 | | 36 | ns | |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 18 | 24 | 30 | | 36 | | |
| Minimum Pulse Width | t_w | \overline{CLR} Low | 12 | 16 | 20 | | 24 | ns | |
| | | CLK high or Low | 12 | 16 | 20 | | 24 | | |
| Minimum Setup Time Before CLK† | t_{su} | \overline{CLR} Inactive | 12 | 16 | 20 | | 24 | ns | |
| | | Data | 12 | 16 | 20 | | 24 | | |
| | | CLKEN high or Low | 12 | 16 | 20 | | 24 | | |
| Minimum Hold Time, \overline{CLKEN} or data after CLK† | t_h | | -3 | 0 | 0 | | 0 | ns | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | pF | |
| Maximum Output Capacitance | C_{OUT} | | 10 | | | | | pF | |
| Power Dissipation Capacitance* (per stage) | C_{PD} | | 5 | | | | | pF | |
| | | | 30 | | | | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

KS54HCTLS 841/842 KS74HCTLS

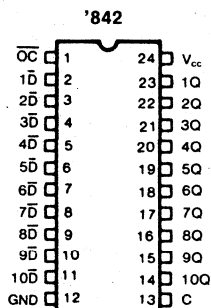
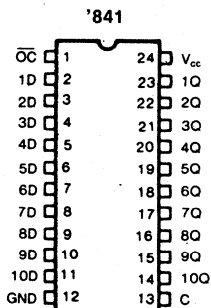
10-Bit Bus Interface D-Type Latches with 3-State Outputs

Preliminary Specifications

FEATURES

- Bus-Structured Pinout
- Provides Extra Bus Driving Latches
- Necessary for Wider Address/Data Paths or Buses with Parity
- Power-Up High-Impedance State
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current ($I_{OL} = 24 \text{ mA @ } V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

PIN CONFIGURATIONS



DESCRIPTION

These 10-bit bus interface latches feature three state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are suitable for implementing wider buffer registers, I/O ports, bidirectional bus drivers, and working registers.

The ten latches are transparent D-type. The '841 has noninverting data (D) inputs and the '842 has inverting (\bar{D}) inputs.

A buffered output control (\overline{OC}) input can be used to place the ten outputs in either a normal logic state (high or low levels) or a high-impedance state. The high-impedance state and increased drive provide the capability to drive the bus lines in a bus-organized system without need for interface or pull-up components.

The output control does not affect the internal operation of the latches. Old data can be retained or new data can be entered while the outputs are off.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLES

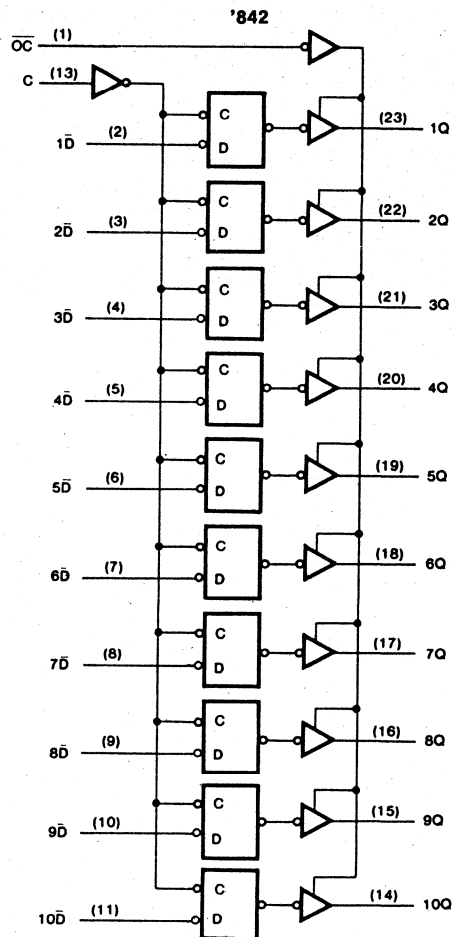
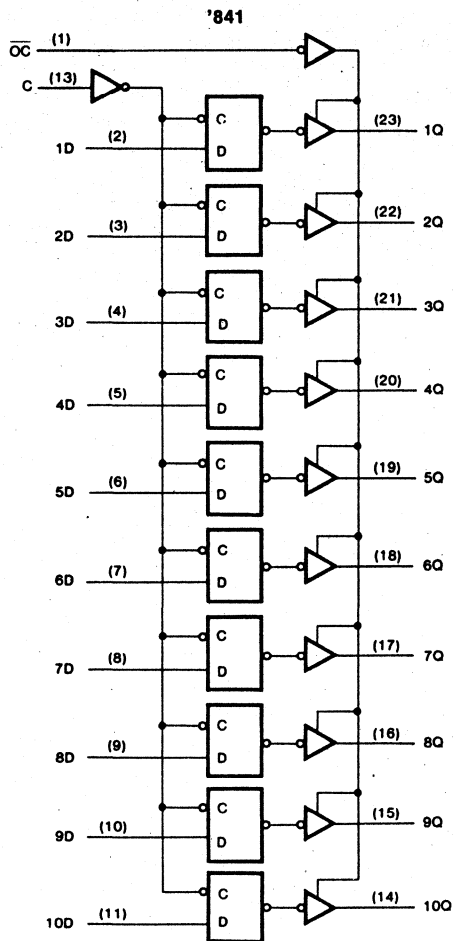
'841

| INPUTS | | | OUTPUT |
|-----------------|---|---|--------|
| \overline{OC} | C | D | Q |
| L | H | H | H |
| L | H | L | L |
| L | L | X | Q_0 |
| H | X | X | Z |

'842

| INPUTS | | | OUTPUT |
|-----------------|---|-----------|--------|
| \overline{OC} | C | \bar{D} | Q |
| L | H | H | L |
| L | H | L | H |
| L | L | X | Q_0 |
| H | X | X | Z |

LOGIC DIAGRAMS



Absolute Maximum Ratings*

| | |
|---|-----------------|
| Supply Voltage Range V_{CC} , | -0.5V to +7V |
| DC Input Diode Current, I_{IK} ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 70 mA |
| Continuous Current Through V_{CC} or GND pins | ± 250 mA |
| Storage Temperature Range, T_{stg} | -65°C to +150°C |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): -12mW/°C from 65°C to 85°C
Ceramic Package (J): -12mW/°C from 100°C to 125°C

Recommended Operating Conditions

| | |
|---|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} .. | 0V to V_{CC} |
| Operating Temperature Range | KS74HCTLS: -40°C to +85°C KS54HCTLS: -55°C to +125°C |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------------|----------------------|----------------------|---|---------------|
| | | | Typ | Guaranteed Limits | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=-20\mu\text{A}$ $I_O=-6\text{mA}$ | V_{CC} 4.2 | $V_{CC}-0.1$ 3.98 | $V_{CC}-0.1$ 3.84 | $V_{CC}-0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O=20\mu\text{A}$ $I_O=12\text{mA}$ $I_O=24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other Inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns, HCTLS841, HCTLS842)

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS | KS54HCTLS | Unit |
|---|-----------|--|--|----------|--|---|------|
| | | | | | $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | |
| | | | Typ | | Guaranteed Limits | | |
| Maximum Propagation Delay, Data to Q | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 15 18 | 20 27 | 25 34 | 30 41 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 15 18 | 20 27 | 25 34 | 30 41 | |
| Maximum Propagation Delay, C to any Q | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 21 24 | 28 35 | 35 44 | 42 53 | ns |
| | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 21 24 | 28 35 | 35 44 | 42 53 | |
| Maximum Output Enable Time, \overline{OC} to any Q | t_{PZH} | $R_L = 1\text{k}\Omega$ $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 18 | 24 | 30 | 36 | ns |
| | | | 24 | 31 | 39 | 47 | |
| | t_{PZL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 18 | 24 | 30 | 36 | |
| | | | 24 | 31 | 39 | 47 | |
| Maximum Output Disable Time, \overline{OC} to any Q | t_{PHZ} | $R_L = 1\text{k}\Omega$ | 18 | 24 | 30 | 36 | ns |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 18 | 24 | 30 | 36 | |
| Minimum Pulse Width, C High | t_w | | 15 | 20 | 25 | 30 | ns |
| Minimum Setup Time, Data before $C\downarrow$ | t_{su} | | 12 | 16 | 20 | 24 | ns |
| Minimum Hold Time, Data after $C\downarrow$ | t_h | | 6 | 8 | 10 | 12 | ns |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF |
| Maximum Output Capacitance | C_{OUT} | | 10 | | | | pF |
| Power Dissipation Capacitance* (per stage) | C_{PD} | $\overline{OC} = V_{CC}$ $\overline{OC} = \text{GND}$ | 5 | | | | pF |
| | | | 30 | | | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

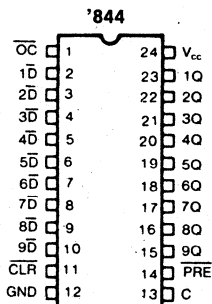
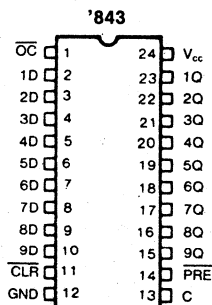
† For AC switching test circuits and timing waveforms see section 2.

Preliminary Specifications

FEATURES

- Bus-Structured Pinout
- Provide Extra Bus Driving Latches
Necessary for Wider Address/Data Paths or Buses with Parity
- Power-Up High Impedance
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current
($I_{OL} = 24 \text{ mA} @ V_{OL} = 0.5\text{V}$) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^\circ\text{C}$
KS54HCTLS: -55°C to $+125^\circ\text{C}$

PIN CONFIGURATIONS



DESCRIPTION

These 9-bit bus interface latches feature three-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are suitable for implementing wider buffer registers, I/O ports, bidirectional bus drivers, parity bus interfacing and working registers.

The nine latches are transparent D-type. The '843 has noninverting data (D) inputs and the '844 has inverting \bar{D} inputs.

A buffered output control (\overline{OC}) input can be used to place the nine outputs in either a normal logic state (high or low levels) or a high-impedance state. The high-impedance state and increased drive provide the capability to drive the bus lines in a bus-organized system without need for interface or pull-up components.

The output control (\overline{OC}) does not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are off.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

FUNCTION TABLES

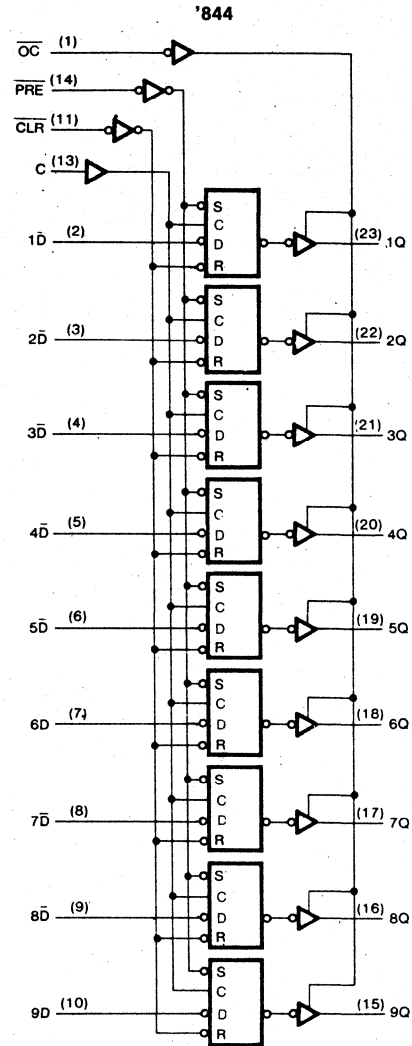
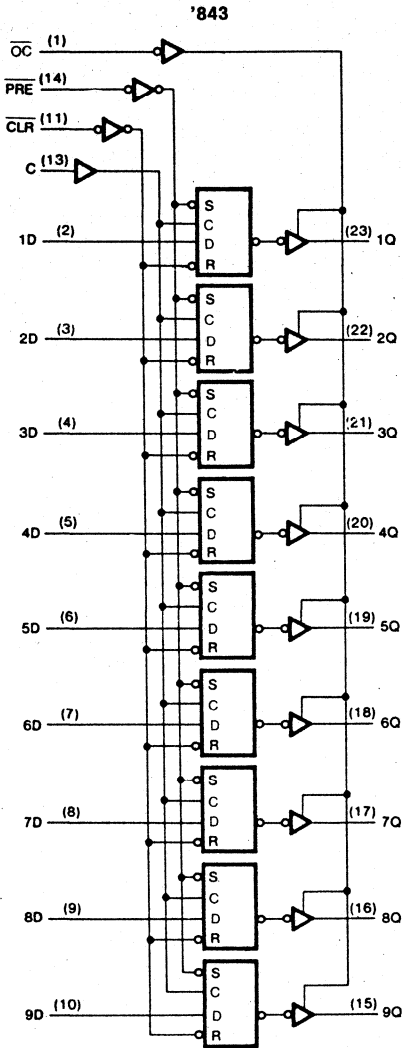
'843

| INPUTS | | | | | OUTPUT |
|------------------|------------------|-----------------|---|---|--------|
| \overline{PRE} | \overline{CLR} | \overline{OC} | C | D | Q |
| L | X | L | X | X | H |
| H | L | L | X | X | L |
| H | H | L | H | L | L |
| H | H | L | H | H | H |
| H | H | L | L | X | Q_0 |
| X | X | H | X | X | Z |

'844

| INPUTS | | | | | OUTPUT |
|------------------|------------------|-----------------|---|-----------|--------|
| \overline{PRE} | \overline{CLR} | \overline{OC} | C | \bar{D} | Q |
| L | X | L | X | X | H |
| H | L | L | X | X | L |
| H | H | L | H | L | H |
| H | H | L | H | H | L |
| H | H | L | L | X | Q_0 |
| X | X | H | X | X | Z |

LOGIC DIAGRAMS



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} -0.5V to +7V
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 70 mA
 Continuous Current Through
 V_{CC} or GND pins ± 250 mA
 Storage Temperature Range, T_{stg} -65°C to $+150^\circ\text{C}$
 Power Dissipation Per Package, P_d^\dagger 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
 Plastic Package (N): $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C
 Ceramic Package (J): $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} 4.5V to 5.5V
 DC Input & Output Voltages*, V_{IN} , V_{OUT} ... 0V to V_{CC}
 Operating Temperature
 Range KS74HCTLS: -40°C to $+85^\circ\text{C}$
 KS54HCTLS: -55°C to $+125^\circ\text{C}$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS | KS54HCTLS | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|--|---|---------------|
| | | | Typ | Guaranteed Limits | $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -6\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | $V_{CC} - 0.1$ 3.7 | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 12\text{mA}$ $I_O = 24\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | 0.1 0.4 | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND | | ± 0.1 | ± 1.0 | ± 1.0 | μA |
| Maximum 3-State Leakage Current | I_{OZ} | Output Enable $=V_{IH}$ $V_{OUT}=V_{CC}$ or GND | | ± 0.5 | ± 5.0 | ± 10.0 | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 8.0 | 80.0 | 160.0 | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I=2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | 3.0 | mA |

5

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS843, HCTLS844

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$ | | KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$ | | Unit |
|--|-----------|--|--|-------------------|---|----------|--|----|------|
| | | | Typ | Guaranteed Limits | | | | | |
| Maximum Propagation Delay, t_o | t_{PLH} | $C_L = 50\text{pF}$ | 18 | 24 | 30 | 36 | ns | | |
| | | $C_L = 150\text{pF}$ | 21 | 31 | 39 | 47 | | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 18 | 24 | 30 | 36 | ns | | |
| | | $C_L = 150\text{pF}$ | 21 | 31 | 39 | 47 | | | |
| Maximum Propagation Delay, C to any Q | t_{PLH} | $C_L = 50\text{pF}$ | 21 | 28 | 35 | 42 | ns | | |
| | | $C_L = 150\text{pF}$ | 24 | 35 | 44 | 53 | | | |
| | t_{PHL} | $C_L = 50\text{pF}$ | 21 | 28 | 35 | 42 | ns | | |
| | | $C_L = 150\text{pF}$ | 24 | 35 | 44 | 53 | | | |
| Maximum Propagation Delay, PRE to Q | t_{PLH} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 23 26 | 30 37 | 38 47 | 46 57 | ns | | |
| Maximum Propagation Delay, CLR to Q | t_{PHL} | $C_L = 50\text{pF}$ $C_L = 150\text{pF}$ | 23 26 | 30 37 | 38 47 | 46 57 | ns | | |
| Maximum Output Enable Time, OC to any Q | t_{PZH} | $R_L = 1\text{ k}\Omega$ | $C_L = 50\text{pF}$ | 18 | 24 | 30 | 36 | ns | |
| | | | $C_L = 150\text{pF}$ | 24 | 31 | 39 | 47 | | |
| | t_{PZL} | $C_L = 50\text{pF}$ | 18 | 24 | 30 | 36 | | | |
| | | $C_L = 150\text{pF}$ | 24 | 31 | 39 | 47 | | | |
| Maximum Output Disable Time, OC to any Q | t_{PHZ} | $R_L = 1\text{ k}\Omega$ | 18 | 24 | 30 | 36 | ns | | |
| | t_{PLZ} | $C_L = 50\text{pF}$ | 18 | 24 | 30 | 36 | | | |
| Minimum Pulse Width, C High | t_w | | 15 | 20 | 25 | 30 | ns | | |
| Minimum Setup Time, Data after C↓ | t_{su} | | 12 | 16 | 20 | 24 | ns | | |
| Minimum Hold Time, Data before C↓ | t_h | | 6 | 8 | 10 | 12 | ns | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | pF | | |
| Maximum Output Capacitance | C_{OUT} | | 10 | | | | pF | | |
| Power Dissipation Capacitance (per stage) | C_{PD} | $\overline{OC} = V_{CC}$ $\overline{OC} = \text{GND}$ | 5 30 | | | | pF | | |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.

KS54HCTLS 4049/4050 KS74HCTLS

Hex Logic Level Down Converters

Preliminary Specifications

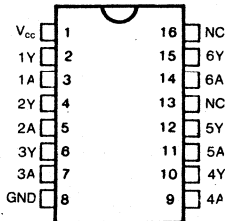
FEATURES

- Modified input structure allows voltages up to 15V
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- High drive current outputs:
 $I_{OL} = 8\text{mA} @ V_{OL} = 0.5\text{V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74HCTLS: -40°C to $+85^{\circ}\text{C}$
KS54HCTLS: -55°C to $+125^{\circ}\text{C}$

DESCRIPTION

The '4049 and '4050 have a modified input protection structure that enable them to be used as logic level translators which will convert high level logic to a low level logic while operating from the low logic supply. For example, 0-15V logic can be converted to 0-5V logic when using a 5V supply. The modified input protection has no diode connected to V_{CC} , thus allowing the input voltage to exceed the supply. The lower zener diode protects the input from both positive and negative static voltages. In addition the '4049 and '4050 can be used as simple buffers or inverters without level translation.

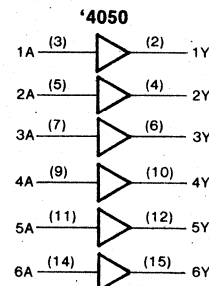
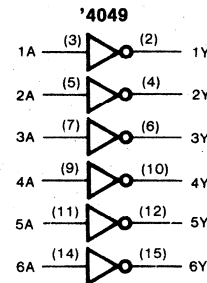
PIN CONFIGURATION



FUNCTION TABLE

| INPUT A | OUTPUT Y | |
|------------|----------|-------|
| | '4049 | '4050 |
| H | L | H |
| L | H | L |

LOGIC DIAGRAMS



Absolute Maximum Ratings*

| | |
|--|---|
| Supply Voltage Range V_{CC} | -0.5V to +7V |
| DC Input Diode Current, I_{IK} | |
| ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) | ± 20 mA |
| DC Output Diode Current, I_{OK} | |
| ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | ± 20 mA |
| Continuous Output Current Per Pin, I_O | |
| ($-0.5V < V_O < V_{CC} + 0.5V$) | ± 35 mA |
| Continuous Current Through | |
| V_{CC} or GND pins | ± 125 mA |
| Storage Temperature Range, T_{stg} | -65°C to $+150^\circ\text{C}$ |
| Power Dissipation Per Package, P_d † | 500 mW |

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

| | |
|----------------------|---|
| Plastic Package (N): | $-12\text{mW}/^\circ\text{C}$ from 65°C to 85°C |
| Ceramic Package (J): | $-12\text{mW}/^\circ\text{C}$ from 100°C to 125°C |

Recommended Operating Conditions

| | |
|--|---|
| Supply Voltage, V_{CC} | 4.5V to 5.5V |
| DC Input & Output Voltages*, V_{IN}, V_{OUT} | 0V to V_{CC} |
| Operating Temperature | |
| Range | KS74HCTLS: -40°C to $+85^\circ\text{C}$ KS54HCTLS: -55°C to $+125^\circ\text{C}$ |
| Input Rise & Fall Times, t_r, t_f | Max 500 ns |

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

| Characteristic | Symbol | Test Conditions | $T_a = 25^\circ\text{C}$ | | KS74HCTLS $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | | KS54HCTLS $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ | | Unit |
|--------------------------------------|-----------------|--|--------------------------|------------------------|---|-------------------|--|-------------------|---------------|
| | | | Typ | Guaranteed Limits | Typ | Guaranteed Limits | Typ | Guaranteed Limits | |
| Minimum High-Level Input Voltage | V_{IH} | | | 2.0 | 2.0 | 2.0 | | | V |
| Maximum Low-Level Input Voltage | V_{IL} | | | 0.8 | 0.8 | 0.8 | | | V |
| Minimum High-Level Output Voltage | V_{OH} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = -20\mu\text{A}$ $I_O = -4\text{mA}$ | V_{CC} 4.2 | $V_{CC} - 0.1$ 3.98 | $V_{CC} - 0.1$ 3.84 | | $V_{CC} - 0.1$ 3.7 | | V |
| Maximum Low-Level Output Voltage | V_{OL} | $V_{IN}=V_{IH}$ or V_{IL} $I_O = 20\mu\text{A}$ $I_O = 4\text{mA}$ $I_O = 8\text{mA}$ | 0 | 0.1 0.26 0.39 | 0.1 0.33 0.5 | | 0.1 0.4 | | V |
| Maximum Input Current | I_{IN} | $V_{IN}=V_{CC}$ or GND $V_{IN}=15V$ | | ± 0.1 | ± 1.0 ± 10.0 | | ± 1.0 ± 10.0 | | μA |
| Maximum Quiescent Supply Current | I_{CC} | $V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$ | | 2.0 | 20.0 | | 40.0 | | μA |
| Additional Worst Case Supply Current | ΔI_{CC} | per input pin $V_I = 2.4V$ other inputs: at V_{CC} or GND $I_{OUT}=0\mu\text{A}$ | | 2.7 | 2.9 | | 3.0 | | mA |

AC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 6$ ns), HCTLS4049, HCTLS4050

| Characteristic | Symbol | Conditions† | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0V$ | | KS74AHCTLS $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | | KS54HCTLS $T_a = -55^\circ\text{C}$ to $+125^\circ\text{C}$ $V_{CC} = 5.0V \pm 10\%$ | | Unit |
|--------------------------------|-----------|---------------------|---|-------------------|--|-------------------|--|-------------------|------|
| | | | Typ | Guaranteed Limits | Typ | Guaranteed Limits | Typ | Guaranteed Limits | |
| Maximum Propagation Delay | t_{PLH} | $C_L = 50\text{pF}$ | 13 | 17 | 21 | | 26 | | ns |
| | t_{PHL} | | 13 | 17 | 21 | | 26 | | |
| Maximum Input Capacitance | C_{IN} | | 5 | | | | | | pF |
| Power Dissipation Capacitance* | C_{PD} | (per gate) | | | | | | | pF |

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.



ENHANCEMENT PROGRAMS 6

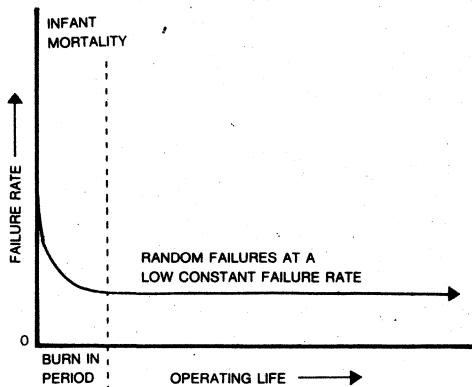
ENHANCEMENT PROGRAMS

SAMSUNG's A+ Program

The SST A+ Program has been designed to offer the customer an alternative to standard off-the-shelf plastic encapsulated CMOS circuits. The A+ Program will significantly reduce incoming inspection requirements as well as early device failures (infant mortality). These results are achieved by a tightened AQL inspection plan and a burn-in of each unit for 160 +8, -0 hours at 125°C or equivalent conditions established from a time/temperature regression curve.

The AQL Plan. Acceptable Quality Levels (AQL) are a measure of the quality of outgoing CMOS circuits. These levels are established by the manufacturer to show the process percent defective being produced and to ensure that the customer is receiving material that meets his requirements. The SST A+ Program has tightened these AQL levels to a point at which incoming inspection by the customer is no longer a necessity. A+ product quality is monitored significantly more closely than standard product; those lots which fail the AQL level are 100% reworked before resubmission to the AQL gate.

The Reliability Plan. Reliability is the statistical probability that a product will give satisfactory performance for a specified period of time when used under specified conditions. A typical rate curve is shown below:



Reliability theory assumes that devices fail according to the above curve. When a group of devices is manufactured a small portion of the units will be inherently weaker than

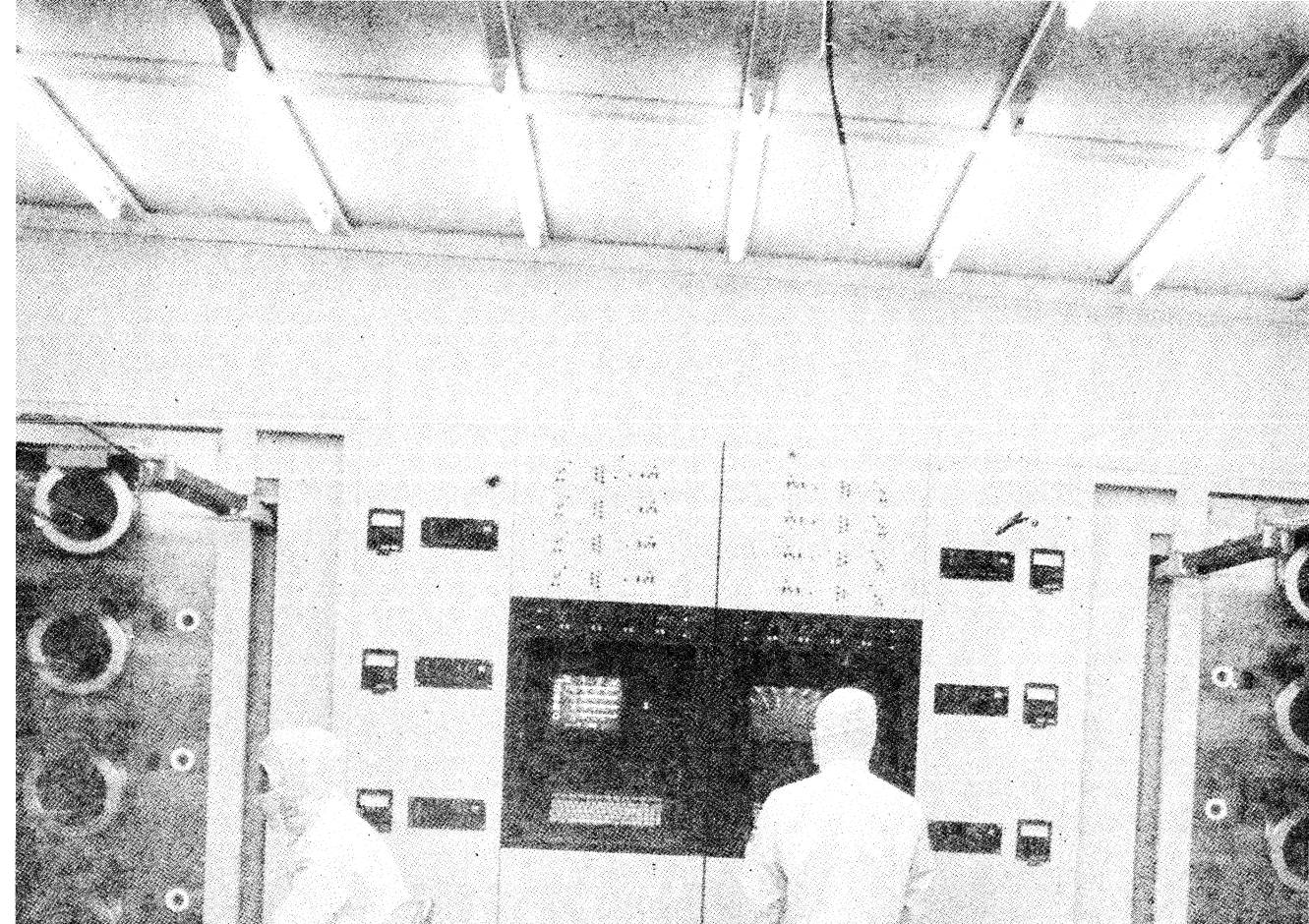
the average. These weak units will *probably* fail during the first few hours of operation—hence the term "infant mortality." If the units are burned-in however, thereby allowing the weak units to fail, there is a much lower probability that those finally put into system use will fail.

The SST A+ Flow. In order to achieve an extremely high quality unit and reduce infant mortality failures the following flow has been established:

Process Flow

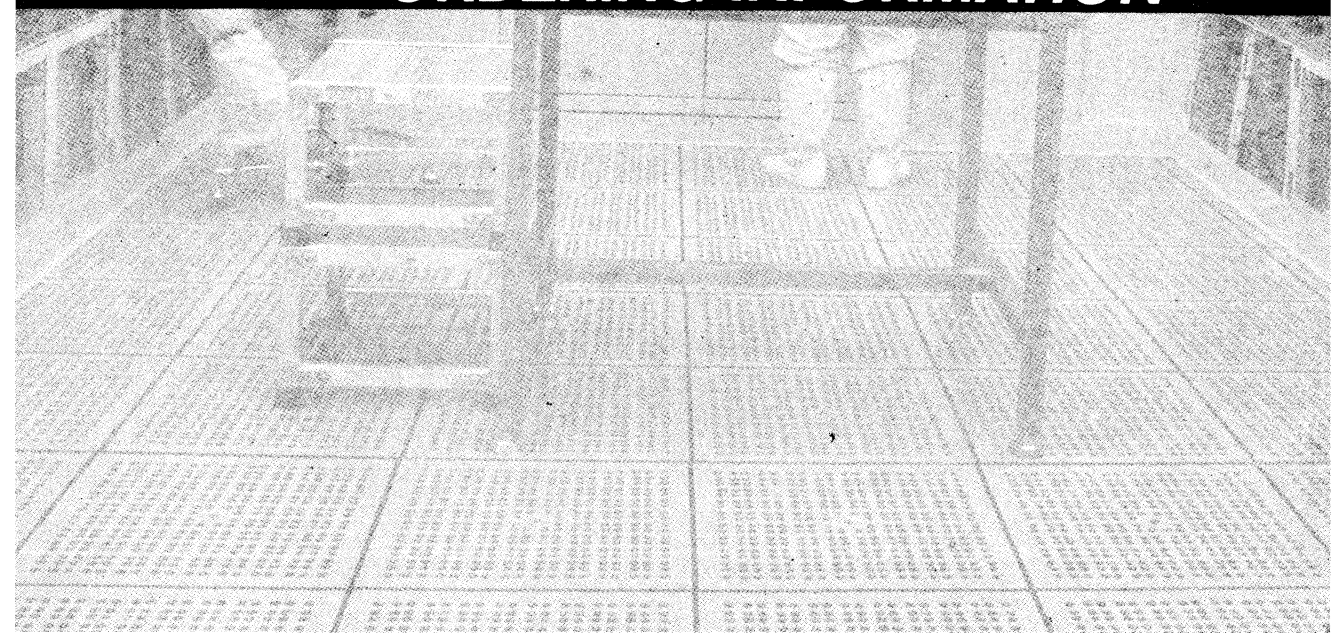
| | DESCRIPTION |
|---|---|
| □ | WAFER FABRICATION CMOS PROCESS CV PLOTS OXIDE AND NITRIDE THICKNESS MEASUREMENTS OPTICAL INSPECTIONS SEM ANALYSIS |
| □ | ENCAPSULATION NITTO HC10 TYPE 2 EPOXY MOLDING COMPOUND ULTRA PURE FOR CMOS APPLICATIONS |
| □ | POST MOLD BAKE 6 HOURS AT 175 DEG. C. CURES PLASTIC STRESSES ALL WIRE BONDS AND DIE |
| □ | O/S FUNCTIONAL ELECTRICAL 100% TESTING OPENS/SHORTS AND INTERMITTENTS REMOVE |
| □ | HIGH TEMPERATURE BURN-IN 160 HOURS AT 125 DEG. C. OR EQUIVALENT CONDITIONS ESTABLISHED FROM A TIME/ TEMPERATURE REGRESSION CURVE. 0.96 eV |
| □ | FULL FUNCTIONAL AND PARAMETRIC ELECTRICAL TESTING 100% ELECTRICAL TESTING AC, DC 88 DEG. C. |
| ■ | THERMAL SHOCK MONITOR -65 DEG. C. TO + 125 DEG. C. LIQUID TO LIQUID 5 CYCLES- SAMPLES SELECTED AT RANDOM |
| □ | TIGHT AQL SAMPLING PLAN ELECTRICAL-0.05% AQL AT 88 DEG. C. MECHANICAL-0.01% AQL CRITICAL & MAJOR |
| □ | SHIP UNITS |

NOTE



**PACKAGE DIMENSIONS &
ORDERING INFORMATION**

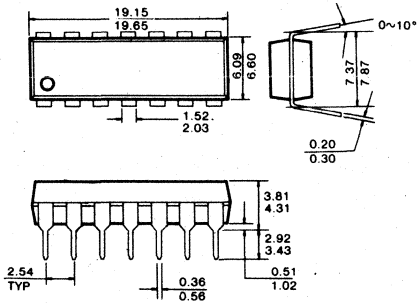
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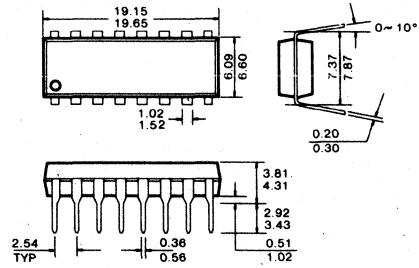
PACKAGE DIMENSIONS

1. PLASTIC PACKAGES

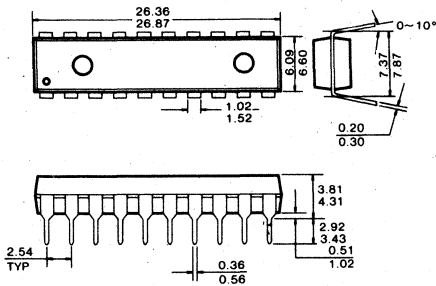
14-Pin Plastic DIP Units: mm



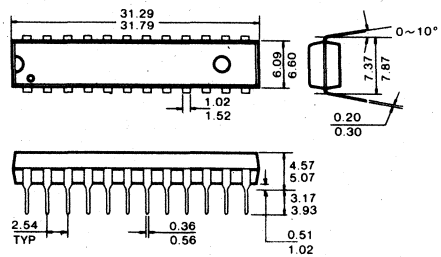
16-Pin Plastic DIP Units: mm



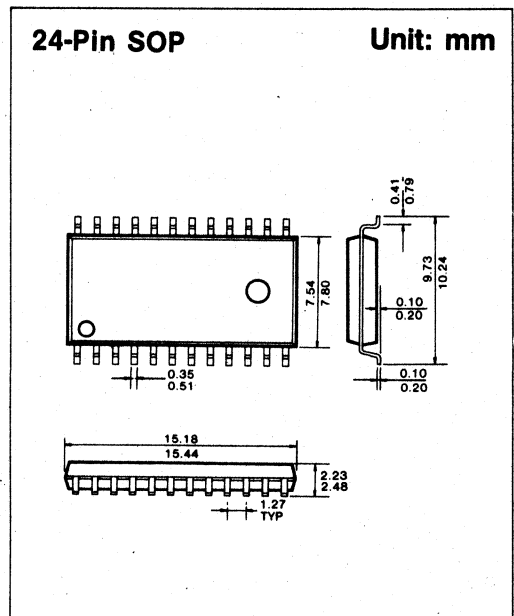
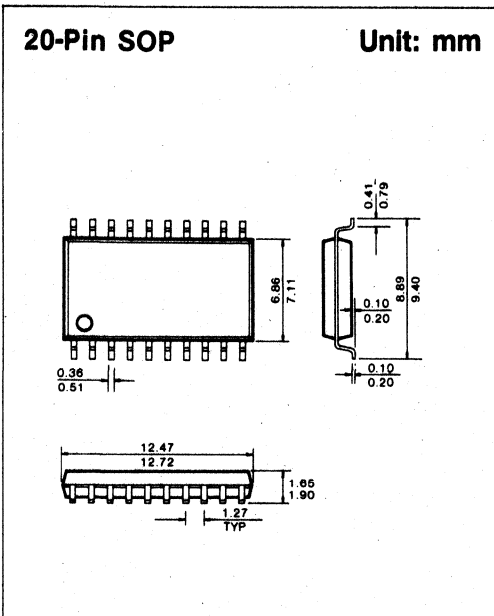
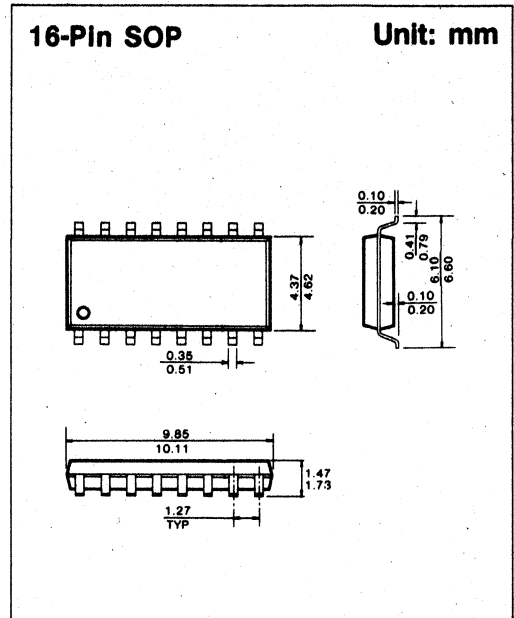
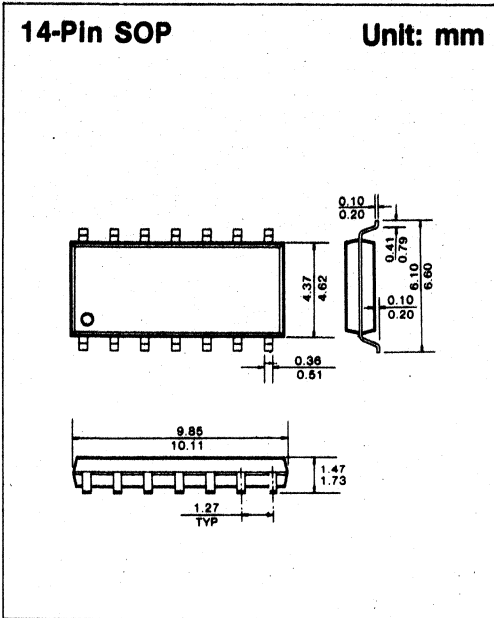
20-Pin Plastic DIP Units: mm



24-Pin Plastic DIP Units: mm



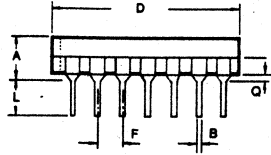
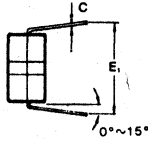
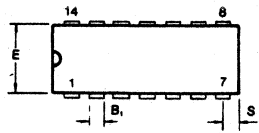
PACKAGE DIMENSIONS



PACKAGE DIMENSIONS

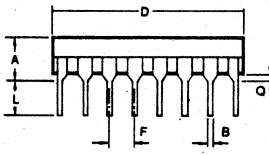
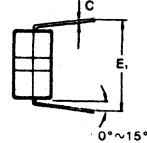
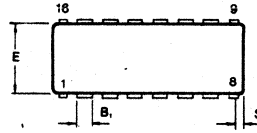
2. CERAMIC PACKAGES

14-Pin Ceramic DIP Units: mm



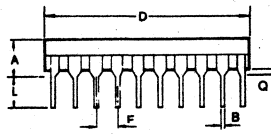
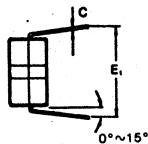
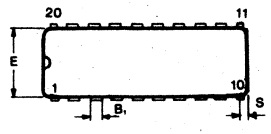
| DIM | Millimeters | |
|----------------|-------------|-------|
| | Min | Max |
| A | — | 5.08 |
| B | 0.38 | 0.58 |
| B ₁ | 1.40 | 1.78 |
| C | 0.20 | 0.38 |
| D | 18.18 | 19.56 |
| E | 6.10 | 7.49 |
| E ₁ | 7.62 | 10.03 |
| F | 2.54 | |
| L | 3.18 | 4.19 |
| Q | 0.51 | 1.02 |
| S | 1.91 | 2.29 |

16-Pin Ceramic DIP Units: mm



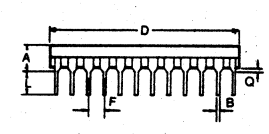
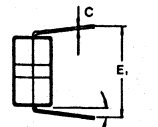
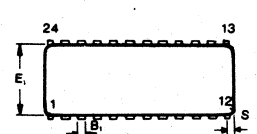
| DIM | Millimeters | |
|----------------|-------------|-------|
| | Min | Max |
| A | — | 5.08 |
| B | 0.38 | 0.58 |
| B ₁ | 1.40 | 1.78 |
| C | 0.20 | 0.38 |
| D | 19.05 | 19.94 |
| E | 6.10 | 7.49 |
| E ₁ | 7.62 | 10.03 |
| F | 2.54 | |
| L | 3.18 | 4.19 |
| Q | 0.51 | 1.02 |
| S | 0.51 | 1.14 |

20-Pin Ceramic DIP Units: mm



| DIM | Millimeters | |
|----------------|-------------|-------|
| | Min | Max |
| A | 4.06 | 5.08 |
| B | 0.38 | 0.53 |
| B ₁ | 1.14 | 1.52 |
| C | 0.20 | 0.38 |
| D | 25.78 | 25.93 |
| E | 6.10 | 6.60 |
| E ₁ | 7.77 | 7.98 |
| F | 2.54 | |
| L | 3.73 | 4.01 |
| Q | 0.38 | 0.89 |
| S | 0.51 | 1.14 |

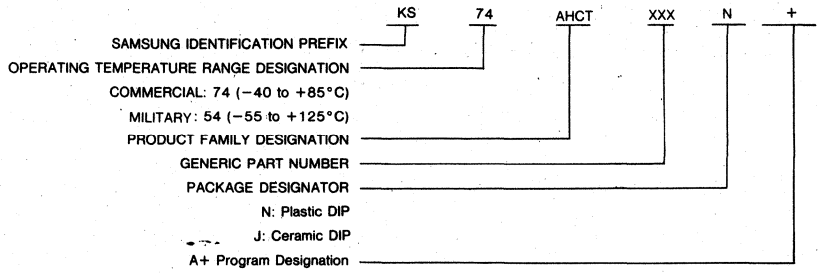
24-Pin Ceramic DIP Units: mm



| DIM | Millimeters | |
|----------------|-------------|-------|
| | Min | Max |
| A | 4.06 | 5.08 |
| B | 0.38 | 0.53 |
| B ₁ | 1.14 | 1.52 |
| C | 0.20 | 0.38 |
| D | 31.50 | 32.64 |
| E | 7.24 | 7.75 |
| E ₁ | 7.77 | 7.98 |
| F | 2.54 | |
| L | 3.73 | 4.01 |
| Q | 0.508 | 1.778 |
| S | 1.85 | 1.93 |

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The ensure prompt and accurate processing of your order, please use the product code system as described in the following example.





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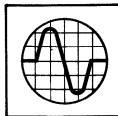
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Tlx: 26777 YOSUNIND
Fax: (02) 503-1278

KENTOP ELECTROICS CO., LTD.

5F-3, 21st CENTURY BLDG.,
NO. 207, TUN-HWA N. RD., TAIPEI
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ADO ELECTRONIC INDUSTRIAL CO., LTD.

7th FL., SASAGE BLDG. 4-6 SOTOKANDA
2-CHOME CHIYODA-KU, TOKYO 101, JAPAN
Tel: 03-257-1618
Fax: 03-257-1579

INTERCOMPO INC.

IHI BLDG, 1-6-7, SHIBUYA, SHIBUYA-KU:
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Tel: 03-406-5612
Fax: 03-409-4834

C. ITOH TECHNOLOGICAL CO., LTD.

A A BLDG 2-9-16 KITA AOYAMA, MINATO-KU
TOKYO 107 JAPAN
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SHINJUKU, SHINJUKU—KU, TOKYO 163 JAPAN
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Fax: 03-344-3949

TOMEN ELECTRONICS CORP.

1-1, USCHISAIWAI—CHO 2 CHOME
CHIYODA—KU TOKYO, 100
Tel: 03-506-3473
Fax: 03-506-3497

DIA SEMICON SYSTEMS INC.

WACORE 64 1-37-8 SANGENJAYA
SETAGAYA—KU TOKYO 154 JAPAN
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Fax: 03-487-8088

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SINTAI HANG TRADING PTE LTD.

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SINGAPORE 1130
Tel: 253-7711
Tlx: 33294 GOGOCO
Fax: 65-253 0610

INDIA

MURUGAPPA ELECTRONICS LTD.

PARRRY HOUSE' 3rd floor 43 Moore Street
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Tlx: 041-8797 HIL IN.

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**SAMSUNG
LIGHT-ELECTRONICS CO., LTD.**

149-Jang Sa Dong
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Tel: 744-2110, 273-1036

SEGYUNG ELECTRONICS

182-2 Jang Sa Dong
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**NEW CASTLE
SEMICONDUCTOR CO., LTD.**

123-1, Joo Kyo Dong
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